

DISCRETE DATABOOK

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Active Components Division

DISCRETE DATABOOK

NATIONAL SEMICONDUCTOR

NPN Transistors

PNP Transistors

Pro Electron Series

JEIDA Series

NA/NB/NR Series

Process Characteristics

Double-Diffused Epitaxial Transistors

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3083262, 3189758, 3231797, 3303356, 3317671, 3323071,
3381071, 3408542, 3421025, 3426423, 3440498, 3518750,
3519897, 3557431, 3560765, 3566218, 3571630, 3575609,
3579059, 3593069, 3597640, 3607469, 3617859, 3631312,
3633052, 3638131, 3648071, 3651565, 3693248.

Introduction

National Semiconductor has added many new transistors and product families since publication of the last handbook. Many have already been widely acclaimed by users.

In addition to small signal, bipolar and field effect transistors that have been the mainstay of our catalog, there are sections for multiple bipolar, multiple field effect and power transistors. More part numbers will be added as market needs expand.

To keep current on all new National transistors please contact your National sales representative or franchised distributor and ask to be placed on the customer mailing list.

HOW TO USE THIS CATALOG

If you know the part/type number
 Turn to the standard parts listing which begins on page 9 and find the desired part number. The electrical specifications page number will be shown. The list also identifies the process number from which that product is selected and the particular package code in which it is assembled. Package codes are cross-referenced to JEDEC code on page A-19.

If performance data is required, turn to the process data sheet indicated in the standard parts listing. Process data sheets are indexed in numerical order and begin on page 6-2.

Refer to the package outlines section beginning on page A-14 for complete physical dimensions.

If you know the application
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Refer to the process sheet which will give you the performance specifications and a reference part type.

To convert a metal can transistor to a molded epoxy type, find the equivalent part number on page 25.

To convert a TO-105/TO-106 product type to a molded epoxy type, find the correct part number on page 26.

If you are looking for a JAN/JANTX/JANTXV type, a complete product listing for bipolar and junction FET types is on page 23.

If none of the above work, refer to the Table of Contents which contains all NSC part types organized by general applications.

In desperation—call your local National representative or field office.

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Transistor Standard Parts List

Transistor Standard Parts List

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| 2N3249 | 2-2 | 64 | 18 | 2N3501JTXV | 1-31 | 08 | 09 | 2N3702 | 2-13 | 63 | 74 |
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| BC168C | 3-4 | 04 | 74 | BC237B-92 | 3-8 | 04 | 77 | BC547C | 3-13 | 04 | 77 |
| BC169 | 3-4 | 04 | 74 | BC238-92 | 3-9 | 04 | 77 | BC548 | 3-14 | 04 | 77 |
| BC169B | 3-4 | 04 | 74 | BC238A-92 | 3-9 | 04 | 77 | BC548A | 3-14 | 04 | 77 |
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| BC549 | 3-14 | 04 | 77 | BD240C | 3-18 | 5F(3C) | 37 | BD373B | 3-22 | | 38 |
| BC549B | 3-14 | 04 | 77 | BD241 | 3-18 | 4F(2C) | 37 | BD373B-10 | 3-22 | | 38 |
| BC549C | 3-14 | 04 | 77 | BD241A | 3-18 | 4F(2C) | 37 | BD373B-16 | 3-22 | | 38 |
| BC550 | 3-14 | 04 | 77 | BD241B | 3-18 | 4F(2C) | 37 | BD373B-25 | 3-22 | | 38 |
| BC550B | 3-14 | 04 | 77 | BD241C | 3-18 | 4F(2C) | 37 | BD373C | 3-22 | | 38 |
| BC550C | 3-14 | 04 | 77 | BD242 | 3-18 | 5E(3E) | 37 | BD373C-6 | 3-22 | | 38 |
| BC557 | 3-14 | 71 | 77 | BD242A | 3-18 | 5E(3E) | 37 | BD373C-10 | 3-22 | | 38 |
| BC557A | 3-14 | 71 | 77 | BD242B | 3-19 | 5E(3E) | 37 | BD373C-16 | 3-22 | | 38 |
| BC557B | 3-14 | 71 | 77 | BD242C | 3-19 | 5E(3E) | 37 | BD373D | 3-22 | | 39 |
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| BC559A | 3-15 | 71 | 77 | BD370B-10 | 3-19 | 78 | 91 | BD375-16 | 3-22 | | 38 |
| BC559B | 3-15 | 71 | 77 | BD370B-16 | 3-19 | 78 | 91 | BD375-25 | 3-22 | | 38 |
| BC559C | 3-15 | 71 | 77 | BD370B-25 | 3-19 | 78 | 91 | BD376 | 3-22 | | 78 |
| BC560 | 3-15 | 71 | 77 | BD370C | 3-19 | 78 | 91 | BD376-6 | 3-22 | | 78 |
| BC560A | 3-15 | 71 | 77 | BD370C-6 | 3-19 | 78 | 91 | BD376-10 | 3-22 | | 78 |
| BC560B | 3-15 | 71 | 77 | BD370C-10 | 3-19 | 78 | 91 | BD376-16 | 3-23 | | 78 |
| BC560C | 3-16 | 71 | 77 | BD370C-16 | 3-19 | 78 | 91 | BD376-25 | 3-23 | | 78 |
| BCY56 | 3-16 | 04 | 02 | BD370C | 3-19 | 79 | 91 | BD377 | 3-23 | | 38 |
| BCY57 | 3-16 | 04 | 02 | BD370C-6 | 3-19 | 79 | 91 | BD377-6 | 3-23 | | 38 |
| BCY58 | 3-16 | 04 | 02 | BD370C-10 | 3-20 | 79 | 91 | BD377-10 | 3-23 | | 38 |
| BCY58-7 | 3-16 | 04 | 02 | BD371A | 3-20 | 37 | 91 | BD377-16 | 3-23 | | 38 |
| BCY58-8 | 3-16 | 04 | 02 | BD371A-10 | 3-20 | 37 | 91 | BD377-25 | 3-23 | | 38 |
| BCY58-9 | 3-16 | 04 | 02 | BD371A-16 | 3-20 | 37 | 91 | BD378 | 3-23 | | 78 |
| BCY58-10 | 3-16 | 04 | 02 | BD371A-25 | 3-20 | 37 | 91 | BD378-6 | 3-23 | | 78 |
| BCY59 | 3-16 | 04 | 02 | BD371B | 3-20 | 38 | 91 | BD378-10 | 3-23 | | 78 |
| BCY59-7 | 3-16 | 04 | 02 | BD371B-10 | 3-20 | 38 | 91 | BD378-16 | 3-23 | | 78 |
| BCY59-8 | 3-16 | 04 | 02 | BD371B-16 | 3-20 | 38 | 91 | BD378-25 | 3-23 | | 78 |
| BCY59-9 | 3-16 | 04 | 02 | BD371B-25 | 3-20 | 38 | 91 | BD379 | 3-23 | | 39 |
| BCY59-10 | 3-16 | 04 | 02 | BD371C | 3-20 | 38 | 91 | BD379-6 | 3-23 | | 39 |
| BCY70 | 3-17 | 71 | 02 | BD371C-6 | 3-20 | 38 | 91 | BD379-10 | 3-23 | | 39 |
| BCY71 | 3-17 | 71 | 02 | BD371C-10 | 3-20 | 38 | 91 | BD379-16 | 3-23 | | 39 |
| BCY71A | 3-17 | 71 | 02 | BD371C-16 | 3-20 | 38 | 91 | BD379-25 | 3-24 | | 39 |
| BCY72 | 3-17 | 71 | 02 | BD371C | 3-20 | 39 | 91 | BD380 | 3-24 | | 79 |
| BD135 | 3-17 | 37 | 38 | BD371C-6 | 3-20 | 39 | 91 | BD380-6 | 3-24 | | 79 |
| BD136 | 3-17 | 77 | 38 | BD371C-10 | 3-20 | 39 | 91 | BD380-10 | 3-24 | | 79 |
| BD137 | 3-17 | 38 | 38 | BD372A | 3-20 | 78 | 90 | BD380-16 | 3-24 | | 79 |
| BD138 | 3-17 | 78 | 38 | BD372A-10 | 3-20 | 78 | 90 | BD380-25 | 3-24 | | 79 |
| BD139 | 3-17 | 39 | 38 | BD372A-16 | 3-20 | 78 | 90 | BD433 | 3-24 | | 2E |
| BD140 | 3-17 | 79 | 38 | BD372A-25 | 3-21 | 78 | 90 | BD434 | 3-24 | | 3E |
| BD201 | 3-17 | 4A | 37 | BD372B | 3-21 | 78 | 90 | BD435 | 3-24 | | 2E |
| BD202 | 3-17 | 5A | 37 | BD372B-10 | 3-21 | 78 | 90 | BD436 | 3-24 | | 3E |
| BD233 | 3-17 | 2C | 37 | BD372B-16 | 3-21 | 78 | 90 | BD437 | 3-24 | | 2E |
| BD234 | 3-18 | 3C | 38 | BD372B-25 | 3-21 | 78 | 90 | BD438 | 3-24 | | 3E |
| BD235 | 3-18 | 2C | 38 | BD372C | 3-21 | 78 | 90 | BD439 | 3-24 | | 2E |
| BD236 | 3-18 | 3C | 38 | BD372C-6 | 3-21 | 78 | 90 | BD440 | 3-24 | | 3E |
| BD237 | 3-18 | 2C | 38 | BD372C-10 | 3-21 | 78 | 90 | BD441 | 3-24 | | 2E |
| BD238 | 3-18 | 3C | 38 | BD372C-16 | 3-21 | 78 | 90 | BD442 | 3-25 | | 3E |
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| BD239B | 3-18 | 4F(2C) | 37 | BD372D-10 | 3-21 | 79 | 90 | BD535 | 3-25 | | 4E(2E) |
| BD239C | 3-18 | 4F(2C) | 37 | BD373A | 3-21 | 37 | 90 | BD536 | 3-25 | | 5E(3E) |
| BD240 | 3-18 | 5F(3C) | 37 | BD373A-10 | 3-21 | 37 | 90 | BD537 | 3-25 | | 4E(2E) |
| BD240A | 3-18 | 5F(3C) | 37 | BD373A-16 | 3-21 | 37 | 90 | BD538 | 3-25 | | 5E(3E) |

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| BD634 | 3-25 | 5F(3C) | 37 | BFX87 | 3-29 | 63 | 04 | D40D11 | 1-34 | 38 | 35 |
| BD635 | 3-25 | 4F(2C) | 37 | BFX88 | 3-29 | 63 | 04 | D40D13 | 1-34 | 38 | 35 |
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| BD637 | 3-25 | 4F(2C) | 37 | BFY76 | 3-29 | 07 | 02 | D40E1 | 1-35 | 38 | 35 |
| BD638 | 3-25 | 5F(3C) | 37 | BSX21 | 3-29 | 07 | 02 | D40E5 | 1-35 | 38 | 35 |
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| BD675A | 3-26 | 2J | 38 | BSX45-10 | 3-29 | 14 | 10 | D40N1 | 1-35 | 48 | 35 |
| BD676 | 3-26 | 3J | 38 | BSX45-16 | 3-29 | 14 | 10 | D40N2 | 1-35 | 48 | 35 |
| BD676A | 3-26 | 3J | 38 | BSX46-6 | 3-29 | 14 | 10 | D40N3 | 1-35 | 48 | 35 |
| BD677 | 3-26 | 2J | 38 | BSX46-10 | 3-29 | 14 | 10 | D40N4 | 1-35 | 48 | 35 |
| BD677A | 3-26 | 2J | 38 | BSX46-16 | 3-29 | 14 | 10 | D40N5 | 1-35 | 48 | 35 |
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| BD678A | 3-26 | 3J | 38 | BSX88 | 3-29 | 21 | 18 | D41D2 | 2-22 | 78 | 35 |
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| BD679A | 3-26 | 2J | 38 | BSY39 | 3-30 | 21 | 18 | D41D5 | 2-22 | 78 | 35 |
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| BD680A | 3-26 | 3J | 38 | BSY52 | 3-30 | 20 | 04 | D41D8 | 2-22 | 78 | 35 |
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| BD682 | 3-26 | 3J | 38 | BSY54 | 3-30 | 20 | 04 | D41D11 | 2-22 | 78 | 35 |
| BD733 | 3-26 | 4F(2C) | 37 | BSY95A | 3-30 | 21 | 02 | D41D13 | 2-22 | 78 | 35 |
| BD734 | 3-26 | 5E(3E) | 37 | CS9011 | 4-4 | 27 | 72 | D41D14 | 2-22 | 78 | 35 |
| BD735 | 3-26 | 4F(2C) | 37 | CS9012 | 4-4 | 60 | 72 | D41E1 | 2-22 | 78 | 35 |
| BD736 | 3-26 | 5E(3E) | 37 | CS9013 | 4-4 | 09 | 72 | D41E5 | 2-22 | 78 | 35 |
| BD737 | 3-26 | 4F(2C) | 37 | CS9014 | 4-4 | 04 | 72 | D41E7 | 2-22 | 78 | 35 |
| BD738 | 3-26 | 5E(3E) | 37 | CS9015 | 4-4 | 71 | 72 | D42C1 | 1-35 | 37 | 36 |
| BF167 | 3-26 | 45 | 28 | CS9016 | 4-4 | 44 | 72 | D42C2 | 1-35 | 37 | 36 |
| BF180 | 3-26 | 41 | 25 | CS9018 | 4-4 | 43 | 72 | D42C3 | 1-35 | 37 | 36 |
| BF181 | 3-26 | 41 | 25 | DH3467CD | 2-4 | 70 | 40 | D42C4 | 1-35 | 37 | 36 |
| BF182 | 3-26 | 41 | 25 | DH3467CN | 2-4 | 70 | 39 | D42C5 | 1-35 | 37 | 36 |
| BF194 | 3-26 | 46 | 78 | DH3468CD | 2-4 | 70 | 40 | D42C6 | 1-35 | 37 | 36 |
| BF195 | 3-27 | 46 | 78 | DH3468CN | 2-4 | 70 | 39 | D42C7 | 1-36 | 38 | 36 |
| BF196 | 3-27 | 45 | 78 | DH3724CD | 1-5 | 25 | 40 | D42C8 | 1-36 | 38 | 36 |
| BF197 | 3-27 | 47 | 78 | DH3724CN | 1-5 | 25 | 39 | D42C9 | 1-36 | 38 | 36 |
| BF198 | 3-27 | 45 | 78 | DH3725CD | 1-5 | 25 | 40 | D42C10 | 1-36 | 38 | 36 |
| BF199 | 3-27 | 47 | 78 | DH3725CN | 1-5 | 25 | 39 | D42C11 | 1-36 | 38 | 36 |
| BF200 | 3-27 | 41 | 25 | D40C1 | 1-50 | 05 | 35 | D42C12 | 1-36 | 38 | 36 |
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| BF233-3 | 3-27 | 49 | 71 | D40C3 | 1-50 | 05 | 35 | D43C2 | 2-22 | 77 | 36 |
| BF233-4 | 3-27 | 49 | 71 | D40C4 | 1-50 | 05 | 35 | D43C3 | 2-22 | 77 | 36 |
| BF233-5 | 3-27 | 49 | 71 | D40C5 | 1-50 | 05 | 35 | D43C4 | 2-22 | 77 | 36 |
| BF240 | 3-27 | 47 | 78 | D40C7 | 1-50 | 05 | 35 | D43C5 | 2-23 | 77 | 36 |
| BF241 | 3-27 | 47 | 78 | D40C8 | 1-50 | 05 | 35 | D43C6 | 2-23 | 77 | 36 |
| BF254 | 3-27 | 46 | 78 | D40D1 | 1-34 | 38 | 35 | D43C7 | 2-23 | 78 | 36 |
| BF255 | 3-27 | 46 | 78 | D40D2 | 1-34 | 38 | 35 | D43C8 | 2-23 | 78 | 36 |
| BF257 | 3-27 | 48 | 10 | D40D3 | 1-34 | 38 | 35 | D43C9 | 2-23 | 78 | 36 |
| BF258 | 3-27 | 48 | 10 | D40D4 | 1-34 | 38 | 35 | D43C10 | 2-23 | 78 | 36 |
| BF259 | 3-28 | 48 | 10 | D40D5 | 1-34 | 38 | 35 | D43C11 | 2-23 | 78 | 36 |
| BF457 | 3-28 | 48 | 38 | D40D7 | 1-34 | 38 | 35 | D43C12 | 2-23 | 78 | 36 |
| BF458 | 3-28 | 48 | 38 | D40D8 | 1-34 | 38 | 35 | D44C1 | 1-43 | 4F(2C) | 37 |
| BF459 | 3-28 | 48 | 38 | | | | | D44C2 | 1-43 | 4F(2C) | 37 |
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| BFX29 | 3-28 | 63 | 04 | | | | | D44C4 | 1-44 | 4F(2C) | 37 |
| BFX30 | 3-28 | 63 | 04 | | | | | D44C5 | 1-44 | 4F(2C) | 37 |
| BFX37 | 3-28 | 62 | 02 | | | | | D44C6 | 1-44 | 4E(2E) | 37 |
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| 2N3994A | 88/23 | 8-12 | 9-20 | 2N5245 | 90/77 | 8-4 | 9-24 |
| 2N4084 | 83/12 | 8-8 | 9-15 | 2N5246 | 90/77 | 8-4 | 9-24 |
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• Denotes JAN qualified type

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| 2N5459 | 55/72 | 8-7 | 9-11 | BF244A | 50/74 | 8-13 | 9-2 |
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| 2N5461 | 89/71 | 8-13 | 9-22 | BF244C | 50/74 | 8-13 | 9-2 |
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| 2N5485 | 50/72 | 8-4 | 9-2 | BF245C | 50/77 | 8-13 | 9-2 |
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| 2N5524 | 95/12 | 8-10 | 9-32 | J109 | 58/72 | 8-3 | 9-13 |
| 2N5545 | *83/12 | 8-9 | 9-15 | J110 | 58/72 | 8-3 | 9-13 |
| 2N5546 | *83/12 | 8-9 | 9-15 | J111 | 51/72 | 8-3 | 9-5 |
| 2N5547 | *83/12 | 8-9 | 9-15 | J112 | 51/72 | 8-3 | 9-5 |
| 2N5555 | 50/72 | 8-2 | 9-2 | J113 | 51/72 | 8-3 | 9-5 |
| 2N5556 | 50/25 | 8-7 | 9-2 | J114 | 90/72 | 8-3 | 9-24 |
| 2N5557 | 50/25 | 8-7 | 9-2 | J174 | 88/74 | 8-12 | 9-20 |
| 2N5558 | 50/25 | 8-7 | 9-2 | J175 | 88/74 | 8-12 | 9-20 |
| 2N5561 | †98/12 | 8-9 | 9-36 | J176 | 88/74 | 8-12 | 9-20 |
| 2N5562 | †98/12 | 8-9 | 9-36 | J177 | 88/74 | 8-12 | 9-20 |
| 2N5563 | †98/12 | 8-9 | 9-36 | J201 | 52/72 | 8-7 | 9-7 |
| 2N5564 | 96/12 | 8-10 | 9-34 | J202 | 52/72 | 8-7 | 9-7 |
| 2N5565 | 96/12 | 8-10 | 9-34 | J203 | 52/72 | 8-7 | 9-7 |
| 2N5566 | 96/12 | 8-10 | 9-34 | J210 | 90/72 | 8-7 | 9-24 |
| 2N5638 | 51/72 | 8-3 | 9-5 | J211 | 90/72 | 8-7 | 9-24 |
| 2N5639 | 51/72 | 8-3 | 9-5 | J212 | 90/72 | 8-7 | 9-24 |
| 2N5640 | 51/72 | 8-3 | 9-5 | J270 | 88/74 | 8-13 | 9-20 |
| 2N5653 | 51/72 | 8-3 | 9-5 | J271 | 88/74 | 8-13 | 9-20 |
| 2N5654 | 51/72 | 8-3 | 9-5 | J300 | 90/72 | 8-4 | 9-24 |
| 2N5668 | 50/72 | 8-4 | 9-2 | J304 | 50/72 | 8-4 | 9-2 |
| 2N5659 | 50/72 | 8-4 | 9-2 | J305 | 50/72 | 8-4 | 9-2 |
| 2N5670 | 50/72 | 8-4 | 9-2 | J308 | 92/72 | 8-4 | 9-26 |
| 2N5902 | 84/24 | 8-11 | 9-17 | J309 | 92/72 | 8-4 | 9-26 |
| 2N5903 | 84/24 | 8-11 | 9-17 | J310 | 92/72 | 8-4 | 9-26 |
| 2N5904 | 84/24 | 8-11 | 9-17 | J401 | †98/60 | 8-9 | 9-36 |
| 2N5905 | 84/24 | 8-11 | 9-17 | J402 | †98/60 | 8-9 | 9-36 |
| 2N5906 | 84/24 | 8-11 | 9-17 | J403 | †98/60 | 8-9 | 9-36 |
| 2N5907 | 84/24 | 8-11 | 9-17 | J404 | †98/60 | 8-9 | 9-36 |
| 2N5908 | 84/24 | 8-11 | 9-17 | J405 | †98/60 | 8-9 | 9-36 |
| 2N5909 | 84/24 | 8-11 | 9-17 | J406 | †98/60 | 8-9 | 9-36 |
| 2N5911 | 93/24 | 8-10 | 9-28 | J410 | 83/60 | 8-9 | 9-15 |

*JAN qualification pending. Consult factory.

†Process in development

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| J411 | 83/60 | 8-9 | 9-15 | PN4856 | 51/72 | 8-3 | 9-5 |
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| MPF103 | 55/72 | 8-7 | 9-11 | PN4859 | 51/72 | 8-3 | 9-5 |
| MPF104 | 55/72 | 8-7 | 9-11 | PN4860 | 51/72 | 8-3 | 9-5 |
| MPF105 | 55/72 | 8-7 | 9-11 | PN4861 | 51/72 | 8-3 | 9-5 |
| MPF106 | 50/72 | 8-5 | 9-2 | PN5033 | 89/71 | 8-13 | 9-22 |
| MPF107 | 50/72 | 8-5 | 9-2 | PN5163 | 50/72 | 8-8 | 9-2 |
| MPF108 | 55/72 | 8-5 | 9-11 | TIS58 | 50/74 | 8-8 | 9-2 |
| MPF109 | 55/72 | 8-7 | 9-11 | TIS59 | 50/74 | 8-8 | 9-2 |
| MPF111 | 50/72 | 8-8 | 9-2 | TIS73 | 51/77 | 8-3 | 9-5 |
| MPF112 | 55/72 | 8-8 | 9-11 | TIS74 | 51/77 | 8-3 | 9-5 |
| NDF9401 | 94/24 | 8-11 | 9-30 | TIS75 | 51/77 | 8-3 | 9-5 |
| NDF9402 | 94/24 | 8-11 | 9-30 | U1897E | 51/72 | 8-3 | 9-5 |
| NDF9403 | 94/24 | 8-11 | 9-30 | U1898E | 51/72 | 8-3 | 9-5 |
| NDF9404 | 94/24 | 8-11 | 9-30 | U1899E | 51/72 | 8-3 | 9-5 |
| NDF9405 | 94/24 | 8-11 | 9-30 | U231 | 83/12 | 8-9 | 9-15 |
| NDF9406 | 94/12 | 8-11 | 9-30 | U232 | 83/12 | 8-9 | 9-15 |
| NDF9407 | 94/12 | 8-11 | 9-30 | U233 | 83/12 | 8-9 | 9-15 |
| NDF9408 | 94/12 | 8-11 | 9-30 | U234 | 83/12 | 8-9 | 9-15 |
| NDF9409 | 94/12 | 8-11 | 9-30 | U235 | 83/12 | 8-9 | 9-15 |
| NDF9410 | 94/12 | 8-11 | 9-30 | U257 | 93/24 | 8-10 | 9-28 |
| NF5101 | 51/25 | 8-5 | 9-5 | U301 | 88/11 | 8-13 | 9-20 |
| NF5102 | 51/25 | 8-5 | 9-5 | U304 | 88/11 | 8-12 | 9-20 |
| NF5103 | 51/25 | 8-5 | 9-5 | U305 | 88/11 | 8-12 | 9-20 |
| NPD5564 | 96/67 | 8-10 | 9-34 | U306 | 88/11 | 8-12 | 9-20 |
| NPD5565 | 96/67 | 8-10 | 9-34 | U308 | 92/07 | 8-5 | 9-26 |
| NPD5566 | 96/67 | 8-10 | 9-34 | U309 | 92/07 | 8-5 | 9-26 |
| NPD8301 | 83/67 | 8-9 | 9-15 | U310 | 92/07 | 8-5 | 9-26 |
| NPD8302 | 83/67 | 8-9 | 9-15 | U312 | 90/07 | 8-5 | 9-24 |
| NPD8303 | 83/67 | 8-9 | 9-15 | U320 | 58/09 | 8-5 | 9-13 |
| NPD9801 | †98/67 | 8-9 | | U321 | 58/09 | 8-5 | 9-13 |
| NPD9802 | †98/67 | 8-9 | | U322 | 58/09 | 8-5 | 9-13 |
| NPD9803 | †98/67 | 8-9 | | U401 | †98/12 | 8-9 | 9-36 |
| P1086E | 88/71 | 8-12 | 9-20 | U402 | †98/12 | 8-9 | 9-36 |
| P1087E | 88/71 | 8-12 | 9-20 | U403 | †98/12 | 8-9 | 9-36 |
| PF5101 | 51/72 | 8-5 | 9-5 | U404 | †98/12 | 8-9 | 9-36 |
| PF5102 | 51/72 | 8-5 | 9-5 | U405 | †98/12 | 8-9 | 9-36 |
| PF5103 | 51/72 | 8-5 | 9-5 | U406 | †98/12 | 8-9 | 9-36 |
| PN3684 | 52/72 | 8-8 | 9-7 | U421 | †86/24 | 8-11 | 9-19 |
| PN3685 | 52/72 | 8-8 | 9-7 | U422 | †86/24 | 8-11 | 9-19 |
| PN3686 | 52/72 | 8-8 | 9-7 | U423 | †86/24 | 8-11 | 9-19 |
| PN3687 | 52/72 | 8-8 | 9-7 | U424 | †86/24 | 8-11 | 9-19 |
| PN4091 | 51/72 | 8-3 | 9-5 | U425 | †86/24 | 8-11 | 9-19 |
| PN4092 | 51/72 | 8-3 | 9-5 | U426 | †86/24 | 8-11 | 9-19 |
| PN4093 | 51/72 | 8-3 | 9-5 | U430 | 92/24 | 8-10 | 9-26 |
| PN4220 | 55/72 | 8-8 | 9-11 | U431 | 92/24 | 8-10 | 9-26 |
| PN4221 | 55/72 | 8-8 | 9-11 | | | | |
| PN4222 | 55/72 | 8-8 | 9-11 | | | | |
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| PN4224 | 50/72 | 8-5 | 9-2 | | | | |
| PN4302 | 52/72 | 8-8 | 9-7 | | | | |
| PN4303 | 52/72 | 8-8 | 9-7 | | | | |
| PN4304 | 52/72 | 8-8 | 9-7 | | | | |
| PN4342 | 89/71 | 8-13 | 9-22 | | | | |
| PN4360 | 89/71 | 8-13 | 9-22 | | | | |
| PN4391 | 51/72 | 8-3 | 9-5 | | | | |
| PN4392 | 51/72 | 8-3 | 9-5 | | | | |
| PN4393 | 51/72 | 8-3 | 9-5 | | | | |
| PN4416 | 50/72 | 8-5 | 9-2 | | | | |

†Process in development

MIL-STD Qualifications

MIL-STD-19500 Qualifications

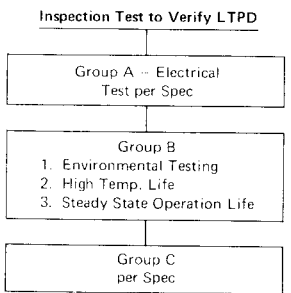
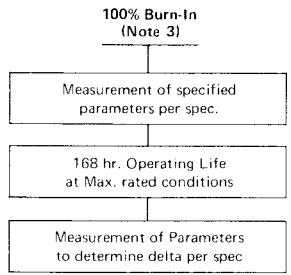
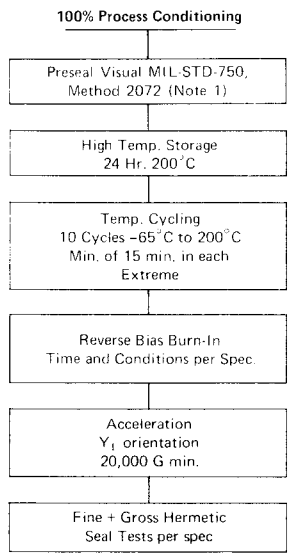
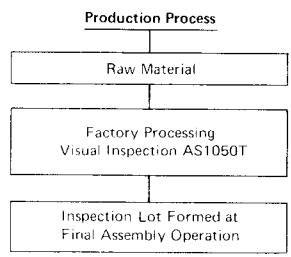
| TYPE | DETAIL SPEC. | QUALIFICATION | | | TYPE | DETAIL SPEC. | QUALIFICATION | | |
|---------|--------------|---------------|-----|------|---------|--------------|---------------|-----|------|
| | | JAN | JTX | JTXV | | | JAN | JTX | JTXV |
| 2N918 | 301 | X | X | X | 2N2920 | 355 | X | X | X |
| 2N929 | 253 | X | X | | 2N3019 | 391 | X | X | X |
| 2N930 | 253 | X | X | | 2N3250A | 323 | X | X | X |
| 2N2218 | 251 | X | X | X | 2N3251A | 323 | X | X | X |
| 2N2218A | 251 | X | X | X | 2N3498 | 366 | X | X | X |
| 2N2219 | 251 | X | X | X | 2N3499 | 366 | X | X | X |
| 2N2219A | 251 | X | X | X | 2N3500 | 366 | X | X | X |
| 2N2221 | 255 | X | X | X | 2N3501 | 366 | X | X | X |
| 2N2221A | 255 | X | X | X | 2N3700 | 391 | X | X | X |
| 2N2222 | 255 | X | X | X | 2N3810 | 366 | X | X | X |
| 2N2222A | 255 | X | X | X | 2N3811 | 366 | X | X | X |
| 2N2369A | 317 | X | X | X | 2N3823 | 375 | X | X | X |
| 2N2484 | 376 | X | X | X | 2N4091 | 431 | X | X | |
| 2N2604 | 354 | X | X | X | 2N4092 | 431 | X | X | |
| 2N2605 | 354 | X | X | X | 2N4093 | 431 | X | X | |
| 2N2608 | 295 | X | X | X | 2N4856 | 385 | X | X | X |
| 2N2857 | 343 | X | X | X | 2N4857 | 385 | X | X | X |
| 2N2904 | 290 | X | X | X | 2N4858 | 385 | X | X | X |
| 2N2904A | 290 | X | X | X | 2N4859 | 385 | X | X | X |
| 2N2905 | 290 | X | X | X | 2N4860 | 385 | X | X | X |
| 2N2905A | 290 | X | X | X | 2N4861 | 385 | X | X | X |
| 2N2906 | 291 | X | X | X | 2N5114 | 476 | X | X | X |
| 2N2906A | 291 | X | X | X | 2N5115 | 476 | X | X | X |
| 2N2907 | 291 | X | X | X | 2N5116 | 476 | X | X | X |
| 2N2907A | 291 | X | X | X | | | | | |

JANTX, TXV, NX and NXV Processing

The 100% reliability pre-conditioning on JANTX parts (vs no pre-conditioning of JAN parts) has resulted in a significant improvement in field reported failure rates.

National Semiconductor also offers JANTXV types (JANTX with 100% preal visual inspection per MIL-STD-750 Method 2072) per the above list.

All hermetically sealed transistors in this catalog (where JANTX or JANTXV specifications do not exist) are available with TX and TXV type 100% processing as NX and NXV types respectively; e.g., NX2N4033 is 2N4033 processed per the flow plans on this page.



Note 1: JANTXV types only.
Note 2: JANTX and JANTXV types only.
Note 3: MIL-STD-19500 was under revision at the time of the publication of this document. Contact the factory for information regarding any changes made by this revision.

Bipolar Transistor and FET Dice

DICE

Standard types from National's transistor families are available in unencapsulated die form for use in hybrid circuits.

FEATURES

- 100% probed and guaranteed to 10% LTPD for key 2N parameters.
 - a. BV_{CBO} , BV_{CEO} , BV_{EBO} and h_{FE} for bipolar transistors.
 - b. BV_{GSS} , I_{DSS} , I_{GSS}^* , R_{ON}^* , Y_{fs} , $V_{GS(off)}$ for FETs.
- Minimum 60% yield to all unprobed 2N parameters.
- 100% visual inspection guaranteed to 10% LTPD for criteria equivalent to MIL-STD-883 Method 2010.
- Gold backing on all types.
- Shipment in waffle carriers.
- Die geometries shown in process section of catalog. Base Pad is identified by adjacent metallized circle on all interdigitated geometries (e.g., see Process 21).

ALL STANDARD TYPES (see index for page listing specification)

***FET NOTE:**

| | | |
|------------------------|-----------------------|---------|
| Leakages (I_{GSS}) | $\leq 100 \text{ pA}$ | 10% AQL |
| $R_{DS(on)}$ | $\leq 10\Omega$ | 10% AQL |

Bipolar Transistor Equivalents List

| METAL P/N | PLASTIC EQUIVALENT | ELECTRICAL EQUIVALENCY* | PROCESS | METAL P/N | PLASTIC EQUIVALENT | ELECTRICAL EQUIVALENCY* | PROCESS |
|-----------|--------------------|-------------------------|---------|-----------|--------------------|-------------------------|---------|
| 2N697 | 2N4400 | A | 13 | 2N2904A | TN2904A | E | 63 |
| 2N706 | MPS706 | E | 21 | 2N2905 | TN2905 | E | 63 |
| 2N708 | MPS3646 | N | 22 | 2N2905A | TN2905A | E | 63 |
| 2N718 | 2N4400 | A | 13 | 2N2906 | PN2906 | E | 63 |
| 2N722 | PN2906 | N | 63 | 2N2906A | PN2906A | E | 63 |
| 2N744 | PN2369 | N | 21 | 2N2907 | PN2907 | E | 63 |
| 2N753 | PN2369 | N | 21 | 2N2907A | PN2907A | E | 63 |
| 2N760A | 2N4409 | N | 07 | 2N3009 | MPS3646 | N | 22 |
| 2N834 | MPS834 | E | 21 | 2N3011 | PN2369 | N | 21 |
| 2N869A | MPS3640 | A | 65 | 2N3012 | MPS3640 | A | 65 |
| 2N915 | MPS6565 | A | 27 | 2N3013 | MPS3646 | E | 22 |
| 2N917 | MPS3563 | E | 43 | 2N3019 | TN3019 | E | 12 |
| 2N918 | PN918 | E | 43 | 2N3020 | TN3020 | E | 12 |
| 2N929 | 2N4409 | N | 07 | 2N3053 | TN3053 | E | 12 |
| 2N930 | PN930 | E | 07 | 2N3117 | 2N5210 | N | 07 |
| 2N956 | PN2222A | N | 19 | 2N3133 | MPS3703 | N | 63 |
| 2N995A | MPS3640 | A | 65 | 2N3134 | MPS3645 | N | 63 |
| 2N1132 | PN2906 | N | 63 | 2N3135 | MPS3703 | N | 63 |
| 2N1613 | PN2221A | N | 19 | 2N3136 | MPS3645 | N | 63 |
| 2N1711 | PN2222A | N | 19 | 2N3250 | 2N3905 | A | 66 |
| 2N2218 | TN2218 | E | 19 | 2N3251 | 2N3906 | A | 66 |
| 2N2218A | TN2218A | E | 19 | 2N3300 | 2N4401 | A | 13 |
| 2N2219 | TN2219 | E | 19 | 2N3301 | 2N4400 | A | 13 |
| 2N2219A | TN2219A | E | 19 | 2N3302 | 2N4401 | A | 13 |
| 2N2221 | PN2221 | E | 19 | 2N3304 | MPS3639 | A | 65 |
| 2N2221A | PN2221A | E | 19 | 2N3724 | TN3724 | E | 25 |
| 2N2222 | PN2222 | E | 19 | 2N3725 | TN3725 | E | 25 |
| 2N2222A | PN2222A | E | 19 | 2N3944 | 2N3903 | N | 23 |
| 2N2369 | PN2369 | E | 21 | 2N3947 | 2N3904 | N | 23 |
| 2N2369A | PN2369A | E | 21 | 2N3962 | 2N5086 | N | 62 |
| 2N2483 | 2N5209 | N | 07 | 2N3964 | 2N5087 | N | 62 |
| 2N2484 | 2N5210 | N | 07 | 2N3965 | 2N5087 | N | 62 |
| 2N2604 | 2N5086 | N | 62 | 2N4033 | TN4033 | E | 67 |
| 2N2605 | 2N5086 | N | 62 | 2N4036 | TN4036 | E | 67 |
| 2N2894 | MPS3640 | A | 65 | 2N4037 | TN4037 | E | 67 |
| 2N289A | MPS3639 | A | 65 | 2N4208 | MPS3640 | N | 65 |
| 2N2904 | TN2904 | E | 63 | 2N4209 | MPS3640 | N | 65 |

*E = Exact electrical equivalent

N = Near electrical equivalent

A = Approximate equivalent

Note: On "N" and "A" categories please refer to device specification section for deviation from metal can specifications.

This list is for use when an alternative to a metal can transistor is needed.

To facilitate conversions on the most popular types National is offering the "PN" series, TO-92 devices that use the same die type and are screened to same electrical specifications. The TO-92 transistors produced by National Semiconductor are the most advanced Plastic Transistors ever manufactured. They utilize epoxy B encapsulation and a copper lead frame, to give a power dissipation of 625 mW @ $T_A = 25^\circ\text{C}$. These transistors provide electrical performance and reliability equivalent to their metal can versions in most applications where T_A does not exceed 150°C .

Conversion of TO-105/TO-106 to TO-92

National has chosen to no longer produce the TO-105/106 plastic transistor line. The decision to drop this line was based on two major factors: cost and performance.

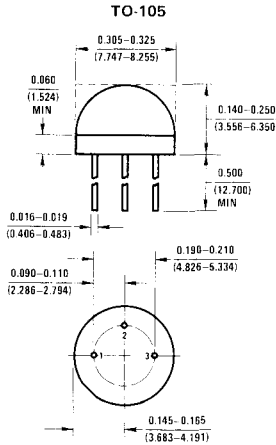
The TO-92 is the most advanced transistor offered today. With its automated assembly, it has the lowest potential cost. By contrast, the TO-105/106 is a hand-assembled product and its cost is tied to ever-increasing labor costs. One can save 20% to 50% by using TO-92 equivalents.

Our TO-92 is encapsulated in "Epoxy B" and has a copper lead frame. This is *the* superior TO-92 available today. As compared with TO-105/106, our TO-92 has better than twice the power dissipation of either package.

We have done several things in order to make this conversion as easy as possible. We are offering a

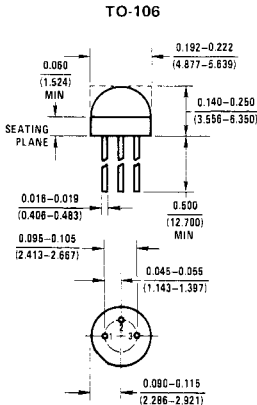
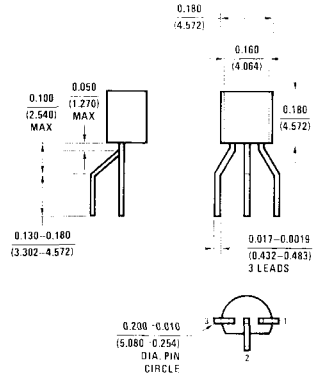
series on "PN" ("PN" and "J" in FETs) part numbers that have exactly the same number as the original part; i.e., 2N3565 becomes a PN3565. These PN types use the same chip and are screened to the same electrical specification as the original part. The original parts have a pin circle, TO-106 = TO-18 and TO-105 = TO-5, so we will supply TO-92 lead formed to the appropriate configuration at no extra charge. If you enter an order to the old part number, our computer will automatically convert it to the correct PN number *with* the correct lead form; i.e., 2N3565 becomes PN3565-18. In the case of some of the less popular types, we have converted to the nearest part type using the same chip. Please use the conversion chart on the next page as a guide.

It is our intent to service our customers with the highest quality and most cost-effective product available.



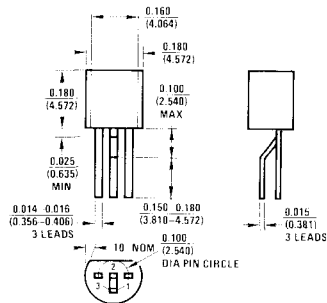
| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |

TO-92 Device to TO-5 Pin Circle



| PIN | FET | T |
|-----|-----|---|
| 1 | S | E |
| 2 | D | B |
| 3 | G | C |

TO-92 Device to TO-18 Pin Circle



Conversion of TO-105/TO-106 to TO-92 (Continued)

Conversion of TO-105/TO-106 to TO-92

Bipolar

| TO-105/106 | TO-92 | TO-105/106 | TO-92 | TO-105/106 | TO-92 |
|------------|------------|------------|------------|------------|-----------|
| EN2222 | PN2222-18 | 2N3692 | PN3692-18 | 2N4965 | 2N5086-18 |
| EN2369A | PN2369A-18 | 2N3693 | MPS3693-18 | 2N4966 | 2N5209-18 |
| EN2484 | PN2484-18 | 2N3694 | PN3694-18 | 2N4967 | 2N5210-18 |
| 3N2907 | PN2907-18 | 2N4121 | PN4121-18 | 2N4968 | 2N5209-18 |
| EN918 | PN918-18 | 2N4122 | PN4122-18 | 2N4969 | PN2221-18 |
| EN930 | PN930-18 | 2N4140 | PN4140-18 | 2N4970 | PN2222-18 |
| SM3904 | 2N3904-18 | 2N4141 | PN4141-18 | 2N4971 | PN2906-18 |
| SM3906 | 2N3906-18 | 2N4142 | PN4142-18 | 2N4972 | PN2907-18 |
| 2N3563 | PN3563-18 | 2N4143 | PN4143-18 | 2N5127 | PN5127-18 |
| 2N3564 | PN3564-18 | 2N4248 | PN4248-18 | 2N5128 | PN5128-5 |
| 2N3565 | PN3565-18 | 2N4249 | PN4249-18 | 2N5129 | PN5129-18 |
| 2N3566 | PN3566-5 | 2N4250 | PN4250-18 | 2N5130 | PN5130-18 |
| 2N3567 | PN3567-5 | 2N4250A | PN4250A-18 | 2N5131 | PN5131-18 |
| 2N3568 | PN3568-5 | 2N4258 | PN4258-18 | 2N5132 | PN5132-18 |
| 2N3569 | PN3569-5 | 2N4258A | PN4258A-18 | 2N5133 | PN5133-18 |
| 2N3638 | PN3638-5 | 2N4274 | PN4274-18 | 2N5134 | PN5134-18 |
| 2N3638A | PN3638A-5 | 2N4275 | PN4275-18 | 2N5135 | PN5135-18 |
| 2N3639 | PN3639-18 | 2N4354 | PN4354-5 | 2N5136 | PN5136-5 |
| 2N3640 | PN3640-18 | 2N4355 | PN4355-5 | 2N5137 | PN5137-18 |
| 2N3641 | PN3641-5 | 2N4356 | PN4356-5 | 2N5138 | PN5138-18 |
| 2N3642 | PN3642-5 | 2N4916 | PN4916-18 | 2N5139 | PN5139-18 |
| 2N3643 | PN3643-5 | 2N4917 | PN4917-18 | 2N5142 | PN5142-18 |
| 2N3644 | PN3644-5 | 2N4944 | PN2222A-18 | 2N5143 | PN5143-18 |
| 2N3645 | PN3645-5 | 2N4945 | PN2222A-18 | 2N5910 | PN5910-18 |
| 2N3646 | PN3646-18 | 2N4946 | PN2222A-18 | | |
| 2N3691 | PN3691-18 | 2N4964 | MPSA70-18 | | |

FETs

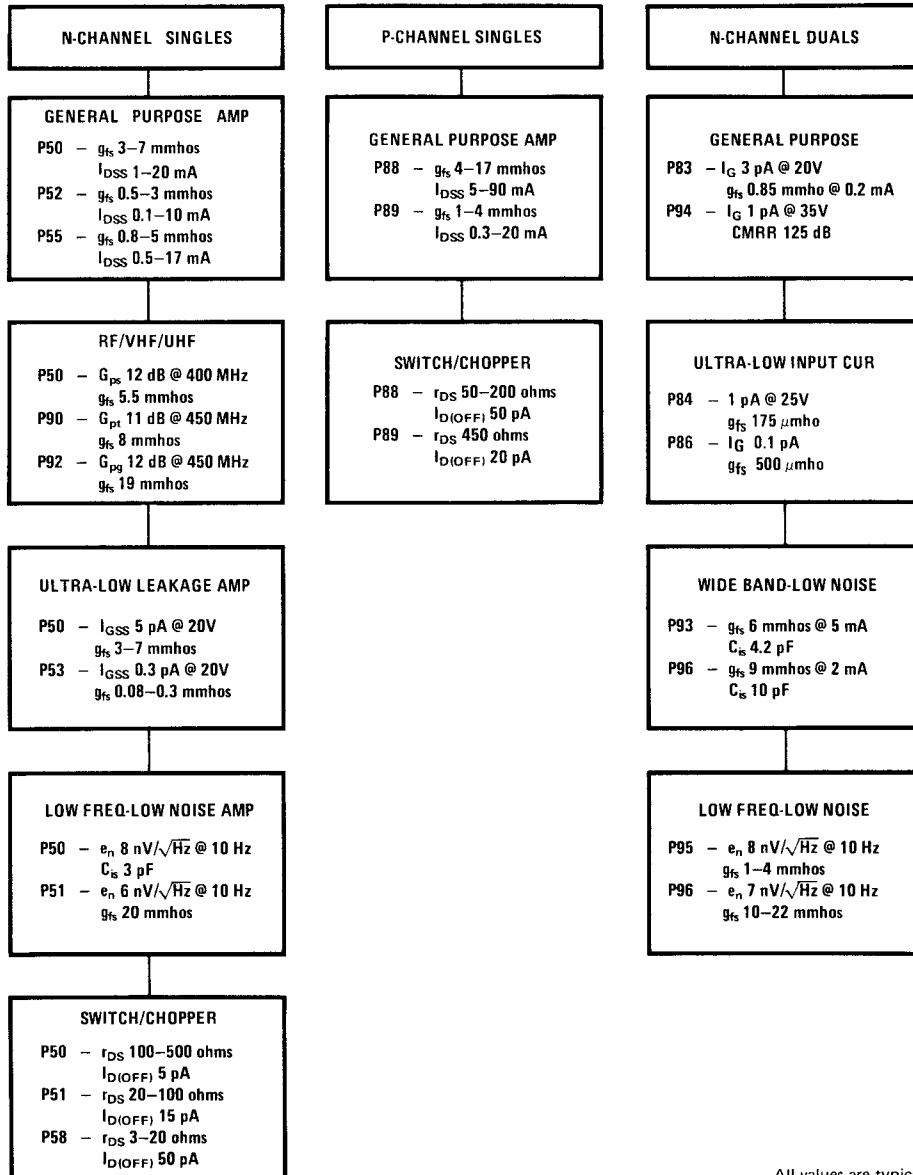
| TO-106 | TO-92 | TO-106 | TO-92 | TO-106 | TO-92 |
|--------|---------|--------|-----------|---------|-----------|
| E100 | J203-18 | E300 | J300-18 | KE4393 | PN4393-18 |
| E101 | J201-18 | E304 | J304-18 | KE4416 | PN4416-18 |
| E102 | J202-18 | E305 | J305-18 | KE4857 | PN4857-18 |
| E103 | J203-18 | E308 | J308-18 | KE4858 | PN4858-18 |
| E108 | J108-18 | E309 | J309-18 | KE4859 | PN4859-18 |
| E109 | J109-18 | E310 | J310-18 | KE4860 | PN4860-18 |
| E110 | J110-18 | E311 | J309-18 | KE4861 | PN4861-18 |
| E111 | J111-18 | E312 | J310-18 | ITE4391 | PN4391-18 |
| E112 | J112-18 | KE3684 | PN3684-18 | ITE4392 | PN4392-18 |
| E113 | J113-18 | KE3685 | PN3685-18 | ITE4393 | PN4393-18 |
| E114 | J114-18 | KE3686 | PN3686-18 | P1086E | P1086E |
| E174 | J174-18 | KE3687 | PN3687-18 | P1087E | P1087E |
| E175 | J175-18 | KE4091 | PN4091-18 | U1897E | U1897E |
| E176 | J176-18 | KE4092 | PN4092-18 | U1898E | U1898E |
| E201 | J201-18 | KE4093 | PN4093-18 | U1899E | U1899E |
| E202 | J202-18 | KE4220 | PN4220-18 | 2N4302 | PN4302-18 |
| E203 | J203-18 | KE4221 | PN4221-18 | 2N4303 | PN4303-18 |
| E210 | J210-18 | KE4222 | PN4222-18 | 2N4304 | PN4304-18 |
| E211 | J211-18 | KE4223 | PN4223-18 | 2N4342 | PN4342-18 |
| E212 | J212-18 | KE4224 | PN4224-18 | 2N4343 | PN4343-18 |
| E270 | J270-18 | KE4391 | PN4391-18 | 2N4360 | PN4360-18 |
| E271 | J271-18 | KE4392 | PN4392-18 | 2N5033 | PN5033 |
| | | | | 2N5163 | PN5163 |

Choose The Proper FET

National Semiconductor utilizes 17 different FET geometries to cover, without compromise, the full spectrum of applications. Detailed data on each process, along with a list of all part numbers manufactured from each process, is to be found in Section 9.

To further simplify the selection procedure, the FET Family Tree is included for quick identification. After narrowing down the process types, it is suggested that the process sheets and specific part number characteristics be consulted.

FET FAMILY TREE



All values are typical

FET Application Guide

National Semiconductor manufactures a broad line of silicon Junction Field Effect Transistors (JFETs). National's JFETs provide excellent performance in many areas such as RF amplifiers, analog switching, low input current amplifiers, low noise high impedance amplifiers and outstanding matched duals for operational amplifiers input applications.

The following FET guides enable the user to determine when to use FETs and where to look for the best choice.

| POPULAR PRODUCT TYPES | 2N4416, 2N5485-6 PN4416, PN4302-4 | 2N4856-61, 2N4391-3 PN4856-61, PN4391-3 | 2N4338-41, 2N3684-7 | 2N4117-9, 2N3452-4 2N4117A-19A | 2N3821-2, 2N4221-2 2N5457-9 | 2N5432-4 | 2N5196-9, 2N5545-7 2N3954-8 | 2N5902-9 | U421-U426 | 2N5018-21, P1086-7E 2N5114-6 | 2N2608-9, 2N5460-62 | 2N5397, J300 | U308-10, J308-10 | 2N5911-12 | NDF9401-10 | 2N5515-24, 2N6483-5 | 2N5564-6 | 2N5561-63 |
|---------------------------------------|--------------------------------------|--|---------------------|-----------------------------------|--------------------------------|----------|--------------------------------|----------|-----------|---------------------------------|---------------------|--------------|------------------|-----------|------------|---------------------|----------|-----------|
| PROCESS DESIGNATION | 50 | 51 | 52 | 53 | 55 | 58 | 83 | 84 | 86 | 88 | 89 | 90 | 92 | 93 | 94 | 95 | 96 | 98 |
| Low Current Amplifier | | | S | P | S | | P | P | P | | P | | | | P | P | | P |
| Low Freq Ampli ≤ 100 Hz | | | S | | S | | P | | | S | S | | | | P | P | | P |
| High Freq Ampli > 100 MHz | P | | | | | | | | | | | P | P | P | | | | P |
| General Purpose Amplifier | P | | P | | P | | | | | | P | | | | | | | |
| Low Noise Amp (10 Hz e _n) | S | S | | | S | S | P | | | | | | | | P | P | P | P |
| Low Noise Amp > 50 MHz | P | | | | S | | | | | | | P | P | P | | | | P |
| High Frequency Mixer | P | | | | | | | | | | | P | P | | | | | |
| Dual Diff Pair | | | | | | | P | P | P | | | | | | P | P | S | P |
| AGC Amplifier | P | | | | P | | | | | | | | | | | | | |
| Electrometer Preamp | | | | | P | | | P | P | | | | | | P | | | S |
| Microvolt Amplifier | | | | | P | | | P | P | | | | | | P | | | P |
| Low Leakage Diode | | | | | P | | | | | | | | | | | | | |
| Diff/Angle Ended Inp. Stag. | | | | | | | P | P | P | | | | | | P | P | | P |
| Active Filter | P | | S | | P | | | | | | S | | | | | | | |
| Oscillator | P | | S | | P | | | | | | S | P | P | | | | | |
| Voltage Variable Resistor | P | P | S | | P | | | | | P | P | | | | | | | P |
| Hybrid Chips | P | P | | P | P | | P | P | P | P | P | | | | P | | | |
| Analog/Digital Switch | | P | | | | P | | | | P | | | | | | | | S |
| Multiplexing | P | P | | | S | S | | | | P | | | | | | | | S |
| Choppers | | P | | | | P | | | | P | | | | | | | | P |
| Nixie Drivers | | | | | | | | | | | | | | | | | | |
| Reed Relay Replacement | | | | | | P | | | | | | | | | | | | |
| Sub pA Dual Diff Pair | | | | | | | | P | P | | | | | | | | | |
| Sample-Hold | P | P | | | S | | | | S | P | | | | | | | | P |
| Buffer Interface to CMOS | | | | | | | | | | P | P | | | | | | | |
| Matched Switch | | | | | | | S | | | | | | | S | S | | | P |
| HF ≥ 400 MHz Prime | | | | | | | | | | | | P | P | | | | | |
| Current Limiter | | P | | | | | | | | P | | | | | | | | |
| Current Source | | | P | S | P | | | | | | S | | | | | | | |

P – Prime Choice S – Secondary (Alternate) Choice

ADVANTAGES OF USING FIELD-EFFECT TRANSISTORS

| APPLICATION | ADVANTAGES | FINAL ASSEMBLY WHERE USED |
|---|---|---|
| DC Amplifiers | High Z_{in} Low drift duals Low noise | Transducers, military guidance systems, control systems, temp indicators, multimeters |
| Low frequency amplifiers | Small coupling capacitors Low noise, distortion High input impedance | Sound detection, microphones, inductive transducers, hearing aids, high impedance transducers |
| Operational amplifiers | Summing point essentially zero. Low device noise. Less loading of transducers | Control systems, potted op amps, test equipment, medical electronics |
| Medium and high frequency amplifiers | Low cross modulation Low device noise | FM tuners, communication received scope inputs, most instrumentation equipment, high impedance inputs |
| Mixers — 100 MHz and up | Low mixing noise Low cross modulation | FM tuners, communication receivers |
| Oscillators | Low drift | Transmitters, receivers, organ |
| Logic gates | Virtually infinite fan in Simplified circuitry Zero storage time Symmetrical | Guidance controls, computer market mini military teaching aids, traffic control, telemetry |
| Choppers | Zero offset Low leakage currents Simplified circuitry Eliminates input transformers | Op amp modules guidance controls instrumentation equipment |
| AD Converters Multiplex switching (arrays) and sample hold | Improved isolation of input and output. Zero offset. Symmetrical. Low resistance Simplified circuitry | Control system, DVM's and any read-out equipment, medical electronics |
| Relay contact replacement | Solid state reliability Zero offset, High isolation Symmetrical No inductive spring No contact bounce High repetition rate | Test equipment, airborne equipment instrumentation market |
| Voltage variable resistor | Symmetrical Solid state reliability Functions as variable resistor. Low noise. High isolation Improved resolution | Organ, tone controls, control ckts to input operational amplifiers |
| Current limiters Sources | Two lead simplicity Wide selection range Low voltage operation | Hybrid circuits, amplifiers, power supply protection, timing ckts, voltage regulators |

JFET Cross Reference Guide

This guide contains cross reference information to more than 850 Junction FETs, including many obsolete or otherwise unavailable types. Every effort has been made to recommend a replacement FET which will plug into an existing socket and work as well as the part it replaces. Let the replacement code be your guide. If you do not find a particular part in this guide and you know its specification, you should refer to "How To Use This Catalog" in this section.

REPLACEMENT CODE

- * Identical specification and pin configuration
 - Equal or better specification, identical pin configuration
 - Similar specification acceptable for all but the most critical applications, similar pin configuration
- CF Consult Factory or Local Sales Representative, available on special order
- N No equivalent process

| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|----------------------|------------------|----------------------|
| 2N2386 | ■ | 2N2608 |
| 2N2386A | ■ | 2N4381 |
| 2N2497 | ■ | 2N5021 |
| 2N2498 | ■ | 2N5021 |
| 2N2499 | ■ | 2N4381 |
| 2N2500 | ■ | 2N4381 |
| 2N2606 | N | |
| 2N2607 | N | |
| 2N2608 | * | 2N2608 |
| 2N2609 | * | 2N2609 |
| 2N2841 | N | |
| 2N2842 | N | |
| 2N2843 | ■ | 2N5020 |
| 2N2844 | ■ | 2N5020 |
| 2N3066 | ● | 2N4340 |
| 2N3067 | ● | 2N4338 |
| 2N3068 | ■ | 2N4338 |
| 2N3069 | * | 2N3069 |
| 2N3070 | * | 2N3070 |
| 2N3071 | * | 2N3071 |
| 2N3084 | ■ | 2N4340 |
| 2N3085 | ● | 2N4340 |
| 2N3086 | ■ | 2N4340 |
| 2N3087 | ● | 2N4340 |
| 2N3088 | ■ | 2N4339 |
| 2N3088A | ■ | 2N4339 |
| 2N3089 | ● | 2N4339 |
| 2N3089A | ● | 2N4339 |
| 2N3277 | N | |
| 2N3278 | N | |
| 2N3328 | ● | 2N3330 |

| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|----------------------|------------------|----------------------|
| 2N3329 | * | 2N3329 |
| 2N3330 | * | 2N3330 |
| 2N3331 | * | 2N3331 |
| 2N3332 | * | 2N3332 |
| 2N3365 | ■ | 2N4340 |
| 2N3366 | ■ | 2N4338 |
| 2N3367 | ■ | 2N4338 |
| 2N3368 | * | 2N3368 |
| 2N3369 | * | 2N3369 |
| 2N3370 | * | 2N3370 |
| 2N3376 | ● | 2N3329 |
| 2N3378 | ■ | 2N3330 |
| 2N3380 | ● | 2N3331 |
| 2N3382 | * | 2N3382 |
| 2N3384 | * | 2N3384 |
| 2N3386 | * | 2N3386 |
| 2N3436 | * | 2N3436 |
| 2N3437 | * | 2N3437 |
| 2N3438 | * | 2N3438 |
| 2N3452 | ■ | 2N3685 |
| 2N3453 | ■ | 2N4118 |
| 2N3454 | ■ | 2N4119 |
| 2N3455 | ■ | 2N3685 |
| 2N3456 | ■ | 2N4118 |
| 2N3457 | ■ | 2N4119 |
| 2N3458 | * | 2N3458 |
| 2N3459 | * | 2N3459 |
| 2N3460 | * | 2N3460 |
| 2N3574 | ■ | 2N3329 |
| 2N3575 | ■ | 2N3329 |
| 2N3578 | ● | 2N2608 |
| 2N3684 | * | 2N3684 |
| 2N3684A | ● | 2N3684 |
| 2N3685 | * | 2N3685 |
| 2N3685A | ● | 2N3685 |
| 2N3686 | * | 2N3686 |
| 2N3686A | ● | 2N3686 |
| 2N3687 | * | 2N3687 |
| 2N3687A | ● | 2N3687 |
| 2N3819 | * | 2N3819 |
| 2N3820 | * | 2N3820 |
| 2N3821 | * | 2N3821 |
| 2N3822 | * | 2N3822 |
| 2N3823 | * | 2N3823 |
| 2N3824 | * | 2N3824 |
| 2N3909 | ● | 2N3331 |
| 2N3909A | ● | 2N3331 |
| 2N3921 | * | 2N3921 |
| 2N3922 | * | 2N3922 |
| 2N3954 | * | 2N3954 |
| 2N3954A | * | 2N3954A |
| 2N3955 | * | 2N3955 |
| 2N3955A | * | 2N3955A |
| 2N3956 | * | 2N3956 |
| 2N3957 | * | 2N3957 |
| 2N3958 | * | 2N3958 |
| 2N3966 | * | 2N3966 |

JFET Cross Reference Guide (Continued)

| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER | INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|-------------------------|---------------------|----------------------------|-------------------------|---------------------|----------------------------|
| 2N3967 | * | 2N3967 | 2N4856 | * | 2N4856 |
| 2N3967A | * | 2N3967A | 2N4856A | * | 2N4856A |
| 2N3968 | * | 2N3968 | 2N4857 | * | 2N4857 |
| 2N3968A | * | 2N3968A | 2N4857A | * | 2N4857A |
| 2N3969 | * | 2N3969 | 2N4858 | * | 2N4858 |
| 2N3969A | * | 2N3969A | 2N4858A | * | 2N4858A |
| 2N3970 | * | 2N3970 | 2N4859 | * | 2N4859 |
| 2N3971 | * | 2N3971 | 2N4859A | * | 2N4859A |
| 2N3972 | * | 2N3972 | 2N4860 | * | 2N4860 |
| 2N3993 | * | 2N3993 | 2N4860A | * | 2N4860A |
| 2N3993A | * | 2N3993A | 2N4861 | * | 2N4861 |
| 2N3994 | * | 2N3994 | 2N4861A | * | 2N4861A |
| 2N3994A | * | 2N3994A | 2N4867 | CF | |
| 2N4082 | CF | | 2N4867A | CF | |
| 2N4083 | CF | | 2N4868 | CF | |
| 2N4084 | * | 2N4084 | 2N4868A | CF | |
| 2N4085 | * | 2N4085 | 2N4869 | CF | |
| 2N4091 | * | 2N4091 | 2N4869A | CF | |
| 2N4092 | * | 2N4092 | 2N4881 | N | |
| 2N4093 | * | 2N4093 | 2N4882 | N | |
| 2N4117 | * | 2N4117 | 2N4883 | N | |
| 2N4117A | * | 2N4117A | 2N4884 | N | |
| 2N4118 | * | 2N4118 | 2N4885 | N | |
| 2N4118A | * | 2N4118A | 2N4886 | N | |
| 2N4119 | * | 2N4119 | 2N4977 | ■ | 2N5432 |
| 2N4119A | * | 2N4119A | 2N4978 | ■ | 2N5433 |
| 2N4139 | CF | | 2N4979 | ■ | 2N5434 |
| 2N4220 | * | 2N4220 | 2N5018 | * | 2N5018 |
| 2N4220A | * | 2N4220A | 2N5019 | * | 2N5019 |
| 2N4221 | * | 2N4221 | 2N5020 | * | 2N5020 |
| 2N4221A | * | 2N4221A | 2N5021 | * | 2N5021 |
| 2N4222 | * | 2N4222 | 2N5033 | ● | PN5033 |
| 2N4222A | * | 2N4222A | 2N5045 | * | 2N5045 |
| 2N4223 | * | 2N4223 | 2N5046 | * | 2N5046 |
| 2N4224 | * | 2N4224 | 2N5047 | * | 2N5047 |
| 2N4302 | ● | PN4302 | 2N5078 | * | 2N5078 |
| 2N4303 | ● | PN4303 | 2N5103 | * | 2N5103 |
| 2N4304 | ● | PN4304 | 2N5104 | * | 2N5104 |
| 2N4338 | * | 2N4338 | 2N5105 | * | 2N5105 |
| 2N4339 | * | 2N4339 | 2N5114 | * | 2N5114 |
| 2N4340 | * | 2N4340 | 2N5115 | * | 2N5115 |
| 2N4341 | * | 2N4341 | 2N5116 | * | 2N5116 |
| 2N4342 | ● | PN4342 | 2N5163 | * | 2N5163 |
| 2N4343 | CF | | 2N5196 | * | 2N5196 |
| 2N4360 | ● | PN4360 | 2N5197 | * | 2N5197 |
| 2N4381 | * | 2N4381 | 2N5198 | * | 2N5198 |
| 2N4382 | ■ | 2N5115 | 2N5199 | * | 2N5199 |
| 2N4391 | * | 2N4391 | 2N5245 | * | 2N5245 |
| 2N4392 | * | 2N4392 | 2N5246 | * | 2N5246 |
| 2N4393 | * | 2N4393 | 2N5247 | * | 2N5247 |
| 2N4416 | * | 2N4416 | 2N5248 | * | 2N5248 |
| 2N4416A | * | 2N4416A | 2N5265 | CF | |
| 2N4417 | N | | 2N5266 | CF | |
| 2N4445 | ● | 2N5432 | 2N5267 | CF | |
| 2N4446 | ● | 2N5433 | 2N5268 | CF | |
| 2N4447 | ● | 2N5432 | 2N5269 | CF | |
| 2N4448 | ● | 2N5433 | 2N5270 | CF | |

JFET Cross Reference Guide (Continued)

| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER | INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|----------------------|------------------|----------------------|----------------------|------------------|----------------------|
| 2N5277 | N | | 2N5555 | * | 2N5555 |
| 2N5278 | N | | 2N5556 | * | 2N5556 |
| 2N5358 | * | 2N5358 | 2N5557 | * | 2N5557 |
| 2N5359 | * | 2N5359 | 2N5558 | * | 2N5558 |
| 2N5360 | * | 2N5360 | 2N5561 | * | 2N5561 |
| 2N5361 | * | 2N5361 | 2N5562 | * | 2N5562 |
| 2N5362 | * | 2N5362 | 2N5563 | * | 2N5563 |
| 2N5363 | * | 2N5363 | 2N5564 | * | 2N5564 |
| 2N5364 | * | 2N5364 | 2N5565 | * | 2N5565 |
| 2N5391 | CF | | 2N5566 | * | 2N5566 |
| 2N5392 | CF | | 2N5638 | * | 2N5638 |
| 2N5393 | CF | | 2N5639 | * | 2N5639 |
| 2N5394 | CF | | 2N5640 | * | 2N5640 |
| 2N5395 | CF | | 2N5647 | ■ | 2N3686 |
| 2N5396 | CF | | 2N5648 | ■ | 2N3686 |
| 2N5397 | * | 2N5397 | 2N5649 | ■ | 2N3685 |
| 2N5398 | * | 2N5398 | 2N5653 | * | 2N5653 |
| 2N5432 | * | 2N5432 | 2N5654 | * | 2N5654 |
| 2N5433 | * | 2N5433 | 2N5668 | * | 2N5668 |
| 2N5434 | * | 2N5434 | 2N5669 | * | 2N5669 |
| 2N5452 | * | 2N5452 | 2N5670 | * | 2N5670 |
| 2N5453 | * | 2N5453 | 2N5902 | * | 2N5902 |
| 2N5454 | * | 2N5454 | 2N5903 | * | 2N5903 |
| 2N5457 | * | 2N5457 | 2N5904 | * | 2N5904 |
| 2N5458 | * | 2N5458 | 2N5905 | * | 2N5905 |
| 2N5459 | * | 2N5459 | 2N5906 | * | 2N5906 |
| 2N5460 | * | 2N5460 | 2N5907 | * | 2N5907 |
| 2N5461 | * | 2N5461 | 2N5908 | * | 2N5908 |
| 2N5462 | * | 2N5462 | 2N5909 | * | 2N5909 |
| 2N5463 | N | | 2N5911 | * | 2N5911 |
| 2N5464 | N | | 2N5912 | * | 2N5912 |
| 2N5465 | N | | 2N5949 | * | 2N5949 |
| 2N5471 | ■ | 2N5020 | 2N5950 | * | 2N5950 |
| 2N5472 | ■ | 2N5020 | 2N5951 | * | 2N5951 |
| 2N5473 | ■ | 2N5020 | 2N5952 | * | 2N5952 |
| 2N5474 | ■ | 2N5020 | 2N5953 | * | 2N5953 |
| 2N5475 | ■ | 2N5020 | 2N6449 | N | |
| 2N5476 | ■ | 2N5020 | 2N6450 | N | |
| 2N5484 | * | 2N5484 | 2N6451 | CF | |
| 2N5485 | * | 2N5485 | 2N6452 | CF | |
| 2N5486 | * | 2N5486 | 2N6453 | CF | |
| 2N5515 | * | 2N5515 | 2N6454 | CF | |
| 2N5516 | * | 2N5516 | 2N6483 | * | 2N6483 |
| 2N5517 | * | 2N5517 | 2N6484 | * | 2N6484 |
| 2N5518 | * | 2N5518 | 2N6485 | * | 2N6485 |
| 2N5519 | * | 2N5519 | A5T6449 | N | |
| 2N5520 | * | 2N5520 | A5T6450 | N | |
| 2N5521 | * | 2N5521 | AD3954 | ● | 2N3954 |
| 2N5522 | * | 2N5522 | AD3954A | ● | 2N3954A |
| 2N5523 | * | 2N5523 | AD3955 | ● | 2N3955 |
| 2N5524 | * | 2N5524 | AD3955A | ● | 2N3955A |
| 2N5543 | N | | AD3956 | ● | 2N3956 |
| 2N5544 | N | | AD3957 | ● | 2N3957 |
| 2N5545 | * | 2N5545 | AD3958 | ● | 2N3958 |
| 2N5546 | * | 2N5546 | AD5905 | ● | 2N5905 |
| 2N5547 | * | 2N5547 | AD5906 | ● | 2N5906 |
| 2N5549 | ● | 2N5397 | AD5907 | ● | 2N5907 |

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| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER | INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|-------------------------|---------------------|----------------------------|-------------------------|---------------------|----------------------------|
| AD5908 | ● | 2N5908 | E100 | ● | J202 |
| AD5909 | ● | 2N5909 | E101 | ● | J201 |
| AD830 | ■ | 2N5906 | E102 | ● | J202 |
| AD831 | ■ | 2N5907 | E103 | ● | J203 |
| AD832 | ■ | 2N5908 | E105 | N | |
| AD833 | ■ | 2N5909 | E106 | N | |
| AD833A | ■ | 2N5909 | E107 | N | |
| AD835 | ■ | NDF9407 | E108 | ● | J108 |
| AD836 | ■ | NDF9408 | E109 | ● | J109 |
| AD837 | ■ | NDF9408 | E110 | ● | J110 |
| AD838 | ■ | NDF9409 | E111 | ● | J111 |
| AD839 | ■ | NDF9410 | E112 | ● | J112 |
| AD840 | ■ | 2N5520 | E113 | ● | J113 |
| AD841 | ■ | 2N5521 | E114 | ● | J114 |
| AD842 | ■ | 2N5523 | E174 | ● | J174 |
| AD845 | ■ | 2N5911 | E175 | ● | J175 |
| AD846 | ■ | 2N5912 | E176 | ● | J176 |
| BF244A | * | BF244A | E177 | ● | J177 |
| BF244B | * | BF244B | E201 | ● | J201 |
| BF244C | * | BF244C | E202 | ● | J202 |
| BF245A | * | BF245A | E203 | ● | J203 |
| BF245B | * | BF245B | E210 | ● | J210 |
| BF245C | * | BF245C | E211 | ● | J211 |
| BF246A | * | BF246A | E212 | ● | J212 |
| BF246B | * | BF246B | E230 | ■ | PN3685 |
| BF246C | * | BF246C | E231 | ■ | PN3684 |
| BF247A | * | BF247A | E232 | ■ | PN368 |
| BF247B | * | BF247B | E270 | ● | J270 |
| BF247C | * | BF247C | E271 | ● | J271 |
| BF256A | * | BF256A | E300 | ● | J300 |
| BF256B | * | BF256B | E304 | ● | J304 |
| BF256C | * | BF256C | E305 | ● | J305 |
| BF264A | * | BF264A | E308 | ● | J308 |
| BF264B | * | BF264B | E309 | ● | J309 |
| BF264C | * | BF264C | E310 | ● | J310 |
| BF264D | * | BF264D | E311 | ● | J309 |
| C413N | ● | 2N4859 | E312 | ● | J310 |
| C681 | ■ | 2N4338 | E400 | CF | |
| C681A | ■ | 2N4338 | E401 | CF | |
| C683 | ■ | 2N4339 | E402 | CF | |
| C683A | ■ | 2N4339 | E410 | CF | |
| C685 | ■ | 2N4220 | E411 | CF | |
| C685A | ■ | 2N4220 | E412 | CF | |
| CM640 | ■ | 2N4391 | E420 | ■ | U257 |
| CM641 | ■ | 2N4391 | E421 | ■ | U257 |
| CM642 | ■ | 2N4392 | FEO654A | ● | PN4416 |
| CM643 | ■ | 2N4391 | FEO654B | ● | PN4303 |
| CM644 | ■ | 2N4393 | FE3819 | ● | 2N3819 |
| CM645 | ■ | 2N4392 | FE5245 | ● | 2N5245 |
| CM646 | ■ | 2N4392 | FE5246 | ● | 2N5246 |
| CM647 | ■ | 2N4392 | FE5247 | ● | 2N5247 |
| CP640 | ● | U322 | FE5457 | ● | 2N5457 |
| CP643 | ■ | 2N4391 | FE5458 | ● | 2N5458 |
| CP650 | ● | U322 | FE5459 | ● | 2N5459 |
| CP651 | ● | U320 | FE5484 | ● | 2N5484 |
| CP652 | ● | U322 | FE5485 | ● | 2N5485 |
| CP653 | ● | U320 | FE5486 | ● | 2N5486 |

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| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER | INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|----------------------|------------------|----------------------|----------------------|------------------|----------------------|
| FM1100A | ■ | 2N5906 | J114 | * | J114 |
| FM1101A | ■ | 2N5906 | J174 | * | J174 |
| FM1102A | ■ | 2N5907 | J175 | * | J175 |
| FM1103A | ■ | 2N5908 | J176 | * | J176 |
| FM1104A | ■ | 2N5909 | J177 | * | J177 |
| FM105A | ■ | NDF9401 | J201 | * | J201 |
| FM1106A | ■ | NDF9401 | J202 | * | J202 |
| FM1107A | ■ | NDF9402 | J203 | * | J203 |
| FM1108A | ■ | NDF9403 | J270 | * | J270 |
| FM1109A | ■ | NDF9405 | J271 | * | J271 |
| FM1110A | ■ | 2N3957 | J300 | * | J300 |
| FM1111A | ■ | 2N3958 | J304 | * | J304 |
| FM3954 | ● | 2N3954 | J305 | * | J305 |
| FM3954A | ● | 2N3954A | J401 | * | J401 |
| FM3955 | ● | 2N3955 | J402 | * | J402 |
| FM3955A | ● | 2N3955A | J403 | * | J403 |
| FM3956 | ● | 2N3956 | J404 | * | J404 |
| FM3957 | ● | 2N3957 | J405 | * | J405 |
| FM3958 | ● | 2N3958 | J406 | * | J406 |
| FT0654A | ■ | 2N3824 | J410 | * | J410 |
| FT0654B | ■ | 2N3824 | J411 | * | J411 |
| FT0654C | ■ | 2N4221 | J412 | * | J412 |
| FT3820 | ● | 2N3820 | J1401 | * | J1401 |
| IMF3954 | ● | 2N3954 | J1402 | * | J1402 |
| IMF3954A | ● | 2N3954A | J1403 | * | J1403 |
| IMF3955 | ● | 2N3955 | J1404 | * | J1404 |
| IMF3955A | ● | 2N3955A | J1405 | * | J1405 |
| IMF3956 | ● | 2N3956 | J1406 | * | J1406 |
| IMF3957 | ● | 2N3957 | KE3684 | ● | PN3684 |
| IMF3958 | ● | 2N3958 | KE3685 | ● | PN3685 |
| IT100 | ■ | 2N5115 | KE3686 | ● | PN3686 |
| IT101 | ■ | 2N5116 | KE3970 | ● | PN4391 |
| IT108 | ● | 2N5486 | KE3971 | ● | PN4392 |
| IT109 | ● | 2N5397 | KE3972 | ● | PN4393 |
| ITE3066 | ■ | 2N4340 | KE4091 | ● | PN4091 |
| ITE3067 | ■ | 2N4338 | KE4092 | ● | PN4092 |
| ITE3068 | ■ | 2N4338 | KE4093 | ● | PN4093 |
| ITE4117 | ● | 2N4117 | KE4220 | ● | PN4220 |
| ITE4118 | ● | 2N4118 | KE4221 | ● | PN4221 |
| ITE4119 | ● | 2N4119 | KE4222 | ● | PN4222 |
| ITE4338 | ● | 2N4338 | KE4223 | ● | PN4223 |
| ITE4339 | ● | 2N4339 | KE4224 | ● | PN4224 |
| ITE4340 | ● | 2N4340 | KE4391 | ● | PN4391 |
| ITE4341 | ● | 2N4391 | KE4392 | ● | PN4392 |
| ITE4391 | * | PN4391 | KE4393 | ● | PN4393 |
| ITE4392 | * | PN4392 | KE4416 | ● | PN4416 |
| ITE4393 | ● | PN4393 | KE4856 | ● | PN4856 |
| ITE4416 | ● | PN4416 | KE4857 | ● | PN4857 |
| ITE4867 | ■ | PN3686 | KE4858 | ● | PN4858 |
| ITE4868 | ■ | PN3685 | KE4859 | ● | PN4859 |
| ITE4869 | ■ | PN3684 | KE4860 | ● | PN4860 |
| J108 | * | J108 | KE4861 | ● | PN4861 |
| J109 | * | J109 | KE5103 | ● | 2N5952 |
| J110 | * | J110 | KE5104 | ● | 2N5953 |
| J111 | * | J111 | KE5105 | ■ | PN4416 |
| J112 | * | J112 | MFE2000 | ■ | 2N4416 |
| J113 | * | J113 | MFE2001 | ■ | 2N4416 |

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| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER | INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|-------------------------|---------------------|----------------------------|-------------------------|---------------------|----------------------------|
| MFE2004 | ■ | 2N4393 | NF532 | ● | 2N3822 |
| MFE2005 | ■ | 2N4392 | NF533 | ● | 2N3821 |
| MFE2006 | ■ | 2N4391 | NF580 | ● | 2N5432 |
| MFE2007 | ■ | 2N4857 | NF581 | ● | 2N5432 |
| MFE2008 | ■ | 2N4391 | NF582 | ● | 2N5434 |
| MFE2009 | ■ | 2N4856 | NF583 | ● | 2N5434 |
| MFE2010 | ■ | 2N4856 | NF584 | ● | 2N5432 |
| MFE2011 | ■ | 2N5433 | NF585 | ● | 2N5433 |
| MFE2012 | ■ | 2N5433 | NF4302 | ● | PN4302 |
| MFE2093 | ■ | 2N3687 | NF4303 | ● | PN4303 |
| MFE2094 | ■ | 2N3686 | NF4304 | ● | PN4304 |
| MFE2095 | ■ | 2N3685 | NF4445 | ● | 2N5432 |
| MFE2133 | ■ | 2N4392 | NF4446 | ● | 2N5433 |
| MFE4007 | ■ | 2N2608 | NF4447 | ● | 2N5432 |
| MFE4008 | ■ | 2N2608 | NF4448 | ● | 2N5433 |
| MFE4009 | ■ | 2N3329 | NF5101 | * | NF5101 |
| MFE4010 | ■ | 2N3330 | NF5102 | * | NF5102 |
| MFE4011 | ■ | 2N3330 | NF5103 | * | NF5103 |
| MFE4012 | ■ | 2N3331 | NF5163 | ● | 2N5163 |
| MPF102 | * | MPF102 | NF5457 | ● | 2N5457 |
| MPF103 | * | MPF103 | NF5458 | ● | 2N5458 |
| MPF104 | * | MPF104 | NF5459 | ● | 2N5459 |
| MPF105 | * | MPF105 | NF5485 | ● | 2N5485 |
| MPF106 | * | MPF106 | NF5486 | ● | 2N5486 |
| MPF107 | * | MPF107 | NF5555 | ● | 2N5555 |
| MPF108 | * | MPF108 | NF5638 | ● | 2N5638 |
| MPF109 | * | MPF109 | NF5639 | ● | 2N5639 |
| MPF111 | * | MPF111 | NF5640 | ● | 2N5640 |
| MPF112 | * | MPF112 | NF5653 | ● | 2N5653 |
| MPF161 | ● | 2N5461 | NF5654 | ● | 2N5654 |
| MPF256 | ● | J211 | NPD5564 | * | NPD5564 |
| MPF820 | ■ | J309 | NPD5565 | * | NPD5565 |
| MPF970 | ● | P1086E | NPD5566 | * | NPD5566 |
| MPF971 | ● | P1087E | NPD8301 | * | NPD8301 |
| MPF4391 | * | PN4391 | NPD8302 | * | NPD8302 |
| MPF4392 | * | PN4392 | NPD8303 | * | NPD8303 |
| MPF4393 | * | PN4393 | NPD9801 | * | NPD9801 |
| NDF9401 | * | NDF9401 | NPD9802 | * | NPD9802 |
| NDF9402 | * | NDF9402 | NPD9803 | * | NPD9803 |
| NDF9403 | * | NDF9403 | P1069E | | |
| NDF9404 | * | NDF9404 | P1086E | * | P1086E |
| NDF9405 | * | NDF9405 | P1087E | * | P1087E |
| NDF9406 | * | NDF9406 | P1117E | CF | |
| NDF9407 | * | NDF9407 | P1118E | CF | |
| NDF9408 | * | NDF9408 | P1119E | CF | |
| NDF9409 | * | NDF9409 | PF510 | ● | PN4392 |
| NDF9410 | * | NDF9410 | PF511 | ● | PN4392 |
| NF500 | ● | 2N4224 | PF5101 | * | PF5101 |
| NF501 | ● | 2N4224 | PF5102 | * | PF5102 |
| NF506 | ● | 2N3823 | PF5103 | * | PF5103 |
| NF510 | ● | 2N4092 | PN3684 | * | PN3684 |
| NF520 | ● | 2N4224 | PN3685 | * | PN3685 |
| NF521 | ● | 2N4220 | PN3686 | * | PN3686 |
| NF522 | ● | 2N4224 | PN3687 | * | PN3687 |
| NF523 | ● | 2N4220 | PN4091 | * | PN4091 |
| NF530 | ● | 2N3822 | PN4092 | * | PN4092 |
| NF531 | ● | 2N3821 | PN4093 | * | PN4093 |

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| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER | INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|-------------------------|---------------------|----------------------------|-------------------------|---------------------|----------------------------|
| PN4220 | * | PN4220 | TD5906A | ■ | 2N5906 |
| PN4221 | * | PN4221 | TD5907 | ■ | 2N5907 |
| PN4222 | * | PN4222 | TD5907A | ■ | 2N5907 |
| PN4223 | * | PN4223 | TD5908 | ■ | 2N5908 |
| PN4224 | * | PN4224 | TD5908A | ■ | 2N5908 |
| PN4302 | * | PN4302 | TD5909 | ■ | 2N5909 |
| PN4303 | * | PN4303 | TD5909A | ■ | 2N5909 |
| PN4304 | * | PN4304 | TD5911 | ■ | 2N5911 |
| PN4342 | * | PN4342 | TD5911A | ■ | 2N5911 |
| PN4343 | ■ | P1087E | TD5912 | ■ | 2N5912 |
| PN4360 | * | PN4360 | TD5912A | ■ | 2N5912 |
| PN4391 | * | PN4391 | TIS25 | N | |
| PN4392 | * | PN4392 | TIS26 | N | |
| PN4393 | * | PN4393 | TIS27 | N | |
| PN4416 | * | PN4416 | TIS34 | ● | 2N5486 |
| PN4856 | * | PN4856 | TIS41 | ■ | 2N4859 |
| PN4857 | * | PN4857 | TIS42 | ■ | PN4392 |
| PN4858 | * | PN4858 | TIS58 | * | TIS58 |
| PN4859 | * | PN4859 | TIS59 | * | TIS59 |
| PN4860 | * | PN4860 | TIS68 | N | |
| PN4861 | * | PN4861 | TIS69 | N | |
| PN5033 | * | PN5033 | TIS70 | N | |
| PN5163 | * | PN5163 | TIS73 | * | TIS73 |
| SU2078 | ● | 2N3955 | TIS74 | * | TIS74 |
| SU2079 | ● | 2N3956 | TIS75 | * | TIS75 |
| SU2080 | | | TIS78 | N | |
| SU2081 | | | TIS79 | N | |
| SU2098 | ● | 2N3954 | TIS88A | ● | 2N5486 |
| SU2098A | ● | 2N3954 | U110 | ■ | 2N5020 |
| SU2098B | ● | 2N3954A | U112 | ● | 2N4381 |
| SU2099 | ● | 2N3955A | U114 | ■ | 2N5020 |
| SU2099A | ● | 2N3955A | U133 | ■ | 2N5020 |
| SU2365 | ● | U401 | U146 | ● | 2N5020 |
| SU2365A | ● | U401 | U147 | ● | 2N5020 |
| SU2366 | ● | U402 | U148 | ● | 2N2608 |
| SU2366A | ● | U402 | U149 | ● | 2N2609 |
| SU2367 | ● | U403 | U168 | ● | 2N2608 |
| SU2367A | ● | U403 | U182 | ● | 2N4857 |
| SU2368 | ● | U404 | U183 | ● | 2N3823 |
| SU2368A | ● | U404 | U184 | ● | 2N4416 |
| SU2369 | ● | U405 | U197 | ● | 2N4338 |
| SU2369A | ● | U405 | U198 | ● | 2N4340 |
| SU2410 | ■ | U424 | U199 | ● | 2N4341 |
| SU2411 | ■ | U425 | U200 | ● | 2N4393 |
| SU2412 | ■ | U426 | U201 | ● | 2N4392 |
| TD5452 | ■ | 2N5452 | U202 | ● | 2N4391 |
| TD5453 | ■ | 2N5453 | U231 | * | U231 |
| TD5454 | ■ | 2N5454 | U232 | * | U232 |
| TD5902 | ■ | 2N5902 | U233 | * | U233 |
| TD5902A | ■ | 2N5902 | U234 | * | U234 |
| TD5903 | ■ | 2N5903 | U235 | * | U235 |
| TD5903A | ■ | 2N5903 | U240 | ● | 2N5432 |
| TD5904 | ■ | 2N5904 | U241 | ● | 2N5433 |
| TD5904A | ■ | 2N5904 | U242 | ● | 2N5432 |
| TD5905 | ■ | 2N5905 | U243 | ● | 2N5433 |
| TD5905A | ■ | 2N5905 | U244 | N | |
| TD5906 | ■ | 2N5906 | U248 | * | 2N5902 |

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| INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER | INDUSTRY TYPE NUMBER | REPLACEMENT CODE | NATIONAL PART NUMBER |
|----------------------|------------------|----------------------|----------------------|------------------|----------------------|
| U248A | * | 2N5906 | U1897E | ● | U1897E |
| U249 | * | 2N5903 | U1898E | ● | U1898E |
| U249A | * | 2N5907 | U1899E | ● | U1899E |
| U250 | * | 2N5904 | U1994E | ● | PN4416 |
| U250A | * | 2N5908 | U2047 | ● | PN4416 |
| U251 | * | 2N5905 | UC155 | ■ | 2N4416 |
| U251A | * | 2N5909 | UC200 | ■ | 2N4393 |
| U252 | * | 2N5911 | UC201 | ■ | 2N4416 |
| U253 | * | 2N5912 | UC210 | ■ | 2N3822 |
| U254 | * | 2N4859 | UC220 | ■ | 2N4220 |
| U255 | * | 2N4860 | UC241 | ■ | 2N3822 |
| U256 | * | 2N4861 | UC250 | ● | 2N4391 |
| U257 | ● | U257 | UC251 | ● | 2N4392 |
| U266 | N | | UC400 | ■ | 2N2609 |
| U280 | ● | 2N3954 | UC401 | ■ | 2N5019 |
| U281 | ● | 2N3954 | UC410 | ■ | 2N2609 |
| U282 | ● | 2N3955 | UC420 | ■ | 2N3329 |
| U283 | ● | 2N3955 | UC588 | ■ | 2N4416 |
| U284 | ● | 2N3956 | UC703 | ■ | 2N3822 |
| U285 | ● | 2N3957 | UC705 | ■ | 2N3824 |
| U290 | N | | UC707 | ■ | 2N4391 |
| U291 | N | | UC714 | ■ | 2N4416 |
| U300 | ■ | U304 | UC734 | ■ | 2N4416 |
| U301 | * | U301 | UC734E | ■ | PN4416 |
| U304 | ● | 2N5114 | UC755 | ■ | 2N4391 |
| U305 | ● | 2N5116 | UC756 | ■ | 2N4224 |
| U306 | ● | 2N5117 | UC805 | ■ | 2N3331 |
| U308 | * | U308 | UC807 | ■ | 2N4861 |
| U309 | * | U309 | UC814 | ■ | 2N3331 |
| U310 | * | U310 | UC851 | ■ | 2N2608 |
| U311 | ● | U311 | UC854 | CF | |
| U312 | * | U312 | UC855 | CF | |
| U320 | * | U320 | UC2139 | CF | |
| U321 | * | U321 | UC2147 | CF | |
| U322 | * | U322 | UC2148 | CF | |
| U328 | N | | UC2149 | CF | |
| U329 | N | | VCR2N | ■ | 2N4092 |
| U330 | N | | VCR3P | ■ | 2N5115 |
| U331 | N | | VCR4N | ■ | 2N4341 |
| U350 | * | U350 | VCR5P | ■ | 2N3331 |
| U401 | * | U401 | VCR7N | ■ | 2N4119 |
| U402 | * | U402 | | | |
| U403 | * | U403 | | | |
| U404 | * | U404 | | | |
| U405 | * | U405 | | | |
| U406 | * | U406 | | | |
| U421 | * | U421 | | | |
| U422 | * | U422 | | | |
| U423 | * | U423 | | | |
| U424 | * | U424 | | | |
| U425 | * | U425 | | | |
| U426 | * | U426 | | | |
| U430 | * | U430 | | | |
| U431 | * | U431 | | | |
| U1714 | ● | 2N4340 | | | |
| U1715 | N | | | | |
| U1837E | ● | 2N5486 | | | |

RF Selector Guide

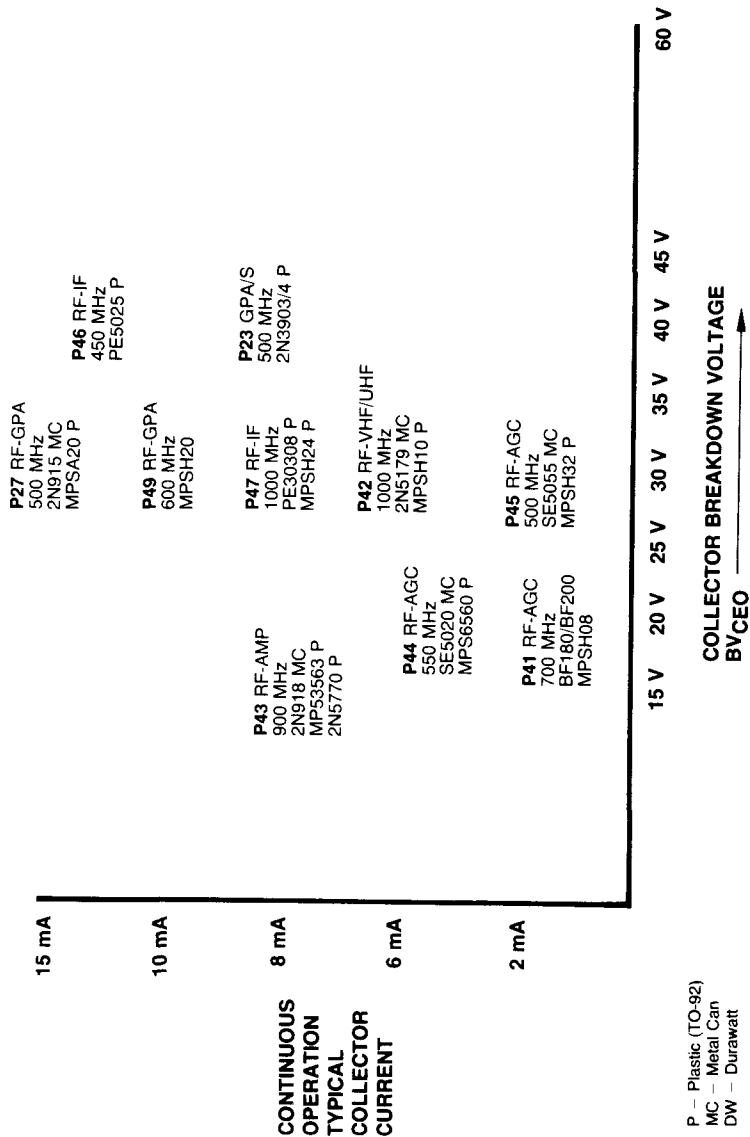
| | BIPOLARS | | | | | | | | JFET'S | | |
|---|----------|----|----|----|----|----|----|----|--------|----|----|
| | 41 | 42 | 43 | 44 | 45 | 46 | 47 | 49 | 50 | 90 | 92 |
| Preamplifiers | | | | | | | | | | | |
| > 500 MHz | • | | | | | | | | | | |
| > 500 MHz with AGC | • | | | | | | | | | | |
| 200–500 MHz | • | • | | | | | | | • | • | |
| 200–500 MHz with AGC | • | | | | | | | | | | |
| 50–250 MHz | | • | | • | | | | | • | • | • |
| 50–250 MHz with AGC | • | | | • | | | | | | | |
| 20–120 MHz | | | | • | | | | • | • | • | |
| Mixers | | | | | | | | | | | |
| Input > 500 MHz | • | | | | | | | | | | |
| Input 200–500 MHz | | • | | | | | • | | • | • | • |
| Input 50–250 MHz | | | | • | | | • | • | • | • | |
| Input 20–120 MHz | | | | | | • | • | • | • | • | |
| Loc Osc | | | | | | | | | | | |
| > 500 MHz Mech. Tuned | | • | • | | | | | | | | |
| > 500 MHz Varactor | | • | | | | | | | | | |
| 200–500 MHz Mech. Tuned | | | • | | | | • | | | | |
| 200–500 MHz Varactor | | | | | | | • | | | | |
| 50–250 MHz | | | • | | | | • | | | | |
| 20–120 MHz | | | • | | | | | | | | |
| IF Amps | | | | | | | | | | | |
| < 75 MHz | | | | | • | • | • | • | • | • | |
| < 15 MHz | | | • | | | • | • | | • | | |
| < 75 MHz with AGC | | | | • | • | • | • | | • | | |
| < 15 MHz with AGC | | | | • | | | | | | | |
| < 75 MHz Last Stage | | | | | | • | • | • | | | |
| < 15 MHz Last Stage | | | | | | • | | • | • | | |
| Special Uses | | | | | | | | | | | |
| 200–500 MHz < 1.0 mA Bias | | • | | | | | | | | | |
| 50–250 MHz < 1.0 mA Bias | | • | | | | | • | | | | |
| 200–500 MHz 5–15 mA Linear IF | | • | | | | | | | | | |
| 50–250 MHz 5–15 mA Linear IF | | | | | | | • | | | | |
| < 120 MHz/20 mA Wideband RF | | | | | | | • | | | | • |
| VHF Freq. Generator and/or Multiplier to 75 mW Levels | | | • | | | | | | | | • |

Transistors NPN GPA Devices

| CONTINUOUS OPERATION TYPICAL COLLECTOR CURRENT | 15 V | 20 V | 25 V | 30 V | 35 V | 40 V | 45 V | 60 V | 80 V | 100 V | 120 V | 220 V | 300 V |
|--|--|------|------|------|------|------|------|------|------|-------|-------|-------|-------|
| 100 mA | P37 GPA-AUDIO DRIVER 200 MHz NSDU01 DW | | | | | | | | | | | | |
| 80 mA | P14 GPA 200 MHz MPS660 P BFY 50 MC | | | | | | | | | | | | |
| 40 mA | P09 AUDIO GPA 400 MHz PN9013P | | | | | | | | | | | | |
| 30 mA | P13 GPA/SW 350 MHz 2N4400 P | | | | | | | | | | | | |
| 20 mA | P113 GPA/SW 350 MHz 2N2219A/22A MC | | | | | | | | | | | | |
| 15 mA | P19 GPA/SW 350 MHz 2N4401 P | | | | | | | | | | | | |
| 10 mA | P27 RF-GPA 500 MHz 2N3180 C | | | | | | | | | | | | |
| 8 mA | P46 RF-IF 450 MHz MPSA20 P PE5025 P | | | | | | | | | | | | |
| 6 mA | P49 RF-GPA 600 MHz MP5H20 | | | | | | | | | | | | |
| 2 mA | P43 RF-AMP 900 MHz 2N3556 MC | | | | | | | | | | | | |
| | P44 RF-AGC 1000 MHz SE5020 MC | | | | | | | | | | | | |
| | P45 RF-AGC 500 MHz BF180/BF200 MP5H08 | | | | | | | | | | | | |
| | P47 RF-IF 1000 MHz PE30308 P | | | | | | | | | | | | |
| | P42 RF-VHF/UHF 1000 MHz 2N5770 P | | | | | | | | | | | | |
| | P04 LOW LEVEL/LOW NOISE AMP 350 MHz MPSH10 P | | | | | | | | | | | | |
| | P41 RF-AGC 500 MHz SE5055 MC | | | | | | | | | | | | |
| | P07 LOW LEVEL/LOW NOISE AMP 500 MHz 2N5088 P | | | | | | | | | | | | |
| | 2N830 MC | | | | | | | | | | | | |
| | P38 GPA-AUDIO DRIVER 200 MHz NSDU06 DW | | | | | | | | | | | | |
| | P12 GPA 130 MHz 2N3019 MC | | | | | | | | | | | | |
| | P15 HIGH VOLTAGE VIDEO 170 MHz BF257/8/9 MC | | | | | | | | | | | | |
| | P08 GPA-HIGH VOLTAGE DRIVER 200 MHz 2N3501 MC | | | | | | | | | | | | |
| | P39 GPA-HIGH VOLTAGE DRIVER NSDU07 DW | | | | | | | | | | | | |
| | P16 GPA-HIGH VOLTAGE 220 MHz 2N3551 P | | | | | | | | | | | | |
| | P48 HIGH VOLTAGE VIDEO DRIVER 80 MHz SE7056 MC | | | | | | | | | | | | |
| | SP7056 DW | | | | | | | | | | | | |
| | P49 HIGH VOLTAGE VIDEO DRIVER 70 MHz SE7057 MC | | | | | | | | | | | | |

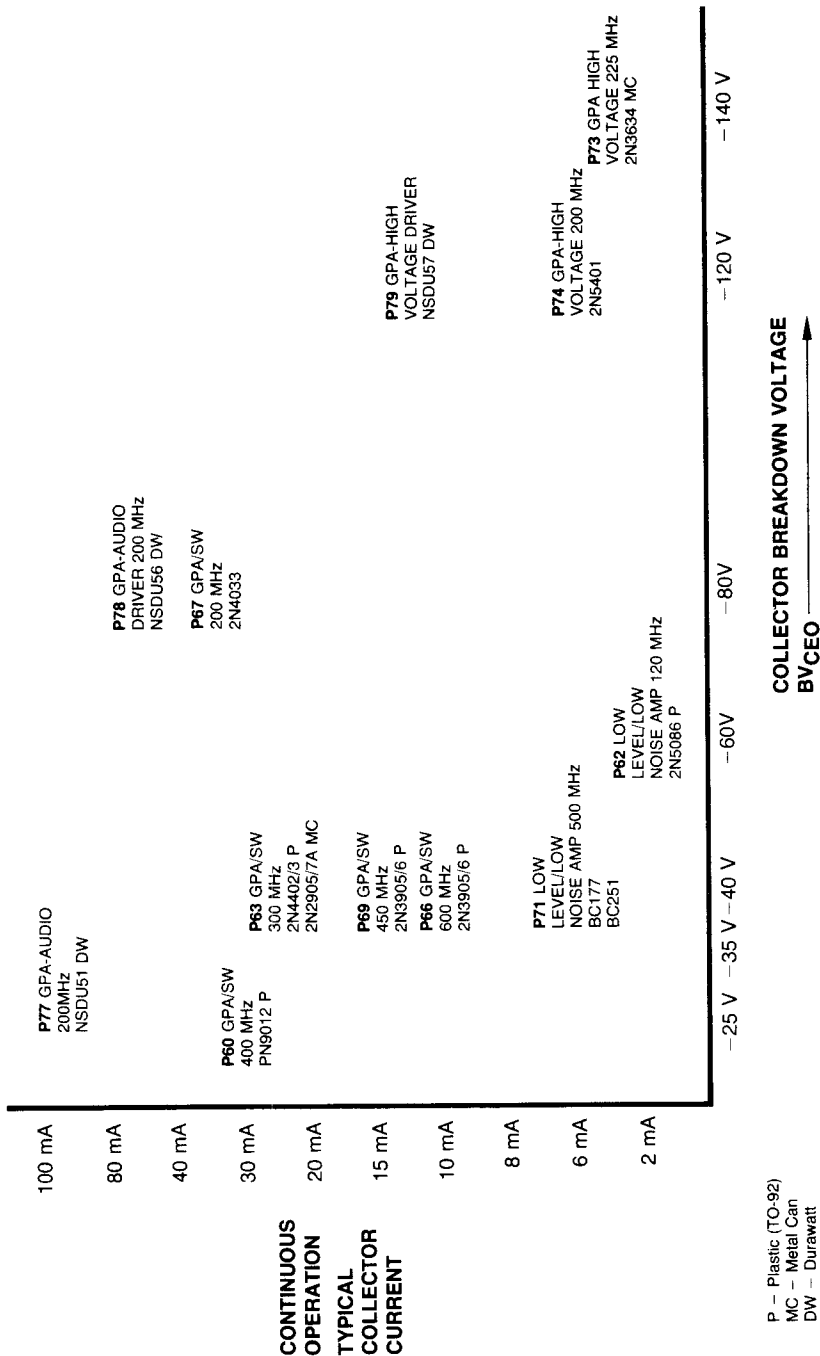
COLLECTOR BREAKDOWN VOLTAGE
BV_{CEO} →

P - Plastic (TO-92)
MC - Metal Can
DW - Durawatt



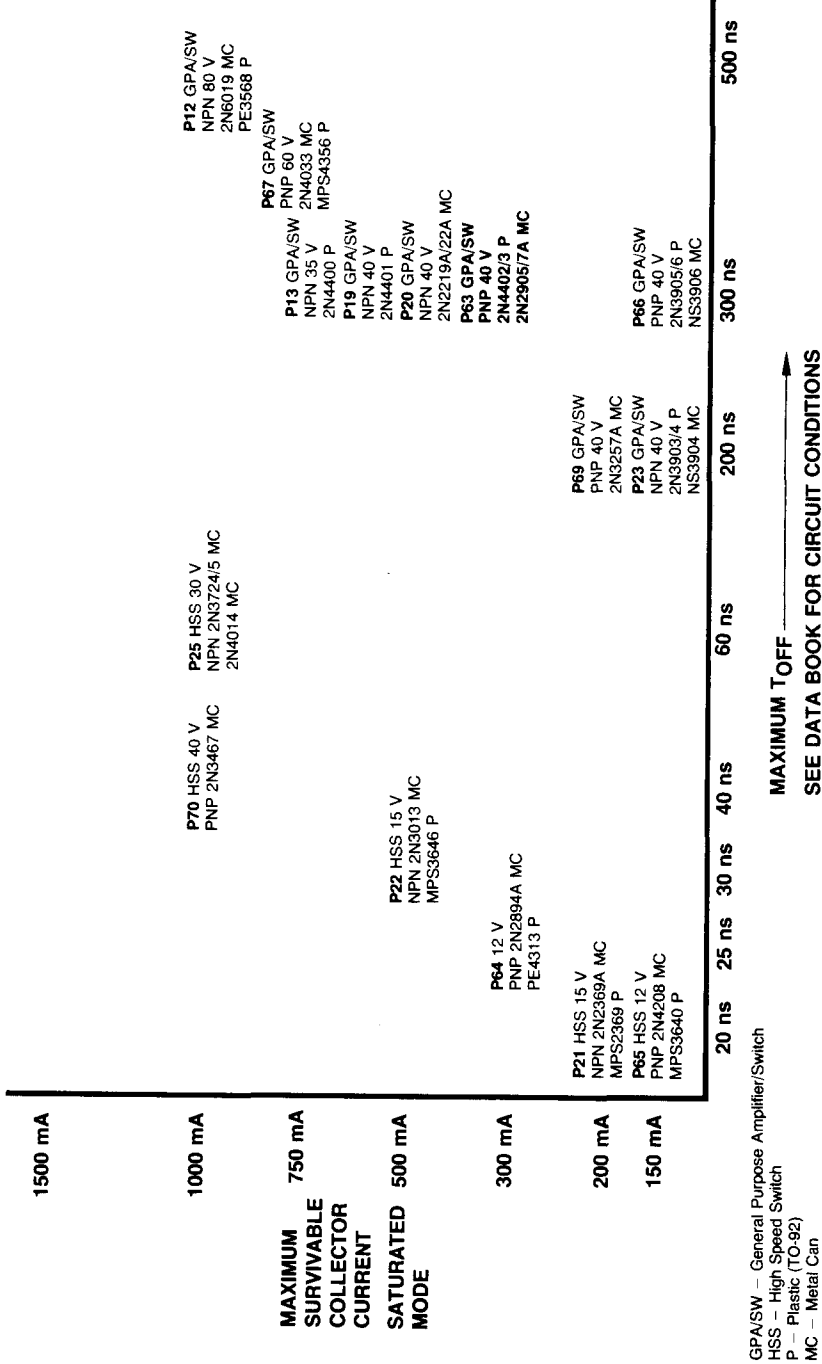
P - Plastic (TO-92)
 MC - Metal Can
 DW - Durawatt

Transistors PNP GPA Devices



P - Plastic (TO-92)
 MC - Metal Can
 DW - Durawatt

Transistors for High Speed Switching



MAXIMUM T_{OFF}
SEE DATA BOOK FOR CIRCUIT CONDITIONS

GPA/SW - General Purpose Amplifier/Switch
HSS - High Speed Switch
P - Plastic (TO-92)
MC - Metal Can

Power Transistor Selector Guide

| HIGH VOLTAGE AND GENERAL PURPOSE | | | | DARLINGTON | | SWITCH MODE | | | | | | | |
|----------------------------------|------|--------|------|-----------------|------|-------------|------|------|-----|-----|-----|------|------|
| Epi Base Mesa | | Mesa | | Triple Epi Mesa | | | | | | | | | |
| Planar | | Planar | Mesa | | | | | | | | | | |
| 400 | | | | | | | | | | | | | |
| 300 | | | | | | | | | | | | | |
| 200 | P-48 | | | | | | | | | | | | |
| 140 | | | | | | | | | | | | | |
| 100 | P-36 | | | | | | | | | | | | |
| 80 | | | | | | | | | | | | | |
| 60 | | | | | | | | | | | | | |
| 40 | | | | | | | | | | | | | |
| I_c → | 0.1A | 0.8A | 2A | 3A | 5A | 7A | 10A | 15A | 20A | 15A | 20A | 10A | 15A |
| Package | | | | | | | | | | | | | |
| TO-92 | 0.6W | | 0.6W | | | | | | | | | | |
| TO-92+ | 1.2W | 1.2W | 1.2W | | | | | | | | | | |
| TO-202 | 10W | 15W | 10W | 15W | 15W | | | | | | | | |
| TO-126 | | 25W | 20W | 30W | 40W | | | | | | | | |
| TO-220 | | | | 40W | 50W | 60W | 70W | 75W | | | | 60W | 125W |
| TO-3 | | | | 40W | 115W | 150W | 175W | 200W | | | | 120W | 175W |

BV_{CEO} - (Volts)

▨ Quote on Request

92+ Power Transistor Reference Guide

| PART NUMBER | | V _{CEO} (V) | I _C (A) | h _{FE} | | I _C (mA) | V _{CE} (V) | | MAX V _{CE} (SAT) (V) @ I _C (mA) | P _D (W) | f _T (MHz) | PROCESS (NPN/PNP) |
|-------------|---------|-------------------------|-----------------------|-----------------|-----|---------------------|---------------------|---------------------|--|-----------------------|-------------------------|----------------------|
| NPN | PNP | | | MIN | MAX | | I _C (mA) | V _{CE} (V) | | | | |
| TN2219 | | 30 | 0.5 | 100 | 300 | 150 | 10 | 0.4 | 1.2 | 250 | 19 | |
| TN3724 | | 30 | 1 | 30 | 150 | 500 | 10 | 0.2 | 1.2 | 300 | 25 | |
| 92PU01 | 92PU51 | 30 | 2 | 40 | 300 | 300 | 1 | 0.32 | 1.2 | 300 | 37/77 | |
| | | | | 60 | | 100 | 1 | 0.5 | 1.2 | 50 | | |
| TN2218A | | 40 | 0.5 | 55 | 120 | 1000 | 1 | 0.3 | 1.2 | 250 | 19 | |
| TN2219A | TN2905 | 40 | 0.5 | 40 | 300 | 500 | 10 | 0.3/0.4 | 1.2 | 300 | 19/63 | |
| TN3053 | TN4037 | 40 | 1 | 25 | 300 | 500 | 10 | 1.4 | 1.2 | 100 | 12/63 | |
| 92PU01A | 92PU51A | 40 | 2 | 40 | 250 | 500 | 10 | 0.5 | 1.2 | 50 | 37/77 | |
| | | | | 60 | | 100 | 1 | 1 | 1.2 | 100 | | |
| 92PU45 | | 40 | 2 | 55 | 300 | 1000 | 1 | 1.5 | 1.2 | 100 | 05 | |
| | | | | 25k | | 200 | 5 | 1 | 1.2 | 100 | | |
| | | | | 4k | | 1000 | 5 | 1.5 | 1.2 | 100 | | |
| 92PE37A | 92PE77A | 45 | 2 | 40 | 150 | 500 | 2 | 0.5 | 1.2 | 50 | 38/78 | |
| TN3725 | | 50 | 1 | 60 | 300 | 100 | 1 | 0.4 | 1.2 | 300 | 25 | |
| 92PU45A | | 50 | 2 | 40 | 150 | 300 | 1 | 0.4 | 1.2 | 300 | 25 | |
| | | | | 25k | | 200 | 5 | 1 | 1.2 | 100 | 05 | |
| | | | | 4k | | 1000 | 5 | 1.5 | 1.2 | 100 | | |
| | | | | 40 | | 150 | 10 | 0.4 | 1.2 | 200 | 63 | |
| TN2904A | | 60 | 0.5 | 40 | 120 | 500 | 10 | 0.4 | 1.2 | 200 | 63 | |
| TN2905A | | 60 | 0.5 | 40 | 300 | 1000 | 10 | 0.4 | 1.2 | 200 | 63 | |
| 92PE37B | 92PE77B | 60 | 2 | 100 | 300 | 150 | 10 | 0.4 | 1.2 | 200 | 63 | |
| 92PU05 | 92PU55 | 60 | 2 | 50 | 300 | 500 | 10 | 0.4 | 1.2 | 200 | 63 | |
| | | | | 40 | | 500 | 2 | 0.5 | 1.2 | 50 | 38/78 | |
| TN2102 | TN4036 | 65 | 1 | 20 | 120 | 500 | 1 | 0.35 | 1.2 | 50 | 39/79 | |
| | | | | 40 | | 150 | 10 | 0.5/0.65 | 1.2 | 60 | 12/67 | |
| | | | | 25 | | 500 | 10 | 0.2 | 1.2 | 100 | 12 | |
| TN3019 | | 80 | 1 | 30 | 300 | 500 | 10 | 0.2 | 1.2 | 100 | 12 | |
| TN3020 | | 80 | 1 | 40 | 120 | 150 | 10 | 0.2 | 1.2 | 100 | 12 | |
| | | | | 100 | 300 | 500 | 10 | 0.15 | 1.2 | 150 | 67 | |
| 92PE37C | 92PE77C | 80 | 2 | 40 | 300 | 100 | 5 | 0.5 | 1.2 | 50 | 38/78 | |
| 92PU06 | 92PU56 | 80 | 2 | 20 | 120 | 500 | 2 | 0.35 | 1.2 | 50 | 39/79 | |
| | | | | 20 | | 500 | 1 | 0.35 | 1.2 | 50 | 39/79 | |
| 92PU07 | 92PU57 | 100 | 2 | 20 | 120 | 500 | 1 | 0.35 | 1.2 | 50 | 39/79 | |
| 92PE487 | | 160 | 0.1 | 30 | 300 | 30 | 10 | 1 | 1.2 | 50 | 48 | |
| 92PU391 | | 200 | 0.1 | 40 | 300 | 10 | 10 | 2 | 1.2 | 50 | 48 | |
| 92PE488 | | 250 | 0.1 | 30 | 300 | 30 | 10 | 1 | 1.2 | 50 | 48 | |
| 92PU392 | | 250 | 0.1 | 40 | 300 | 10 | 10 | 2 | 1.2 | 50 | 48 | |
| 92PE489 | | 300 | 0.1 | 30 | 300 | 30 | 10 | 1 | 1.2 | 50 | 48 | |
| 92PU393 | | 300 | 0.1 | 40 | 300 | 10 | 10 | 2 | 1.2 | 50 | 48 | |
| 92PU10 | | 300 | 0.1 | 40 | 300 | 30 | 10 | 0.75 | 1.2 | 50 | 48 | |

TO-202 Power Transistor Reference Guide

| PART NUMBER | PART NUMBER | | V _{CEO} (V) | hFE | | MAX V _{CE(SAT)} (V)@I _C (A) | P _D (W) | f _T (MHz) | PROCESS (NPN/PNP) | PART NUMBER | | I _C (A) | V _{CEO} (V) | hFE | | MAX V _{CE(SAT)} (V)@I _C (A) | P _D (W) | f _T (MHz) | PROCESS (NPN/PNP) |
|-------------|-------------|-----|-------------------------|-----------------------|------------------------|---|-----------------------|-------------------------|----------------------|-------------|-----|-----------------------|-------------------------|-----------------------|------------------------|---|-----------------------|-------------------------|----------------------|
| | NPN | PNP | | NPN | PNP | | | | | MIN | MAX | | | MIN | MAX | | | | |
| | | | | I _C (A) | V _{CE} (V) | | | | | | | | | I _C (A) | V _{CE} (V) | | | | |
| NSD467 | | | 0.1 | 160 | 25 | 0.03 | 1.75 | 50 | 48 | D40D14 | 1 | 75 | 0.5 | 2 | 1 | 1.3 | 38/78 | | |
| NSD457 | | | 0.1 | 160 | 25 | 0.03 | 1.75 | 50 | 48 | 2N6552 | 1 | 80 | 0.5 | 2 | 1 | 0.25 | 39/79 | | |
| NSD458 | | | 0.1 | 250 | 25 | 0.03 | 1.75 | 50 | 48 | NSD104 | 1 | 80 | 0.5 | 2 | 1 | 0.1 | 39/79 | | |
| NSD459 | | | 0.1 | 250 | 25 | 0.03 | 1.75 | 50 | 48 | NSD105 | 1 | 80 | 0.5 | 2 | 1 | 0.1 | 39/79 | | |
| D40N1 | | | 0.1 | 250 | 30 | 0.02 | 1.3 | 50 | 48 | NSD106 | 1 | 100 | 0.5 | 2 | 1 | 0.1 | 39/79 | | |
| D40N2 | | | 0.1 | 250 | 30 | 0.02 | 1.3 | 50 | 48 | 2N6553 | 1 | 100 | 0.5 | 2 | 1 | 0.1 | 39/79 | | |
| NSD131 | | | 0.1 | 250 | 30 | 0.03 | 1.75 | 50 | 48 | NSD366 | 1 | 150 | 0.5 | 2 | 1 | 0.1 | 36 | | |
| NSD132 | | | 0.1 | 250 | 60 | 0.03 | 1.75 | 50 | 48 | NSD368A | 1 | 200 | 0.5 | 2 | 1 | 0.1 | 36 | | |
| D40N3 | | | 0.1 | 300 | 30 | 0.02 | 1.3 | 50 | 48 | NSD368 | 1 | 250 | 0.5 | 2 | 1 | 0.1 | 36 | | |
| D40N4 | | | 0.1 | 300 | 60 | 0.02 | 1.3 | 50 | 48 | NSD36C | 1 | 300 | 0.5 | 2 | 1 | 0.1 | 36 | | |
| NSD133 | | | 0.1 | 300 | 30 | 0.03 | 1.75 | 50 | 48 | NSDU01 | 2 | 30 | 0.5 | 2 | 1 | 0.5 | 37/77 | | |
| NSD134 | | | 0.1 | 300 | 60 | 0.03 | 1.75 | 50 | 48 | NSD151 | 1 | 30 | 0.5 | 2 | 1 | 0.1 | 05 | | |
| NSD469 | | | 0.1 | 300 | 25 | 0.03 | 1.75 | 50 | 48 | NSD153 | 2 | 30 | 0.5 | 2 | 1 | 0.1 | 05 | | |
| NSD455 | | | 0.1 | 300 | 25 | 0.03 | 1.75 | 50 | 48 | D40E1 | 2 | 30 | 0.5 | 2 | 1 | 1.3 | 38/78 | | |
| NSDU10 | | | 0.1 | 300 | 40 | 0.03 | 1.5 | 60 | 48 | NSDU01A | 2 | 40 | 0.5 | 2 | 1 | 0.5 | 37/77 | | |
| D40N5 | | | 0.1 | 375 | 20 | 0.02 | 1.3 | 50 | 48 | NSDU02 | 2 | 40 | 0.5 | 2 | 1 | 0.5 | 37/77 | | |
| NSD135 | | | 0.1 | 375 | 30 | 0.03 | 1.75 | 50 | 48 | NSDU04 | 2 | 40 | 0.5 | 2 | 1 | 0.5 | 05 | | |
| D40C1 | | | 0.5 | 30 | 10k | 0.2 | 5 | 1.5 | 05 | 2N6549 | 2 | 40 | 0.25k | 5 | 1.5 | 1 | 1.75 | 100 | |
| D40C2 | | | 0.5 | 30 | 40k | 0.2 | 5 | 1.5 | 05 | NSDU45 | 2 | 40 | 25k | 5 | 1.5 | 1 | 1.75 | 100 | |
| D40C3 | | | 0.5 | 30 | 90k | 0.2 | 5 | 1.5 | 05 | NSDU45 | 2 | 40 | 25k | 5 | 1.5 | 1 | 1.75 | 100 | |
| D40C4 | | | 0.5 | 40 | 10k | 0.2 | 5 | 1.5 | 05 | NSDU45A | 2 | 40 | 25k | 5 | 1.5 | 1 | 1.75 | 100 | |
| D40C5 | | | 0.5 | 40 | 40k | 0.2 | 5 | 1.5 | 05 | NSDU45A | 2 | 40 | 25k | 5 | 1.5 | 1 | 1.75 | 100 | |
| D40C6 | | | 0.5 | 50 | 10k | 0.2 | 5 | 1.5 | 05 | NSDU05 | 2 | 50 | 25k | 5 | 1.5 | 0.25 | 05 | | |
| D40C7 | | | 0.5 | 50 | 10k | 0.2 | 5 | 1.5 | 05 | NSDU05 | 2 | 60 | 80 | 0.05 | 1 | 0.5 | 38/78 | | |
| D40C8 | | | 0.5 | 50 | 40k | 0.2 | 5 | 1.5 | 05 | D40E5 | 2 | 60 | 80 | 0.05 | 1 | 1.3 | 38/78 | | |
| D40P1 | | | 0.5 | 120 | 40 | 0.08 | 1.0 | 1 | 36 | NSDU06 | 2 | 80 | 50 | 0.05 | 1 | 0.5 | 39/79 | | |
| D40P3 | | | 0.5 | 180 | 40 | 0.08 | 1.0 | 1 | 36 | D40E7 | 2 | 80 | 50 | 0.05 | 1 | 1.3 | 38/78 | | |
| D40P5 | | | 0.5 | 225 | 40 | 0.08 | 1.0 | 1 | 36 | NSDU07 | 2 | 100 | 80 | 0.05 | 1 | 1.3 | 39/79 | | |
| D40D1 | | | 1 | 30 | 50 | 0.1 | 2 | 0.5 | 05 | NSD123 | 2,2 | 120 | 40 | 0.05 | 1 | 0.5 | 05 | | |
| D40D2 | | | 1 | 30 | 120 | 0.1 | 2 | 0.5 | 05 | D42C1 | 3 | 30 | 25 | 0.2 | 1 | 0.4 | 05 | | |
| D40D3 | | | 1 | 30 | 290 | 0.1 | 2 | 0.5 | 05 | D42C2 | 3 | 30 | 25 | 0.2 | 1 | 0.5 | 37/77 | | |
| D40D4 | | | 1 | 45 | 50 | 0.1 | 2 | 0.5 | 05 | D43C3 | 3 | 40 | 120 | 0.2 | 1 | 1.7 | 50 | | |
| D40D5 | | | 1 | 45 | 120 | 0.1 | 2 | 0.5 | 05 | D42C3 | 3 | 40 | 120 | 0.2 | 1 | 0.5 | 37/77 | | |
| NSD102 | | | 1 | 45 | 50 | 0.1 | 2 | 0.5 | 05 | D42C4 | 3 | 45 | 25 | 0.2 | 1 | 1.7 | 50 | | |
| NSD103 | | | 1 | 45 | 120 | 0.1 | 2 | 0.5 | 05 | D43C4 | 3 | 45 | 25 | 0.2 | 1 | 0.5 | 37/77 | | |
| D40D7 | | | 1 | 60 | 50 | 0.1 | 2 | 0.5 | 05 | D43C5 | 3 | 45 | 40 | 0.2 | 1 | 0.5 | 37/77 | | |
| D40D8 | | | 1 | 60 | 50 | 0.1 | 2 | 0.5 | 05 | D43C6 | 3 | 45 | 40 | 0.2 | 1 | 0.5 | 37/77 | | |
| D40D9 | | | 1 | 60 | 120 | 0.1 | 2 | 0.5 | 05 | D43C7 | 3 | 60 | 25 | 0.2 | 1 | 0.5 | 37/77 | | |
| 2N6554 | | | 1 | 60 | 80 | 0.1 | 2 | 0.5 | 05 | D43C8 | 3 | 60 | 40 | 0.2 | 1 | 0.5 | 37/77 | | |
| D40D10 | | | 1 | 75 | 50 | 0.1 | 2 | 1 | 05 | D43C9 | 3 | 60 | 40 | 0.2 | 1 | 1.7 | 50 | | |
| D40D11 | | | 1 | 75 | 120 | 0.1 | 2 | 1 | 05 | D42C10 | 3 | 80 | 25 | 0.2 | 1 | 0.5 | 38/78 | | |
| D40D13 | | | 1 | 75 | 50 | 0.1 | 2 | 1 | 05 | D43C11 | 3 | 80 | 40 | 0.2 | 1 | 1.7 | 50 | | |
| | | | 1 | 75 | 120 | 0.1 | 2 | 1 | 05 | D43C12 | 3 | 80 | 40 | 0.2 | 1 | 0.5 | 38/78 | | |

Note: Preferred part types are shaded.

TO-126 Power Transistor Reference Guide

| PART NUMBER | PNP | I _C (A) | V _{CEO} (V) | hFE | | I _C (A) @ | | V _{CE} (V) | MAX V _{CE} (SAT) (V) @ I _C (A) | P _D (W) | f _T (MHz) | PROCESS (NPN/PNP) |
|-------------|--------|-----------------------|-------------------------|-----|-----|----------------------|---------------------|---------------------|---|-----------------------|-------------------------|----------------------|
| | | | | MIN | MAX | I _C (A) | V _{CE} (V) | | | | | |
| MJE3440 | | 0.3 | 250 | 40 | 160 | 0.02 | 10 | 0.05 | 0.05 | 15 | 15 | 36 |
| MJE3439 | | 0.3 | 350 | 40 | 160 | 0.02 | 10 | 0.05 | 0.05 | 15 | 15 | 36 |
| MJE341 | | 0.5 | 150 | 25 | 200 | 0.05 | 10 | 0.05 | 1 | 20 | 15 | 36 |
| MJE344 | | 0.5 | 200 | 30 | 300 | 0.05 | 10 | 0.05 | 1 | 30 | 15 | 36 |
| 2N5655 | | 0.5 | 250 | 30 | 250 | 0.1 | 10 | 0.1 | 1 | 20 | 10 | 36 |
| MJE340 | | 0.5 | 300 | 30 | 240 | 0.05 | 10 | 0.05 | 1 | 20 | 10 | 36 |
| 2N5656 | | 0.5 | 300 | 30 | 250 | 0.1 | 10 | 0.1 | 1 | 20 | 10 | 36 |
| 2N5657 | | 0.5 | 350 | 30 | 250 | 0.1 | 10 | 0.1 | 1 | 20 | 10 | 36 |
| MJE520 | MJE370 | 1 | 30 | 25 | 100 | 1 | 1 | 0.6 | 1 | 25 | 3 | 2C/3C |
| 2N4921 | 2N4918 | 1 | 40 | 20 | 100 | 0.5 | 1 | 0.6 | 1 | 30 | 3 | 2C/3C |
| 2N4922 | 2N4919 | 1 | 60 | 20 | 100 | 0.5 | 1 | 0.6 | 1 | 30 | 3 | 2C/3C |
| 2N4923 | 2N4920 | 1 | 80 | 20 | 100 | 0.5 | 1 | 0.6 | 1 | 30 | 3 | 2C/3C |
| MJE720 | MJE710 | 1.5 | 40 | 40 | 250 | 0.15 | 1 | 0.15 | 0.15 | 20 | 50 | 37/77 |
| BD345 | BD344 | 1.5 | 60 | 40 | 250 | 0.2 | 1 | 0.4 | 0.2 | 20 | 50 | 38/78 |
| MJE721 | MJE711 | 1.5 | 60 | 40 | 250 | 0.15 | 1 | 0.15 | 0.15 | 20 | 50 | 38/78 |
| BD349 | BD348 | 1.5 | 80 | 50 | 250 | 0.25 | 1 | 0.5 | 0.25 | 20 | 50 | 39/79 |
| MJE722 | MJE712 | 1.5 | 80 | 40 | 250 | 0.15 | 1 | 0.15 | 0.15 | 20 | 50 | 39/79 |
| MJE180 | MJE170 | 3 | 40 | 50 | 250 | 0.1 | 1 | 0.3 | 0.5 | 12.5 | 50 | 37/77 |
| MJE181 | MJE171 | 3 | 60 | 50 | 250 | 0.1 | 1 | 0.3 | 0.5 | 12.5 | 50 | 38/78 |
| MJE182 | MJE172 | 3 | 80 | 50 | 250 | 0.1 | 1 | 0.3 | 0.5 | 12.5 | 50 | 39/79 |
| MJE521 | MJE371 | 4 | 40 | 40 | 100 | 0.1 | 1 | 0.6 | 1.5 | 40 | 2 | 2C/3C |
| 2N5190 | 2N5193 | 4 | 40 | 25 | 15k | 1.5 | 2 | 0.6 | 2 | 40 | 2 | 2E/3E |
| 2N6037 | 2N6034 | 4 | 40 | 750 | 15k | 2 | 3 | 2.8 | 2 | 40 | 2 | 2J/3J |
| 2N5191 | 2N5194 | 4 | 60 | 25 | 100 | 1.5 | 2 | 0.6 | 1.5 | 40 | 2 | 2E/3E |
| MJE800 | MJE700 | 4 | 60 | 750 | 15k | 1.5 | 3 | 2.5 | 1.5 | 40 | 2 | 2J/3J |
| MJE801 | MJE701 | 4 | 60 | 750 | 15k | 2 | 3 | 2.8 | 2 | 40 | 2 | 2J/3J |
| 2N6038 | 2N6035 | 4 | 60 | 750 | 15k | 2 | 3 | 2.8 | 2 | 40 | 2 | 2J/3J |
| MJE802 | MJE702 | 4 | 80 | 750 | 15k | 1.5 | 3 | 2.5 | 1.5 | 40 | 2 | 2J/3J |
| MJE803 | MJE703 | 4 | 80 | 750 | 15k | 2 | 3 | 2.8 | 2 | 40 | 2 | 2J/3J |
| 2N5192 | 2N5195 | 4 | 80 | 20 | 80 | 1.5 | 2 | 0.6 | 1.5 | 40 | 2 | 2E/3E |
| 2N6039 | 2N6036 | 4 | 80 | 750 | 15k | 2 | 3 | 2.8 | 2 | 40 | 2 | 2J/3J |

TO-3 Power Transistor Reference Guide

| PART NUMBER | | I _C (A) | V _{CEO} (V) | hFE | | I _C (A) @ | | MAX V _{CE(SAT)} (V) @ I _C (A) | P _D (W) | f _T (MHz) | PROCESS (NPN/PNP) |
|-------------|--------|-----------------------|-------------------------|------|--------|----------------------|---------------------|--|-----------------------|-------------------------|----------------------|
| NPN | PNP | | | MIN | MAX | I _C (A) | V _{CE} (V) | | | | |
| 2N5067 | 2N4901 | 5 | 40 | 20 | 80 | 1 | 2 | 0.4 | 87.5 | 4 | 4A/5A |
| 2N4913 | 2N4904 | 5 | 40 | 25 | 100 | 2.5 | 2 | 1 | 87.5 | 4 | 4A/5A |
| 2N5068 | 2N4902 | 5 | 60 | 20 | 80 | 1 | 2 | 0.4 | 87.5 | 4 | 4A/5A |
| 2N4914 | 2N4905 | 5 | 60 | 25 | 100 | 2.5 | 2 | 1 | 87.5 | 4 | 4A/5A |
| 2N5069 | 2N4903 | 5 | 80 | 20 | 80 | 1 | 2 | 0.4 | 87.5 | 4 | 4A/5A |
| 2N4915 | 2N4906 | 5 | 80 | 25 | 100 | 2.5 | 2 | 1 | 87.5 | 4 | 4A/5A |
| 2N5758 | 2N6226 | 6 | 100 | 25 | 100 | 3 | 2 | 1 | 150 | 1 | 4B/5B |
| 2N5759 | 2N6227 | 6 | 120 | 20 | 80 | 3 | 2 | 1 | 150 | 1 | 4B/5B |
| 2N5760 | 2N6228 | 6 | 140 | 15 | 60 | 3 | 2 | 1 | 150 | 1 | 4B/5B |
| 2N5873 | 2N5871 | 7 | 60 | 20 | 100 | 2.5 | 4 | 1 | 115 | 4 | 4A/5A |
| 2N5874 | 2N5872 | 7 | 80 | 20 | 100 | 2.5 | 4 | 1 | 115 | 4 | 4A/5A |
| 2N6055 | 2N6053 | 8 | 60 | 750 | 18,000 | 4 | 3 | 2 | 100 | 4 | 4K/5K |
| MJ1000 | MJ900 | 8 | 60 | 1000 | | 3 | 3 | 2 | 90 | 4 | 4K/5K |
| 2N6056 | 2N6054 | 8 | 80 | 750 | 18,000 | 4 | 3 | 2 | 100 | 4 | 4K/5K |
| MJ1001 | MJ901 | 8 | 80 | 1000 | | 3 | 3 | 2 | 90 | 4 | 4K/5K |
| 2N3713 | 2N4907 | 10 | 40 | 20 | 80 | 4 | 4 | 0.75 | 150 | 4 | 5B |
| 2N3715 | 2N3789 | 10 | 60 | 25 | 90 | 1 | 2 | 1 | 150 | 4 | 4B/5B |
| MJ2840 | 2N3791 | 10 | 60 | 50 | 150 | 1 | 2 | 0.8 | 150 | 4 | 4B/5B |
| 2N5877 | MJ2940 | 10 | 60 | 20 | 100 | 3 | 2 | | 150 | 2 | 4B/5B |
| 2N3714 | 2N4908 | 10 | 60 | 20 | 80 | 4 | 4 | 0.75 | 150 | 4 | 5B |
| 2N3716 | 2N5875 | 10 | 60 | 20 | 100 | 4 | 4 | 1 | 150 | 4 | 4B/5B |
| 2N5632 | 2N3790 | 10 | 80 | 25 | 90 | 1 | 2 | 1 | 150 | 4 | 4B/5B |
| 2N5633 | 2N3792 | 10 | 80 | 50 | 150 | 1 | 2 | 0.8 | 150 | 4 | 4B/5B |
| 2N5634 | 2N4909 | 10 | 80 | 20 | 80 | 4 | 4 | 0.75 | 150 | 4 | 5B |
| 2N5878 | 2N5876 | 10 | 80 | 20 | 100 | 4 | 4 | 1 | 150 | 4 | 4B/5B |
| MJ2841 | MJ2941 | 10 | 80 | 20 | 100 | 4 | 2 | | 150 | 2 | 4B/5B |
| 2N5632 | 2N6229 | 10 | 100 | 25 | 100 | 5 | 2 | 1 | 150 | 1 | 4C/5C |
| 2N5633 | 2N6230 | 10 | 120 | 20 | 80 | 5 | 2 | 1 | 150 | 1 | 4C/5C |
| 2N5634 | 2N6231 | 10 | 140 | 15 | 60 | 5 | 2 | 1 | 150 | 1 | 4C/5C |
| 2N6569 | 2N6594 | 12 | 40 | 15 | 200 | 4 | 3 | | 100 | 4 | 4A/5A |
| MJ2801 | MJ2901 | 15 | 40 | 15 | 60 | 8 | 4 | 1.5 | 115 | 1 | 4A/5A |
| 2N3055 | MJ2955 | 15 | 60 | 20 | 70 | 4 | 4 | 1.1 | 115 | 2.5 | 4A/5A |
| 2N5681 | 2N5879 | 15 | 60 | 20 | 100 | 6 | 4 | 1 | 160 | 4 | 4C/5C |
| BD351 | BD350 | 15 | 80 | 20 | 100 | 6 | 2.5 | 2 | 160 | 4 | 4C/5C |
| 2N5882 | 2N5880 | 15 | 80 | 20 | 100 | 6 | 4 | 1 | 160 | 4 | 4C/5C |



Appendices
Glossary of Symbols
Package Outlines

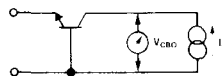


DC PARAMETERS

BV_{CBO}

Collector-Base Breakdown Voltage with Emitter Open-Circuited

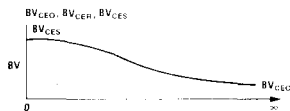
The breakdown voltage of the collector-base junction, measured at a specified current, with the emitter open-circuited.



BV_{CEO}

Collector-Emitter Breakdown Voltage with the Base Open-Circuited

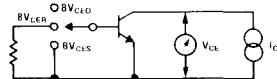
The collector-emitter breakdown voltage, measured at a specified collector current, with the base open-circuited.



BV_{CER}

Collector-Emitter Breakdown Voltage with Resistance between Emitter and Base

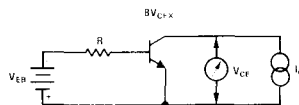
The collector-emitter breakdown voltage measured at a specified current with a specified resistance R connected between the base and the emitter.



BV_{CES}

Collector-Emitter Breakdown Voltage with Base Shorted to Emitter

The collector-emitter breakdown, measured at a specified current, with the base shorted to the emitter.



BV_{CEX}

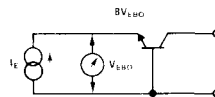
Collector-Emitter Breakdown Voltage at a Specified Condition

The collector-emitter breakdown voltage measured at a specified current with the base-emitter junction forward or reverse biased by a specified voltage or current.

BV_{EBO}

Emitter-Base Breakdown Voltage with Collector Open-Circuited

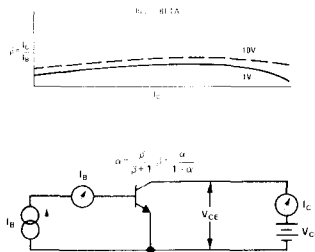
The emitter-base breakdown voltage, measured at a specified current, with collector open-circuited.



h_{FE}

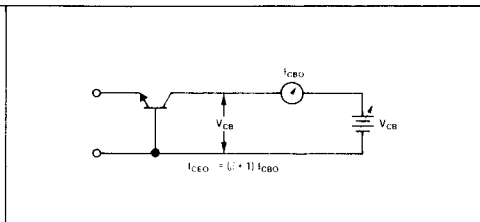
Common-Emitter DC Current Gain

The ratio of DC collector current to DC base current measured at a specified collector-emitter voltage and a specified collector current.



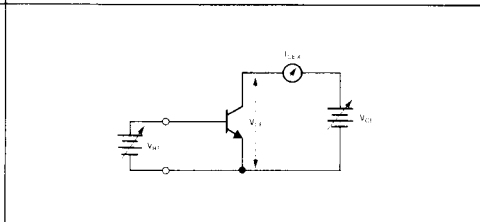
I_{CBO} **Inverse Collector-Base Current**

The collector-base current with the junction reverse biased by a specified voltage, with the emitter open-circuited.



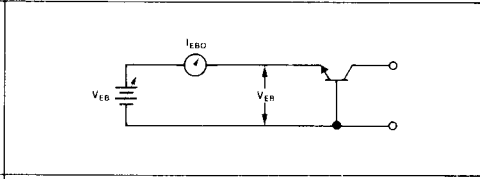
I_{CEX} **Inverse Collector-Emitter Current at a Specified Condition**

The collector-emitter current measured at a specified collector-emitter voltage with the base forward or reverse biased by a specified voltage or current.



I_{EBO} **Inverse Emitter-Base Current**

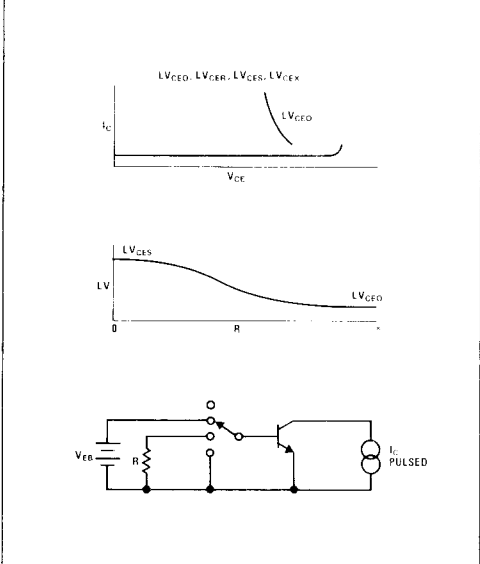
The emitter-base current with the junction reverse biased by a specified voltage with the collector open-circuited.



LV_{CEO} , LV_{CER} , LV_{CES} , LV_{CEX} or, $V_{CEO}(sust)$, $V_{CER}(sust)$, $V_{CES}(sust)$, $V_{CEX}(sust)$

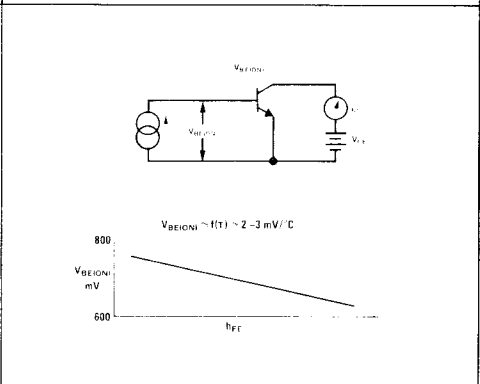
Pulsed Limiting Breakdown Voltages

These are similar to the corresponding, above defined, BV parameters but are measured at a specified high current point where collector-emitter voltage is lowest. The duration of the pulse and its duty cycle must be specified. The letter L indicates LIMITING Value and is measured outside the negative resistance zone of the reverse characteristic.

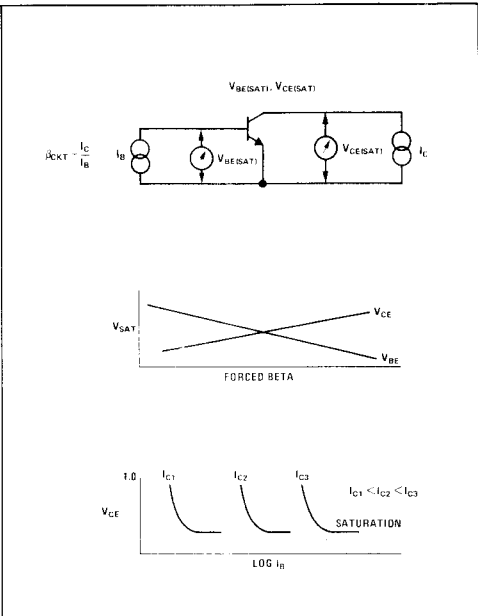


$V_{BE(ON)}$ **Unsaturated Base-Emitter Voltage**

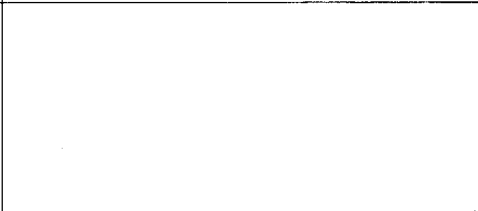
The base-emitter voltage measured in the common-emitter connection at a specified collector to emitter voltage and specified collector current.



| | |
|---------------|--|
| $V_{BE(SAT)}$ | <p>Base-Emitter Saturation Voltage</p> <p>The base-emitter voltage measured in the common-emitter connection at a specified collector and base saturation currents.</p> |
| $V_{CE(SAT)}$ | <p>Collector-Emitter Saturation Voltage</p> <p>The collector-emitter voltage measured in the common-emitter connection at specified collector and base saturation currents.</p> |

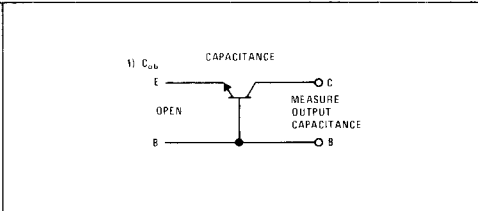


| | |
|----------|--|
| V_{RT} | <p>Reach Through Voltage</p> |
| V_{PT} | <p>Punch Through Voltage</p> <p>The collector-base voltage above which an increase of applied voltage can be measured in the emitter-base open circuit.</p> |



SMALL SIGNAL PARAMETERS

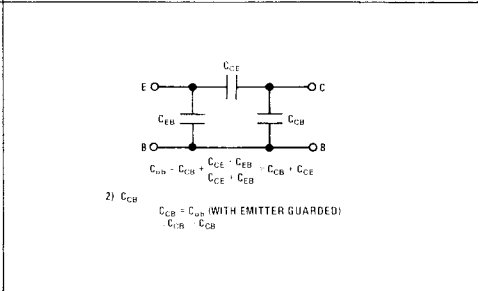
| | |
|----------|--|
| C_{ob} | <p>Common-Base Output Capacitance</p> <p>The common-base output capacitance with input ac open.</p> |
|----------|--|



| | |
|----------|---|
| C_{re} | <p>Common Emitter Reverse Transfer Capacitance</p> <p>This parameter is the imaginary part of y_{re}. When $I_C = 0$, C_{re} is identical to C_{CB}.</p> |
|----------|---|



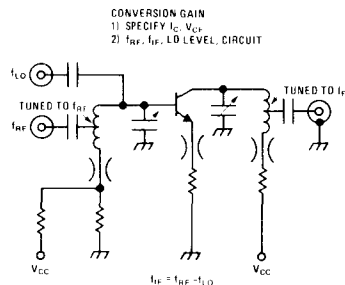
| | |
|----------|---|
| C_{TE} | <p>Base-Emitter Capacitance</p> <p>The capacity of the base-emitter junction at a specified inverse voltage with the collector open.</p> |
| C_{CB} | <p>Collector Base Capacitance</p> <p>Collector Base Capacitance measured at some Specified Collector Base Voltage.</p> |



CG_e, CG_b

Conversion Gain, Common-Emitter or Common-Base

The ratio of the output power of a mixer, at one specified frequency, to its input power, at another specified frequency. This parameter is a function of oscillator injection voltage and the mixer operating point.



f_{ub}, f_{hfb}

Common-Base Cut Off Frequency

The frequency at which the h_{fb} (α) is reduced to 0.707 of its low frequency value.

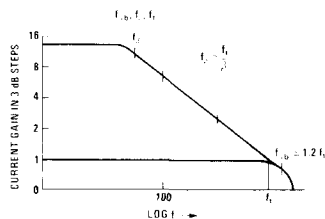
f_{β}, f_{hfe}

Common-Emitter Cut Off Frequency

The frequency at which the h_{fe} (β) is reduced to 0.707 of its low frequency value.

Gain Band-Width Product

The common-emitter current gain bandwidth product in the frequency range where the current gain is falling at approximately 6 db/octave.



f_t

Maximum Frequency of Oscillation

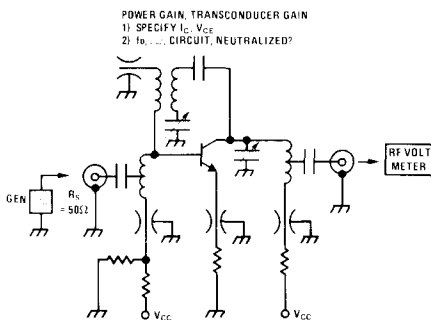
This parameter is a device figure of merit that is calculated from f_t and $rb'c_c$.

$f_{MAX} = \text{MAX FREQUENCY OF OSCILLATION FREQUENCY AT WHICH MAG} = 1$

$$f_{MAX} = \sqrt{\frac{f_T}{8\pi rb'c_c}} = f \sqrt{PG}$$

G_e

Common-Emitter Power Gain



C_{TE}

Common Emitter Transducer Gain

A test fixture must be specified.

$$G_{TE} = \frac{\text{POWER DELIVERED TO THE LOAD}}{\text{POWER AVAILABLE FROM THE SOURCE}}$$

GMA

Stability Limited Gain or Gain Maximum Available

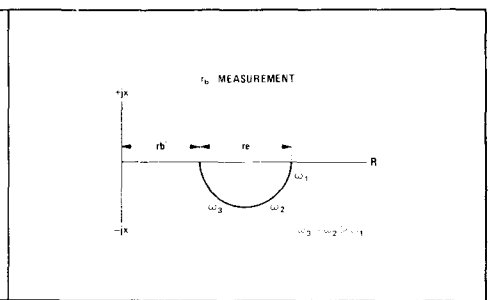
This parameter is a device figure of merit and must be calculated from the two port "y" parameters.

$$GMA = 10 \text{ LOG } \left[\frac{|Y_{fe}|}{|Y_{re}|} \left(K - \sqrt{K^2 - 1} \right) \right]$$

NOT DEFINED FOR $K < 1$

| | |
|--|---|
| | <p style="text-align: center;">h Parameters</p> <div style="text-align: center;"> </div> <p style="text-align: center;">WHERE e_1, i_1, e_2, i_2 ARE SMALL SIGNAL VOLTAGES AND CURRENTS THE h - (HYBRID) PARAMETERS ARE DEFINED BY $e_1 = h_{11} i_1 + h_{12} e_2$ $i_1 = h_{21} i_2 + h_{22} e_2$ AND FOR COMMON EMITTER OPERATION THESE EQUATIONS BECOME $e_1 = h_{ie} i_1 + h_{re} e_2$ $i_2 = h_{fe} i_1 + h_{oe} e_2$</p> |
| <p>h_{fe}</p> <p>Common-Emitter Current Gain</p> <p>The common-emitter forward current transfer ratio with output ac shorted. This is a complex quantity.</p> | <p style="text-align: center;">h PARAMETERS COMMON EMITTER</p> <div style="text-align: center;"> </div> |
| <p>h_{ie}</p> <p>Common-Emitter Input Impedance</p> <p>The common-emitter input impedance with the output ac shorted. This is a complex quantity.</p> | <div style="text-align: center;"> </div> |
| <p>h_{oe}</p> <p>Common-Emitter Output Admittance</p> <p>The common-emitter output admittance with the input ac open. This is a complex quantity.</p> | <div style="text-align: center;"> </div> |
| <p>h_{re}</p> <p>Common-Emitter Reverse Voltage Transfer Ratio</p> <p>The common-emitter reverse voltage transfer ratio with input ac open. This is a complex quantity.</p> | <div style="text-align: center;"> </div> |
| <p>MAG</p> <p>Maximum Available Gain</p> <p>Device figure of merit that must be calculated from the two port "y" parameters.</p> | $MAG = 10 \text{ LOG } \frac{ Y_{21} ^2}{4 \text{ Re } (Y_{11}) \text{ RE } (Y_{22})}$ |
| <p>MSG</p> <p>Maximum Stable Gain</p> <p>This parameter is a device figure of merit that is calculated from the two port "y" parameters.</p> | $MSG = 10 \text{ LOG } \frac{ Y_{fe} }{ Y_{re} }$ |
| <p>NF</p> <p>Noise Figure</p> <p>Noise figure = $10 \log_{10} F$, where F is the ratio of total output noise power to the output power due solely to the thermal noise of the source impedance.</p> | <p style="text-align: center;">NOISE FIGURE MUST SPECIFY 1) V_{ce}, I_c 2) R_{s}, f, PBW</p> <div style="text-align: center;"> </div> |

r_{bb}' , r_{b}' **Base << Spreading >> Resistance**
 Equivalent to the real part of h_{ie} at some specified very high frequency.



$r_{b}'C_c$ **Collector Base Time Constant**
 This parameter is a device figure of merit and is measured in a specified test circuit.

$r_{b}'C_c =$ **COLLECTOR BASE TIME CONSTANT**
 SPECIFY - $I_C, V_{CE},$ FREQUENCY

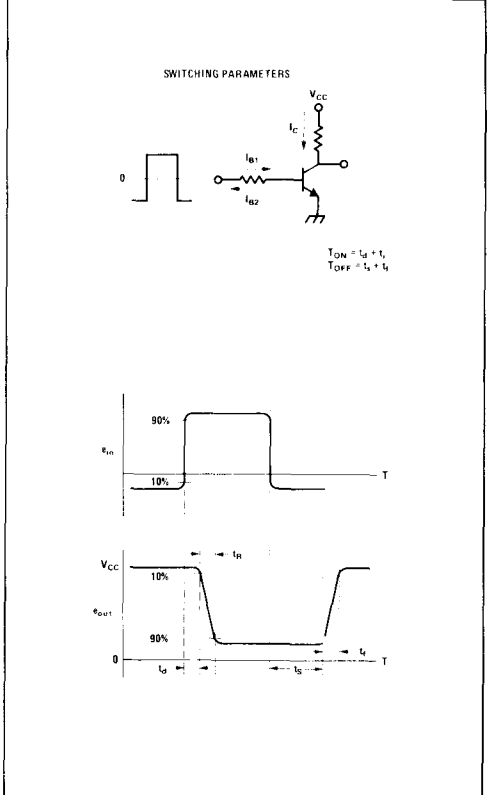
Common-Emitter Switching Parameters
 In the following, drive circuit conditions and collector circuit conditions must be specified. The transition times of the input must be negligible compared to the measured times.

t_d **Delay Time**
 The time interval during turn-on from the point when the input pulse at the base reaches 10% of its full amplitude to the point when the collector pulse changes from 0 to 10% of its maximum amplitude.

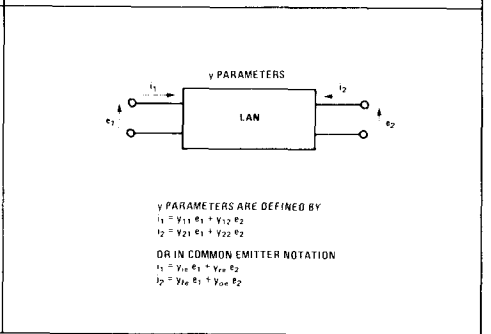
t_r **Rise Time**
 The time interval during turn-on in which the collector pulse changes from 10% to 90% of its maximum amplitude.


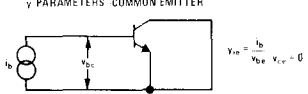
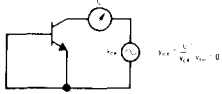
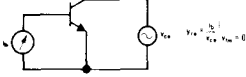

t_s **Storage Time**
 The time interval during turn-off from the point when the turn-off pulse at the base changes from 100% to 90% of its full amplitude to the time when the collector current has changed from 100% to 90% of its maximum amplitude.

t_f **Fall Time**
 The time interval during turn-off in which the collector pulse decreases from 90% to 10% of its maximum amplitude.



y Parameters

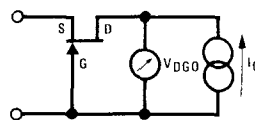


| | | |
|---------------------------------------|---|--|
| <p>Y_{fe}</p> | <p>Common-Emitter Forward Transfer Admittance</p> <p>The common-emitter forward transfer admittance with output ac shorted. This is a complex quantity ($g_{fe} + jb_{fe}$).</p> |  |
| <p>Y_{ie}</p> | <p>Common-Emitter Input Admittance</p> <p>The common-emitter input admittance with output ac shorted. This is a complex quantity ($g_{ie} + b_{ie}$).</p> | <p>y PARAMETERS COMMON EMITTER</p>  |
| <p>Y_{oe}</p> | <p>Common-Emitter Output Admittance</p> <p>The common-emitter output admittance with input ac open. This is a complex quantity ($g_{oe} + jb_{oe}$).</p> |  |
| <p>Y_{re}</p> | <p>Common-Emitter Reverse Transfer Admittance</p> <p>The common-emitter reverse transfer admittance with input ac shorted. This is a complex quantity ($g_{re} + jb_{re}$).</p> |  |
| <p>LARGE SIGNAL PARAMETERS</p> | | |
| <p>η</p> | <p>Collector Efficiency</p> <p>This parameter applies to oscillators and class C amplifiers, predominantly. It is defined as the ratio of RF Power Out/DC Power In.</p> | <p>η - COLLECTOR EFFICIENCY</p> $\eta = \frac{P_o(\text{RF})}{P_{in}(\text{DC})} = \frac{v_i}{I_c \times V_{ce}}$ |
| <p>P_o</p> | <p>Power Out</p> <p>This parameter applies to oscillators. The units are watts and a test circuit must be specified.</p> |  <p>SPECIFY - I_c, V_{ce} UNDER QUIESCENT CONDITIONS - $I_{c, R_{L, OAD}}$</p> |
| <p>THERMAL PARAMETERS</p> | | |
| <p>R_{TH}</p> | <p>Internal Junction-to Case Thermal Resistance</p> <p>The rated increase of junction temperature with respect to the case temperature per unit of dissipated power. It is also called Thermal Resistance with infinite heat sink.</p> | <p>θ_{JC} Junction-to Case Thermal Rating</p> <p>θ_{JA} Junction-to Ambient Thermal Rating</p> |

DC PARAMETERS

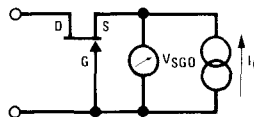
**BV_{DG0} (V)
or BV_{GDO}** **Drain-Gate Breakdown Voltage with Source Open-Circuited**

The breakdown voltage of the drain-gate junction, measured at a specified current with the source open-circuited.



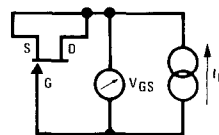
**BV_{SG0} (V)
or BV_{GSO}** **Source-Gate Breakdown Voltage with Drain Open-Circuited**

The breakdown voltage of the source-gate junction, measured at a specified current, with the drain open-circuited.



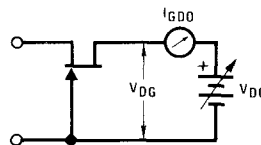
**BV_{GSS} (V)
or $BV_{(BR)GSS}$** **Source-Gate Breakdown Voltage with Drain-Source Shorted**

The breakdown voltage of the source-gate and drain-gate junctions, measured at a specified current with the drain-source shorted.



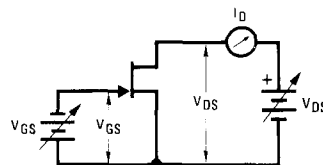
**I_{DG0} (pA)
or I_{GDO}** **Drain-Gate Leakage Current, Source Open-Circuited**

The leakage current of the drain-gate junction, measured at a specified voltage, with the source open-circuited.



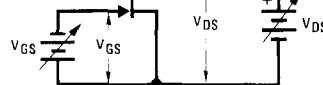
**I_D (μA)
or $I_{D(ON)}$** **Drain ON Current**

The drain current, measured at a specified drain-source voltage and gate-source voltage.



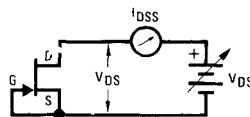
$I_{D(OFF)}$ (pA) **Drain Cutoff Current**

The drain cutoff current, measured at a specified drain-source voltage and gate-source voltage.



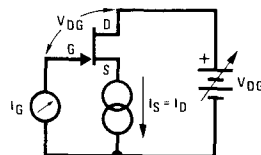
I_{DSS} (mA) **Drain Saturation Current**

The drain current, measured at a specified drain-source voltage with the source shorted to the gate ($V_{GS} = 0$)



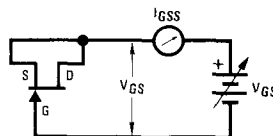
**I_G (pA)
or $I_{G(ON)}$** **Gate Leakage Current with Drain Current Flowing**

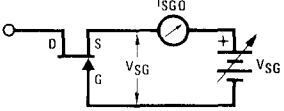
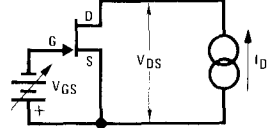
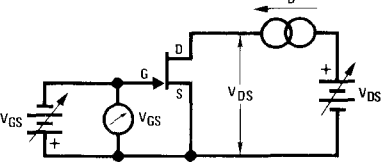
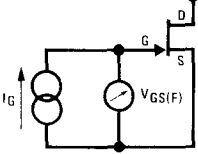
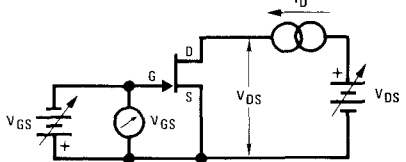
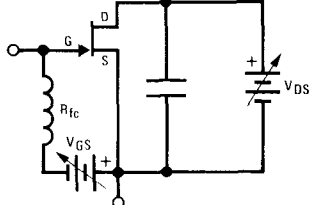
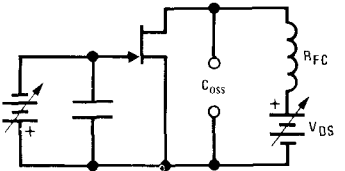
The gate leakage current, measured at a specified drain current and drain-gate voltage.



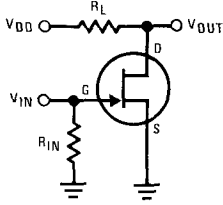
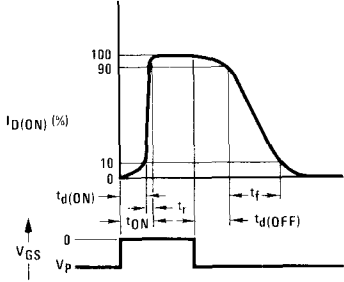
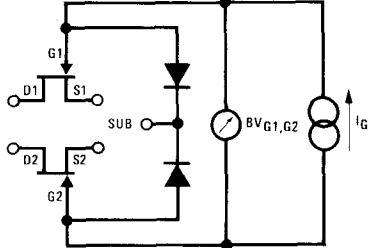
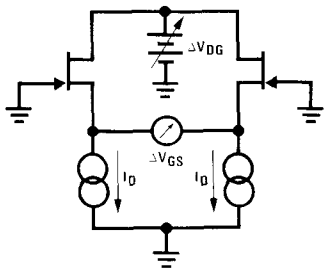
I_{GSS} (pA) **Gate-Source Reverse Leakage Current with Drain-Source Shorted**

The gate-source reverse leakage current measured at a specified gate-source voltage.



| | | |
|---|---|--|
| <p>I_{SGO} (pA) or I_{GSO}</p> | <p>Source-Gate Reverse Leakage Current with Drain Open-Circuited</p> <p>The leakage current of the source-gate junction, measured at a specified voltage, with the drain open-circuited.</p> |  |
| <p>r_{DS} (Ω) or r_{ds}, R_{DS}, $r_{DS(ON)}$</p> | <p>Drain-Source ON Resistance</p> <p>The drain-source ON resistance, measured at a specified gate-source voltage and drain current.</p> |  |
| <p>$V_{DS(ON)}$ (mV)</p> | <p>Drain-Source ON Voltage</p> <p>The drain-source ON voltage, measured at a specified gate-source voltage and drain current.</p> | <p style="text-align: center;">$r_{DS} = \frac{V_{DS}}{I_D}$</p> |
| <p>V_{GS} (V) or $V_{GS(ON)}$, V_G</p> | <p>Operating Gate-Source Voltage</p> <p>The gate-source voltage, measured at a specified drain current and drain-source voltage.</p> |  |
| <p>$V_{GS(F)}$ (V)</p> | <p>Forward Gate-Source Voltage</p> <p>The forward gate-source voltage, measured at specified current.</p> |  |
| <p>$V_{GS(OFF)}$ (V) or V_p</p> | <p>Gate-Source Cutoff (Pinch-Off) Voltage</p> <p>The gate-source cutoff voltage, measured at a specified drain current and drain-source voltage.</p> |  |
| SMALL SIGNAL PARAMETERS | | |
| <p>C_{iss} (pF) or C_{iss}, C_{gss}</p> | <p>Common-Source Input Capacitance</p> <p>The common-source input capacitance measured between the gate and source with the drain A-C shorted to the source at specified drain-source and gate-source voltages.</p> |  |
| <p>C_{oss} (pF) or C_{os}, C_{dss}</p> | <p>Common-Source Output Capacitance</p> <p>The common-source output capacitance, measured between the drain and source with the source A-C shorted to the gate at specified drain-source and gate-source voltages.</p> |  |

| | | |
|--|---|--|
| <p>C_{rss} (pF) or C_{rs}, C_{dg}</p> | <p>Common-Source Reverse Transfer Capacitance</p> <p>The common-source reverse transfer capacitance, measured between the drain and gate at specified drain-source and gate source voltages.</p> | |
| <p>e_n (nV/$\sqrt{\text{Hz}}$) or e_n, V_n, E_n</p> | <p>Equivalent Input Noise Voltage</p> <p>The equivalent input noise voltage per unit bandwidth, measured with the input A-C shorted to the source at a specified operating condition.</p> | |
| <p>g_{fg} (mV) or Y_{fg}</p> | <p>Common-Gate Forward Transconductance</p> <p>The common-gate forward transconductance with the output A-C shorted. This is a complex quantity ($g_{fg} + jbf_g$).</p> | $Y_{fg} = \frac{I_D}{V_{GS}} \Big _{V_{DS} = 0}$ |
| <p>g_{fs} (mV) or g_m, Y_{fs} $\text{Re}\{Y_{fs}\}$</p> | <p>Common-Source Forward Transconductance</p> <p>The common source forward transconductance with the output A-C shorted. This is a complex quantity ($g_{fs} + jbf_s$).</p> | $Y_{fs} = \frac{I_D}{V_{GS}} \Big _{V_{DS} = 0}$ |
| <p>g_{is} (μV) or Y_{is}</p> | <p>Common-Source Input Conductance</p> <p>The common-source input conductance with the output A-C shorted. This is a complex quantity ($g_{is} + jbf_s$).</p> | $Y_{is} = \frac{I_G}{V_{GS}} \Big _{V_{DS} = 0}$ |
| <p>g_{os} (μV) or Y_{os}</p> | <p>Common-Source Output Conductance</p> <p>The common source output conductance with the input A-C shorted. This is a complex quantity ($g_{os} + jbf_{os}$).</p> | $Y_{os} = \frac{I_D}{V_{DS}} \Big _{V_{GS} = 0}$ |
| <p>G_{pg} (dB)</p> | <p>Common-Gate Power Gain</p> <p>The common-gate power gain is the ratio of output power to input power.</p> | $G_p = 10 \log_{10} \frac{P_o}{P_i}$ |
| <p>G_{ps} (dB)</p> | <p>Common-Source Power Gain</p> <p>The common-source power gain is the ratio of output power to input power.</p> | $G_p = 10 \log_{10} \frac{P_o}{P_i}$ |
| <p>i_n (pA/$\sqrt{\text{Hz}}$)</p> | <p>Equivalent Input Noise Current</p> <p>The equivalent input noise current measured with the input open-circuited under specified operating conditions.</p> | |

| | | |
|---|---|--|
| <p>NF (dB)</p> | <p>Spot Noise Figure</p> <p>Noise figure = $10 \log_{10} F$ where F is noise factor which is the ratio of the total output noise power to the output noise power of the source. Measured at specified operating conditions and source resistance.</p> | $F = \frac{\text{Total Output Noise Power}}{\text{Source Output Noise Power}}$ |
| <p>COMMON-SOURCE SWITCHING PARAMETERS</p> | | |
| <p>$t_d(\text{ON})$</p> | <p>Turn-On Delay Time</p> <p>The time interval during turn-on from the point when the input pulse at the gate reaches 10% of its full amplitude to the point when the drain pulse changes from 0 to 10% of its maximum amplitude.</p> |  |
| <p>t_r</p> | <p>Rise Time</p> <p>The time interval during turn-on in which the drain current pulse changes from 10% to 90% of its maximum amplitude.</p> | $I_{D(\text{ON})} = \frac{V_{DD} - V_{DS(\text{ON})}}{R_L}$ |
| <p>$t_d(\text{OFF})$</p> | <p>Turn-Off Delay Time</p> <p>The time interval during turn-off from the point when the turn-off pulse at the gate changes from 100% to 90% of its full amplitude to the time when the drain current has changed from 100% to 90% of its maximum amplitude.</p> |  |
| <p>t_f</p> | <p>Fall Time</p> <p>The time interval during turn-off in which the drain current pulse decreases from 90% to 10% of its maximum amplitude.</p> | |
| <p>DUAL FET PARAMETERS</p> | | |
| <p>$BV_{G1, G2}$ (V) or BV_{G1-2}</p> | <p>Gate to Gate Breakdown Voltage</p> <p>The breakdown voltage of the gate to gate junctions, measured at a specified current.</p> |  |
| <p>CMRR (dB) or CMR</p> | <p>Common-Mode Rejection Ratio</p> <p>The common-mode rejection ratio is the ratio of the change in differential gate voltage with a change in the drain to gate voltage.</p> $CMRR = 20 \log_{10} \frac{\Delta V_{DG}}{\Delta V_{OS}}$ |  |

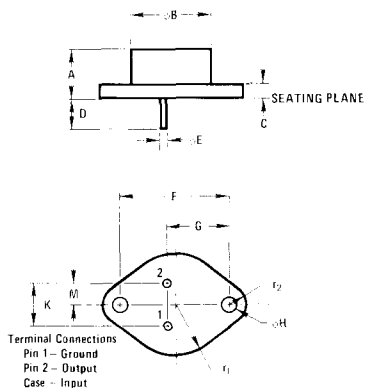
| | | |
|---|--|--|
| <p>g_{fs1-2} (%) or g_{fs1}/g_{fs2}</p> | <p>Common-Source Forward Transconductance Ratio (Match)</p> <p>The transconductance ratio = $g_{fs1}/g_{fs2} \times 100$ (%) measured at specified drain-gate voltage and drain current.</p> | |
| <p>g_{oss1-2} (μV) or g_{os1-2}</p> | <p>Common-Source Output Conductance (Match)</p> <p>Output conductance match = $g_{os1} - g_{os2}$ measured at specified drain-gate voltage and drain current.</p> | |
| <p>I_{DSS1-2} (%) or I_{DS1-2}, I_{DSS1}/I_{DSS2}</p> | <p>Drain Saturation Current Ratio (Match)</p> <p>The drain saturation current ratio = $I_{DSS1}/I_{DSS2} \times 100\%$ measured at specified drain-source voltages.</p> | |
| <p>I_{G1-2} (pA)</p> | <p>Differential Gate Leakage Current</p> <p>Differential gate leakage current = $I_{G1} - I_{G2}$ measured at specified drain-gate voltage and drain current.</p> | |
| <p>$I_{G1, G2}$ (pA)</p> | <p>Gate to Gate Reverse Leakage Current</p> <p>The gate to gate reverse leakage measured at a specified voltage monolithic dual with diode isolation shown.</p> | |
| <p>V_{GS1-2} (mV) or ΔV_{GS}, V_{os}, $V_{GS1} - V_{GS2}$</p> | <p>Differential Gate-Source Voltage</p> <p>The differential gate-source voltage, measured at a specified drain-gate voltage and drain current.</p> | |
| <p>ΔV_{GS1-2} ($\mu V/^{\circ}C$) or $\Delta V_{GS1} - V_{GS2} /\Delta T$ $\Delta V_{os}/\Delta T$</p> | <p>Differential Gate-Source Voltage Drift</p> <p>The differential gate-source voltage drift is the change in the differential gate-source voltage with a change in device temperature at a specified operating condition.</p> $\frac{\Delta V_{os}}{\Delta T} = \left \frac{(V_{GS1} - V_{GS2}) T_1 - (V_{GS1} - V_{GS2}) T_2}{T_1 - T_2} \right $ | |

Dimensions are in inches
(millimeters)

Numbers in parentheses behind package titles are NS internal package codes.

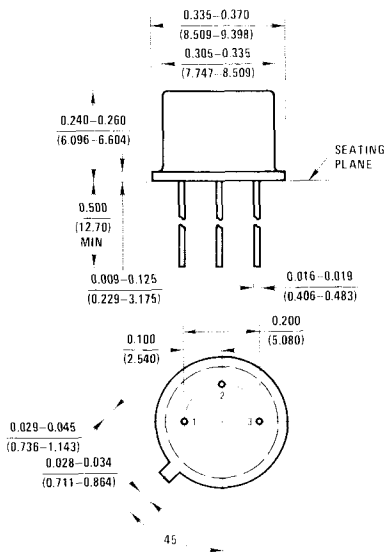
TO-3 (98)

| SYMBOL | INCHES (MILLIMETERS) | |
|--------|-------------------------|----------------|
| | MIN | MAX |
| A | 0.250 (6.35) | 0.450 (11.43) |
| ∅E | 0.038 (0.965) | 0.043 (1.092) |
| ∅B | | 0.875 (22.225) |
| K | 0.420 (10.668) | 0.440 (11.176) |
| M | 0.205 (5.207) | 0.225 (5.715) |
| C | | 0.135 (3.429) |
| D | 0.312 (7.925) | |
| ∅H | 0.151 (3.835) | 0.161 (4.089) |
| F | 1.177 (29.896) | 1.197 (30.404) |
| r1 | | 0.525 (13.335) |
| r2 | | 0.188 (4.775) |
| G | 0.655 (16.637) | 0.675 (17.145) |



TO-5 (04)

| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |

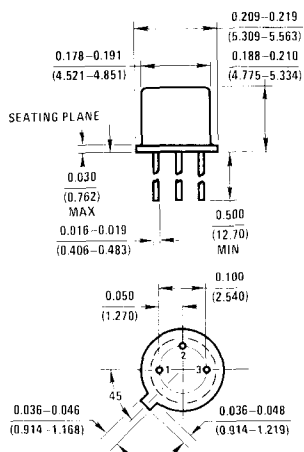


TO-18 (02, 11, 19)

| PIN | T (02), (19) |
|-----|--------------|
| 1 | E |
| 2 | B |
| 3 | C |

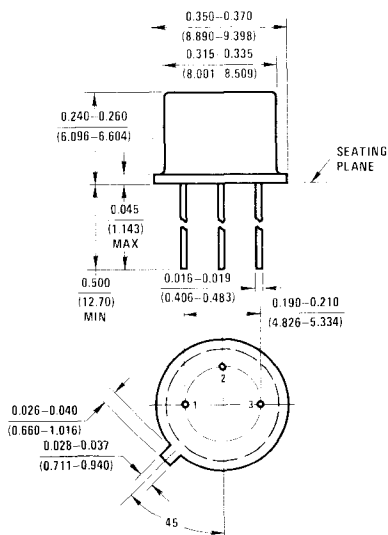
| PIN | FET N (02) |
|-----|------------|
| 1 | S |
| 2 | D |
| 3 | G |

| PIN | FET P (11) |
|-----|------------|
| 1 | S |
| 2 | G |
| 3 | D |



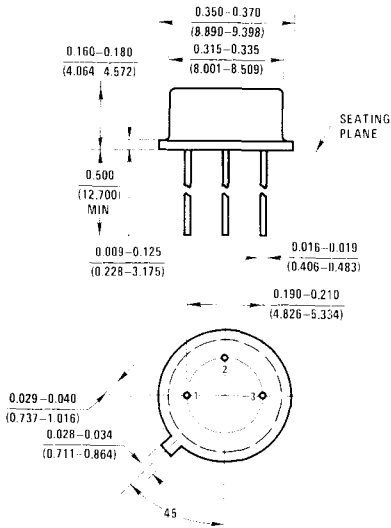
TO-39 (10, 16)*

| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |



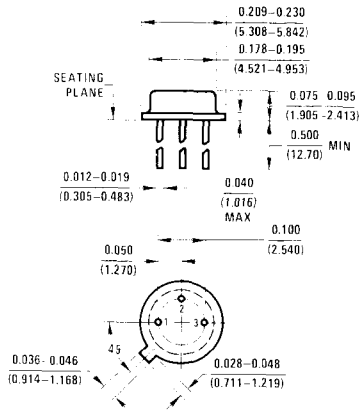
TO-39 (17) LO-PROFILE

| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |



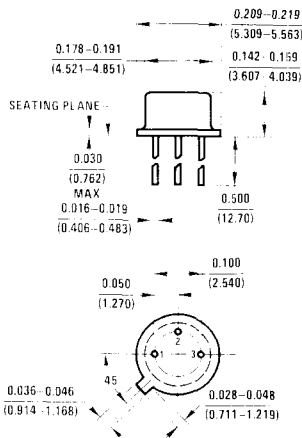
TO-46 (06)

| PIN | T |
|-----|---|
| 1 | E |
| 2 | B |
| 3 | C |



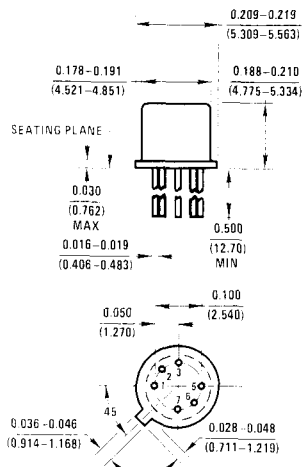
TO-52 (07, 18)

| PIN | T (18) | FET (07) |
|-----|--------|----------|
| 1 | E | S |
| 2 | B | D |
| 3 | C | G |



TO-71 (08, 12)

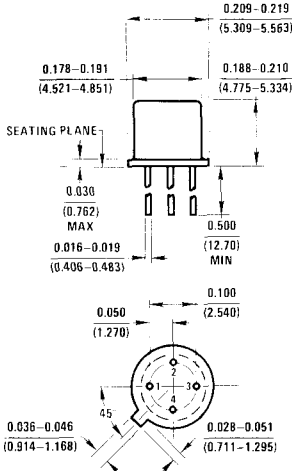
| PIN | T (08) | FET (12) |
|-----|--------|----------|
| 1 | E | S1 |
| 2 | B | D1 |
| 3 | C | G1 |
| 5 | E | S2 |
| 6 | B | D2 |
| 7 | C | G2 |



TO-72, (23, 25, 28, 29)

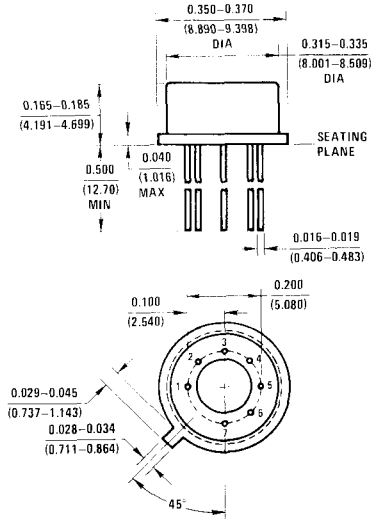
| PIN | T (25) | FET N (25, 29) |
|-----|--------|----------------|
| 1 | E | S |
| 2 | B | D |
| 3 | C | G |
| 4 | GND | CASE |

| PIN | T (28) | FET P (23) |
|-----|--------|------------|
| 1 | B | S |
| 2 | E | G |
| 3 | C | D |
| 4 | GND | CASE |



TO-78 (24, 27)

| PIN | T (27) | FET (24) |
|-----|--------|----------|
| 1 | C | S1 |
| 2 | B | D1 |
| 3 | E | G1 |
| 5 | E | S2 |
| 6 | B | D2 |
| 7 | C | G2 |



TO-92 (71, 72, 74, 76, 77, 78)

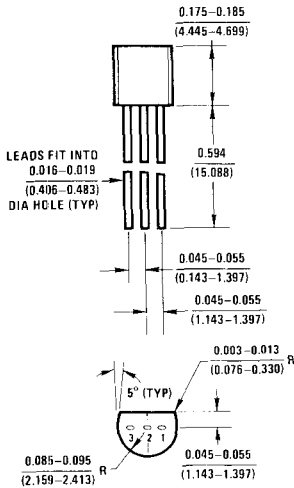
| PIN | 75/72 (Std) | |
|-----|-------------|-----|
| | T | FET |
| 1 | C | G |
| 2 | B | S |
| 3 | E | D |

| PIN | 76/71 | |
|-----|-------|-----|
| | T | FET |
| 1 | C | G |
| 2 | E | D |
| 3 | B | S |

| PIN | 74 | |
|-----|----|-----|
| | T | FET |
| 1 | B | S |
| 2 | C | G |
| 3 | E | D |

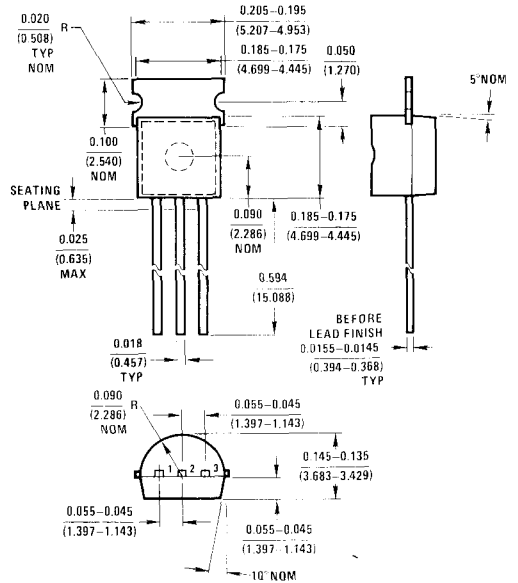
| PIN | 77 | |
|-----|----|-----|
| | T | FET |
| 1 | E | D |
| 2 | B | S |
| 3 | C | G |

| PIN | 78 | |
|-----|----|-----|
| | T | FET |
| 1 | B | S |
| 2 | E | G |
| 3 | C | D |



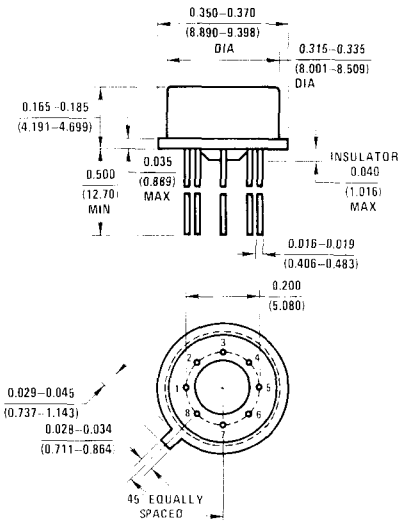
92-PLUS (90, 91)

| PIN | PACKAGE 90 | PACKAGE 91 |
|-----|------------|------------|
| 1 | Base | Collector |
| 2 | Collector | Base |
| 3 | Emitter | Emitter |

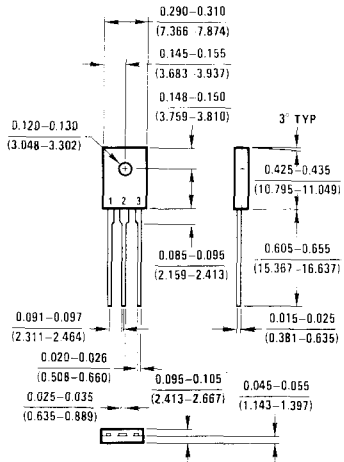


TO-99 (22)

| PIN | FET |
|-----|-----|
| 1 | S |
| 2 | D |
| 3 | G |
| 4 | SUB |
| 5 | S |
| 6 | D |
| 7 | G |
| 8 | NC |



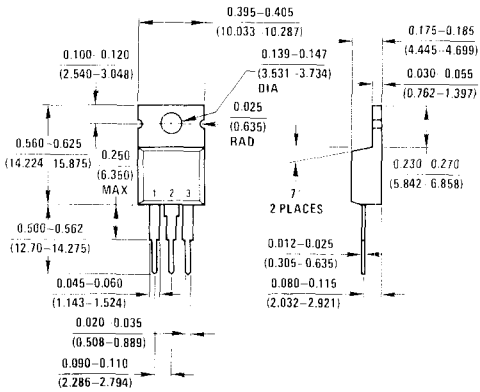
TO-126 (38)



- Pin 1. Emitter
- 2. Collector
- 3. Base

When mounting the device, torque not to exceed 6.0 in lb.
If lead bending is required, use suitable clamp or other supports between transistor case and point of bend.

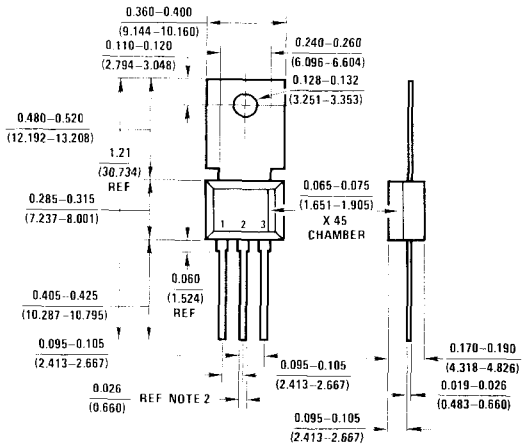
TO-220 (37)



- Pin 1. Base
- 2. Collector
- 3. Emitter

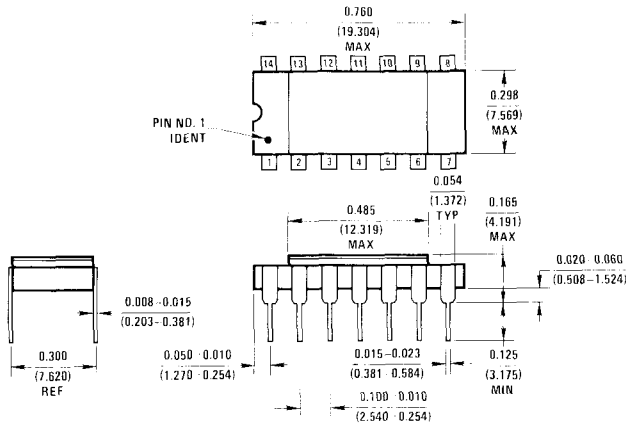
TO-202 (35, 36)

| PIN | PACKAGE 35 | PACKAGE 36 |
|-----|------------|------------|
| | T | T |
| 1 | Emitter | Emitter |
| 2 | Base | Collector |
| 3 | Collector | Base |

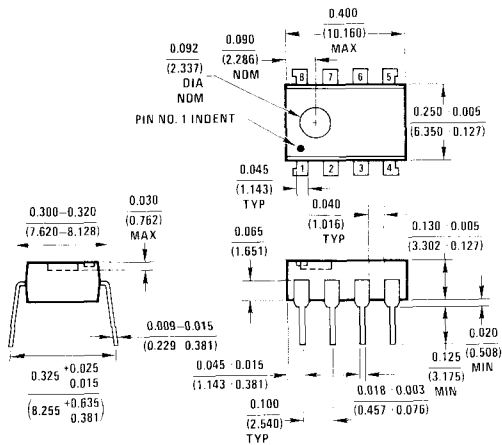


NOTES:
1. ALL DIM. ARE IN INCHES AND ARE REF. UNLESS TOLERANCED.
2. 043-057 LEAD WIDTH WITHIN 0.100 OF BODY.

CAVITY DUAL-IN-LINE PACKAGE D (40)

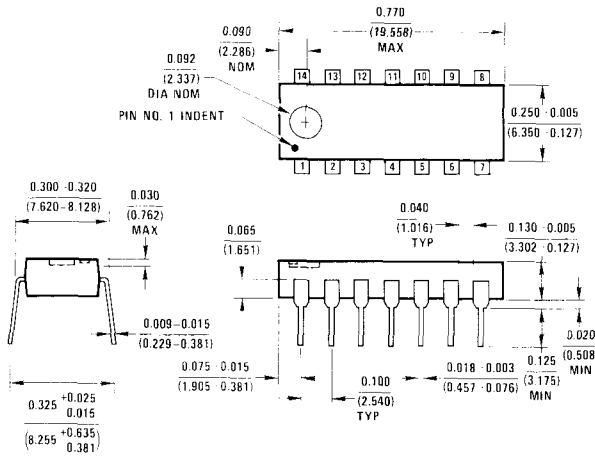


MOLDED MINI-DIP (60, 67)



| PIN | 60 | 67 |
|-----|----|----|
| 1 | NC | S1 |
| 2 | S1 | D1 |
| 3 | D1 | NC |
| 4 | G1 | G1 |
| 5 | S2 | S2 |
| 6 | D2 | D2 |
| 7 | G2 | NC |
| 8 | NC | G2 |

MOLDED DUAL-IN-LINE PACKAGE N (39)



| NS PACKAGE CODE | JEDEC CODE | NS PACKAGE CODE | JEDEC CODE |
|-----------------|--|-----------------|-----------------------------------|
| 02 | TO-18 Glass | 37 | TO-220 BCE |
| 03 | TO-5 Glass | 38 | TO-126 ECB |
| 04 | TO-5 Glass | 39 | TO-116 14-Lead M/DIP CN |
| 05 | TO-71 Diff. Amp. TO-18 | 40 | TO-116 14-Lead Ceramic DIP CD |
| 06 | TO-46 Solid | 41 | TO-116 14-Lead Molded Array |
| 07 | TO-52 Solid | 56 | TO-100 10-Lead Header |
| 08 | TO-71 Diff. Amp. TO-18 | 57 | TO-100 10-Lead Header |
| 09 | TO-39 Solid Kovar | 58 | 16-Lead Side Braze DIP |
| 10 | TO-39 Solid Steel | 59 | 16-Lead Side Braze DIP |
| 11 | TO-18 Glass SDG | 60 | 8-Lead Molded DIP, Plastic (CN) |
| 12 | TO-71 Glass TO-18 Diff. Amp. | 61 | 14-Lead Molded DIP, Plastic (CN) |
| 13 | TO-46 Header/TO-72 Can (4-Lead) | 62 | 16-Lead Molded DIP, Plastic (CN) |
| 16 | TO-39 Solid Kovar | 63 | 14-Lead Side Braze DIP |
| 17 | TO-39 Solid Steel Low Profile | 64 | 14-Lead Side Braze DIP |
| 18 | TO-52 Glass | 65 | 14-Lead Ceramic DIP (CJ) |
| 19 | TO-18 Solid | 66 | 16-Lead Ceramic DIP (CJ) |
| 22 | TO-5 10-Lead | 67 | 8-Lead Molded DIP (CN) |
| 23 | TO-72 Glass 4-Lead TO-18 SGD | 69 | TO-92 3-Lead Top Gate Plastic GSD |
| 24 | TO-78 Glass TO-5 Diff. Amp. | 71 | TO-92 BEC |
| 25 | TO-72 4-Lead TO-18 EBC | 72 | TO-92 EBC |
| 27 | TO-78 Diff. Amp. TO-5 | 74 | TO-92 ECB |
| 28 | TO-72 4-Lead TO-18 BEC | 75 | TO-92 Faraday Shield EBC |
| 29 | TO-72 Glass TO-18 SDG 4-Lead Top Gate | 76 | TO-92 Faraday Shield BEC |
| 30 | TO-78 Diff. Amp. TO-5 | 77 | TO-92 CBE |
| 31 | TO-202 ECB | 78 | TO-92 Faraday Shield CEB |
| 32 | TO-126 EC- | 79 | TO-92 C-E |
| 35 | TO-202 EBC | 90 | Mini-Watt ECB |
| 36 | TO-202 BCE | 91 | Mini-Watt EBC |
| | | 98 | TO-3 |



Section 1

NPN Transistors

1



SATURATED SWITCHES

| Type No. | Case Style | V _{CE0} [*] (V) Min | V _{CE0} [*] (V) Max | V _{BE0} [*] (V) Min | V _{BE0} [*] (V) Max | V _{BO} (V) Min | V _{BO} (V) Max | I _{CS} [*] (mA) Max | I _{CB0} (mA) Max | I _{CB} (mA) Max | hFE Min | hFE Max | I _C (mA) Max | V _{CE} (V) Max | V _{CE} (V) Min | V _{BE} ^(sat) (V) Max | V _{BE} ^(sat) (V) Min | I _C (mA) Max | I _C (mA) Min | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) Max | t _(off) (ns) Max | Test Condition | Process No. |
|-------------------------|------------|---|---|---|---|-------------------------------|-------------------------------|---|---------------------------------|--------------------------------|------------|------------|-------------------------------|-------------------------------|-------------------------------|--|--|-------------------------------|-------------------------------|--------------------------------|--------------------------------|--------------------------------|-------------------------------|-----------------------------------|----------------|-------------|
| | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 2N706 | TO-18 | 5 | 15 | 25 | 15 | 5 | 15 | 500 | 100 | 15 | 20 | 120 | 10 | 1 | 0.5 | 0.7 | 0.9 | 10 | 10 | 6 | 200 | 700 | 10 | 75 | 2 | 21 |
| 2N706J | TO-52 | 5 | 15 | 25 | 15 | 5 | 15 | 100 | 100 | 15 | 20 | 60 | 10 | 1 | 0.5 | 0.7 | 0.9 | 10 | 10 | 6 | 200 | 700 | 10 | 75 | 2 | 21 |
| 2N708 | TO-52 | 5 | 15 | 40 | 15 | 5 | 20 | 25 | 100 | 20 | 30 | 120 | 10 | 1 | 0.4 | 0.72 | 0.8 | 10 | 10 | 6 | 300 | | 10 | | | 22 |
| 2N743 | TO-52 | 12 | 20 | 40 | 20 | 5 | 20 | 1 μA | 100 | 20 | 10 | 60 | 10 | 0.35 | 0.65 | 0.85 | 10 | 10 | 5 | 300 | | 10 | 24 | 1 | 21 | |
| 2N744 | TO-52 | 12 | 20 | 40 | 20 | 5 | 20 | 1 μA | 100 | 20 | 20 | 120 | 10 | 0.35 | 0.65 | 0.85 | 10 | 10 | 5 | 280 | | 10 | 24 | 1 | 21 | |
| 2N753 | TO-52 | 15 | 25 | 40 | 25 | 5 | 15 | 500 | 100 | 15 | 40 | 120 | 10 | 1 | 0.6 | 0.7 | 0.9 | 10 | 10 | 5 | 200 | | 10 | 75 | 2 | 21 |
| 2N834 | TO-52 | 5 | 15 | 40 | 15 | 5 | 20 | 500 | 100 | 20 | 25 | 10 | 1 | 0.25 | 0.25 | 0.9 | 10 | 10 | 4 | 350 | | 10 | 30 | 2 | 21 | |
| 2N2369 | TO-52 | 15 | 25 | 40 | 20 | 4.5 | 20 | 400 | 100 | 20 | 20 | 100 | 2 | 0.25 | 0.25 | 0.7 | 0.85 | 10 | 4 | 500 | | 10 | 18 | 1 | 21 | |
| 2N2369A | TO-52 | 15 | 25 | 40 | 20 | 4.5 | 20 | 30 | 100 | 20 | 20 | 100 | 1 | 0.2 | 0.2 | 0.7 | 0.85 | 10 | 4 | 500 | | 10 | 18 | 1 | 21 | |
| 2N2369A J, JTX, JTXV | TO-18 | 5 | 15 | 40 | 15 | 4.5 | 20 | 400* | 100 | 20 | 20 | 120 | 100 | 1 | 0.2 | 0.7 | 0.85 | 10 | 4 | 500 | | 10 | 18 | 1 | 21 | |
| 2N3009 | TO-52 | 4 | 15 | 40 | 15 | 4 | 20 | 500* | 100 | 20 | 15 | 300 | 1 | 0.18 | 0.18 | 0.75 | 0.85 | 30 | 5 | 350 | | 30 | 25 | 3 | 22 | |
| 2N3011 | TO-52 | 5 | 15 | 40 | 15 | 5 | 20 | 400* | 100 | 20 | 25 | 100 | 0.5 | 0.28 | 0.28 | 0.7 | 0.85 | 10 | 4 | 400 | | 20 | 20 | 4 | 21 | |
| 2N3013 | TO-52 | 5 | 15 | 40 | 15 | 5 | 20 | 300* | 100 | 20 | 15 | 300 | 1 | 0.18 | 0.18 | 0.75 | 0.85 | 30 | 5 | 350 | | 30 | 25 | 3 | 22 | |
| 2N3015 | TO-39 | 5 | 15 | 40 | 15 | 5 | 20 | 200 | 100 | 30 | 10 | 120 | 150 | 10 | 0.4 | 0.4 | 0.7 | 0.85 | 10 | 8 | 250 | | 50 | 60 | 5 & 6 | 25 |
| 2N3252 | TO-39 | 5 | 15 | 40 | 15 | 5 | 20 | 500 | 100 | 40 | 25 | 90 | 150 | 1 | 0.3 | 0.3 | 0.7 | 0.85 | 10 | 12 | 200 | | 50 | 70 | 7 | 25 |



SATURATED SWITCHES (Continued)

| Type No. | Case Style | V _{CE(sat)} (V) Min | V _{BE(sat)} (V) Min | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | V _{BE(sat)} (V) Max | I _C (mA) (I _B = I _C / 10) | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) | t _(off) (ns) Max | Test Condition | Process No. | | | | |
|--|---------------|------------------------------------|------------------------------------|------------------------------------|------------------------------------|------------------------------------|--|--------------------------------|--------------------------------|--------------------------------|------------------------|-----------------------------------|----------------|-------------|------------------------|------------------------|--|-----|
| | | | | | | | | | | | | | | | h _{FE} Min | h _{FE} Max | I _C (mA) & V _{CE} (V) | |
| 2N3253 | TO-39 | 40 | 5 | 60 | 0.35 | 1.0 | 150 | 12 | 175 | 50 | 70 | 7 | 25 | | | | | |
| | | | | | | | | | | | | | | 25 | 75 | 0.6 | 1.3 | 500 |
| | | | | | | | | | | | | | | 25 | 150 | 1.2 | 1.8 | 1A |
| 2N3444 | TO-39 | 50 | 5 | 60 | 0.35 | 1.0 | 150 | 12 | 150 | 50 | 70 | 7 | 25 | | | | | |
| | | | | | | | | | | | | | | 20 | 60 | 0.6 | 1.3 | 500 |
| | | | | | | | | | | | | | | 20 | 150 | 1.2 | 1.8 | 1A |
| 2N3605 | TO-92 (74) | 14 | 500 | 18 | 0.25 | 0.85 | 10 | 6 | 300 | 10 | 45 | 2 | 21 | | | | | |
| | | | | | | | | | | | | | | 30 | 10 | 1 | | |
| | | | | | | | | | | | | | | 30 | 10 | 1 | | |
| 2N3606 | TO-92 (74) | 14 | 500 | 18 | 0.25 | 0.85 | 10 | 6 | 300 | 10 | 60 | 2 | 21 | | | | | |
| | | | | | | | | | | | | | | 30 | 10 | 1 | | |
| | | | | | | | | | | | | | | 30 | 10 | 1 | | |
| 2N3607 | TO-92 (74) | 14 | 500 | 18 | 0.25 | 0.85 | 10 | 6 | 300 | 10 | 70 | 2 | 21 | | | | | |
| | | | | | | | | | | | | | | 30 | 10 | 1 | | |
| | | | | | | | | | | | | | | 30 | 10 | 1 | | |
| 2N3646 Same as PN3646, see pages 1-6 for explanation | | | | | | | | | | | | | | | | | | |
| 2N3724 | TO-39 | 50 | 30 | 6 | 1.7 μA | 40 | 30 | 1A | 5 | 300 | 50 | 60 | 7 | 25 | | | | |
| | | | | | | | | | | | | | | | 25 | 800 | 2 | |
| | | | | | | | | | | | | | | | 35 | 500 | 1 | |
| | | | | | | | | | | | | | | | 40 | 300 | 1 | |
| | | | | | | | | | | | | | | | 60 | 150 | 1 | |
| 2N3724A | TO-39 | 50 | 30 | 6 | 500 | 40 | 25 | 1.5A | 5 | 300 | 50 | 50 | 8 | 25 | | | | |
| | | | | | | | | | | | | | | | 30 | 800 | 2 | |
| | | | | | | | | | | | | | | | 35 | 500 | 1 | |
| | | | | | | | | | | | | | | | 40 | 300 | 1 | |
| | | | | | | | | | | | | | | | 60 | 150 | 1 | |
| 2N3725 | TO-39 | 80 | 50 | 6 | 1.7 μA | 60 | 25 | 1A | 5 | 300 | 50 | 60 | 7 | 25 | | | | |
| | | | | | | | | | | | | | | | 20 | 800 | 2 | |
| | | | | | | | | | | | | | | | 35 | 500 | 1 | |
| | | | | | | | | | | | | | | | 40 | 300 | 1 | |
| | | | | | | | | | | | | | | | 60 | 150 | 1 | |

TEST CONDITIONS:

- (1) V_{CC} = 3V, I_C = 10mA, I_B¹ = 3mA, I_B² = 1.5mA, (2) V_{CC} = 3V, I_C = 10mA, I_B¹ = 3mA, I_B² = 1mA, (3) V_{CC} = 10V, I_C = 300mA, I_B¹ = I_B² = 30mA, (4) V_{CC} = 2V, I_C = 30mA, I_B¹ = I_B² = 3mA, (5) V_{CC} = 25V, I_C = 300mA, I_B¹ = I_B² = 30mA, (6) V_{CC} = 25V, I_C = 500mA, I_B¹ = I_B² = 50mA, (7) V_{CC} = 30V, I_C = 500mA, I_B¹ = I_B² = 50mA, (8) V_{CC} = 30V, I_C = 1A, I_B¹ = I_B² = 100mA, (9) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 1mA, (10) V_{CC} = 10.7V, I_C = 1A, I_B¹ = I_B² = 100mA, (11) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 3mA, (12) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 3.3mA.





SATURATED SWITCHES (Continued)

| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | IC _{BO} * (mA) Max | V _{CB} (V) @ Max | h _{FE} Min Max | IC, V _{CE} & (mA), (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min & Max | IC (mA) @ IB = IC/10 Max | C _{ob} (pF) Max | f _T (MHz) Min Max | IC (mA) @ Max | t _(off) (ns) Max | Test Condition | Process No. | |
|----------|---------------|---|--------------------------------|--------------------------------|-----------------------------------|------------------------------------|----------------------------------|--|---|--|--------------------------------------|--------------------------------|---------------------------------------|------------------------|-----------------------------------|----------------|-------------|----|
| 2N43725A | TO-39 | 80 | 50 | 6 | 500 | 60 | 20 25 25 35 40 60 | 1.5A 1A 800 500 300 100 10 | 0.4 0.52 0.8 0.9 | 1.1 1.2 1.3 1.4 | 300 500 800 1A | 10 | 50 | 50 | 50 | 8 | 25 | |
| 2N4013 | TO-18 | 50 | 30 | 6 | 1.7 μA | 40 | 30 25 35 40 60 30 | 1A 800 500 300 100 10 | 0.25 0.2 0.32 0.42 0.65 0.75 | 0.76 0.86 1.1 1.2 1.5 1.7 | 10 100 300 500 800 1A | 12 | 300 | 50 | 60 | 7 | 25 | |
| 2N4014 | TO-18 | 80 | 50 | 6 | 1.7 μA | 60 | 25 20 35 40 60 30 | 1A 800 500 300 100 10 | 0.25 0.26 0.4 0.25 0.8 0.9 | 0.76 0.86 1.1 1.2 1.5 1.7 | 10 100 300 500 800 1A | 10 | 300 | 50 | 60 | 7 | 25 | |
| 2N4047 | TO-39 | 80 | 50 | 6 | 1.7 μA | 60 | 15 15 20 30 40 20 | 1A 800 500 300 100 10 | 0.4 0.52 0.8 0.95 | 1.1 1.2 1.5 1.7 | 300 500 800 1A | 10 | 250 | 50 | 60 | 7 | 25 | |
| 2N4274 | TO-92 (72) | Same as PN4274, see page 1-6 for explanation | | | | | | | | | | | | | | | | |
| 2N4275 | TO-92 (72) | Same as PN4275, see page 1-6 for explanation | | | | | | | | | | | | | | | | |
| 2N4294 | TO-92 (74) | 30 | 12 | 4.5 | 400 | 20 | 20 30 | 100 10 | 0.25 | 0.6 | 0.9 | 10 | 5 | 400 | 10 | 20 | 1 | 21 |
| 2N4295 | TO-92 (74) | 40 | 15 | 5 | 100 | 20 | 20 40 | 100 10 | 0.25 | 0.6 | 0.9 | 10 | 4 | 500 | 10 | 15 | 1 | 21 |
| 2N5030 | TO-92 (74) | 30 | 12 | 4 | 250 | 20 | 30 | 10 | 0.25 | 0.72 | 0.87 | 10 | 4 | 400 | 10 | 30 | 9 | 21 |
| 2N5134 | TO-92 (72) | Same as PN5134, see page 1-6 for explanation | | | | | | | | | | | | | | | | |
| 2N5189 | TO-39 | 60 | 35 | 5 | 500 | 30 | 15 35 30 | 1A 500 100 | 1.0 | 1.5 | 1A | 12 | 250 | 50 | 70 | 10 | 25 | |



SATURATED SWITCHES (Continued)

| Type No. | Case Style | V _{CE} * V _{CEO} (V) Min | V _{BE} (V) Min | ICES* I _{CBO} (mA) Max | V _{CE} (V) & V _{CE} (V) | h _{FE} @ I _C (mA) & V _{CE} (V) | V _{CE} (sat) (V) & V _{BE} (sat) (V) | V _{BE} (sat) (V) @ I _C (mA) & I _B (mA) | I _C (mA) & C _{ob} (pF) | f _T (MHz) @ I _C (mA) & I _B (mA) | t _(off) (ns) Max | Test Condition | Process No. | |
|----------|------------------|---|-------------------------------|--|---|---|---|---|--|--|-----------------------------|----------------|-------------|----|
| 2N5224 | TO-92 (72) | 25 | 5 | 500 | 15 | 100 | 0.35 | 0.9 | 10 | 250 | 60 | 11 | 21 | |
| 2N5769 | TO-92 (72) | 40 | 4.5 | 400 | 20 | 100 | 0.2 | 0.7 | 10 | 500 | 18 | 1 | 21 | |
| 2N5772 | TO-92 (72) | 40 | 5 | 500 | 20 | 100 | 0.2 | 0.75 | 30 | 350 | 28 | 3 | 21 | |
| DH3724CD | Ceramic DIP (40) | 50* | 60 | 1.7 μA | 40 | 1A | 0.75 | 1.7 | 500 | 12 | 300 | 7 | 25 | |
| DH3724CN | Molded DIP (39) | Electrical, same as DH3724CD | | | | | | | | | | | | 25 |
| DH3725CD | Ceramic DIP (40) | 80* | 6 | 1.7 μA | 60 | 1A | 0.95 | 1.7 | 500 | 10 | 250 | 7 | 25 | |
| DH3725CN | Molded DIP (39) | Electrical, same as DH3725CD | | | | | | | | | | | | 25 |
| EN2369A | TO-92 (72) | Same as PN2369A, see page 1-6 for explanation | | | | | | | | | | | | 21 |
| MPS706 | TO-92 (72) | 15 | 3 | 500 | 15 | 20 | 0.6 | 0.9 | 10 | 200 | 75 | 11 | 21 | |
| MPS834 | TO-92 (72) | 40 | 5 | 500 | 20 | 25 | 0.25 | 0.9 | 10 | 350 | 30 | 2 | 21 | |
| MPS2369 | TO-92 (72) | 40* | 15 | 400 | 20 | 20 | 0.25 | 0.7 | 10 | 500 | 18 | 7 | 21 | |
| MPS2713 | TO-92 (72) | 18 | 5 | 500 | 18 | 30 | 0.3 | 1.3 | 50 | | | | 21 | |
| MPS2714 | TO-92 (72) | 18 | 5 | 500 | 18 | 75 | 0.3 | 0.6 | 1.3 | 50 | | | 21 | |
| MPS3646 | TO-92 (72) | Same as PN3646, see page 1-6 for explanation | | | | | | | | | | | | |
| PN2369 | TO-92 (72) | 40* | 15 | 400 | 20 | 20 | 0.25 | 0.7 | 10 | 500 | 18 | 1 | 21 | |

TEST CONDITIONS:

- (1) V_{CC} = 3V, I_C = 10mA, I_B¹ = 3mA, I_B² = 1.5mA. (2) V_{CC} = 3V, I_C = 10mA, I_B¹ = 3mA, I_B² = 1mA. (3) V_{CC} = 10V, I_C = 300mA, I_B¹ = I_B² = 30mA. (4) V_{CC} = 2V, I_C = 30mA, I_B¹ = I_B² = 3mA. (5) V_{CC} = 25V, I_C = 300mA, I_B¹ = I_B² = 30mA. (6) V_{CC} = 25V, I_C = 500mA, I_B¹ = I_B² = 50mA. (7) V_{CC} = 30V, I_C = 500mA, I_B¹ = I_B² = 50mA. (8) V_{CC} = 30V, I_C = 1A, I_B¹ = I_B² = 100mA. (9) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 1mA. (10) V_{CC} = 10.7V, I_C = 1A, I_B¹ = I_B² = 100mA. (11) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 3mA. (12) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 3.3mA.



SATURATED SWITCHES (Continued)

| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | ICES* I _{CB0} (mA) Max | V _{CB} @ (V) | h _{FE} Min Max | I _C @ (mA) | V _{CE} (V) | V _{CE} (V) & Max | V _{BE} (sat) (V) & Min | I _C (mA) @ (I _B = I _C / 10) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | Test Condition | Process No. | | | |
|----------|---------------|--|-----------------------------|-----------------------------|---------------------------------------|-----------------------|----------------------------|-----------------------|---------------------|---------------------------------|---------------------------------------|--|-----------------------------|---------------------------------|----------------------------|------------------------------|----------------|-------------|----|--|--|
| PN2369A | TO-92 (72) | 40* | 15 | 4.5 | 30 | 20 | 20 | 100 | 1 | 0.2 | 0.7 | 0.85 | 10 | 4 | 500 | 10 | 18 | 1 | 21 | | |
| | | | | | | | 30 | 30 | 0.4 | 0.2 | 1.15 | 30 | | | | | | | | | |
| | | | | | | | 40 | 120 | 1 | 0.5 | 1.6 | 100 | | | | | | | | | |
| PN3646 | TO-92 (72) | 40* | 15 | 5 | 500* | 20 | 15 | 300 | 1 | 0.2 | 0.75 | 0.95 | 30 | 5 | 350 | 30 | 28 | 3 | 22 | | |
| | | | | | | | 20 | 100 | 0.5 | 0.28 | 1.2 | 100 | | | | | | | | | |
| | | | | | | | 30 | 120 | 0.4 | 0.5 | 1.7 | 300 | | | | | | | | | |
| PN4274 | TO-92 (72) | 30* | 12 | 4.5 | 500 | 20 | 18 | 100 | 1 | 0.2 | 0.7 | 0.85 | 10 | 4 | 400 | 10 | 12 | 12 | 21 | | |
| | | | | | | | 30 | 30 | 0.4 | 0.25 | 1.15 | 30 | | | | | | | | | |
| | | | | | | | 35 | 120 | 1 | 0.5 | 1.6 | 100 | | | | | | | | | |
| PN4275 | TO-92 (72) | 40* | 15 | 4.5 | 500 | 20 | 18 | 100 | 1 | 0.2 | 0.72 | 0.85 | 10 | 4 | 400 | 10 | 12 | 12 | 21 | | |
| | | | | | | | 30 | 30 | 0.4 | 0.25 | 1.15 | 30 | | | | | | | | | |
| | | | | | | | 35 | 120 | 1 | 0.5 | 1.6 | 100 | | | | | | | | | |
| PN5134 | TO-92 (72) | 20* | 10 | 3.5 | 100 | 15 | 15 | 30 | 0.4 | 0.25 | 0.7 | 0.9 | 10 | 4 | 250 | 10 | 18 | 12 | 21 | | |
| | | | | | | | 20 | 150 | 1 | | | | | | | | | | | | |

TEST CONDITIONS:

- (1) V_{CC} = 3V, I_C = 10mA, I_B¹ = 3mA, I_B² = 1.5mA, (2) V_{CC} = 3V, I_C = 10mA, I_B¹ = 3mA, I_B² = 1mA, (3) V_{CC} = 10V, I_C = 300mA, I_B¹ = I_B² = 30mA, (4) V_{CC} = 2V, I_C = 30mA, I_B¹ = I_B² = 3mA, (5) V_{CC} = 25V, I_C = 300mA, I_B¹ = I_B² = 30mA, (6) V_{CC} = 25V, I_C = 500mA, I_B¹ = I_B² = 50mA, (7) V_{CC} = 30V, I_C = 500mA, I_B¹ = I_B² = 50mA, (8) V_{CC} = 30V, I_C = 1A, I_B¹ = I_B² = 100mA, (9) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 1mA, (10) V_{CC} = 10.7V, I_C = 1A, I_B¹ = I_B² = 100mA, (11) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 3mA, (12) V_{CC} = 3V, I_C = 10mA, I_B¹ = I_B² = 3.3mA.



RF AMPS AND OSCILLATORS

| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} @ (V) | h _{FE} Min Max | I _C @ (mA) | V _{CE} (V) & Max | V _{CE} (SAT) (V) & Max | V _{BE} (SAT) (V) & Min | I _C (mA) Max | C _{ob} /C _{re} (pF) Min Max | f _T (MHz) Min Max | I _C (mA) Max | NF (dB) @ (MHz) Max | Freq (MHz) Max | Process No. | |
|------------------------|------------|--|-----------------------------|-----------------------------|------------------------------|-----------------------|----------------------------|-----------------------|---------------------------------|---------------------------------------|---------------------------------------|----------------------------|--|---------------------------------|----------------------------|------------------------|-------------------|-------------|----|
| 2N917 | TO-72 | 30 | 15 | 3 | 1 | 15 | 20 | 3 | 1 | 0.5 | 0.87 | 3 | 3 | 500 | 4 | 6 | 60 | 43 | |
| | | | | | | | | 10 | 1 | 0.4 | 1.0 | 10 | 3 | 600 | 4 | 6 | 60 | 43 | |
| 2N918 J, JTX, JTXV | TO-72 | 30 | 15 | 3 | 10 | 15 | 20 | 10 | 10 | 0.4 | 1.0 | 10 | 1.7 | 600 | 4 | 6 | 60 | 43 | |
| | | | | | | | | 200 | 3 | 1 | 1.0 | 10 | | | | | | | |
| | | | | | | | | 500 μA | 10 | | | | | | | | | | |
| 2N2857 J, JTX, JTXV | TO-72 | 30 | 15 | 2.5 | 10 | 15 | 30 | 150 | 3 | 1 | 1.0 | 10 | 1 | 1000 | 1900 | 5 | 4.5 | 450 | |
| | | | | | | | | 150 | 3 | 1 | 1.0 | 10 | 1 | 1000 | 1900 | 5 | 4.5 | 450 | 42 |
| 2N3478 | TO-72 | 30 | 15 | 2 | 20 | 1 | 25 | 150 | 2 | 8 | | | 1 | 750 | 1600 | 5 | 4.5 | 200 | |
| | | | | | | | | 150 | 2 | 8 | | | | | | | | | |



RF AMPS AND OSCILLATORS (Continued)

| Type No. | Case Style | V _{CE} * | | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CBO} V _{CB} | | h _{FE} Max @ I _C & V _{CE} (mA) & (V) | V _{CE(SAT)} & V _{BE(SAT)} (V) & (V) | | C _{ob} /C _{re} (pF) | | f _T (MHz) | | NF (dB) @ Max | F _{req} (MHz) | Process No. | | |
|----------|------------|---|-----------------------------|-----------------------------|-----------------------------|----------------------------------|---------|---|---|-----|---------------------------------------|------|----------------------|------|---------------|------------------------|-------------|-----|----|
| | | V _{CE0} (V) Min | V _{CB0} (V) Min | | | (mA) Max | (V) Max | | Max | Min | Max | Min | Max | Min | | | | Max | |
| 2N3563 | TO-92 (72) | Same as PN3563, see page 1-10 for explanation | | | | | | | | | | | | | | | | | |
| 2N3564 | TO-92 (72) | Same as PN3564, see page 1-10 for explanation | | | | | | | | | | | | | | | | | |
| 2N3600 | TO-72 | 30 | 15 | 3 | 10 | 15 | 20 | 150 | 3 | 1 | | 1 | 850 | 1500 | 5 | 4.5 | 200 | 43 | |
| 2N3662 | TO-92 (74) | 18 | 12 | 3 | 500 | 15 | 20 | 200 | 8 | 10 | | 0.8 | 700 | 2100 | 5 | 6.5 | 60 | 43 | |
| 2N3663 | TO-92 (74) | 30 | 12 | 3 | 500 | 15 | 20 | 200 | 8 | 10 | | 0.8 | 700 | 2100 | 5 | 6.5 | 60 | 43 | |
| 2N3825 | TO-92 (74) | 30 | 15 | 4 | 100 | 15 | 20 | 200 | 2 | 10 | 0.25 | 3.5 | 200 | 800 | 2 | 5.5 | 1 | 43 | |
| 2N3932 | TO-72 | 30 | 20 | 2.5 | 10 | 15 | 40 | 150 | 2 | 8 | | 0.55 | 750 | 1600 | 2 | 4.5 | 200 | 42 | |
| 2N3933 | TO-72 | 40 | 30 | 2.5 | 10 | 15 | 60 | 200 | 2 | 8 | | 0.55 | 750 | 1600 | 2 | 4 | 200 | 42 | |
| 2N4134 | TO-72 | 30 | 30 | 3 | 50 | 10 | 25 | 200 | 4 | 5 | | 0.5 | 350 | 800 | 4 | 2.5 | 60 | 44 | |
| 2N4135 | TO-72 | 30 | 30 | 3 | 50 | 10 | 25 | 200 | 4 | 5 | | 0.5 | 425 | 800 | 4 | 5 | 450 | 44 | |
| 2N4252 | TO-72 | 30 | 18 | 4 | 50 | 15 | 50 | 200 | 2 | 10 | | 0.45 | 600 | 1400 | 2 | | | 42 | |
| 2N4259 | TO-72 | 40 | 30 | 2.5 | 10 | 15 | 60 | 250 | 2 | 8 | | 0.55 | 750 | 1600 | 2 | 5 | 450 | 42 | |
| 2N4292 | TO-92 (74) | 30 | 15 | 3 | 500 | 15 | 20 | 200 | 3 | 1 | 0.6 | 3.5 | 600 | 4 | 6 | 60 | 43 | | |
| 2N4293 | TO-92 (74) | 30 | 15 | 3 | 500 | 15 | 20 | 200 | 3 | 1 | 0.6 | 3.5 | 600 | 4 | 6 | 60 | 43 | | |
| 2N5130 | TO-92 (72) | Same as PN5130, see page 1-10 for explanation | | | | | | | | | | | | | | | | | |
| 2N5179 | TO-72 | 20 | 12 | 2.5 | 20 | 15 | 25 | 250 | 3 | 1 | 0.4 | 1.0 | 10 | 900 | 2000 | 5 | 4.5 | 200 | 42 |
| 2N5180 | TO-72 | 30 | 15 | 2 | 500 | 8 | 20 | 200 | 2 | 8 | | 1 | 650 | 1700 | 2 | | | 42 | |
| 2N5222 | TO-92 (71) | 20 | 15 | 2 | 100 | 10 | 20 | 1500 | 4 | 10 | 1.0 | 1.3 | 450 | 4 | | | | 49 | |
| 2N5770 | TO-92 (72) | 30 | 15 | 4.5 | 10 | 15 | 50 | 200 | 8 | 10 | 0.4 | 0.7 | 1.1 | 90 | 1800 | 8 | 6 | 60 | 43 |
| 40235 | TO-72 | 35 | | 3 | 1 μA | 35 | 40 | 170 | 1 | 6 | | 0.65 | | | | | | 42 | |
| 40236 | TO-72 | 35 | | 3 | 1 μA | 35 | 40 | 275 | 1 | 6 | | 0.65 | | | | | | 42 | |
| 40237 | TO-72 | 35 | | 3 | 1 μA | 35 | 27 | 275 | 1 | 6 | | 0.8 | | | | | | 42 | |



RF AMPS AND OSCILLATORS (Continued)

| Type No. | Case Style | V _{CE} * V _{CB} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) @ I _C Max | h _{FE} Min | h _{FE} Max | I _C (mA) & V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) Max | C _{ob} /C _{re} (pF) Min | C _{ob} /C _{re} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) @ f _T Max | NF (dB)@ (MHz) Max | Process No. | |
|--|---------------|--|--------------------------------|--------------------------------|---------------------------------|---|------------------------|------------------------|---|------------------------------------|------------------------------------|-------------------------------|---|---|--------------------------------|--------------------------------|--|-----------------------------|-------------|----|
| 40238 | TO-72 | 35 | | 3 | 1 μA | 35 | 40 | 170 | 1 | 6 | | | 0.65 | 0.65 | | | | | 42 | |
| 40239 | TO-72 | 35 | | 3 | 1 μA | 35 | 27 | 100 | 1 | 6 | | | 0.65 | 0.65 | | | | | 42 | |
| 40240 | TO-72 | 35 | | 3 | 1 μA | 35 | 27 | 275 | 1 | 6 | | | 0.65 | 0.65 | | | | | 42 | |
| 40242 | TO-72 | 35 | | 3 | 20 | 1 | 40 | 170 | 1 | 6 | | | 0.65 | 0.65 | | | | | 42 | |
| 40243 | TO-72 | 35 | | 3 | 20 | 1 | 40 | 170 | 1 | 6 | | | 0.65 | 0.65 | | | | | 42 | |
| 40244 | TO-72 | 35 | | 3 | 20 | 1 | 27 | 170 | 1 | 6 | | | 0.65 | 0.65 | | | | | 42 | |
| 40245 | TO-72 | 35 | | 3 | 20 | 1 | 70 | 170 | 1 | 6 | | | 0.8 | 0.8 | | | | | 42 | |
| 40246 | TO-72 | 35 | | 3 | 20 | 1 | 27 | 170 | 1 | 6 | | | 0.65 | 0.65 | | | | | 42 | |
| EN918 | TO-92 (72) | | | | | | | | | | | | | | | | | | 43 | |
| Same as PN918, see page 1-10 for explanation | | | | | | | | | | | | | | | | | | | | |
| MPSH07 | TO-92 (75) | 30 | 30 | 3 | 50 | 15 | 20 | 3 | 3 | 10 | | | 0.3 | 0.3 | 400 | 3 | 3.2 | 100 | 41 | |
| MPSH08 | TO-92 (75) | 30 | 30 | 3 | 50 | 15 | 20 | 3 | 3 | 10 | | | 0.3 | 0.3 | 500 | 3 | 3.5 | 200 | 41 | |
| MPSH10 | TO-92 (71) | 30 | 25 | 3 | 100 | 25 | 60 | 4 | 4 | 10 | 0.5 | 4 | 0.35 | 0.65 | 650 | 4 | | | 42 | |
| MPSH11 | TO-92 (76) | 30 | 25 | 3 | 100 | 25 | 60 | 4 | 4 | 10 | 0.5 | 4 | 0.6 | 0.9 | 650 | 4 | | | 47 | |
| MPSH19 | TO-92 (76) | 30 | 25 | 3 | 100 | 15 | 45 | 4 | 4 | 10 | | | 0.65 | 0.65 | 300 | 4 | | | 47 | |
| MPSH20 | TO-92 (71) | 40 | 30 | 4 | 50 | 15 | 25 | 4 | 4 | 10 | 0.95 | 10 | 0.65 | 0.65 | 400 | 4 | | | 49 | |
| MPSH24 | TO-92 (47) | 40 | 30 | 4 | 50 | 15 | 30 | 8 | 8 | 10 | | | 0.36 | 0.36 | 400 | 8 | | | 47 | |
| MPSH30 | TO-92 (71) | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 0.3 | 0.96 | 10 | 0.65 | 300 | 800 | 4 | 6 | 45 | 44 |
| MPSH31 | TO-92 (71) | 20 | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 0.3 | 0.96 | 10 | 0.65 | 300 | 800 | 4 | 6 | 45 | 44 |
| MPSH32 | TO-92 (76) | 30 | 30 | 4 | 50 | 10 | 27 | 200 | 4 | 5 | 0.3 | 1.2 | 10 | 0.22 | 300 | 4 | | | 45 | |
| MPSH34 | TO-92 (76) | 45 | 45 | 4 | 50 | 30 | 15 | 20 | 20 | 2 | 0.5 | 20 | 0.32 | 0.32 | 500 | 15 | | | 47 | |
| MPSH37 | TO-92 (71) | | 40 | 5 | 500 | 35 | 25 | 5 | 5 | 10 | 0.5 | 10 | 0.7 | 0.7 | 300 | 5 | | | 49 | |



RF AMPS AND OSCILLATORS (Continued)

| Type No. | Case Style | V _{CE} * | | V _{CEO} (V) Min | V _{EBO} (V) Min | I _{CBO} (mA) @ V _{CB} (V) | | h _{FE} @ I _C & V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) @ I _C Max | C _{ob} /C _{re} (pF) | | f _T (MHz) @ I _C (mA) Max | NF (dB) @ (MHz) Max | Process No. | |
|----------|------------|---|-----|-----------------------------|-----------------------------|---|-----|--|------------------------------|------------------------------|--|---------------------------------------|------|--|---------------------|-------------|--|
| | | Min | Max | | | Min | Max | | | | | Min | Max | | | | |
| MPS3563 | TO-92 (72) | Same as PN3563, see page 1-10 for explanation | | | | | | | | | | | | | | | |
| MPS6507 | TO-92 (72) | 30* | | 20 | | 5 | 15 | 25 | 10 | | | | 2.5 | 700 | | 43 | |
| MPS6511 | TO-92 (72) | 30* | | 20 | | 50 | 15 | 25 | 10 | | | | 2.5 | | | 43 | |
| MPS6539 | TO-92 (71) | 20 | | 20 | | 50 | 15 | 20 | 4 | 10 | | | 0.7 | 500 | 4 4.5 100 | 42 | |
| MPS6540 | TO-92 (71) | 30 | | 30 | 4 | 100 | 25 | 25 | 2 | 10 | 10 | | 0.65 | 350 | 2 | 49 | |
| MPS6541 | TO-92 (72) | 30* | | 20 | 4 | 50 | 15 | 25 | 4 | 10 | | | 1.7 | 600 1500 4 | | 43 | |
| MPS6542 | TO-92 (76) | 30* | | 20 | | 50 | 15 | 25 | 2 | 10 | | | 1.5 | 700 | 10 | 47 | |
| MPS6543 | TO-92 (76) | 35 | | 20 | 3 | 100 | 25 | 25 | 4 | 10 | 0.35 | 0.95 | 1 | 750 | 4 | 47 | |
| MPS6544 | TO-92 (71) | 60 | | 45 | 4 | 500 | 35 | 20 | 30 | 10 | 30 | | 0.65 | | | 49 | |
| MPS6546 | TO-92 (76) | 35 | | 25 | 3 | 100 | 25 | 20 | 2 | 10 | 10 | | 0.45 | 600 | 2 | 47 | |
| MPS6547 | TO-92 (76) | 35 | | 25 | 3 | 100 | 25 | 20 | 2 | 5 | 10 | | 0.35 | 600 | 2 | 47 | |
| MPS6548 | TO-92 (71) | 30 | | 25 | 3 | 100 | 25 | 25 | 4 | 10 | 0.5 | 0.95 | 0.7 | 650 | 4 | 42 | |
| MPS6567 | TO-92 (71) | | | 40 | 5 | 500 | 35 | 25 | 10 | 5 | 10 | | 0.7 | | | 49 | |
| MPS6568A | TO-92 (71) | 20 | | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 0.3 | 0.96 | 375 800 4 | 3.3 200 | 44 | |
| MPS6569 | TO-92 (71) | 20 | | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3 | 0.96 | 300 800 4 | 6 45 | 44 | |
| MPS6570 | TO-92 (71) | 20 | | 20 | 3 | 50 | 10 | 20 | 200 | 4 | 5 | 3 | 0.96 | 300 800 4 | 6 45 | 44 | |
| MRF501 | TO-72 | 25 | | 15 | 3.5 | 50 | 1 | 30 | 250 | 1 | 6 | | | 600 | 5 | 42 | |
| MRF502 | TO-72 | 35 | | 15 | 3.5 | 20 | 1 | 40 | 170 | 1 | 6 | | | 800 | 5 | 42 | |
| NSC460 | TO-92 (74) | 30 | | 30 | 5 | 500 | 18 | 35 | 200 | 2 | 12 | 1.1 | | | 6.5 1 | 46 | |
| NSC461 | TO-92 (74) | 30 | | 30 | 5 | 500 | 18 | 35 | 200 | 2 | 12 | 1.1 | | | | 46 | |



RF AMPS AND OSCILLATORS (Continued)

| Type No. | Case Style | V _{CS} * V _{CBO} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CBO} @ V _{CB} (mA) (V) Max | h _{FE} Min Max | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min Max | I _C @ (mA) Min Max | C _{ob} /C _{re} (pF) Min Max | f _T (MHz) Min Max | I _C (mA) Max | NF (dB) @ (MHz) Max | Process No. |
|----------|---------------|--|-----------------------------|-----------------------------|---|----------------------------|---|---------------------------------|-------------------------------------|----------------------------------|---|------------------------------------|-------------------------------|---------------------------|-------------|
| PE3100 | TO-92 (76) | 30* | 30 | 3 | 200 30 | 30 225 5 10 | | | | | 0.8 | 500 | 5 | | 47 |
| PE5025 | TO-92 (72) | 30 | 30 | 3 | 50 30 | 20 100 10 10 | 0.6 | | | 20 | 0.6 1 | 300 700 | 10 | | 46 |
| PE5029 | TO-92 (76) | 30 | 30 | 3 | 200 30 | 30 225 5 10 | | | | | 0.4 | 500 | 5 | 6 45 | 47 |
| PE5030B | TO-92 (76) | 45 | 40 | 4.5 | 100 30 | 45 150 7 15 | 3 | | 0.92 10 | 20 | 0.25 0.4 | 600 | 7 | | 47 |
| PE5031 | TO-92 (76) | 40 | 30 | 4 | 100 30 | 30 180 5 10 | 1 | | | 10 | 0.4 | 500 | 5 | 4.5 200 | 47 |
| PN918 | TO-92 (72) | 30 | 15 | 3 | 10 15 | 20 3 1 | 0.4 | | 1.0 10 | 10 | 1.7 | 600 | 4 | 6 60 | 43 |
| PN3563 | TO-92 (72) | 30 | 15 | 2 | 50 15 | 20 200 8 10 | | | | | 1.7 | 600 1500 | 8 | | 43 |
| PN3564 | TO-92 (72) | 30 | 15 | 4 | 50 15 | 20 500 15 10 | 0.3 | | 0.97 20 | 15 | 3.5 | 400 1200 | 15 | | 43 |
| PN5130 | TO-92 (72) | 30 | 12 | 1 | 50 10 | 15 250 8 10 | 0.6 | | 1.0 10 | 10 | 1.7 | 450 | 8 | | 43 |
| PN5179 | TO-92 (71) | 20 | 15 | 2.5 | 2 15 | 25 250 3 1 | 0.4 | | 1.0 10 | 10 | 1.0 | 900 2000 | 5 | 4.5 200 | 42 |
| SE5020 | TO-72 | 20 | 20 | 3 | 50 10 | 20 200 4 5 | 3.0 | | 0.96 10 | 10 | 0.25 0.5 | 375 800 | 4 | 3.3 200 | 44 |
| SE5021 | TO-72 | 20 | 20 | 3 | 50 10 | 20 200 4 5 | 3.0 | | 0.96 10 | 10 | 0.25 0.5 | 375 800 | 4 | 4 200 | 44 |
| SE5022 | TO-72 | 20 | 20 | 3 | 50 10 | 20 200 4 5 | 3.0 | | 0.96 10 | 10 | 0.25 0.5 | 300 800 | 4 | | 44 |
| SE5023 | TO-72 | 20 | 20 | 3 | 50 10 | 20 200 4 5 | 3.0 | | 0.96 10 | 10 | 0.25 0.5 | 300 800 | 4 | 6 45 | 44 |
| SE5024 | TO-72 | 20 | 20 | 3 | 50 10 | 20 200 4 5 | 3.0 | | 0.96 10 | 10 | 0.25 0.5 | 300 800 | 4 | 6 45 | 44 |
| SE5050 | TO-72 | 20 | 20 | 3 | 50 10 | 20 200 4 5 | 3.0 | | 0.96 10 | 10 | 0.25 0.5 | 300 | 4 | 4 100 | 44 |
| SE5051 | TO-72 | 20 | 20 | 3 | 50 10 | 20 200 4 5 | 3.0 | | 0.96 10 | 10 | 0.25 0.5 | 300 | 4 | | 44 |
| SE5052 | TO-72 | 20 | 20 | 3 | 50 10 | | 3.0 | | | 10 | | 375 | 4 | 4 200 | 44 |
| SE5055 | TO-72 | 20 | 20 | 3 | 50 20 | 20 220 2 10 | 2.75 | | | 10 | 0.22 | 300 | 2 | 5 45 | 44 |
| TI586 | TO-92 (78) | 30 | 30 | | 100 15 | 40 200 4 10 | 0.5 | | | 15 | 0.45 | 500 | 4 | 5 200 | 47 |
| TI587 | TO-92 (78) | 45 | 45 | | 100 15 | 30 150 12 12 | 0.5 | | | 15 | 0.45 | 500 | 12 | | 47 |



LOW LEVEL AMPS

| Type No. | Case Style | V _{CB} (V) | | V _{CE0} (V) | | V _{EB0} (V) | | I _{CB0} (mA) | | V _{CB} @ I _{CB0} | | h _{FE} | | I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(SAT)} | | I _C (mA) | | C _{ob} (pF) | | f _T (MHz) | | NF (dB) @ | | Process No. | | |
|--------------|------------|---------------------|-----|----------------------|-----|----------------------|-----|-----------------------|-----|------------------------------------|-----|-----------------|-----|----------------------------------|------|---|-----|---------------------|-----|----------------------|-----|----------------------|-----|-----------|-----|-------------|-----|--|
| | | Min | Max | Min | Max | Min | Max | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | | Max | |
| 2N760 | TO-18 | 45 | 45 | 45 | 45 | 8 | 30 | 200 | 30 | 30 | 30 | 76 | 300 | 1 | 5 | 1.0 | 0.6 | 1.1 | 10 | 10 | 8 | 50 | 50 | 1.0 | | 07 | | |
| 2N760A | TO-18 | 60 | 60 | 60 | 60 | 8 | 30 | 100 | 30 | 30 | 30 | 76 | 333 | 1 | 5 | 1.0 | | 1.1 | 10 | 10 | 8 | 50 | 50 | 1.0 | | 07 | | |
| 2N929 | TO-18 | 45 | 45 | 45 | 45 | 5 | 45 | 10 | 45 | 45 | 45 | 60 | 350 | 10 | 5 | 1.0 | 0.6 | 1.0 | 10 | 10 | 8 | 30 | 30 | 0.5 | 4 | 15.7 | 07 | |
| 2N929 | TO-18 | 60 | 60 | 60 | 60 | 6 | 45 | 10 | 45 | 45 | 45 | 60 | 350 | 10 | 5 | 1.0 | 0.6 | 1.0 | 10 | 10 | 8 | 45 | 45 | 0.5 | 5 | 100 Hz | 07 | |
| J, JTX | | | | | | | | | | | | 40 | 120 | 10 | 5 | | | | | | | | | | 3 | 1 | | |
| | | | | | | | | | | | | 40 | 120 | 10 | 5 | | | | | | | | | | 3 | 10 | | |
| 2N929A | TO-18 | 60 | 60 | 45 | 45 | 6 | 45 | 2 | 45 | 45 | 45 | 350 | 10 | 5 | 5 | 0.5 | 0.7 | 0.9 | 10 | 10 | 6 | 45 | 45 | 0.5 | 4 | 10 | 07 | |
| 2N930 | TO-18 | 45 | 45 | 45 | 45 | 5 | 45 | 10 | 45 | 45 | 45 | 60 | 10 | 5 | 5 | 1.0 | 0.6 | 1.0 | 10 | 10 | 8 | 30 | 30 | 0.5 | 3 | 15.7 | 07 | |
| | | | | | | | | | | | | 150 | 500 | 5 | 5 | | | | | | | | | | | | | |
| | | | | | | | | | | | | 100 | 300 | 10 | 5 | | | | | | | | | | | | | |
| 2N930 | TO-18 | 60 | 45 | 45 | 45 | 6 | 45 | 10 | 45 | 45 | 45 | 150 | 500 | 5 | 5 | 1.0 | 0.6 | 1.0 | 10 | 10 | 8 | 45 | 45 | 0.5 | 5 | 100 Hz | 07 | |
| J, JTX | | | | | | | | | | | | 100 | 300 | 10 | 5 | | | | | | | | | | | 3 | 1 | |
| | | | | | | | | | | | | 100 | 300 | 10 | 5 | | | | | | | | | | | 3 | 10 | |
| 2N930A | TO-18 | 60 | 60 | 45 | 45 | 6 | 45 | 2 | 45 | 45 | 45 | 600 | 10 | 5 | 5 | 0.5 | 0.7 | 0.9 | 10 | 10 | 6 | 45 | 45 | 0.5 | 3 | 10 | 07 | |
| | | | | | | | | | | | | 150 | 500 | 5 | 5 | | | | | | | | | | | | | |
| | | | | | | | | | | | | 60 | 1 | 5 | 5 | | | | | | | | | | | | | |
| 2N981 | TO-18 | 80 | 80 | 80 | 80 | 8 | 30 | 1 | 30 | 30 | 30 | 36 | 100 | 1 | 5 | 3.0 | | | 10 | 10 | 5 | 50 | 50 | 1.0 | | 07 | | |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| 2N2484 | TO-18 | 60 | 60 | 60 | 60 | 6 | 45 | 10 | 45 | 45 | 45 | 250 | 1 | 5 | 0.35 | | | 1 | 1 | 10 | 15 | 15 | 15 | 0.05 | 10 | 20 Hz | 07 | |
| | | | | | | | | | | | | 200 | 500 | 5 | 5 | | | | | | | | | | 3 | 200 Hz | | |
| | | | | | | | | | | | | 175 | 100 | 5 | 5 | | | | | | | | | | 2 | 2 | | |
| | | | | | | | | | | | | 100 | 500 | 10 | 5 | | | | | | | | | | 3 | 15.7 | | |
| | | | | | | | | | | | | 30 | 1 | 5 | 5 | | | | | | | | | | | | | |
| 2N2484 | TO-18 | 60 | 60 | 60 | 60 | 6 | 45 | 10 | 45 | 45 | 45 | 250 | 1 | 5 | 0.3 | | | 1 | 1 | 5 | 60 | 60 | 60 | 0.5 | 7.5 | 100 Hz | 07 | |
| J, JTX, JTXV | | | | | | | | | | | | 250 | 500 | 5 | 5 | | | | | | | | | | 3 | 1 | | |
| | | | | | | | | | | | | 225 | 100 | 5 | 5 | | | | | | | | | | 2 | 10 | | |
| | | | | | | | | | | | | 200 | 500 | 10 | 5 | | | | | | | | | | 3 | 15.7 | | |
| | | | | | | | | | | | | 45 | 1 | 5 | 5 | | | | | | | | | | | | | |
| 2N2509 | TO-18 | 125 | 80 | 80 | 80 | 7 | 100 | 5 | 100 | 100 | 100 | 40 | 10 | 5 | 1.0 | 0.9 | 0.9 | 5 | 5 | 6 | 45 | 45 | 45 | 5 | 7 | 1 | 07 | |
| | | | | | | | | | | | | 25 | 10 | 5 | 5 | | | | | | | | | | | | | |
| 2N2510 | TO-18 | 100 | 65 | 65 | 65 | 7 | 80 | 5 | 80 | 80 | 150 | 500 | 10 | 5 | 1.0 | 0.9 | 0.9 | 5 | 5 | 6 | 45 | 45 | 45 | 5 | 4 | 1 | 07 | |
| | | | | | | | | | | | | 75 | 10 | 5 | 5 | | | | | | | | | | | | | |



LOW LEVEL AMPS (Continued)

| Type No. | Case Style | V _{CB0} (V) | | V _{CE0} (V) | | V _{EB0} (V) | | I _{CB0} (mA) | | V _{CB} (V) | | I _{FE} | | I _C & V _{CE} (V) | | V _{CE(SAT)} & V _{BE(SAT)} (V) | | I _C (mA) | | f _T (MHz) | | NF (dB) | | Process No. | |
|----------|------------|---|-----|----------------------|-----|----------------------|-----|-----------------------|-----|---------------------|-----|-----------------|-----|--------------------------------------|-----|---|-----|---------------------|-----|----------------------|-----|---------|-------------------|-------------|-----|
| | | Min | Max | Min | Max | Min | Max | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | | Max |
| 2N2511 | TO-18 | 80 | 50 | 7 | 60 | 5 | 60 | 5 | 60 | 10 | 5 | 240 | 750 | 10 | 5 | 1.0 | 0.9 | 5 | 5 | 6 | 45 | 4 | 1 | 07 | |
| 2N2504 | TO-46 | 60 | 45 | 6 | 45 | 2 | 45 | 150 | 600 | 1 | 5 | 150 | 600 | 1 | 5 | 0.5 | 0.7 | 0.9 | 10 | 6 | 45 | 3 | 10 | 07 | |
| 2N2586 | TO-18 | 60 | 45 | 6 | 45 | 2 | 45 | 150 | 600 | 10 | 5 | 150 | 600 | 10 | 5 | 0.5 | 0.7 | 0.9 | 10 | 7 | 45 | 3 | 1 | 07 | |
| 2N3117 | TO-18 | 60 | 60 | 6 | 45 | 10 | 45 | 300 | 400 | 1 | 5 | 300 | 500 | 100 | 5 | 0.35 | | | 1 | 4.5 | 60 | 4 | 20 Hz 15 10 Hz | 07 | |
| 2N3246 | TO-18 | 60 | 40 | 10 | 40 | 1 | 40 | 250 | 800 | 10 | 5 | 250 | 500 | 100 | 5 | 0.5 | 0.7 | 0.9 | 5 | 5 | 60 | 2 | 15 | 07 | |
| 2N3565 | TO-92 (72) | Same as PN3565, see page 1-14 for explanation | | | | | | | | | | | | | | | | | | | | | | | |
| 2N3707 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 20 | 100 | 400 | 100 | 5 | 100 | 400 | 100 | 5 | 1.0 | | | 10 | | | | 5 | 15.7 | 07 |
| 2N3708 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 20 | 45 | 660 | 1 | 5 | 45 | 660 | 1 | 5 | 1.0 | | | 10 | | | | | | |
| 2N3709 | TO-92 (74) | 30 | 30 | | 100 | 20 | 20 | 45 | 165 | 1 | 5 | 45 | 165 | 1 | 5 | 1.0 | | | 10 | | | | | | 07 |
| 2N3710 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 20 | 90 | 330 | 1 | 5 | 90 | 330 | 1 | 5 | 1.0 | | | 10 | | | | | | 07 |
| 2N3711 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 20 | 180 | 660 | 1 | 5 | 180 | 660 | 1 | 5 | 1.0 | | | 10 | | | | | | 07 |
| 2N3858A | TO-92 (74) | 60 | 60 | 6 | 500 | 18 | 18 | 60 | 120 | 10 | 1 | 60 | 120 | 10 | 1 | | | | | 4 | 90 | 250 | 2 | | 07 |
| 2N3859A | TO-92 (74) | 60 | 60 | 6 | 500 | 18 | 18 | 75 | 200 | 10 | 1 | 75 | 200 | 10 | 1 | | | | | 4 | 90 | 250 | 2 | | 07 |
| 2N3877 | TO-92 (74) | 70 | 70 | 4 | 500 | 70 | 70 | 20 | 250 | 2 | 4.5 | 20 | 250 | 2 | 4.5 | 0.5 | 0.9 | 10 | | | | | | | 07 |



LOW LEVEL AMPS (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CB0} (nA) Max | h _{FE} Min | h _{FE} Max | I _C (mA) | V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) | | I _C (mA) | C _{ob} (pF) Max | f _T (MHz) | | NF (dB) Max | Freq (kHz) | Process No. | |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|---------------------|---------------------|---------------------|------------------------------|--------------------------|-----|---------------------|--------------------------|----------------------|-----|-------------|------------|-------------|-----|
| | | | | | | | | | | | Min | Max | | | Max | Min | | | | Max |
| 2N3877A | TO-92 (74) | 85 | 85 | 4 | 500 | 20 | 250 | 2 | 4.5 | | 0.5 | 0.9 | 10 | | | | | | 07 | |
| 2N3900 | TO-92 (74) | 18 | 18 | 5 | 100 | 250 | 500 | 2 | 4.5 | | | | | 12 | | | | | 07 | |
| 2N3900A | TO-92 (74) | 18 | 18 | 5 | 100 | 250 | 500 | 2 | 4.5 | | | | | 12 | | | 5 | 15.7 | 07 | |
| 2N3901 | TO-92 (74) | 18 | 18 | 5 | 100 | 350 | 700 | 2 | 4.5 | | | | | | | | 5 | 15.7 | 07 | |
| 2N4286 | TO-92 (74) | 30 | 25 | 6 | 50 | 150 | 600 | 1 | 5 | 0.35 | 0.8 | 1 | 6 | 6 | 40 | 1 | | | 07 | |
| 2N4287 | TO-92 (74) | 45 | 45 | 7 | 10 | 150 | 600 | 1 | 5 | 0.35 | 0.8 | 1 | 6 | 6 | 40 | 1 | 5 | 15.7 | 07 | |
| 2N4384 | TO-18 | 40 | 30 | 5 | 10 | 150 | 10 | 10 | 5 | 0.2 | 0.65 | 0.8 | 10 | 8 | 30 | 120 | 0.5 | 2 | 15.7 | 07 |
| 2N4386 | TO-18 | 40 | 30 | 5 | 10 | 120 | 10 | 10 | 5 | 0.2 | 0.65 | 0.8 | 10 | 8 | 30 | 120 | 0.5 | 3 | 15.7 | 07 |
| 2N4409 | TO-92 (72) | 80 | 50 | 5 | 10 | 40 | 500 | 10 μA | 5 | | | | | | | | | | 07 | |
| 2N4410 | TO-92 (72) | 120 | 80 | 5 | 10 | 60 | 400 | 10 | 1 | 0.2 | 0.8 | 1 | 12 | 12 | 60 | 300 | 10 | | 07 | |
| 2N4966 | TO-92 (72) | | | | | 60 | 400 | 10 | 1 | 0.2 | 0.8 | 1 | 12 | 12 | 60 | 300 | 10 | | 07 | |
| 2N4967 | TO-92 (72) | | | | | 60 | 400 | 10 | 1 | | | | | | | | | | 07 | |
| 2N4968 | TO-92 (72) | | | | | 60 | 400 | 10 | 1 | | | | | | | | | | 07 | |
| 2N5088 | TO-92 (72) | 35 | 30 | | 50 | 300 | 10 | 5 | 5 | 0.5 | | 10 | 4 | | | | 3 | 15.7 | 07 | |
| 2N5089 | TO-92 (72) | 30 | 25 | | 50 | 350 | 1 | 5 | 5 | | | | | | | | | | 07 | |
| 2N5133 | TO-92 (72) | | | | | 400 | 1200 | 100 μA | 5 | 0.5 | | 10 | 4 | | | | 2 | 15.7 | 07 | |

Same as 2N5209, see page 1-14 for explanation

Same as 2N5210, see page 1-14 for explanation

Same as 2N5209, see page 1-14 for explanation

LOW LEVEL AMPS (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) | h _{FE} Min | I _C @ Max (mA) | V _{CE} & V _{BE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Max | I _C (mA) @ Min | NF (dB) (dB) @ Max | Freq (kHz) @ | Process No. |
|----------|---------------|---|-----------------------------|-----------------------------|------------------------------|---------------------|------------------------|------------------------------|--|---------------------------------|---------------------------------|----------------------------|-----------------------------|-----------------------------|---------------------------------|--------------------------|-----------------|-------------|
| 2N5209 | TO-92 (72) | 50 | 50 | | 50 | 35 | 150 | 10 | 5 | 0.7 | | 10 | 4 | 30 | 0.5 | 4 | 1 | 07 |
| | | | | | | | 150 | 1 | 5 | | | | | | | | | |
| | | | | | | | 100 | 300 | 5 | | | | | | | | | |
| 2N5210 | TO-92 (72) | 50 | 50 | | 50 | 35 | 250 | 10 | 5 | 0.7 | | 10 | 4 | 30 | 0.5 | 3 | 1 | 07 |
| | | | | | | | 250 | 1 | 5 | | | | | | | | | |
| | | | | | | | 200 | 600 | 5 | | | | | | | | | |
| 2N5232 | TO-92 (74) | | 50 | | 30 | 50 | 250 | 500 | 2 | 0.125 | | 10 | 4 | | | | | 07 |
| | | | | | | | 250 | 500 | 5 | | | | | | | | | |
| 2N5232A | TO-92 (74) | | 50 | | 30 | 50 | 250 | 500 | 2 | 0.125 | | 10 | 4 | | | | | 07 |
| | | | | | | | 250 | 500 | 5 | | | | | | | | | |
| EN930 | TO-92 (72) | Same as PN930, see below for explanation | | | | | | | | | | | | | | | 07 | |
| EN2484 | TO-92 (72) | Same as PN2484, see below for explanation | | | | | | | | | | | | | | | 07 | |
| MPSA09 | TO-92 (72) | 50 | 50 | | 100 | 25 | 100 | 600 | 100 μA | 0.9 | | 10 | 5 | 600 | 0.5 | | | 07 |
| MPS3707 | TO-92 (72) | | 30 | | 100 | 20 | 100 | 400 | 100 μA | 1.0 | | 10 | | | | 5 | 15.7 | 07 |
| MPS3708 | TO-92 (72) | | 30 | | 100 | 20 | 45 | 660 | 1 | 1.0 | | 10 | | | | | | 07 |
| MPS3709 | TO-92 (72) | | 30 | | 100 | 20 | 45 | 165 | 1 | 1.0 | | 10 | | | | | | 07 |
| MPS3710 | TO-92 (72) | | 30 | | 100 | 20 | 90 | 330 | 1 | 1.0 | | 10 | | | | | | 07 |
| MPS3711 | TO-92 (72) | | 30 | | 100 | 20 | 180 | 660 | 1 | 1.0 | | 10 | | | | | | 07 |
| MPS6571 | TO-92 (72) | 25 | 20 | 3 | 50 | 20 | 250 | 1000 | 100 μA | 0.5 | | 10 | 4.5 | 50 | 0.5 | | | 07 |
| PE4010 | TO-92 (72) | 30 | 25 | 6 | 200 | 5 | 200 | 1000 | 1 | 0.35 | | 1 | 4 | 20 | 0.05 | 3 | 1 | 07 |
| | | | | | | | 150 | 600 | 5 | | | | | 60 | 1 | | | |
| PN930 | TO-92 (72) | 45 | 45 | 5 | 10 | 45 | 100 | 300 | 10 μA | 1.0 | 0.6 | 1.0 | 8 | 30 | 0.5 | 3 | 15.7 | 07 |
| PN2484 | TO-92 (72) | 60 | 60 | 6 | 10 | 45 | 800 | 10 | 5 | 0.35 | | 10 | 6 | | | | 100 Hz | 07 |
| | | | | | | | 250 | 1 | 5 | | | | | | | | | |
| | | | | | | | 200 | 500 μA | 5 | | | | | | | | | |
| | | | | | | | 175 | 100 μA | 5 | | | | | | | | | |
| | | | | | | | 100 | 500 | 5 | | | | | | | | | |
| | | | | | | | 30 | 1 μA | 5 | | | | | | | | | |
| PN3565 | TO-92 (72) | 30 | 25 | 6 | 50 | 25 | 150 | 600 | 1 | 0.35 | | 1 | 4 | 40 | 240 | 1 | | 07 |
| | | | | | | | 60 | 1000 | 1 | | | | | | | | | |
| PN5133 | TO-92 (72) | 20 | 18 | 3 | 50 | 15 | 60 | 1000 | 1 | 0.4 | | 1 | 5 | 40 | 240 | 1 | | 07 |



GENERAL PURPOSE AMPS AND SWITCHES

| Type No. | Case Style | V _{CE0} (V) | | V _{BE0} (V) | | I _{CBO} (nA) @ (V) | | h _{FE} @ I _C & V _{CE} (V) | | V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA) | | C _{ob} (pF) @ I _C (mA) | | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | | NF (dB) Max | Test Condition | Process No. | |
|---------------------|------------|----------------------|-----|----------------------|-----|-----------------------------|-----|--|--------|---|-----|--|-----|--|-----|---------------------------|-----|-------------|----------------|-------------|----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | |
| 2N697 | TO-5 | 60 | 45 | 5 | 30 | 1 μA | 30 | 40 | 120 | 150 | 10 | 1.5 | 1.3 | 150 | 35 | 50 | 50 | | | 20 | |
| 2N718 | TO-18 | 60 | 30 | 5 | 30 | 1 μA | 30 | 40 | 120 | 150 | 10 | 1.5 | 1.3 | 150 | 35 | 50 | 15 | | | 20 | |
| 2N718A | TO-18 | 75 | | 7 | 60 | | | 20 | 500 | 10 | 10 | 1.5 | 1.3 | 150 | 25 | 60 | 50 | | 12 | 1 | 20 |
| 2N915 | TO-18 | 70 | 50 | 5 | 60 | 50 | 200 | 10 | 5 | 10 | 1.0 | 0.9 | 10 | 3.5 | 250 | 10 | | | | 23 | |
| 2N916 | TO-18 | 45 | 25 | 5 | 30 | 50 | 200 | 10 | 1 | 0.5 | 0.9 | 10 | 6 | 300 | 10 | 10 | | | | 23 | |
| 2N956 | TO-18 | 75 | 35 | 7 | 60 | 10 | 60 | 40 | 500 | 10 | 1.5 | 1.3 | 150 | 25 | 70 | 50 | | 8 | 1 | 20 | |
| 2N1420 | TO-5 | 60 | 30 | 5 | 30 | 1 μA | 30 | 100 | 300 | 150 | 10 | 1.5 | 1.3 | 150 | 35 | 50 | 50 | | | 20 | |
| 2N1566 | TO-5 | 80 | 60 | 5 | 40 | 1 μA | 40 | 80 | 200 | 5 | 1.0 | | 10 | 10 | 60 | 5 | | | | 20 | |
| 2N1613 | TO-5 | 75 | 35 | 7 | 60 | 10 | 60 | 20 | 500 | 10 | 1.5 | 1.3 | 150 | 25 | 60 | 50 | | 12 | 1 | 20 | |
| 2N1711 | TO-5 | 75 | 35 | 7 | 60 | 10 | 60 | 40 | 120 | 150 | 10 | 1.5 | 1.3 | 150 | 25 | 70 | 50 | | 8 | 1 | 20 |
| 2N2218 | TO-5 | 60 | 30 | 5 | 50 | 10 | 50 | 20 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | | | | 20 | |
| 2N2218 J, JTX, JTXV | TO-5 | 60 | 30 | 5 | 50 | 10 | 50 | 20 | 150 | 1 | 1.6 | 2.6 | 500 | | | | | | | 20 | |
| | | | | | | | | 40 | 120 | 150 | 10 | 0.4 | 0.6 | 1.3 | 150 | 8 | 250 | 20 | 250 | 2 | 20 |
| | | | | | | | | 35 | 10 | 10 | 1.6 | 2.6 | 500 | | | | | | | | 20 |
| | | | | | | | | 25 | 1 | 10 | 1.6 | 2.6 | 500 | | | | | | | | 20 |
| | | | | | | | | 20 | 100 μA | 10 | 0.4 | 0.6 | 1.3 | 150 | 8 | 250 | 20 | 250 | 2 | 20 | |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1kHz. (2) I_C = 150mA, V_{CC} = 30V, I_{B1} = I_{B2} = 15mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (4) I_C = 300mA, V_{CC} = 25V, I_{B1} = I_{B2} = 30mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7kHz. (6) I_C = 10mA, V_{CC} = 3V, I_{B1} = I_{B2} = 1mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10Hz-15.7kHz. (9) I_C = 3mA, V_{CE} = 10V, f = 1MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz.





GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) @ I _C | h _{FE} Min | I _C @ (mA) Max | V _{CE} (V) & V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) @ I _C Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-------------------------|------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|---|------------------------|------------------------------|--|---------------------------------|---------------------------------|---|-----------------------------|-----------------------------|-----------------------------|------------------------------|----------------|----------------|-------------|
| 2N2218A | TO-5 | 75 | 40 | 6 | 10 | 60 | 25 | 500 | 10 | 0.3 | 0.6 | 1.2 | 8 | 250 | 285 | 2 | 20 | | |
| | | | | | | | 20 | 150 | 1 | 40 | 120 | 150 | 10 | 35 | 10 | | | | |
| 2N2218A J, JTX, JTXV | TO-5 | 75 | 50 | 6 | 10 | 60 | 20 | 500 | 10 | 0.3 | 0.6 | 1.2 | 8 | 250 | 300 | 2 | 20 | | |
| | | | | | | | 40 | 120 | 150 | 10 | 40 | 10 | 10 | 35 | 1 | | | | |
| 2N2219 | TO-5 | 60 | 30 | 5 | 10 | 50 | 30 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | | | | |
| | | | | | | | 50 | 150 | 1 | 100 | 300 | 150 | 10 | 75 | | | | | |
| 2N2219 J, JTX, JTXV | TO-5 | 60 | 30 | 5 | 10 | 50 | 30 | 500 | 10 | 0.4 | 0.6 | 1.2 | 8 | 250 | 250 | 2 | 20 | | |
| | | | | | | | 100 | 300 | 150 | 10 | 75 | 10 | 10 | 50 | 1 | | | | |
| 2N2219A | TO-5 | 75 | 40 | 6 | 10 | 60 | 40 | 500 | 10 | 0.6 | 1.2 | 150 | 8 | 300 | 285 | 2 | 20 | | |
| | | | | | | | 50 | 150 | 1 | 100 | 300 | 150 | 10 | 75 | 10 | | | | |
| 2N2219A J, JTX, JTXV | TO-5 | 75 | 50 | 6 | 10 | 60 | 30 | 500 | 10 | 0.3 | 0.6 | 1.2 | 8 | 250 | 300 | 2 | 20 | | |
| | | | | | | | 100 | 300 | 150 | 10 | 40 | 10 | 10 | 35 | 1 | | | | |
| 2N2221 | TO-18 | 60 | 30 | 5 | 10 | 50 | 20 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | | | | |
| | | | | | | | 20 | 150 | 1 | 40 | 120 | 150 | 10 | 35 | | | | | |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) | | V _{CE0} (V) | | V _{CB0} (V) | | V _{CB} (V) | | h _{FE} @ I _C & V _{CE} (V) | | V _{BE(SAT)} @ I _C (mA) | | C _{ob} (pF) | | f _T (MHz) | | t _{off} (ns) | | NF (dB) Max | Test Condition | Process No. |
|-------------------------|------------|----------------------|-----|----------------------|-----|----------------------|-----|---------------------|-----|--|-----|--|-----|----------------------|-----|----------------------|-----|-----------------------|-----|-------------|----------------|-------------|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | |
| 2N2221 J, JTX, JTXV | TO-18 | 60 | 30 | 5 | 10 | 50 | 20 | 40 | 120 | 150 | 10 | 0.4 | 0.6 | 1.3 | 150 | 8 | 250 | 20 | 250 | 2 | 20 | |
| | | | | | | | | | | | | | | | | | | | | | | 35 |
| 2N2221A | TO-18 | 75 | 40 | 6 | 10 | 60 | 25 | 40 | 120 | 150 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | 20 | 285 | 2 | 20 | |
| | | | | | | | | | | | | | | | | | | | | | | 35 |
| 2N2221A J, JTX, JTXV | TO-18 | 75 | 50 | 6 | 10 | 60 | 20 | 40 | 120 | 150 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | 20 | 300 | 2 | 20 | |
| | | | | | | | | | | | | | | | | | | | | | | 35 |
| 2N2222 | TO-18 | 60 | 30 | 5 | 10 | 50 | 30 | 50 | 100 | 150 | 10 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | 250 | 20 | 2 | 20 | |
| | | | | | | | | | | | | | | | | | | | | | | 50 |
| 2N2222 J, JTX, JTXV | TO-18 | 60 | 30 | 5 | 10 | 50 | 100 | 75 | 50 | 10 | 10 | 0.4 | 0.5 | 1.3 | 150 | 8 | 250 | 20 | 250 | 2 | 20 | |
| | | | | | | | | | | | | | | | | | | | | | | 35 |
| 2N222A | TO-18 | 75 | 40 | 6 | 10 | 60 | 40 | 50 | 300 | 150 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | 20 | 285 | 4 | 2/3 | 20 |
| | | | | | | | | | | | | | | | | | | | | | | |
| 2N222A J, JTX, JTXV | TO-18 | 75 | 50 | 6 | 10 | 60 | 30 | 300 | 100 | 150 | 10 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | 20 | 300 | 2 | 20 | |
| | | | | | | | | | | | | | | | | | | | | | | 75 |
| 2N2712 (74) | TO-92 | 18 | 18 | 5 | 500 | 18 | 75 | 225 | 2 | 4.5 | | | | | 12 | 80 | 300 | 2 | | | 27 | |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1kHz. (2) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (4) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7kHz. (6) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10Hz-15.7kHz. (9) I_C = 3mA, V_{CE} = 10V, f = 1MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz.

GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C (mA) Max | V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|---------------------|---------------------|-------------------------|---------------------|------------------------------|------------------------------|-------------------------|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|
| 2N2714 | TO-92 (74) | 18 | 18 | 5 | 500 | 18 | 75 | 225 | 2 | 4.5 | 0.3 | 0.6 | 1.2 | 50 | | | | | | 27 |
| 2N2923 | TO-92 (74) | 25 | 25 | 5 | 100 | 25 | 90 | 180 | 2 | 10 | | | | 10 | | | | | | 04 |
| 2N2924 | TO-92 (74) | 25 | 25 | 5 | 100 | 25 | 150 | 300 | 2 | 10 | | | | 10 | | | | | | 04 |
| 2N2925 | TO-92 (74) | 25 | 25 | 5 | 100 | 25 | 235 | 470 | 2 | 10 | | | | 10 | | | | | | 04 |
| 2N2926 | TO-92 (74) | 18 | 18 | 5 | 500 | 18 | 35 | 470 | 2 | 10 | | | | 10 | | | | | | 04 |
| 2N3115 | TO-18 | 60 | 20 | 5 | 25 | 50 | 40 | 120 | 150 | 10 | 0.5 | 1.3 | 150 | 8 | 250 | 20 | 500 | | 2 | 20 |
| 2N3116 | TO-18 | 60 | 20 | 5 | 25 | 50 | 100 | 300 | 150 | 10 | 0.5 | 1.3 | 150 | 8 | 250 | 20 | 500 | | 2 | 20 |
| 2N3299 | TO-5 | 60 | 30 | 5 | 10* | 50 | 20 | 500 | 10 | 10 | 0.22 | 1.1 | 150 | 8 | 250 | 50 | 150 | | 4 | 20 |
| | | | | | | | 20 | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 40 | 120 | 150 | 10 | | | | | | | | | | |
| | | | | | | | 35 | 10 | 10 | 10 | 0.6 | 1.5 | 500 | | | | | | | |
| | | | | | | | 25 | 1 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 20 | 100 μA | 10 | 10 | | | | | | | | | | |
| 2N3300 | TO-5 | 60 | 30 | 5 | 10* | 50 | 50 | 500 | 10 | 10 | 0.22 | 1.1 | 150 | 8 | 250 | 50 | 150 | | 4 | 20 |
| | | | | | | | 50 | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | | | | | | | | | | |
| | | | | | | | 75 | 10 | 10 | 10 | 0.6 | 1.5 | 500 | | | | | | | |
| | | | | | | | 50 | 1 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 35 | 100 μA | 10 | 10 | | | | | | | | | | |
| 2N3301 | TO-18 | 60 | 30 | 5 | 10* | 50 | 20 | 500 | 10 | 10 | 0.22 | 1.1 | 150 | 8 | 250 | 50 | 150 | | 4 | 20 |
| | | | | | | | 20 | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 40 | 120 | 150 | 10 | 0.6 | 1.5 | 500 | | | | | | | |
| | | | | | | | 35 | 10 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 25 | 1 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 20 | 100 μA | 10 | 10 | | | | | | | | | | |
| 2N3302 | TO-18 | 60 | 30 | 5 | 10* | 50 | 50 | 500 | 10 | 10 | 0.22 | 1.1 | 150 | 8 | 250 | 50 | 150 | | 4 | 20 |
| | | | | | | | 50 | 150 | 1 | | | | | | | | | | | |
| | | | | | | | 100 | 300 | 150 | 10 | 0.6 | 1.5 | 500 | | | | | | | |
| | | | | | | | 75 | 10 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 50 | 1 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 20 | 100 μA | 10 | 10 | | | | | | | | | | |
| 2N3390 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 400 | 800 | 2 | 4.5 | | | | 10 | | | | | | 04 |
| 2N3391 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 250 | 500 | 2 | 4.5 | | | | 10 | | | | | | 04 |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C (mA) @ V _{CE} | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) @ I _C | | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|---|--------------------------|--------------------------|---------------------------|---------------------|---------------------|---------------------|---------------------------------------|------------------------------|---|-----|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|----|
| | | | | | | | | | | | Min | Max | | | | | | | | |
| 2N3391 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 250 | 500 | 2 | 4.5 | | | 10 | | | | | 5 | 04 | |
| 2N3392 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 150 | 300 | 2 | 4.5 | | | 10 | | | | | | 04 | |
| 2N3393 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 90 | 180 | 2 | 4.5 | | | 10 | | | | | | 04 | |
| 2N3394 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 55 | 110 | 2 | 4.5 | | | 10 | | | | | | 0.4 | |
| 2N3395 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 150 | 500 | 2 | 4.5 | | | 10 | | | | | | 04 | |
| 2N3396 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 90 | 500 | 2 | 4.5 | | | 10 | | | | | | 04 | |
| 2N3397 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 55 | 500 | 2 | 4.5 | | | 10 | | | | | | 04 | |
| 2N3398 | TO-92 (74) | 25 | 25 | 5 | 100 | 18 | 55 | 800 | 2 | 4.5 | | | 10 | | | | | | 04 | |
| 2N3414 | TO-92 (74) | 25 | 25 | 5 | 100 | 25 | 75 | 225 | 2 | 4.5 | 0.3 | 0.6 | 1.3 | 50 | | | | | 19 | |
| 2N3415 | TO-92 (74) | 25 | 25 | 5 | 100 | 25 | 180 | 540 | 2 | 4.5 | 0.3 | 0.6 | 1.3 | 50 | | | | | 04 | |
| 2N3416 | TO-92 (74) | 50 | 50 | 5 | 100 | 25 | 75 | 225 | 2 | 4.5 | 0.3 | 0.6 | 1.3 | 50 | | | | | 04 | |
| 2N3417 | TO-92 (74) | 50 | 50 | 5 | 100 | 25 | 180 | 540 | 2 | 4.5 | 0.3 | 0.6 | 1.3 | 50 | | | | | 04 | |
| 2N3641 | TO-92 (72) | Same as PN3641, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N3642 | TO-92 (72) | Same as PN3642, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N3643 | TO-92 (72) | Same as PN3643, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N3678 | TO-5 | 75 | 55 | 6 | 10 | 60 | 25 | 20 | 500 | 10 | 0.4 | 0.6 | 1.2 | 150 | | | 250 | | 2 | 20 |
| | | | | | | | 40 | 120 | 150 | 10 | 1.0 | 2.0 | 500 | | | | | | | |
| | | | | | | | 35 | 10 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 25 | 1 | 10 | 10 | | | | | | | | | | |
| | | | | | | | 20 | 100 | 100 | 10 | | | | | | | | | | |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1kHz. (2) I_C = 150mA, V_{CE} = 30V, I_B¹ = I_B² = 15mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (4) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7kHz. (6) I_C = 10mA, V_{CE} = 3V, I_B¹ = I_B² = 1mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10Hz-15.7kHz. (9) I_C = 3mA, V_{CE} = 10V, f = 1MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz.



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CE0} (V) | | V _{BE0} (V) | | I _{CBO} (nA) @ V _{CB} (V) | | h _{FE} @ I _C (mA) | | V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA) | | C _{ob} (pF) | | f _T (MHz) | | t _{off} (ns) | | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|---|-----|----------------------|-----|---|-----|---------------------------------------|-----|---|------|----------------------|-----|----------------------|-----|-----------------------|-----|-------------|----------------|-------------|----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | |
| 2N3691 | TO-92 (72) | Same as PN3691, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | | 23 |
| 2N3692 | TO-92 (72) | Same as PN3692, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | | 23 |
| 2N3693 | TO-92 (72) | Same as MP3693, see page 1-24 for explanation | | | | | | | | | | | | | | | | | | | 27 |
| 2N3694 | TO-92 (72) | Same as PN3694, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | | 27 |
| 2N3704 | TO-92 (74) | 50 | 30 | 5 | 100 | 20 | 100 | 300 | 50 | 2 | 0.6 | 100 | 12 | 100 | 50 | | | | | 13 | |
| 2N3705 | TO-92 (74) | 50 | 30 | 5 | 100 | 20 | 50 | 150 | 50 | 2 | 0.8 | 100 | 12 | 100 | 50 | | | | | 13 | |
| 2N3706 | TO-92 (74) | 40 | 20 | 5 | 100 | 20 | 30 | 600 | 50 | 2 | 1.0 | 100 | 12 | 100 | 50 | | | | | 13 | |
| 2N3721 | TO-92 (74) | 18 | 18 | 5 | 500 | 18 | 60 | 660 | 2 | 10 | | 12 | | | | | | | | 27 | |
| 2N3793 | TO-92 (74) | 40 | 20 | 5 | 500 | 15 | 20 | 120 | 10 | 10 | 0.4 | 10 | 10 | 100 | 600 | 10 | | | | 13 | |
| 2N3794 | TO-92 (74) | 40 | 20 | 5 | 500 | 15 | 100 | 600 | 10 | 10 | 0.4 | 10 | 10 | 100 | 600 | 10 | | | | 13 | |
| 2N3827 | TO-92 (74) | 60 | 45 | 4 | 100 | 30 | 100 | 400 | 10 | 10 | | 3.5 | 200 | 800 | 10 | | | | | 27 | |
| 2N3858 | TO-92 (74) | 30 | 30 | 4 | 500 | 18 | 60 | 120 | 2 | 4.5 | | 4 | 90 | 250 | 2 | | | | | 27 | |
| 2N3859 | TO-92 (74) | 30 | 30 | 4 | 500 | 18 | 100 | 200 | 2 | 4.5 | | 4 | 90 | 250 | 2 | | | | | 27 | |
| 2N3860 | TO-92 (74) | 30 | 30 | 4 | 500 | 18 | 150 | 300 | 2 | 4.5 | | 4 | 90 | 250 | 2 | | | | | 27 | |
| 2N3903 | TO-92 (72) | 60 | 40 | 6 | | | 15 | 100 | 1 | 0.2 | 0.6 | 0.85 | 10 | 4 | 250 | 10 | 225 | 6 | 6/7 | 23 | |
| | | | | | | | 30 | 50 | 1 | 0.3 | 0.95 | 50 | | | | | | | | | |
| | | | | | | | 50 | 150 | 1 | | | | | | | | | | | | |
| | | | | | | | 35 | 1 | 1 | | | | | | | | | | | | |
| | | | | | | | 20 | 100 | 100 | 1 | | | | | | | | | | | |
| 2N3904 | TO-92 (72) | 60 | 40 | 6 | 30 | 30 | 30 | 100 | 1 | 0.2 | 0.65 | 0.85 | 10 | 4 | 300 | 10 | 250 | 5 | 6/7 | 23 | |
| | | | | | | | 60 | 50 | 1 | 0.3 | 0.95 | 50 | | | | | | | | | |
| | | | | | | | 100 | 300 | 10 | | | | | | | | | | | | |
| | | | | | | | 70 | 1 | 1 | | | | | | | | | | | | |
| | | | | | | | 40 | 100 | 100 | 1 | | | | | | | | | | | |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CE0} (V) | | V _{BE0} (V) | | I _{CBO} (nA) @ V _{CB} (V) | | h _{FE} @ I _C & V _{CE} (V) | | V _{CE(SAT)} & V _{BE(SAT)} (V) @ I _C (mA) | | C _{ob} (pF) | | f _T (MHz) | | t _{off} (ns) | | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|---|-----|----------------------|-----|---|-----|--|-----|---|------|----------------------|-----|----------------------|-----|-----------------------|-----|-------------|----------------|-------------|----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | |
| 2N3946 | TO-18 | 60 | 40 | 6 | | | | 20 | 50 | 0.2 | 0.6 | 0.9 | 10 | 4 | 250 | 10 | 375 | 5 | 6/7 | 23 | |
| | | | | | | | | 50 | 150 | 1 | 1 | 0.3 | 1.0 | 50 | | | | | | | |
| 2N3947 | TO-18 | 60 | 40 | 6 | | | | 40 | 50 | 0.2 | 0.6 | 0.9 | 10 | 4 | 300 | 10 | 450 | 5 | 6/7 | 23 | |
| | | | | | | | | 100 | 300 | 1 | 1 | 0.3 | 1.0 | 50 | | | | | | | |
| 2N4123 | TO-92 (72) | 40 | 30 | 5 | 20 | 20 | 50 | 25 | 50 | 0.3 | 0.95 | 50 | 4 | 250 | 10 | 6 | 7 | 7 | 23 | | |
| | | | | | | | | 60 | 150 | 2 | 1 | | | | | | | | | | |
| 2N4124 | TO-92 (72) | 30 | 25 | 5 | 20 | 50 | 50 | 60 | 50 | 0.3 | 0.95 | 50 | 4 | 300 | 10 | 5 | 7 | 7 | 23 | | |
| | | | | | | | | 120 | 360 | 2 | 1 | | | | | | | | | | |
| 2N4140 | TO-92 (72) | Same as PN4140, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | | |
| 2N4141 | TO-92 (72) | Same as PN4141, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | | |
| 2N4400 | TO-92 (72) | 60 | 40 | 6 | | | | 20 | 500 | 0.4 | 0.75 | 0.95 | 150 | 6.5 | 200 | 20 | 255 | | 2 | 13 | |
| | | | | | | | | 50 | 150 | 1 | 1 | 0.75 | 1.2 | 500 | | | | | | | |
| 2N4401 | TO-92 (72) | 60 | 40 | 6 | | | | 40 | 500 | 0.4 | 0.75 | 0.95 | 150 | 6.5 | 250 | 20 | 255 | | 2 | 13 | |
| | | | | | | | | 100 | 300 | 1 | 1 | 0.75 | 1.2 | 500 | | | | | | | |
| PN2221 | TO-92 (72) | 60 | 30 | 5 | 10 | 50 | 100 | 20 | 500 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | 250 | 20 | 285 | | 2 | 19 |
| | | | | | | | | 20 | 150 | 1 | 1 | 1.6 | 2.6 | 500 | | | | | | | |
| PN2221A | TO-92 (72) | 75 | 40 | 6 | 10 | 60 | 500 | 25 | 500 | 0.3 | 0.6 | 1.2 | 150 | 8 | 250 | 20 | 285 | | 2 | 19 | |
| | | | | | | | | 20 | 150 | 1 | 1 | 1.0 | 2.0 | 500 | | | | | | | |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1kHz. (2) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (4) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7kHz. (6) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10Hz-15.7kHz. (9) I_C = 3mA, V_{CE} = 10V, f = 1MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz.



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CBO} (nA) @ V _{CB} Max | h _{FE} Min | h _{FE} Max | I _C @ V _{CE} & V _{BE} (mA) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C @ V _{CE(SAT)} & V _{BE(SAT)} (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|---|---------------------|---------------------|---|------------------------------|------------------------------|---|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|
| PN2222 | TO-92 (72) | 30 | 5 | 10 | 30 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | | | | 19 |
| PN2222A | TO-92 (72) | 40 | 6 | 10 | 40 | 500 | 10 | 0.3 | 0.6 | 150 | 8 | 300 | 20 | 285 | | 2 | 19 |
| PN3641 | TO-92 (72) | 60* | 5 | 50* | 15 | 500 | 10 | 0.22 | | 150 | 8 | 250 | 50 | | | | 19 |
| PN3642 | TO-92 (72) | 60 | 5 | 50* | 15 | 500 | 10 | 0.22 | | 150 | 8 | 250 | 50 | | | | 19 |
| PN3643 | TO-92 (72) | 60 | 5 | 50* | 20 | 500 | 10 | 0.22 | | 150 | 8 | 250 | 50 | | | | 19 |
| PN3691 | TO-92 (72) | 35 | 4 | 50 | 40 | 160 | 1 | 0.7 | 0.9 | 10 | 3.5 | 200 | 500 | | | | 23 |
| PN3692 | TO-92 (72) | 35 | 4 | 50 | 100 | 400 | 1 | 0.7 | 0.9 | 10 | 3.5 | 200 | 500 | | | | 23 |
| PN3694 | TO-92 (72) | 45 | 4 | 50 | 100 | 400 | 1 | | | | 6 | 200 | 10 | | | | 27 |
| PN4140 | TO-92 (72) | 30 | 5 | | 20 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | 250 | 20 | 310 | | 2 | 19 |
| PN4141 | TO-92 (72) | 30 | 5 | | 20 | 150 | 1 | 1.6 | 2.6 | 500 | | | | | | | 19 |
| PN5127 | TO-92 (72) | 20 | 3 | 50 | 15 | 300 | 2 | 0.3 | 1.0 | 10 | 3.5 | 150 | 2 | 310 | | 2 | 27 |
| PN5128 | TO-92 (72) | 15 | 3 | 50 | 35 | 350 | 50 | 0.25 | 1.1 | 150 | 10 | 200 | 800 | | | | 19 |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CBO} (mA) @ V _{CB} Max | h _{FE} @ I _C & V _{CE} Min Max | V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C Max Min | I _C (mA) @ I _C Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|---|-----------------------------|-----------------------------|--|---|---|---|-----------------------------|---------------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| | | | | | | | | | | | | | | | |
| PN5129 | TO-92 (72) | 15 | 12 | 3 | 50 | 35 350 50 20 | 0.25 1.1 | 150 50 | 10 | 200 800 | 50 | | | | 19 |
| PN5131 | TO-92 (72) | 20 | 15 | 3 | 50 | 35 500 10 1 | 1.0 | 10 | 6 | 100 | 10 | | | | 27 |
| PN5132 | TO-92 (72) | 20 | 20 | 3 | 50 | 30 400 10 10 | 2.0 | 10 | 3.5 | 200 | 10 | | | | 27 |
| PN5135 | TO-92 (72) | 30 | 25 | 4 | 300 | 50 60* 10 15 2 | 1.0 1.0 | 100 30 | 25 | 40 500 | 30 | | | | 19 |
| PN5136 | TO-92 (72) | 30 | 20 | 3 | 100 | 20 400 150 1 20 30 1 | 0.25 1.1 | 150 50 | 35 | 40 400 | 50 | | | | 19 |
| PN5137 | TO-92 (72) | 30 | 20 | 3 | 100 | 20 400 150 1 20 30 1 | 0.25 1.1 | 150 50 | 35 | 40 400 | 50 | | | | 19 |
| EN2222 | TO-92 (72) | Same as PN2222, see page 1-22 for explanation | | | | | | | | | | | | | |
| MPSA10 | TO-92 (72) | | 40 | 4 | 100 | 30 40 400 5 10 | | | 4 | 50 | 5 | | | | 27 |
| MPSA20 | TO-92 (72) | | 40 | 4 | 100 | 30 40 400 5 10 | | | 4 | 125 | 5 | | | | 02 |
| MPSL01 | TO-92 (72) | 140 | 120 | 5 | 1 μA | 40 50 300 10 5 | 0.2 0.3 | 10 50 | 8 | 60 | 10 | | | | 16 |
| MPS2711 | TO-92 (72) | 18 | 18 | 5 | 500 | 18 30 90 2 4.5 | | | 4 | | | | | | 23 |
| MPS2712 | TO-92 (72) | 18 | 18 | 5 | 500 | 18 75 225 2 4.5 | | | 4 | | | | | | 23 |
| MPS2716 | TO-92 (72) | 18 | 18 | 5 | 500 | 18 75 225 2 4.5 | | | 3.5 | | | | | | 23 |
| MPS2923 | TO-92 (72) | 25 | 25 | 5 | 500 | 25 90 180 2 10 (1 kHz) | | | 12 | | | | | | 04 |
| MPS2924 | TO-92 (72) | 25 | 25 | 5 | 500 | 25 150 300 2 10 (1 kHz) | | | 12 | | | | | | 04 |
| MPS2925 | TO-92 (72) | 25 | 25 | 5 | 500 | 25 235 470 2 10 (1 kHz) | | | 12 | | | | | | 04 |
| MPS2926 | TO-92 (72) | 25 | 25 | 5 | 500 | 18 35 470 2 (1 kHz) (5 Groups) | | | 3.5 | | | | | | 04 |
| MPS3392 | TO-92 (72) | 25 | 25 | 5 | 100 | 18 150 300 2 4.5 | | | 10 | | | | | | 04 |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1kHz. (2) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (4) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7kHz. (6) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10Hz-15.7kHz. (9) I_C = 3mA, V_{CE} = 10V, f = 1MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz.

GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CEO} (V) Min | V _{EBO} (V) Min | ICBO (mA) Max | V _{CB} (V) Max | h _{FE} Min | h _{FE} Max | IC @ (mA) | V _{CE} (V) | V _{CE(SAT)} (V) Max & V _{BE(SAT)} (V) Min | IC (mA) @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--|--------------------------|---------------|-------------------------|---------------------|---------------------|-----------|---------------------|---|--------------------|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|
| MPS3393 | TO-92 (72) | | 25 | | 100 | 18 | 90 | 180 | 2 | 4.5 | | | 3.5 | | | | | | 04 |
| MPS3394 | TO-92 (72) | | 25 | | 100 | 18 | 55 | 110 | 2 | 4.5 | | | 3.5 | | | | | | 04 |
| MPS3395 | TO-92 (72) | | 25 | | 100 | 18 | 150 | 500 | 2 | 4.5 | | | 3.5 | | | | | | 04 |
| MPS3396 | TO-92 (72) | | 25 | | 100 | 18 | 90 | 500 | 2 | 4.5 | | | 3.5 | | | | | | 04 |
| MPS3397 | TO-92 (72) | | 25 | | 100 | 18 | 55 | 500 | 2 | 4.5 | | | 3.5 | | | | | | 04 |
| MPS3398 | TO-92 (72) | | 25 | | 100 | 18 | 55 | 800 | 2 | 4.5 | | | 3.5 | | | | | | 04 |
| MPS3642 | TO-92 (72) | | Same as PN3642, see page 1.22 for explanation. | | | | | | | | | | | | | | | | |
| MPS3693 | TO-92 (72) | 45 | 45 | 4 | 50 | 35 | 40 | 160 | 10 | 10 | | | 3.5 | 200 | 10 | | 4 | | 27 |
| MPS3694 | TO-92 (72) | 45 | 45 | 4 | 50 | 35 | 100 | 400 | 10 | 10 | | | 3.5 | 200 | 10 | | 4 | | 27 |
| MPS3704 | TO-92 (72) | 50 | 30 | 5 | 100 | 20 | 100 | 300 | 50 | 2 | 0.6 | 100 | 12 | 100 | 50 | | | | 13 |
| MPS3705 | TO-92 (72) | 50 | 30 | 5 | 100 | 20 | 50 | 150 | 50 | 2 | 0.8 | 100 | 12 | 100 | 50 | | | | 13 |
| MPS3706 | TO-92 (72) | 40 | 20 | 5 | 100 | 20 | 30 | 600 | 50 | 2 | 1.0 | 100 | 12 | 100 | 50 | | | | 13 |
| MPS3721 | TO-92 (72) | | | | 500 | 18 | 60 | 660 | 2 | 10 | | | 3.5 | | | | | | 23 |
| MPS3826 | TO-92 (72) | 60 | 45 | 4 | 100 | 30 | 40 | 160 | 10 | 10 | | | 3.5 | 200 | 800 | 10 | | | 23 |
| MPS3827 | TO-92 (72) | 60 | 45 | 4 | 100 | 30 | 100 | 400 | 10 | 10 | | | 3.5 | 200 | 800 | 10 | | | 23 |
| MPS5172 | TO-92 (72) | 25 | 25 | 5 | 100 | 25 | 100 | 500 | 10 | 10 | 0.25 | 10 | 10 | | | | | | 04 |
| MPS6512 | TO-92 (72) | 40 | 30 | 4 | 50 | 30 | 30 | 100 | 100 | 10 | 0.5 | 50 | 3.5 | | | | | | 23 |
| MPS6513 | TO-92 (72) | 40 | 30 | 4 | 50 | 30 | 60 | 100 | 100 | 10 | 0.5 | 50 | 3.5 | | | | | | 23 |
| MPS6514 | TO-92 (72) | 40 | 25 | 4 | 50 | 30 | 90 | 180 | 2 | 10 | 0.5 | 50 | 3.5 | | | | | | 23 |
| | | | | | | | 150 | 300 | 2 | 10 | 0.5 | 50 | 3.5 | | | | | | 23 |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) Max | h _{FE} | | I _C & V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------|-------------------------|----------------------------|------------------------------|--------------------------------------|------------------------------|--------------------------|-----|-------------------------|--------------------------|--------------------------|-------------------------|---------------------------|-------------|----------------|-------------|
| | | | | | | | Min | Max | | | Min | Max | | | | | | | | |
| MPS6515 | TO-92 (72) | 40 | 25 | 4 | 50 | 30 | 150 250 | 100 500 | 10 2 | 0.5 | 50 | 3.5 | | | | | | | | 23 |
| MPS6520 | TO-92 (72) | | 25 | 4 | 50 | 30 | 200 100 | 400 100 | 2 100 | 0.5 | 50 | 3.5 | | | | | | | 10 | 04 |
| MPS6521 | TO-92 (72) | | 25 | 4 | 50 | 30 | 200 150 | 600 100 | 2 100 | 0.5 | 50 | 3.5 | | | | | | | 10 | 04 |
| MPS6530 | TO-92 (72) | 60 | 40 | 5 | 50 | 40 | 25 40 30 | 500 120 100 | 10 1 1 | 0.5 | 100 100 | 5 | | | | | | | | 13 |
| MPS6531 | TO-92 (72) | 60 | 40 | 5 | 50 | 40 | 50 90 60 | 500 270 100 | 10 1 1 | 0.3 | 100 100 | 5 | | | | | | | | 13 |
| MPS6532 | TO-92 (72) | 50 | 30 | 5 | 100 | 30 | 30 | 100 | 1 | 0.5 | 100 | 5 | | | | | | | | 13 |
| MPS6564 | TO-92 (72) | | 45 | 5 | 500 | 40 | 25 | 10 | 5 | 0.5 | 10 | 4 | | | | | | | | 27 |
| MPS6565 | TO-92 (72) | 60 | 45 | 4 | 100 | 30 | 40 | 160 | 10 | 0.4 | 10 | 3.5 | | | | | | | | 27 |
| MPS6566 | TO-92 (72) | 60 | 45 | 4 | 100 | 30 | 100 | 400 | 10 | 0.4 | 10 | 3.5 | | | | | | | | 27 |
| MPS6573 | TO-92 (72) | | 35 | | 100 | 35 | 100 200 | 100 500 | 10 10 | 0.5 | 10 | 12 | | | | | | | | 02 |
| MPS6574 | TO-92 (72) | | 35 | | 100 | 35 | 100 (4 Groups) | 300 1 | 5 | 0.5 | 10 | 12 | | | | | | | | 02 |
| MPS6575 | TO-92 (72) | | 45 | | 100 | 45 | 100 200 | 100 500 | 10 10 | 0.5 | 10 | 12 | | | | | | | | 02 |
| MPS6576 | TO-92 (72) | | 45 | | 100 | 45 | 100 (4 Groups) | 300 1 | 5 | 0.5 | 10 | 12 | | | | | | | | 02 |
| NCBT13 | TO-92 (72) | 60 | 40 | 4 | 100 | 30 | 40 | 20 | 1 | 0.15 | 100 | 6 | | | | | | | | 13 |
| NS3903 | TO-18 | 60 | 40 | 6 | | | 15 30 50 35 20 | 100 50 150 1 100 | 1 1 1 1 1 | 0.2 0.65 0.85 | 10 10 50 | 4 | | | | | | | 6 | 23 |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1kHz. (2) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (4) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7kHz. (6) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7kHz. (8) I_C = 250 μA, V_{CE} = 5V, f = 10Hz-15.7kHz. (9) I_C = 3mA, V_{CE} = 10V, f = 1MHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz.



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CB0} (nA) @ V _{CB} Max | h _{FE} Min | h _{FE} Max | I _C & V _{CE} (mA) & (V) | V _{CE(SAT)} (V) & V _{BE(SAT)} (V) Max | I _C (mA) @ V _{CE} Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) @ V _{CE} Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | |
|----------|------------|--|-----------------------------|-----------------------------|--|------------------------|------------------------|--|--|--|-----------------------------|-----------------------------|-----------------------------|--|------------------------------|----------------|----------------|-------------|-----|-----|
| | | | | | | | | | | | | | | | | | | | Max | Min |
| NS3904 | TO-18 | 60 | 40 | 6 | | 30 | 100 | 1 | 0.2 | 0.65 | 0.85 | 10 | 4 | 300 | 10 | 250 | | 6 | 23 | |
| 2N4424 | TO-92 (74) | 40 | 40 | 5 | 100 | 25 | 180 | 540 | 2 | 4.5 | | | | | | | | | 04 | |
| 2N4944 | TO-92 (72) | Same as PN2222A, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4945 | (72) | Same as PN2222A, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4946 | (72) | Same as PN2222A, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4951 | TO-92 (74) | 60 | 30 | 5 | 50 | 40 | 60 | 200 | 150 | 10 | 0.3 | 1.3 | 150 | 8 | 250 | 20 | 400 | | 2 | 13 |
| 2N4952 | TO-92 (74) | 60 | 30 | 5 | 50 | 40 | 100 | 300 | 150 | 10 | 0.3 | 1.3 | 150 | 8 | 250 | 20 | 400 | | 2 | 13 |
| 2N4953 | TO-92 (74) | 60 | 30 | 5 | 50 | 40 | 200 | 600 | 150 | 10 | 0.3 | 1.3 | 150 | 8 | 250 | 20 | 400 | | 2 | 13 |
| 2N4954 | TO-92 (74) | 40 | 30 | 5 | 50 | 30 | 60 | 600 | 150 | 10 | 0.3 | 1.3 | 150 | 8 | 250 | 20 | 400 | | 2 | 13 |
| 2N4969 | TO-92 (72) | Same as PN2221, see page 1-21 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4970 | TO-92 (72) | Same as PN2222, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N5127 | TO-92 (72) | Same as PN5127, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N5128 | TO-92 (72) | Same as PN5128, see page 1-22 for explanation | | | | | | | | | | | | | | | | | | |
| 2N5129 | TO-92 (72) | Same as PN5129, see page 1-23 for explanation | | | | | | | | | | | | | | | | | | |
| 2N5131 | TO-92 (72) | Same as PN5131, see page 1-23 for explanation | | | | | | | | | | | | | | | | | | |
| 2N5132 | TO-92 (72) | Same as PN5132, see page 1-23 for explanation | | | | | | | | | | | | | | | | | | |
| 2N5135 | TO-92 (72) | Same as PN5135, see page 1-23 for explanation | | | | | | | | | | | | | | | | | | |
| 2N5136 | TO-92 (72) | Same as PN5136, see page 1-23 for explanation | | | | | | | | | | | | | | | | | | |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CEO} (V) Max | V _{EB0} (V) Min | V _{EB0} (V) Max | I _{CB0} (mA) @ V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C (mA) & V _{CE} (V) | V _{CE} (SAT) (V) Max | V _{BE} (SAT) (V) Min | V _{BE} (SAT) (V) Max | I _C (mA) @ I _T (MHz) | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|--------------------------|--------------------------|--------------------------|--------------------------|---|---------------------|---------------------|---|-------------------------------|-------------------------------|-------------------------------|--|---------------------------|-------------|----------------|-------------|
| 2N5137 | TO-92 (72) | 25 | 25 | 5 | 100 | 25 | 100 | 500 | 10 | 0.25 | | | | | | | 19 |
| 2N5172 | TO-92 (74) | 20 | 15 | 3 | 100 | 10 | 35 | 500 | 2 | 0.4 | 1.0 | 1.0 | 10 | | | | 04 |
| 2N5219 | TO-92 (72) | 15 | 15 | 3 | 100 | 10 | 30 | 600 | 50 | 0.5 | 1.1 | 1.50 | 10 | | | | 27 |
| 2N5220 | TO-92 (72) | 25 | 20 | 3 | 100 | 10 | 50 | 800 | 2 | 0.7 | 1.2 | 1.0 | 10 | | | | 13 |
| 2N5223 | TO-92 (72) | 25 | 25 | 4 | 300 | 15 | 30 | 600 | 50 | 0.8 | 1.0 | 1.00 | 20 | | | | 27 |
| 2N5225 | TO-92 (72) | 160 | 140 | 6 | 100 | 100 | 20 | 50 | 5 | 0.15 | 1.0 | 1.0 | 10 | | | | 13 |
| 2N5550 | TO-92 (72) | 180 | 160 | 6 | 50 | 120 | 60 | 250 | 1 | 0.25 | 1.2 | 50 | 10 | | | | 16 |
| 2N5551 | TO-92 (72) | 50 | 40 | 5 | 100 | 25 | 80 | 250 | 5 | 0.15 | 1.0 | 1.0 | 10 | | | | 16 |
| 2N5816 | TO-92 (77) | 60 | 30 | 5 | 10 | 50 | 25 | 200 | 2 | 0.75 | 1.2 | 500 | 15 | | | | 13 |
| TN2219 | TO-92+ (91) | 75 | 40 | 6 | 10 | 60 | 30 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | | | | 19 |
| TN2219A | TO-92+ (91) | 75 | 40 | 6 | 10 | 60 | 50 | 150 | 1 | 1.6 | 2.6 | 500 | | | | | 19 |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 1kHz; (2) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA; (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz; (4) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA; (5) I_C = 100 μA, V_{CE} = 4.5V, f = 15.7kHz; (6) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA; (7) I_C = 100 μA, V_{CE} = 5V, f = 15.7kHz; (8) I_C = 250 μA, V_{CE} = 5V, f = 10Hz-15.7kHz; (9) I_C = 3mA, V_{CE} = 10V, f = 1MHz; (10) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz.



MEDIUM POWER

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (nA) Max | I _{CB0} @ (nA) Max | h _{FE} Min | I _C @ (mA) Max | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|-----------------------------------|-----------------------------------|------------------------|--|------------------------------------|------------------------------------|---------------------------------|--------------------------------|--------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| | | | | | | | | | | | | | | | | | | |
| 2N699 | TO-39 | 120 | 60 | 5 | 2 | 60 | 40 | 120 | 5 | 1.3 | 150 | 20 | 50 | 50 | | | | 12 |
| 2N2017 | TO-39 | 60 | 60 | 8 | 10 μA | 30 | 20 | 1A 200 mA 10 mA | 2 | | 200 | | | | | | | 12 |
| 2N2102 | TO-39 | 120 | 65 | 7 | 2 | 60 | 10 | 1A 500 120 | 0.5 | 1.1 | 150 | 15 | 60 | 50 | | 6 | 1 | 12 |
| 2N2192 | TO-39 | 60 | 40 | 5 | 10 | 30 | 15 | 1A 500 150 100 300 75 10 15 | 0.35 | 1.3 | 150 | 10 | 50 | 50 | | | | 12 |
| 2N2192A | TO-39 | 60 | 40 | 5 | 10 | 30 | 35 | 500 10 70 150 10 300 150 10 75 10 15 | 0.25 | 1.3 | 150 | 20 | 50 | 50 | | | | 12 |
| 2N2193 | TO-39 | 80 | 50 | 8 | 10 | 60 | 15 | 1A 20 30 40 30 15 | 0.35 | 1.3 | 150 | 20 | 50 | 50 | | | | 12 |
| 2N2193A | TO-39 | 80 | 50 | 8 | 10 | 60 | 15 | 1A 20 30 40 30 15 | 0.25 | 1.3 | 150 | 20 | 50 | 50 | | | | 12 |
| 2N2195 | TO-39 | 45 | 25 | 5 | 100 | 30 | 20 | 150 10 150 10 15 | 0.35 | 1.3 | 150 | 20 | 50 | 50 | | | | 12 |
| 2N2195A | TO-39 | 45 | 25 | 5 | 100 | 30 | 20 | 150 10 150 10 15 | 0.25 | 1.3 | 150 | 20 | 50 | 50 | | | | 12 |



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | I _{CB0} (mA) @ V _{CB} (V) | h _{FE} Min | I _C @ V _{CE} & V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C @ V _{BE(sat)} (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|---------------------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---|---------------------|--|------------------------------|------------------------------|--|--------------------------|--------------------------|-------------------------|---------------------------|-------------|----------------|-------------|
| 2N2243 | TO-39 | 120 | 80 | 7 | 10 | 60 | 15 | 500 | 10 | 1.3 | 150 | 15 | 50 | 50 | | | | 12 |
| | | | | | | | 30 | 150 | | | | | | | | | | |
| | | | | | | | 40 | 120 | | | | | | | | | | |
| | | | | | | | 30 | 10 | | | | | | | | | | |
| | | | | | | | 15 | 0.1 | | | | | | | | | | |
| 2N2243A | TO-39 | 120 | 80 | 7 | 10 | 60 | 15 | 500 | 10 | 1.3 | 150 | 15 | 50 | 50 | | | | 12 |
| | | | | | | | 30 | 150 | | | | | | | | | | |
| | | | | | | | 40 | 120 | | | | | | | | | | |
| | | | | | | | 30 | 10 | | | | | | | | | | |
| | | | | | | | 15 | 0.1 | | | | | | | | | | |
| 2N2270 | TO-39 | 60 | 45 | 7 | 50 | 60 | 50 | 200 | 10 | 1.2 | 150 | 15 | 100 | 50 | | 6 | 1 | 12 |
| | | | | | | | 30 | 1 | | | | | | | | | | |
| 2N2657 | TO-39 | 80 | 50 | 8 | 100 | 60 | 15 | 5A | 6 | 1.5 | 1A | 150 | 20 | 200 | 1.5 | | 2 | 34 |
| | | | | | | | 40 | 120 | | 2.5 | 5A | | | | | | | |
| 2N2658 | TO-39 | 100 | 80 | 8 | 100 | 60 | 15 | 5A | 6 | 1.5 | 1A | | 20 | 200 | 1.5 | | 2 | 34 |
| | | | | | | | 40 | 120 | | 2.5 | 5A | | | | | | | |
| 2N2890 | TO-39 | 100 | 80 | 5 | 50 | 60 | 25 | 2A | 5 | 1.2 | 1A | 70 | 30 | 200 | 1.5 | | 3 | 34 |
| | | | | | | | 30 | 1A | 2 | | | | | | | | | |
| | | | | | | | 20 | 100 | 2 | 0.75 | 1.3 | 2A | | | | | | |
| 2N2891 | TO-39 | 100 | 80 | 5 | 50 | 60 | 40 | 2A | 5 | 1.2 | 1A | 70 | 30 | 200 | 1.5 | | 3 | 34 |
| | | | | | | | 50 | 150 | | | | | | | | | | |
| | | | | | | | 35 | 100 | 2 | | | | | | | | | |
| | | | | | | | 50 | 300 | 10 | 0.75 | 1.3 | 2A | | | | | | |
| 2N3019 | TO-39 | 140 | 80 | 7 | 10 | 90 | 15 | 1A | 10 | 1.1 | 150 | 12 | 100 | 50 | | 4 | 4 | 12 |
| | | | | | | | 50 | 500 | 10 | | | | | | | | | |
| | | | | | | | 100 | 300 | 10 | | | | | | | | | |
| | | | | | | | 90 | 10 | 10 | | | | | | | | | |
| | | | | | | | 50 | 0.1 | 10 | | | | | | | | | |
| 2N3019 J, JTX, JTXV | TO-39 | 140 | 80 | 7 | 10* | 90 | 15 | 1A | 10 | 1.1 | 150 | 12 | 100 | 400 | | 4 | 4 | 12 |
| | | | | | | | 50 | 200 | 10 | | | | | | | | | |
| | | | | | | | 100 | 300 | 10 | 0.5 | 500 | | | | | | | |
| | | | | | | | 90 | 10 | 10 | | | | | | | | | |
| | | | | | | | 50 | 200 | 0.1 | | | | | | | | | |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 15.7kHz. (2) I_C = 1A, V_{CC} = 20V, I_B¹ = I_B² = 100mA. (3) I_C = 1A, V_{CC} = 20V, I_B¹ = I_B² = 50mA. (4) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (5) I_C = 150mA, V_{CC} = 20V, I_B¹ = I_B² = 7.5mA. (6) I_C = 30 μA, V_{CE} = 10V, f = 1kHz. (7) I_C = 150mA, V_{EB} = 2V, I_B¹ = I_B² = 15mA. (8) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (9) I_C = 2A, V_{CC} = 40V, I_B¹ = I_B² = 200mA.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | ICES* ICBO (mA) @ V _{CB} Max | hFE Min | hFE Max | IC @ VCE & VCE (mA) (V) | VCE(sat) (V) Max | VBE(sat) (V) & Min | IC @ VCE(sat) (mA) Max | Cob (pF) Max | fT (MHz) Min | fT (MHz) @ IC (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------------------|---------|---------|-------------------------|------------------|--------------------|------------------------|--------------|--------------|------------------------|---------------------------|-------------|----------------|-------------|-----|----|
| 2N3020 | TO-39 | 140 | 80 | 7 | 10 | 90 | 15 | 1A | 10 | 0.2 | 1.1 | 150 | 12 | 80 | 50 | | | 12 | | |
| | | | | | | | 30 | 100 | 500 | 0.5 | 500 | | | | | | | | | |
| | | | | | | | 40 | 120 | 150 | | | | | | | | | | | |
| | | | | | | | 30 | 100 | 0.1 | | | | | | | | | | | |
| 2N3053 | TO-39 | 60 | 40 | 5 | 250 | 30 | 50 | 250 | 150 | 1.4 | 1.7 | 150 | 15 | 100 | 50 | | | 12 | | |
| | | | | | | | 25 | 150 | 2.5 | | | | | | | | | | | |
| 2N3107 | TO-39 | 100 | 60 | 7 | 10 | 60 | 40 | 500 | 10 | 0.25 | 1.1 | 150 | 20 | 70 | 50 | 1000 | 7 | 5/6 | 12 | |
| | | | | | | | 100 | 300 | 150 | 1.0 | 2.0 | 1A | | | | | | | | |
| | | | | | | | 35 | 0.1 | 10 | | | | | | | | | | | |
| 2N3108 | TO-39 | 100 | 60 | 7 | 10 | 60 | 25 | 500 | 10 | 0.25 | 1.1 | 150 | 20 | 60 | 50 | 600 | 7 | 5/6 | 12 | |
| | | | | | | | 40 | 120 | 150 | 1.0 | 2.0 | 1A | | | | | | | | |
| | | | | | | | 20 | 0.1 | 10 | | | | | | | | | | | |
| 2N3109 | TO-39 | 80 | 40 | 7 | 10* | 60 | 40 | 500 | 10 | 0.25 | 1.1 | 150 | 25 | 70 | 50 | 1000 | 7 | 5/6 | 12 | |
| | | | | | | | 100 | 300 | 150 | 1.0 | 2.0 | 1A | | | | | | | | |
| | | | | | | | 35 | 0.1 | 10 | | | | | | | | | | | |
| 2N3110 | TO-39 | 80 | 40 | 7 | 10* | 60 | 25 | 500 | 10 | 0.25 | 1.1 | 150 | 25 | 60 | 50 | 600 | 7 | 5/6 | 12 | |
| | | | | | | | 40 | 120 | 150 | 1.0 | 2.0 | 1A | | | | | | | | |
| | | | | | | | 20 | 0.1 | 10 | | | | | | | | | | | |
| 2N3114 | TO-39 | 150 | 150 | 5 | 10 | 100 | 30 | 120 | 30 | 1.0 | 0.9 | 50 | 9 | 40 | 30 | | | 08 | | |
| | | | | | | | 15 | 0.1 | 10 | | | | | | | | | | | |
| 2N3498 | TO-39 | 100 | 100 | 6 | 50 | 50 | 15 | 500 | 10 | 0.2 | 0.8 | 10 | 10 | 150 | 20 | | | 08 | | |
| | | | | | | | 40 | 120 | 150 | 0.25 | 0.9 | 50 | | | | | | | | |
| | | | | | | | 35 | 10 | 10 | 0.6 | 1.4 | 300 | | | | | | | | |
| | | | | | | | 25 | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 20 | 0.1 | 10 | | | | | | | | | | | |
| 2N3498 | TO-39 | 100 | 100 | 6 | 50 | 50 | 15 | 500 | 10 | 0.2 | 0.8 | 10 | 10 | 150 | 800 | 20 | 1150 | 16 | 7/8 | 08 |
| | | | | | | | 40 | 120 | 150 | 0.6 | 1.4 | 300 | | | | | | | | |
| | | | | | | | 35 | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 25 | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 20 | 0.1 | 10 | | | | | | | | | | | |
| 2N3498 | TO-39 | 100 | 100 | 6 | 50 | 50 | 15 | 500 | 10 | 0.2 | 0.8 | 10 | 10 | 150 | 800 | 20 | 1150 | 16 | 7/8 | 08 |
| | | | | | | | 40 | 120 | 150 | 0.6 | 1.4 | 300 | | | | | | | | |
| | | | | | | | 35 | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 25 | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 20 | 0.1 | 10 | | | | | | | | | | | |
| 2N3499 | TO-39 | 100 | 100 | 6 | 50 | 50 | 20 | 500 | 10 | 0.2 | 0.8 | 10 | 10 | 150 | 20 | | | 08 | | |
| | | | | | | | 100 | 300 | 150 | 0.25 | 0.9 | 50 | | | | | | | | |
| | | | | | | | 75 | 10 | 10 | 0.6 | 1.4 | 300 | | | | | | | | |
| | | | | | | | 50 | 1 | 10 | | | | | | | | | | | |
| | | | | | | | 35 | 0.1 | 10 | | | | | | | | | | | |



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CEO} (V) Max | V _{BE(sat)} (V) Min | V _{BE(sat)} (V) Max | V _{CE(sat)} (V) Min | V _{CE(sat)} (V) Max | V _{CE} (V) | I _C (mA) Min | I _C (mA) Max | h _{FE} Min | h _{FE} Max | I _{CES} * I _{CEO} (mA) Min | I _{CES} * I _{CEO} (mA) Max | V _{CB} (V) | I _C (mA) Min | I _C (mA) Max | V _{CE} (V) | V _{BE(sat)} (V) Min | V _{BE(sat)} (V) Max | I _C (mA) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | | | |
|------------------------|------------|---|--------------------------|------------------------------|------------------------------|------------------------------|------------------------------|---------------------|-------------------------|-------------------------|---------------------|---------------------|--|--|---------------------|-------------------------|-------------------------|---------------------|------------------------------|------------------------------|-------------------------|-------------------------|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|-----|----|----|
| 2N3499 J, JTX, JTXV | TO-39 | 100 | 100 | 6 | 50 | 10 | 10 | 10 | 500 | 10 | 20 | 300 | 150 | 150 | 50 | 10 | 10 | 10 | 0.2 | 0.8 | 1.4 | 10 | 20 | 10 | 150 | 800 | 20 | 1150 | 16 | 7/8 | 08 | |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | 75 |
| 2N3500 | TO-39 | 150 | 150 | 6 | 75 | 10 | 10 | 10 | 300 | 10 | 15 | 120 | 150 | 150 | 75 | 10 | 10 | 10 | 0.2 | 0.8 | 1.2 | 10 | 20 | 8 | 150 | 20 | | | | 0.8 | | |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | 35 | 10 |
| 2N3500 J, JTX, JTXV | TO-39 | 150 | 150 | 6 | 75 | 10 | 10 | 10 | 300 | 10 | 15 | 120 | 150 | 150 | 75 | 10 | 10 | 10 | 0.2 | 0.8 | 1.2 | 10 | 20 | 8 | 150 | 800 | 20 | 1150 | 16 | 7/8 | 08 | |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | 35 |
| 2N3501 | TO-39 | 150 | 150 | 6 | 75 | 10 | 10 | 10 | 300 | 10 | 20 | 300 | 150 | 150 | 75 | 10 | 10 | 10 | 0.2 | 0.8 | 1.2 | 10 | 20 | 8 | 150 | 20 | | | | 0.8 | | |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | 50 | 10 |
| 2N3501 J, JTX, JTXV | TO-39 | 150 | 150 | 6 | 75 | 10 | 10 | 10 | 300 | 10 | 20 | 300 | 150 | 150 | 75 | 10 | 10 | 10 | 0.2 | 0.8 | 1.2 | 10 | 20 | 8 | 150 | 800 | 20 | 1150 | 16 | 7/8 | 08 | |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | 50 |
| 2N3566 | TO-92 (72) | Same as PN3566, see page 1-39 for explanation | | | | | | | | | | | | | | | 14 | | | | | | | | | | | | | | | |
| 2N3567 | TO-92 (72) | Same as PN3567, see page 1-39 for explanation | | | | | | | | | | | | | | | 14 | | | | | | | | | | | | | | | |
| 2N3568 | TO-92 (72) | Same as PN3568, see page 1-39 for explanation | | | | | | | | | | | | | | | 12 | | | | | | | | | | | | | | | |
| 2N3569 | TO-92 (72) | Same as PN3569, see page 1-39 for explanation | | | | | | | | | | | | | | | 14 | | | | | | | | | | | | | | | |
| 2N3665 | TO-39 | 120 | 80 | 10 | 50 | 60 | 25 | 500 | 10 | 10 | 0.5 | 1.2 | 150 | 12 | 60 | 50 | 50 | 10 | 0.5 | 1.2 | 1.8 | 500 | | | | | | | | | | 12 |
| | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 15.7kHz. (2) I_C = 1A, V_{CE} = 20V, I_B¹ = I_B² = 100mA. (3) I_C = 1A, V_{CE} = 20V, I_B¹ = I_B² = 50mA. (4) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (5) I_C = 150mA, V_{CE} = 20V, I_B¹ = I_B² = 7.5mA. (6) I_C = 30 μA, V_{CE} = 10V, f = 1kHz. (7) I_C = 150mA, V_{EB} = 2V, I_B¹ = I_B² = 15mA. (8) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (9) I_C = 2A, V_{CE} = 40V, I_B¹ = I_B² = 200mA.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{CEO} (V) Min | V _{BE0} (V) Min | ICES* I _{CB0} (mA) @ (V) Max | h _{FE} Min | I _C @ (mA) Max | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min & Max | I _C @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) @ (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|------------------------|------------|-----------------------------|-----------------------------|-----------------------------|--|------------------------|------------------------------|---------------------------------|---------------------------------------|------------------------------|-----------------------------|-----------------------------|---------------------------------------|------------------------------|----------------|----------------|-------------|
| 2N3866 | TO-39 | 120 | 80 | 10 | 50 | 50 | 500 | 0.5 | 1.2 | 150 | 12 | 60 | 50 | | | | 12 |
| 2N3700 J, JTX, JTXV | TO-18 | 140 | 80 | 7 | 10 | 15 | 1A | 0.2 | 1.1 | 150 | 12 | 100 | 200 | | 4 | 4 | 12 |
| 2N3700 | TO-18 | 140 | 80 | 7 | 10 | 15 | 1A | 0.2 | 1.1 | 150 | 12 | 100 | 400 | | 4 | 4 | 12 |
| 2N3742 | TO-39 | 300 | 300 | 7 | 200 | 20 | 50 | 0.75 | 1.0 | 10 | 6 | 60 | 10 | | | | 48 |
| 2N3945 | TO-39 | 70 | 50 | 8 | 40 | 20 | 500 | 1.8 | 1.8 | 500 | 12 | 60 | 50 | | | | 12 |
| 2N4237 | TO-39 | | 40 | | 100 μA | 15 | 1A | 0.6 | 1.5 | 1A | 100 | 1 | 100 | | | | 14 |
| 2N4924 | TO-39 | 100 | 100 | 5 | 100 | 30 | 500 | 0.3 | | 500 | 10 | 10 | 500 | | | | 12 |
| 2N4926 | TO-39 | 200 | 200 | 7 | 100 | 20 | 50 | 0.25 | | 10 | 6 | 30 | 300 | | | | 48 |
| 2N4927 | TO-39 | 250 | 250 | 7 | 100 | 20 | 50 | 0.4 | | 50 | 6 | 30 | 300 | | | | 48 |
| 2N5148 | TO-39 | | 80 | | 1 μA* | 5 | 3A | 0.85 | 1.5 | 200 | 70 | 50 | 200 | | | | 34 |
| | | | | | | 15 | 2A | 0.46 | 1.2 | 100 | | | | | | | |
| | | | | | | 30 | 90 | | | | | | | | | | |
| | | | | | | 20 | 50 | | | | | | | | | | |



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | I _{CB0} @ (mA) Max | V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C @ (mA) & V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T @ (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|--------------------------|--------------------------|--------------------------|-----------------------------|-----------------------------|---------------------|---------------------|---------------------|---|------------------------------|------------------------------|---------------------------|--------------------------|--------------------------|---------------------------|---------------------------|-------------|----------------|-------------|
| 2N5150 | TO-39 | | 80 | | 1 μA* | 60 | 60 | 15 | 3A | 5 | 0.46 | 1.2 | 100 | 70 | 80 | 200 | | | | 34 |
| | | | | | | | | 30 | 2A | 5 | 5.0 | | 3A | | | | | | | |
| | | | | | | | | 70 | 200 1A | 5 | | | | | | | | | | |
| | | | | | | | | 50 | 50 | 5 | | | | | | | | | | |
| 2N5336 | TO-39 | | 80 | | 10 μA | 80 | 80 | 20 | 5A | 2 | 0.7 | 1.2 | 2A | | 30 | 500 | 2200 | | 9 | 34 |
| | | | | | | | | 30 | 120 2A | 2 | | | | | | | | | | |
| | | | | | | | | 30 | 500 | 2 | 1.2 | 1.8 | 5A | | 30 | 500 | 2200 | | 9 | 34 |
| 2N5338 | TO-39 | | 100 | | 10 μA | 100 | 100 | 20 | 5A | 2 | 0.7 | 1.2 | 2A | | 30 | 500 | 2200 | | | |
| | | | | | | | | 30 | 120 2A | 2 | | | | | | | | | | |
| | | | | | | | | 30 | 500 | 2 | 1.2 | 1.8 | 5A | | | | | | | |
| 40314 | TO-39 | | 40 | | 250 | 15 | 70 | 70 | 350 | 4 | 1.4 | | 150 | | | | | | | 12 |
| 40321 | TO-39 | | 300 | | 100 | 150 | 25 | 200 | 20 | 10 | | | | | | | | | | 48 |
| 92PE37A | TO-92+ (90) | | 45 | | 100 | 60 | 40 | 40 | 500 | 2 | 0.5 | | 500 | 30 | 50 | 200 | | | | 38 |
| | | | | | | | 40 | 250 | 2 | | | | | | | | | | | |
| | | | | | | | 25 | 50 | 2 | 1.0 | | | 1A | | | | | | | |
| 92PE37B | TO-92+ (90) | | 60 | | 100 | 80 | 40 | 40 | 500 | 2 | 0.5 | | 500 | 30 | 50 | 200 | | | | 38 |
| | | | | | | | 40 | 250 | 2 | | | | | | | | | | | |
| | | | | | | | 25 | 50 | 2 | 1.0 | | | 1A | | | | | | | |
| 92PE37C | TO-92+ (90) | | 80 | | 100 | 100 | 40 | 40 | 500 | 2 | 0.5 | | 500 | 30 | 50 | 200 | | | | 38 |
| | | | | | | | 40 | 250 | 2 | | | | | | | | | | | |
| | | | | | | | 25 | 50 | 2 | 1.0 | | | 1A | | | | | | | |
| 92PE487 | TO-92+ (90) | 160 | 160 | 7 | 50 | 100 | 30 | 30 | 30 | 10 | 1.0 | | 30 | 3 | | | | | | 48 |
| | | | | | | | 15 | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 15 | 1 | 10 | | | | | | | | | | | |
| 92PE488 | TO-92+ (90) | 250 | 250 | 7 | 50 | 200 | 30 | 30 | 30 | 10 | 1.0 | | 30 | 3 | | | | | | 48 |
| | | | | | | | 15 | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 15 | 1 | 10 | | | | | | | | | | | |
| 92PE489 | TO-92+ (90) | 300 | 300 | 7 | 50 | 200 | 30 | 30 | 30 | 10 | 1.0 | | 30 | 3 | | | | | | 48 |
| | | | | | | | 15 | 10 | 10 | | | | | | | | | | | |
| | | | | | | | 15 | 1 | 10 | | | | | | | | | | | |
| 92PU01 | TO-92+ (91) | | 30 | | 100 | 40 | 50 | 50 | 1A | 1 | 0.5 | | 1A | 30 | 1000 | 50 | | | | 37 |
| | | | | | | | 60 | 100 | 10 | 1 | | | | | | | | | | |
| | | | | | | | 55 | 10 | 1 | | | | | | | | | | | |
| 92PU01A | TO-92+ (91) | | 40 | | 100 | 50 | 50 | 50 | 1A | 1 | 0.5 | | 1A | 30 | 100 | 50 | | | | 37 |
| | | | | | | | 60 | 100 | 10 | 1 | | | | | | | | | | |
| | | | | | | | 55 | 10 | 1 | | | | | | | | | | | |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 15.7kHz. (2) I_C = 1A, V_{CC} = 20V, I_B¹ = I_B² = 100mA. (3) I_C = 1A, V_{CC} = 20V, I_B¹ = I_B² = 50mA. (4) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (5) I_C = 150mA, V_{CC} = 20V, I_B¹ = I_B² = 7.5mA. (6) I_C = 30 μA, V_{CE} = 10V, f = 1kHz. (7) I_C = 150mA, V_{EB} = 2V, I_B¹ = I_B² = 15mA. (8) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (9) I_C = 2A, V_{CC} = 40V, I_B¹ = I_B² = 200mA.





MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} [*] (mA) Max | V _{CB} (V) @ I _C | h _{FE} Min | I _C (mA) @ V _{CE} | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C (mA) @ V _{BE(sat)} | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) @ f _T Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|-----------------------------|-----------------------------|-----------------------------|---|---|---------------------|--|---------------------------------|---------------------------------|---|-----------------------------|-----------------------------|---|------------------------------|----------------|----------------|-------------|
| 92PU05 | TO-92+ (91) | | 60 | | 100 | 40 | 20 | 500 | 0.35 | | 250 | 30 | 50 | 200 | | | | 39 |
| 92PU06 | TO-92+ (91) | | 100 | | 100 | 80 | 20 | 500 | 0.35 | | 250 | 30 | 50 | 200 | | | | 39 |
| 92PU10 | TO-92+ (91) | | 300 | | 100 | 200 | 40 | 30 | 0.75 | | 30 | 3.5 | | | | | | 48 |
| 92PU100 | TO-92+ (91) | 100 | 80 | | 100 | 80 | 100 | 300 | 0.35 | | 350 | 20 | 50 | 100 | | | | 39 |
| 92PU391 | TO-92+ (91) | 200 | 200 | 6 | 100 | 160 | 40 | 10 | 2.0 | 2.0 | 20 | 2.5 | 50 | 10 | | | | 48 |
| 92PU392 | TO-92+ (91) | 250 | 250 | 6 | 100 | 200 | 40 | 10 | 2.0 | 2.0 | 20 | 2.5 | 50 | 10 | | | | 48 |
| 92PU393 | TO-92+ (91) | 300 | 300 | 6 | 100 | 260 | 40 | 10 | 2.0 | 2.0 | 20 | 2.5 | 50 | 10 | | | | 48 |
| D40D1 | TO-202 (35) | | 30 | | 100* | 45 | 10 | 1A | 0.5 | 1.5 | 500 | | | | | | | 38 |
| D40D2 | TO-202 (35) | | 30 | | 100* | 45 | 20 | 1A | 0.5 | 1.5 | 500 | | | | | | | 38 |
| D40D3 | TO-202 (35) | | 30 | | 100* | 45 | 10 | 1A | | 1.5 | 500 | | | | | | | 38 |
| D40D4 | TO-202 (35) | | 45 | | 100* | 60 | 10 | 1A | 0.5 | 1.5 | 500 | | | | | | | 38 |
| D40D5 | TO-202 (35) | | 45 | | 100* | 60 | 120 | 360 | 0.5 | 1.5 | 500 | | | | | | | 38 |
| D40D6 | TO-202 (35) | | 60 | | 100* | 75 | 10 | 1A | 1.0 | 1.5 | 500 | | | | | | | 38 |
| D40D8 | TO-202 (35) | | 60 | | 100* | 75 | 10 | 1A | 1.0 | 1.5 | 500 | | | | | | | 38 |
| D40D10 | TO-202 (35) | | 75 | | 100* | 90 | 10 | 1A | 1.0 | 1.5 | 500 | | | | | | | 38 |
| D40D11 | TO-202 (35) | | 75 | | 100* | 90 | 10 | 1A | 1.0 | 1.5 | 500 | | | | | | | 38 |
| D40D13 | TO-202 (35) | | 75 | | 100* | 90 | 50 | 150 | 1.0 | 1.5 | 500 | | | | | | | 38 |



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{BE0} (V) Min | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CE0} (mA) Max | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CE0} (mA) Max | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|--------------------------|--------------------------|--------------------------|--------------------------|---------------------------|--------------------------|--------------------------|---------------------------|------------------------------|------------------------------|-------------------------|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|
| D40D14 | TO-202 (35) | 75 | 90 | 100* | 90 | 100* | 120 | 360 | 100 | 2 | 1.0 | 1.5 | 500 | | | | | | 38 |
| D40E1 | TO-202 (35) | 30 | 40 | 100* | 40 | 100* | 10 | 100 | 2 | 2 | 1.0 | 1.3 | 1A | | | | | | 38 |
| D40E5 | TO-202 (35) | 60 | 70 | 100* | 70 | 100* | 10 | 100 | 2 | 2 | 1.0 | 1.3 | 1A | | | | | | 38 |
| D40E7 | TO-202 (35) | 80 | 90 | 100* | 90 | 100* | 10 | 100 | 2 | 2 | 1.0 | 1.3 | 1A | | | | | | 38 |
| D40N1 | TO-202 (35) | 250 | 250 | 10 μA | 250 | 10 μA | 20 | 40 | 10 | 10 | | | | 3 | 75 | 20 | | | 48 |
| D40N2 | TO-202 (35) | 250 | 250 | 10 μA | 250 | 10 μA | 30 | 40 | 10 | 10 | | | | 3 | 75 | 20 | | | 48 |
| D40N3 | TO-202 (35) | 300 | 300 | 10 μA | 300 | 10 μA | 30 | 90 | 20 | 10 | | | | 3 | 75 | 20 | | | 48 |
| D40N4 | TO-202 (35) | 300 | 300 | 10 μA | 300 | 10 μA | 30 | 180 | 20 | 10 | | | | 3 | 75 | 20 | | | 48 |
| D40N5 | TO-202 (35) | 375 | 300 | 10 μA | 300 | 10 μA | 15 | 40 | 10 | 10 | | | | 3 | 75 | 20 | | | 48 |
| D42C1 | TO-202 (36) | 30 | 30 | 1 μA* | 30 | 1 μA* | 25 | 200 | 1 | 1 | 0.5 | 1.3 | 1A | 30 | | | | | 37 |
| D42C2 | TO-202 (36) | 30 | 30 | 1 μA* | 30 | 1 μA* | 20 | 1A | 1 | 1 | 0.5 | 1.3 | 1A | 30 | | | | | 37 |
| D42C3 | TO-202 (36) | 30 | 30 | 1 μA* | 30 | 1 μA* | 20 | 2A | 1 | 1 | 0.5 | 1.3 | 1A | 30 | | | | | 37 |
| D42C4 | TO-202 (36) | 45 | 45 | 1 μA* | 45 | 1 μA* | 10 | 1A | 1 | 1 | 0.5 | 1.3 | 1A | 30 | | | | | 37 |
| D42C5 | TO-202 (36) | 45 | 45 | 1 μA* | 45 | 1 μA* | 20 | 1A | 1 | 1 | 0.5 | 1.3 | 1A | 30 | | | | | 37 |
| D42C6 | TO-202 (36) | 45 | 45 | 1 μA* | 45 | 1 μA* | 20 | 2A | 1 | 1 | 0.5 | 1.3 | 1A | 30 | | | | | 37 |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 15.7kHz. (2) I_C = 1A, V_{CC} = 20V, I_B¹ = I_B² = 100mA. (3) I_C = 1A, V_{CC} = 20V, I_B¹ = I_B² = 50mA. (4) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (5) I_C = 150mA, V_{CC} = 20V, I_B¹ = I_B² = 7.5mA. (6) I_C = 30 μA, V_{CE} = 10V, f = 1kHz. (7) I_C = 150mA, V_{EB} = 2V, I_B¹ = I_B² = 15mA. (8) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (9) I_C = 2A, V_{CC} = 40V, I_B¹ = I_B² = 200mA.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{BE0} (V) Min | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CE0} (mA) Max | V _{CE} (V) & V _{BE} (V) | h _{FE} Min | I _C (mA) Max | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|----------------|-----------------------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|--|------------------------|----------------------------|---------------------------------|---------------------------------|----------------------------|-----------------------------|-----------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| D42C7 | TO-202 (36) | 60 | 1.3 | 60 | 1.3 | 10 | 1 | 25 | 1A | 0.5 | 1.3 | 1A | 30 | | | | | | 38 |
| D42C8 | TO-202 (36) | 60 | 1.3 | 60 | 1.3 | 20 | 1 | 40 | 1A | 0.5 | 1.3 | 1A | 30 | | | | | | 38 |
| D42C9 | TO-202 (36) | 60 | 1.3 | 60 | 1.3 | 20 | 1 | 40 | 2A | 0.5 | 1.3 | 1A | 30 | | | | | | 38 |
| D42C10 | TO-202 (36) | 80 | 10.0 | 90 | 10.0 | 10 | 1 | 25 | 1A | 0.5 | 1.3 | 1A | 100 | | | | | | 38 |
| D42C11 | TO-202 (36) | 80 | 10.0 | 90 | 10.0 | 20 | 1 | 40 | 1A | 0.5 | 1.3 | 1A | 100 | | | | | | 38 |
| D42C12 | TO-202 (36) | 80 | 10.0 | 90 | 10.0 | 20 | 1 | 40 | 2A | 0.5 | 1.3 | 1A | 100 | | | | | | 38 |
| MPSA05 | TO-92 (72) | 60 | 4 | 60 | 4 | 50 | 1 | 50 | 100 | 0.25 | | 100 | | 100 | 100 | | | | 12 |
| MPSA06 | TO-92 (72) | 80 | 4 | 80 | 4 | 50 | 1 | 50 | 10 | 0.25 | | 100 | | 100 | 100 | | | | 12 |
| MPSA42 | TO-92 (72) | 300 | 8 | 200 | 8 | 40 | 10 | 40 | 30 | 0.5 | 0.9 | 20 | 3 | 50 | 10 | | | | 48 |
| MPSA43 | TO-92 (72) | 200 | 6 | 160 | 6 | 50 | 10 | 25 | 30 | 0.4 | 0.9 | 20 | 4 | 50 | 10 | | | | 48 |
| MPS6560 | TO-92 (72) | 25 | 5 | 20 | 5 | 50 | 1 | 35 | 500 | 0.5 | | 500 | 30 | 60 | 10 | | | | 14 |
| MPS6561 | TO-92 (72) | 20 | 5 | 20 | 5 | 50 | 1 | 35 | 100 | 0.5 | | 350 | 30 | 60 | 10 | | | | 14 |
| MRF8004 | TO-39 | 60 | 3 | 50 | 3 | 10 | 2 | | 400 | | | | 70 | | | | | | 35 |
| NCB514 | TO-39 | 60 | 4 | 30 | 4 | 60 | 1 | | 20 | 0.15 | | 100 | 10 | 125 | 20 | | | | 14 |
| NCB835 | TO-39 | 65 | 3 | 40 | 3 | 30 | 1 | | 150 | 0.5 | | 1A | 35 | 120 | 100 | | | | 35 |
| NCBV14 | TO-202 (36) | 60 | 4 | 30 | 4 | 75 | 1 | | 50 | 0.4 | | 500 | 100 | 125 | 50 | | | | 14 |
| NCBX14 | TO-92+ (91) | 60 | 4 | 30 | 4 | 60 | 1 | | 20 | 0.15 | | 100 | 10 | 125 | 20 | | | | 14 |
| NSD102 | TO-202 (36) | 60 | 5 | 60 | 5 | 25 | 5 | 40 | 1A | 0.2 | 0.9 | 100 | 30 | 60 | 50 | | | | 37 |
| | | | | | | 50 | 5 | 40 | 500 | 0.4 | 1.2 | 500 | | | | | | | |
| | | | | | | 40 | 5 | | 10 | | | | | | | | | | |



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CE0} (V) Min | V _{CE0} (V) Max | I _{CE0} (mA) Max | V _{CE0} (V) Max | I _{CE0} (mA) Max | V _{CE0} (V) Max | h _{FE} Min | h _{FE} Max | I _C (mA) Max | V _{CE} (V) Max | V _{BE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|--------------------------|--------------------------|--------------------------|---------------------------|--------------------------|---------------------------|--------------------------|---------------------|---------------------|-------------------------|-------------------------|------------------------------|------------------------------|-------------------------|--------------------------|--------------------------|--------------------------|-------------------------|---------------------------|-------------|----------------|-------------|
| NSD103 | TO-202 (35) | 60 | 45 | 5 | 100 | 60 | 30 | 5 | 30 | 500 | 1A | 0.2 | 0.9 | 1.2 | 100 | 30 | 60 | 50 | | | | | 37 |
| NSD104 | TO-202 (35) | 100 | 80 | 7 | 100 | 100 | 10 | 5 | 10 | 150 | 1A | 0.2 | 0.9 | 1.2 | 100 | 30 | 60 | 50 | | | | | 39 |
| NSD105 | TO-202 (35) | 100 | 80 | 7 | 100 | 100 | 10 | 5 | 120 | 360 | 1A | 0.2 | 0.9 | 1.2 | 100 | 30 | 60 | 50 | | | | | 39 |
| NSD106 | TO-202 (35) | 140 | 100 | 7 | 100 | 140 | 25 | 5 | 50 | 150 | 500 | 0.2 | 0.9 | 1.2 | 100 | 30 | 60 | 50 | | | | | 39 |
| NSD123 | TO-202 (35) | 120 | 120 | 6 | 50 | 50 | 15 | 10 | 30 | 300 | 10 | 0.4 | 1.2 | 1.50 | 10 | | | | | | | | 08 |
| NSD131 | TO-202 (35) | 250 | 250 | 7 | 100 | 150 | 30 | 10 | 15 | 10 | 10 | 1.0 | 0.85 | 2.0 | 3 | | | | | | | | 48 |
| NSD132 | TO-202 (35) | 250 | 250 | 7 | 100 | 150 | 60 | 10 | 30 | 180 | 30 | 1.0 | 0.85 | 2.0 | 3 | | | | | | | | 48 |
| NSD133 | TO-202 (35) | 300 | 300 | 7 | 100 | 150 | 15 | 10 | 15 | 1 | 10 | 1.0 | 0.85 | 2.0 | 3 | | | | | | | | 48 |
| NSD134 | TO-202 (35) | 300 | 300 | 7 | 100 | 150 | 60 | 10 | 30 | 180 | 30 | 1.0 | 0.85 | 2.0 | 3 | | | | | | | | 48 |
| NSD135 | TO-202 (35) | 375 | 375 | 7 | 100 | 150 | 30 | 10 | 30 | 30 | 10 | 1.0 | 0.85 | 2.0 | 3 | | | | | | | | 48 |
| NSD457 | TO-202 (35) | 160 | 160 | 5 | 50 | 100 | 25 | 10 | 15 | 1 | 10 | 1.0 | 0.85 | 2.0 | 30 | | | | | | | | 48 |
| NSD458 | TO-202 (35) | 250 | 250 | 5 | 50 | 200 | 25 | 10 | 30 | 30 | 10 | 1.0 | 0.85 | 2.0 | 30 | | | | | | | | 48 |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 15.7kHz. (2) I_C = 1A, V_{CE} = 20V, I_B¹ = I_B² = 100mA. (3) I_C = 1A, V_{CE} = 20V, I_B¹ = I_B² = 50mA. (4) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (5) I_C = 150mA, V_{CE} = 20V, I_B¹ = I_B² = 7.5mA. (6) I_C = 30 μA, V_{CE} = 10V, f = 1kHz. (7) I_C = 150mA, V_{BE} = 2V, I_B¹ = I_B² = 15mA. (8) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (9) I_C = 2A, V_{CE} = 40V, I_B¹ = I_B² = 200mA.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CB0} (mA) Max | I _{CB0} (mA) Max | I _{CB0} (mA) Max | h _{FE} @ I _C (mA) Min Max | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|------------------------------|------------------------------|--|---------------------------------|-------------------------------------|----------------------------|-----------------------------|---------------------------------|------------------------------|----------------|----------------|-------------|
| | | | | | | | | | | | | | | | | | |
| NSD459 | TO-202 (35) | 300 | 300 | 5 | 50 | 250 | 30 | 25 | 1.0 | | 30 | | | | | | 48 |
| NSD3439 | TO-202 (35) | | 350 | | 20 | 300 | 20 | 40 | 0.5 | 1.3 | 50 | 20 | 15 | | | | 36 |
| NSD3440 | TO-202 (35) | | 250 | | 500 | 200 | 40 | 40 | 0.5 | 1.3 | 50 | 20 | 15 | | | | 36 |
| NSD6178 | TO-202 (35) | | 75 | | 500 | 80 | 10 | 40 | 0.5 | 1.2 | 500 | 30 | 50 | | | | 38 |
| NSD6179 | TO-202 (35) | | 50 | | 500 | 60 | 10 | 40 | 0.5 | 1.2 | 500 | 30 | 50 | | | | 38 |
| NSDU01 | TO-202 (35) | 40 | 30 | 5 | 100 | 30 | 50 | 60 | 0.5 | 1.2 | 1A | 30 | 50 | | | | 37 |
| NSDU01A | TO-202 (35) | 50 | 40 | 5 | 100 | 40 | 50 | 60 | 0.5 | 1.2 | 1A | 30 | 50 | | | | 37 |
| NSDU02 | TO-202 (35) | 60 | 40 | 5 | 100 | 40 | 30 | 50 | 0.4 | 1.3 | 150 | 20 | 50 | | | | 37 |
| NSDU05 | TO-202 (35) | 60 | 60 | 4 | 100 | 60 | 20 | 50 | 0.35 | | 250 | 50 | 200 | | | | 38 |
| NSDU06 | TO-202 (35) | 80 | 80 | 4 | 100 | 80 | 20 | 50 | 0.35 | | 250 | 50 | 200 | | | | 39 |
| NSDU07 | TO-202 (35) | 100 | 100 | 4 | 100 | 100 | 20 | 50 | 0.35 | | 250 | 50 | 200 | | | | 39 |
| NSDU10 | TO-202 (35) | 300 | 300 | 8 | 200 | 200 | 40 | 40 | 1.5 | 0.8 | 20 | 3 | 60 | | | | 48 |
| NSE180 | TO-202 (36) | | 40 | | 100 | 60 | 12 | 30 | 0.9 | 1.5 | 1.5A | | 50 | | | | 37 |
| NSE181 | TO-202 (36) | | 60 | | 100 | 80 | 12 | 30 | 0.9 | 1.5 | 1.5A | | 50 | | | | 38 |



MEDIUM POWER (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICES* (nCBO) (nA) Max | ICBO @ VCB (V) (nA) Max | hFE Min | hFE Max | IC (mA) & VCE (V) | VCE(sat) (V) Max | VBE(sat) (V) Min | IC (mA) @ VBE(sat) Max | Cob (pF) Max | fT (MHz) Min | fT (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|--------------|--------------|--------------|-----------------------|-------------------------|---------|---------|-------------------|------------------|------------------|------------------------|--------------|--------------|--------------|---------------------------|-------------|----------------|-------------|
| NSE457 | TO-202 (36) | 160 | 160 | 5 | 50 | 100 | 25 | 30 | 10 | 1.0 | | 30 | | | | | | | 48 |
| NSE458 | TO-202 (36) | 250 | 250 | 5 | 50 | 200 | 25 | 30 | 10 | 1.0 | | 30 | | | | | | | 48 |
| NSE459 | TO-202 (36) | 300 | 300 | 5 | 50 | 250 | 25 | 30 | 10 | 1.0 | | 30 | | | | | | | 48 |
| PN3566 | TO-92 (72) | 40 | 30 | 5 | 50 | 20 | 150 | 600 | 10 | 1.0 | | 100 | 25 | 4 | 100 | 30 | | | 14 |
| PN3567 | TO-92 (72) | 80 | 40 | 5 | 50 | 40 | 40 | 120 | 150 | 0.25 | | 150 | 20 | 60 | 600 | 50 | | | 14 |
| PN3568 | TO-92 (72) | 80 | 60 | 5 | 50 | 40 | 40 | 120 | 150 | 0.25 | | 150 | 20 | 60 | 600 | 50 | | | 12 |
| PN3569 | TO-92 (72) | 80 | 40 | 5 | 50 | 40 | 100 | 300 | 150 | 0.25 | | 150 | 20 | 60 | 600 | 50 | | | 14 |
| PN7055 | TO-92 (72) | 220 | 220 | 7 | 100 | 150 | 40 | 30 | 20 | 1.0 | 0.85 | 20 | 3.5 | 50 | 15 | | | | 48 |
| SE7055 | TO-39 | 220 | 220 | 7 | 100 | 150 | 40 | 30 | 20 | 1.0 | 0.85 | 20 | 3.5 | 50 | 15 | | | | 48 |
| SE7056 | TO-39 | 300 | 300 | 7 | 100 | 200 | 40 | 30 | 20 | 1.0 | 0.85 | 20 | 3 | 50 | 15 | | | | 48 |
| SV7056 | TO-202 (35) | 300 | 300 | 7 | 100 | 200 | 40 | 30 | 20 | 1.0 | 0.85 | 20 | 3 | 50 | 15 | | | | 48 |
| TN2102 | TO-92+ (91) | 120 | 65 | 7 | 10 | 60 | 10 | 1A | 10 | 0.5 | 1.1 | 150 | 15 | 60 | 50 | | | | 12 |

TEST CONDITIONS:

(1) IC = 300 μA, VCE = 10V, f = 15.7kHz. (2) IC = 1A, VCC = 20V, IB¹ = IB² = 100mA. (3) IC = 1A, VCC = 20V, IB¹ = IB² = 50mA. (4) IC = 100 μA, VCE = 10V, f = 1kHz. (5) IC = 150mA, VCC = 20V, IB¹ = IB² = 7.5mA. (6) IC = 30 μA, VCE = 10V, f = 1kHz. (7) IC = 150mA, VEB = 2V, IB¹ = IB² = 15mA. (8) IC = 500 μA, VCE = 10V, f = 1kHz. (9) IC = 2A, VCC = 40V, IB¹ = IB² = 200mA.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | I _{CB0} (mA) @ V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C (mA) & V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C (mA) @ V _{BE(sat)} (V) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|--------------------------|--------------------------|--------------------------|---------------------------|---|---------------------|---------------------|---|------------------------------|------------------------------|--|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|
| TN3019 | TO-92+ (91) | 140 | 80 | 7 | 10 | 90 | 15 | 50 | 1A, 10, 10 | 0.2 | 1.1 | 150 | 12 | 100 | 50 | | 4 | 1 | 12 |
| TN3020 | TO-92+ (91) | 140 | 80 | 7 | 10 | 90 | 15 | 30, 40, 40, 30 | 1A, 10, 150, 10, 150, 10, 10, 10 | 0.2 | 1.1 | 150 | 12 | 80 | 50 | | | | 12 |
| TN3053 | TO-92+ (91) | 60 | 40 | 5 | 250 | 30 | 50 | 25 | 250, 150, 150 | 1.4 | 1.7 | 150 | 15 | 100 | 50 | | | | 12 |

TEST CONDITIONS:

(1) I_C = 300 μA, V_{CE} = 10V, f = 15.7kHz. (2) I_C = 1A, V_{CC} = 20V, I_{B1} = I_{B2} = 100mA. (3) I_C = 1A, V_{CC} = 20V, I_{B1} = I_{B2} = 50mA. (4) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (5) I_C = 150mA, V_{CC} = 20V, I_{B1} = I_{B2} = 7.5mA. (6) I_C = 30 μA, V_{CE} = 10V, f = 1kHz. (7) I_C = 150mA, V_{EB} = 2V, I_{B1} = I_{B2} = 15mA. (8) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (9) I_C = 2A, V_{CC} = 40V, I_{B1} = I_{B2} = 200mA.



POWER

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (μA) Max | I _{CB0} (μA) @ V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C (A) & V _{CE} (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C (A) @ V _{BE(sat)} (V) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | Process |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---|---------------------|---------------------|--|------------------------------|------------------------------|---|--------------------------|--------------------------|--------------------------|---------|
| 2N4921 | TO-126 | | 40 | | 100 | 40 | 10 | 20 | 1, 1, 0.5, 1, 0.05, 1 | 0.6 | 1.3 | 1 | 100 | 300 | 0.25 | 2C |
| 2N4922 | TO-126 | | 60 | | 100 | 60 | 10 | 20 | 1, 1, 0.5, 1, 0.05, 1 | 0.6 | 1.3 | 1 | 100 | 300 | 0.25 | 2C |
| 2N4923 | TO-126 | | 80 | | 100 | 80 | 10 | 20 | 1, 1, 0.5, 1, 0.05, 1 | 0.6 | 1.3 | 1 | 100 | 300 | 0.25 | 2C |
| 2N5190 | TO-126 | | 40 | | 100 | 40 | 10 | 25 | 4, 2, 1.5, 2, 0.05, 1 | 0.6 | 1.5 | 1.5 | | 2 | 1 | 2E |
| 2N5191 | TO-126 | | 60 | | 100 | 60 | 10 | 25 | 4, 2, 1.5, 2, 0.05, 1 | 0.6 | 1.5 | 1.5 | | 2 | 1 | 2E |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CEX} [*] I _{CEB1} [†] I _{CB0} (μA) Max | V _{CB} (V) @ I _C & V _{CE} (V) | h _{FE} Min Max @ I _C (A) | V _{CE(sat)} (V) Max & V _{BE(sat)} (V) Min Max @ I _C (A) | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (A) @ Max | Process |
|----------|-------------------------|--------------------------|--------------------------|--------------------------|--|--|--|--|--------------------------|------------------------------|--------------------------|---------|
| 2N5192 | TO-126 | | 80 | | 100 | 80 | 7 20 80 | 0.6 1.4 | | 2 | 1 | 2F |
| 2N5293 | Lead Bend + Clip TO-220 | | 10 | | 500† | 50 (100Ω) | 30 120 | 1.0 | | 2 | 0.2 | 4E |
| 2N5294 | TO-220 | | 70 | | 500† | 50 (100Ω) | 30 120 | 1.0 | | 2 | 0.2 | 4E |
| 2N5295 | Lead Bend + Clip TO-220 | | 40 | | 100 | 35 | 30 120 | 1.0 | | 2 | 0.2 | 4E |
| 2N5296 | TO-220 | | 40 | | 100 | 35 | 30 120 | 1.0 | | 2 | 0.2 | 4E |
| 2N5297 | Lead Bend + Clip TO-220 | | 60 | | 500† | 50 (100Ω) | 20 80 | 1.0 | | 2 | 0.2 | 4E |
| 2N5298 | TO-220 | | 60 | | 500† | 50 (100Ω) | 20 80 | 1.0 | | 2 | 0.2 | 4E |
| 2N5490 | TO-220 | | 40 | | 5 mA* | 55 | 5 20 100 | 2 | | | 6.5 | 4E |
| 2N5491 | Lead Form + Clip TO-220 | | 40 | | 5 mA* | 55 | 5 20 100 | 2 | | | 6.5 | 4E |
| 2N5492 | TO-220 | | 55 | | 1 mA* | 70 | 5 20 100 | 2 | | | 6.2 | 4E |
| 2N5493 | Lead Form + Clip TO-220 | | 55 | | 1 mA* | 70 | 5 20 100 | 2 | | | 6.5 | 4E |
| 2N5494 | TO-220 | | 40 | | 1 mA* | 55 | 5 20 100 | 2 | | | 6.5 | 4E |
| 2N5495 | Lead Form + Clip TO-220 | | 40 | | 1 mA* | 55 | 5 20 100 | 2 | | | 6.5 | 4E |
| 2N5496 | TO-220 | | 70 | | 1 mA* | 85 | 5 20 100 | 2 | | | 7 | 4E |
| 2N5497 | Lead Form + Clip TO-220 | | 70 | | 1 mA* | 85 | 5 20 100 | 2 | | | 7 | 4E |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CEX} [*] I _{CEBT} I _{CB0} (μA) Max | V _{CB} (V) @ I _C & V _{CE} (V) | h _{FE} Min Max @ I _C (A) | V _{CE(sat)} (V) Max & V _{BE(sat)} (V) Min | I _C (A) @ I _C (A) | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (A) @ I _C (A) | Process |
|----------|----------------------------|-----------------------------|-----------------------------|-----------------------------|--|---|--|---|--|-----------------------------|------------------------------------|--|---------|
| 2N5655 | TO-126 | | 250 | | 10 | 275 | 5 15 30 25 | 1.0 2.5 10 | 0.1 0.25 0.5 | 25 | 10 | 0.05 | 36 |
| 2N5656 | TO-126 | | 300 | | 10 | 350 | 5 15 30 25 | 1.0 2.5 10 | 0.1 0.25 0.5 | 25 | 10 | 0.05 | 36 |
| 2N5657 | TO-126 | | 350 | | 10 | 375 | 5 15 30 25 | 1.0 2.5 10 | 0.1 0.25 0.5 | 25 | 10 | 0.05 | 36 |
| 2N6037 | TO-126 | | 40 | | 500 | 40 | 100 750 500 | 2.0 3.0 | 4.0 2 4 | 200 | 25 | 0.75 | 2J |
| 2N6038 | TO-126 | | 60 | | 500 | 60 | 100 750 500 | 2.0 3.0 | 4.0 2 4 | 200 | 25 | 0.75 | 2J |
| 2N6039 | TO-126 | | 80 | | 500 | 80 | 100 750 500 | 2.0 3.0 | 4.0 2 4 | 200 | 25 | 0.75 | 2J |
| 2N6098 | Lead Bend + Clip TO-220 | | 60 | | 2 mA* | 65 | 5 20 | 2.5 | 10 | | | 10 | 4A |
| 2N6099 | TO-220 | | 60 | | 2 mA* | 65 | 5 20 | 2.5 | 10 | | | 10 | 4A |
| 2N6100 | Lead Bend + Clip TO-220 | | 70 | | 2 mA* | 75 | 5 20 | 2.5 | 10 | | | 10 | 4A |
| 2N6101 | TO-220 | | 70 | | 2 mA* | 75 | 5 20 | 2.5 | 10 | | | 10 | 4A |
| 2N6102 | Lead Bend + Clip TO-220 | | 40 | | 2 mA* | 40 | 5 15 | 2.5 | 16 | | | 16 | 4A |
| 2N6103 | TO-220 | | 40 | | 2 mA* | 40 | 5 15 | 2.5 | 16 | | | 16 | 4A |
| 2N6121 | TO-220 | | 45 | | 100 | 45 | 10 25 | 0.6 1.4 | 1.5 4 | | 2.5 | 1 | 4E |



POWER (Continued)

| Type No. | Case Style | V _{CSO} (V) Min | V _{CEO} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CEX*} I _{CEBT} I _{CSO} (μA) Max | V _{CB} (V) | h _{FE} Min | I _C & V _{CE} (V) Max | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | I _C (A) Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (A) Max | Process |
|----------|-------------------------|--------------------------|--------------------------|--------------------------|--------------------------|---|---------------------|---------------------|--|------------------------------|------------------------------|------------------------|--------------------------|--------------------------|------------------------|---------|
| 2N6122 | TO-220 | | CC | | | 100 | 50 | 10 25 | 4 1.5 2 | 0.6 1.4 | | 1.5 4 | | 2.5 | 1 | 4E |
| 2N6123 | TO-220 | | 80 | | | 100 | 80 | 7 20 | 4 1.5 2 | 0.6 1.4 | | 1.5 4 | | 2.5 | 1 | 4E |
| 2N6128 | TO-220 | | 40 | | | 100 | 40 | 7 20 | 7 2.5 4 | 1.4 | | 7 | | | | 4E |
| 2N6130 | TO-220 | | 60 | | | 100 | 60 | 7 20 | 7 2.5 4 | 1.4 | | 7 | | | | 4E |
| 2N6131 | TO-220 | | 80 | | | 100 | 80 | 5 20 | 7 4 2.5 4 | 2.0 | | 7 | | | | 4E |
| 2N6288 | TO-220 | | 30 | | | 100* | 37.5 | 5 30 | 6.5 3 4 2.0 | 1.0 2.0 | | 3 6.5 | 250 | 4 | 0.5 | 4E |
| 2N6289 | Lead Bend + Clip TO-220 | | 30 | | | 100* | 37.5 | 5 30 | 6.5 3 4 2.0 | 1.0 2.0 | | 3 6.5 | 250 | 4 | 0.5 | 4E |
| 2N6290 | TO-220 | | 50 | | | 100* | 56 | 5 30 | 6.5 3 4 2.0 | 1.0 2.0 | | 2.5 6.5 | 250 | 4 | 0.5 | 4E |
| 2N6291 | Lead Bend + Clip TO-220 | | 50 | | | 100* | 50 | 5 3 | 6.5 3 4 2.0 | 1.0 2.0 | | 2.5 6.5 | 250 | 4 | 0.5 | 4E |
| 2N6292 | TO-220 | | 70 | | | 100* | 75 | 5 30 | 6.5 2 4 2.0 | 1.0 2.0 | | 2 6.5 | 250 | 4 | 0.5 | 4E |
| 2N6293 | Lead Bend + Clip TO-220 | | 70 | | | 100* | 75 | 5 30 | 6.5 2 4 2.0 | 1.0 2.0 | | 2 6.5 | 250 | 4 | 0.5 | 4E |
| 2N6386 | TO-220 | | 40 | | | 300* | 40 | 100 1000 | 8 20,000 3 3 | 2.0 3.0 | | 3 8 | 200 | 20 | 1 | 4J |
| 2N6486 | TO-220 | | 40 | | | 500* | 35 (100Ω) | 5 20 | 15 5 4 3.5 | 1.3 3.5 | | 5 15 | | | | 4A |
| 2N6487 | TO-220 | | 60 | | | 500* | 55 (100Ω) | 5 20 | 15 5 4 3.5 | 1.3 3.5 | | 5 15 | | | | 4A |
| 2N6488 | TO-220 | | 80 | | | 500* | 75 (100Ω) | 5 20 | 15 5 4 3.5 | 1.3 3.5 | | 5 15 | | | | 4A |
| D44C1 | TO-220 | | 30 | | | 10* | 40 | 10 25 | 1 0.2 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 4F |
| D44C2 | TO-220 | | 30 | | | 10* | 40 | 20 40 | 1 0.2 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 4F |



POWER (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{EB0} (V) Min | ICEX* IC _{EBT} @ IC _{BO} (μA) Max | h _{FE} Min | IC @ Max (A) | V _{CE} (V) Min | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | IC @ Max (A) | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | IC @ Max (A) | Process |
|----------|------------|-----------------------------|-----------------------------|--|------------------------|-----------------|----------------------------|---------------------------------|---------------------------------|-----------------|-----------------------------|-----------------------------|-----------------------------|-----------------|---------|
| D44C3 | TO-220 | 30 | | 10* | 20 40 | 2 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4E |
| D44C4 | TO-220 | 45 | | 10* | 10 25 | 1 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4F |
| D44C5 | TO-220 | 45 | | 10* | 20 40 | 120 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4F |
| D44C6 | TO-220 | 45 | | 10* | 20 40 | 2 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4E |
| D44C7 | TO-220 | 60 | | 10* | 10 25 | 1 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4F |
| D44C8 | TO-220 | 60 | | 10* | 20 40 | 1 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4F |
| D44C9 | TO-220 | 60 | | 10* | 20 40 | 2 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4E |
| D44C10 | TO-220 | 80 | | 10* | 10 25 | 1 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4F |
| D44C11 | TO-220 | 80 | | 10* | 20 40 | 120 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4E |
| D44C12 | TO-220 | 80 | | 10* | 20 40 | 2 0.2 | 1 1 | 0.5 | 1.3 | 1 | 100 | 3 | 0.02 | 0.02 | 4E |
| D44H1 | TO-220 | 30 | | 10 | 20 35 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |
| D44H2 | TO-220 | 30 | | 10 | 40 60 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |
| D44H4 | TO-220 | 45 | | 10 | 20 35 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |
| D44H5 | TO-220 | 45 | | 10 | 40 60 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |
| D44H7 | TO-220 | 60 | | 10 | 20 35 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |
| D44H8 | TO-220 | 60 | | 10 | 40 60 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |
| D44H10 | TO-220 | 80 | | 10 | 20 35 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |
| D44H11 | TO-220 | 80 | | 10 | 40 60 | 4 2 | 1 1 | 1.0 | 1.5 | 8 | | | | | 4A |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CEX} [*] I _{CEB} [†] I _{CB0} (μA) Max | V _{CB} (V) | h _{FE} Min Max | I _C & V _{CE} (V) | V _{CE(sat)} & I _C (A) Max | V _{BE(sat)} (V) Min Max | I _C (A) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (A) Max | Process |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|--|---------------------|-------------------------------|--------------------------------------|--|--|---------------------------|-----------------------------|------------------------------------|---------------------------|---------|
| MJE180 | TO-126 | | 40 | | 0.1 | 60 | 12 30 50 | 1.5 0.5 0.1 | 0.3 0.9 1.7 | | 0.500 1.5 3 | 30 | 50 50 | 0.05 0.1 | 37 |
| MJE181 | TO-126 | | 60 | | 0.1 | 80 | 12 30 50 | 1.5 0.5 0.1 | 0.3 0.9 1.7 | | 0.500 1.5 3 | 30 | 50 | 0.1 | 38 |
| MJE182 | TO-126 | | 80 | | 0.1 | 100 | 12 30 50 | 1.5 0.5 0.1 | 0.3 0.9 1.7 | | 0.500 1.5 3 | 30 | 50 | 0.05 | 39 |
| MJE340 | TO-126 | | 300 | | 100 | 300 | 30 | 0.05 | 1.0 | | 0.05 | 15 | 15 | 0.05 | 36 |
| MJE341 | TO-126 | | 150 | | 300 | 175 | 25 | 0.05 | 2.3 | | 0.15 | 15 | 15 | 0.05 | 36 |
| MJE344 | TO-126 | | 200 | | 100 | 200 | 30 | 0.05 | 1.0 | | 0.05 | 15 | 15 | 0.05 | 36 |
| MJE520 | TO-126 | | 30 | | 100 | 30 | 25 | 1 | | | | | | | 2C |
| MJE521 | TO-126 | | 40 | | 100 | 40 | 40 | 1 | | | | | | | 2C |
| MJE720 | TO-126 | | 40 | | 100* | 40 | 8 20 40 | 1 0.5 0.15 | 0.15 0.4 1.0 | | 0.15 0.5 1.5 | | | | 37 |
| MJE721 | TO-126 | | 60 | | 100* | 60 | 8 20 40 | 1 0.5 0.15 | 0.15 0.4 1.0 | | 0.15 0.5 1.5 | | | | 38 |
| MJE722 | TO-126 | | 80 | | 100* | 80 | 8 20 40 | 1 0.5 0.15 | 0.15 0.4 1.0 | | 0.15 0.5 1.5 | | | | 39 |
| MJE800 | TO-126 | | 60 | | 200 | 60 | 750 | 1.5 | 2.5 | | 1.5 | | | | 2J |
| MJE801 | TO-126 | | 60 | | 200 | 60 | 750 | 2 | 2.8 | | 2 | | | | 2J |
| MJE802 | TO-126 | | 80 | | 200 | 80 | 750 | 1.5 | 2.5 | | 1.5 | | | | 2J |
| MJE803 | TO-126 | | 80 | | 200 | 80 | 750 | 2 | 2.8 | | 2 | | | | 2J |
| MJE3439 | TO-126 | | 350 | | 20 | 360 | 40 30 | 0.02 0.002 | 0.5 | 1.3 | 0.05 | 10 | 15 | 0.01 | 36 |
| MJE3440 | TO-126 | | 250 | | 20 | 250 | 40 30 | 0.02 0.002 | 0.5 | 1.3 | 0.05 | 10 | 15 | 0.01 | 36 |
| MRF472 | TO-126 | | 30 | 3 | 10 | 50 | 10 | 0.4 | | | | 70 | | | 35 |
| NCBJ14 | TO-126 | 60 | 40 | 4 | 0.1 | 30 | 75 | 0.05 | 0.4 | | 0.5 | 10 | 125 | 0.05 | 14 |
| NCBJ35 | TO-126 | | 65 | 3 | 10 | 40 | 30 | 0.1 | 0.5 | | 1 | 35 | 120 | 0.1 | 35 |
| NCBW35 | TO-220 | | 65 | 3 | 10 | 40 | 30 | 0.1 | 0.5 | | 1 | 35 | 120 | 0.1 | 35 |

NPN Transistors



POWER (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICEX* ICBE† ICBO (μA) Max | VCB (V) | hFE Min | hFE Max | IC (A) @ VCE (V) | VCE(sat) (V) Max & VBE(sat) (V) Min | IC (A) @ VBE(sat) (V) Max | Cob (pF) Max | fT (MHz) Min | fT (MHz) Max | Process |
|----------|------------|--------------|--------------|--------------|---------------------------------|---------|---------|---------|------------------|-------------------------------------|---------------------------|--------------|--------------|--------------|---------|
| NSP41 | TO-220 | | 40 | | 400 | 40 | 15 | 75 | 3 | 4 | 5 | | 3 | | 4E |
| | | | | | 30 | | 30 | 0.3 | 0.3 | 4 | 5 | | 3 | | 4E |
| NSP41A | TO-220 | | 60 | | 400 | 60 | 30 | | 0.3 | 4 | | | | | |
| NSP41B | TO-220 | | 80 | | 400 | 80 | 15 | 75 | 3 | 4 | 5 | | 3 | | 4E |
| | | | | | 30 | | 30 | 0.3 | 0.3 | 4 | | | | | |
| NSP41C | TO-220 | | 100 | | 400 | 100 | 15 | 75 | 3 | 4 | 5 | | 3 | | 4E |
| | | | | | 15 | | 15 | 0.3 | 0.3 | 4 | | | | | |
| NSP205 | TO-220 | | 50 | | 100 | 50 | 25 | 100 | 2 | 2 | | | | | 4A |
| NSP520 | TO-220 | | 30 | | 100 | 30 | 25 | | 1 | 1 | | | | | 4F |
| NSP521 | TO-220 | | 40 | | 100 | 40 | 40 | | 1 | 1 | | | | | 4F |
| NSP575 | TO-220 | 45 | 45 | | 100 | 45 | 25 | | 1 | 1 | 0.6 | | 3 | | 4F |
| NSP577 | TO-220 | | 60 | | 100 | 60 | 25 | | 1 | 1 | 0.6 | | 3 | | 4F |
| NSP579 | TO-220 | 80 | 80 | | 100 | 80 | 15 | | 1 | 1 | 0.8 | | 3 | | 4F |
| NSP581 | TO-220 | 100 | 100 | | 100 | 100 | 15 | | 1 | 1 | 0.8 | | 3 | | 4F |
| NSP585 | TO-220 | 45 | 45 | | 100 | 45 | 25 | 2 | 2 | 2 | 0.8 | | 3 | | 4E |
| | | | | | 40 | | 40 | 0.5 | 0.5 | 2 | 2 | | 3 | | 4E |
| NSP587 | TO-220 | 60 | 60 | | 100 | 60 | 25 | | 2 | 2 | 0.8 | | 3 | | 4E |
| | | | | | 40 | | 40 | 0.5 | 0.5 | 2 | | | | | |
| NSP589 | TO-220 | 80 | 80 | | 100 | 80 | 15 | | 2 | 2 | 0.8 | | 3 | | 4E |
| | | | | | 30 | | 30 | 0.5 | 0.5 | 2 | | | | | |
| NSP595 | TO-220 | 45 | 45 | | 100 | 45 | 25 | | 3 | 2 | 1.0 | | 3 | | 4E |
| | | | | | 40 | | 40 | 1 | 1 | 2 | | | | | |
| NSP597 | TO-220 | 60 | 60 | | 100 | 60 | 25 | | 3 | 2 | 1.0 | | 3 | | 4E |
| | | | | | 40 | | 40 | 1 | 1 | 2 | | | | | |
| NSP599 | TO-220 | 80 | 80 | | 100* | 80 | 15 | | 3 | 2 | 1.0 | | 3 | | 4E |
| | | | | | 30 | | 30 | 1 | 1 | 2 | | | | | |
| NSP601 | TO-220 | | 100 | | 100 | 100 | 15 | | 3 | 2 | 1.0 | | 3 | | 4A |
| | | | | | 30 | | 30 | 1 | 1 | 2 | | | | | |
| NSP695 | TO-220 | 45 | 45 | | 200 | 45 | 750 | | 3 | 3 | 2.5 | | | | 4J |
| NSP695A | TO-220 | 45 | 45 | | 200 | 45 | 750 | | 4 | 3 | 2.8 | | | | 4J |
| NSP697 | TO-220 | 60 | 60 | | 200 | 60 | 750 | | 3 | 3 | 2.5 | | | | 4J |
| NSP697A | TO-220 | 60 | 60 | | 200 | 60 | 750 | | 4 | 3 | 2.8 | | | | 4J |
| NSP699 | TO-220 | 80 | 80 | | 200 | 80 | 750 | | 3 | 3 | 2.5 | | | | 4J |
| NSP699A | TO-220 | 80 | 80 | | 200 | 80 | 750 | | 4 | 3 | 2.8 | | | | 4J |
| NSP701 | TO-220 | 100 | 100 | | 200 | 100 | 750 | | 3 | 3 | 2.5 | | | | 4J |



POWER (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICEX* ICEBT ICBO @ (μ A) Max | VCS (V) | hFE Min Max @ (A) | IC & VCE (V) | VCE(sat) (V) Max | VBE(sat) (V) Min Max | IC (A) @ Min Max | Cob (pF) Max | fT (MHz) Min Max | IC (A) @ Min Max | Process |
|----------|-------------------------|--------------|--------------|--------------|--|---------|-------------------------|---------------|------------------|----------------------|---------------------|--------------|------------------|---------------------|---------|
| NSP2020 | TO-220 | | 40 | | 400 | 40 | 15 25 125 1 | 3 4 4 | 1.0 1.5 | 3.5 5 | 0.5 | | 3 | 0.5 | 4A |
| NSP2021 | TO-220 | | 60 | | 400 | 60 | 15 20 125 1 | 3 4 4 | 1.0 1.5 | 3.5 5 | 0.5 | | 3 | 0.5 | 4A |
| NSP2100 | TO-220 | | 60 | | 200 | 60 | 750 4 3 | 3 3 | 2.5 | 4 | | | | | 4J |
| NSP2101 | TO-220 | | 60 | | 200 | 60 | 750 4 3 | 3 3 | 2.5 | 4 | | | | | 4J |
| NSP2102 | TO-220 | | 80 | | 200 | 80 | 750 3 3 | 3 3 | 2.5 | 3 | | | | | 4J |
| NSP2103 | TO-220 | | 80 | | 200 | 80 | 750 4 3 | 3 3 | 2.5 | 4 | | | | | 4J |
| NSP2480 | TO-220 | | 40 | | 100 | 40 | 20 40 100 1 | 1.5 4 4 | 1.4 0.7 | 4 1.5 | | | | | 4A |
| NSP2481 | TO-220 | | 60 | | 100 | 60 | 20 40 100 1 | 1.5 4 4 | 1.4 0.7 | 4 1.5 | | | | | 4A |
| NSP2482 | TO-220 | | 40 | | 100 | 40 | 20 40 100 1 | 1.5 4 4 | 1.4 0.7 | 4 1.5 | | | | | 4A |
| NSP2483 | TO-220 | | 60 | | 100 | 60 | 20 40 100 1 | 1.5 4 4 | 1.4 0.7 | 4 1.5 | | | | | 4A |
| NSP2520 | TO-220 | | 40 | | 200* | 40 | 10 40 200 0.2 | 4 4 | 0.7 | 1 | | | | | 4F |
| NSP3054 | Lead Bend + Clip TO-220 | | 55 | | 1 mA* | 90 | 5 25 100 0.5 | 3 4 4 | 1.0 6.0 | 0.5 3 | | | | | 4E |
| NSP3055 | TO-220 | | 60 | | 1 mA | 70 | 5 20 70 4 | 4 4 | 1.0 8.0 | 4 10 | | | 2 | 0.5 | 4A |
| NSP4921 | TO-220 | | 40 | | 100 | 40 | 10 20 100 0.5 | 1 1 | 0.6 | 1.3 | 1 | | 3 | 0.25 | 4F |
| NSP4922 | TO-220 | | 60 | | 100 | 60 | 10 20 100 0.5 | 1 1 | 0.6 | 1.3 | 1 | | 3 | 0.25 | 4F |
| NSP4923 | TO-220 | | 80 | | 100 | 80 | 10 20 100 0.5 | 1 1 | 0.6 | 1.3 | 1 | | 3 | 0.25 | 4F |
| NSP5190 | TO-220 | | 40 | | 100 | 40 | 10 25 100 1.5 | 4 1 | 0.6 | 1.5 | 4 | | | | 4E |
| NSP5191 | TO-220 | | 60 | | 100 | 60 | 10 25 100 1.5 | 4 1 | 0.6 | 1.5 | 4 | | | | 4E |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | IC _{CB0} [*] (μA) Max | IC _{CEB1} [*] (A) Max | V _{CB} (V) | hFE Min | hFE Max | IC & VCE (A) (V) | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min | IC (A) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | IC (A) Max | Process |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|--|--|---------------------|------------|------------|---------------------|---------------------------------|---------------------------------|---------------|-----------------------------|-----------------------------|-----------------------------|---------------|---------|
| NSP5192 | TO-220 | | 80 | | 100 | 80 | 80 | 7 | 4 | 2 | 0.6 | | 1.5 | | | | | 4E |
| NSP5977 | TO-220 | | 40 | | 100* | 60 | 60 | 7 | 5 | 2 | 1.7 | 2.5 | 5 | 200 | 2 | 0.5 | | 4A |
| NSP5978 | TO-220 | | 60 | | 100* | 80 | 80 | 20 | 120 | 2 | 0.6 | 2.5 | 2.5 | | | | | 4A |
| NSP5979 | TO-220 | | 80 | | 100* | 100 | 100 | 7 | 5 | 2 | 1.7 | 2.5 | 5 | 200 | 2 | 0.5 | | 4A |
| NSP5983 | TO-220 | | 40 | | 100* | 60 | 60 | 20 | 150 | 2 | 0.6 | 2.5 | 2.5 | | | | | 4A |
| NSP5984 | TO-220 | | 60 | | 100* | 80 | 80 | 7 | 8 | 2 | 1.7 | 2.5 | 8 | 250 | 2 | 0.5 | | 4A |
| NSP5985 | TO-220 | | 80 | | 100* | 80 | 80 | 20 | 120 | 2 | 1.7 | 2.5 | 8 | 250 | 2 | 0.5 | | 4A |
| TIP29 | TO-220 | | 40 | | 200* | 40 | 40 | 15 | 75 | 1 | 0.7 | 2.5 | 4 | | | | | 4F |
| TIP29A | TO-220 | | 60 | | 200* | 60 | 60 | 15 | 75 | 1 | 0.7 | 2.5 | 4 | | | | | 4F |
| TIP29B | TO-220 | | 80 | | 200* | 80 | 80 | 15 | 75 | 1 | 0.7 | 2.5 | 4 | | | | | 4F |
| TIP29C | TO-220 | | 100 | | 200* | 100 | 100 | 15 | 75 | 1 | 0.7 | 2.5 | 4 | | | | | 4F |
| TIP31 | TO-220 | | 40 | | 200* | 40 | 40 | 10 | 50 | 3 | 1.2 | 2.5 | 3 | | | | | 4F |
| TIP31A | TO-220 | | 60 | | 200* | 60 | 60 | 10 | 50 | 3 | 1.2 | 2.5 | 3 | | | | | 4F |
| TIP31B | TO-220 | | 80 | | 200* | 80 | 80 | 10 | 50 | 3 | 1.2 | 2.5 | 3 | | | | | 4F |
| TIP31C | TO-220 | | 100 | | 200* | 100 | 100 | 10 | 50 | 3 | 1.2 | 2.5 | 3 | | | | | 4F |
| TIP41 | TO-220 | | 40 | | 400* | 40 | 40 | 15 | 75 | 3 | 1.5 | 2.5 | 6 | | | | | 4A |



POWER (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | IC _{EX} [*] IC _{BE} [†] IC _{BO} (μA) Max | V _{CB} (V) Min | hFE Min Max | IC & V _{CE} (V) Max | V _{CE(sat)} (V) Max | V _{BE(sat)} (V) Min Max | IC (A) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | IC (A) Max | Process |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|--|----------------------------|----------------|---------------------------------|---------------------------------|-------------------------------------|---------------|-----------------------------|---------------------------------|---------------|---------|
| TIP41A | TO-220 | 60 | 60 | | 400* | 60 | 15 75 | 3 4 | 1.5 | | 6 | | 3 | 0.5 | 4A |
| TIP41B | TO-220 | 80 | 80 | | 400* | 80 | 15 75 | 3 4 | 1.5 | | 6 | | 3 | 0.5 | 4A |
| TIP41C | TO-220 | 100 | 100 | | 400* | 100 | 15 75 | 3 4 | 1.5 | | 6 | | 3 | 0.5 | 4A |
| TIP61 | TO-220 | 40 | 40 | | 200* | 40 | 15 100 | 0.5 4 | 0.7 | | 0.5 | | 3 | 0.05 | 4F |
| TIP61A | TO-220 | 60 | 60 | | 200* | 60 | 15 100 | 0.5 4 | 0.7 | | 0.5 | | 3 | 0.05 | 4F |
| TIP61B | TO-220 | 80 | 80 | | 200* | 80 | 15 100 | 0.5 4 | 0.7 | | 0.5 | | 3 | 0.05 | 4F |
| TIP61C | TO-220 | 100 | 100 | | 200* | 100 | 15 100 | 0.5 4 | 0.7 | | 0.5 | | 3 | 0.05 | 4F |
| TIP110 | TO-220 | 60 | 60 | | 1 mA | 60 | 500 1000 | 2 4 | 2.5 | | 2 | | | | 4J |
| TIP111 | TO-220 | 80 | 80 | | 1 mA | 80 | 500 1000 | 2 4 | 2.5 | | 2 | | | | 4J |
| TIP112 | TO-220 | 100 | 100 | | 1 mA | 100 | 500 1000 | 2 4 | 2.5 | | 2 | | | | 4J |
| TIP120 | TO-220 | 60 | 60 | | 200 | 60 | 1000 | 3 3 | 2.0 | | 3 | | | | 4K |
| TIP121 | TO-220 | 80 | 80 | | 200 | 80 | 1000 | 0.5 3 | 4.0 | | 5 | | | | 4K |
| TIP122 | TO-220 | 100 | 100 | | 200 | 100 | 1000 | 0.5 3 | 2.0 | | 3 | | | | 4K |
| TIP130 | TO-220 | 60 | 60 | | 200 | 60 | 1000 | 0.5 3 | 4.0 | | 5 | | | | 4K |
| TIP131 | TO-220 | 80 | 80 | | 200 | 80 | 1000 | 4 4 | 2.0 | | 4 | | | | 4K |
| TIP132 | TO-220 | 100 | 100 | | 200 | 100 | 1000 | 1 4 | 3.0 | | 6 | | | | 4K |



DARLINGTON

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | ICES* ICBO (mA) @ (V) Max | hFE Min Max | IC (mA) @ (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) & Min Max | IC (mA) @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | IC (mA) @ (mA) Max | Process |
|----------|----------------|-----------------------------|-----------------------------|-----------------------------|------------------------------------|--------------------------|-------------------------|---------------------------------|---|--------------------------|-----------------------------|------------------------------------|--------------------------|---------|
| 2N5305 | TO-92 (74) | | | | 100 25 | 2000 20,000 | 2 5 | 1.4 | | 200 | 10 | 60 | 2 | 05 |
| 2N5306 | TO-92 (74) | | | | 100 25 | 7000 70,000 | 2 5 | 1.4 | | 200 | 10 | 60 | 2 | 05 |
| 2N5307 | TO-92 (74) | | | | 100 40 | 2000 20,000 | 2 5 | 1.4 | | 200 | 10 | 60 | 2 | 05 |
| 2N5308 | TO-92 (74) | | | | 100 40 | 7000 70,000 | 2 5 | 1.4 | | 200 | 10 | 60 | 2 | 05 |
| 92PU45 | TO-92+ (91) | 50 | | 12 | 100 30 | 4000 15,000 25,000 | 1A 5 5 200 | 1.5 1.0 | 2.0 | 1A 200 | | 100 | 200 | 05 |
| 92PU45A | TO-92+ (91) | 60 | | 12 | 100 40 | 4000 15,000 25,000 | 1A 5 5 200 | 1.5 1.0 | 2.0 | 1A 200 | | 100 | 200 | 05 |
| D40C1 | TO-202 (35) | | 30 | | 500* | 10,000 | 200 | 1.5 | 2.0 | 500 | 10 | | | 05 |
| D40C2 | TO-202 (35) | | 30 | | 500* | 40,000 | 200 | 1.5 | 2.0 | 500 | 10 | | | 05 |
| D40C3 | TO-202 (35) | | 30 | | 500* | 90,000 | 200 | 1.5 | 2.0 | 500 | 10 | | | 05 |
| D40C4 | TO-202 (35) | | 40 | | 500* | 10,000 | 200 | 1.5 | 2.0 | 500 | 10 | | | 05 |
| D40C5 | TO-202 (35) | | 40 | | 500* | 40,000 | 200 | 1.5 | 2.0 | 500 | 10 | | | 05 |
| D40C7 | TO-202 (35) | | 50 | | 500* | 10,000 | 200 | 1.5 | 2.0 | 500 | 10 | | | 05 |
| D40C8 | TO-202 (35) | | 50 | | 500* | 40,000 | 200 | 1.5 | 2.0 | 500 | 10 | | | 05 |
| MPSA12 | TO-92 (72) | 20 | | | 100 15 | 20,000 | 10 | 1.0 | | 10 | | | | 05 |
| MPSA13 | TO-92 (72) | 30 | | | 100 30 | 10,000 5,000 | 100 5 | 1.5 | | 100 | | 125 | 10 | 05 |
| MPSA14 | TO-92 (72) | 30 | | | 100 30 | 20,000 10,000 | 100 5 | 1.5 | | 100 | | 125 | 10 | 05 |



DUAL DIFFERENTIAL AMPS

| Type No. | Case Style | V _{CE0} (V) Min | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CBO} (nA) @ Max | V _{CB} (V) | HFE Min | HFE Max | I _C (mA) @ | HFE1 HFE2 (%) Max | V _{BE1} -V _{BE2} (mV) Max | ΔV_{EE1} -V _{EE2} ΔT ($\mu V/^\circ C$) Max | C _{ob} (pF) Max | f _t (MHz) Min | f _t (MHz) Max | NF (dB) ΔT Max | Test Condition | Process No. |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|--------------------------------|---------------------|-------------------|--------------------|--------------------------|-------------------------|---|--|-----------------------------|-----------------------------|-----------------------------|------------------------------|----------------|-------------|
| 2N2453 | TO-78 | 30 | 60 | 7 | 5 | 60 | 150 80 | 600 | 1 0.01 | 10 | 5 3 | 10 | 8 | 60 | | 7 | 1 | 07 |
| 2N2453A | TO-78 | 50 | 80 | 7 | 5 | 60 | 150 80 | 600 | 1 0.01 | 10 | 5 3 | 5 | 4 | 60 | | 4 | 1 | 07 |
| 2N2639 | TO-78 | 45 | 45 | 5 | 10 | 45 | 65 55 50 | 1 0.1 300 | 1 0.1 0.01 | 10 | 5 | 10 | 8 | 80 | | 4 | 2 | 07 |
| 2N2640 | TO-78 | 45 | 45 | 5 | 10 | 45 | 65 55 50 | 1 0.1 300 | 1 0.1 0.01 | 20 | 10 | 20 | 8 | 80 | | 4 | 2 | 07 |
| 2N2641 | TO-78 | 45 | 45 | 5 | 10 | 45 | 65 55 50 | 1 0.1 300 | 1 0.1 0.01 | | | | 8 | 80 | | 4 | 2 | 07 |
| 2N2642 | TO-78 | 45 | 45 | 5 | 10 | 45 | 130 110 100 | 1 0.1 300 | 1 0.1 0.01 | 10 | 5 | 10 | 8 | 80 | | 4 | 2 | 07 |
| 2N2643 | TO-78 | 45 | 45 | 5 | 10 | 45 | 130 110 100 | 1 0.1 300 | 1 0.1 0.01 | 20 | 10 | 20 | 8 | 80 | | 4 | 2 | 07 |
| 2N2644 | TO-78 | 45 | 45 | 5 | 10 | 45 | 130 110 100 | 1 0.1 300 | 1 0.1 0.01 | | | | 8 | 80 | | 4 | 2 | 07 |
| 2N2722 | TO-78 | 45 | 45 | 5 | 1 | 30 | 120 100 50 | 0.1 0.01 250 | 0.1 0.01 0.001 | 10 | 5 | 20 | 6 | 100 | | 4 | 2 | 07 |
| 2N2903 | TO-78 | 30 | 60 | 7 | 10 | 50 | 125 60 | 625 0.1 | 1 | 20 | 10 | 20 | 8 | 60 | | 7 | 1 | 07 |
| 2N2903A | TO-78 | 30 | 60 | 7 | 10 | 50 | 125 60 | 625 0.01 | 1 | 10 | 5 | 10 | 8 | 60 | | 7 | 1 | 07 |
| 2N2913 | TO-78 | 45 | 45 | 6 | 10 | 45 | 150 100 60 | 1 0.1 240 | 1 0.1 0.01 | | | | 6 | 60 | | 4 | 1 | 07 |
| 2N2914 | TO-78 | 45 | 45 | 6 | 10 | 45 | 300 225 150 | 600 0.1 0.01 | 1 0.1 0.01 | | | | 6 | 60 | | 3 | 1 | 07 |

TEST CONDITIONS:

(1) I_C = 10 μ A, V_{CE} = 5V, f = 1kHz. (2) I_C = 10 μ A, V_{CE} = 5V, f = 15.7kHz. (3) I_C = 100 μ A, V_{CE} = 5V, f = 1kHz.





DUAL DIFFERENTIAL AMPS (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) @ Max | V _{CB} (V) Min | HFE Min | I _C (mA) @ Max | HFE1 HFE2 (%) Max | V _{BE1} -V _{BE2} (mV) Max | $\frac{\Delta V_{EE1}}{\Delta T}$ $\frac{-\Delta V_{EE2}}{\Delta T}$ (μ V/ $^{\circ}$ C) Max | C _{ob} (pF) Max | f _t (MHz) Min | Max | NF (dB) Max | Test Condition | Process No. |
|------------------------|------------|-----------------------------|-----------------------------|-----------------------------|--------------------------------|----------------------------|-------------------|---------------------------------|-------------------------|---|---|-----------------------------|-----------------------------|-----|----------------|----------------|-------------|
| 2N2915 | TO-78 | 45 | 45 | 6 | 10 | 45 | 150 100 60 | 1 0.1 0.01 | 10 | 5 3 5 | 10 | 6 | 60 | | 4 | 1 | 07 |
| 2N2915A | TO-78 | 45 | 45 | 6 | 10 | 45 | 150 100 60 | 1 0.1 0.01 | 10 | 2 1.5 2 | 5 | 6 | 60 | 160 | 4 | 1 | 07 |
| 2N2916 | TO-78 | 45 | 45 | 6 | 10 | 45 | 300 225 150 | 1 0.1 0.01 | 10 | 3 | 10 | 6 | 60 | | 3 | 1 | 07 |
| 2N2916A | TO-78 | 45 | 45 | 6 | 10 | 45 | 300 225 150 | 1 0.1 0.01 | 10 | 2 1.5 2 | 5 | 6 | 60 | 160 | 3 | 1 | 07 |
| 2N2917 | TO-78 | 45 | 45 | 6 | 10 | 45 | 150 100 60 | 1 0.1 0.01 | 20 | 10 5 10 | 20 | 6 | 60 | | 4 | 1 | 07 |
| 2N2918 | TO-78 | 45 | 45 | 6 | 10 | 45 | 300 225 150 | 1 0.1 0.01 | 20 | 10 5 10 | 20 | 6 | 60 | | 3 | 1 | 07 |
| 2N2919 | TO-78 | 60 | 60 | 6 | 2 | 45 | 150 100 60 | 1 0.1 0.01 | 10 | 5 3 5 | 10 | 6 | 60 | | 4 | 1 | 07 |
| 2N2919A | TO-78 | 60 | 60 | 6 | 2 | 45 | 150 100 60 | 1 0.1 0.01 | 10 | 2 1.5 2 | 5 | 6 | 60 | 160 | 4 | 1 | 07 |
| 2N2920 | TO-78 | 60 | 60 | 6 | 2 | 45 | 300 225 150 | 1 0.1 0.01 | 10 | 5 3 5 | 10 | 6 | 60 | | 3 | 1 | 07 |
| 2N2920 J, JTX, JTXV | TO-78 | 70 | 60 | 6 | 2 | 45 | 300 235 175 | 1 0.1 0.01 | 10 | 5 3 5 | 10 | 5 | 60 | 400 | 3 | 1 | 07 |
| 2N2920A | TO-78 | 60 | 60 | 6 | 2 | 45 | 300 225 150 | 1 0.1 0.01 | 10 | 2 1.5 2 | 5 | 6 | 60 | 160 | 3 | 1 | 07 |
| 2N2972 | TO-71 | 45 | 45 | 6 | 10 | 45 | 150 100 60 | 1 0.1 0.01 | | | | 6 | 60 | | 4 | 1 | 07 |
| 2N2973 | TO-71 | 45 | 45 | 6 | 10 | 45 | 300 225 150 | 1 0.1 0.01 | | | | 6 | 60 | | 3 | 1 | 07 |



DUAL DIFFERENTIAL AMPS (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CB0} (nA) Max | V _{CB} (V) | H _{FE} Min Max | I _C (mA) @ | H _{FE1} H _{FE2} (%) Max | V _{BE1} -V _{BE2} (mV) Max | $\Delta V_{EE1} -V_{EE2} \Delta T$ ($\mu V/^\circ C$) Max | C _{ob} (pF) Max | f _t (MHz) Min Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|-------------------------|---------------------------|---|---|---|--------------------------|------------------------------|-------------|----------------|-------------|
| 2N2974 | TO-71 | 45 | 45 | 6 | 10 | 45 | 150 60 | 1 0.1 240 0.01 | 10 | 5 3 | 10 | 6 | 50 | 4 | 1 | 07 |
| 2N2975 | TO-71 | 45 | 45 | 6 | 10 | 45 | 300 225 120 | 0.1 0.1 600 0.01 | 10 | 5 3 5 | 10 | 6 | 60 | 3 | 1 | 07 |
| 2N2976 | TO-71 | 45 | 45 | 6 | 10 | 45 | 150 100 60 | 0.1 0.1 240 0.01 | 20 | 10 5 10 | 20 | 6 | 60 | 4 | 1 | 07 |
| 2N2977 | TO-71 | 45 | 45 | 6 | 10 | 45 | 300 225 120 | 1 0.1 600 0.01 | 20 | 10 5 10 | 20 | 6 | 60 | 3 | 1 | 07 |
| 2N2978 | TO-71 | 60 | 60 | 6 | 2 | 45 | 150 100 60 | 1 0.1 240 0.01 | 10 | 5 3 5 | 10 | 6 | 60 | 4 | 1 | 07 |
| 2N2979 | TO-71 | 60 | 60 | 6 | 2 | 45 | 300 225 120 | 1 0.1 600 0.01 | 10 | 5 3 5 | 10 | 6 | 60 | 3 | 1 | 07 |
| 2N3587 | TO-78 | 60 | 45 | 6 | 10 | 40 | 80 50 | 500 0.1 | 10 | 20 | 20 | 8 | 80 200 | 10 | 3 | 07 |
| 2N3580 | TO-78 | 60 | 50 | 6 | 10 | 45 | 300 225 150 80 | 1 0.1 600 0.001 | 10 | 3 | 5 | 6 | 60 240 | 3 | 2 | 07 |
| 2N3907 | TO-78 | 60 | 45 | 6 | 10 | 45 | 120 70 60 | 1 500 300 0.01 | 10 | 2.5 1 2 | 5 | 6 | 60 240 | 4 | 1 | 07 |
| 2N3908 | TO-78 | 60 | 60 | 6 | 2 | 45 | 200 125 100 40 | 1 0.1 500 0.001 | 10 | 2.5 1 | 5 | 6 | 60 240 | 3 | 1 | 07 |

TEST CONDITIONS:

(1) I_C = 10 μ A, V_{CE} = 5V, f = 1kHz. (2) I_C = 10 μ A, V_{CE} = 5V, f = 15.7kHz. (3) I_C = 100 μ A, V_{CE} = 5V, f = 1kHz.



Section 2

PNP Transistors

2



SATURATED SWITCHES

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | I _C & V _{CE} (mA) (V) | h _{FE} | | I _C @ (mA) | V _{BE(SAT)} (V) Min Max | V _{CE(SAT)} (V) Max | | I _C @ (mA) | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C @ (mA) | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|-----------------------------------|--|-----------------|-----|-----------------------|--|------------------------------------|------|-----------------------|--------------------------------|------------------------------------|-----------------------|---------------------------------|-------------------|----------------|-------------|
| | | | | | | | Min | Max | | | Max | Min | | | | | | | | |
| 2N869 | TO-52 | 25 | | 5 | 10 | 15 | 20 | 120 | 10 | 5 | 1.0 | 1.0 | 10 | 9 | 100 | 10 | | | | 64 |
| 2N869A | TO-52 | 25 | 18 | 5 | 10 | 15 | 25 | 120 | 100 | 1 | 0.15 | 0.78 | 0.98 | 6 | 400 | 10 | 80 | 1 | | 64 |
| | | | | | | | 30 | 120 | 10 | 0.3 | 0.2 | 0.85 | 1.2 | | | | | | | |
| 2N995 | TO-52 | 20 | | 4 | 5 | 15 | 35 | 140 | 20 | 1 | 0.2 | 0.95 | 20 | 10 | 100 | 10 | | | | 64 |
| 2N995A | TO-52 | 20 | 15 | 4 | 5 | 15 | 25 | 50 | 100 | 1 | 0.2 | 0.95 | 20 | 6 | 100 | 10 | 90 | 2 | | 64 |
| | | | | | | | 25 | 20 | 1 | 0.5 | 1.7 | 100 | | | | | | | | |
| | | | | | | | 35 | 140 | 1 | | | | | | | | | | | |
| 2N2894 | TO-52 | 12 | | 4 | 10* | 6 | 25 | 100 | 100 | 1 | 0.15 | 0.78 | 0.98 | 6 | 400 | 30 | 90 | 2 | | 64 |
| | | | | | | | 40 | 150 | 30 | 0.5 | 0.2 | 0.85 | 1.2 | | | | | | | |
| | | | | | | | 30 | 10 | 0.3 | 0.5 | 1.7 | 100 | | | | | | | | |
| 2N2894A | TO-52 | 12 | | 4.5 | 50* | 10 | 30 | 100 | 100 | 1 | 0.13 | 0.78 | 0.92 | 4.5 | 800 | 30 | 25 | 3 | | 64 |
| | | | | | | | 40 | 120 | 30 | 0.5 | 0.19 | 0.85 | 1.15 | | | | | | | |
| | | | | | | | 30 | 10 | 0.3 | 0.45 | 1 | 1.5 | 100 | | | | | | | |
| | | | | | | | 20 | 1 | 0.5 | | | | | | | | | | | |
| 2N3012 | TO-52 | 12 | | 4 | 80* | 6 | 20 | 100 | 100 | 1 | 0.15 | 0.78 | 0.98 | 6 | 400 | 30 | 75 | 2 | | 64 |
| | | | | | | | 30 | 120 | 30 | 0.5 | 0.2 | 0.85 | 1.2 | | | | | | | |
| | | | | | | | 25 | 10 | 0.3 | 0.5 | 1.7 | 100 | | | | | | | | |
| 2N3209 | TO-52 | 20 | | 4 | 80* | 10 | 15 | 100 | 100 | 1 | 0.15 | 0.78 | 0.98 | 5 | 400 | 30 | 90 | 2 | | 64 |
| | | | | | | | 30 | 120 | 30 | 0.5 | 0.2 | 0.85 | 1.2 | | | | | | | |
| | | | | | | | 20 | 10 | 0.3 | 0.6 | 1.7 | 100 | | | | | | | | |
| 2N3244 | TO-39 | 40 | | 5 | 50 | 30 | 25 | 750 | 5 | 5 | 0.3 | 1.1 | 150 | 25 | 175 | 50 | 185 | 4 | | 70 |
| | | | | | | | 50 | 150 | 500 | 1 | 0.5 | 0.75 | 1.5 | | | | | | | |
| | | | | | | | 60 | 150 | 1 | | | | | | | | | | | |
| 2N3245 | TO-39 | 50 | | 5 | 50 | 50 | 20 | 1A | 5 | 5 | 0.35 | 1.1 | 150 | 25 | 150 | 50 | 165 | 4 | | 70 |
| | | | | | | | 30 | 90 | 500 | 1 | 0.6 | 0.75 | 1.5 | | | | | | | |
| | | | | | | | 35 | 150 | 1 | 1.2 | 2 | 1A | | | | | | | | |
| 2N3248 | TO-52 | 15 | | 5 | | | 25 | 100 | 100 | 1 | 0.125 | 0.6 | 0.9 | 8 | 250 | 20 | 100 | 5 | | 64 |
| | | | | | | | 35 | 50 | 1 | 0.25 | 0.7 | 1.1 | 50 | | | | | | | |
| | | | | | | | 50 | 10 | 1 | 1 | 1 | 1 | 1 | | | | | | | |
| | | | | | | | 50 | 150 | 0.1 | 1 | 0.4 | 1.3 | 100 | | | | | | | |
| 2N3249 | TO-52 | 15 | | 5 | | | 35 | 100 | 100 | 1 | 0.125 | 0.6 | 0.9 | 8 | 300 | 20 | 100 | 5 | | 64 |
| | | | | | | | 75 | 50 | 1 | 0.25 | 0.7 | 1.1 | 50 | | | | | | | |
| | | | | | | | 100 | 10 | 1 | 1 | 1 | 1 | 1 | | | | | | | |
| | | | | | | | 100 | 1 | 1 | 1 | 1 | 1 | 1 | | | | | | | |
| | | | | | | | 100 | 300 | 0.1 | 1 | 0.45 | 1.3 | 100 | | | | | | | |



SATURATED SWITCHES (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{BE0} (V) Min | ICES* I _{CB0} (mA) Max | hFE Min | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) @ Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) @ Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|---|-----------------------------|---------------------------------------|------------|---|---------------------------------|---------------------------------|---------------------------------|-----------------------------|-----------------------------|---------------------------------|------------------------------|----------------|----------------|-------------|
| | | | | | | | | | | | | | | | | |
| 2N3304 | TO-52 | 6 | 4 | 10* | 20 | 50 | 0.15 | 0.7 | 1 | 3.5 | 500 | 10 | 60 | | 7 | 65 |
| | | | | | 30 | 120 | 0.16 | 0.8 | 1 | | | | | | | |
| | | | | | 15 | 1 | 0.5 | 1.5 | 50 | | | | | | | |
| 2N3451 | TO-52 | 6 | 4 | 10* | 20 | 50 | 0.16 | 0.8 | 10 | 5.5 | 500 | 10 | 60 | | 7 | 65 |
| 2N3467 | TO-39 | 40 | 5 | 100 | 30 | 120 | 0.5 | 1.5 | 50 | | | | | | 4 | 70 |
| | | | | | 40 | 120 | 0.3 | 1.0 | 150 | 25 | 175 | 50 | 90 | | | |
| | | | | | 40 | 150 | 0.5 | 0.8 | 1.2 | | | | | | | |
| 2N3468 | TO-39 | 50 | 5 | 100 | 20 | 1 | 0.35 | 1.0 | 150 | 25 | 150 | 50 | 90 | | 4 | 70 |
| | | | | | 25 | 75 | 0.6 | 0.8 | 1.2 | | | | | | | |
| | | | | | 25 | 150 | 0.6 | 0.8 | 1.2 | | | | | | | |
| 2N3545 | TO-52 | 20 | 5 | 10 | 30 | 100 | 0.2 | 0.6 | 0.85 | 10 | 250 | 10 | 90 | | 8 | 64 |
| | | | | | 35 | 50 | 0.3 | 1.1 | 50 | 8 | | | | | | |
| | | | | | 40 | 120 | 0.5 | 1.3 | 100 | | | | | | | |
| | | | | | 30 | 1 | 0.5 | 1.3 | 100 | | | | | | | |
| 2N3546 | TO-52 | 15 | 4.5 | 10 | 15 | 100 | 0.15 | 0.7 | 0.9 | 10 | 700 | 10 | 30 | | 9 | 64 |
| | | | | | 25 | 50 | 0.25 | 0.8 | 1.3 | 50 | | | | | | |
| | | | | | 30 | 120 | 0.5 | 1.6 | 100 | | | | | | | |
| 2N3576 | TO-52 | 20 | 5 | 10 | 10 | 100 | 0.15 | 0.75 | 0.95 | 10 | 400 | 10 | 50 | | 5 | 64 |
| | | | | | 40 | 120 | 0.5 | 1.1 | 100 | 4.5 | | | | | | |
| 2N3639 | TO-92 (72) | Same as PN3639, see page 2-5 for explanation | | | | | | | | | | | | | | |
| 2N3640 | TO-92 (72) | Same as PN3640, see page 2-5 for explanation | | | | | | | | | | | | | | |
| 2N4208 | TO-52 | 12 | 4.5 | 10* | 30 | 50 | 0.13 | 0.8 | 1 | 3 | 700 | 10 | 20 | | 5 | 65 |
| | | | | | 30 | 120 | 0.3 | 0.8 | 0.95 | 10 | | | | | | |
| | | | | | 15 | 1 | 0.5 | 1.5 | 50 | | | | | | | |
| 2N4209 | TO-52 | 15 | 4.5 | 10* | 40 | 50 | 0.15 | 0.8 | 1 | 3 | 850 | 10 | 20 | | 5 | 65 |
| | | | | | 50 | 120 | 0.3 | 0.8 | 0.95 | 10 | | | | | | |
| | | | | | 35 | 1 | 0.6 | 1.5 | 50 | | | | | | | |
| 2N4258 | TO-92 (72) | Same as PN4258, see page 2-5 for explanation | | | | | | | | | | | | | | |
| 2N4258A | TO-92 (72) | Same as PN4258A, see page 2-5 for explanation | | | | | | | | | | | | | | |

TEST CONDITIONS:

(1) I_C = 30mA, V_{CC} = 3V, I_{B1} = 3mA, I_{B2} = 1.5mA, (2) I_C = 30mA, V_{CC} = 3V, I_{B1} = I_{B2} = 1.5mA, (3) I_C = 30mA, V_{CC} = 3V, I_{B1} = I_{B2} = 3mA, (4) I_C = 500mA, V_{CC} = 30V, I_{B1} = I_{B2} = 50mA, (5) I_C = 10mA, V_{CC} = 3V, I_{B1} = I_{B2} = 1mA, (6) I_C = 10mA, V_{CC} = 1.5V, I_{B1} = I_{B2} = 1mA, (7) I_C = 10mA, V_{CC} = 1.5V, I_{B1} = I_{B2} = 500 μA, (8) I_C = 10mA, V_{CC} = 2V, I_{B1} = I_{B2} = 1mA, (9) I_C = 50mA, V_{CC} = 3V, I_{B1} = I_{B2} = 5mA, (10) I_C = 1A, V_{CC} = 30V, I_{B1} = I_{B2} = 100mA.



SATURATED SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | V _{CB} (V) @ I _C | hFE Min Max | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min Max | I _C (mA) @ I _C | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) @ I _C | t _{off} (ns) Max | NF (dB) (dB) Max | Test Condition | Process No. |
|----------|------------------------|--|-----------------------------|-----------------------------|-----------------------------------|--|----------------------|---|---------------------------------|--|--|-----------------------------|------------------------------------|--|------------------------------|------------------------|----------------|-------------|
| 2N5022 | TO-39 | 50 | 5 | 5 | 100* | 30 | 25 25 15 | 1A 5 500 1 100 1 | 0.2 0.4 0.8 | 1.0 1.4 1.75 | 100 500 1A | 25 | 170 | 50 | 90 | | 4 | 70 |
| 2N5023 | TO-39 | 30 | 30 | 5 | 100* | 20 | 40 40 30 | 1A 5 500 1 100 1 | 0.17 0.35 0.7 | 1.0 1.4 1.75 | 100 500 1A | 25 | 200 | 50 | 90 | | 4 | 70 |
| 2N5056 | TO-52 | 15 | 15 | 4.5 | 50* | 10 | 20 30 20 12 | 100 1 30 0.5 10 0.3 1 0.5 | 0.13 0.19 0.45 | 0.92 1.15 1.5 | 10 30 100 | 4.5 | 600 | 30 | 35 | | 3 | 64 |
| 2N5057 | TO-52 | 15 | 15 | 4.5 | 50* | 10 | 30 40 30 20 | 100 1 30 0.5 10 0.3 1 0.5 | 0.13 0.19 0.45 | 0.92 1.15 1.5 | 10 30 100 | 4.5 | 800 | 30 | 35 | | 3 | 64 |
| 2N5140 | TO-92 (72) | Same as PN5140, see page 2-5 for explanation | | | | | | | | | | | | | | | | |
| 2N5771 | TO-92 (72) | 15 | 15 | 4.5 | 10 | 8 | 40 50 35 | 50 1.0 120 0.3 1 0.5 | 0.15 0.18 0.6 | 0.8 0.95 1.5 | 1 10 50 | 3 | 850 | 10 | 20 | | 6 | 65 |
| 2N5910 | TO-92 (72) | Same as PN5910, see page 2-5 for explanation | | | | | | | | | | | | | | | | |
| DH3467CD | Ceramic DIP (40) | 40 | 40 | 5 | 100 | 30 | 40 40 40 | 1A 5 500 1 150 1 | 1.0 0.5 0.3 | 1.6 1.2 1.0 | 1A 500 150 | 25 | 175 | 50 | 90 | | 4 | 70 |
| DH3467CN | Molded DIP (39) | 40 | 40 | 5 | 100 | 30 | 40 40 40 | 1A 5 500 1 150 1 | 1.0 0.5 0.3 | 1.6 1.2 1.0 | 1A 500 150 | 25 | 175 | 50 | 90 | | 4 | 70 |
| DH3468CD | Ceramic DIP (40) | 50 | 50 | 5 | 100 | 30 | 20 25 25 | 1A 5 500 1 150 1 | 1.2 0.6 0.35 | 1.6 1.2 1.0 | 1A 500 150 | 25 | 150 | 50 | 90 | | 4 | 70 |
| DH3468CN | Molded DIP (39) | 50 | 50 | 5 | 100 | 30 | 20 25 25 | 1A 5 500 1 150 1 | 1.2 0.6 0.35 | 1.6 1.2 1.0 | 1A 500 150 | 25 | 150 | 50 | 90 | | 4 | 70 |
| MPS3639 | TO-92 (72) | Same as PN3639, see page 2-5 for explanation | | | | | | | | | | | | | | | | |
| MPS3640 | TO-92 (72) | Same as PN3640, see page 2-5 for explanation | | | | | | | | | | | | | | | | |



SATURATED SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C & V _{CE} (mA) (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|-----------------------------|-----------------------------|-----------------------------|-----------------------------------|---------------------|------------------------|------------------------|--|------------------------------------|------------------------------------|-------------------------------|--------------------------------|--------------------------------|--------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| NS3762 | TO-39 | 40 | 40 | 5 | | | 30 | 120 | 1.5A 5 1A 1.5 500 1 150 1 | 0.9 0.5 0.22 0.15 | 1.4 1.2 1.0 0.8 | 1A 500 150 10 | 18 | 180 | 50 | 115 | | | 10 | 70 |
| NS3763 | TO-39 | 60 | 60 | 5 | | | 20 | 80 | 1.5A 5 1A 1.5 500 1 150 1 | 0.9 0.5 0.22 0.15 | 1.4 1.2 1.0 0.8 | 1A 500 150 10 | 18 | 180 | 50 | 115 | | | 10 | 70 |
| PN3639 | TO-92 (72) | 6 | 6 | 4 | 10* | 3 | 20 | 120 | 50 1.0 10 0.3 | 0.16 0.5 | 0.8 1.5 | 10 50 | 3.5 | 300 | 10 | 60 | | | 7 | 65 |
| PN3640 | TO-92 (72) | 12 | 12 | 4 | 10* | 6 | 20 | 120 | 50 1.0 10 0.3 | 0.2 0.6 | 0.8 1.5 | 10 50 | 3.5 | 300 | 10 | 75 | | | 7 | 65 |
| PN4258 | TO-92 (72) | 12 | 12 | 4.5 | 10* | 6 | 30 | 120 | 50 1 10 3 1 0.5 | 0.15 0.5 | 0.7 1.5 | 10 50 | 3 | 700 | 10 | 20 | | | 6 | 65 |
| PN4258A | TO-92 (72) | 12 | 12 | 4.5 | 10* | 6 | 30 | 120 | 50 1 10 3 1 0.5 | 0.15 0.5 | 0.7 1.5 | 10 50 | 3 | 700 | 10 | 18 | | | 6 | 65 |
| PN5140 | TO-92 (72) | 5 | 5 | 4 | 50* | 3 | 20 | 40 | 10 1 | 0.2 0.75 | 1.2 | 10 50 | 5 | 400 | 10 | 20 | | | 6 | 65 |
| PN5910 | TO-92 (72) | 20 | 20 | 4.5 | 10* | 10 | 30 | 120 | 50 1 10 0.3 1 0.5 | 0.15 0.5 | 0.75 1.5 | 10 50 | 3 | 700 | 10 | 20 | | | 6 | 65 |

TEST CONDITIONS:

(1) I_C = 30mA, V_{CC} = 3V, I_{B1} = 3mA, I_{B2} = 1.5mA, V_{CE} = 3V, I_{B1} = I_{B2} = 3mA, V_{CC} = 3V, I_C = 500mA, V_{CE} = 30V, I_{B1} = I_{B2} = 50mA.
 (5) I_C = 10mA, V_{CC} = 3V, I_{B1} = I_{B2} = 1mA, V_{CE} = 1.5V, I_{B1} = I_{B2} = 1mA, V_{CC} = 1.5V, I_{B1} = I_{B2} = 1mA, V_{CE} = 2V, I_{B1} = I_{B2} = 1mA, V_{CC} = 2V, I_{B1} = I_{B2} = 1mA, V_{CE} = 50mA.
 (10) I_C = 1A, V_{CC} = 30V, I_{B1} = I_{B2} = 100mA.

PNP Transistors



LOW LEVEL AMPS

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) | h _{FE} Min | I _C @ (mA) Max | V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) Max | NF (dB) @ (kHz) Max | Freq (kHz) | Process No. |
|------------------------|------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|---------------------|------------------------|------------------------------|---------------------|---------------------------------|---------------------------------|------------------------------|-----------------------------|-----------------------------|-----------------------------|----------------------------|------------------------|------------|-------------|
| 2N2604 | TO-46 | 60 | 45 | 6 | 10 | 45 | 60 | 350 | 5 | 0.5 | 0.7 | 10 | 6 | 30 | 4 | 0.5 | 4 | 1 | 62 |
| 2N2604 J, JTX, JTXV | TO-46 | 80 | 60 | 6 | 10 | 50 | 60 | 350 | 5 | 0.5 | 0.7 | 10 | 6 | 30 | 3 | 140 | 0.5 | 3 | 62 |
| 2N2605 | TO-46 | 60 | 45 | 6 | 10 | 45 | 150 | 600 | 5 | 0.5 | 0.7 | 10 | 6 | 30 | 3 | 0.5 | 3 | 1 | 62 |
| 2N2605 J, JTX, JTXV | TO-46 | 70 | 60 | 6 | 10 | 50 | 100 | 600 | 5 | 0.5 | 0.7 | 10 | 6 | 30 | 3 | 140 | 0.5 | 3 | 62 |
| 2N3547 | TO-18 | 60 | 60 | 6 | 25 | 45 | 75 | 10 | 5 | 1.0 | 1.0 | 10 | 8 | 45 | 5 | 1 | 5 | 1 | 62 |
| 2N3540 | TO-18 | 60 | 45 | 5 | 10 | 45 | 150 | 600 | 5 | 1.0 | 1.0 | 10 | 8 | 60 | 4 | 150 | 1 | 4 | 62 |
| 2N3549 | TO-18 | 60 | 60 | 6 | 10 | 45 | 100 | 800 | 5 | 1.0 | 1.0 | 10 | 8 | 60 | 4 | 150 | 1 | 4 | 62 |
| 2N3550 | TO-18 | 60 | 45 | 8 | 1 | 45 | 300 | 800 | 5 | 0.5 | 0.7 | 5 | 8 | 60 | 4 | 150 | 1 | 4 | 62 |
| 2N3799 | TO-18 | 60 | 60 | 5 | 10 | 50 | 300 | 300 | 5 | 0.25 | 0.8 | 1 | 4 | 30 | 1.5 | 0.5 | 1 | 62 | |
| 2N3962 | TO-18 | 60 | 60 | 6 | 10 | 50 | 90 | 50 | 5 | 0.25 | 0.9 | 10 | 6 | 40 | 3 | 160 | 0.5 | 3 | 62 |
| | | | | | | | 100 | 10 | 5 | 0.4 | 0.95 | 50 | | | | | | | |
| | | | | | | | 100 | 450 | 5 | | | | | | | | | | |
| | | | | | | | 100 | 300 | 5 | | | | | | | | | | |
| | | | | | | | 60 | 0.001 | 5 | | | | | | | | | | |



LOW LEVEL AMPS (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICBO (mA) Max | V _{CB} (V) @ | h _{FE} Min | h _{FE} Max | I _C (mA) & V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) @ | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) @ | NF (dB) Max | Freq (kHz) @ | Process No. | |
|----------|------------|---|--------------|--------------|---------------|-----------------------|---------------------|---------------------|---|------------------------------|------------------------------|-----------------------|--------------------------|--------------------------|--------------------------|-----------------------|-------------|--------------|-------------|----|
| 2N3963 | TO-18 | 80 | 80 | 6 | 10 | 70 | 90 | 450 | 5 | 0.25 | 0.9 | 10 | 6 | 40 | 160 | 0.5 | 3 | 1 | 62 | |
| 2N3964 | TO-18 | 45 | 45 | 6 | 10 | 40 | 180 | 600 | 5 | 0.25 | 0.9 | 10 | 6 | 50 | 160 | 0.5 | 2 | 1 | 62 | |
| 2N3965 | TO-18 | 60 | 60 | 6 | 10 | 50 | 180 | 600 | 5 | 0.25 | 0.9 | 10 | 6 | 50 | 160 | 0.5 | 2 | 1 | 62 | |
| 2N4058 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 180 | 400 | 5 | 0.7 | | 10 | | | | | 5 | 1 | 62 | |
| 2N4059 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 45 | 660 | 5 | 0.7 | | 10 | | | | | | | 62 | |
| 2N4061 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 90 | 330 | 5 | 0.7 | | 10 | | | | | | | 62 | |
| 2N4062 | TO-92 (74) | 30 | 30 | 6 | 100 | 20 | 180 | 660 | 5 | 0.7 | | 10 | | | | | | | 62 | |
| 2N4248 | TO-92 (72) | Same as PN4248, see page 2.8 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4249 | TO-92 (72) | Same as PN4249, see page 2.8 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4250 | TO-92 (72) | Same as PN4250, see page 2.8 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4250A | TO-92 (72) | Same as PN4250A, see page 2.8 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4288 | TO-92 (74) | 30 | 25 | 6 | 50 | 25 | 75 | 10 | 5 | 0.35 | 0.8 | 1 | 8 | 40 | | 1 | | | 62 | |
| 2N4289 | TO-92 (74) | 60 | 45 | 7 | 10 | 45 | 75 | 10 | 5 | 0.35 | 0.8 | 1 | 8 | 40 | | 1 | | 4 | 1 | 62 |

LOW LEVEL AMPS (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICBO (mA) Max | VCB (V) | hFE Min | hFE Max | IC (mA) & VCE (V) | VCE(SAT) (V) Max | VBE(SAT) (V) Min | IC (mA) Max | Cob (pF) Max | fT (MHz) Min | fT (MHz) Max | IC (mA) @ (mV) | NF (dB) @ (kHz) Max | Process No. |
|----------|------------|--------------|---|--------------|---------------|---------|---------|---------|-------------------|------------------|------------------|-------------|--------------|--------------|--------------|----------------|---------------------|-------------|
| 2N4964 | TO-92 (72) | | Same as MP5A70, see below for explanation | | | | | | | | | | | | | | | 62 |
| 2N4965 | TO-92 (72) | | Same as 2N5086, see below for explanation | | | | | | | | | | | | | | | 62 |
| 2N5086 | TO-92 (72) | 50 | 50 | | 50 | 35 | 150 | 10 | 5 | 0.3 | | 10 | 4 | 40 | 0.5 | | 3 | 62 |
| 2N5087 | TO-92 (72) | 50 | 50 | | 50 | 35 | 150 | 500 | 5 | 0.3 | | 10 | 4 | 40 | 0.5 | | 2 | 62 |
| 2N5227 | TO-92 (72) | 30 | 30 | 3 | 100 | 10 | 50 | 700 | 10 | 0.4 | 1.0 | 10 | 5 | 100 | 10 | | | 62 |
| MP5A70 | TO-92 (72) | | 40 | 4 | 100 | 30 | 40 | 400 | 5 | 0.25 | | 10 | 4 | 125 | 5 | | | 62 |
| MP56523 | TO-92 (72) | | 25 | 4 | 50 | 20 | 300 | 600 | 2 | 0.5 | | 50 | 4 | | | | | 62 |
| PN4248 | TO-92 (72) | 40 | 40 | 5 | 10 | 40 | 50 | 0.1 | 5 | 0.25 | | 10 | 6 | | | | 3 | 62 |
| PN4249 | TO-92 (72) | 60 | 60 | 5 | 10 | 40 | 100 | 300 | 0.1 | 0.25 | | 10 | 6 | | | | 3 | 62 |
| PN4250 | TO-92 (72) | 40 | 40 | 5 | 10 | 40 | 250 | 700 | 0.1 | 0.25 | | 10 | 6 | | | | 2 | 62 |
| PN4250A | TO-92 (72) | 60 | 60 | 5 | 10 | 50 | 250 | 700 | 0.1 | 0.25 | | 10 | 6 | | | | 2 | 62 |



GENERAL PURPOSE AMPS AND SWITCHES

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICBO (mA) Max | VCB (V) | hFE Min | hFE Max | IC (mA) & VCE (V) | VCE(SAT) (V) Max | VBE(SAT) (V) Min | IC (mA) Max | Cob (pF) Max | fT (MHz) Min | fT (MHz) Max | IC (mA) @ (mV) | NF (dB) Min | Test Condition | Process No. |
|----------|------------|--------------|--------------|--------------|---------------|---------|---------|---------|-------------------|------------------|------------------|-------------|--------------|--------------|--------------|----------------|-------------|----------------|-------------|
| 2N722 | TO-18 | 50 | 35 | 5 | 100 | 30 | 30 | 90 | 150 | 10 | 1.3 | 150 | 45 | 60 | 50 | 50 | | | 63 |
| 2N1132 | TO-5 | 50 | 35 | 2 | 100 | 30 | 30 | 90 | 150 | 10 | 1.3 | 150 | 45 | 60 | 50 | 50 | | | 63 |
| 2N2696 | TO-18 | 25 | 25 | | 25 | 10 | 20 | 300 | 2 | 0.25 | 1.1 | 50 | 20 | 100 | 50 | 170 | | 1 | 63 |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) | | V _{BEBO} (V) | | I _{CBO} (nA) @ V _{CE} | | h _{FE} @ I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(SAT)} (V) | | I _C (mA) @ V _{CE} | | C _{ob} (pF) | f _T (MHz) | | I _C (mA) | t _{off} (ns) | NF (dB) | Test Condition | Process No. |
|-------------------------|------------|----------------------|-----|-----------------------|-----|---|-----|--|-----|---|-----|---------------------------------------|-----|----------------------|----------------------|-----|---------------------|-----------------------|---------|----------------|-------------|
| | | Min | Max | Min | Max | Max | Min | Max | Min | Max | Min | Max | Min | | Max | Min | | | | | |
| 2N2904 | TO-5 | 60 | 40 | 5 | 40 | 20 | 50 | 500 | 10 | 20 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 100 | | 2 | 63 | |
| 2N2904 J, JTX, JTXV | TO-5 | 60 | 40 | 5 | 40 | 20 | 50 | 500 | 10 | 20 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 175 | | 2 | 63 | |
| 2N2904A | TO-5 | 60 | 60 | 5 | 60 | 10 | 50 | 500 | 10 | 40 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 100 | | 2 | 63 | |
| 2N2904A J, JTX, JTXV | TO-5 | 60 | 60 | 5 | 60 | 10 | 50 | 500 | 10 | 40 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 175 | | 2 | 63 | |
| 2N2905 | TO-5 | 60 | 40 | 5 | 40 | 20 | 50 | 500 | 10 | 30 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 100 | | 2 | 63 | |
| 2N2905 J, JTX, JTXV | TO-5 | 60 | 40 | 5 | 40 | 20 | 50 | 500 | 10 | 30 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 200 | | 2 | 63 | |
| 2N2905A | TO-5 | 60 | 60 | 5 | 60 | 10 | 50 | 500 | 10 | 50 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 100 | | 2 | 63 | |
| 2N2905A J, JTX, JTXV | TO-5 | 60 | 60 | 5 | 60 | 10 | 50 | 500 | 10 | 50 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 175 | | 2 | 63 | |

TEST CONDITIONS:

(1) I_C = 300mA, V_{CC} = 10V, I_B¹ = I_B² = 30mA. (2) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA. (3) I_C = 300mA, V_{CC} = 15V, I_B¹ = I_B² = 30mA. (4) I_C = 300mA, V_{CC} = 30V, I_B¹ = I_B² = 30mA.
 (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 100Hz. (7) I_C = 30 μA, V_{CE} = 5V, f = 1kHz. (8) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (9) I_C = 250 μA, V_{CE} = 5V, f = 1kHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 50mA, V_{CC} = 30V, I_B¹ = I_B² = 5mA. (12) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (13) I_C = 50mA, V_{CC} = 10V, I_B¹ = I_B² = 5mA.

GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CBO} (mA) Max | V _{CB} (V) @ I _C | h _{FE} @ I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(SAT)} @ I _C | | C _{ob} (pF) Max | f _T (MHz) | | I _C (mA) @ I _C Max | t _{off} (ns) Max | NF (dB) Min | Test Condition | Process No. |
|-------------------------|------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|---|--|-----|--|-----|-----------------------------|----------------------|-----|---|------------------------------|----------------|----------------|-------------|
| | | | | | | | Min | Max | Max | Min | | Min | Max | | | | | |
| 2N2905A J, JTX, JTXV | TO-5 | 60 | 60 | 5 | 10 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 200 | 50 | 200 | | 2 | 63 |
| | | | | | | | | 100 | 1.6 | 500 | | | | | | | | |
| 2N2906 | TO-18 | 60 | 40 | 5 | 20 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 100 | 50 | | | 2 | 63 |
| | | | | | | | | 40 | 2.6 | 500 | | | | | | | | |
| 2N2906 J, JTX, JTXV | TO-18 | 60 | 40 | 5 | 20 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 175 | 50 | | | 2 | 63 |
| | | | | | | | | 40 | 2.6 | 500 | | | | | | | | |
| 2N2906A | TO-18 | 60 | 60 | 5 | 10 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 100 | 50 | | | 2 | 63 |
| | | | | | | | | 40 | 2.6 | 500 | | | | | | | | |
| 2N2906A J, JTX, JTXV | TO-18 | 60 | 60 | 5 | 10 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 175 | 50 | | | 2 | 63 |
| | | | | | | | | 40 | 2.6 | 500 | | | | | | | | |
| 2N2907 | TO-18 | 60 | 40 | 5 | 20 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 100 | 50 | | | 2 | 63 |
| | | | | | | | | 100 | 2.6 | 500 | | | | | | | | |
| 2N2907 J, JTX, JTXV | TO-18 | 60 | 40 | 5 | 20 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 200 | 50 | | | 2 | 63 |
| | | | | | | | | 40 | 2.6 | 500 | | | | | | | | |
| 2N2907A | TO-18 | 60 | 60 | 5 | 10 | 50 | 10 | 500 | 1.3 | 150 | 8 | 200 | 100 | 50 | | | 2 | 63 |
| | | | | | | | | 100 | 2.6 | 500 | | | | | | | | |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) | | V _{CE0} (V) | | V _{EB0} (V) | | I _{CB0} (mA) @ V _{CB} (V) | | h _{FE} @ I _C & V _{CE} (V) | | V _{CE(SAT)} (V) & V _{BE(SAT)} (V) @ I _C (mA) | | C _{ob} (pF) | | f _T (MHz) @ I _C (mA) | | t _{off} (ns) | | NF (dB) Min | Test Condition | Process No. | |
|-------------------------|------------|----------------------|-----|----------------------|-----|----------------------|-----|---|-----|--|-----|---|-----|----------------------|-----|--|-----|-----------------------|-----|-------------|----------------|-------------|----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | |
| 2N2907A J, JTX, JTXV | TO-18 | 60 | 60 | 5 | 60 | 5 | 60 | 10 | 50 | 50 | 500 | 10 | 10 | 0.4 | 1.3 | 150 | 50 | 200 | 200 | 200 | | 2 | 63 |
| | | | | | | | | | | | 100 | 300 | 10 | 10 | 1.5 | 2.6 | 500 | | | | | | |
| 2N3072 | TO-5 | 60 | 60 | 4 | 60 | 4 | 60 | 10* | 30 | 15 | 300 | 2 | 2 | 0.25 | 1.2 | 50 | 50 | 100 | 100 | 100 | | 3 | 63 |
| 2N3073 | TO-18 | 60 | 60 | 4 | 60 | 4 | 60 | 10* | 30 | 15 | 300 | 2 | 2 | 0.25 | 1.2 | 50 | 50 | 100 | 100 | 100 | | 3 | 63 |
| 2N3120 | TO-5 | 45 | 45 | 4 | 45 | 4 | 45 | 10* | 30 | 15 | 300 | 2 | 2 | 0.25 | 1.2 | 50 | 50 | 100 | 100 | 100 | | 4 | 63 |
| 2N3121 | TO-18 | 45 | 45 | 4 | 45 | 4 | 45 | 10* | 30 | 15 | 300 | 2 | 2 | 0.25 | 1.2 | 50 | 50 | 100 | 100 | 100 | | 4 | 63 |
| 2N3133 | TO-5 | 50 | 35 | 4 | 35 | 4 | 35 | 50 | 30 | 10 | 150 | 1 | 1 | 0.6 | 1.5 | 150 | 50 | 150 | 150 | 150 | | 2 | 63 |
| 2N3134 | TO-5 | 50 | 35 | 4 | 35 | 4 | 35 | 50 | 30 | 50 | 150 | 1 | 1 | 0.6 | 1.5 | 150 | 50 | 150 | 150 | 150 | | 2 | 63 |
| 2N3135 | TO-18 | 50 | 35 | 4 | 35 | 4 | 35 | 50 | 30 | 25 | 150 | 1 | 1 | 0.6 | 1.5 | 150 | 50 | 150 | 150 | 150 | | 2 | 63 |
| 2N3136 | TO-18 | 50 | 35 | 4 | 35 | 4 | 35 | 50 | 30 | 40 | 120 | 10 | 10 | 0.6 | 1.5 | 150 | 50 | 150 | 150 | 150 | | 2 | 63 |
| 2N3250 | TO-18 | 50 | 40 | 5 | 40 | 5 | 40 | 50 | 30 | 25 | 150 | 1 | 1 | 0.6 | 1.5 | 150 | 50 | 157 | 157 | 157 | | 2 | 63 |
| 2N3250A | TO-18 | 60 | 60 | 5 | 60 | 5 | 60 | 50 | 30 | 15 | 50 | 1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 225 | 225 | 225 | 6 | 5/6 | 69 |
| | | | | | | | | | | 50 | 150 | 10 | 1 | 0.5 | 1.2 | 50 | 10 | 225 | 225 | 225 | 6 | 5/6 | 69 |
| | | | | | | | | | | 45 | 1 | 1 | 1 | 0.5 | 1.2 | 50 | 10 | 225 | 225 | 225 | 6 | 5/6 | 69 |
| | | | | | | | | | | 40 | 0.1 | 1 | 1 | 0.5 | 1.2 | 50 | 10 | 225 | 225 | 225 | 6 | 5/6 | 69 |
| | | | | | | | | | | 15 | 50 | 1 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 6 | 6 | 6 | 5/6 | 69 |
| | | | | | | | | | | 50 | 150 | 10 | 1 | 0.25 | 0.6 | 0.9 | 10 | 6 | 6 | 6 | 6 | 5/6 | 69 |
| | | | | | | | | | | 45 | 1 | 1 | 1 | 0.5 | 1.2 | 50 | 10 | 225 | 225 | 225 | 6 | 5/6 | 69 |
| | | | | | | | | | | 40 | 0.1 | 1 | 1 | 0.5 | 1.2 | 50 | 10 | 225 | 225 | 225 | 6 | 5/6 | 69 |

TEST CONDITIONS:

(1) I_C = 300mA, V_{CC} = 10V, I_{B1} = I_{B2} = 30mA. (2) I_C = 150mA, V_{CC} = 6V, I_{B1} = I_{B2} = 15mA. (3) I_C = 300mA, V_{CC} = 15V, I_{B1} = I_{B2} = 30mA. (4) I_C = 300mA, V_{CC} = 30V, I_{B1} = I_{B2} = 30mA.
 (5) I_C = 10mA, V_{CC} = 3V, I_{B1} = I_{B2} = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 100kHz. (7) I_C = 30 μA, V_{CE} = 5V, f = 1kHz. (8) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (9) I_C = 250 μA, V_{CE} = 5V, f = 1kHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 50mA, V_{CC} = 30V, I_{B1} = I_{B2} = 5mA. (12) I_C = 150mA, V_{CC} = 30V, I_{B1} = I_{B2} = 15mA. (13) I_C = 50mA, V_{CC} = 10V, I_{B1} = I_{B2} = 5mA.



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICBO (mA) Max | VCB (V) @ | hFE @ | | VCE (V) & | VBE(SAT) (V) & | | IC (mA) @ | Cob (pF) Max | fT (MHz) @ | | IC (mA) Max | toff (ns) Max | NF (dB) Min | Test Condition | Process No. |
|-------------------------|---------------|-----------------|-----------------|-----------------|------------------|--------------|-------|-----|--------------|-------------------|------|--------------|-----------------|---------------|-----|----------------|------------------|----------------|----------------|-------------|
| | | | | | | | Min | Max | | Max | Min | | | Min | Max | | | | | |
| 2N3250A J, JTX, JTXV | TO-18 | 60 | 60 | 5 | | | 15 | 50 | 1 | 0.2 | 0.6 | 10 | 6 | 250 | 10 | 225 | 6 | 5/6 | 63 | |
| | | | | | | | 50 | 150 | 1 | | | | | | | | | | | |
| 2N3251 | TO-18 | 50 | 40 | 5 | | | 30 | 50 | 1 | 0.25 | 0.6 | 10 | 6 | 300 | 20 | 250 | 6 | 5/6 | 69 | |
| | | | | | | | 100 | 300 | 1 | | | | | | | | | | | |
| 2N3251A | TO-18 | 60 | 60 | 5 | | | 30 | 50 | 1 | 0.25 | 0.6 | 10 | 6 | 300 | 10 | 250 | 6 | 5/6 | 69 | |
| | | | | | | | 100 | 300 | 1 | | | | | | | | | | | |
| 2N3251A J, JTX, JTXV | TO-18 | 60 | 60 | 5 | | | 30 | 50 | 1 | 0.25 | 0.6 | 10 | 6 | 300 | 10 | 250 | 6 | 5/6 | 69 | |
| | | | | | | | 90 | 300 | 1 | | | | | | | | | | | |
| 2N3502 | TO-5 | 45 | 45 | 5 | 10 | 30 | 50 | 500 | 10 | 0.25 | 1.0 | 50 | 8 | 200 | 50 | 100 | 4 | 4/7 | 63 | |
| | | | | | | | 100 | 300 | 150 | | | | | | | | | | | |
| 2N3503 | TO-5 | 60 | 60 | 5 | 10 | 50 | 50 | 500 | 10 | 0.25 | 1 | 50 | 8 | 200 | 50 | 100 | 4 | 4/7 | 63 | |
| | | | | | | | 140 | 10 | 10 | 0.4 | 1.3 | 150 | | | | | | | | |
| 2N3504 | TO-18 | 45 | 45 | 5 | 10 | 30 | 50 | 500 | 10 | 0.25 | 1 | 50 | 8 | 200 | 50 | 100 | 4 | 4/7 | 63 | |
| | | | | | | | 140 | 10 | 10 | 0.4 | 1.3 | 150 | | | | | | | | |
| 2N3505 | TO-18 | 60 | 60 | 5 | 10 | 50 | 50 | 500 | 10 | 0.25 | 1 | 50 | 8 | 200 | 50 | 100 | 4 | 4/7 | 63 | |
| | | | | | | | 140 | 10 | 10 | 0.4 | 1.3 | 150 | | | | | | | | |
| 2N3638 | TO-92 (72) | | | | | | 100 | 300 | 150 | 10 | 0.25 | 1 | 50 | 8 | 200 | 50 | 100 | 4 | 4/7 | 63 |
| | | | | | | | 140 | 10 | 10 | 0.4 | 1.3 | 150 | | | | | | | | |

Same as PN3638, see page 2-16 for explanation



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) | | V _{CE0} (V) | | V _{EBO} (V) | | I _{CBO} (mA) @ | | V _{CE} (V) & V _{CE} (V) | | I _C (mA) @ | | V _{BE} (SAT) & (V) @ | | I _C (mA) @ | | f _T (MHz) @ | | t _{off} (ns) | | NF (dB) | Test Condition | Process No. |
|----------|------------|--|-----|----------------------|-----|----------------------|-----|-------------------------|-----|---|------|-----------------------|-----|-------------------------------|-----|-----------------------|-----|------------------------|-----|-----------------------|-----|---------|----------------|-------------|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | |
| 2N3638A | TO-92 (72) | Same as PN3638A, see page 2-17 for explanation | | | | | | | | | | | | | | | | | | | | | | 63 |
| 2N3644 | TO-92 (72) | Same as PN3644, see page 2-17 for explanation | | | | | | | | | | | | | | | | | | | | | | 63 |
| 2N3702 | TO-92 (74) | 40 | 25 | 5 | 100 | 20 | 60 | 300 | 50 | 5 | 0.25 | 50 | 12 | 100 | | | | | | | | | | 63 |
| 2N3703 | TO-92 (74) | 50 | 30 | 5 | 100 | 20 | 30 | 150 | 50 | 5 | 0.25 | 50 | 12 | 100 | | | | | | | | | | 63 |
| 2N3905 | TO-92 (72) | 40 | 40 | 5 | | | 15 | 100 | 1 | 0.25 | 0.65 | 0.85 | 10 | 4.5 | 200 | 10 | 260 | 5 | 5/8 | | | | | 66 |
| 2N3906 | TO-92 (72) | 40 | 40 | 5 | 30 | 100 | 1 | 100 | 1 | 0.25 | 0.65 | 0.85 | 10 | 4.5 | 250 | 10 | 300 | 4 | 5/8 | | | | 66 | |
| 2N4121 | TO-92 (72) | Same as PN4121, see page 2-17 for explanation | | | | | | | | | | | | | | | | | | | | | | 66 |
| 2N4122 | TO-92 (72) | Same as PN4122, see page 2-17 for explanation | | | | | | | | | | | | | | | | | | | | | | 66 |
| 2N4125 | TO-92 (72) | 30 | 30 | 4 | 50 | 20 | 25 | 50 | 1 | 0.4 | 0.95 | 50 | 4.5 | 200 | 10 | 5 | 8 | | | | | | 66 | |
| 2N4126 | TO-92 (72) | 25 | 25 | 4 | 50 | 20 | 60 | 150 | 2 | 0.4 | 0.95 | 50 | 4.5 | 250 | 10 | 4 | 8 | | | | | | 66 | |
| 2N4142 | TO-92 (72) | Same as PN4142, see page 2-17 for explanation | | | | | | | | | | | | | | | | | | | | | | 63 |
| 2N4143 | TO-92 (72) | Same as PN4143, see page 2-17 for explanation | | | | | | | | | | | | | | | | | | | | | | 63 |
| 2N4290 | TO-92 (74) | 30 | 20 | 5 | 500 | 20 | 50 | 300 | 100 | 10 | 0.4 | 1.5 | 100 | 10 | 100 | 10 | | | | | | | | 63 |

TEST CONDITIONS:

(1) I_C = 300mA, V_{CC} = 10V, I_B¹ = I_B² = 30mA. (2) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA. (3) I_C = 300mA, V_{CC} = 15V, I_B¹ = I_B² = 30mA. (4) I_C = 300mA, V_{CC} = 30V, I_B¹ = I_B² = 30mA.
 (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 100kHz. (7) I_C = 30 μA, V_{CE} = 5V, f = 1kHz. (8) I_C = 100 μA, V_{CE} = 5V; f = 1kHz. (9) I_C = 250 μA, V_{CE} = 5V, f = 1kHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 50mA, V_{CC} = 30V, I_B¹ = I_B² = 5mA. (12) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (13) I_C = 50mA, V_{CC} = 10V, I_B¹ = I_B² = 5mA.

GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CB} (V) Min | V _{CE} (V) Min | V _{EBO} (V) Min | I _{CB} (mA) Max | V _{CB} (V) Max | h _{FE} Min | I _C (mA) Max | V _{CE} (V) Max | V _{CE(SAT)} & V _{BE(SAT)} | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) | | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Min | Test Condition | Process No. | |
|----------|---------------|---|----------------------------|-----------------------------|-----------------------------|----------------------------|------------------------|----------------------------|----------------------------|---|------------|----------------------------|-----------------------------|----------------------|-----|----------------------------|------------------------------|----------------|----------------|-------------|-----|
| | | | | | | | | | | (V) Max | (V) Min | | | Min | Max | | | | | | Min |
| 2N4291 | TO-92 (74) | 40 | 30 | 6 | 200 | 30 | 100 | 300 | 0.4 | 1.5 | 100 | 10 | 10 | 100 | | 10 | | | | 63 | |
| 2N4402 | TO-92 (72) | 40 | 40 | 5 | | | 20 | 500 | 0.4 | 0.7 | 0.95 | 150 | 10 | 150 | | 20 | 255 | | 4 | 63 | |
| 2N4403 | TO-92 (72) | 40 | 40 | 5 | | | 50 | 150 | 0.4 | 0.75 | 1.3 | 500 | | 200 | | 20 | 255 | | 4 | 63 | |
| 2N4916 | TO-92 (72) | Same as PN4916, see page 2-18 for explanation | | | | | | | | | | | | | | | | | | | 66 |
| 2N4917 | TO-92 (72) | Same as PN4917, see page 2-18 for explanation | | | | | | | | | | | | | | | | | | | 66 |
| 2N4971 | TO-92 (72) | Same as PN2906, see page 2-16 for explanation | | | | | | | | | | | | | | | | | | | 63 |
| 2N4972 | TO-92 (72) | Same as PN2907, see page 2-16 for explanation | | | | | | | | | | | | | | | | | | | 63 |
| 2N5138 | TO-92 (72) | Same as PN5138, see page 2-18 for explanation | | | | | | | | | | | | | | | | | | | 66 |
| 2N5139 | TO-92 (72) | Same as PN5139, see page 2-18 for explanation | | | | | | | | | | | | | | | | | | | 66 |
| 2N5142 | TO-92 (72) | Same as PN5142, see page 2-18 for explanation | | | | | | | | | | | | | | | | | | | 63 |
| 2N5143 | TO-92 (72) | Same as PN5143, see page 2-18 for explanation | | | | | | | | | | | | | | | | | | | 63 |
| 2N5221 | TO-92 (72) | 15 | 15 | 3 | 100 | 10 | 30 | 600 | 0.5 | 1.1 | 150 | 15 | 15 | 100 | | 20 | | | | 63 | |
| 2N5226 | TO-92 (72) | 25 | 25 | 4 | 300 | 15 | 30 | 600 | 0.8 | 1.0 | 100 | 20 | 20 | 50 | | 20 | | | | 63 | |
| 2N5356 | TO-92 (74) | 25 | 25 | 4 | 100 | 25 | 40 | 120 | 0.25 | | 50 | 8 | 8 | | | | | | | 63 | |
| 2N5355 | TO-92 (74) | 25 | 25 | 4 | 100 | 25 | 100 | 300 | 0.25 | | 50 | 8 | 8 | | | | | | | 63 | |
| 2N5365 | TO-92 (74) | 40 | 40 | 4 | 100 | 40 | 20 | 300 | 0.25 | 1.1 | 50 | 8 | 8 | | | | | | | 63 | |
| | | | | | | | 32 | 2 | 1.0 | 2.0 | 300 | | | | | | | | | | |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{BE} (V) Min | I _{CEO} (mA) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) | | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Min | Test Condition | Process No. |
|----------|------------|--|----------------------------|------------------------------|---------------------------------|--------------------------|-----|----------------------------|-----------------------------|----------------------|------|----------------------------|------------------------------|----------------|----------------|-------------|
| | | | | | | Min | Max | | | Min | Max | | | | | |
| 2N5366 | TO-92 (74) | 40 | 40 | 100 | 40 | 300 | 5 | 1 | 8 | 1.1 | 50 | 300 | | | | 63 |
| | | | | | | | | | | | | | | | | |
| 2N5400 | TO-92 (72) | 130 | 120 | 100 | 40 | 50 | 5 | 5 | 6 | 1.0 | 10 | 400 | | 8 | 9 | 74 |
| | | | | | | | | | | | | | | | | |
| 2N5401 | TO-92 (72) | 160 | 150 | 50 | 50 | 50 | 5 | 5 | 6 | 1.0 | 10 | 300 | | 8 | 9 | 74 |
| | | | | | | | | | | | | | | | | |
| 2N5817 | TO-92 (77) | 50 | 40 | 100 | 25 | 500 | 2 | 2 | 15 | 1.2 | 500 | 100 | | | | 63 |
| | | | | | | | | | | | | | | | | |
| EN2907 | TO-92 (72) | Same as PN2907, see page 2-16 for explanation | | | | | | | | | | | | | | |
| MPSL51 | TO-92 (72) | 100 | 100 | 1 | 40 | 250 | 50 | 5 | 8 | 1.2 | 10 | 60 | | | | 74 |
| | | | | | | | | | | | | | | | | |
| MPS3638 | TO-92 (72) | Same as PN3638, see page 2-16 for explanation | | | | | | | | | | | | | | |
| MPS3638A | TO-92 (72) | Same as PN3638A, see page 2-17 for explanation | | | | | | | | | | | | | | |
| MPS3644 | TO-92 (72) | Same as PN3644, see page 2-17 for explanation | | | | | | | | | | | | | | |
| MPS3645 | TO-92 (72) | Same as PN3645, see page 2-17 for explanation | | | | | | | | | | | | | | |
| MPS3702 | TO-92 (72) | 40 | 25 | 5 | 100 | 20 | 60 | 300 | 50 | 5 | 0.25 | 50 | 12 | 100 | 50 | 63 |
| | | | | | | | | | | | | | | | | |
| MPS3703 | TO-92 (72) | 50 | 30 | 5 | 100 | 20 | 30 | 150 | 50 | 5 | 0.25 | 50 | 12 | 100 | 50 | 63 |
| | | | | | | | | | | | | | | | | |
| MPS6516 | TO-92 (72) | 40 | 40 | 4 | 50 | 30 | 60 | 100 | 10 | 10 | 0.5 | 50 | 4 | | | 66 |
| | | | | | | | | | | | | | | | | |
| MPS6518 | TO-92 (72) | 40 | 40 | 4 | 500 | 30 | 90 | 100 | 10 | 10 | 0.5 | 50 | 4 | | | 66 |
| | | | | | | | | | | | | | | | | |
| MPS6522 | TO-92 (72) | 25 | 4 | 50 | 20 | 400 | 2 | 10 | 10 | 0.5 | 50 | 4 | 3 | 10 | | 66 |
| | | | | | | | | | | | | | | | | |

TEST CONDITIONS:

(1) I_C = 300mA, V_{CC} = 10V, I_B¹ = I_B² = 30mA, (2) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA, (3) I_C = 300mA, V_{CC} = 15V, I_B¹ = I_B² = 30mA, (4) I_C = 300mA, V_{CC} = 30V, I_B¹ = I_B² = 30mA, (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA, (6) I_C = 100 μA, V_{CE} = 5V, f = 100kHz, (7) I_C = 30 μA, V_{CE} = 5V, f = 1kHz, (8) I_C = 100 μA, V_{CE} = 5V, f = 1kHz, (9) I_C = 250 μA, V_{CE} = 5V, f = 1kHz, (10) I_C = 10 μA, V_{CE} = 5V, f = 1kHz, (11) I_C = 50mA, V_{CC} = 30V, I_B¹ = I_B² = 5mA, (12) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA, (13) I_C = 50mA, V_{CC} = 10V, I_B¹ = I_B² = 5mA.

GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CBO} (mA) Max | V _{CB} (V) Min | h _{FE} @ I _C & V _{CE} Min Max | V _{CE(SAT)} (V) | | V _{BE(SAT)} (V) | | I _C @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Min | Test Condition | Process No. |
|----------|---------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|----------------------------|---|------------------------------|----------------------|--------------------------|--------------|------------------------------|-----------------------------|---------------------------------|----|----------------------------|------------------------------|----------------|----------------|-------------|
| | | | | | | | | Max | Min | Max | Min | | | | | | | | | |
| MPS6533 | TO-92 (72) | 40 | 40 | 4 | 50 | 30 | 25 40 30 | 500 100 10 | 10 1 | 0.5 | 1.0 | 100 | 6 | | | | | | | 63 |
| MPS6534 | TO-92 (72) | 40 | 40 | 4 | 50 | 30 | 50 90 60 | 500 100 10 | 10 1 | 0.3 | 1.0 | 100 | 6 | | | | | | | 63 |
| MPS6535 | TO-92 (72) | 30 | 30 | 4 | 100 | 20 | 30 | 100 | 1 | 0.5 | 1.2 | 100 | 6 | | | | | | | 63 |
| NS3905 | TO-18 | 40 | 40 | 5 | | | 15 30 50 40 30 | 100 50 10 1 0.1 | 1 | 0.25 0.4 | 0.85 0.95 | 10 50 | 4.5 | 200 | 10 | 260 | 5 | 5/8 | | 66 |
| NS3906 | TO-18 | 40 | 40 | 5 | | | 60 100 80 60 | 100 50 1 0.1 | 1 | 0.25 0.4 | 0.85 0.95 | 10 50 | 4.5 | 250 | 10 | 300 | 4 | 5/8 | | 66 |
| PN2906 | TO-92 (72) | 60 | 40 | 5 | 20 | 50 | 20 40 35 25 20 | 500 150 10 1 0.1 | 10 10 10 10 | 0.4 1.6 | 1.3 2.6 | 150 500 | 8 | 200 | 50 | 100 | | 2 | | 63 |
| PN2906A | TO-92 (72) | 60 | 60 | 5 | 10 | 50 | 40 40 40 40 | 500 150 10 0.1 | 10 10 10 10 | 0.4 1.6 | 1.3 2.6 | 150 500 | 8 | 200 | 50 | 100 | | 2 | | 63 |
| PN2907 | TO-92 (72) | 60 | 40 | 5 | 20 | 50 | 30 100 75 50 35 | 500 300 10 1 0.1 | 10 10 10 10 | 0.4 1.6 | 1.3 2.6 | 150 500 | 8 | 200 | 50 | 100 | | 2 | | 63 |
| PN2907A | TO-92 (72) | 60 | 60 | 5 | 20 | 50 | 50 100 100 75 | 500 300 10 0.1 | 10 10 10 10 | 0.4 1.6 | 1.3 2.6 | 150 500 | 8 | 200 | 50 | 100 | | 2 | | 63 |
| PN3638 | TO-92 (72) | 25 | 25 | 4 | 35* | 15 | 20 20 30 | 300 50 10 | 2 1 10 | 0.25 1.0 | 1.1 0.8 | 50 300 | 20 | 100 | 50 | 170 | | 1 | | 63 |



GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) @ I _C | h _{FE} @ I _C & V _{CE} (V) | | V _{CE(SAT)} & V _{BE(SAT)} @ I _C (mA) | | C _{ob} (pF) Max | f _T (MHz) @ I _C (mA) | | t _{off} (ns) Max | NF (dB) Min | Test Condition | Process No. | |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|---|--|-----|---|------|-----------------------------|--|-----|------------------------------|----------------|----------------|-------------|-----|
| | | | | | | | Min | Max | Min | Max | | Min | Max | | | | | Min |
| PN3638A | TO-92 (72) | 25 | 25 | 4 | 25* | 15 | 20 | 300 | 2 | 0.25 | 1.1 | 50 | 10 | 150 | 50 | 170 | 1 | 63 |
| | | | | | | | 100 | 50 | 1 | 1.0 | 0.8 | 2.0 | 300 | | | | | |
| PN3644 | TO-92 (72) | 45 | 45 | 5 | 35* | 30 | 20 | 300 | 2 | 0.25 | 1.0 | 50 | 8 | 200 | 20 | 100 | 4 | 63 |
| | | | | | | | 100 | 300 | 150 | 10 | 0.4 | 1.3 | 150 | | | | | |
| PN3645 | TO-92 (72) | 60 | 60 | 5 | 35* | 50 | 20 | 300 | 2 | 0.25 | 1.0 | 50 | 8 | 200 | 20 | 100 | 4 | 63 |
| | | | | | | | 80 | 240 | 50 | 1 | 0.4 | 1.3 | 150 | | | | | |
| PN4121 | TO-92 (72) | 40 | 40 | 5 | 25* | 30 | 15 | 50 | 1 | 0.13 | 0.75 | 1 | 4.5 | 400 | 10 | 150 | 4 | 66 |
| | | | | | | | 70 | 200 | 10 | 1 | 0.14 | 0.7 | 0.9 | 10 | | | | |
| PN4122 | TO-92 (72) | 40 | 40 | 5 | 25* | 30 | 30 | 50 | 1 | 0.13 | 0.75 | 1 | 4.5 | 450 | 10 | 150 | 4 | 66 |
| | | | | | | | 150 | 300 | 10 | 1 | 0.14 | 0.7 | 0.9 | 10 | | | | |
| PN4142 | TO-92 | 60 | 40 | 5 | | | 20 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 100 | 12 | 63 |
| | | | | | | | 20 | 150 | 1 | 1.6 | 2.6 | 500 | | | | | | |
| PN4143 | TO-92 (72) | 60 | 40 | 5 | | | 30 | 500 | 10 | 0.4 | 1.3 | 150 | 8 | 200 | 50 | 100 | 12 | 63 |
| | | | | | | | 50 | 150 | 1 | 1.6 | 2.6 | 500 | | | | | | |

TEST CONDITIONS:

(1) I_C = 300mA, V_{CC} = 10V, I_B¹ = I_B² = 30mA, (2) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA, (3) I_C = 300mA, V_{CC} = 15V, I_B¹ = I_B² = 30mA, (4) I_C = 300mA, V_{CC} = 30V, I_B¹ = I_B² = 30mA, (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA, (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz, (7) I_C = 30 μA, V_{CE} = 5V, f = 1kHz, (8) I_C = 100 μA, V_{CE} = 5V, f = 1kHz, (9) I_C = 250 μA, V_{CE} = 5V, f = 1kHz, (10) I_C = 10 μA, V_{CE} = 5V, f = 1kHz, (11) I_C = 50mA, V_{CC} = 30V, I_B¹ = I_B² = 5mA, (12) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA, (13) I_C = 50mA, V_{CC} = 10V, I_B¹ = I_B² = 5mA.

GENERAL PURPOSE AMPS AND SWITCHES (Continued)

| Type No. | Case Style | V _{CEO} (V) | | V _{BO} (V) | | I _{CBO} (mA) @ (V) | | h _{FE} @ (mA) (V) | | V _{CE(SAT)} & V _{BE(SAT)} (V) @ (mA) | | C _{ob} (pF) | | f _T (MHz) | | I _C (mA) | | t _{off} (ns) | | NF (dB) | Test Condition | Process No. |
|----------|-------------|----------------------|-----|---------------------|-----|-----------------------------|-----|----------------------------|-----|--|-----|----------------------|------|----------------------|-----|---------------------|-----|-----------------------|-----|---------|----------------|-------------|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | |
| PN4916 | TO-92 (72) | 30 | | 5 | 15 | 25* | | 15 | 200 | 50 | 1 | 0.13 | 0.75 | 4.5 | 400 | 10 | 150 | 4 | | | 13/8 | 66 |
| PN4917 | TO-92 (72) | 30 | | 5 | 15 | 25* | | 30 | 300 | 50 | 1 | 0.13 | 0.75 | 4.5 | 450 | 10 | 150 | 4 | | | 13/8 | 66 |
| PN5138 | TO-92 (72) | 30 | | 5 | 20 | 50 | | 50 | 10 | 10 | 10 | 0.3 | 1.0 | 7 | 30 | 0.5 | | | | | | 66 |
| PN5139 | TO-92 (72) | 20 | | 5 | 15 | 50* | | 15 | 50 | 10 | 10 | 0.2 | 1.0 | 5 | 300 | 10 | 200 | | | | 13 | 66 |
| PN5142 | TO-92 (72) | 20 | | 4 | 12 | 50* | | 30 | 300 | 10 | 10 | 0.5 | 1.25 | 10 | 100 | 50 | 200 | | | | 1 | 63 |
| PN5143 | TO-92 (72) | 20 | | 4 | 12 | 50* | | 15 | 300 | 10 | 10 | 0.5 | 1.5 | 10 | 100 | 50 | 200 | | | | 1 | 63 |
| TN2905 | TO-92+ (91) | 60 | | 5 | 50 | 20 | | 30 | 500 | 10 | 10 | 0.4 | 1.3 | 8 | 200 | 50 | 100 | | | | 2 | 63 |
| TN2905A | TO-92+ (91) | 60 | | 5 | 50 | 10 | | 50 | 500 | 10 | 10 | 0.4 | 1.3 | 8 | 200 | 50 | 100 | | | | 2 | 63 |

TEST CONDITIONS:

- (1) I_C = 30mA, V_{CE} = 10V, I_B¹ = I_B² = 30mA. (2) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA. (3) I_C = 300mA, V_{CE} = 15V, I_B¹ = I_B² = 30mA. (4) I_C = 300mA, V_{CC} = 30V, I_B¹ = I_B² = 30mA.
 (5) I_C = 10mA, V_{CE} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 30 μA, V_{CE} = 5V, f = 1kHz. (8) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (9) I_C = 250 μA, V_{CE} = 5V, f = 1kHz. (10) I_C = 10 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 50mA, V_{CC} = 30V, I_B¹ = I_B² = 5mA. (12) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (13) I_C = 50mA, V_{CC} = 10V, I_B¹ = I_B² = 5mA.



MEDIUM POWER

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) | h _{FE} @ I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(SAT)} @ I _C | | C _{ob} (pF) Max | f _T (MHz) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|------------------|------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|---------------------|--|-----|--|------|-----------------------------|----------------------|-----|------------------------------|----------------|----------------|-------------|
| | | | | | | | Min | Max | Min | Max | | Min | Max | | | | |
| 2N3634 | TO-39 | 140 | 140 | 5 | 100 | 100 | 25 | 150 | 0.3 | 0.8 | 10 | 150 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 50 | 50 | 0.5 | 0.65 | 0.9 | 50 | | | | | |
| 2N3634 J, JTX | TO-39 | 140 | 140 | 5 | 100 | 100 | 30 | 150 | 0.3 | 0.8 | 10 | 150 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 50 | 50 | 0.6 | 0.65 | 0.9 | 50 | | | | | |
| 2N3635 | TO-39 | 140 | 140 | 5 | 100 | 100 | 50 | 150 | 0.3 | 0.8 | 10 | 200 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 100 | 300 | 0.5 | 0.65 | 0.9 | 50 | | | | | |
| 2N3635 J, JTX | TO-39 | 140 | 140 | 5 | 100 | 100 | 60 | 150 | 0.3 | 0.8 | 10 | 200 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 100 | 300 | 0.6 | 0.65 | 0.9 | 50 | | | | | |
| 2N3636 | TO-39 | 175 | 175 | 5 | 100 | 100 | 25 | 150 | 0.3 | 0.8 | 10 | 150 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 50 | 50 | 0.5 | 0.65 | 0.9 | 50 | | | | | |
| 2N3636 J, JTX | TO-39 | 175 | 175 | 5 | 100 | 175 | 30 | 150 | 0.3 | 0.8 | 10 | 150 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 50 | 150 | 0.6 | 0.65 | 0.9 | 50 | | | | | |
| 2N3637 | TO-39 | 175 | 175 | 5 | 100 | 100 | 50 | 150 | 0.3 | 0.8 | 10 | 200 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 100 | 300 | 0.5 | 0.65 | 0.9 | 50 | | | | | |
| 2N3637 J, JTX | TO-39 | 175 | 175 | 5 | 100 | 175 | 60 | 150 | 0.3 | 0.8 | 10 | 200 | 30 | 600 | 3 | 1/2 | 73 |
| | | | | | | | 100 | 300 | 0.6 | 0.65 | 0.9 | 50 | | | | | |

TEST CONDITIONS:

(1) I_C = 50mA, V_{CC} = 100V, I_B = I_B² = 5mA. (2) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (3) I_C = 500mA, V_{CC} = 30V, I_B = I_B² = 50mA. (4) I_C = 150mA, V_{CC} = 30V, I_B = I_B² = 15mA. (5) I_C = 100 μA, V_{CC} = 10V, f = 1kHz.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{BE0} (V) Min | I _{CBO} (mA) Max | V _{CEB} (V) | h _{FE} | | I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(SAT)} | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|---|--------------------------|---------------------------|----------------------|-----------------|-----|----------------------------------|---------------------|---|------|-------------------------|--------------------------|----------------------|-----|---------------------------|-------------|----------------|-------------|-----|
| | | | | | | Min | Max | I _C (mA) | V _{CE} (V) | Max | Min | | | Min | Max | | | | | Min |
| 2N4030 | TO-39 | 60 | 60 | 50 | 50 | 15 | 25 | 1A | 5 | 1.0 | 0.5 | 1A | 20 | 100 | 400 | 400 | | 3 | 67 | |
| 2N4031 | TO-39 | 80 | 80 | 50 | 60 | 10 | 25 | 1A | 5 | 0.5 | 0.15 | 500 | 20 | 100 | 400 | 400 | | 3 | 67 | |
| 2N4032 | TO-39 | 60 | 60 | 50 | 50 | 40 | 100 | 100 | 5 | 1 | 0.15 | 1A | 20 | 150 | 500 | 400 | | 3 | 67 | |
| 2N4033 | TO-39 | 80 | 80 | 50 | 60 | 25 | 70 | 1A | 5 | 0.5 | 0.15 | 500 | 20 | 150 | 500 | 400 | | 3 | 67 | |
| 2N4036 | TO-39 | 90 | 65 | 20 | 60 | 20 | 40 | 500 | 10 | 0.6 | | 30 | 60 | 60 | 700 | | | 4 | 67 | |
| 2N4037 | TO-39 | 60 | 40 | 250 | 60 | 50 | 150 | 150 | 10 | 1.4 | | 30 | 60 | 60 | 50 | | | | 67 | |
| 2N4234 | TO-39 | 40 | 40 | 100 μA | 40 | 10 | 30 | 1A | 1 | 0.6 | | 100 | 3 | 3 | 100 | | | | 67 | |
| 2N4235 | TO-39 | 60 | 60 | 100 μA | 60 | 10 | 30 | 1A | 1 | 0.6 | | 100 | 3 | 3 | 100 | | | | 67 | |
| 2N4236 | TO-39 | 80 | 80 | 100 μA | 80 | 10 | 30 | 1A | 1 | 0.6 | | 100 | 3 | 3 | 100 | | | | 67 | |
| 2N4314 | TO-39 | 90 | 65 | 250 | 60 | 50 | 150 | 150 | 10 | 1.4 | | 30 | 60 | 60 | 50 | | | | 67 | |
| 2N4354 | TO-92 (72) | Same as PN4354, see page 2-25 for explanation | | | | | | | | | | | | | | | | | | |
| 2N4355 | TO-92 (72) | Same as PN4355, see page 2-25 for explanation | | | | | | | | | | | | | | | | | | |



MEDIUM POWER (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICBO (nA) Max | VCB (V) Max | hFE @ IC (mA) & VCE (V) | | VCE(SAT) (V) Max | VBE(SAT) (V) @ IC (mA) | | C-ob (pF) Max | fT (MHz) @ IC (mA) | | toff (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|---|--------------|--------------|---------------|-------------|-------------------------|-----|------------------|------------------------|-----|---------------|--------------------|-----|---------------|-------------|----------------|-------------|
| | | | | | | | Min | Max | | Min | Max | | Min | Max | | | | |
| 2N4356 | TO-92 (72) | Same as PN4356, see page 2-25 for explanation | | | | | | | | | | | | | | | | 67 |
| 2N6554 | TO-202 (35) | 60 | 60 | 5 | 100 | 40 | 500 | 1 | 1.0 | 1A | 18 | 75 | 250 | 100 | | | | 78 |
| | | | | | | | 25 | 1 | | | | | | | | | | |
| 2N6555 | TO-202 (35) | 80 | 80 | 5 | 100 | 60 | 500 | 1 | 1.0 | 1A | 18 | 75 | 250 | 100 | | | | 78 |
| | | | | | | | 25 | 1 | | | | | | | | | | |
| 2N6556 | TO-202 (35) | 100 | 100 | 5 | 100 | 80 | 500 | 1 | 1.0 | 1A | 18 | 75 | 250 | 100 | | | | 78 |
| | | | | | | | 25 | 1 | | | | | | | | | | |
| 40319 | TO-39 | | 40 | | 250 | 15 | 35 | 200 | 50 | 4 | 1.4 | | | | | | | 67 |
| 92PE77A | TO-92+ (90) | | 45 | | 100 | 60 | 500 | 2 | 0.5 | 500 | 30 | 50 | 200 | | | | | 78 |
| | | | | | | | 40 | 2 | | | | | | | | | | |
| 92PE77B | TO-92+ (90) | | 60 | | 100 | 80 | 500 | 2 | 0.5 | 500 | 30 | 50 | 200 | | | | | 78 |
| | | | | | | | 40 | 2 | | | | | | | | | | |
| 92PE77C | TO-92+ (90) | | 80 | | 100 | 100 | 500 | 2 | 0.5 | 500 | 30 | 50 | 200 | | | | | 78 |
| | | | | | | | 40 | 2 | | | | | | | | | | |
| 92PU51 | TO-92+ (91) | | 30 | | 100 | 40 | 50 | 1A | 0.5 | 1A | 30 | 50 | 50 | 50 | | | | 77 |
| | | | | | | | 60 | 100 | | | | | | | | | | |
| 92PU51A | TO-92+ (91) | | 40 | | 100 | 50 | 50 | 1A | 0.5 | 1A | 30 | 50 | 50 | 50 | | | | 77 |
| | | | | | | | 60 | 100 | | | | | | | | | | |
| 92PU55 | TO-92+ (91) | | 60 | | 100 | 40 | 500 | 1 | 0.35 | 250 | 30 | 50 | 200 | | | | | 79 |
| | | | | | | | 20 | 500 | | | | | | | | | | |
| 92PU56 | TO-92+ (91) | | 80 | | 100 | 60 | 500 | 1 | 0.35 | 250 | 30 | 50 | 200 | | | | | 79 |
| | | | | | | | 20 | 500 | | | | | | | | | | |

TEST CONDITIONS:
 (1) IC = 50mA, VCC = 100V, IB¹ = IB² = 5mA, (2) IC = 500 μA, VCE = 10V, f = 1kHz, (3) IC = 500mA, VCC = 30V, IB¹ = IB² = 15mA, (4) IC = 150mA, VCC = 30V, IB¹ = IB² = 15mA, (5) IC = 100 μA, VCC = 10V, f = 1kHz.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EBO} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) Min | h _{FE} Min | h _{FE} Max | I _C & V _{CE} (mA) (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|----------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|----------------------------|------------------------|------------------------|--|---------------------------------|---------------------------------|----------------------------|-----------------------------|-----------------------------|-----------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| 92PU57 | TO-92+ (91) | | 100 | | 100 | 80 | 20 | 500 | 1 | 0.35 | | 250 | 30 | 50 | | 200 | | | | 79 |
| 92PU200 | TO-92+ (91) | 100 | 80 | | 100 | 80 | 100 | 300 | 2 | 0.35 | | 350 | 20 | 500 | | 100 | | | | 79 |
| D41D1 | TO-202 (35) | | 30 | | 100* | 45 | 10 | 150 | 2 | 0.5 | | 500 | | | | | | | | 78 |
| D41D2 | TO-202 (35) | | 30 | | 100* | 45 | 20 | 300 | 2 | 0.5 | | 500 | | | | | | | | 78 |
| D41D4 | TO-202 (35) | | 45 | | 100* | 60 | 10 | 150 | 2 | 0.5 | | 500 | | | | | | | | 78 |
| D41D5 | TO-202 (35) | | 45 | | 100* | 60 | 20 | 150 | 2 | 0.5 | | 500 | | | | | | | | 78 |
| D41D7 | TO-202 (35) | | 60 | | 100* | 75 | 10 | 360 | 2 | 1.0 | | 500 | | | | | | | | 78 |
| D41D8 | TO-202 (35) | | 60 | | 100* | 75 | 20 | 360 | 2 | 1.0 | | 500 | | | | | | | | 78 |
| D41D10 | TO-202 (35) | | 75 | | 100* | 90 | 10 | 150 | 2 | 1.0 | | 500 | | | | | | | | 78 |
| D41D11 | TO-202 (35) | | 75 | | 100* | 90 | 20 | 360 | 2 | 1.0 | | 500 | | | | | | | | 78 |
| D41D13 | TO-202 (35) | | 75 | | 100* | 90 | 50 | 150 | 2 | 1.0 | | 500 | | | | | | | | 78 |
| D41D14 | TO-202 (35) | | 75 | | 100* | 90 | 120 | 360 | 2 | 1.0 | | 500 | | | | | | | | 78 |
| D41E1 | TO-202 (35) | | 30 | | 100* | 40 | 10 | 100 | 2 | 1.0 | | 1 A | | | | | | | | 78 |
| D41E5 | TO-202 (35) | | 60 | | 100* | 70 | 10 | 100 | 2 | 1.0 | | 1 A | | | | | | | | 78 |
| D41E7 | TO-202 (35) | | 80 | | 100* | 90 | 10 | 100 | 2 | 1.0 | | 1 A | | | | | | | | 78 |
| D43C1 | TO-202 (36) | | 30 | | 1 μA* | 30 | 10 | 1 A | 1 | 0.5 | | 1 A | 30 | | | | | | | 77 |
| D43C2 | TO-202 (36) | | 30 | | 1 μA* | 30 | 20 | 120 | 1 | 0.5 | | 1 A | 30 | | | | | | | 77 |
| D43C3 | TO-202 (36) | | 30 | | 1 μA* | 30 | 40 | 200 | 1 | 0.5 | | 1 A | 30 | | | | | | | 77 |
| D43C4 | TO-202 (36) | | 45 | | 1 μA* | 45 | 10 | 200 | 1 | 0.5 | | 1 A | 30 | | | | | | | 77 |



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) @ I _C & V _{CE} | hFE Min | hFE Max @ I _C (mA) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (mA) @ V _{CE(SAT)} Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|-------------|---|--------------------------|---------------------------|--|---------|-------------------------------|------------------------------|------------------------------|--|--------------------------|--------------------------|--------------------------|---------------------------|-------------|----------------|-------------|
| D43C5 | TO-202 (36) | 45 | | 1 μA* | 45 | 20 | 1A | 0.5 | 1.3 | 1A | 30 | | | | | | 77 |
| D43C6 | TO-202 (36) | 45 | | 1 μA* | 45 | 20 | 2A | 0.5 | 1.3 | 1A | 30 | | | | | | 77 |
| D43C7 | TO-202 (36) | 60 | | 1 μA* | 60 | 10 | 1A | 0.5 | 1.3 | 1A | 30 | | | | | | 78 |
| D43C8 | TO-202 (36) | 60 | | 1 μA* | 60 | 20 | 1A | 0.5 | 1.3 | 1A | 30 | | | | | | 78 |
| D43C9 | TO-202 (36) | 60 | | 1 μA* | 60 | 20 | 2A | 0.5 | 1.3 | 1A | 30 | | | | | | 78 |
| D43C10 | TO-202 (36) | 80 | | 10 μA* | 90 | 10 | 1A | 0.5 | 1.3 | 1A | 100 | | | | | | 78 |
| D43C11 | TO-202 (36) | 80 | | 10 μA* | 90 | 20 | 1A | 0.5 | 1.3 | 1A | 100 | | | | | | 78 |
| D43C12 | TO-202 (36) | 80 | | 10 μA* | 90 | 40 | 2A | 0.5 | 1.3 | 1A | 100 | | | | | | 78 |
| MPSA55 | TO-92 (72) | 60 | 4 | 100 | 60 | 50 | 100 | 0.25 | | 100 | | 50 | 100 | | | | 67 |
| MPSA56 | TO-92 (72) | 80 | 4 | 100 | 80 | 50 | 100 | 0.25 | | 100 | | 50 | 100 | | | | 67 |
| MPSA354 | TO-92 (72) | Same as PN4354, see page 2-25 for explanation | | | | | | | | | | | | | | | |
| MPSA355 | TO-92 (72) | Same as PN4355, see page 2-25 for explanation | | | | | | | | | | | | | | | |
| MPSA356 | TO-92 (72) | Same as PN4356, see page 2-25 for explanation | | | | | | | | | | | | | | | |
| MPS6562 | TO-92 (72) | | 5 | 100 | 20 | 50 | 200 | 0.5 | | 500 | 30 | 60 | 10 | | | | 67 |
| MPS6563 | TO-92 (72) | | 5 | 100 | 20 | 50 | 200 | 0.5 | | 350 | 30 | 60 | 10 | | | | 60 |
| NSD202 | TO-202 (35) | 60 | 45 | 100 | 60 | 25 | 1A | 0.2 | 0.9 | 100 | 30 | 60 | 50 | | | | 77 |
| | | | | | | 40 | 500 | 5 | | 5 | | | | | | | |
| | | | | | | 40 | 150 | 5 | | 5 | | | | | | | |
| | | | | | | 40 | 10 | 5 | 0.4 | 1.2 | 500 | | | | | | |

TEST CONDITIONS:

(1) I_C = 50mA, V_{CC} = 100V, I_B¹ = I_B² = 5mA. (2) I_C = 500μA, V_{CE} = 10V, f = 1kHz. (3) I_C = 500mA, V_{CC} = 30V, I_B¹ = I_B² = 50mA. (4) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (5) I_C = 100μA, V_{CC} = 10V, f = 1kHz.



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (nA) Max | V _{CB} (V) @ I _C | h _{FE} @ I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(SAT)} | | C _{ob} (pF) Max | f _T (MHz) @ I _C | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|----------------|-----------------------------|-----------------------------|-----------------------------|------------------------------|---|--|------|---|------|-----------------------------|---------------------------------------|-----|------------------------------|----------------|----------------|-------------|
| | | | | | | | Min | Max | Min | Max | | Min | Max | | | | |
| NSD203 | TO-202 (35) | 60 | 45 | 5 | 100 | 60 | 30 | 1A | 5 | 0.2 | 0.9 | 100 | 30 | 60 | 50 | | 77 |
| | | | | | | | 50 | 500 | 5 | | | | | | | | |
| | | | | | | | 120 | 360 | 100 | 0.4 | 1.2 | 500 | | | | | |
| NSD204 | TO-202 (35) | 100 | 80 | 7 | 100 | 100 | 10 | 1A | 5 | 0.2 | 0.9 | 100 | 30 | 60 | 50 | | 79 |
| | | | | | | | 50 | 150 | 100 | | | | | | | | |
| | | | | | | | 20 | 10 | 5 | 0.5 | 1.2 | 500 | | | | | |
| NSD205 | TO-202 (35) | 100 | 80 | 7 | 100 | 100 | 10 | 1A | 5 | 0.2 | 0.9 | 100 | 30 | 60 | 50 | | 79 |
| | | | | | | | 120 | 360 | 100 | | | | | | | | |
| | | | | | | | 20 | 10 | 5 | 0.5 | 1.2 | 500 | | | | | |
| NSD206 | TO-202 (35) | 140 | 100 | 7 | 100 | 140 | 25 | 500 | 5 | 0.2 | 0.9 | 100 | 30 | 60 | 50 | | 79 |
| | | | | | | | 50 | 150 | 100 | | | | | | | | |
| | | | | | | | 20 | 10 | 5 | 0.5 | 1.2 | 500 | | | | | |
| NSD6180 | TO-202 (35) | | 75 | | 500 | 80 | 10 | 1A | 2 | 0.5 | 1.2 | 500 | 30 | 50 | 50 | | 78 |
| | | | | | | | 40 | 250 | 500 | | | | | | | | |
| | | | | | | | 30 | 50 | 2 | | | | | | | | |
| NSD6181 | TO-202 (35) | | 50 | | 500 | 60 | 10 | 1A | 2 | 0.5 | 1.2 | 500 | 30 | 50 | 50 | | 78 |
| | | | | | | | 40 | 250 | 500 | | | | | | | | |
| | | | | | | | 30 | 50 | 2 | | | | | | | | |
| NSDU51 | TO-202 (35) | 40 | 30 | 5 | 100 | 30 | 50 | 1A | 1 | 0.7 | | 1A | 30 | 50 | 50 | | 77 |
| | | | | | | | 60 | 100 | 1 | | | | | | | | |
| | | | | | | | 55 | 10 | 1 | | | | | | | | |
| NSDU51A | TO-202 (35) | 50 | 40 | 5 | 100 | 40 | 50 | 1A | 1 | 0.7 | | 1A | 30 | 50 | 50 | | 77 |
| | | | | | | | 60 | 100 | 1 | | | | | | | | |
| | | | | | | | 55 | 10 | 1 | | | | | | | | |
| NSDU52 | TO-202 (35) | 60 | 40 | 5 | 100 | 40 | 30 | 500 | 10 | 0.4 | 1.3 | 150 | 20 | 150 | 20 | | 77 |
| | | | | | | | 50 | 300 | 150 | | | | | | | | |
| | | | | | | | 50 | 10 | 10 | | | | | | | | |
| NSDU55 | TO-202 (35) | 60 | 60 | 4 | 100 | 60 | 20 | 500 | 1 | 0.35 | | 250 | 30 | 50 | 200 | | 78 |
| | | | | | | | 50 | 250 | 1 | | | | | | | | |
| | | | | | | | 80 | 50 | 1 | | | | | | | | |
| NSDU56 | TO-202 (35) | 80 | 80 | 4 | 100 | 80 | 20 | 500 | 1 | 0.35 | | 250 | 30 | 50 | 200 | | 79 |
| | | | | | | | 50 | 250 | 1 | | | | | | | | |
| | | | | | | | 80 | 50 | 1 | | | | | | | | |
| NSDU57 | TO-202 (35) | 100 | 100 | 4 | 100 | 100 | 20 | 500 | 1 | 0.35 | | 250 | 30 | 50 | 200 | | 79 |
| | | | | | | | 50 | 250 | 1 | | | | | | | | |
| | | | | | | | 80 | 50 | 1 | | | | | | | | |
| NSE170 | TO-202 (36) | | 40 | | 100 | 60 | 12 | 1.5A | 1 | 0.9 | 1.5 | 1.5A | | 50 | 100 | | 77 |
| | | | | | | | 30 | 500 | 1 | 0.3 | | 500 | | | | | |
| | | | | | | | 50 | 250 | 100 | | | | | | | | |



MEDIUM POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (nA) @ Max | V _{CB} (V) (V) | h _{FE} @ I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(SAT)} | | C _{ob} (pF) Max | f _T (MHz) @ I _C | | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|----------------|-----------------------------|-----------------------------|-----------------------------|--------------------------------|----------------------------|--|-----|---|------|-----------------------------|---------------------------------------|-----|------------------------------|----------------|----------------|-------------|
| | | | | | | | Min | Max | Min | Max | | Min | Max | | | | |
| NSET171 | TO-202 (36) | | 60 | | 100 | 80 | 1 | 12 | 1.5A | 0.9 | 1.5 | 100 | 100 | | | | 78 |
| | | | | | | | | 30 | 500 | 0.3 | 500 | | | | | | |
| PN4354 | TO-92 (72) | 60 | 60 | 5 | 50 | 50 | 10 | 30 | 500 | 0.15 | 0.9 | 30 | 100 | 400 | 3 | 3/5 | 67 |
| | | | | | | | | 40 | 100 | 0.5 | 1.1 | 50 | 500 | | | | |
| PN4355 | TO-92 (72) | 60 | 60 | 5 | 50 | 50 | 10 | 75 | 500 | 0.15 | 0.9 | 30 | 100 | 400 | 3 | 3/5 | 67 |
| | | | | | | | | 100 | 100 | 0.5 | 1.1 | 50 | 500 | | | | |
| PN4356 | TO-92 (72) | 80 | 80 | 5 | 50 | 50 | 10 | 30 | 500 | 0.15 | 0.9 | 30 | 100 | 400 | 3 | 3/5 | 67 |
| | | | | | | | | 40 | 100 | 0.5 | 1.1 | 50 | 500 | | | | |
| TN4036 | TO-92+ (91) | 90 | 65 | 7 | 20 | 60 | 10 | 20 | 500 | 0.65 | 1.4 | 30 | 60 | 700 | | 4 | 67 |
| | | | | | | | | 40 | 140 | | | 50 | 50 | | | | |
| TN4037 | TO-92+ (91) | 60 | 40 | 7 | 250 | 60 | 10 | 50 | 2 | 1.4 | 150 | 30 | 60 | | | | 67 |
| | | | | | | | | 15 | 1 | 10 | 10 | 150 | 50 | | | | |

TEST CONDITIONS:

(1) I_C = 50mA, V_{CC} = 100V, I_B¹ = I_B² = 5mA. (2) I_C = 500 μA, V_{CE} = 10V, f = 1kHz. (3) I_C = 500mA, V_{CC} = 30V, I_B¹ = I_B² = 50mA. (4) I_C = 150mA, V_{CC} = 30V, I_B¹ = I_B² = 15mA. (5) I_C = 100 μA, V_{CC} = 10V, f = 1kHz.

PNP Transistors



POWER

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CEX} * (μ A) Max | V _{CB} (V) @ I _C Max | h _{FE} Min Max | I _C (A) @ I _C Max & V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min Max | I _C (A) @ I _C Max | C _{ob} (pF) Max | f _T (MHz) Min Max | IC (A) @ I _C Max | Process |
|----------|----------------------------------|-----------------------------|-----------------------------|-----------------------------|---|--|-------------------------------|---|---|---|-----------------------------|------------------------------------|-----------------------------------|---------|
| 2N4918 | TO-126 | 40 | | | 100 | 40 | 10 20 40 | 1 0.5 0.05 | 1.3 | 1 | 100 | 3 | 0.25 | 3C |
| 2N4919 | TO-126 | 60 | | | 100 | 60 | 10 20 40 | 1 0.5 0.05 | 1.3 | 1 | 100 | 3 | 0.25 | 3C |
| 2N4920 | TO-126 | 80 | | | 100 | 80 | 10 20 40 | 1 0.5 0.05 | 1.3 | 1 | 100 | 3 | 0.25 | 3C |
| 2N5193 | TO-126 | 40 | | | 100 | 40 | 10 25 | 4 1.5 2 | 0.6 | 1.5 4 | | 2 | 1 | 3E |
| 2N5194 | TO-126 | 60 | | | 100 | 60 | 10 25 | 4 1.5 2 | 0.6 | 1.5 4 | | 2 | 1 | 3E |
| 2N5195 | TO-126 | 80 | | | 100 | 80 | 7 20 | 4 1.5 2 | 0.6 | 1.5 4 | | 2 | 1 | 3E |
| 2N6034 | TO-126 | 40 | | | 500 | 40 | 100 750 500 | 4 2 0.05 | 2.0 | 2 | 200 | 25 | 0.75 | 3J |
| 2N6035 | TO-126 | 60 | | | 500 | 60 | 100 750 500 | 4 2 0.05 | 2.0 | 2 | 200 | 25 | 0.75 | 3J |
| 2N6036 | TO-126 | 80 | | | 500 | 80 | 100 750 500 | 4 2 0.5 | 2.0 | 2 | 200 | 25 | 0.75 | 3J |
| 2N6106 | TO-220 Lead Form + Clip | 70 | | | 100† | 75 | 5 30 | 6.5 2 | 1.0 2.0 | 2 6.5 | 250 | 10 | 0.5 | 5E |
| 2N6107 | TO-220 | 70 | | | 100† | 75 | 5 30 | 6.5 2 | 1.0 2.0 | 2 6.5 | 250 | 10 | 0.5 | 5E |
| 2N6108 | TO-220 Lead Form + Clip | 50 | | | 100† | 56 | 5 30 | 6.5 2.5 | 1.0 2.0 | 2.5 6.5 | 250 | 10 | 0.5 | 5E |
| 2N6109 | TO-220 | 50 | | | 100† | 56 | 5 30 | 6.5 2.5 | 1.0 2.0 | 2.5 6.5 | 250 | 10 | 0.5 | 5E |
| 2N6110 | TO-220 Lead Form + Clip | 30 | | | 100† | 37.5 | 5 30 | 6.5 3 | 1.0 2.0 | 3 6.5 | 250 | 10 | 0.5 | 5E |



POWER (Continued)

| Type No. | Case Style | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CEX1} [†] (μA) Max | V _{CB} (V) @ I _C & V _{CE} (V) | h _{FE} Min Max @ I _C (A) | V _{CE(SAT)} (V) Max & V _{BE(SAT)} (V) Min | I _C (A) @ V _{CE(SAT)} & V _{BE(SAT)} | C _{ob} (pF) Max | f _T (MHz) Min Max @ I _C (A) | Process |
|----------|------------|-----------------------------|-----------------------------|--|---|---|---|---|-----------------------------|--|---------|
| 2N6111 | TO-220 | 30 | | 100 [†] | 37.5 | 5 30 150 6.5 3 4 4 | 1.0 2.0 | 3 6.5 | 250 | 10 0.5 | 5E |
| 2N6124 | TO-220 | 45 | | 100 | 45 | 10 25 100 4 2 2 0.6 1.4 | 0.6 1.4 | 1.5 4 | | 2.5 1 | 5E |
| 2N6125 | TO-220 | 60 | | 100 | 60 | 10 25 100 4 2 2 0.6 1.4 | 0.6 1.4 | 1.5 4 | | 2.5 1 | 5E |
| 2N6126 | TO-220 | 80 | | 100 | 80 | 7 20 80 4 2 2 0.6 1.4 | 0.6 1.4 | 1.5 4 | | 2.5 1 | 5E |
| 2N6132 | TO-220 | 40 | | 100 | 40 | 7 20 100 7 4 4 1.4 | 1.4 | 7 7 | | 2.5 1 | 5E |
| 2N6133 | TO-220 | 60 | | 100 | 60 | 7 20 100 7 4 4 1.4 | 1.4 | 7 7 | | 2.5 1 | 5E |
| 2N6134 | TO-220 | 80 | | 100 | 60 | 5 20 100 7 4 4 2.0 | 2.0 | 7 7 | | 2.5 1 | 5E |
| 2N6489 | TO-220 | 40 | | 500 [†] | 45 | 5 20 150 15 4 4 1.3 3.5 | 1.3 3.5 | 5 15 | | 5 1 | 5A |
| 2N6490 | TO-220 | 60 | | 500 [†] | 65 | 5 20 150 15 4 4 1.3 3.5 | 1.3 3.5 | 5 15 | | 5 1 | 5A |
| 2N6491 | TO-220 | 80 | | 500 [†] | 85 | 5 20 150 15 4 4 1.3 3.5 | 1.3 3.5 | 5 15 | | 5 1 | 5A |
| D45C1 | TO-220 | 30 | | 10* | 40 | 10 25 100 0.2 1 1 0.5 | 0.5 | 1.3 1 | 125 | 3 0.02 | 5F |
| D45C2 | TO-220 | 30 | | 10* | 40 | 20 40 120 0.2 1 1 0.5 | 0.5 | 1.3 1 | 125 | 3 0.02 | 5F |
| D45C3 | TO-220 | 30 | | 10* | 40 | 20 40 120 0.2 1 1 0.5 | 0.5 | 1.3 1 | 125 | 3 0.02 | 5E |
| D45C4 | TO-220 | 45 | | 10* | 55 | 10 25 100 0.2 1 1 0.5 | 0.5 | 1.3 1 | 125 | 3 0.02 | 5F |
| D45C5 | TO-220 | 45 | | 10* | 55 | 20 40 120 0.2 1 1 0.5 | 0.5 | 1.3 1 | 125 | 3 0.02 | 5F |
| D45C6 | TO-220 | 45 | | 10* | 55 | 20 40 120 0.2 1 1 0.5 | 0.5 | 1.3 1 | 125 | 3 0.02 | 5E |
| D45C7 | TO-220 | 60 | | 10* | 70 | 10 25 100 0.2 1 1 0.5 | 0.5 | 1.3 1 | 125 | 3 0.02 | 5F |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | ICES* ICEXT* (μ A) Max | V _{CB} (V) Max | hFE Min Max | IC (A) Max | V _{CE} (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min Max | IC (A) Max | C _{ob} (pF) Max | t _T (MHz) Min Max | IC (A) Max | Process |
|----------|------------|--------------------------------|--------------------------------|--------------------------------|--------------------------------------|-------------------------------|-------------------|-------------------|-------------------------------|------------------------------------|---|------------------|--------------------------------|---------------------------------------|------------------|---------|
| D45C8 | TO-220 | | 60 | | 10* | 70 | 20 40 | 1 0.2 | 1 | 0.5 | 1.3 | 1 | 125 | 3 | 0.02 | 5F |
| D45C9 | TO-220 | | 60 | | 10* | 70 | 20 40 | 2 0.2 | 1 | 0.5 | 1.3 | 1 | 125 | 3 | 0.02 | 5E |
| D45C10 | TO-220 | | 80 | | 10* | 90 | 10 25 | 1 0.2 | 1 | 0.5 | 1.3 | 1 | 125 | 3 | 0.02 | 5F |
| D45C11 | TO-220 | | 80 | | 10* | 90 | 20 40 | 1 0.2 | 1 | 0.5 | 1.3 | 1 | 125 | 3 | 0.02 | 5E |
| D45C12 | TO-220 | | 80 | | 10* | 90 | 20 40 | 2 0.2 | 1 | 0.5 | 1.3 | 1 | 125 | 3 | 0.02 | 5E |
| D45H1 | TO-220 | | 30 | | 10 | 30 | 20 35 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| D45H2 | TO-220 | | 30 | | 10 | 30 | 40 60 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| D45H4 | TO-220 | | 45 | | 10 | 45 | 20 35 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| D45H5 | TO-220 | | 45 | | 10 | 45 | 40 60 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| D45H7 | TO-220 | | 60 | | 10 | 60 | 20 35 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| D45H8 | TO-220 | | 60 | | 10 | 60 | 40 60 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| D45H10 | TO-220 | | 80 | | 10 | 80 | 20 35 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| D45H11 | TO-220 | | 80 | | 10 | 80 | 40 60 | 4 2 | 1 | 1.0 | 1.5 | 8 | | | | 5A |
| MJE170 | TO-126 | | 40 | | 0.1 | 60 | 12 30 50 | 1.5 0.5 0.1 | 1 1 1 | 1.7 0.9 0.3 | 2.0 1.5 0.5 | 3 1.5 0.5 | 50 | 50 | 0.1 | 77 |
| MJE171 | TO-126 | | 60 | | 0.1 | 80 | 12 30 50 | 1.5 0.5 0.1 | 1 1 1 | 1.7 0.9 0.3 | 2.0 1.5 0.5 | 3 1.5 0.5 | 50 | 50 | 0.1 | 78 |
| MJE172 | TO-126 | | 80 | | 0.1 | 100 | 12 30 50 | 1.5 0.5 0.1 | 1 1 1 | 1.7 0.9 0.3 | 2.0 1.5 0.5 | 3 1.5 0.5 | 50 | 50 | 0.1 | 79 |
| MJE370 | TO-126 | | 30 | | 100 | 30 | 25 | 1 | 1 | | | | | | | 3C |
| MJE371 | TO-126 | | 40 | | 100 | 40 | 40 | 1 | 1 | | | | | | | 3E |
| MJE700 | TO-126 | | 60 | | 200 | 60 | 750 | 1.5 | 3 | 2.5 | 1.5 | 1.5 | | 1 | 1.5 | 3J |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | ICES* ICEX† @ (A) Max | V _{CB} (V) | h _{FE} Min | h _{FE} Max | IC @ (A) | V _{CE} & V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) & Min | IC @ (A) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | IC (A) | Process |
|----------|------------|--------------------------|--------------------------|--------------------------|--------------------------|---------------------|---------------------|---------------------|----------|---------------------------------------|------------------------------|--------------------------------|--------------|--------------------------|--------------------------|--------------------------|--------|---------|
| MJE701 | TO-126 | | 60 | | 200 | 60 | 750 | 2 | 3 | 2.8 | | | 2 | | 1 | 1.5 | 1.5 | 3J |
| MJE702 | TO-126 | | 60 | | 200 | 60 | 750 | 2 | 3 | 2.8 | | | 2 | | 1 | 1.5 | 1.5 | 3J |
| MJE703 | TO-126 | | 80 | | 200 | 80 | 750 | 2 | 2 | 3 | 2.8 | | 2 | | 1 | 1.5 | 1.5 | 3J |
| MJE710 | TO-126 | | 40 | | 100† | 40 | 8 | | 1 | 1 | 1.0 | 1.3 | 1.5 | | | | | 77 |
| | | | | | | | 20 | | 0.5 | 1 | 0.4 | | 0.5 | | | | | |
| | | | | | | | 40 | | 0.15 | 1 | 0.15 | | 0.15 | | | | | |
| MJE711 | TO-126 | | 60 | | 100† | 60 | 8 | | 1 | 1 | 1.0 | 1.3 | 1.5 | | | | | 78 |
| | | | | | | | 20 | | 0.5 | 1 | 0.4 | | 0.5 | | | | | |
| | | | | | | | 40 | | 0.15 | 1 | 0.15 | | 0.15 | | | | | |
| MJE712 | TO-126 | | 80 | | 100† | 80 | 8 | | 1 | 1 | 1.0 | 1.3 | 1.5 | | | | | 79 |
| | | | | | | | 20 | | 0.5 | 1 | 0.4 | | 0.5 | | | | | |
| | | | | | | | 40 | | 0.15 | 1 | 0.15 | | 0.15 | | | | | |
| NSP42 | TO-220 | | 40 | | 400* | 40 | 15 | 75 | 3 | 4 | 1.5 | | 5 | | 3 | 0.5 | 0.5 | 5E |
| | | | | | | | 30 | | 0.3 | 4 | | | | | | | | |
| NSP42A | TO-220 | | 60 | | 400* | 60 | 15 | 75 | 3 | 4 | 1.5 | | 5 | | 3 | 0.5 | 0.5 | 5E |
| | | | | | | | 30 | | 0.3 | 4 | | | | | | | | |
| NSP42B | TO-220 | | 80 | | 400* | 80 | 15 | 75 | 3 | 4 | 1.5 | | 5 | | 3 | 0.5 | 0.5 | 5E |
| | | | | | | | 30 | | 0.3 | 4 | | | | | | | | |
| NSP42C | TO-220 | | 100 | | 400* | 100 | 15 | 75 | 3 | 4 | 1.5 | | 5 | | 3 | 0.5 | 0.5 | 5E |
| | | | | | | | 30 | | 0.3 | 4 | | | | | | | | |
| NSP105 | TO-220 | | 50 | | 100 | 50 | 25 | 100 | 2 | 2 | | | | | | | | 5A |
| NSP370 | TO-220 | | 30 | | 100 | 30 | 25 | | 1 | 1 | | | | | | | | 5F |
| NSP371 | TO-220 | | 40 | | 100 | 40 | 40 | | 1 | 1 | | | | | | | | 5F |
| NSP576 | TO-220 | 45 | 45 | | 100 | 45 | 25 | | 1 | 1 | 0.6 | | 1 | | 3 | 0.5 | 0.5 | 5F |
| NSP578 | TO-220 | 60 | 60 | | 100 | 60 | 25 | | 1 | 1 | 0.6 | | 1 | | 3 | 0.5 | 0.5 | 5F |
| NSP580 | TO-220 | 80 | 80 | | 100 | 80 | 15 | | 1 | 1 | 0.8 | | 1 | | 3 | 0.5 | 0.5 | 5F |
| NSP582 | TO-220 | 100 | 100 | | 100 | 100 | 15 | | 1 | 1 | 0.8 | | 1 | | 3 | 0.5 | 0.5 | 5F |
| NSP586 | TO-220 | 45 | 45 | | 100 | 45 | 25 | | 2 | 2 | 0.8 | | 2 | | 3 | 0.25 | 0.25 | 5E |
| | | | | | | | 40 | | 0.5 | 2 | | | | | | | | |
| NSP588 | TO-220 | 60 | 60 | | 100 | 60 | 20 | | 2 | 2 | 0.8 | | 2 | | 3 | 0.25 | 0.25 | 5E |
| | | | | | | | 40 | | 0.5 | 2 | | | | | | | | |
| NSP590 | TO-220 | 80 | 80 | | 100 | 80 | 15 | | 2 | 2 | 0.8 | | 2 | | 3 | 0.25 | 0.25 | 5E |
| | | | | | | | 30 | | 0.5 | 2 | | | | | | | | |
| NSP596 | TO-220 | 45 | 45 | | 100 | 45 | 25 | | 3 | 2 | 1.0 | | 3 | | 3 | 0.25 | 0.25 | 5E |
| | | | | | | | 40 | | 1 | 2 | | | | | | | | |
| NSP598 | TO-220 | 60 | 60 | | 100 | 60 | 25 | | 3 | 2 | 1.0 | | 3 | | 3 | 0.25 | 0.25 | 5E |
| | | | | | | | 40 | | 1 | 2 | | | | | | | | |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CEX} [†] (mA) Max | V _{CB} (V) | I _{CE} [†] (A) Max | h _{FE} Min | h _{FE} Max | I _C (A) Max | V _{CE} (V) Max | V _{BE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (A) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (A) Max | Process |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|---|---------------------|---|------------------------|------------------------|---------------------------|----------------------------|---------------------------------|---------------------------------|---------------------------|-----------------------------|-----------------------------|-----------------------------|---------------------------|---------|
| NSP600 | TO-220 | 80 | 80 | | 100 | 80 | 100 | 15 | 30 | 3 | 1.0 | | | 3 | | 3 | 0.25 | | 5E |
| NSP602 | TO-220 | | 100 | | 100 | 100 | 100 | 15 | 30 | 3 | 1.0 | | | 3 | | 3 | 0.25 | | 5E |
| NSP692 | TO-220 | | 45 | | 200 | 45 | 200 | 750 | | 3 | 2.5 | | | 3 | | 1 | 3 | | 5J |
| NSP696A | TO-220 | | 45 | | 200 | 45 | 200 | 750 | | 4 | 2.8 | | | 4 | | 1 | 3 | | 5J |
| NSP698 | TO-220 | | 60 | | 200 | 60 | 200 | 750 | | 3 | 2.5 | | | 3 | | 1 | 3 | | 5J |
| NSP698A | TO-220 | | 60 | | 200 | 60 | 200 | 750 | | 4 | 2.8 | | | 4 | | 1 | 3 | | 5J |
| NSP700 | TO-220 | | 80 | | 200 | 80 | 200 | 750 | | 3 | 2.5 | | | 3 | | 1 | 3 | | 5J |
| NSP700A | TO-220 | | 80 | | 200 | 80 | 200 | 750 | | 4 | 2.8 | | | 4 | | 1 | 3 | | 5J |
| NSP702 | TO-220 | | 100 | | 200 | 100 | 200 | 750 | | 3 | 2.5 | | | 3 | | 1 | 3 | | 5J |
| NSP2010 | TO-220 | | 40 | | 400 | 40 | 400 | 15 | 25 | 3 | 1.5 | | | 5 | | 3 | 0.5 | | 5A |
| NSP2011 | TO-220 | | 60 | | 400 | 60 | 400 | 15 | 25 | 3 | 1.5 | | | 5 | | 3 | 0.5 | | 5A |
| NSP2090 | TO-220 | | 60 | | 200 | 60 | 200 | 750 | | 3 | 2.5 | | | 3 | | 1 | 3 | | 5J |
| NSP2091 | TO-220 | | 60 | | 200 | 60 | 200 | 750 | | 4 | 2.5 | | | 4 | | 1 | 3 | | 5J |
| NSP2092 | TO-220 | | 80 | | 200 | 80 | 200 | 750 | | 3 | 2.5 | | | 3 | | 1 | 3 | | 5J |
| NSP2093 | TO-220 | | 80 | | 200 | 80 | 200 | 750 | | 4 | 2.5 | | | 4 | | 1 | 3 | | 5J |
| NSP2370 | TO-220 | | 40 | | 200† | 40 | 200† | 10 | 40 | 1 | 0.7 | | | 1 | | 3 | 0.5 | | 5F |
| NSP2490 | TO-220 | | 40 | | 200† | 40 | 200† | 8 | 20 | 3 | 1.2 | | | 3 | | 3 | 0.5 | | 5E |
| NSP2491 | TO-220 | | 60 | | 200† | 60 | 200† | 8 | 20 | 3 | 1.2 | | | 3 | | 3 | 0.5 | | 5E |
| NSP2955 | TO-220 | | 60 | | 100 | 70 | 100 | 5 | 20 | 10 | 8.0 | | | 10 | | 2 | 0.5 | | 5A |
| NSP3740 | TO-220 | | 60 | | 100 | 60 | 100 | 10 | 20 | 4 | 1.1 | | | 4 | | 3 | 0.1 | | 5F |
| | Lead | | | | 20 | | | 20 | | 0.5 | 0.6 | | | 1 | | | | | |
| | Bend + | | | | 30 | | | 100 | | 0.25 | | | | 1 | | | | | |
| | Clip | | | | 40 | | | 40 | | 0.1 | | | | 1 | | | | | |
| NSP3741 | TO-220 | | 80 | | 100 | 80 | 100 | 10 | 20 | 1 | 0.6 | | | 1 | | 3 | 0.100 | | 5F |
| | Lead | | | | 20 | | | 30 | | 0.5 | | | | 1 | | | | | |
| | Bend + | | | | 30 | | | 100 | | 0.25 | | | | 1 | | | | | |
| | Clip | | | | 40 | | | 40 | | 0.1 | | | | 1 | | | | | |



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CEX} [†] (μA) Max | V _{CB} (V) | h _{FE} Min | h _{FE} Max | I _C (A) @ V _{CE} (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min | I _C (A) @ V _{BE(SAT)} (V) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | I _C (A) | Process |
|----------|------------|--------------------------|--------------------------|--------------------------|--|---------------------|---------------------|---------------------|--|------------------------------|------------------------------|---|--------------------------|--------------------------|--------------------------|--------------------|---------|
| NSP4918 | TO-220 | | 40 | | 100 | 40 | 10 | 100 | 1 0.5 0.05 | 0.6 | 1.3 | 1 | | 3 | | 0.25 | 5F |
| NSP4919 | TO-220 | | 60 | | 100 | 60 | 10 | 100 | 1 0.5 0.05 | 0.6 | 1.3 | 1 | | 3 | | 0.25 | 5F |
| NSP4920 | TO-220 | | 80 | | 100 | 80 | 10 | 100 | 1 0.5 0.05 | 0.6 | 1.3 | 1 | | 3 | | 0.25 | 5F |
| NSP5193 | TO-220 | | 40 | | 100 | 40 | 25 | 100 | 1.5 2 | 1.4 | | 4 | | 2 | | 1 | 5E |
| NSP5194 | TO-220 | | 60 | | 100 | 60 | 10 | 100 | 4 2 | 1.4 | | 4 | | 2 | | 1 | 5E |
| NSP5195 | TO-220 | | 80 | | 100 | 80 | 20 | 80 | 4 2 | 1.4 | | 4 | | 2 | | 1 | 5E |
| NSP5974 | TO-220 | | 40 | | 100 [†] | 60 | 7 | 120 | 5 2.5 0.5 | 1.7 | 2.5 | 5 | 300 | 2 | | 0.5 | 5A |
| NSP5975 | TO-220 | | 60 | | 100 [†] | 80 | 7 | 120 | 5 2.5 0.5 | 1.7 | 2.5 | 5 | 300 | 2 | | 0.5 | 5A |
| NSP5976 | TO-220 | | 80 | | 100 [†] | 100 | 7 | 120 | 5 2.5 0.5 | 1.7 | 2.5 | 5 | 300 | 2 | | 0.5 | 5A |
| NSP5980 | TO-220 | | 40 | | 100 [†] | 60 | 20 | 120 | 8 4 2 | 1.7 | 2.5 | 8 | 350 | 2 | | 0.5 | 5A |
| NSP5981 | TO-220 | | 60 | | 100 [†] | 80 | 20 | 120 | 8 4 2 | 1.7 | 2.5 | 8 | 350 | 2 | | 0.5 | 5A |
| NSP5982 | TO-220 | | 80 | | 100 [†] | 100 | 20 | 120 | 8 4 2 | 1.7 | 2.5 | 8 | 350 | 2 | | 0.5 | 5A |
| TIP30 | TO-220 | | 40 | | 200* | 40 | 15 | 75 | 1 0.2 | 0.7 | | 1 | | 3 | | 0.2 | 5F |
| TIP30A | TO-220 | | 60 | | 200* | 60 | 15 | 75 | 1 0.2 | 0.7 | | 1 | | 3 | | 0.2 | 5F |
| TIP30B | TO-220 | | 80 | | 200* | 80 | 15 | 75 | 1 0.2 | 0.7 | | 1 | | 3 | | 0.2 | 5F |

PNP Transistors



POWER (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CEX1*} (μA) Max | V _{CB} (V) | hFE Min Max | I _C (A) Max | V _{CE} (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} (V) Min Max | I _C (A) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (A) Max | Process |
|----------|------------|-----------------------------|-----------------------------|-----------------------------|--------------------------------|---------------------|-------------------|---------------------------|----------------------------|---------------------------------|--|---------------------------|-----------------------------|------------------------------------|---------------------------|---------|
| TIP30C | TO-220 | | 100 | | 200* | 100 | 15 40 | 1 0.2 | 4 4 | 0.7 | | 1 | | 3 | 0.2 | 5F |
| TIP32 | TO-220 | | 40 | | 200* | 40 | 10 25 | 3 1 | 4 4 | 1.2 | | 3 | | 3 | 0.5 | 5F |
| TIP32A | TO-220 | | 60 | | 200* | 60 | 10 25 | 3 1 | 4 4 | 1.2 | | 3 | | 3 | 0.5 | 5F |
| TIP32B | TO-220 | | 80 | | 200* | 80 | 10 25 | 3 1 | 4 4 | 1.2 | | 3 | | 3 | 0.5 | 5F |
| TIP32C | TO-220 | | 100 | | 200* | 100 | 10 25 | 3 1 | 4 4 | 1.2 | | 3 | | 3 | 0.5 | 5F |
| TIP42 | TO-220 | | 40 | | 400* | 40 | 15 30 | 3 0.3 | 4 4 | 1.5 | | 6 | | 3 | 0.5 | 5A |
| TIP42A | TO-220 | | 60 | | 400* | 60 | 15 30 | 3 0.3 | 4 4 | 1.5 | | 6 | | 3 | 0.5 | 5A |
| TIP42B | TO-220 | | 80 | | 400* | 80 | 15 30 | 3 0.3 | 4 4 | 1.5 | | 6 | | 3 | 0.5 | 5A |
| TIP42C | TO-220 | | 100 | | 400* | 100 | 15 30 | 3 0.3 | 4 4 | 1.5 | | 6 | | 3 | 0.5 | 5A |
| TIP62 | TO-220 | | 40 | | 200* | 40 | 15 40 | 0.5 0.05 | 4 4 | 0.7 | | 0.5 | | 3 | 0.05 | 5F |
| TIP62A | TO-220 | | 60 | | 200* | 60 | 15 40 | 0.5 0.05 | 4 4 | 0.7 | | 0.5 | | 3 | 0.05 | 5F |
| TIP62B | TO-220 | | 80 | | 200* | 80 | 15 40 | 0.5 0.05 | 4 4 | 0.7 | | 0.5 | | 3 | 0.05 | 5F |
| TIP62C | TO-220 | | 100 | | 200* | 100 | 15 40 | 0.5 0.05 | 4 4 | 0.7 | | 0.5 | | 3 | 0.05 | 5F |
| TIP115 | TO-220 | | 60 | | 1 mA | 60 | 500 1000 | 2 1 | 4 4 | 2.5 | | 2 | | 3 | | 5J |
| TIP116 | TO-220 | | 80 | | 1 mA | 80 | 500 1000 | 2 1 | 4 4 | 2.5 | | 2 | | 3 | | 5J |
| TIP117 | TO-220 | | 100 | | 1 mA | 100 | 500 1000 | 2 1 | 4 4 | 2.5 | | 2 | | 3 | | 5J |
| TIP125 | TO-220 | | 60 | | 200 | 60 | 1000 1000 | 3 0.5 | 3 3 | 4.0 2.0 | | 5 3 | | | | 5K |
| TIP126 | TO-220 | | 80 | | 200 | 80 | 1000 1000 | 3 0.5 | 3 3 | 4.0 2.0 | | 5 3 | | | | 5K |
| TIP127 | TO-220 | | 100 | | 200 | 100 | 1000 1000 | 3 0.5 | 3 3 | 4.0 2.0 | | 5 3 | | | | 5K |



POWER (Continued)

| Type No. | Case Style | VCBO (V) | | VCEO (V) | | VEBO (V) | | ICES* ICEX† @ (μA) | | VCE (V) & IC (A) | | VCE(SAT) (V) & VBE(SAT) (V) @ IC (A) | | Cob (pF) & fT (MHz) @ IC (A) | | Process | |
|----------|------------|----------|-----|----------|-----|----------|-----|-----------------------|-----|------------------|-------------|--------------------------------------|------------|------------------------------|-----|---------|----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | |
| TIP135 | TO-220 | | | 60 | | | | 200 | | 1000 500 | 15,000 4 | 4 4 | 3.0 2.0 | 6 4 | 200 | | 5K |
| TIP136 | TO-220 | | | 80 | | | | 200 | | 1000 500 | 15,000 4 | 4 4 | 3.0 2.0 | 6 4 | 200 | | 5K |
| TIP137 | TO-220 | | | 100 | | | | 200 | | 1000 500 | 15,000 4 | 4 4 | 3.0 2.0 | 6 4 | 200 | | 5K |



DUAL DIFFERENTIAL AMPS

| Type No. | Case Style | VCBO (V) | | VCEO (V) | | VEBO (V) | | ICBO (mA) @ VCE (V) | | HFE ¹ / HFE ² (%) & IC (mA) | | VBE ¹ / -VBE ² (mV) & ΔVBE ¹ - ΔVBE ² / ΔT (μV/°C) | | Cob (pF) & fT (MHz) | | Test Condition | No. Process | |
|----------|------------|----------|-----|----------|-----|----------|-----|-------------------------|-----|---|------|--|-----|---------------------|-----|----------------|-------------|----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | |
| 2N3347 | TO-78 | 60 | | 45 | | 6 | | 10 40 | 45 | 10 300 | 0.01 | 5 | 10 | 6 | 240 | 4 | 1 | 62 |
| 2N3348 | TO-78 | 60 | | 45 | | 6 | | 60 40 | 45 | 1 300 | 0.01 | 10 | 20 | 6 | 240 | 4 | 1 | 62 |
| 2N3349 | TO-78 | 60 | | 45 | | 6 | | 60 40 | 45 | 1 300 | 0.01 | 20 | 40 | 6 | 240 | 4 | 1 | 62 |
| 2N3350 | TO-78 | 60 | | 45 | | 6 | | 150 100 | 45 | 1 300 | 0.01 | 5 | 10 | 6 | 240 | 4 | 1 | 62 |
| 2N3351 | TO-78 | 60 | | 45 | | 6 | | 150 100 | 45 | 1 300 | 0.01 | 10 | 20 | 6 | 240 | 4 | 1 | 62 |
| 2N3352 | TO-78 | 60 | | 45 | | 6 | | 150 100 | 45 | 1 300 | 0.01 | 20 | 40 | 6 | 240 | 4 | 1 | 62 |
| 2N3726 | TO-78 | 45 | | 45 | | 5 | | 115 135 120 80 | 30 | 50 350 0.1 0.01 | | 5 | 20 | 8 | 600 | 4 | 2 | 62 |
| 2N3727 | TO-78 | 45 | | 45 | | 5 | | 115 135 120 80 | 30 | 50 350 0.1 0.01 | | 2.5 | 10 | 8 | 600 | 4 | 2 | 62 |

TEST CONDITIONS:

(1) IC = 10 μA, VCE = 5V, f = 15.7kHz. (2) IC = 30 μA, VCE = 5V, f = 1kHz. (3) IC = 100 μA, VCE = 10V, f = 1kHz. (4) IC = 20 μA, VCE = 5V, f = 1kHz.



DUAL DIFFERENTIAL AMPS (Continued)

| Type No. | Case Style | VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICBO (mA) @ VCB (V) | HFE Min | IC @ (mA) | HFE1 HFE2 (%) Max | VBE1 -VBE2 (mV) Max | $\Delta VBE1$ - $\Delta VBE2$ ($\mu V/^\circ C$) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | NF (dB) Max | Test Condition | No. Process |
|---------------------------|------------|--------------|--------------|--------------|---------------------|---------------------------------|---------------------------------|----------------------|------------------------|--|--------------------------|--------------------------|--------------------------|-------------|----------------|-------------|
| 2N3800 | TO-71 | 60 | 60 | 5 | 10 | 125 150 150 100 | 10 450 0.5 0.1 0.01 | | | | 4 | 100 | 500 | 3 | 4 | 62 |
| 2N3806 | TO-78 | 60 | 60 | 5 | 10 | 125 150 150 100 | 10 450 0.5 0.1 0.01 | | | | 4 | 100 | 500 | 3 | 3 | 62 |
| 2N3807 | TO-78 | 60 | 60 | 5 | 10 | 250 300 300 300 225 | 10 900 0.5 0.1 0.01 | | | | 4 | 100 | 500 | 1.5 | 3 | 62 |
| 2N3808 | TO-78 | 60 | 60 | 5 | 10 | 125 150 150 100 | 10 450 0.5 0.1 0.01 | 20 | 5 | 20 | 4 | 100 | 500 | 3 | 3 | 62 |
| 2N3809 | TO-78 | 60 | 60 | 5 | 10 | 250 300 300 300 250 | 10 900 0.5 0.1 0.01 | 20 | 5 | 20 | 4 | 100 | 500 | 1.5 | 3 | 62 |
| 2N3810 | TO-78 | 60 | 60 | 5 | 10 | 125 150 150 100 | 10 450 0.5 0.1 0.01 | 10 | 3 | 10 | 4 | 100 | 500 | 3 | 3 | 62 |
| 2N3810 J, JTX, JTXV | TO-78 | 60 | 60 | 5 | 10 | 125 150 150 100 | 10 450 0.5 0.1 0.01 | 10 | 5 | 10 | 5 | 100 | 500 | 3 | 3 | 62 |



DUAL DIFFERENTIAL AMPS (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) | HFE Min | HFE Max @ I _C (mA) | HFE ¹ HFE ² (%) Max | V _{BE1} - V _{BE2} (mV) Max | ΔV _{BE1} - V _{BE2} (ΔT) (μV/°C) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | NF (dB) Max | Test Condition | No. Process |
|---------------------------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|---------------------------------|---------------------------------|--|--|---|--------------------------|------------------------------|-------------|----------------|-------------|
| 2N3810A | TO-78 | 60 | 60 | 5 | 10 | 50 | 125 150 150 150 100 | 10 450 450 450 0.01 | 5 | 1.5 | 5 | 4 | 100 500 | 3 | 3 | 62 |
| 2N3811 | TO-78 | 60 | 60 | 5 | 10 | 50 | 250 300 300 300 225 | 10 900 0.5 0.1 0.01 | 10 | 3 | 10 | 4 | 100 500 | 1.5 | 3 | 62 |
| 2N3811 J, JTX, JTXV | TO-78 | 60 | 60 | 5 | 10 | 50 | 250 300 300 300 225 | 10 900 0.5 0.1 0.01 | 10 | 3 | 10 | 5 | 100 500 | 1.5 | 3 | 62 |
| 2N3811A | TO-78 | 60 | 60 | 5 | 10 | 50 | 300 300 300 225 | 10 900 0.5 0.01 | 5 | 1.5 | 5 | 4 | 100 500 | 1.5 | 3 | 62 |
| 2N4015 | TO-78 | 60 | 60 | 5 | 10 | 50 | 115 135 120 80 | 50 350 0.1 0.01 | 10 | 5 | 20 | 8 | 200 600 | 4 | 2 | 62 |
| 2N4016 | TO-78 | 60 | 60 | 5 | 10 | 50 | 115 135 120 80 | 50 350 0.1 0.01 | 10 | 2.5 | 10 | 8 | 200 600 | 4 | 2 | 62 |
| 2N4017 | TO-78 | 80 | 80 | 6 | 10 | 70 | 90 100 100 100 60 | 50 10 500 0.1 0.01 | | | | 6 | 40 160 | 3 | 4 | 62 |

TEST CONDITIONS:

(1) I_C = 10 μA, V_{CE} = 5V, f = 15.7 kHz. (2) I_C = 30 μA, V_{CE} = 5V, f = 1 kHz. (3) I_C = 100 μA, V_{CE} = 10V, f = 1 kHz. (4) I_C = 20 μA, V_{CE} = 5V, f = 1 kHz.



DUAL DIFFERENTIAL AMPS (Continued)

| Type No. | Case Style | V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} (mA) Max | V _{CB} (V) | HFE Max @ I _C | I _C (mA) | HFE ¹ HFE ² (%) Max | V _{BE¹} -V _{BE²} (mV) Max | $\frac{\Delta V_{BE}^1}{\Delta T}$ (μ V/°C) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | NF (dB) Max | Test Condition | No. Process | |
|----------|------------|--------------------------|--------------------------|--------------------------|---------------------------|---------------------|--------------------------|---------------------|--|--|---|--------------------------|------------------------------|-------------|----------------|-------------|----|
| 2N4018 | TO-78 | 60 | 60 | 6 | 10 | 50 | 50 | 50 | | | | 6 | 40 | 160 | 3 | 4 | 62 |
| | | | | | | | 100 | 10 | | | | | 100 | 600 | | | |
| 2N4019 | TO-78 | 45 | 45 | 6 | 10 | 30 | 180 | 50 | | | | 6 | 50 | 160 | 2 | 4 | 62 |
| | | | | | | | 200 | 10 | | | | | 250 | 600 | | | |
| 2N4020 | TO-78 | 45 | 45 | 6 | 10 | 30 | 180 | 50 | | 5 | 20 | 6 | 50 | 160 | 2 | 4 | 62 |
| | | | | | | | 200 | 10 | | | | | 250 | 600 | | | |
| 2N4021 | TO-78 | 60 | 60 | 6 | 10 | 50 | 90 | 50 | | 5 | 20 | 6 | 40 | 160 | 3 | 4 | 62 |
| | | | | | | | 100 | 10 | | | | | 100 | 500 | | | |
| 2N4023 | TO-78 | 45 | 45 | 6 | 10 | 30 | 180 | 50 | | 3 | 10 | 6 | 50 | 160 | 2 | 4 | 62 |
| | | | | | | | 200 | 10 | | | | | 250 | 600 | | | |
| 2N4024 | TO-78 | 60 | 60 | 6 | 10 | 50 | 90 | 50 | | 3 | 10 | 6 | 40 | 160 | 3 | 4 | 62 |
| | | | | | | | 100 | 10 | | | | | 100 | 500 | | | |
| 2N4025 | TO-78 | 60 | 60 | 6 | 10 | 50 | 180 | 50 | | 3 | 10 | 6 | 50 | 160 | 2 | 4 | 62 |
| | | | | | | | 200 | 10 | | | | | 250 | 600 | | | |

TEST CONDITIONS:

(1) I_C = 10 μA, V_{CE} = 5V, f = 15.7kHz. (2) I_C = 30 μA, V_{CE} = 5V, f = 1kHz. (3) I_C = 100 μA, V_{CE} = 10V, f = 1kHz. (4) I_C = 20 μA, V_{CE} = 5V, f = 1kHz.



Section 3

Pro Electron Series

3



| Type No. | Case Style | VCES* VCBO (V) Min | VCEO (V) Min | VEBO (V) Min | ICES* ICBO (mA) Max | V _{CB} (V) Max | HFE | | IC & V _{CE} (mA) (V) Max | V _{CE(SAT)} & V _{BE(ON)*} (V) (V) Max Min | | V _{BE(SAT)} & V _{BE(ON)*} (V) (V) Min Max | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--------------------------|-----------------|-----------------|---------------------------|----------------------------|---------------------------|------------------------|---|---|-----------------------------|---|-----------------------------|-------------------------------|--------------------------------|------------------------------------|---------------------------------|-------------------|----------------|-------------|
| | | | | | | | h _{FE} 1 kHz* | h _{FE} Max | | V _{CE(SAT)} Max | V _{BE(ON)*} Min | V _{BE(SAT)} Min | V _{BE(ON)*} Max | | | | | | | |
| BC107 | TO-18 | 50 | 45 | 6 | 15* | 50 | 40 125 40 | 0.01 500* 0.01 | 5 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 10 | 1 | 04 | |
| BC107A | TO-18 | 50 | 45 | 6 | 15* | 50 | 125 | 260* 2 | 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 10 | 1 | 04 | |
| BC107B | TO-18 | 50 | 45 | 6 | 15* | 50 | 40 240 | 0.01 500* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 10 | 1 | 04 | |
| BC108 | TO-18 | 30 | 20 | 5 | 15* | 30 | 40 125 | 0.01 900* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 10 | 1 | 04 | |
| BC108A | TO-18 | 30 | 20 | 5 | 15* | 30 | 40 125 | 0.01 260* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 10 | 1 | 04 | |
| BC108B | TO-18 | 30 | 20 | 5 | 15* | 30 | 40 240 | 0.01 500* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 10 | 1 | 04 | |
| BC108C | TO-18 | 30 | 20 | 5 | 15* | 30 | 40 450 | 0.01 900* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 10 | 1 | 04 | |
| BC109 | TO-18 | 30 | 20 | 5 | 15* | 30 | 100 240 | 0.01 900* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 4 | 1 | 04 | |
| BC109B | TO-18 | 30 | 20 | 5 | 15* | 30 | 100 240 | 0.01 500* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 4 | 1 | 04 | |
| BC109C | TO-18 | 30 | 20 | 5 | 15* | 30 | 100 450 | 0.01 900* 2 | 5 5 | 0.6 0.2 | 0.55 0.7* | 100 10 | 4.5 | 150 | 10 | | 4 | 1 | 04 | |
| BC140 | TO-39 | 80* | 40 | 7 | 100* | 60 | 40 | 250 100 1 | 1 1 | 1.0 | 1.8* | 1A | 25 | 50 | 850 | | 850 | 2 | 14 | |
| BC140-6 | TO-39 | 80* | 40 | 7 | 100* | 60 | 40 | 100 100 1 | 1 1 | 1.0 | 1.8* | 1A | 25 | 50 | 850 | | 850 | 2 | 14 | |
| BC140-10 | TO-39 | 80* | 40 | 7 | 100* | 60 | 63 | 160 100 1 | 1 1 | 1.0 | 1.8* | 1A | 25 | 50 | 850 | | 850 | 2 | 14 | |
| BC140-16 | TO-39 | 80* | 40 | 7 | 100* | 60 | 100 | 250 100 1 | 1 1 | 1.0 | 1.8* | 1A | 25 | 50 | 850 | | 850 | 2 | 14 | |
| BC141 | TO-39 | 100* | 60 | 7 | 100* | 60 | 40 | 250 100 1 | 1 1 | 1.0 | 1.8* | 1A | 25 | 50 | 850 | | 850 | 2 | 14 | |
| BC141-6 | TO-39 | 100* | 60 | 7 | 100* | 60 | 40 | 100 100 1 | 1 1 | 1.0 | 1.8* | 1A | 25 | 50 | 850 | | 850 | 2 | 14 | |
| BC141-10 | TO-39 | 100* | 60 | 7 | 100* | 60 | 63 | 160 100 1 | 1 1 | 1.0 | 1.8* | 1A | 25 | 50 | 850 | | 850 | 2 | 14 | |
| BC143 | TO-5 | 60 | 60 | 5 | 50 | 40 | 20 | 200 2 | 1.5 | 1.5 | 1.5 | 500 200 | 20 | 60 | | | 2 | 63 | | |



| Type No. | Case Style | VCES* VCBO (V) | VCEO (V) | VEBO (V) | ICES* ICBO @ (mA) | VCB (V) | HFE h _{FE} @ 1 kHz* | IC & VCE @ (mA) (V) | VCE(SAT) & VBE(ON)* (V) | | VBE(SAT) & VBE(ON)* @ IC (mA) | | Cob (pF) Max | f _T (MHz) @ IC (mA) | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|-------------------|----------|----------|----------------------|---------|---------------------------------|---------------------|-------------------------|------------|-------------------------------|-------------|--------------|--------------------------------|---------------------------|-------------|----------------|-------------|
| | | | | | | | | | Max | Min | Max | Min | | | | | | |
| BC146-1 | TO-92 (74) | 20 | 20 | 4 | 50 | 40 | 100 80 | 2 200 | 1 0.2 | 1.5 | 1.5 | 500 200 | 20 | 60 | 50 | | 2 | 04 |
| BC146-2 | TO-92 (74) | 20 | 20 | 4 | 50 | 40 | 140 140 | 2 350 | 1 0.2 | 1.5 | 1.5 | 500 200 | 20 | 60 | 50 | | 2 | 04 |
| BC146-3 | TO-92 (74) | 20 | 20 | 4 | 50 | 40 | 280 280 | 2 550 | 1 0.2 | 1.5 | 1.5 | 500 200 | 20 | 60 | 50 | | 2 | 04 |
| BC160 | TO-39 | 40* | 5 | 40 | 100 | 40 | 40 | 250 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC160-6 | TO-39 | 40* | 5 | 40 | 100 | 40 | 40 | 100 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC160-10 | TO-39 | 40* | 5 | 40 | 100 | 40 | 63 | 160 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC160-16 | TO-39 | 40* | 5 | 40 | 100 | 40 | 100 | 250 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC161 | TO-39 | 60* | 5 | 60 | 100 | 60 | 40 | 250 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC161-6 | TO-39 | 60* | 5 | 60 | 100 | 60 | 63 | 160 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC161-10 | TO-39 | 60* | 5 | 60 | 100 | 60 | 63 | 160 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC161-16 | TO-39 | 60* | 5 | 60 | 100 | 60 | 100 | 250 | 100 | 1.0 | 1.7* | 1A | 30 | 50 | 50 | 650 | 2 | 67 |
| BC167 | TO-92 (74) | 60* | 45 | 6 | 15* | 50 | 110 125 | 2 500 | 5 2 | 0.2 0.6 | 1.0 0.55 | 10 0.7* | 4.5 | 150 | 10 | 10 | 1 | 04 |
| BC167A | TO-92 (74) | 60* | 45 | 6 | 15* | 50 | 110 125 | 260* | 2 5 | 0.2 0.6 | 1.0 0.55 | 10 0.7* | 4.5 | 150 | 10 | 10 | 1 | 04 |
| BC167B | TO-92 (74) | 60* | 45 | 6 | 15* | 50 | 110 240 | 500* | 2 5 | 0.2 0.6 | 1.0 0.55 | 10 0.7* | 4.5 | 150 | 10 | 10 | 1 | 04 |
| BC168 | TO-92 (74) | 60* | 20 | 5 | 15* | 30 | 110 125 | 2 900 | 5 5 | 0.2 0.6 | 1.0 0.55 | 10 0.70* | 4.5 | 150 | 10 | 10 | 1 | 04 |
| BC168A | TO-92 (74) | 60* | 20 | 5 | 15* | 30 | 110 125 | 2 260 | 5 5 | 0.2 0.6 | 1.0 0.55 | 10 0.70* | 4.5 | 150 | 10 | 10 | 1 | 04 |
| BC168B | TO-92 (74) | 60* | 20 | 5 | 15* | 30 | 110 240 | 500* | 2 5 | 0.2 0.6 | 1.0 0.55 | 10 0.70* | 4.5 | 150 | 10 | 10 | 1 | 04 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CE} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CE} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CE} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CE} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CE} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} [*] V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CE0} [*] (mA) Max | V _{CB} (V) | HFE | | I _C & V _{CE} | | V _{CE(SAT)} & V _{BE(ON)} [*] | | V _{BE(SAT)} & V _{BE(ON)} [*] | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) | | I _C (mA) @ Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|---|-----------------------------|-----------------------------|--|---------------------|-----|------------|----------------------------------|--------|---|-----------------------|---|-----|----------------------------|-----------------------------|----------------------|-----|---------------------------------|------------------------------|----------------|----------------|-------------|
| | | | | | | | Min | Max | Min | Max | Min | Max | Min | Max | | | Min | Max | | | | | |
| BC168C | TO-92 (74) | | 20 | 5 | 15* | 30 | | 110 450 | 2 900* | 5 5 | 0.2 0.6 | 0.55 0.70* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 04 | |
| BC169 | TO-92 (74) | | 20 | 5 | 15* | 30 | | 110 240 | 2 900* | 5 5 | 0.2 0.6 | 0.55 0.70* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 04 | |
| BC169B | TO-92 (74) | | 20 | 5 | 15* | 30 | | 110 240 | 2 500* | 5 5 | 0.2 0.6 | 0.55 0.70* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 04 | |
| BC169C | TO-92 (74) | | 20 | 5 | 15* | 30 | | 110 450 | 2 900* | 5 5 | 0.2 0.6 | 0.55 0.70* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 04 | |
| BC177 | TO-18 | 50 | 45 | 5 | 100 | 20 | | 110 125 | 2 500* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC177A | TO-18 | 50 | 45 | 5 | 100 | 20 | | 110 125 | 2 260* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC177B | TO-18 | 50 | 45 | 5 | 100 | 20 | | 110 240 | 2 500* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC177VI | TO-18 | 50 | 45 | 5 | 100 | 20 | | 110 75 | 2 150* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC178 | TO-18 | 30 | 25 | 5 | 100 | 20 | | 110 125 | 2 900* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC178A | TO-18 | 30 | 25 | 5 | 100 | 20 | | 110 125 | 2 260* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC178B | TO-18 | 30 | 25 | 5 | 100 | 20 | | 110 240 | 2 500* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC179 | TO-18 | 25 | 20 | 5 | 100 | 20 | | 110 125 | 2 900* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |
| BC179A | TO-18 | 25 | 20 | 5 | 100 | 20 | | 110 125 | 2 260* | 5 5 | 0.18 | 0.78 0.75* 1.0* | 10 100 | 4.5 | 150 | 10 | | | 10 | | 1 | 71 | |



| Type No. | Case Style | V _{CE5} * V _{CB0} (V) Min | V _{CEO} (V) Min | VEBO (V) Min | IC _{CS0} * IC _{BO} (mA) Max | V _{CB} (V) | HFE h _{FE} 1 kHz* Min Max | IC & VCE (mA) (V) Min Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} * (V) Min Max | IC (mA) Min Max | Cob (pF) Max | f _T (MHz) Min Max | IC (mA) Min Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|---|-----------------------------|-----------------|---|---------------------|---|---------------------------------|------------------------------------|---|--------------------|-----------------|---------------------------------|--------------------|------------------------------|----------------|----------------|-------------|
| BC179B | TO-18 | 25 | 20 | 5 | 100 | 20 | 110 240 | 2 500* 2 5 | 0.18 | 0.78 0.75* 2 1.0* | 10 | 4.5 | 150 | 10 | | 4 | 1 | 71 |
| BC182 | TO-92 (77) | 60 | 50 | 5 | 15 | 50 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 1.2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC182A | TO-92 (77) | 60 | 50 | 5 | 15 | 50 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC182B | TO-92 (77) | 60 | 50 | 5 | 15 | 50 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC182L | TO-92 (74) | 60 | 50 | 5 | 15 | 50 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC182LA | TO-92 (74) | 60 | 50 | 5 | 15 | 50 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC182LB | TO-92 (74) | 60 | 50 | 5 | 15 | 50 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC183 | TO-92 (77) | 45 | 30 | 5 | 15 | 30 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC183A | TO-92 (77) | 45 | 30 | 5 | 15 | 30 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC183B | TO-92 (77) | 45 | 30 | 5 | 15 | 30 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC183C | TO-92 (77) | 45 | 30 | 5 | 15 | 30 | 40 80 | 0.01 100 5 100 5 | 0.6 0.25 | 0.55 0.70* 2 | 100 | 5 | 150 | 10 | | 10 | 1 | 04 |

TEST CONDITIONS:

(1) IC = 200 μA, VCE = 5V, f = 1kHz. (2) IC = 100mA, VCC = 20V, IB¹ = IB² = 5mA. (3) IC = 200 μA, VCE = 2V, f = 1kHz. (4) IC = 100mA, VCC = 10V, IB¹ = IB² = 10mA. (5) IC = 10mA, VCC = 3V, IB¹ = IB² = 1mA. (6) IC = 100 μA, VCE = 5V, f = 1kHz. (7) IC = 1mA, VCE = 10V, f = 200kHz. (8) IC = 1mA, VCE = 5V, f = 1kHz. (9) IC = 150mA, VCC = 6V, IB¹ = IB² = 15mA. (10) IC = 200 μA, VCE = 5V, f = 1kHz. (11) IC = 150mA, VCC = 10V, IB¹ = IB² = 75mA. (12) IC = 300mA, VCC = 25V, IB¹ = IB² = 30mA. (13) IC = 10 μA, VCE = 5V, f = WB. (14) IC = 500mA, VCC = 25V, IB¹ = 50mA, IB² = 25mA. (15) IC = 10mA, VBE = 2V, IB¹ = 3mA, IB² = 1mA. (16) IC = 100mA, IB¹ = 40mA, IB² = 20mA.



| Type No. | Case Style | V _{CE0} (V) Min | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CB0} [*] (nA) Max | V _{CB} (V) | H _{FE} h _{FE} 1 kHz [*] Min Max | I _C & V _{CE} (mA) & (V) Min Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max | I _C (mA) Min Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|--------------------------------|--------------------------------|--------------------------------|--|------------------------|---|---|------------------------------------|--|-----------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| BC183L | TO-92 (74) | 30 | 30 | 5 | 15 | 30 | 40 80 125 | 0.01 100 900* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC183LA | TO-92 (74) | 30 | 30 | 5 | 15 | 30 | 40 80 125 | 0.01 100 260* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC183LB | TO-92 (74) | 30 | 30 | 5 | 15 | 30 | 80 240 | 0.01 100 500* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC183LC | TO-92 (74) | 30 | 30 | 5 | 15 | 30 | 80 450 | 0.01 100 900* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 10 | 1 | 04 |
| BC184 | TO-92 (77) | 30 | 30 | 50 | 15 | 30 | 100 130 240 | 0.01 100 900* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 4 | 1 | 04 |
| BC184B | TO-92 (77) | 30 | 30 | 50 | 15 | 30 | 100 130 240 | 0.01 100 500* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 4 | 1 | 04 |
| BC184C | TO-92 (77) | 30 | 30 | 50 | 15 | 30 | 100 130 450 | 0.01 100 900* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 4 | 1 | 04 |
| BC184L | TO-92 (74) | 30 | 30 | 50 | 15 | 30 | 100 130 240 | 0.01 100 900* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 4 | 1 | 04 |
| BC184LB | TO-92 (74) | 30 | 30 | 50 | 15 | 30 | 100 130 240 | 0.01 100 500* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 4 | 1 | 04 |
| BC184LC | TO-92 (74) | 30 | 30 | 50 | 15 | 30 | 100 130 450 | 0.01 100 900* 2 | 0.6 0.25 | 1.2 0.70* | 100 10 2 | 5 | 150 | 10 | | 4 | 1 | 04 |
| BC212 | TO-92 (77) | 50 | 50 | 5 | 15 | 30 | 60 | 400* 2 | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC212A | TO-92 (77) | 50 | 50 | 5 | 15 | 30 | 100 | 300* 2 | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC212B | TO-92 (77) | 50 | 50 | 5 | 15 | 30 | 200 | 400* 2 | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 10 | 1 | 63 |



| Type No. | Case Style | V _{CE} * V _{CEO} (V) Min | VEBO (V) Min | ICES* I _{CB} O (mA) Max | V _{CE} & V _{CE} I _C (mA) (V) Max | V _{CE} (SAT) (V) Max | V _{BE} (SAT) & V _{BE} (ON)* (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--|-----------------|--|---|----------------------------------|--|----------------------------|-----------------------------|---------------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| BC212L | TO-92 (74) | 60 | 5 | 15 | 0.01 5 300 2 5 60* | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC212LA | TO-92 (74) | 60 | 5 | 15 | 0.01 5 60 2 5 100 300* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC212LB | TO-92 (74) | 60 | 5 | 15 | 0.01 5 60 2 5 200 400* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC213 | TO-92 (77) | 45 | 5 | 15 | 0.01 5 60 2 5 80 600* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC213A | TO-92 (77) | 45 | 5 | 15 | 0.01 5 60 2 5 100 300* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC213B | TO-92 (77) | 45 | 5 | 15 | 0.01 5 60 2 5 200 400* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC213C | TO-92 (77) | 45 | 5 | 15 | 0.01 5 60 2 5 350 600* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC213L | TO-92 (74) | 45 | 5 | 15 | 0.01 5 80 2 5 80* | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC213LA | TO-92 (74) | 45 | 5 | 15 | 0.01 5 80 2 5 100 300* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC213LB | TO-92 (74) | 45 | 5 | 15 | 0.01 5 80 2 5 200 400* 2 5 | 0.6 0.25 | 1.1 0.6 0.72* 2 | 100 10 | 10 | 200 | 10 | | 10 | 1 | 63 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz, (2) I_C = 100mA, V_{CE} = 20V, I_B¹ = I_B² = 5mA, (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz, (4) I_C = 100mA, V_{CE} = 10V, I_B¹ = I_B² = 10mA, (5) I_C = 3V, I_B¹ = I_B² = 1mA, (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz, (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz, (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz, (9) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA, (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz, (11) I_C = 150mA, V_{CE} = 10V, I_B¹ = I_B² = 75mA, (12) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA, (13) I_C = 10 μA, V_{CE} = 5V, f = WB, (14) I_C = 500mA, V_{CE} = 25V, I_B¹ = 50mA, I_B² = 25mA, (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA, (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * I _{CB0} (mA) Max | HFE h _{FE} 1 kHz* | I _C & V _{CE} I _C (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} * (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-----------|---------------|--|-----------------------------|-----------------------------|--|----------------------------------|--|------------------------------------|---|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| BC213LC | TO-92 (74) | 45 | 30 | 5 | 15 | 40 80 350 | 0.01 2 600* | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 10 | 1 | 63 |
| BC214 | TO-92 (77) | 45 | 30 | 5 | 15 | 40 80 140 | 0.01 2 600* | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 2 | 1 | 63 |
| BC214A | TO-92 (77) | 45 | 30 | 5 | 15 | 40 80 100 | 0.01 2 300* | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 2 | 1 | 63 |
| BC214B | TO-92 (77) | 45 | 30 | 5 | 15 | 40 80 200 | 0.01 2 400* | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 2 | 1 | 63 |
| BC214C | TO-92 (77) | 45 | 30 | 5 | 15 | 40 80 350 | 0.01 2 600* | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 2 | 1 | 63 |
| BC214L | TO-92 (74) | 45 | 30 | 5 | 15 | 100 140 120 140* | 0.01 2 100 5 | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 2 | 1 | 63 |
| BC214LB | TO-92 (74) | 45 | 30 | 5 | 15 | 100 140 120 200 | 0.01 2 100 5 | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 2 | 1 | 63 |
| BC214LC | TO-92 (74) | 45 | 30 | 5 | 15 | 100 140 120 350 | 0.01 2 100 5 | 0.6 0.25 | 1.1 0.72* | 100 10 2 | 10 | 200 | 10 | | 2 | 1 | 63 |
| BC237-92 | TO-92 (77) | 50 | 45 | 6 | 50 | 100 140 120 125 | 0.01 2 100 5 | 0.25 | 0.77* 0.6 0.55 | 10 100 2 | 4.5 | | | | 10 | 1 | 04 |
| BC237A-92 | TO-92 (77) | 50 | 45 | 6 | 50 | 100 140 120 | 0.01 2 100 | 0.25 | 0.77* 0.6 0.55 | 10 100 2 | 4.5 | | | | 10 | 1 | 04 |
| BC237B-92 | TO-92 (77) | 50 | 45 | 6 | 50 | 100 140 120 240 | 0.01 2 100 5 | 0.25 | 0.77* 0.6 0.55 | 10 100 2 | 4.5 | | | | 10 | 1 | 04 |



| Type No. | Case Style | V _{CE} [*] V _{CB} | | V _{CE} (V) Min | V _{EB} (V) Min | I _{CS} [*] I _{CB} (mA) Max | V _{CB} (V) | H _{FE} h _{FE} 1 kHz [*] | | I _C & V _{CE} (mA) & (V) | | V _{CE} (SAT) (V) Max | | V _{BE} (SAT) & V _{BE} (ON) [*] (V) Min Max | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-----------|---------------|---|-----|-------------------------------|-------------------------------|--|------------------------|--|--------------------------|--|------------------|-------------------------------------|----------------------|---|----------------|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| | | Min | Max | | | | | Min | Max | Min | Max | Min | Max | Min | Max | | | | | | | | |
| BC238-92 | TO-92 (77) | 30 | | 20 | 5 | 50 | 20 | | 100 140 120 125 | 0.01 2 100 900* | 5 5 5 5 | 0.25 | 0.77* 0.6 0.55 | 0.70* 100 2 | 10 100 2 | 4.5 | | | | 10 | 1 | 04 | |
| BC238A-92 | TO-92 (77) | 30 | | 20 | 5 | 50 | 20 | | 100 140 120 125 | 0.01 2 100 900* | 5 5 5 5 | 0.25 | 0.77* 0.6 0.55 | 0.70* 100 2 | 10 100 2 | 4.5 | | | | 10 | 1 | 04 | |
| BC238B-92 | TO-92 (77) | 30 | | 20 | 5 | 50 | 20 | | 100 140 120 240 | 0.01 2 100 500* | 5 5 5 5 | 0.25 | 0.77* 0.6 0.55 | 0.70* 100 2 | 10 100 2 | 4.5 | | | | 10 | 1 | 04 | |
| BC238C-92 | TO-92 (77) | 30 | | 20 | 5 | 50 | 20 | | 100 140 120 450 | 0.01 2 100 900* | 5 5 5 5 | 0.25 | 0.77* 0.6 0.55 | 0.70* 100 2 | 10 100 2 | 4.5 | | | | 10 | 1 | 04 | |
| BC239-92 | TO-92 (77) | 30 | | 20 | 5 | 50 | 20 | | 100 140 120 240 | 0.01 2 100 900* | 5 5 5 5 | 0.25 | 0.77* 0.6 0.55 | 0.70* 100 2 | 10 100 2 | 4.5 | | | | 4 | 1 | 04 | |
| BC239B-92 | TO-92 (77) | 30 | | 20 | 5 | 50 | 20 | | 100 140 120 240 | 0.01 2 100 500* | 5 5 5 5 | 0.25 | 0.77* 0.6 0.55 | 0.70* 100 2 | 10 100 2 | 4.5 | | | | 4 | 1 | 04 | |
| BC239C-92 | TO-92 (77) | 30 | | 20 | 5 | 50 | 20 | | 100 140 120 450 | 0.01 2 100 900* | 5 5 5 5 | 0.25 | 0.77* 0.6 0.55 | 0.70* 100 2 | 10 100 2 | 4.5 | | | | 4 | 1 | 04 | |
| BC261A | TO-18 | | | 45 | | 50 | 45 | | 100 140 120 125 | 0.01 2 100 260* | 5 5 5 5 | 0.25 0.6 | 0.9 10 | 10 100 | 4.5 | | | | | 6 | 3 | 71 | |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CE} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CE} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CE} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CE} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CE} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CE} * I _{CB0} (mA) Max | V _{CB} (V) Min | HFE h _{FE} @ 1 kHz* Min Max | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} * (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-----------|---------------|--|-----------------------------|-----------------------------|---|----------------------------|--|---|---------------------------------|---|----------------------------|-----------------------------|---------------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| BC261B | TO-18 | | 45 | | 50 | 45 | 100 140 120 240 | 0.01 2 100 500* | 0.25 0.6 | 0.9 0.9 | 10 100 | | | | | 6 | 3 | 71 |
| BC262A | TO-18 | | 20 | 5 | 50 | 20 | 100 140 120 125 | 0.01 2 100 260* | 0.25 0.6 | 0.9 0.9 | 10 100 | | | | | 6 | 3 | 71 |
| BC262B | TO-18 | | 20 | 5 | 50 | 20 | 100 140 120 240 | 0.01 2 100 500* | 0.25 0.6 | 0.9 0.9 | 10 100 | | | | | 6 | 3 | 71 |
| BC263A | TO-18 | | 20 | 5 | 50 | 20 | 100 140 120 125 | 0.01 2 100 260* | 0.25 0.6 | 0.9 0.9 | 10 100 | | | | | 2.5 | 3 | 71 |
| BC263B | TO-18 | | 20 | 5 | 50 | 20 | 100 140 120 240 | 0.01 2 100 500* | 0.25 0.6 | 0.9 0.9 | 10 100 | | | | | 2.5 | 3 | 71 |
| BC307-92 | TO-92 (77) | | 45 | 5 | 100 | 20 | 100 140 120 75 | 0.01 2 100 500* | 0.18 | 0.78 1.0* | 10 100 | | | | | 10 | 1 | 71 |
| BC307A-92 | TO-92 (77) | | 45 | 5 | 100 | 20 | 100 140 120 125 | 0.01 2 100 260* | 0.18 | 0.78 1.0* | 10 100 | | | | | 10 | 1 | 71 |
| BC307B-92 | TO-92 (77) | | 45 | 5 | 100 | 20 | 100 140 120 240 | 0.01 2 100 500* | 0.18 | 0.78 1.0* | 10 100 | | | | | 10 | 1 | 71 |
| BC308-92 | TO-92 (77) | | 25 | 5 | 100 | 20 | 100 140 120 125 | 0.01 2 100 900* | 0.18 | 0.78 1.0* | 10 100 | | | | | 10 | 1 | 71 |
| BC308A-92 | TO-92 (77) | | 25 | 5 | 100 | 20 | 100 140 120 125 | 0.01 2 100 260* | 0.18 | 0.78 1.0* | 10 100 | | | | | 10 | 1 | 71 |



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | V _{CB} (V) | HFE h _{FE} 1 kHz | I _C & V _{CE} (mA) & (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)*} (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-----------|---------------|---|--------------------------------|--------------------------------|-----------------------------------|------------------------|---------------------------------|--|------------------------------------|--|-------------------------------|--------------------------------|------------------------------------|---------------------------------|-------------------|-------------------|----------------|
| BC3088-92 | TO-92 (77) | 30 | 25 | 5 | 100 | 20 | 100 140 240 | 0.01 2 500* | 0.18 | 0.78 1.0* | 10 100 | | | | 10 | 1 | 71 |
| BC308C-92 | TO-92 (77) | 30 | 25 | 5 | 100 | 20 | 100 140 240 | 0.01 2 500* | 0.18 | 0.78 1.0* | 10 100 | | | | 10 | 1 | 71 |
| BC308-92 | TO-92 (77) | 25 | 20 | 5 | 100 | 20 | 100 140 240 | 0.01 2 500* | 0.18 | 0.78 1.0 | 10 100 | | | | 4 | 1 | 71 |
| BC308E-92 | TO-92 (77) | 25 | 20 | 5 | 100 | 20 | 100 140 240 | 0.01 2 500* | 0.18 | 0.78 1.0 | 10 100 | | | | 4 | 1 | 71 |
| BC308C-92 | TO-92 (77) | 25 | 20 | 5 | 100 | 20 | 100 140 240 | 0.01 2 500* | 0.8 | 0.78 1.0 | 10 100 | | | | 4 | 1 | 71 |
| BC317 | TO-92 (72) | 50 | 45 | 6 | 30 | 20 | 110 125 | 450 500* | 0.2 0.5 | 0.77* 0.57 0.72* | 10 100 | 4 | | | 6 | 1 | 04 |
| BC317A | TO-92 (72) | 50 | 45 | 6 | 30 | 20 | 110 125 | 220 260* | 0.2 0.5 | 0.77* 0.57 0.72* | 10 100 | 4 | | | 6 | 1 | 04 |
| BC317B | TO-92 (72) | 50 | 45 | 6 | 30 | 20 | 200 240 | 450 500* | 0.2 0.5 | 0.77* 0.57 0.72* | 10 100 | 4 | | | 6 | 1 | 04 |
| BC318 | TO-92 (72) | 30 | 20 | 5 | 30 | 20 | 110 125 | 800 900* | 0.2 0.5 | 0.77* 0.57 0.72* | 10 100 | 4 | | | 6 | 1 | 04 |
| BC318A | TO-92 (72) | 30 | 20 | 5 | 30 | 20 | 110 125 | 220 260* | 0.2 0.5 | 0.77* 0.57 0.72* | 10 100 | 4 | | | 6 | 1 | 04 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CE} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CE} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CE} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CE} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CS} [*] V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | ICES [*] I _{CB0} (mA) Max | V _{CB} (V) | HFE h _{FE} @ 1 kHz Min Max | I _C & V _{CE} (mA) (V) Min Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} [*] (V) (V) Min Max | I _C (mA) Min Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|---|-----------------------------|-----------------------------|---|---------------------|---|---|---------------------------------|---|--------------------------------|-----------------------------|---------------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| BC318B | TO-29 (72) | 30 | 20 | 5 | 30 | 20 | 200 480 240 | 2 5 | 0.2 0.5 | 0.77* 0.57 0.72* 2 | 10 100 | 4 | | | | 6 | 1 | 04 |
| BC318C | TO-92 (72) | 30 | 20 | 5 | 30 | 20 | 100 480 450 | 0.01 2 900* | 0.2 0.5 | 0.77* 0.57 0.72* 2 | 10 100 | 4 | | | | 6 | 1 | 04 |
| BC319 | TO-92 (72) | 30 | 20 | 5 | 30 | 20 | 40 200 240 | 0.01 2 900* | 0.2 0.5 | 0.77* 0.57 0.72* 2 | 10 100 | 4 | | | | 4 | 1 | 04 |
| BC319B | TO-92 (72) | 30 | 20 | 5 | 30 | 20 | 200 450 240 | 2 5 | 0.2 0.5 | 0.77* 0.57 0.72* 2 | 10 100 | 4 | | | | 4 | 1 | 04 |
| BC319C | TO-92 (72) | 30 | 20 | 5 | 30 | 20 | 100 420 450 | 0.01 2 900* | 0.2 0.5 | 0.77* 0.57 0.72* 2 | 10 100 | 4 | | | | 4 | 1 | 04 |
| BC327 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 100 | 300 100 | 0.7 | 12* 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC327-10 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 63 | 300 160 | 0.7 | 1.2* 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC327-16 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 70 | 300 250 | 0.7 | 1.2* 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC327-25 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 160 | 300 400 | 0.7 | 1.2* 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC328 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 40 100 | 300 600 | 0.7 | 1.2 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC328-10 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 40 63 | 300 160 | 0.7 | 1.2 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC328-16 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 40 100 | 300 250 | 0.7 | 1.2 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC328-25 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 40 160 | 300 400 | 0.7 | 1.2 300 | 500 | 4 | | | | 4 | 1 | 67 |
| BC337 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 100 | 300 100 | 0.7 | 1.2* 300 | 500 | 4 | | | | 4 | 1 | 14 |
| BC377-10 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 63 | 300 160 | 0.7 | 1.2* 300 | 500 | 4 | | | | 4 | 1 | 14 |
| BC337-16 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 100 | 300 250 | 0.7 | 1.2* 300 | 500 | 4 | | | | 4 | 1 | 14 |
| BC337-25 | TO-92 (77) | 50 [†] | 45 | 5 | 100 [†] | 45 | 40 160 | 300 400 | 0.7 | 1.2* 300 | 500 | 4 | | | | 4 | 1 | 14 |



| Type No. | Case Style | V _{CE} [†] V _{CE0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CE} [†] I _{CB0} (mA) Max | V _{CB} (V) | h _{FE} h _{FE} 1 kHz* Min | I _C & V _{CE} (mA) & (V) Max | V _{CE} (SAT) (V) Max | V _{BE} (SAT) & V _{BE} (ON)* (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|--|--------------------------------|--------------------------------|---|------------------------|---|---|-------------------------------------|--|-------------------------------|--------------------------------|--------------------------------|--------------------------------|---------------------------------|-------------------|----------------|-------------|
| BC338 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 40 100 | 300 100 | 0.7 | 1.2* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC338-10 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 63 100 | 300 100 | 0.7 | 1.2* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC338-16 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 40 100 | 300 100 | 0.7 | 1.2* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC338-25 | TO-92 (77) | 30 [†] | 25 | 5 | 100 [†] | 25 | 40 160 | 300 100 | 0.7 | 1.2* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC485 | TO-92 (77) | 45 | 45 | 5 | 100 | 30 | 15 40 60 | 1A 10 400 | 0.5 | 1.2 .12* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC485A | TO-92 (77) | 45 | 45 | 5 | 100 | 30 | 15 40 100 | 1A 10 250 | 0.5 | 1.2 1.2* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC485B | TO-92 (77) | 45 | 45 | 5 | 100 | 30 | 15 40 160 | 1A 10 400 | 0.5 | 1.2 1.2* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC485L | TO-92 (77) | 45 | 45 | 5 | 100 | 30 | 15 40 60 | 1A 10 150 | 0.5 | 1.2 1.2* | 500 300 | 4 | | | | 4 | 1 | 14 |
| BC547 | TO-92 (77) | 50 | 45 | 6 | 10 | 20 | 125 | 500* 2 | 0.25 0.6 | 0.77* 0.70* 2 | 10 100 | 4.5 | | | | 10 | 1 | 04 |
| BC547A | TO-92 (77) | 50 | 45 | 6 | 10 | 20 | 125 | 260* 2 | 0.25 0.6 | 0.77* 0.70* 2 | 10 100 | 4.5 | | | | 10 | 1 | 04 |
| BC547B | TO-92 (77) | 50 | 45 | 6 | 10 | 20 | 240 | 500* 2 | 0.25 0.6 | 0.77* 0.70* 2 | 10 100 | 4.5 | | | | 10 | 1 | 04 |
| BC547C | TO-92 (77) | 50 | 45 | 6 | 10 | 20 | 450 | 900* 2 | 0.25 0.6 | 0.77* 0.70* 2 | 10 100 | 4.5 | | | | 10 | 1 | 04 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CC} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CC} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CC} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = 5V. (14) I_C = 500mA, V_{CC} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CE0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CE} * I _{CB0} (mA) Max | V _{CB} (V) | H _{FE} h _{FE} @ 1 kHz* Min Max | I _C & V _{CE} (mA) & (V) Max | V _{CE(SAT)} & V _{BE(ON)*} (V) & (V) Max Min | V _{BE(SAT)} & V _{BE(ON)*} (V) & (V) Max Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--|-----------------------------|-----------------------------|---|---------------------|--|---|---|---|----------------------------|-----------------------------|---------------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| BC548 | TO-92 (77) | 30 | 20 | 5 | 10 | 20 | 125 900* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 4.5 | 4.5 | | | 10 | 1 | 04 | |
| BC548A | TO-92 (77) | 30 | 20 | 5 | 10 | 20 | 125 260* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 4.5 | 4.5 | | | 10 | 1 | 04 | |
| BC548B | TO-92 (77) | 30 | 20 | 5 | 10 | 20 | 240 500* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 4.5 | 4.5 | | | 10 | 1 | 04 | |
| BC548C | TO-92 (77) | 30 | 20 | 5 | 10 | 20 | 450 900* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 4.5 | 4.5 | | | 10 | 1 | 04 | |
| BC549 | TO-92 (77) | 30 | 20 | 5 | 10 | 20 | 240 900* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 4.5 | 4.5 | | | 4 | 1 | 04 | |
| BC549B | TO-92 (77) | 30 | 20 | 5 | 10 | 20 | 240 500* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 4.5 | 4.5 | | | 4 | 1 | 04 | |
| BC549C | TO-92 (77) | 30 | 20 | 5 | 10 | 20 | 450 900* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 4.5 | 4.5 | | | 4 | 1 | 04 | |
| BC550 | TO-92 (77) | 50 | 45 | 5 | 10 | 45 | 240 900* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 3 | 3 | | | 3 | 1 | 04 | |
| BC550B | TO-92 (77) | 50 | 45 | 5 | 10 | 45 | 240 500* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 3 | 3 | | | 3 | 1 | 04 | |
| BC550C | TO-92 (77) | 50 | 45 | 5 | 10 | 45 | 450 900* 2 | 0.25 0.6 | 0.25 0.77* 10 100 | 0.25 0.77* 10 100 | 3 | 3 | | | 3 | 1 | 04 | |
| BC557 | TO-92 (77) | 50 | 45 | 5 | 100 | 20 | 75 260* 2 | 0.3 0.65 | 0.3 0.82* 10 100 | 0.3 0.82* 10 100 | 10 | 10 | | | 10 | 1 | 71 | |
| BC557A | TO-92 (77) | 50 | 45 | 5 | 100 | 20 | 125 260* 2 | 0.3 0.65 | 0.3 0.82* 10 100 | 0.3 0.82* 10 100 | 10 | 10 | | | 10 | 1 | 71 | |
| BC557B | TO-92 (77) | 50 | 45 | 5 | 100 | 20 | 240 500* 2 | 0.3 0.65 | 0.3 0.82* 10 100 | 0.3 0.82* 10 100 | 10 | 10 | | | 10 | 1 | 71 | |



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | V _{CB} (V) | f _{HE} h _{FE} 1 kHz* Min Max | I _C & V _{CE} (mA) (V) Max | V _{CE} (SAT) (V) Max | V _{BE} (SAT) & V _{BE} (ON)* (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|---|--------------------------------|--------------------------------|-----------------------------------|------------------------|---|---|-------------------------------------|---|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| BC558 | TO-92 (77) | 30 | 25 | 5 | 100 | 20 | 75 500* 2 5 | 0.3 0.65 | 0.32* 0.75 2 | 100 | | | | | | 10 | 1 | 71 |
| BC558A | TO-92 (77) | 30 | 25 | 5 | 100 | 20 | 125 260* 2 5 | 0.3 0.65 | 0.82* 0.75 2 | 100 | | | | | | 10 | 1 | 71 |
| BC558B | TO-92 (77) | 30 | 25 | 5 | 100 | 20 | 240 500* 2 5 | 0.3 0.65 | 0.82* 0.75 2 | 100 | | | | | | 10 | 1 | 71 |
| BC558C | TO-92 (77) | 30 | 25 | 5 | 100 | 20 | 450 900* 2 5 | 0.3 0.65 | 0.82* 0.75 2 | 100 | | | | | | 10 | 1 | 71 |
| BC559 | TO-92 (77) | 25 | 20 | 5 | 100 | 20 | 125 500* 2 5 | 0.3 0.65 | 0.82* 0.75* 2 | 100 | | | | | | 4 | 1 | 71 |
| BC559A | TO-92 (77) | 25 | 20 | 5 | 100 | 20 | 125 260* 2 5 | 0.3 0.65 | 0.82* 0.75* 2 | 100 | | | | | | 4 | 1 | 71 |
| BC559B | TO-92 (77) | 25 | 20 | 5 | 100 | 20 | 240 500* 2 5 | 0.3 0.65 | 0.82* 0.75* 2 | 100 | | | | | | 4 | 1 | 71 |
| BC559C | TO-92 (77) | 25 | 20 | 5 | 100 | 20 | 450 900* 2 5 | 0.3 0.65 | 0.82* 0.75* 2 | 100 | | | | | | 4 | 1 | 71 |
| BC560 | TO-92 (77) | 50 | 45 | 5 | 100 | 45 | 125 500* 2 5 | 0.3 0.65 | 0.82* 0.75* 2 | 100 | | | | | | 2 | 1 | 71 |
| BC560A | TO-92 (77) | 50 | 45 | 5 | 100 | 45 | 125 260* 2 5 | 0.3 0.65 | 0.82* 0.75* 2 | 100 | | | | | | 2 | 1 | 71 |
| BC560B | TO-92 (77) | 50 | 45 | 5 | 100 | 45 | 240 500* 2 5 | 0.3 0.65 | 0.82* 0.75* 2 | 100 | | | | | | 2 | 1 | 71 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CC} = 20V, I_B = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CC} = 10V, I_B = I_B² = 10mA. (5) I_C = 10mA, V_{CC} = 3V, I_B = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CC} = 6V, I_B = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CC} = 10V, I_B = I_B² = 75mA. (12) I_C = 300mA, V_{CC} = 25V, I_B = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CC} = 25V, I_B = I_B² = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE(S)} V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} [*] (mA) Max | V _{CB} (V) | HFE h _{FE} 1 kHz Min | I _C (mA) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|--|--------------------------------|--------------------------------|--|------------------------|--|-----------------------------------|------------------------------------|--|-------------------------------|--------------------------------|--------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| BC560C | TO-92 (77) | 50 | 45 | 5 | 100 | 45 | 450 | 900* 2 | 0.3 0.65 | 0.82* 0.75* 2 | 10 100 | | | | | 2 | 1 | 71 |
| BCY56 | TO-18 | 45 | 45 | 5 | 100 | 20 | 100 125 40 | 450* 2 500* 2 0.01 5 | 0.6 0.6 | 0.7* 2 | 2 | | | | | 5 | 1 | 04 |
| BCY67 | TO-18 | 25 | 20 | 5 | 100 | 20 | 200 200 240 100 | 10 5 2 5 900* 2 5 0.01 5 | 0.6 | 0.7* 2 | 2 | | | | | 5 | 1 | 04 |
| BCY68 | TO-18 | | 32 | 7 | 10 [†] | 32 | 40 80 125 | 100 1 1000 10 1 700* 2 5 | 0.35 0.7 | 0.85 1.2 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY68-7 | TO-18 | | 32 | 7 | 10 [†] | 32 | 40 80 125 | 100 1 1000 10 1 250* 2 5 | 0.35 0.7 | 0.85 1.2 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY68-8 | TO-18 | | 32 | 7 | 10 [†] | 32 | 40 80 175 | 100 1 1000 10 1 350* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY68-9 | TO-18 | | 32 | 7 | 10 [†] | 32 | 40 80 250 | 100 1 1000 10 1 500* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY68-10 | TO-18 | | 32 | 7 | 10 [†] | 32 | 40 80 350 | 100 1 1000 10 1 700* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY69 | TO-18 | | 45 | 7 | 10 [†] | 45 | 40 80 125 | 100 1 1000 10 1 700* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY69-7 | TO-18 | | 45 | 7 | 10 [†] | 45 | 40 80 125 | 100 1 1000 10 1 700* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY69-8 | TO-18 | | 45 | 7 | 10 [†] | 45 | 40 80 175 | 100 1 1000 10 1 350* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY69-9 | TO-18 | | 45 | 7 | 10 [†] | 45 | 40 80 250 | 100 1 1000 10 1 500* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |
| BCY69-10 | TO-18 | | 45 | 7 | 10 [†] | 45 | 40 80 350 | 100 1 1000 10 1 700* 2 5 | 0.35 0.7 | 0.85 1.2 0.55 0.7* 2 | 10 100 2 | 6 | 125 | 10 | 800 | 6 | 4/1 | 04 |



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | ICES* I _{CB0} (mA) Max | V _{CB} (V) | HFE h _{FE} @ 1 kHz* Min Max | I _C & V _{CE} (mA) (V) Min Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)*} (V) Min Max | I _C (mA) Min Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) @ Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--|-----------------------------|-----------------------------|---------------------------------------|---------------------|--|---|---------------------------------|--|--------------------------------|-----------------------------|---------------------------------|---------------------------------|------------------------------|----------------|----------------|-------------|
| BCY70 | TO-18 | 50 | 40 | 5 | 10 | 40 | 0.1 45 15 | 1 1 1 | 0.25 | 0.6 0.9 | 10 | 6 | 250 | 10 | 420 | 6 | 5/6 | 71 |
| BCY71 | TO-18 | 45 | 45 | 5 | 500 | 45 | 0.01 0.1 1 100 | 1 1 1 1 | 0.25 | 0.6 1.2 | 10 | 6 | 200 | 10 | | 2 | 6 | 71 |
| BCY71A | TO-18 | 45 | 45 | 5 | 500 | 45 | 0.01 0.1 1 100 | 1 1 1 1 | 0.25 | 0.6 1.2 | 10 | 6 | 300 | 10 | 420 | 2 | 6 | 71 |
| BCY72 | TO-18 | 25 | 25 | 5 | 500 | 20 | 1 10 | 1 1 | 0.25 0.5 | 1.2 50 | 10 50 | 6 | 200 | 10 | 420 | 6 | 5/6 | 71 |
| BD135 | TO-126 | 45 | 45 | 5 | 100 | 30 | 25 40 | 500 2 | 0.5 | 1.0* | 500 | | 50 | 50 | 420 | 6 | 5/6 | 37 |
| BC136 | TO-126 | 45 | 45 | 5 | 100 | 30 | 25 40 | 500 2 | 0.5 | 1.0* | 500 | | 50 | 50 | | | | 77 |
| BD137 | TO-126 | 60 | 60 | 5 | 100 | 30 | 25 40 | 500 2 | 0.5 | 1.0* | 500 | | 50 | 50 | 420 | 6 | 5/6 | 38 |
| BD138 | TO-126 | 60 | 60 | 5 | 100 | 30 | 25 40 | 500 2 | 0.5 | 1.0* | 500 | | 50 | 50 | | | | 78 |
| BD139 | TO-126 | 80 | 80 | 5 | 100 | 30 | 25 40 | 500 2 | 0.5 | 1.0* | 500 | | 50 | 50 | 420 | 6 | 5/6 | 39 |
| BD140 | TO-126 | 80 | 80 | 5 | 100 | 30 | 25 40 | 500 2 | 0.5 | 1.0* | 500 | | 50 | 50 | 420 | 6 | 5/6 | 79 |
| BD201 | TO-220 | 60 | 45 | 5 | 10 μA | 40 | 30 30 75 | 3A 1A 500 | 1.0 | 1.5* | 3A | | 3 | 300 | 420 | 6 | 5/6 | 4A |
| BD202 | TO-220 | 60 | 45 | 5 | 10 μA | 40 | 30 30 75 | 3A 1A 500 | 1.0 | 1.5* | 3A | | 3 | 300 | 420 | 6 | 5/6 | 5A |
| BD233 | TO-126 | 45 | 45 | | 100 μA | 45 | 25 40 | 1A 2 | 0.6 | 1.3* | 1A | | 3 | 250 | 420 | 6 | 5/6 | 2C |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz, (2) I_C = 100mA, V_{CC} = 20V, I_B¹ = I_B² = 5mA, (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz, (4) I_C = 100mA, V_{CC} = 10V, I_B¹ = I_B² = 10mA, (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA, (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz, (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz, (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz, (9) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA, (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz, (11) I_C = 150mA, V_{CC} = 10V, I_B¹ = I_B² = 75mA, (12) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA, (13) I_C = 10 μA, V_{CE} = 5V, f = WB, (14) I_C = 500mA, V_{CC} = 25V, I_B¹ = 50mA, I_B² = 25mA, (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA, (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE(S)} V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} [*] (mA) Max | V _{CB} (V) | h _{FE} h _{FE} 1 kHz [*] Min Max | I _C & V _{CE} (mA) (V) Min Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|---|-----------------------------|-----------------------------|--|---------------------|---|---|------------------------------------|---|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| BD234 | TO-126 | 45 | 45 | | 100 μA | 45 | 25 40 | 1A 150 2 | 0.6 | 1.3* | 1A | | 3 | 250 | 420 | 6 | 5/6 | 3C |
| BD235 | TO-126 | 60 | 60 | | 100 μA | 60 | 25 40 | 1A 150 2 | 0.6 | 1.3* | 1A | | 3 | 250 | 420 | 6 | 5/6 | 2C |
| BD236 | TO-126 | 60 | 60 | | 100 μA | 60 | 25 40 | 1A 150 2 | 0.6 | 1.3* | 1A | | 3 | 250 | 420 | 6 | 5/6 | 3C |
| BD237 | TO-126 | 80 | 80 | | 100 μA | 80 | 25 40 | 1A 150 2 | 0.6 | 1.3* | 1A | | 3 | 250 | 420 | 6 | 5/6 | 2C |
| BD238 | TO-126 | 80 | 80 | | 100 μA | 80 | 25 40 | 1A 150 2 | 0.6 | 1.3* | 1A | | 3 | 250 | 420 | 6 | 5/6 | 3C |
| BD239 | TO-220 | | 45 | | 200 μA* | 45 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 4F(2C) |
| BD239A | TO-220 | | 60 | | 200 μA* | 60 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 4F(2C) |
| BD239B | TO-220 | | 80 | | 200 μA* | 80 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 4F(2C) |
| BD239C | TO-220 | | 100 | | 200 μA* | 100 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 4F(2C) |
| BD240 | TO-220 | | 45 | | 200 μA* | 45 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 5F(3C) |
| BD240A | TO-220 | | 60 | | 200 μA* | 60 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 5F(3C) |
| BD240B | TO-220 | | 80 | | 200 μA* | 80 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 5F(3C) |
| BD240C | TO-220 | | 80 | | 200 μA* | 80 | 15 40 | 1A 200 4 | 0.7 | 1.3* | 1A | | 3 | 200 | 420 | 6 | 5/6 | 5F(3C) |
| BD241 | TO-220 | | 45 | | 200 μA* | 45 | 10 25 | 3A 1A 4 | 1.3 | 1.8* | 3A | | 3 | 500 | 420 | 6 | 5/6 | 4F(2C) |
| BD241A | TO-220 | | 60 | | 200 μA* | 60 | 10 25 | 3A 1A 4 | 1.3 | 1.8* | 3A | | 3 | 500 | 420 | 6 | 5/6 | 4F(2C) |
| BD241B | TO-220 | | 80 | | 200 μA* | 80 | 10 25 | 3A 1A 4 | 1.3 | 1.8* | 3A | | 3 | 500 | 420 | 6 | 5/6 | 4F(2C) |
| BD241C | TO-220 | | 80 | | 200 μA* | 100 | 10 25 | 3A 1A 4 | 1.3 | 1.8* | 3A | | 3 | 500 | 420 | 6 | 5/6 | 4F(2C) |
| BD242 | TO-220 | | 80 | | 200 μA* | 45 | 10 25 | 3A 1A 4 | 1.2 | 1.8* | 3A | | 3 | 500 | 420 | 6 | 5/6 | 5E(3E) |
| BD242A | TO-220 | | 60 | | 200 μA* | 60 | 10 25 | 3A 1A 4 | 1.2 | 1.8* | 3A | | 3 | 500 | 420 | 6 | 5/6 | 5E(3E) |



| Type No. | Case Style | V _{CE0} [*] V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} [*] (mA) Max | V _{CB} (V) | H _{FE} I _{FE} @ 1 kHz [*] Min Max | I _C & V _{CE} (mA) (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} [*] (V) @ I _C (mA) Min Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C @ (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No |
|-----------|----------------|--|-----------------------------|-----------------------------|--|---------------------|--|--|---------------------------------|---|-----------------------------|---------------------------------|------------------------------|------------------------------|----------------|----------------|------------|
| BD242B | TO-220 | 80 | 80 | | 200 μA [*] | 80 | 10 25 | 3A 1A 4 | 1.2 | 1.8 [*] | 3 | 3 | 500 | 420 | 6 | 5/6 | 5E(3E) |
| BD242C | TO-220 | 80 | 100 | | 200 μA [*] | 100 | 10 25 | 3A 1A 4 | 1.2 | 1.8 [*] | | 3 | 500 | 420 | 6 | 5/6 | 5E(3E) |
| BD370A | TO-92+ (91) | 80 | 45 | | 100 | 45 | 25 40 | 500 400 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370A-10 | TO-92+ (91) | 80 | 45 | | 100 | 45 | 25 63 | 500 160 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370A-16 | TO-92+ (91) | 80 | 45 | | 100 | 45 | 100 250 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370A-25 | TO-92+ (91) | 80 | 45 | | 100 | 45 | 160 400 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370B | TO-92+ (91) | 80 | 60 | | 100 | 60 | 25 40 | 500 400 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370B-10 | TO-92+ (91) | 80 | 60 | | 100 | 60 | 25 63 | 500 160 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370B-16 | TO-92+ (91) | 80 | 60 | | 100 | 60 | 100 250 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370B-25 | TO-92+ (91) | 80 | 60 | | 100 | 60 | 160 400 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370C | TO-92+ (91) | 80 | 80 | | 100 | 80 | 40 400 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370-6 | TO-92+ (91) | 80 | 80 | | 100 | 80 | 40 400 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370C-10 | TO-92+ (91) | 80 | 80 | | 100 | 80 | 63 160 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370C-16 | TO-92+ (91) | 80 | 80 | | 100 | 80 | 100 250 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD370D | TO-92+ (91) | 80 | 100 | | 100 | 80 | 25 40 | 500 400 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD370D-6 | TO-92+ (91) | 80 | 100 | | 100 | 80 | 40 100 | 500 100 2 1 | 0.7 | 1.2 [*] | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CE} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CE} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CE} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CE} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CE} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | V _{CB} (V) | HFE h _{FE} 1 kHz* Min | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} * (V) Min | I _C (mA) Max | f _T (MHz) Min | f _T (MHz) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-----------|----------------|--|-----------------------------|-----------------------------|-----------------------------------|---------------------|---|---|------------------------------------|---|-------------------------------|--------------------------------|--------------------------------|---------------------------------|-------------------|-------------------|----------------|
| BD370D-10 | TO-92+ (91) | 80 | 100 | 80 | 100 | 45 | 25 63 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD371A | TO-92+ (91) | 80 | 45 | 45 | 100 | 45 | 25 40 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371A-10 | TO-92+ (91) | 80 | 45 | 45 | 100 | 45 | 25 63 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371A-16 | TO-92+ (91) | 80 | 45 | 45 | 100 | 45 | 25 100 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371A-25 | TO-92+ (91) | 80 | 45 | 45 | 100 | 45 | 25 160 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371B | TO-92+ (91) | 80 | 60 | 60 | 100 | 60 | 25 40 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371B-10 | TO-92+ (91) | 80 | 60 | 60 | 100 | 60 | 25 63 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371B-16 | TO-92+ (91) | 80 | 60 | 60 | 100 | 60 | 25 100 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371B-25 | TO-92+ (91) | 80 | 60 | 60 | 100 | 60 | 25 160 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371C | TO-92+ (91) | 80 | 80 | 80 | 100 | 80 | 25 40 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371C-6 | TO-92+ (91) | 80 | 80 | 80 | 100 | 80 | 25 40 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371C-10 | TO-92+ (91) | 80 | 80 | 80 | 100 | 80 | 25 63 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371C-16 | TO-92+ (91) | 80 | 80 | 80 | 100 | 80 | 25 100 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD371D | TO-92+ (91) | 80 | 100 | 100 | 100 | 100 | 25 40 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD371D-6 | TO-92+ (91) | 80 | 100 | 100 | 100 | 100 | 25 40 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD371D-10 | TO-92+ (91) | 80 | 100 | 100 | 100 | 100 | 25 63 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD372A | TO-92+ (90) | 80 | 45 | 45 | 100 | 45 | 25 40 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372A-10 | TO-92+ (90) | 80 | 45 | 45 | 100 | 45 | 25 63 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372A-16 | TO-92+ (90) | 80 | 45 | 45 | 100 | 45 | 25 100 | 500 100 1 | 0.7 | 1.2* | 1A | 50 | 200 | 420 | 6 | 5/6 | 78 |



| Type No. | Case Style | V _{CE} [*] V _{CE} ^{BO} (V) Min | V _{CE} ⁰ (V) Min | V _{EB} ⁰ (V) Min | I _{CB} [*] I _{CB} ⁰ (mA) Max | V _{CB} (V) | H _{FE} h _{FE} @ 1 kHz Min Max | I _C & V _{CE} (mA) (V) | V _{CE} (SAT) (V) Max | V _{BE} (ON) [*] (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-----------|----------------|---|--|--|---|------------------------|--|--|-------------------------------------|---|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| BD372A-25 | TO-92+ (90) | 80 | 45 | | 100 | 45 | 25 160 400 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372B | TO-92 (90) | 80 | 60 | | 100 | 60 | 25 40 400 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372B-10 | TO-92 (90) | 80 | 60 | | 100 | 60 | 25 63 160 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372B-16 | TO-92 (90) | 80 | 60 | | 100 | 60 | 25 100 250 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372B-25 | TO-92 (90) | 80 | 60 | | 100 | 60 | 25 160 400 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372C | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 40 400 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372C-6 | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 40 100 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372C-10 | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 63 160 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372C-16 | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 100 250 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD372D | TO-92+ (90) | 80 | 100 | | 100 | 100 | 25 40 400 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD372D-6 | TO-92+ (90) | 80 | 100 | | 100 | 100 | 25 40 100 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD372D-10 | TO-92+ (90) | 80 | 100 | | 100 | 100 | 25 63 160 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD373A | TO-92+ (90) | 80 | 45 | | 100 | 45 | 25 63 40 400 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373A-10 | TO-92+ (90) | 80 | 45 | | 100 | 45 | 25 63 160 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373A-16 | TO-92+ (90) | 80 | 45 | | 100 | 45 | 25 100 250 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373A-25 | TO-92+ (90) | 80 | 45 | | 100 | 45 | 25 160 400 100 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CC} = 20V, I_B = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CC} = 10V, I_B = I_B² = 10mA. (5) I_C = 10mA, V_{CC} = 3V, I_B = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CC} = 6V, I_B = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CC} = 10V, I_B = I_B² = 75mA. (12) I_C = 300mA, V_{CC} = 25V, I_B = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = 100kHz. (14) I_C = 500mA, V_{CC} = 25V, I_B = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * @ (mA) Max | V _{CB} (V) | h _{FE} 1 kHz* Min | h _{FE} Max | I _C & V _{CE} @ (mA) & (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT) & V_{BE(ON)*} (V) Min} | I _C @ (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | f _T Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|-----------|-------------|---------------------------|--------------------------|--------------------------|-------------------------------|---------------------|----------------------------|---------------------|---|------------------------------|--|---------------------------|--------------------------|--------------------------|--------------------|---------------------------|-------------|----------------|-------------|
| BD373B | TO-92+ (90) | 80 | 60 | | 100 | 60 | 25 | 40 | 500 2 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373B-10 | TO-92+ (90) | 80 | 60 | | 100 | 60 | 25 | 63 | 500 2 160 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373B-16 | TO-92+ (90) | 80 | 60 | | 100 | 60 | 25 | 100 | 500 2 250 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373B-25 | TO-92+ (90) | 80 | 60 | | 100 | 60 | 25 | 160 | 500 2 400 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373C | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 | 40 | 500 2 400 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373C-6 | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 | 40 | 500 2 100 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373C-10 | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 | 63 | 500 2 160 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373C-16 | TO-92+ (90) | 80 | 80 | | 100 | 80 | 25 | 100 | 500 2 250 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD373D | TO-92+ (90) | 80 | 100 | | 100 | 100 | 25 | 40 | 500 2 400 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD373D-6 | TO-92+ (90) | 80 | 100 | | 100 | 100 | 25 | 40 | 500 2 100 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD373D-10 | TO-92+ (90) | 80 | 100 | | 100 | 100 | 25 | 63 | 500 2 160 100 1 | 0.7 | 1.2* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD375 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 40 | 1A 2 375 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD375-6 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 40 | 1A 2 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD375-10 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 63 | 1A 2 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD375-16 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 100 | 1A 2 250 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD375-25 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 150 | 1A 2 375 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD376 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 40 | 1A 2 375 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD376-6 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 40 | 1A 2 100 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD376-10 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 | 63 | 1A 2 160 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |



| Type No. | Case Style | V _{CE0} (V) Min | V _{CE0} (V) Min | V _{BE0} (V) Min | I _{CB0} (nA) Max | V _{CEB} (V) Max | HFE h _{FE} 1 kHz* | I _C & V _{CE} (mA) & (V) | V _{CE(SAT)} (V) Max | V _{BE(ON)} * (V) Min | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | T _{est} Conditon: | Process No. |
|----------|------------|--------------------------------|--------------------------------|--------------------------------|---------------------------------|--------------------------------|----------------------------------|--|------------------------------------|-------------------------------------|-------------------------------|--------------------------------|--------------------------------|-------------------------------|---------------------------------|-------------------|-------------------------------|----------------|
| BD376-16 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 100 | 1A 200 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD376-25 | TO-126 | 50 | 45 | | 2 μA | 45 | 20 150 | 1A 375 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD377 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 40 | 1A 375 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD377-6 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 40 | 1A 100 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD377-10 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 63 | 1A 160 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD377-16 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 100 | 1A 250 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD377-25 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 150 | 1A 375 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 38 |
| BD378 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 40 | 1A 375 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD378-6 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 40 | 1A 100 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD378-10 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 63 | 1A 160 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD378-16 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 100 | 1A 250 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD378-25 | TO-126 | 75 | 60 | | 2 μA | 60 | 20 150 | 1A 375 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 78 |
| BD379 | TO-126 | 100 | 80 | | 2 μA | 80 | 20 40 | 1A 375 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD379-6 | TO-126 | 100 | 80 | | 2 μA | 80 | 20 40 | 1A 100 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD379-10 | TO-126 | 100 | 80 | | 2 μA | 80 | 20 63 | 1A 160 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD379-16 | TO-126 | 100 | 80 | | 2 μA | 80 | 20 100 | 1A 250 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CE} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CE} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CE} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CE} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CE} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CBO} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CE} * I _{CBO} (mA) Max | V _{CB} (V) Min | HFE h _{FE} @ 1 kHz* Min Max | I _C & V _{CE} (mA) (V) Min Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)*} (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | f _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--|-----------------------------|-----------------------------|---|----------------------------|--|---|------------------------------------|--|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|-------------------|----------------|
| BD379-25 | TO-126 | 100 | 80 | 80 | 2 μA | 80 | 20 150 | 1A 375 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 39 |
| BD380 | TO-126 | 100 | 80 | 80 | 2 μA | 80 | 20 40 | 1A 375 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD380-6 | TO-126 | 100 | 80 | 80 | 2 μA | 80 | 20 40 | 1A 100 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD380-10 | TO-126 | 100 | 80 | 80 | 2 μA | 80 | 63 100 | 1A 160 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD380-16 | TO-126 | 100 | 80 | 80 | 2 μA | 80 | 20 100 | 1A 250 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD380-25 | TO-126 | 100 | 80 | 80 | 2 μA | 80 | 20 150 | 1A 375 150 2 | 1.0 | 1.5* | 1A | 30 | 50 | 200 | 420 | 6 | 5/6 | 79 |
| BD433 | TO-126 | 22† | 22 | 5 | 100 μA | 22 | 50 85 40 | 2A 475 500 1 10 5 | 0.5 | 1.1* | 2A | | 3 | 250 | 420 | 6 | 5/6 | 2E |
| BD434 | TO-126 | 22† | 22 | 5 | 100 μA | 22 | 50 85 40 | 2A 475 500 1 10 5 | 0.5 | 1.1* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 3E |
| BD435 | TO-126 | 32† | 32 | 5 | 100 μA | 32 | 50 85 40 | 2A 475 500 1 10 5 | 0.5 | 1.1* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 2E |
| BD436 | TO-126 | 32† | 32 | 5 | 100 μA | 32 | 50 85 40 | 2A 475 500 1 10 5 | 0.5 | 1.1* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 3E |
| BD437 | TO-126 | 45† | 45 | 5 | 100 μA | 45 | 40 40 30 | 2A 236 500 1 10 5 | 0.6 | 1.2* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 2E |
| BD438 | TO-126 | 45† | 45 | 5 | 100 μA | 45 | 40 40 30 | 2A 236 500 1 10 5 | 0.6 | 1.2* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 3E |
| BD439 | TO-126 | 60† | 60 | 5 | 100 μA | 60 | 25 40 20 | 2A 236 500 1 10 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 2E |
| BD440 | TO-126 | 60† | 60 | 5 | 100 μA | 60 | 25 40 20 | 2A 236 500 1 10 5 | 0.8 | 1.5* | 2A | 80 | 3 | 250 | 420 | 6 | 5/6 | 3E |
| BD441 | TO-126 | 80† | 80 | 5 | 100 μA | 80 | 15 40 15 | 2A 236 500 1 10 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 2E |



| Type No. | Case Style | V _{CE} * V _{CB0} (V) | | V _{CE0} (V) Min | V _{EB0} (V) | | I _{CB0} * (mA) | | HFE h _{FE} @ 1 kHz* | | I _C & V _{CE} (mA) (V) | | V _{CE(SAT)} & V _{BE(ON)*} (V) (V) | | C _{ob} (pF) | | f _T (MHz) | | I _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|---|-----|-----------------------------|----------------------|-----|----------------------------|----------------|---------------------------------|-------------|--|------|--|-----|----------------------|-----|----------------------|-----|------------------------------|----------------|----------------|-------------|
| | | Min | Max | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | |
| BD442 | TO-126 | 80† | | 80 | 5 | 80 | 100 μA | 15 40 15 | 2A 500 10 | 1 1 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 3E | | |
| BD533 | TO-220 | 80† | | 45 | 5 | 45 | 100 μA | 25 40 20 | 2A 500 10 | 2 2 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 4E | | |
| BD534 | TO-220 | 80† | | 45 | 5 | 45 | 100 μA | 25 40 20 | 2A 500 10 | 2 2 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 5E | | |
| BD535 | TO-220 | 80† | | 60 | 5 | 60 | 100 μA | 25 40 20 | 2A 500 10 | 2 2 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 4E | | |
| BD536 | TO-220 | 80† | | 60 | 5 | 60 | 100 μA | 25 40 20 | 2A 500 10 | 2 2 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 5E | | |
| BD537 | TO-220 | 80† | | 80 | 5 | 80 | 100 μA | 15 40 15 | 2A 500 10 | 2 2 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 4E | | |
| BD538 | TO-220 | 80† | | 80 | 5 | 80 | 100 μA | 15 40 15 | 2A 500 10 | 2 2 5 | 0.8 | 1.5* | 2A | 30 | 3 | 250 | 420 | 6 | 5/6 | 5E | | |
| BD633 | TO-220 | 45 | | 45 | 5 | 45 | 200 μA† | 25 40 | 1A 25 | 2 2 | 0.6 | 1.3* | 1A | 30 | 3 | 250 | 420 | 6 | 5/6 | 4F | | |
| BD634 | TO-220 | 45 | | 45 | 5 | 45 | 200 μA† | 25 40 | 1A 25 | 2 2 | 0.6 | 1.3* | 1A | 30 | 3 | 250 | 420 | 6 | 5/6 | 5F | | |
| BD635 | TO-220 | 60 | | 60 | 5 | 60 | 200 μA† | 25 40 | 1A 25 | 2 2 | 0.6 | 1.3* | 1A | 30 | 3 | 250 | 420 | 6 | 5/6 | 4F | | |
| BD636 | TO-220 | 60 | | 60 | 5 | 60 | 200 μA† | 25 40 | 1A 25 | 2 2 | 0.6 | 1.3* | 1A | 30 | 3 | 250 | 420 | 6 | 5/6 | 5F | | |
| BD637 | TO-220 | 100 | | 80 | 5 | 80 | 200 μA† | 25 40 | 1A 25 | 2 2 | 0.6 | 1.3* | 1A | 30 | 3 | 250 | 420 | 6 | 5/6 | 4F | | |
| BD638 | TO-220 | 100 | | 80 | 5 | 80 | 200 μA† | 25 40 | 1A 25 | 2 2 | 0.6 | 1.3 | 1A | 30 | 3 | 250 | 420 | 6 | 5/6 | 5F | | |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CE} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CE} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CE} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CE} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CE} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CE} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CE} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CEO} (V) Min | V _{EB0} (V) Min | I _{CE} * I _{CB0} (mA) Max | V _{CB} (V) Min | HFE h _{fe} @ 1 kHz* Min | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)*} (V) Min | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|--|-----------------------------|-----------------------------|---|----------------------------|---|---|---------------------------------|---|----------------------------|------------------------------|----------------|----------------|-------------|
| BD675 | TO-126 | 45 | 45 | 200 μA | 45 | 750 | 1.5A | 3 | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 2J |
| BD675A | TO-126 | 45 | 45 | 200 μA | 45 | 750 | 2A | 3 | 2.8 | 2.5* | 2A | 1 | 1.5A | | 2J |
| BD676 | TO-126 | 45 | 45 | 200 μA | 45 | 750 | 1.5A | 3V | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 3J |
| BD676A | TO-126 | 45 | 45 | 200 μA | 45 | 750 | 2A | 3V | 2.8 | 2.5* | 2A | 1 | 1.5A | | 3J |
| BD677 | TO-126 | 60 | 60 | 200 μA | 60 | 750 | 1.5A | 3V | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 2J |
| BD677A | TO-126 | 60 | 60 | 200 μA | 60 | 750 | 2A | 3V | 2.8 | 2.5* | 2A | 1 | 1.5A | | 2J |
| BD678 | TO-126 | 60 | 60 | 200 μA | 60 | 750 | 1.5A | 3V | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 3J |
| BD678A | TO-126 | 60 | 60 | 200 μA | 60 | 750 | 2A | 3V | 2.8 | 2.5* | 2A | 1 | 1.5A | | 3J |
| BD679 | TO-126 | 80 | 80 | 200 μA | 80 | 750 | 1.5A | 3V | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 2J |
| BD679A | TO-126 | 80 | 80 | 200 μA | 80 | 750 | 2A | 3V | 2.8 | 2.5* | 2A | 1 | 1.5A | | 2J |
| BD680 | TO-126 | 80 | 80 | 200 μA | 80 | 750 | 1.5A | 3V | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 2J |
| BD680A | TO-126 | 80 | 80 | 200 μA | 80 | 750 | 2A | 3V | 2.8 | 2.5* | 2A | 1 | 1.5A | | 2J |
| BD681 | TO-126 | 100 | 100 | 200 μA | 100 | 750 | 1.5A | 3V | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 3J |
| BD682 | TO-126 | 100 | 100 | 200 μA | 100 | 750 | 1.5A | 3V | 2.5 | 2.5* | 1.5A | 1 | 1.5A | | 3J |
| BD733 | TO-220 | 25 | 25 | 5 | 200 μA† | 50 | 2A | 1 | 0.6 | 1.1* | 2A | 1 | 1.5A | | 4F |
| BD734 | TO-220 | 25 | 25 | 5 | 200 μA† | 50 | 2A | 1 | 0.6 | 1.1* | 2A | 1 | 1.5A | | 5E |
| BD735 | TO-220 | 35 | 35 | 5 | 200 μA† | 40 | 2A | 1 | 0.6 | 1.1* | 2A | 1 | 1.5A | | 4F |
| BD736 | TO-220 | 35 | 35 | 5 | 200 μA† | 40 | 2A | 1 | 0.6 | 1.1* | 2A | 1 | 1.5A | | 5E |
| BD737 | TO-220 | 45 | 45 | 5 | 200 μA† | 40 | 2A | 1 | 0.8 | 1.1* | 2A | 1 | 1.5A | | 4F |
| BD738 | TO-220 | 45 | 45 | 5 | 200 μA† | 40 | 2A | 1 | 0.8 | 1.1* | 2A | 1 | 1.5A | | 5E |
| BF167 | TO-72 (28) | 40 | 30 | 4 | 100† | 26 | 4 | 10 | | 0.84* | 4 | | | | 45 |
| BF180 | TO-72 (25) | 30 | 20 | 3 | 100 | 13 | 2 | 10 | | | | | | | 41 |
| BF181 | TO-72 (25) | 30 | 20 | 3 | 100 | 13 | 2 | 10 | | | | | | | 41 |
| BF182 | TO-72 (25) | 25 | 20 | 3 | 100 | 10 | 2 | 10 | | | | | | | 41 |
| BF194 | TO-92 (78) | | | | | 6 | 12 | 7 | | | | | | | 46 |

* Same as BF254, see page 3-27 for explanation



| Type No. | Case Style | V _{CE0} [*] V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} [*] (mA) Max | V _{CB} (V) Max | f _{re} 1 kHz [*] Min | HFE Min | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} [*] (V) (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No | |
|--|---------------|--|--------------------------------|--|-------------------------------|--|------------|---|------------------------------------|--|-------------------------------|--------------------------------|------------------------------------|---------------------------------|-------------------|----------------|------------|----|
| BF195 | TO-92 (76) | | | | | | | | | | | | | | | | 46 | |
| Same as BF255, see below for explanation | | | | | | | | | | | | | | | | | | |
| BF196 | TO-92 (78) | | | | | | | | | | | | | | | | 45 | |
| Same as BF198, see below for explanation | | | | | | | | | | | | | | | | | | |
| BF197 | TO-92 (78) | | | | | | | | | | | | | | | | 47 | |
| Same as BF199, see below for explanation | | | | | | | | | | | | | | | | | | |
| BF198 | TO-92 (78) | 40 | 4 | 100 | 40 | 26 6 | 4 10 | 10 7 | | 0.85 [*] | 4 | | | | | | 45 | |
| BF199 | TO-92 (78) | 40 | 4 | 100 | 40 | 38 6 | 7 10 | 10 7 | | | | | 1100 typ | | | | 47 | |
| BF200 | TO-72 (25) | 30 | 3 | 100 | 40 | 15 6 | 3 10 | 10 7 | | | | | | | | | 41 | |
| BF233-2 | TO-92 (71) | 30 | 4 | 100 | 10 | 40 6 | 70 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 1.0 | 150 | | | 49 | |
| BF233-3 | TO-92 (71) | 30 | 4 | 100 | 10 | 60 6 | 100 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 1.0 | 150 | | | 49 | |
| BF233-4 | TO-92 (71) | 30 | 4 | 100 | 10 | 90 6 | 150 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 1.0 | 150 | | | 49 | |
| BF233-5 | TO-92 (71) | 30 | 4 | 100 | 10 | 140 6 | 220 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 1.0 | 150 | | | 49 | |
| BF240 | TO-92 (78) | 40 | 4 | 100 | 20 | 67 6 | 222 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 0.34 | | | 3.5 | 7 | 47 |
| BF241 | TO-92 (78) | 40 | 4 | 100 | 20 | 36 6 | 125 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 0.34 | | | 3.5 | 7 | 47 |
| BF254 | TO-92 (78) | 30 | 5 | 100 | 20 | 67 6 | 220 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 0.34 | | | 3.5 | 7 | 46 |
| BF255 | TO-92 (78) | 30 | 5 | 100 | 20 | 35 6 | 125 12 | 10 7 | | 0.65 | 0.74 [*] | 1 | 0.34 | | | 3.5 | 7 | 46 |
| BF257 | TO-39 | 160 | 5 | 50 | 100 | 25 6 | 30 12 | 10 7 | 1.0 | 0.65 | 0.74 [*] | 30 | 0.34 | | | 3.5 | 7 | 48 |
| BF258 | TO-39 | 250 | 5 | 50 | 200 | 25 6 | 30 12 | 10 7 | 1.0 | 0.65 | 0.74 [*] | 30 | 0.34 | | | 3.5 | 7 | 48 |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CC} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CC} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CC} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = 5V, I_B¹ = I_B² = 500mA, V_{CC} = 25V, I_B¹ = 50mA, I_B² = 25mA. (14) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (15) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | VEBO (V) Min | ICES* IC _{BO} (mA) Max | HFE h _{FE} @ 1 kHz* Min Max | IC & VCE (mA) (V) | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} (V) Min Max | IC (mA) | C _{ob} (pF) Max | f _T (MHz) Min Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--|-----------------------------|-----------------|---------------------------------------|--|-----------------------------------|---------------------------------|---|------------------------|-----------------------------|---------------------------------|------------------------------|----------------|----------------|-------------|
| BF259 | TO-39 | 300 | 300 | 5 | 50 | 25 6 | 30 10 12 7 | 1.0 | 0.65 0.74* | 30 | 0.34 | 1 | | 3.5 | 7 | 48 |
| BF457 | TO-126 | 160 | 160 | 5 | 50 | 25 6 | 30 10 12 7 | 1.0 | 0.65 0.74* | 30 | 0.34 | 1 | | 3.5 | 7 | 48 |
| BF458 | TO-126 | 250 | 250 | 5 | 50 | 25 6 | 30 10 12 7 | 1.0 | 0.65 0.74* | 30 | 0.34 | 1 | | 3.5 | 7 | 48 |
| BF459 | TO-126 | 300 | 300 | 5 | 50 | 25 6 | 30 10 12 7 | 1.0 | 0.65 0.74* | 30 | 0.34 | 1 | | 3.5 | 7 | 48 |
| BFX13 | TO-18 | 20 | 15 | 5 | 50 | 10 50 18 | 100 2 10 0.35 1 2 | 0.2 0.25 1.5 | 0.78 0.7 1.5 | 1 10 100 | 6 | 150 | | 10 | 8 | 66 |
| BFX29 | TO-5 | 20 | 15 | 5 | 50 | 40 50 40 20 | 150 10 10 0.1 10 | 0.4 | 1.3 0.9 | 150 30 | 12 | 100 | 150 | | 9 | 63 |
| BFX30 | TO-5 | 65 | 65 | 5 | 50 | 20 50 50 40 | 0.4 0.4 0.4 0.4 | 0.9 1.3 | 30 150 | | 12 | | 290 | | 4 | 63 |
| BFX37 | TO-18 | 60 | 60 | 6 | 20 ¹ | 100 100 0.85 70 | 10 5 0.1 0.01 5 | 0.4 0.25 | 1.0 0.9 | 50 10 | 6 | 40 | 0.5 | 3 | 10 | 62 |
| BFX65 | TO-18 | 45 | 45 | 6 | 10* | 100 100 100 40 | 5 5 5 5 | 0.25 | 0.9 | 10 | 6.5 | | | 3 | 10 | 62 |
| BFX64 | TO-39 | 45 | 45 | 6 | 500 | 15 20 30 20 | 1A 10 500 10 10 10 | 0.15 0.35 1.0 1.6 | 1.2 1.3 1.5 2.0 | 10 150 500 1A | 12 | 50 | 360 | | 9 | 14 |
| BFX85 | TO-39 | 45 | 45 | 6 | 50 | 15 30 70 50 | 1A 10 500 10 10 10 | 0.15 0.35 1.0 1.6 | 1.2 1.3 1.5 2.0 | 10 150 500 1A | 12 | 50 | 360 | | 9 | 14 |
| BFX86 | TO-39 | 45 | 45 | 6 | 50 | 15 30 70 50 | 1A 10 500 10 10 10 | 0.15 0.35 1.0 1.6 | 1.2 1.3 1.5 2.0 | 10 150 500 1A | 12 | 50 | 360 | | 9 | 14 |



| Type No. | Case Style | V _{CE5} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CE5} * I _{CB0} (mA) Max | V _{CB} (V) @ | HFE h _{FE} 1 kHz* | | I _C & V _{CE} (mA) (V) Max | V _{CE(SAT)} (V) Max | | V _{BE(SAT)} & V _{BE(ON)*} (V) Min Max | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|------------|--|--------------------------------|--------------------------------|---|-----------------------------|----------------------------------|-----|---|------------------------------------|------|--|-----|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| | | | | | | | Min | Max | | Min | Max | Min | Max | | | | | | | | |
| BFX87 | TO-5 | 45 | 50 | 6 | 50 | 40 | 25 | 500 | 10 | 0.4 | 1.3 | 150 | 12 | 50 | 150 | 100 | 50 | 150 | | 9 | 63 |
| | | | | | | | 40 | 150 | 10 | | 0.9 | 30 | | | | | | | | | |
| | | | | | | | 40 | 10 | 10 | | | | | | | | | | | | |
| | | | | | | | 40 | 1 | 10 | | | | | | | | | | | | |
| BFX88 | TO-5 | 45 | 40 | 6 | 50 | 30 | 25 | 500 | 10 | 0.4 | 1.3 | 150 | 12 | 50 | 150 | 100 | 50 | 150 | | 9 | 63 |
| | | | | | | | 40 | 150 | 10 | | 0.9 | 30 | | | | | | | | | |
| | | | | | | | 40 | 10 | 10 | | | | | | | | | | | | |
| | | | | | | | 40 | 1 | 10 | | | | | | | | | | | | |
| BFY72 | TO-5 | 50 | 28 | 5 | 20† | 40 | 15 | 500 | 10 | 0.7 | 1.6 | 500 | 8 | 50 | 170 | 250 | 50 | 170 | | 12 | 20 |
| | | | | | | | 45 | 150 | 10 | | | | | | | | | | | | |
| | | | | | | | 30 | 10 | 10 | | 1.2 | 150 | | | | | | | | | |
| | | | | | | | 20 | 1 | 10 | | | | | | | | | | | | |
| | | | | | | | 15 | 0.1 | 10 | | | | | | | | | | | | |
| BFY76 | TO-18 | 45 | 45 | 6 | 20† | 30 | 140 | 1 | 5 | 0.35 | | 1 | 6 | 12 | 0.05 | 60 | 0.05 | | 4 | 13 | 07 |
| | | | | | | | 80 | 0.5 | 5 | | 0.5 | 0.1 | | | | | | | | | |
| | | | | | | | 30 | 200 | 0.01 | | | 4 | | | | | | | | | |
| BSX21 | TO-18 | 45 | 80 | 6 | 40 μA | 120 | 20 | 4 | 3 | | 0.9* | 4 | 20 | 60 | 4 | 60 | 4 | | | 11 | 14 |
| BSX45-6 | TO-39 | 80† | 40 | 7 | 10† | 60 | 40 | 100 | 100 | 1.0 | 2.0 | 500 | 20 | 60 | 50 | 60 | 50 | 650 | | 11 | 14 |
| | | | | | | | 63 | 160 | 100 | | | | | | | | | | | | |
| BSX45-10 | TO-39 | 80† | 40 | 7 | 10† | 60 | 100 | 100 | 1 | 1.0 | 2.0 | 500 | 20 | 60 | 50 | 60 | 50 | 650 | | 11 | 14 |
| | | | | | | | 100 | 250 | 100 | | | | | | | | | | | | |
| BSX45-16 | TO-39 | 80† | 40 | 7 | 10† | 60 | 40 | 100 | 1 | 1.0 | 2.0 | 500 | 20 | 60 | 50 | 60 | 50 | 650 | | 11 | 14 |
| | | | | | | | 40 | 100 | 100 | | | | | | | | | | | | |
| BSX46-6 | TO-39 | 100† | 60 | 7 | 10† | 60 | 40 | 100 | 1 | 1.0 | 2.0 | 500 | 25 | 60 | 50 | 60 | 50 | 650 | | 11 | 14 |
| | | | | | | | 63 | 160 | 100 | | | | | | | | | | | | |
| BSX46-10 | TO-39 | 100† | 60 | 7 | 10† | 60 | 100 | 100 | 1 | 1.0 | 2.0 | 500 | 25 | 60 | 50 | 60 | 50 | 650 | | 11 | 14 |
| | | | | | | | 100 | 250 | 100 | | | | | | | | | | | | |
| BSX46-16 | TO-39 | 100† | 60 | 7 | 10† | 60 | 100 | 100 | 1 | 1.0 | 2.0 | 500 | 6 | 250 | 30 | 110 | 30 | 110 | | 14 | 20 |
| | | | | | | | 30 | 120 | 10 | | 1.5 | 500 | 6 | 300 | 10 | 75 | 10 | 75 | | 15 | 21 |
| BSX48 | TO-18 | 50 | 25 | 5 | 120 | 50 | 17 | 100 | 1 | 1.5 | 0.72 | 0.8 | 10 | 6 | 300 | 10 | 75 | | | | |
| BSX88 | TO-52 | 40 | 15 | 5 | 25 | 20 | 15 | 0.5 | 1 | 0.4 | 0.72 | 0.8 | 10 | 6 | 300 | 10 | 75 | | | | |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CC} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CC} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CC} = 10V, I_B¹ = I_B² = 7.5mA. (12) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = 500Hz. (14) I_C = 500mA, V_{CC} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



| Type No. | Case Style | V _{CE} * V _{CB0} (V) Min | V _{CE0} (V) Min | V _{EB0} (V) Min | I _{CB0} * (mA) Max | V _{CB} (V) | HFE | | I _C & V _{CE} (mA) & (V) | V _{CE(SAT)} & V _{BE(ON)*} (V) & (V) | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. | |
|----------|------------|--|-----------------------------|-----------------------------|-----------------------------------|---------------------|---------------------------|-------------------------------|--|--|--------------|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|-------------------|----------------|-----|
| | | | | | | | h _{fe} 1 kHz* | Min | | Max | Max | | | | | | | | | Min |
| BSY38 | TO-52 | 20 | 12 | 5 | 100 | 20 | 15 30 | 45 60 | 100 10 | 0.35 0.35 | 0.6 0.25 | 1.5 0.85 | 100 10 | 5 | 200 | 10 | 45 | | 16 | 21 |
| BSY39 | TO-52 | 20 | 12 | 5 | 100 | 20 | 20 40 | 70 120 | 100 10 | 0.35 0.35 | 0.6 0.25 | 1.5 0.85 | 100 10 | 5 | 200 | 10 | 45 | | 16 | 21 |
| BSY51 | TO-5 | 60 | 25 | 5 | 100 | 30 | 20 40 | 70 120 | 100 10 | 1 | 1.0 | 1.3 | 150 | 9 | 130 | 50 | 45 | | 16 | 20 |
| BSY52 | TO-5 | 60 | 25 | 5 | 100 | 30 | 20 100 | 70 300 | 100 150 | 1 | 1.0 | 1.3 | 150 | 9 | 130 | 50 | 45 | | 16 | 20 |
| BSY53 | TO-5 | 75 | 30 | 7 | 10 | 60 | 20 40 35 20 | 500 120 150 10 10 | 10 10 10 | 0.6 2.0 | 1.3 | 150 | 9 | 150 | 50 | 45 | | 16 | 20 | |
| BSY54 | TO-5 | 75 | 30 | 7 | 10 | 60 | 40 100 75 35 | 500 300 150 10 10 | 10 10 10 | 0.6 2.0 | 1.3 | 150 | 9 | 150 | 50 | 45 | | 16 | 20 | |
| BSY95A | TO-52 | 20 | 15 | 5 | 50 | 16 | 50 30 | 200 1 | 10 0.35 | 0.35 0.35 | 0.67 0.87 | 10 | 6 | 200 | 10 | 50 | | 16 | 21 | |

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (2) I_C = 100mA, V_{CC} = 20V, I_B¹ = I_B² = 5mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1kHz. (4) I_C = 100mA, V_{CC} = 10V, I_B¹ = I_B² = 10mA. (5) I_C = 10mA, V_{CC} = 3V, I_B¹ = I_B² = 1mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 200kHz. (8) I_C = 1mA, V_{CE} = 5V, f = 1kHz. (9) I_C = 150mA, V_{CC} = 6V, I_B¹ = I_B² = 15mA. (10) I_C = 200 μA, V_{CE} = 5V, f = 1kHz. (11) I_C = 150mA, V_{CC} = 10V, I_B¹ = I_B² = 75mA. (12) I_C = 300mA, V_{CC} = 25V, I_B¹ = I_B² = 30mA. (13) I_C = 10 μA, V_{CE} = 5V, f = WB. (14) I_C = 500mA, V_{CC} = 25V, I_B¹ = 50mA, I_B² = 25mA. (15) I_C = 10mA, V_{BE} = 2V, I_B¹ = 3mA, I_B² = 1mA. (16) I_C = 100mA, I_B¹ = 40mA, I_B² = 20mA.



Section 4

JEIDA Series

4

JEIDA SERIES

| Type No. | Case Style | V _{CE} [†] V _{CB} (V) Min | V _{CE} (V) Min | V _{EB} (V) Min | I _{CB} (mA) Max | V _{CB} (V) @ I _C & V _{CE} (V) | H _{FE} h _{FE} @ I _C & V _{CE} 1 kHz* Min Max | I _C (mA) Max | V _{CE(SAT)} (V) Max | V _{BE(SAT)} & V _{BE(ON)} * (V) Min Max | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|--|----------------------------|----------------------------|-----------------------------|--|--|----------------------------|---------------------------------|--|----------------------------|-----------------------------|---------------------------------|----------------------------|------------------------------|----------------|----------------|-------------|
| 2SA719 | TO-92 (74) | 30 | 25 | 5 | 100 | 20 | 40 | 500 | 0.6 | 1.5 | 500 | | 200 | 50 | | | | 63 |
| 2SA738 | TO-126 | 25 | 25 | 5 | 20 μA | 25 | 20 | 1.5A | 1.0 | 1.5A | 2A | | | | | | | 77 |
| 2SC313 | TO-72 (25) | 30 | 19 | 2 | 500 | 10 | 35 | 320 | 1.0 | 1.5* | 20 | 2 | 600 | 10 | | | | 42 |
| 2SC372 | TO-92 (74) | 35 | 30 | 4 | 500 | 18 | 200 | 400 | 0.4 | | 10 | 3.5 | 80 | 1 | | | | 04 |
| 2SC380 | TO-92 (74) | 35 | 30 | 4 | 500 | 18 | 40 | 240 | 1.3 | | 10 | 3.2 | 400 | 1 | | | | 23 |
| 2SC385 | TO-92 (74) | 30 | 15 | 3 | 500 | 15 | 20 | 8 | | | | 1.5 | 600 | 8 | | | | 43 |
| 2SC387 | TO-92 (74) | 30 | 15 | 3 | 500 | 15 | 20 | 8 | 0.6 | 1.2 | 10 | 1.5 | 650 | 8 | | | | 43 |
| 2SC388 | TO-92 (74) | 25 | 25 | 3 | 25 | 10 | 20 | 200 | 0.2 | 1.5 | 15 | 2 | 300 | 12.5 | | | | 46 |
| 2SC394 | TO-92 (74) | 35 | 30 | 4 | 500 | 18 | 40 | 240 | | | | 3.5 | 100 | 1 | | | | 23 |
| 2SC398 | TO-72 (25) | 20 | 20 | 3 | 50 | 10 | 16 | 0.1 | | | | 0.5 | 250 | 4 | | 4.5 | 1 | 44 |
| 2SC399 | TO-72 (25) | 20 | 20 | 3 | 50 | 10 | 20 | 200 | | | | 0.5 | 250 | 4 | | 5.0 | 1 | 44 |
| 2SC454 | TO-92 (74) | 30 | 30 | 5 | 500 | 18 | 100 | 320 | 0.5 | 0.32* | 1 | 3.5 | | | | 25 | 2 | 27 |
| 2SC458 | TO-92 (74) | 30 | 30 | 5 | 500 | 18 | 100 | 500 | 0.5 | 0.75* | 2 | 3.5 | | | | 10 | 2 | 27 |
| 2SC460 | TO-92 (74) | 30 | 30 | 5 | 500 | 18 | 35 | 200 | 1.1 | 0.75* | 1 | 3.5 | | | | 6.5 | 3 | 27 |
| 2SC461 | TO-92 (74) | 30 | 30 | 5 | 500 | 18 | 35 | 200 | 1.1 | 0.75* | 2 | 3.5 | | | | | | 27 |
| 2SC463 | TO-72 (25) | 35 | 35 | 4 | 100 | 10 | 30 | 150 | 0.2 | | 10 | 0.6 | | | | 4 | 4 | 44 |
| 2SC464 | TO-72 (25) | 30 | 19 | 2 | 500 | 10 | 20* | | 1.0 | | 20 | 2.0 | 600 | 10 | | | | 42 |
| 2SC466 | TO-72 (25) | 30 | 19 | 2 | 500 | 10 | 20* | | 1.0 | | 20 | 2.0 | 600 | 10 | | | | 42 |
| 2SC495 | TO-126 | 70 | 50 | 5 | 1 μA | 30 | 40 | 240 | 0.8 | 1.1* | 500 | 10 | 50 | 10 | | | | 14 |
| 2SC535 | TO-92 (74) | 30 | 20 | 4 | 500 | 10 | 35 | 200 | | | | 1.2 | 450 | 1 | | 5.5 | 5 | 42 |
| 2SC536 | TO-92 (74) | 40 | 30 | 5 | 1 μA | 35 | 60 | 960 | | | | | | | | | | 04 |



JEIDA SERIES (Continued)

| Type No. | Case Style | V _{CE} [*] V _{CB} Min | V _{CEO} (V) Min | VEBO (V) Min | ICES [*] I _{CB} (mA) Max | V _{CB} (V) | HFE h _{fe} 1 kHz [*] Min Max | I _C & V _{CE} (mA) (V) | V _{CE} (SAT) (V) Max | V _{BE} (SAT) & V _{BE} (ON) [*] (V) Min Max | I _C (mA) | C _{ob} (pF) Max | f _T (MHz) Min Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|--|--------------------------------|--------------------|---|------------------------|---|--|-------------------------------------|---|------------------------|--------------------------------|------------------------------------|---------------------------------|-------------------|----------------|-------------|
| 25C562 | TO-72 (28) | 40 | 30 | 4 | 1 μA | 10 | 26 | 4 10 | | | 0.22 | 0.22 | 220 500 | 4 | | | 45 |
| 25C563 | TO-72 (28) | 40 | 25 | 4 | 10 μA | 40 | 38 | 7 10 | | | 0.32 | 0.32 | 360 820 | 5 | | | 47 |
| 25C644 | TO-92 (74) | 30 | 25 | 5 | 1 μA | 40 | 90 | 700 2 5 | | | | | | | 5 | 6 | 04 |
| 25C682 | TO-72 (25) | 20 | 20 | 3 | 100 | 10 | 20 | 200 2 10 | | | | | | | 4 | 4 | 44 |
| 25C683 | TO-72 (25) | 20 | 20 | 3 | 100 | 10 | 20 | 200 2 10 | | | 0.6 | 0.6 | 400 2 | | | | 44 |
| 25C684 | TO-92 (74) | 30 | 19 | 2 | | | 40 | 10 10 | 1.0 | | 2 | 2 | 900 10 | | | | 42 |
| 25C717 | TO-92 (74) | 30 | 19 | 2 | 500 | 10 | 40 | 1 6 | 1.0 | | 2 | 2 | 600 10 | | | | 43 |
| 25C733 | TO-92 (74) | 35 | 30 | 5 | 100 | 18 | 70 | 700 2 6 | 0.3 | | 10 | | 80 1 | | | | 04 |
| 25C735 | TO-92 (74) | 35 | 30 | 5 | 100 | 18 | 25 | 400 5 | | | | | | | | | 19 |
| 25C761 | TO-72 (25) | 30 | 20 | 3 | | | 25 | 2 10 | 0.25 | | 100 | | | | | | 41 |
| 25C762 | TO-72 (25) | 30 | 20 | 3 | | | 22 | 2 10 | | | | | | | | | 41 |
| 25C784 | TO-92 (74) | 40 | 30 | 4 | 500 | | 18 | 25 140 1 | 6 | | | 0.9 | | | 6 | 5 | 42 |
| 25C785 | TO-92 (74) | 40 | 30 | 4 | 500 | 18 | 25 | 140 1 6 | | | | 0.9 | | | | | 42 |
| 25C828 | TO-92 (74) | 30 | 25 | 5 | 1 μA | 10 | 65 | 700 2 5 | | | | | | | | | 04 |
| 25C829 | TO-92 (74) | 30 | 20 | 5 | 1 μA | 10 | 40 | 500 1 10 | | | | 1.6 | | | | | 23 |
| 25C947 | TO-72 (25) | 25 | 20 | 3 | | | 10 | 2 10 | | | | 0.3 | 400 1000 | 3 | | | 41 |
| 25C1047 | TO-92 (74) | 30 | 20 | 3 | | | 40 | 500 1 6 | | | | 1.0 | 460 | 1 | | | 42 |
| 25C1117 | TO-72 (25) | 20 | 20 | 3 | | | 60 | 320 2 10 | | | | 45 | 600 | 2 | 7 | 4 | 41 |

TEST CONDITIONS:

(1) V_{AG} = 1.4V, V_{CC} = 12V, f = 200MHz. (2) I_C = 0.1mA, V_{CE} = 6V, f = 1kHz. (3) I_C = 2mA, V_{CC} = 10V, V_{CE} = 6V, f = 100MHz. (4) I_C = 2mA, V_{CC} = 10V, V_{CE} = 6V, f = 200MHz. (5) I_C = 1mA, V_{CE} = 6V, f = 100MHz. (6) I_C = 0.2mA, V_{CE} = 5V, f = 0.1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 5MHz.



JEIDA SERIES (Continued)

| Type No. | Case Style | V _{CE} * V _{CB} (V) Min | V _{CE} (V) Min | V _{BO} (V) Min | I _{CS} * I _{CB} (mA) Max | V _{CB} (V) Max | HFE | | I _C & V _{CE} (mA) & (V) | V _{CE} (SAT) (V) Max | V _{BE} (SAT) & V _{BE} (ON)* (V) Min Max | | I _C (mA) Max | C _{ob} (pF) Max | f _T (MHz) Min Max | I _C (mA) Max | t _{off} (ns) Max | NF (dB) Max | Test Condition | Process No. |
|----------|---------------|--|-------------------------------|-------------------------------|---|-------------------------------|---------------------------|---------------------------|--|-------------------------------------|--|-----|-------------------------------|--------------------------------|------------------------------------|-------------------------------|---------------------------------|-------------------|----------------|-------------|
| | | | | | | | h _{fe} 1 kHz* | h _{FE} 1 kHz* | | | | | | | | | | | | |
| 25C1205 | TO-92 (74) | 30 | 30 | 5 | 500 | 18 | 35 | 200 | 2 | 1.1 | 0.75* | 1 | 3.5 | | | | | | | 27 |
| 25C1215 | TO-92 (74) | 30 | 20 | 3 | 100 | 10 | 25 | 2 | 10 | 1.5 | 0.72* | 2 | 1.5 | 650 | 10 | | | | | 42 |
| 25C1306 | TO-220 | 65 | | 4 | 10 μA | 40 | 30 | 150 | 10 | 0.6 | | 1A | 30 | 200 | 150 | | | | | 35 |
| 25C1335* | TO-92 (74) | 30 | 30 | 5 | 500 | 18 | 160 | 1200 | 2 | 0.5 | 0.75* | 2 | 3.5 | | | | | 6 | 2 | 04 |
| 25C1342 | TO-92 (74) | 30 | 20 | 4 | 500 | 10 | 35 | 200 | 1 | 1.2 | | 10 | 1.5 | 150 | 1 | | | 8.5 | 5 | 23 |
| 25C1344 | TO-92 (74) | 30 | 30 | 5 | 500 | 18 | 160 | 1200 | 2 | 0.5 | 0.75* | 2 | 3.5 | | | | | 8 | 2 | 04 |
| 25C1359 | TO-92 (74) | 30 | 20 | 5 | 100 | 10 | 50 | 220 | 1 | 10 | | | 1.5 | 150 | 1 | | | 4 | 7 | 23 |
| 25C1678 | TO-220 | 65 | | 4 | 10 μA | 30 | 15 | 500 | 5 | 1.0 | | 500 | 45 | 100 | 100 | | | | | 35 |
| 25C1318* | TO-92 (74) | 60 | 50 | 5 | 100 | 20 | 40 | 340 | 10 | 0.6 | 1.5 | 500 | | 200 | 50 | | | | | 62 |
| CS9011 | TO-92 (72) | | 18 | 3 | 50 | 18 | 29 | 280 | 1 | 5 | | | | | | | | | | 27 |
| CS9012 | TO-92 (72) | | 25 | 3 | | | 64 | 202 | 5 | 1 | | 250 | | | | | | | | 60 |
| CS9013 | TO-92 (72) | | 25 | 3 | | | 64 | 202 | 5 | 1 | | 250 | | | | | | | | 09 |
| CS9014 | TO-92 (72) | | 18 | 3 | 50 | 18 | 60 | 1000 | 1 | 0.5 | | 1 | | | | | | | | 04 |
| CS9015 | TO-92 (72) | | 18 | 3 | 50 | 18 | 60 | 1000 | 1 | 0.5 | | 1 | | | | | | | | 71 |
| CS9016 | TO-92 (72) | | 20 | 3 | 50 | 18 | 29 | 146 | 1 | 5 | 1 | 10 | | | | | | | | 44 |
| CS9018 | TO-92 (72) | | 12 | 2 | 50 | 15 | 29 | 198 | 1 | 5 | 0.6 | 10 | | | | | | | | 43 |

TEST CONDITIONS:

- (1) V_{AG} = 1.4V, V_{CC} = 12V, f = 200MHz. (2) I_C = 0.1mA, V_{CE} = 6V, f = 1kHz. (3) I_C = 2mA, V_{CE} = 6V, f = 10V, f = 200MHz. (4) I_C = 2mA, V_{CC} = 10V, f = 200MHz. (5) I_C = 1mA, V_{CE} = 6V, f = 100MHz.
 (6) I_C = 0.2mA, V_{CE} = 5V, f = 0.1kHz. (7) I_C = 1mA, V_{CE} = 10V, f = 5MHz.



Section 5

NA/NB/NR Series





NA/NB TRANSISTOR SERIES SELECTION GUIDE

GENERAL DESCRIPTION

The NA series of transistors are complementary power series which provide minimum collector saturation voltages at low drive conditions and feature matched HFE, guaranteed V_{BE} (on), V_{BE} (sat), V_{CE} (sat), etc, for estimating circuit performance at limit conditions. They are ideal for use with the NB series in complementary audio power amplifier applications. In addition, the collector breakdown voltages range from 20 to 60 Volts, which allows great flexibility in other power applications, such as converters/inverters, servo amplifiers, etc. The NB series of transistors are complementary general-purpose devices which cover a wide range of applications from low-noise equalizer preamplifiers to 1.5 Amp class B drivers. This series provides low leakage, low V_{CE} (sat), high HFE and three different types of collector breakdown voltages (35, 50 and 65 Volts) for multi-purpose usage and total flexibility.

NA — APPLICATIONS

- 0.1 to 25 Watts fully complementary audio power amplifiers
- Converters/Inverters
- Power control circuits
- Switching/linear regulators
- High current switching circuits
- Servo amplifiers

NB — APPLICATIONS

- Low noise equalizer preamplifiers
- Class A general purpose amplifiers
- Class B drivers
- Oscillators
- Control/Switching circuits
- Display/line drivers
- Servo amplifiers

NA SERIES — — COMPLEMENTARY POWER TRANSISTORS

device types and ratings

| PART # | | AVAILABLE PACKAGES | V_{CE} (max) VOLTS | I_C (max) AMPS | HFE | DESCRIPTION |
|--------|------|--------------------|-------------------------|---------------------|----------------|--------------------------------------|
| NPN | PNP | | | | | |
| NA01 | NA02 | TO-92 | 20 | 0.8 | Matched | 0.8A complementary power transistors |
| NA11 | NA12 | TO-92 | 20 | 1.0 | Matched | 1.0A complementary power transistors |
| NA21 | NA22 | TO-92, TO-92 PLUS | 20 | 1.5 | Matched | 1.5A complementary power transistors |
| NA31 | NA32 | TO-92 PLUS, TO-202 | 30 | 2.0 | Matched | 2.0A complementary power transistors |
| NA41 | NA42 | TO-126, TO-220 | 30 | 2.5 | Guaranteed min | 2.5A complementary power transistors |
| NA51 | NA52 | TO-126, TO-220 | 45 | 3.5 | Guaranteed min | 3.5A complementary power transistors |
| NA61 | NA62 | TO-126, TO-220 | 45 | 4.5 | Guaranteed min | 4.5A complementary power transistors |
| NA71 | NA72 | TO-126, TO-220 | 60 | 3.5 | Guaranteed min | 3.5A complementary power transistors |

NB SERIES — — GENERAL PURPOSE COMPLEMENTARY TRANSISTORS

device types and ratings

| PART # | | AVAILABLE PACKAGES | V_{CE} (max) VOLTS | I_C (max) AMPS | V_{CE} (sat) | | DESCRIPTION |
|--------|-------|---------------------------|-------------------------|---------------------|----------------|----------------|-----------------------------------|
| NPN | PNP | | | | max | I_C/I_B (mA) | |
| NB011 | NB021 | TO-92 | 35 | 0.03 | 0.3 | 10/0.5 | 30mA general purpose transistors |
| NB012 | NB022 | TO-92 | 50 | 0.03 | 0.3 | 10/0.5 | 30mA general purpose transistors |
| NB013 | NB023 | TO-92 | 35 | 0.03 | 0.3 | 10/0.5 | 30mA low noise transistors |
| NB014 | NB024 | TO-92 | 50 | 0.03 | 0.3 | 10/0.5 | 30mA low noise transistors |
| NB111 | NB121 | TO-92 | 35 | 0.1 | 0.3 | 40/0.8 | 100mA general purpose transistors |
| NB112 | NB122 | TO-92 | 50 | 0.1 | 0.3 | 40/0.8 | 100mA general purpose transistors |
| NB113 | NB123 | TO-92 | 65 | 0.1 | 0.3 | 40/0.8 | 100mA general purpose transistors |
| NB211 | NB221 | TO-92, TO-92 PLUS | 35 | 0.5 | 0.4 | 100/2 | 500mA medium current drivers |
| NB212 | NB222 | TO-92, TO-92 PLUS | 50 | 0.5 | 0.4 | 100/2 | 500mA medium current drivers |
| NB213 | NB223 | TO-92, TO-92 PLUS | 65 | 0.5 | 0.4 | 100/2 | 500mA medium current drivers |
| NB311 | NB321 | TO-92, TO-92 PLUS, TO-202 | 35 | 1.5 | 0.5 | 300/10 | 1.5A complementary power drivers |
| NB312 | NB322 | TO-92, TO-92 PLUS, TO-202 | 50 | 1.5 | 0.5 | 300/10 | 1.5A complementary power drivers |
| NB313 | NB323 | TO-92, TO-92 PLUS, TO-202 | 65 | 1.5 | 0.5 | 300/10 | 1.5A complementary power drivers |

COMPLEMENTARY AUDIO AMPLIFIER CROSS REFERENCE CHARTS

AUDIO OUTPUT POWER — Battery operated "OTL" amplifiers

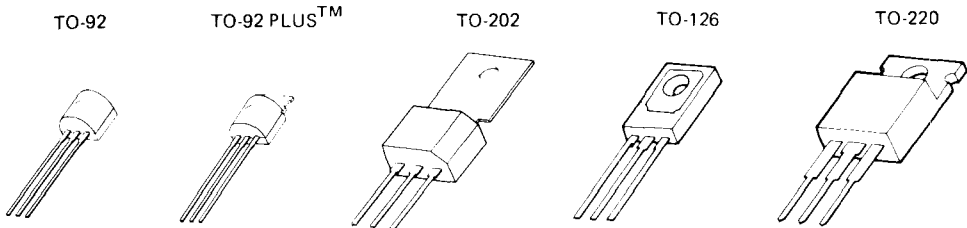
| OPERATING CONDITIONS | (1) OUTPUT POWER minimum | @ 10% THD typical | RECOMMENDED OUTPUT DEVICES | RECOMMENDED DRIVER DEVICES |
|---|----------------------------|----------------------------|---|---|
| 6 Volts/8Ω single-bootstrapping 6 Volts/8Ω single-bootstrapping 6 Volts/4Ω single-bootstrapping | 380 mW 380 mW 680 mW | 380 mW 480 mW 850 mW | NA01 / NA02 NA11 / NA12 NA21 / NA22 | NB111 / NB121 NB111 / NB121 NB111 / NB121 |
| 6 Volts/4Ω double-bootstrapping 9 Volts/8Ω single-bootstrapping 9 Volts/4Ω single-bootstrapping | 920 mW 800 mW 1.4 W | 1.0 W 1.0 W 1.8 W | NA21 / NA22 NA21 / NA22 NA21 / NA22 | NB111 / NB121 NB111 / NB121 NB111 / NB121 |
| 9 Volts/4Ω double-bootstrapping 14 Volts/8Ω single-bootstrapping 14 Volts/4Ω single-bootstrapping | 1.9 W 2.0 W 3.8 W | 2.2 W 2.3 W 4.2 W | NA21 / NA22 NA21 / NA22 NA31 / NA32 | NB111 / NB121 NB111 / NB121 NB211 / NB221 |

AUDIO OUTPUT POWER — AC operated "OTL" amplifiers

| OUTPUT POWER (min) @ 10% THD | LOAD IMPEDENCE | (2) REQUIRED SUPPLY VOLTAGE (min) | RECOMMENDED OUTPUT DEVICES | RECOMMENDED DRIVER DEVICES |
|---------------------------------|----------------|-----------------------------------|---|---|
| 3 Watts 4 Watts 6 Watts | 8Ω 8Ω 8Ω | 15 17 20 | NA31 / NA32 NA31 / NA32 NA41 / NA42 | NB211 / NB221 NB211 / NB221 NB211 / NB221 |
| 8 Watts 12 Watts 15 Watts | 8Ω 8Ω 8Ω | 23 27 32 | NA51 / NA52 NA51 / NA52 NA71 / NA72 | NB212 / NB222 NB312 / NB322 NB312 / NB322 |
| 18 Watts 24 Watts | 8Ω 8Ω | 35 40 | NA71 / NA72 NA71 / NA72 | NB313 / NB323 NB313 / NB323 |
| 3 Watts 4 Watts 6 Watts | 4Ω 4Ω 4Ω | 11 13 16 | NA31 / NA32 NA31 / NA32 NA41 / NA42 | NB211 / NB221 NB211 / NB221 NB211 / NB221 |
| 8 Watts 12 Watts 15 Watts | 4Ω 4Ω 4Ω | 18 20 23 | NA51 / NA52 NA51 / NA52 NA61 / NA62 | NB211 / NB221 NB311 / NB321 NB312 / NB322 |
| 18 Watts 24 Watts | 4Ω 4Ω | 26 30 | NA61 / NA62 NA61 / NA62 | NB312 / NB322 NB312 / NB322 |

NOTES: (1) Minimum Output Power levels shown are obtained by considering transistor parameter variations only, and do not include external component value tolerances.
 (2) Voltage drops across emitter ballast resistors of the output devices are not included as part of the minimum required supply voltages; voltages specified are dc and under full load condition.

PACKAGE OUTLINES



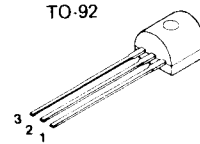


**NAO1(NPN)
NAO2(PNP)** 800mA complementary power transistors

features

- 20 Volt/800 mA Amp rating
- Low $V_{CE(sat)}$ and $V_{BE(sat)}$ characteristics at $I_C = 500\text{ mA}$, $I_B = 50\text{ mA}$
- Guaranteed $V_{BE(on)}$ characteristics at low current for stable biasing
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability

1 package and lead coding



applications

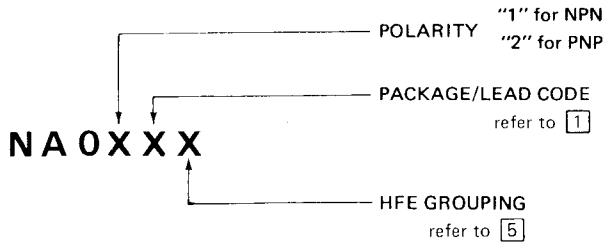
- 0.2 to 1 Watt audio power amplifiers
- Medium power switching circuits
- Converter/Inverter circuits
- Circuits for toys

| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|-------------------|--------------|--------------------|
| Collector-Emitter Voltage | V_{CEO} | 20 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 25 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 5.0 | V_{DC} |
| Collector Current (continuous) | $I_C(\text{max})$ | 800 | mA |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | |
| TO-92 | | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | |
| TO-92 | | 1.0 | W |
| Thermal Resistance | | | |
| TO-92 | θ_{JA} | 208 | $^\circ\text{C/W}$ |
| | θ_{JC} | 125 | $^\circ\text{C/W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | $^\circ\text{C}$ |

3 ordering information



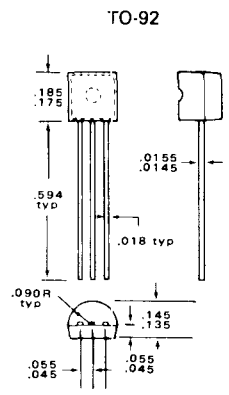
4 electrical characteristics $T_C = 25^\circ C$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|---|-----|------------|-----|----------|
| V_{CE0} | Collector-Emitter Sustaining Voltage | $I_C = 1 \text{ mA}$ | 20 | | | V |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 100\mu A$ | 25 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\mu A$ | 5 | | | V |
| I_{CE0} | Collector-Emitter Leakage Current | $V_{CE} = 15V$ | | | 100 | μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 20V$ | | | 1 | μA |
| $V_{BE}(\text{on})$ | Base-Emitter Voltage | $I_C = 10 \text{ mA}, V_{CE} = 3V$ | 630 | 680 | 730 | mV |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 400 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.9 | 1.0 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 400 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.3 | 0.5 | V |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 4.5 7.0 | | pF pF |
| f_t | Current Gain Bandwidth Product | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 50 | 200 | | MHz |

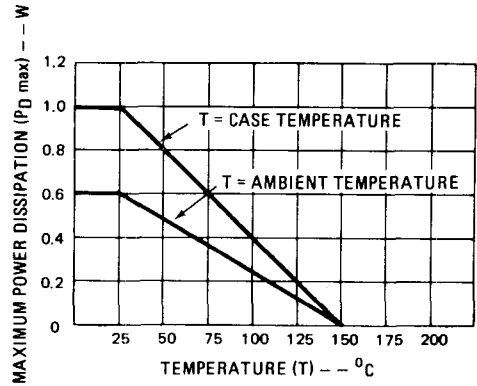
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|-------------------------------------|-----|-----|-----|-------|
| G | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 100 | 127 | 160 | 1:1.6 |
| I | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 200 | 260 | 350 | 1:1.6 |
| X | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 30 | 58 | 110 | 1:3.5 |
| Y | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 100 | 190 | 350 | 1:3.5 |

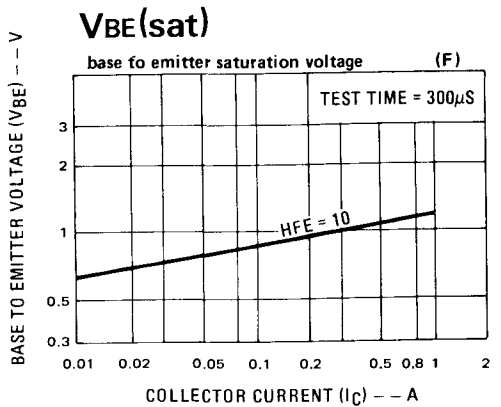
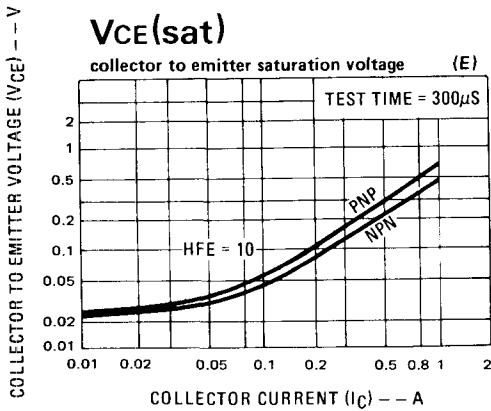
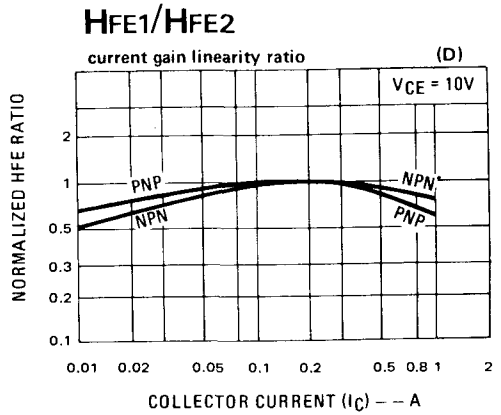
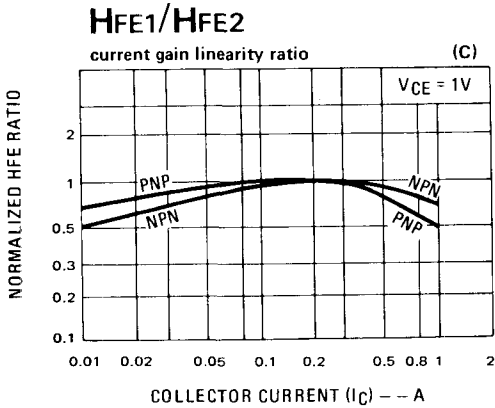
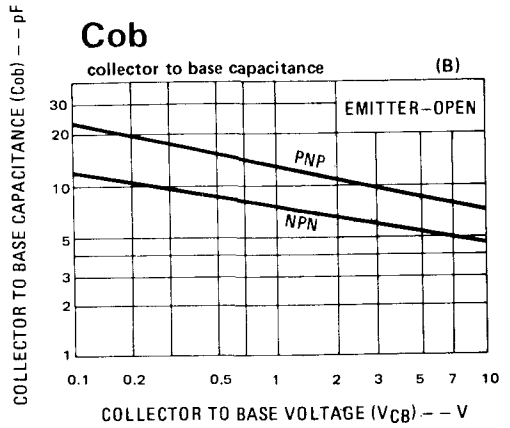
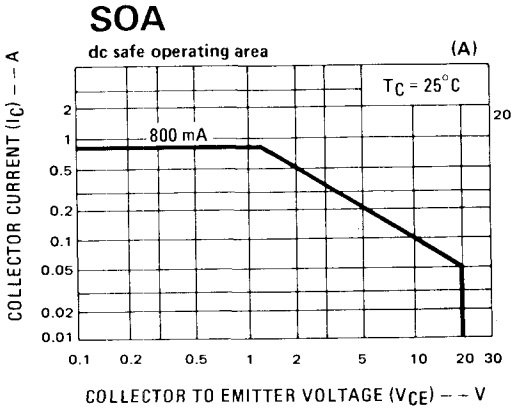
6 physical dimensions



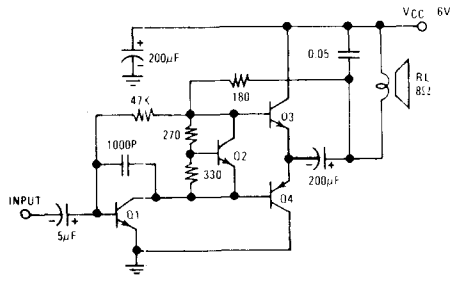
7 max power dissipation



8 typical performance characteristics

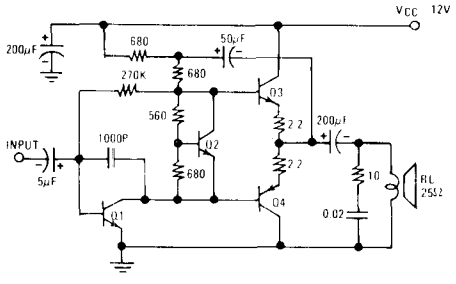


9 typical applications



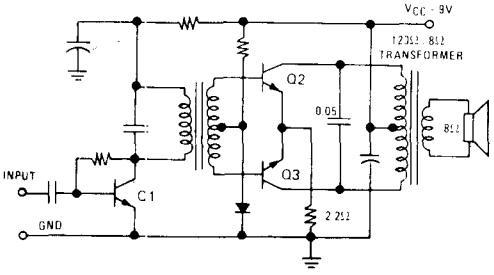
Q1 NB111EH/J Q3 NA01EG/J
Q2 NF001E Q4 NA01EG/J

Figure A. 380mW 6V/8Ω OTL Amplifier



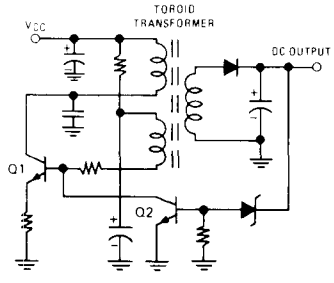
Q1 NB111EH/J Q3 NA01EG/J
Q2 NR001E Q4 NA01EG/J

Figure B. 650mW 12V/25Ω OTL Amplifier



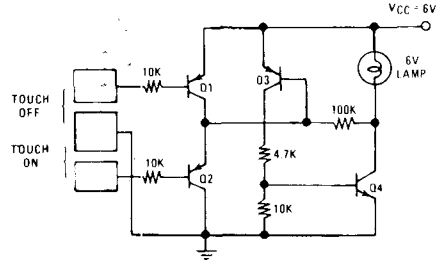
Q1 NB111EH/J Q2 NA01EG/J Q3 NA01EG/J

Figure C. 1.2W Audio Amplifier



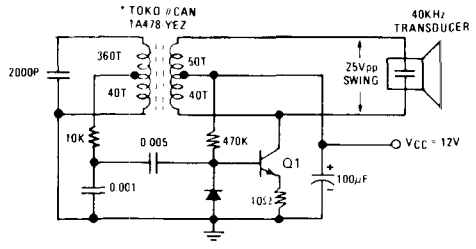
Q1 NA01EX Q2 NB111EY

Figure D. Typical Converter Circuit



Q1 NB021EY Q3 NB021EY
Q2 NB021EY Q4 NA01EX

Figure E. Touch-on/Touch-off Electronic Switch



Q1 NA01EX

Figure F. 40KHz Ultrasonic Transmitter



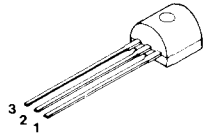
**NA11 (NPN)
NA12 (PNP) 1 Amp complementary power transistors**

features

- 20 Volt/1 Amp rating
- Low V_{CE} (sat) and V_{BE} (sat) characteristics at $I_C = 400$ mA, $I_B = 10$ mA
- Guaranteed V_{BE} (on) characteristics at low current for stable biasing
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability

1 package and lead coding

TO-92



applications

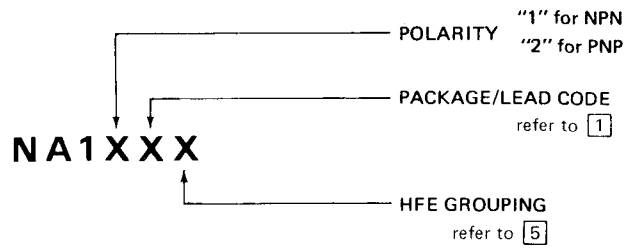
- 0.2 to 1 Watt audio power amplifiers
- Medium power switching circuits
- Converter/Inverter circuits
- Circuits for toys

| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|----------------|-------------|--------------------|
| Collector-Emitter Voltage | V_{CEO} | 20 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 25 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 5.0 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 1.0 | A |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | |
| TO-92 | | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | |
| TO-92 | | 1.0 | W |
| Thermal Resistance | | | |
| TO-92 | θ_{JA} | 208 | $^\circ\text{C/W}$ |
| | θ_{JC} | 125 | $^\circ\text{C/W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

3 ordering information



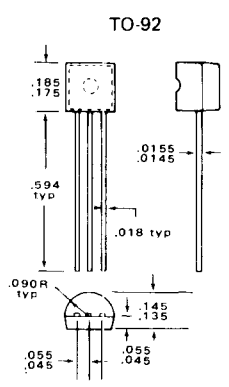
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|---|-----|------|-----|---------------|
| V_{CE0} | Collector-Emitter Sustaining Voltage | $I_C = 1 \text{ mA}$ | 20 | | | V |
| V_{CB0} | Collector-Base Breakdown Voltage | $I_C = 100\mu\text{A}$ | 25 | | | V |
| V_{E0} | Emitter-Base Breakdown Voltage | $I_E = 10\mu\text{A}$ | 5 | | | V |
| I_{CE0} | Collector-Emitter Leakage Current | $V_{CE} = 15\text{V}$ | | | 100 | μA |
| I_{CB0} | Collector-Base Leakage Current | $V_{CB} = 20\text{V}$ | | | 1 | μA |
| $V_{BE}(\text{on})$ | Base-Emitter Voltage | $I_C = 10 \text{ mA}, V_{CE} = 3\text{V}$ | 630 | 680 | 730 | mV |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.95 | 1.5 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.2 | 0.5 | V |
| Cob | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10\text{V}, f = 1 \text{ MHz}$ | | 4.5 | | pF |
| | | | | 7.0 | | pF |
| ft | Current Gain Bandwidth Product | $I_C = 100 \text{ mA}, V_{CE} = 3\text{V}$ | 50 | 200 | | MHz |

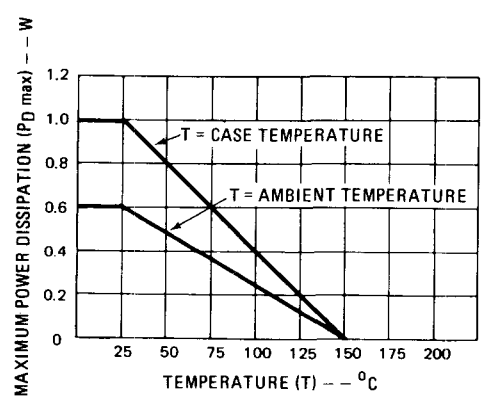
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|--|-----|-----|-----|-------|
| G | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3\text{V}$ | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3\text{V}$ | 100 | 127 | 160 | 1:1.6 |
| I | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3\text{V}$ | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3\text{V}$ | 200 | 260 | 350 | 1:1.6 |
| X | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3\text{V}$ | 30 | 58 | 110 | 1:3.5 |
| Y | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3\text{V}$ | 100 | 190 | 350 | 1:3.5 |

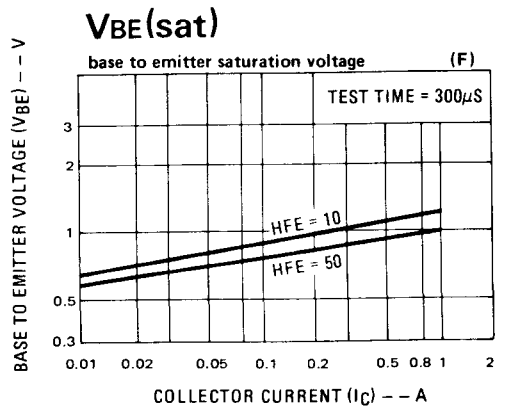
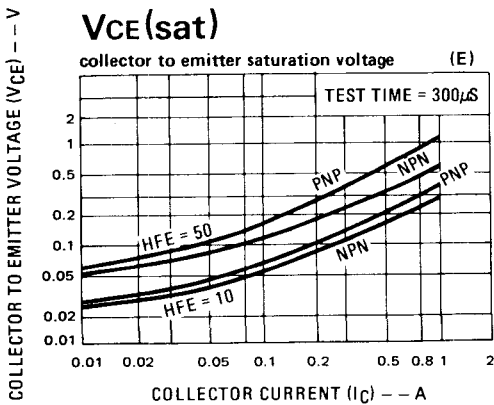
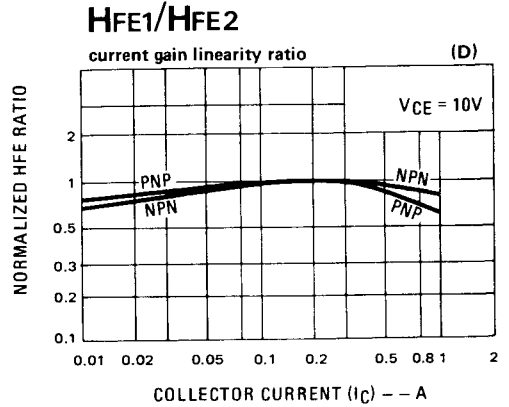
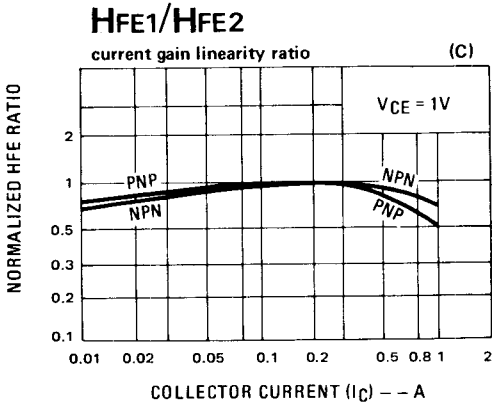
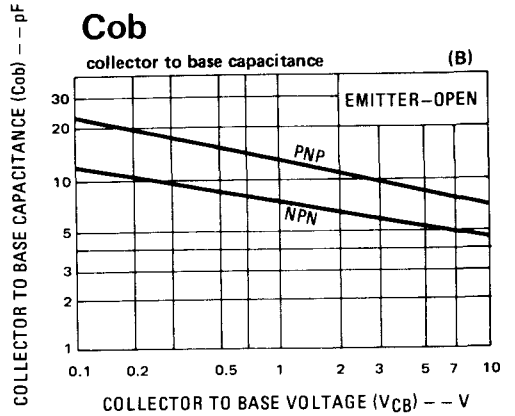
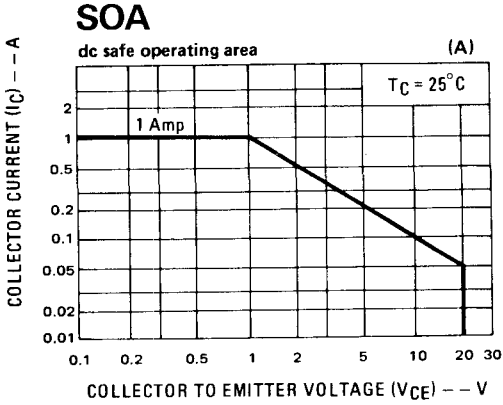
6 physical dimensions



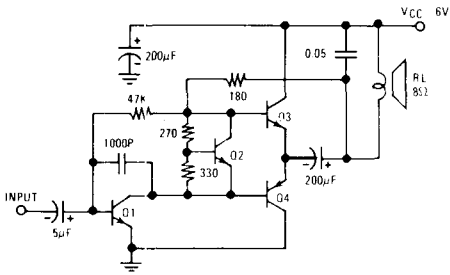
7 max power dissipation



8 typical performance characteristics

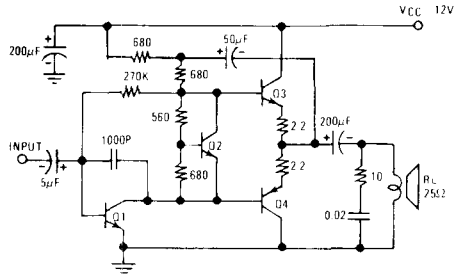


9 typical applications



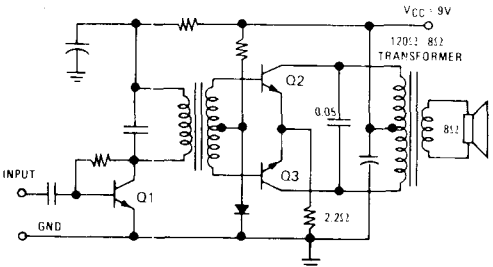
- Q1 NB111EH/J Q3 NA11EG/J
Q2 NR001E Q4 NA12EG/J

Figure A. 380mW 6V/8Ω OTL Amplifier



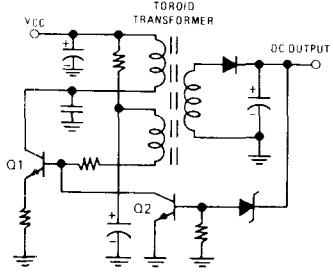
- Q1 NB111EH/J Q3 NA11EG/J
Q2 NR001E Q4 NA12EG/J

Figure B. 650mW 12V/25Ω OTL Amplifier



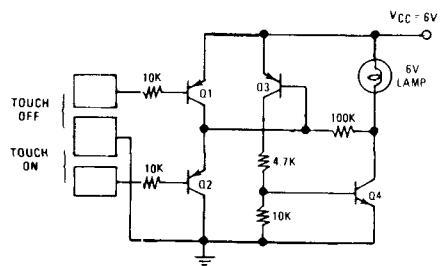
- Q1 NB111EH/J Q2 NA11EG/J Q3 NA11EG/J

Figure C. 1.2W Audio Amplifier



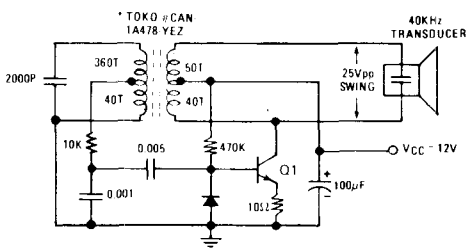
- Q1 NA11EX Q2 NB111EY

Figure D. Typical Converter Circuit



- Q1 NB021EY Q3 NB021EY
Q2 NB021EY Q4 NA11EX

Figure E. Touch-on/Touch-off Electronic Switch



- Q1 NA11EX

Figure F. 40KHz Ultrasonic Transmitter

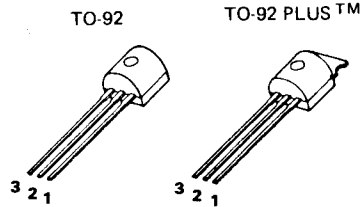


NA21 (NPN) NA22 (PNP) 1.5 Amp complementary power transistors

features

- 20 Volt/1.5 Amp rating
- 1.2 Watts practical power dissipation (TO-92 PLUS™)
- Low $V_{CE(sat)}$ and $V_{BE(sat)}$ characteristics at $I_C = 700\text{ mA}$, $I_B = 14\text{ mA}$
- Guaranteed $V_{BE(on)}$ characteristics at small current for stable biasing
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability

1 package and lead coding



applications

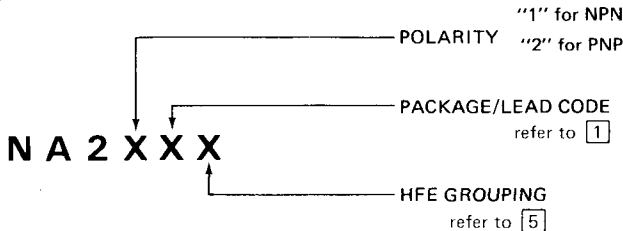
- 0.5 – 2 Watt audio power amplifiers
- Medium power switching circuits
- Converter/Inverter circuits
- Toy circuits

| PACKAGE CODE | | LEAD | | |
|--------------|------------|------|---|---|
| TO-92 | TO-92 PLUS | 1 | 2 | 3 |
| E | X | E | B | C |
| F | Y | E | C | B |
| | Z | B | C | E |
| H | | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|-----------------------------|-------------|--------------------|
| Collector-Emitter Voltage | V_{CE} | 20 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 25 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 5.0 | V_{DC} |
| Collector Current (continuous) | $I_C (max)$ | 1.5 | A |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | |
| TO-92 | | 0.6 | W |
| TO-92 PLUS | | 0.75 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | |
| TO-92 | | 1.0 | W |
| TO-92 PLUS | | 2.5 | W |
| Thermal Resistance | | | |
| TO-92 | $\theta_{JA} / \theta_{JC}$ | 208/125 | $^\circ\text{C/W}$ |
| TO-92 PLUS | $\theta_{JA} / \theta_{JC}$ | 167/50 | $^\circ\text{C/W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

3 ordering information



4 electrical characteristics $T_C = 25^\circ C$

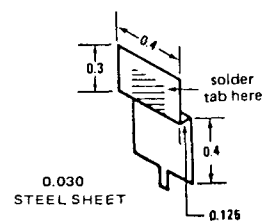
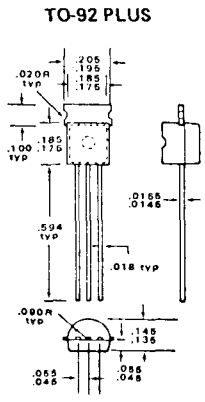
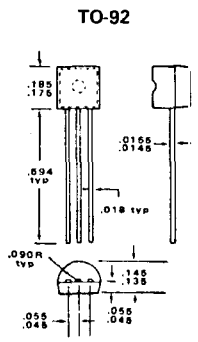
| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--------------------------------------|---|-----|------|-----|---------|
| BV_{CEO} | Collector-Emitter Sustaining Voltage | $I_C = 1 \text{ mA}$ | 20 | | | V |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 100 \mu A$ | 25 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu A$ | 5 | | | V |
| I_{CEO} | Collector-Emitter Leakage Current | $V_{CE} = 15V$ | | | 100 | μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 20V$ | | | 1 | μA |
| $V_{BE}(\text{on})$ | Base-Emitter Voltage | $I_C = 10 \text{ mA}, V_{CE} = 3V$ | 630 | 680 | 730 | mV |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 700 \text{ mA}, I_B = 14 \text{ mA}$ | | 0.9 | 1.0 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 700 \text{ mA}, I_B = 14 \text{ mA}$ | | | | |
| | NPN types | | | 0.35 | 0.5 | V |
| | PNP types | | | 0.65 | 1 | V |
| C_{ob} | Collector Output Capacitance | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 0.45 | | pF |
| | NPN types | | | 0.7 | | pF |
| | PNP types | | | | | |
| f_t | Current Gain Bandwidth Product | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 50 | 200 | | MHz |

5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|-------------------------------------|-----|-----|-----|-------|
| G | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 100 | 127 | 160 | 1:1.6 |
| I | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 200 | 260 | 350 | 1:1.6 |
| X | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 30 | 58 | 110 | 1:3.5 |
| Y | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 3V$ | 100 | 190 | 350 | 1:3.5 |

6 physical dimensions

7 heatsink information



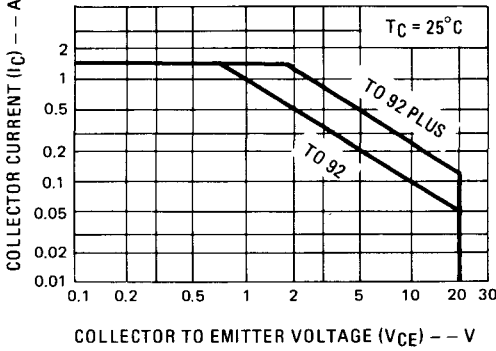
■ TO-92 PLUS package with heatsink shown on right permits 1.6 Watts power dissipation and combined Thermal Resistance $\theta_{JA} = 78^\circ C/W$. If used without heatsink and PCB land area at collector lead $> 1 \text{ sq. inch}$, $P_D = 1.2W$.

8 typical performance characteristics

SOA

dc safe operating area

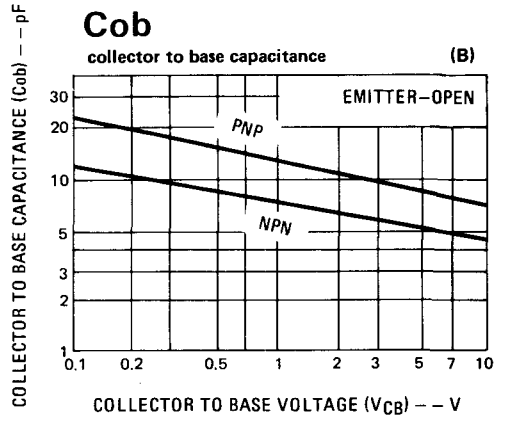
(A)



Cob

collector to base capacitance

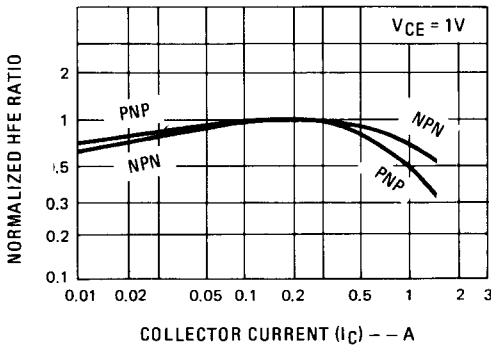
(B)



HFE1/HFE2

current gain linearity ratio

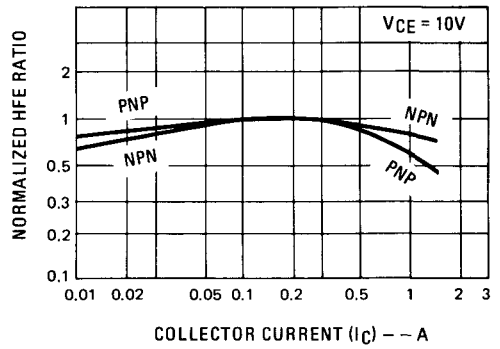
(C)



HFE1/HFE2

current gain linearity ratio

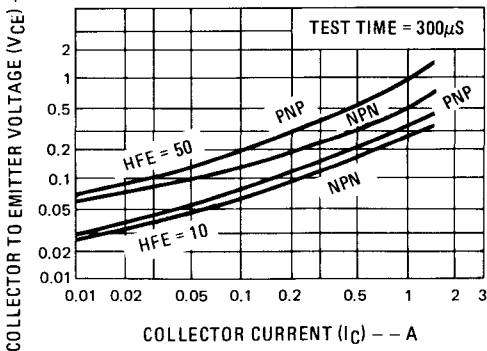
(D)



VCE(sat)

collector to emitter saturation voltage

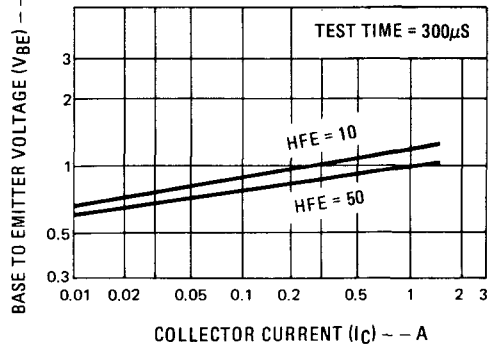
(E)



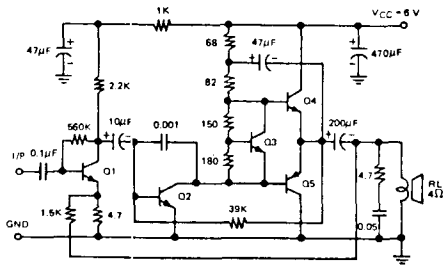
VBE(sat)

base to emitter saturation voltage

(F)

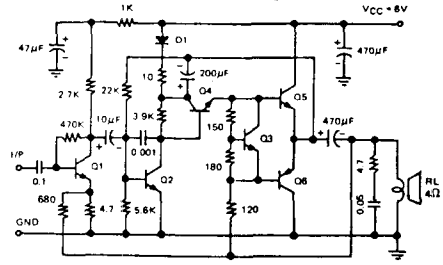


9 typical applications



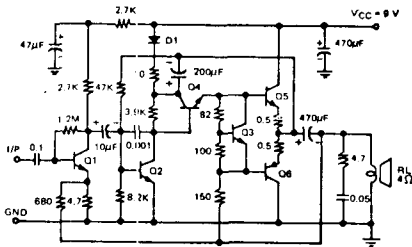
Q1 NB01EY Q3 NR001E Q5 NA22EG/J
Q2 NB11EH/J Q4 NA21EG/J

Figure A. 700mW 6V/4Ω OTL Amplifier



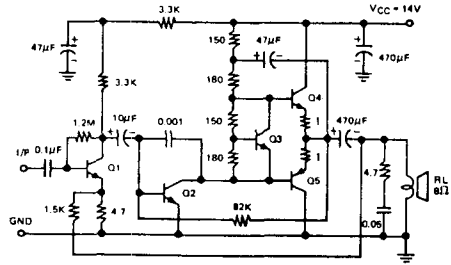
Q1 NB011EY Q3 NR001E Q5 NA21EG/J
Q2 NB011EY Q4 NB111EY Q6 NA22EG/J

Figure B. 950mW 6V/4Ω OTL Amplifier



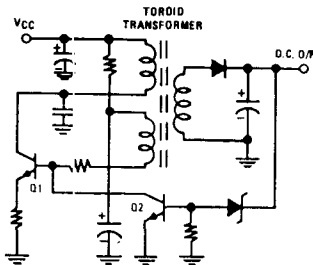
Q1 NB011EY Q3 NR001E Q5 NA21EG/J
Q2 NB011EY Q4 NB111EY Q6 NA22EG/J

Figure C. 2W 9V/4Ω OTL Amplifier



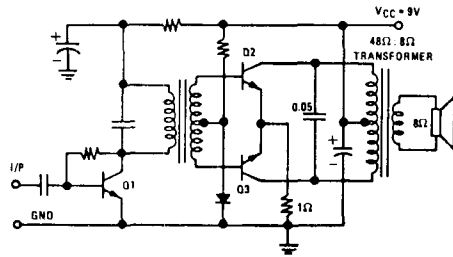
Q1 NB011EY Q3 NR001E Q5 NA22EG/J
Q2 NB111EH/J Q4 NA21EG/J

Figure D. 2.2W 14V/8Ω OTL Amplifier



Q1 NA21EX Q2 NB111EY

Figure E. Typical Converter Circuit



Q1 NB111E Q2 NA21Y G/J Q3 NA21Y G/J

Figure F. 2W Audio Amplifier

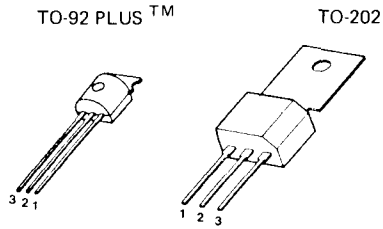


NA31 (NPN) 2 Amp complementary power transistors
NA32 (PNP)

features

- 30 Volt/2 Amp rating
- 1.2 Watts practical power dissipation (TO-92 PLUS™)
- 1.75 Watts free air power dissipation (TO-202)
- Low $V_{CE(sat)}$ and $V_{BE(sat)}$ characteristics at $I_C = 1.2A, I_B = 30 mA$
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability

1 packages and lead coding



applications

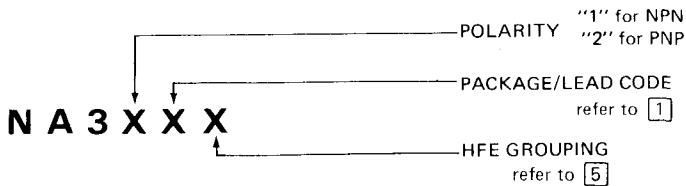
- 4-Watt audio power amplifiers
- Medium power switching circuits
- Converter/Inverter circuits
- TV receivers

| PACKAGE CODE | | LEAD | | |
|--------------|--------|------|---|---|
| TO-92 PLUS | TO-202 | 1 | 2 | 3 |
| X | K | E | B | C |
| Y | L | E | C | B |
| Z | M | B | C | E |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|---------------------------|--------------|--------------|
| Collector-Emitter Voltage | V_{CEO} | 30 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 35 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 5.0 | V_{DC} |
| Collector Current (continuous) | $I_C (max)$ | 2.0 | A |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | | |
| TO-92 PLUS | | 0.75 | W |
| TO-202 | | 1.75 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | | |
| TO-92 PLUS | | 2.5 | W |
| TO-202 | | 10 | W |
| Thermal Resistance | | | |
| TO-92 PLUS | θ_{JA}/θ_{JC} | 167/ 50 | $^\circ C/W$ |
| TO-202 | θ_{JA}/θ_{JC} | 72/ 12.5 | $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | $^\circ C$ |

3 ordering information



4 electrical characteristics $T_C = 25^\circ C$

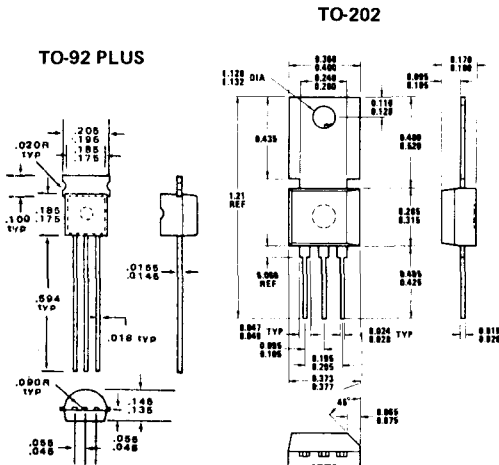
| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------|--|-------------------------------------|-----|----------|-----|----------|
| BV_{CEO} | Collector-Emitter Sustaining Voltage | $I_C = 1 \text{ mA}$ | 30 | | | V |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 100 \mu A$ | 35 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu A$ | 5 | | | V |
| I_{CEO} | Collector-Emitter Leakage Current | $V_{CE} = 25V$ | | | 100 | μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 30V$ | | | 1 | μA |
| $V_{BE(on)}$ | Base-Emitter Voltage | $I_C = 15 \text{ mA}, V_{CE} = 5V$ | 600 | 650 | 700 | mV |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C = 1.2A, I_B = 30 \text{ mA}$ | | 0.95 | 1.2 | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 1.2A, I_B = 30 \text{ mA}$ | | 0.5 | 1 | V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C = 1.2A, I_B = 120 \text{ mA}$ | | 1.0 | 1.4 | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 1.2A, I_B = 120 \text{ mA}$ | | 0.25 | 0.5 | V |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 10 17 | | pF pF |
| f_t | Current Gain Bandwidth Product | $I_C = 300 \text{ mA}, V_{CE} = 5V$ | 20 | | | MHz |

5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|-------------------------------------|-----|-----|-----|-------|
| G | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 5V$ | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 5V$ | 100 | 127 | 160 | 1:1.6 |
| I | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 5V$ | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 5V$ | 200 | 260 | 350 | 1:1.6 |
| X | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 5V$ | 30 | 58 | 110 | 1:3.5 |
| Y | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 5V$ | 100 | 190 | 350 | 1:3.5 |

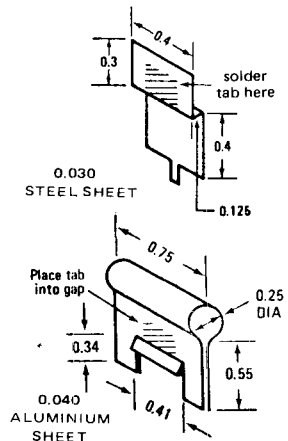
6 physical dimensions

7 heatsink information

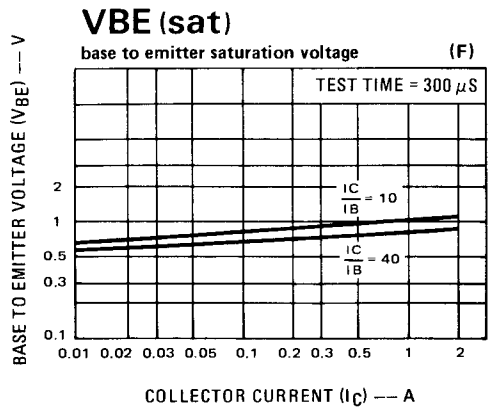
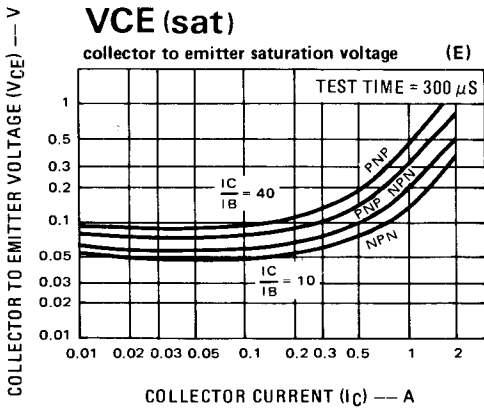
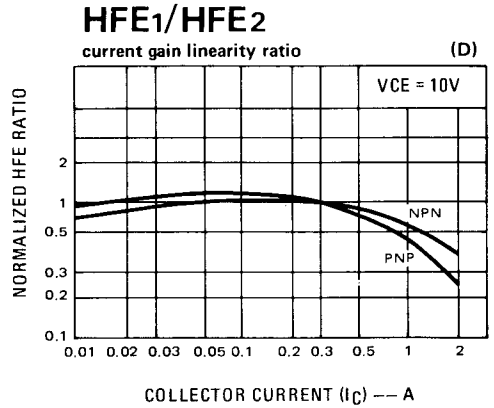
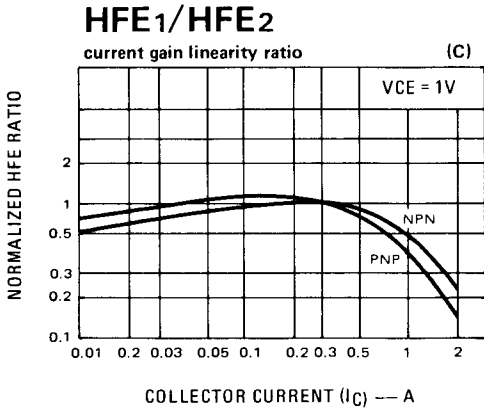
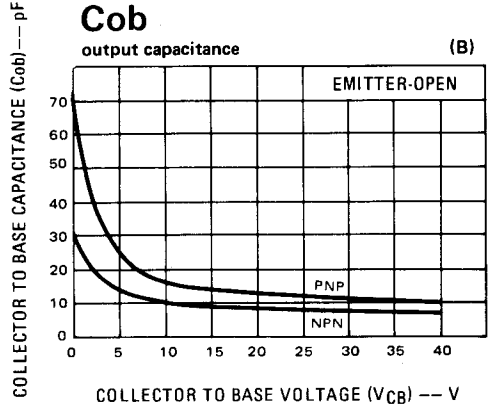
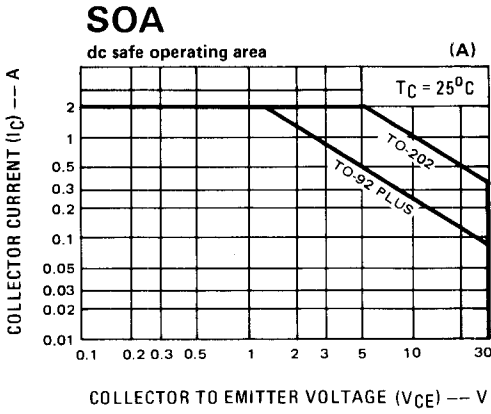


■ TO-92 PLUS package with heatsink shown on right permits 1.6 Watts power dissipation and combined Thermal Resistance $\theta_{JA} = 78^\circ C/W$. If used without heatsink and PCB land area at collector lead > 1 sq. inch, $P_D = 1.2W$.

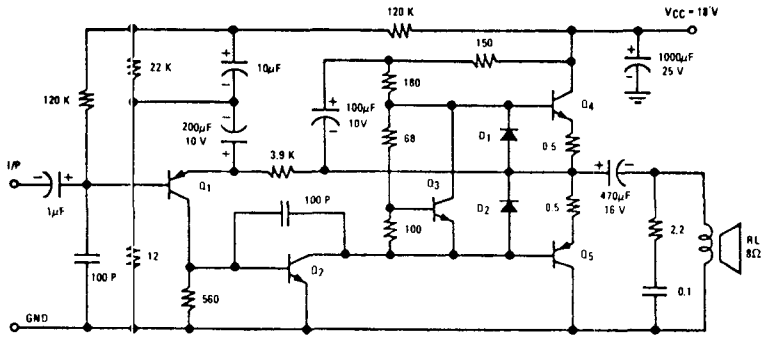
■ TO-202 package with heatsink shown on right permits 3 Watts P_D and $\theta_{JA} = 42^\circ C/W$.



8 typical performance characteristics

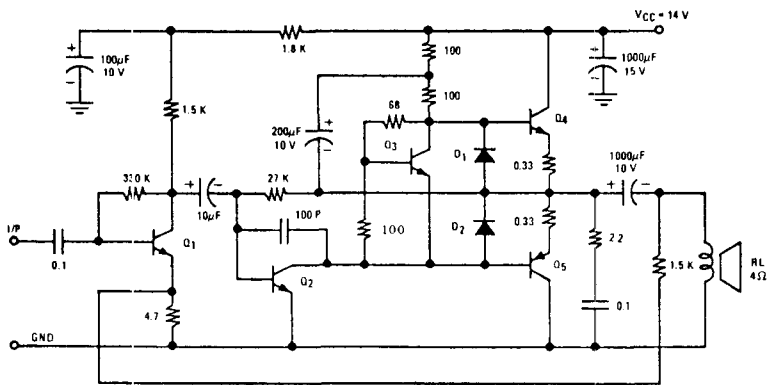


9 typical applications



- Q1 NB021EY
- Q2 NB211EY
- Q3 NR001E
- Q4 NA31YG/I
- Q5 NA32YG/I

Figure A. 4 Watt / 8 Ohm OTL Amplifier



- Q1 NB011EU
- Q2 NB211EH/J
- Q3 NR001E
- Q4 NA31YG/I
- Q5 NA32YG/I

Figure B. 4 Watt / 4 Ohm OTL Amplifier

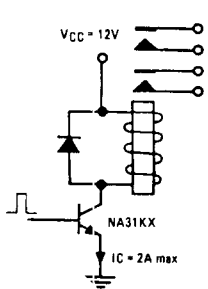


Figure C. Relay Driver

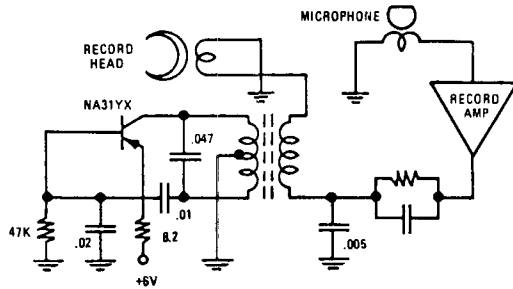


Figure D. Cassette Bias Oscillator



**NA41 (NPN)
NA42 (PNP) 2.5 Amp complementary power transistors**

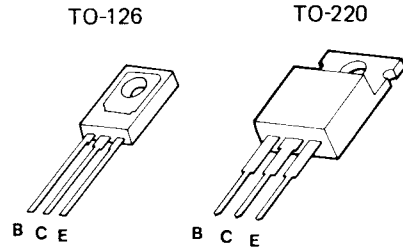
features

- 30 Volt/2.5 Amp rating
- Available in TO-126 and TO-220 packages
- Low V_{CE} (sat) and V_{BE} (sat) characteristics at $I_C = 1.6$ A, $I_B = 40$ mA
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability

applications

- 4 to 7 Watt, 4 or 8 Ohm audio power amplifiers
- High current switching circuits
- Converter/Inverter circuits
- TV receivers

1 packages and lead coding

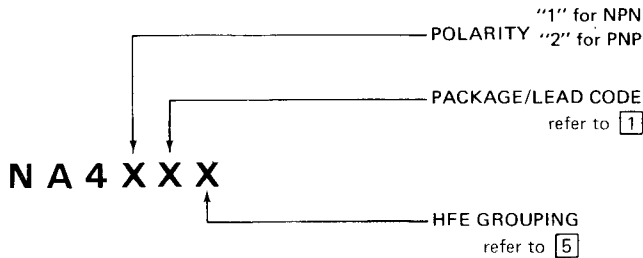


| PACKAGE CODE | |
|--------------|--------|
| TO 126 | TO 220 |
| U | W |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|---------------------------|--------------|---------------------------|
| Collector-Emitter Voltage | V_{CE} | 30 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 35 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 4 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 2.5 | A |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 1.7 | W |
| TO-220 | | 1.8 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 25 | W |
| TO-220 | | 25 | W |
| Thermal Resistance | | | |
| TO-126 | θ_{JA}/θ_{JC} | 73.5/5 | $^\circ\text{C}/\text{W}$ |
| TO-220 | θ_{JA}/θ_{JC} | 69.4/5 | $^\circ\text{C}/\text{W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | $^\circ\text{C}$ |

3 ordering information



4 electrical characteristics $T_C = 25^\circ C$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|-------------------------------------|-----|----------|-----|----------|
| BV_{CEr} | Collector-Emitter Sustaining Voltage | $I_C = 10 \text{ mA}, R = 1K$ | 30 | | | V |
| BV_{CB0} | Collector-Base Breakdown Voltage | $I_C = 100\mu A$ | 35 | | | V |
| BV_{EB0} | Emitter-Base Breakdown Voltage | $I_E = 100\mu A$ | 4 | | | V |
| I_{CER} | Collector-Emitter Leakage Current | $V_{CE} = 20V, R = 1K$ | | | 500 | μA |
| I_{CB0} | Collector-Base Leakage Current | $V_{CB} = 25V$ | | | 200 | μA |
| $V_{BE}(\text{on})$ | Base-Emitter Voltage | $I_C = 10 \text{ mA}, V_{CE} = 10V$ | 510 | 590 | 670 | mV |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 1.6A, I_B = 40 \text{ mA}$ | | | 1.2 | V |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 1.6A, I_B = 160 \text{ mA}$ | | | 1.4 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 1.6A, I_B = 40 \text{ mA}$ | | | 1.2 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 1.6A, I_B = 160 \text{ mA}$ | | | 0.6 | V |
| Cob | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 35 65 | | pF pF |

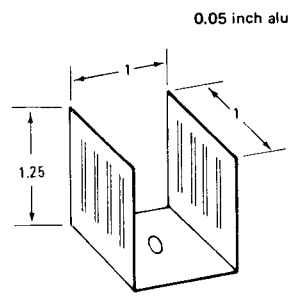
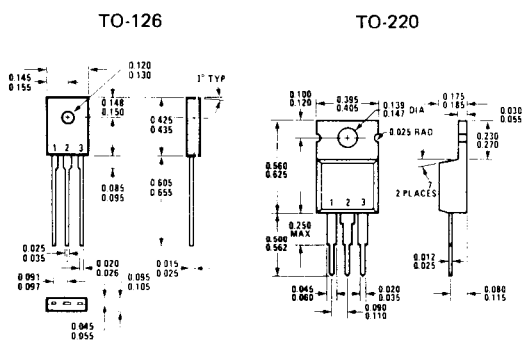
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|--------------------------------------|-----|-----|-----|-------|
| G | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 10V$ | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 10V$ | 100 | 127 | 160 | 1:1.6 |
| I | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 10V$ | 140 | 180 | 240 | 1:1.6 |
| X | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 10V$ | 30 | 58 | 110 | 1:3.5 |
| Y | DC Current Gain | $I_C = 300 \text{ mA}, V_{CE} = 10V$ | 100 | 190 | 350 | 1:3.5 |

6 physical dimensions

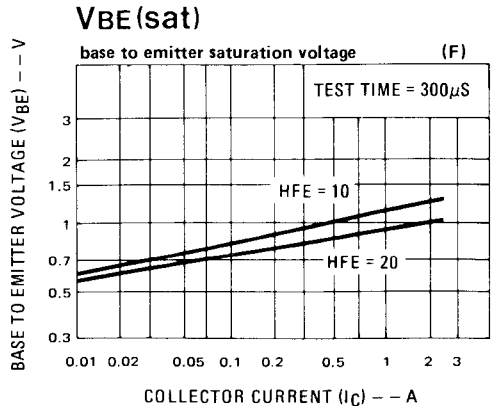
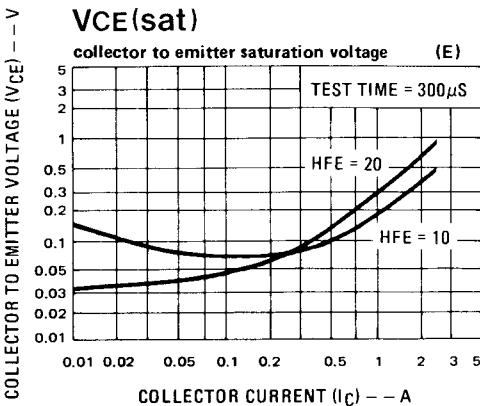
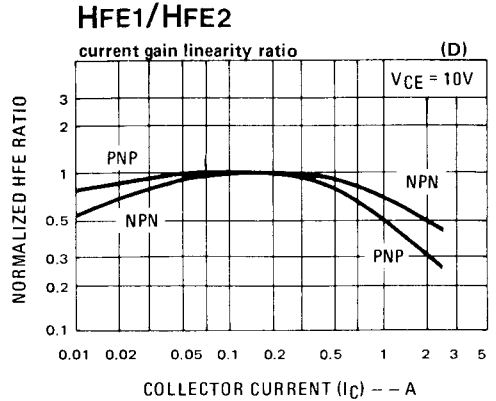
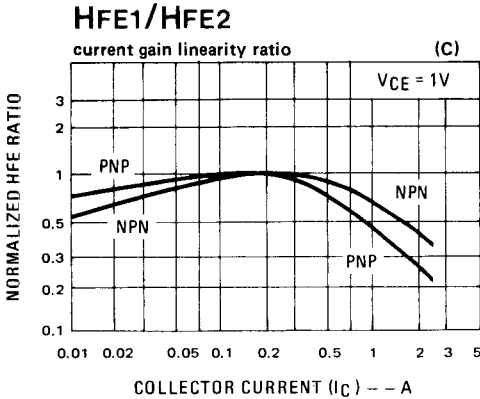
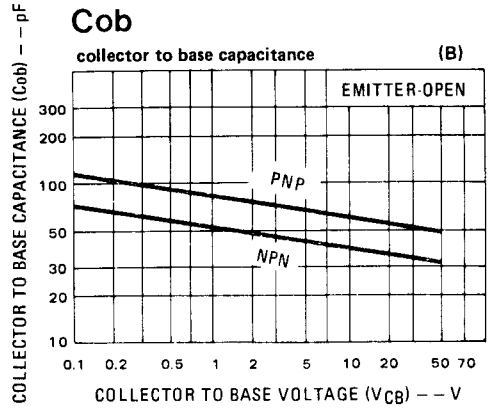
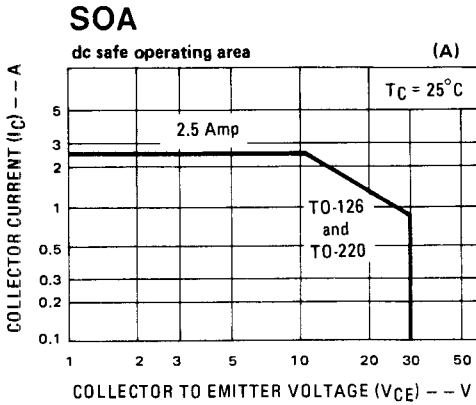
7 heatsink information

The TO-126 and TO-220 packages used with heatsink shown below permits about 8.7 Watts Power Dissipation and $\theta_{CA} = 9.4^\circ C/W$.



Mount transistor under heatsink and apply thermally conductive compound between contact surfaces.

8 typical performance characteristics



9 typical applications

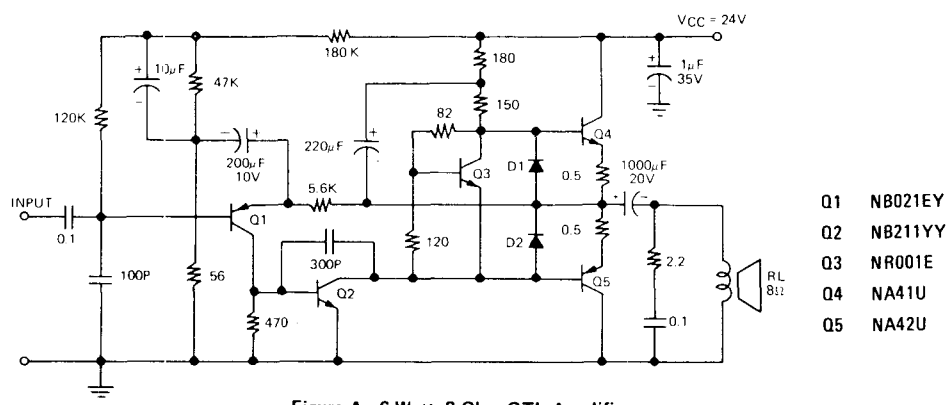


Figure A. 6 Watt, 8 Ohm OTL Amplifier

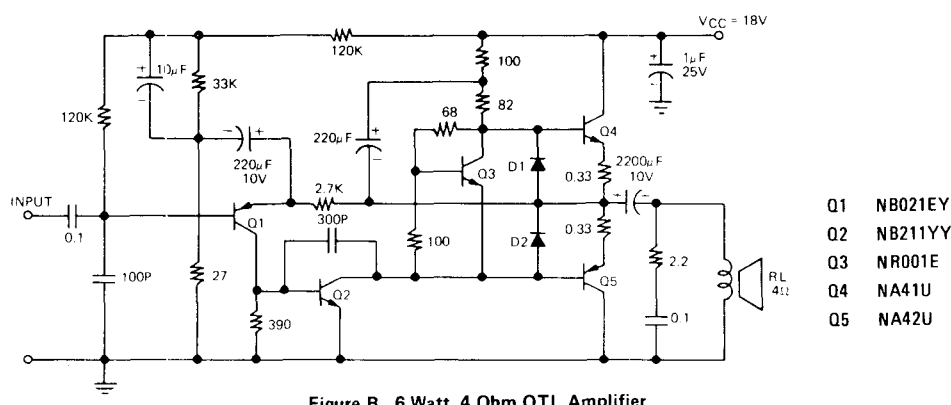


Figure B. 6 Watt, 4 Ohm OTL Amplifier

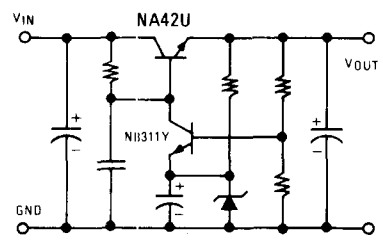


Figure C. Linear Regulator Circuit

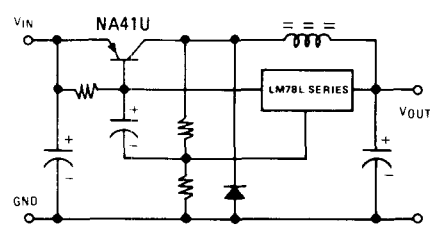


Figure D. Switching Regulator Circuit

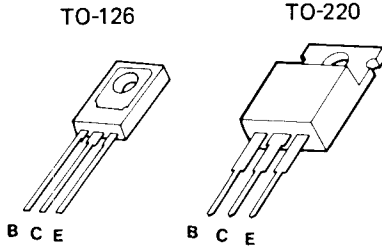


**NA51 (NPN)
NA52 (PNP) 3.5 Amp complementary power transistors**

features

- 45 Volt/3.5 Amp rating
- Available in TO-126 and TO-220 packages
- Low $V_{CE(sat)}$ and $V_{BE(sat)}$ characteristics at $I_C = 2A, I_B = 80\text{ mA}$
- Guaranteed $V_{CE(sat)}$ and $V_{BE(sat)}$ at $I_C = 3A, I_B = 160\text{ mA}$ for improved short-circuit protection design in audio amplifier
- "Epoxy B" packaging concept for excellent reliability

1 packages and lead coding



applications

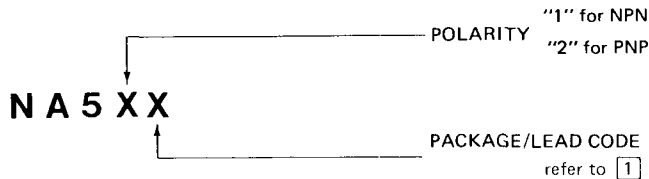
- 6 to 14 Watt, 4 or 8 Ohm audio power amplifier
- High current switching circuits
- Converter/Inverter circuits
- TV receivers

| PACKAGE CODE | |
|--------------|--------|
| TO 126 | TO 220 |
| U | W |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|---------------------------|-------------|--------------------|
| Collector-Emitter Voltage | V_{CE} | 45 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 50 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 4 | V_{DC} |
| Collector Current (continuous) | $I_C(\text{max})$ | 3.5 | A |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 1.8 | W |
| TO-220 | | 2.0 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 30 | W |
| TO-220 | | 30 | W |
| Thermal Resistance | | | |
| TO-126 | θ_{JA}/θ_{JC} | 69.4/4.17 | $^\circ\text{C/W}$ |
| TO-220 | θ_{JA}/θ_{JC} | 62.5/4.17 | $^\circ\text{C/W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

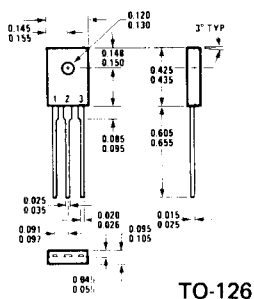
3 ordering information



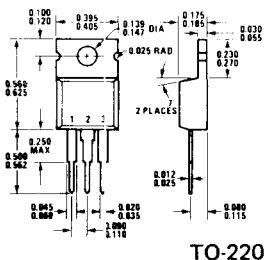
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--------------------------------------|--|-----|-----|-----|-------|
| BV_{CEr} | Collector-Emitter Sustaining Voltage | $I_C = 10\text{ mA}, R = 1\text{K}$ | 45 | | | V |
| BV_{CB0} | Collector-Base Breakdown Voltage | $I_C = 100\mu\text{A}$ | 50 | | | V |
| BV_{EB0} | Emitter-Base Breakdown Voltage | $I_E = 100\mu\text{A}$ | 4 | | | V |
| I_{CER} | Collector-Emitter Leakage Current | $V_{CE} = 35\text{V}, R = 1\text{K}$ | | | 1 | mA |
| I_{CB0} | Collector-Base Leakage Current | $V_{CB} = 40\text{V}$ | | | 0.5 | mA |
| $V_{BE}(\text{on})$ | Base-Emitter Voltage | $I_C = 15\text{ mA}, V_{CE} = 10\text{V}$ | 520 | 600 | 680 | mV |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 2\text{A}, I_B = 80\text{ mA}$ | | | 1.3 | V |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 3\text{A}, I_B = 160\text{ mA}$ | | | 1.6 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 2\text{A}, I_B = 80\text{ mA}$ | | | 1.5 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 3\text{A}, I_B = 160\text{ mA}$ | | | 5 | V |
| HFE_1 | DC Current Gain | $I_C = 500\text{ mA}, V_{CE} = 10\text{V}$ | 30 | 100 | | ratio |
| C_{ob} | Collector Output Capacitance | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | | | pF |
| | NPN types | | | 35 | | pF |
| | PNP types | | | 65 | | pF |

5 physical dimensions



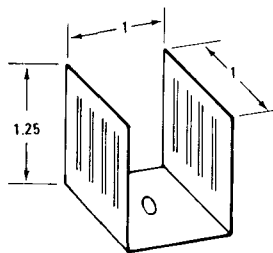
TO-126



TO-220

6 heatsink information

The TO-126 and TO-220 packages used with heatsink shown below permits about 9.2 Watts power dissipation and $\theta_{CA} = 9.4^\circ\text{C/W}$.



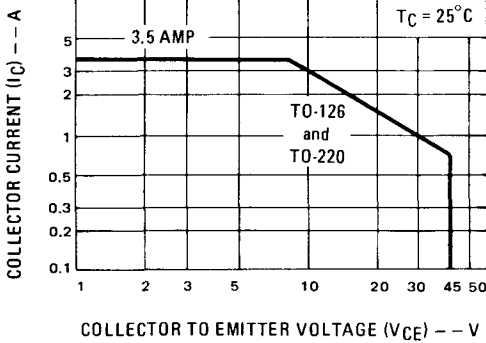
0.05 inch aluminium sheet

Mount transistor under heatsink and apply thermally conductive compound between contact surfaces.

7 typical performance characteristics

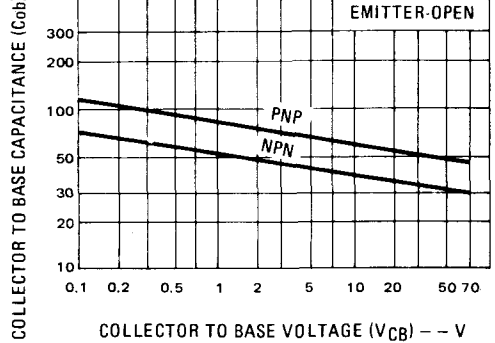
SOA

dc safe operating area (A)



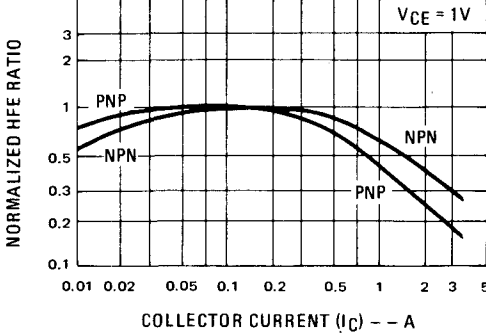
Cob

collector to base capacitance (B)



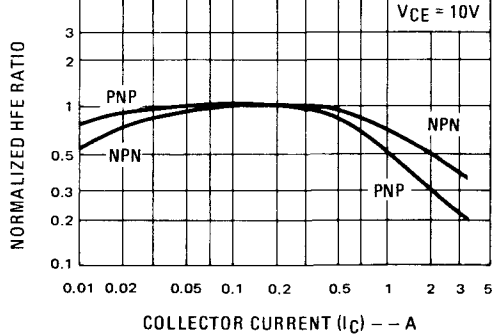
HFE1/HFE2

current gain linearity ratio (C)



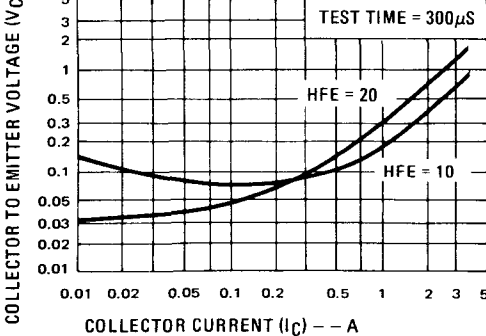
HFE1/HFE2

current gain linearity ratio (D)



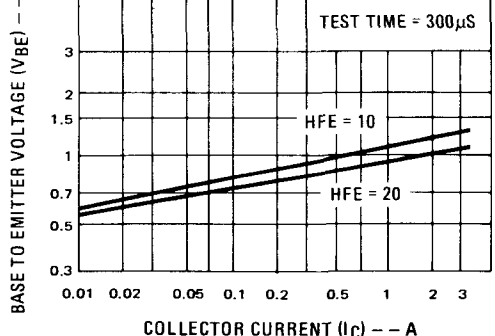
VCE(sat)

collector to emitter saturation voltage (E)

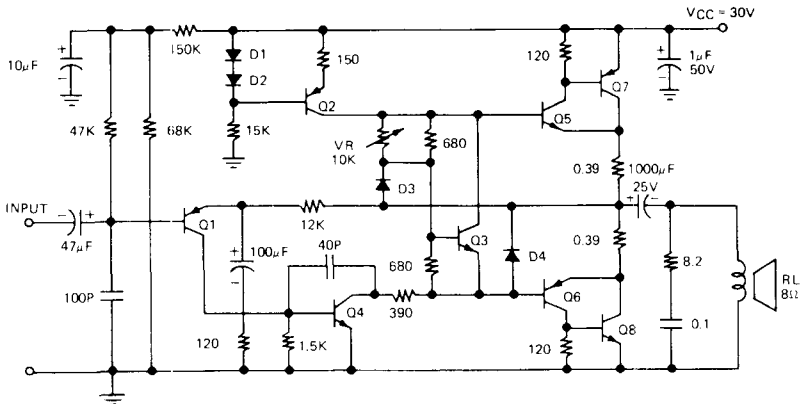


VBE(sat)

base to emitter saturation voltage (F)

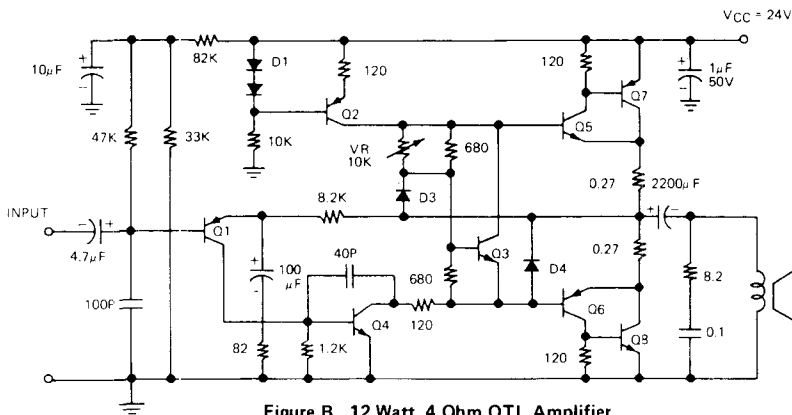


8 typical applications



- Q1 NB021EY
- Q2 NB122EY
- Q3 NR001E
- Q4 NB112EY
- Q5 NB312E
- Q6 NB322E
- Q7 NA52W
- Q8 NA51W

Figure A. 12 Watt, 8 Ohm OTL Amplifier



- Q1 NB021EY
- Q2 NB122EY
- Q3 NR001E
- Q4 NB112EY
- Q5 NB312E
- Q6 NB322E
- Q7 NA52W
- Q8 NA51W

Figure B. 12 Watt, 4 Ohm OTL Amplifier

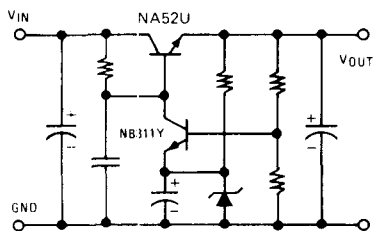


Figure C. Linear Regulator Circuit

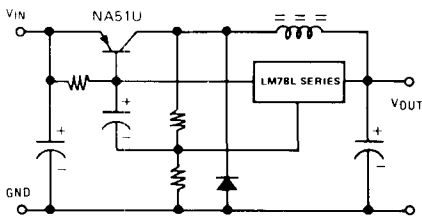


Figure D. Switching Regulator Circuit

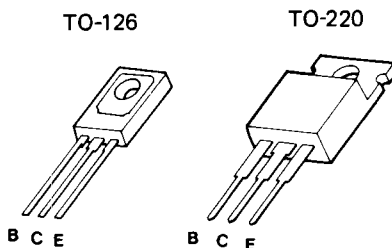


NA61 (NPN) 4.5 Amp complementary power transistors NA62 (PNP)

features

- 45 Volt/4.5 Amp rating
- Available in TO-126 and TO-220 packages
- Low $V_{CE(sat)}$ and $V_{BE(sat)}$ characteristics at $I_C = 3A, I_B = 150\text{ mA}$
- Guaranteed $V_{CE(sat)}$ and $V_{BE(sat)}$ at $I_C = 4.5A, I_B = 300\text{ mA}$ for improved short-circuit protection design in audio amplifiers
- "Epoxy B" packaging concept for excellent reliability

1 packages and lead coding



applications

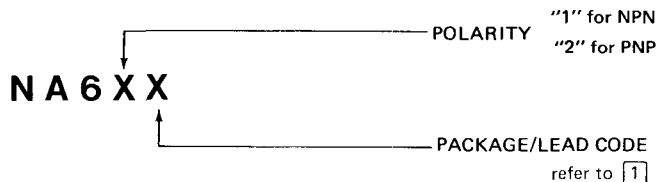
- 10 to 25 Watt, 4 Ohm audio power amplifiers
- High current switching circuits
- Converter/Inverter circuits
- TV receivers

| PACKAGE CODE | |
|--------------|--------|
| TO 126 | TO 220 |
| U | W |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|---------------------------|-------------|--------------------|
| Collector-Emitter Voltage | V_{CE} | 45 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 50 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 4 | V_{DC} |
| Collector Current (continuous) | $I_C(\text{max})$ | 4.5 | A |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 1.8 | W |
| TO-220 | | 2.0 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 40 | W |
| TO-220 | | 40 | W |
| Thermal Resistance | | | |
| TO-126 | θ_{JA}/θ_{JC} | 69.4/3.125 | $^\circ\text{C/W}$ |
| TO-220 | θ_{JA}/θ_{JC} | 62.5/3.125 | $^\circ\text{C/W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

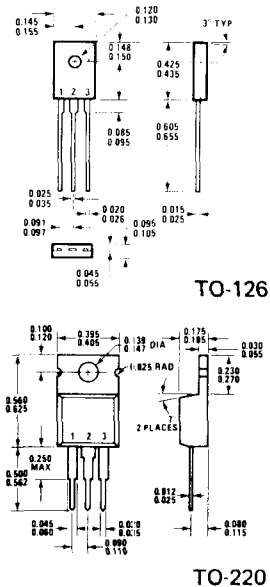
3 ordering information



4 electrical characteristics $T_C = 25^\circ\text{C}$

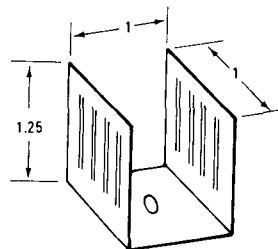
| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|--|-----|----------|-----|----------|
| V_{CEr} | Collector-Emitter Sustaining Voltage | $I_C = 10\text{ mA}, R = 1\text{K}$ | 45 | | | V |
| V_{CB0} | Collector-Base Breakdown Voltage | $I_C = 100\mu\text{A}$ | 50 | | | V |
| V_{EB0} | Emitter-Base Breakdown Voltage | $I_E = 100\mu\text{A}$ | 4 | | | V |
| I_{CER} | Collector-Emitter Leakage Current | $V_{CE} = 35\text{V}, R = 1\text{K}$ | | | 2 | mA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 40\text{V}$ | | | 1 | mA |
| $V_{BE}(\text{on})$ | Base-Emitter Voltage | $I_C = 20\text{ mA}, V_{CE} = 10\text{V}$ | 520 | 600 | 680 | mV |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 3\text{A}, I_B = 150\text{ mA}$ | | | 1.5 | V |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 4.5\text{A}, I_B = 300\text{ mA}$ | | | 2 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 3\text{A}, I_B = 150\text{ mA}$ | | | 2 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 4.5\text{A}, I_B = 300\text{ mA}$ | | | 5 | V |
| HFE_1 | DC Current Gain | $I_C = 500\text{ mA}, V_{CE} = 10\text{V}$ | 30 | 100 | | ratio |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | 40 70 | | pF pF |

5 physical dimensions



6 heatsink information

The TO-126 and TO-220 packages used with heatsink shown below permits about 10 Watts power dissipation and $\theta_{CA} = 9.4^\circ\text{C/W}$.



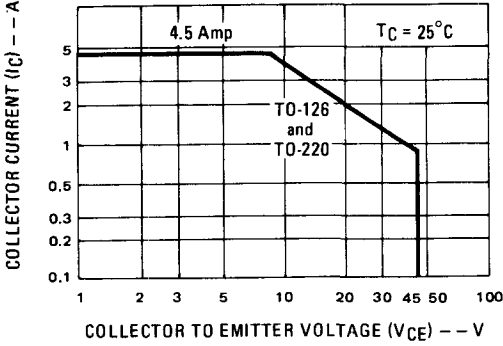
0.05 inch aluminium sheet

Mount transistor under heatsink and apply thermally conductive compound between contact surfaces.

7 typical performance characteristics

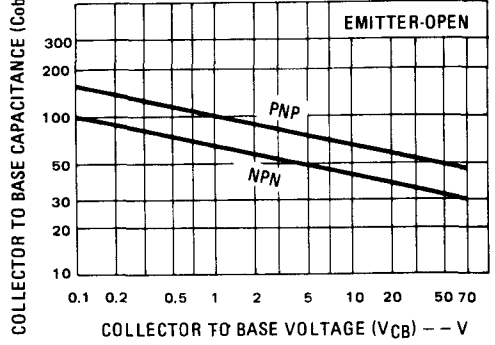
SOA

dc safe operating area (A)



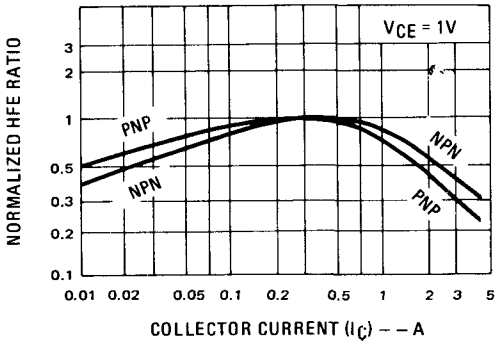
C_{ob}

collector to base capacitance (B)



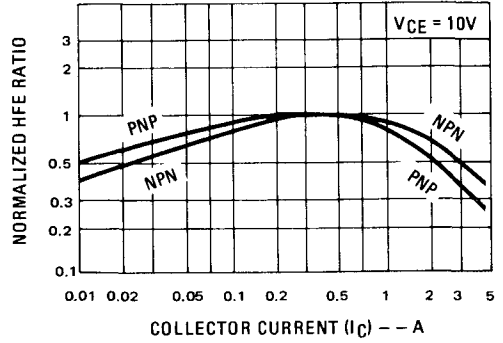
HFE1/HFE2

current gain linearity ratio (C)



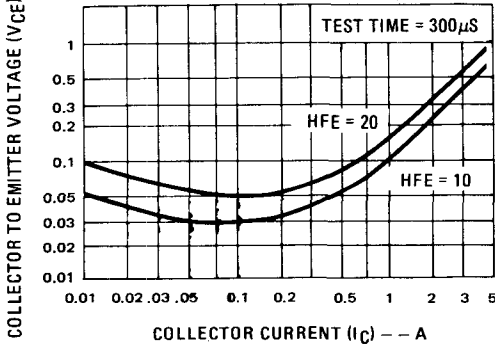
HFE1/HFE2

current gain linearity ratio (D)



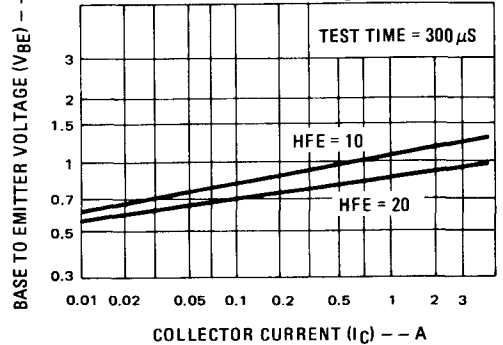
VCE(sat)

collector to emitter saturation voltage (E)

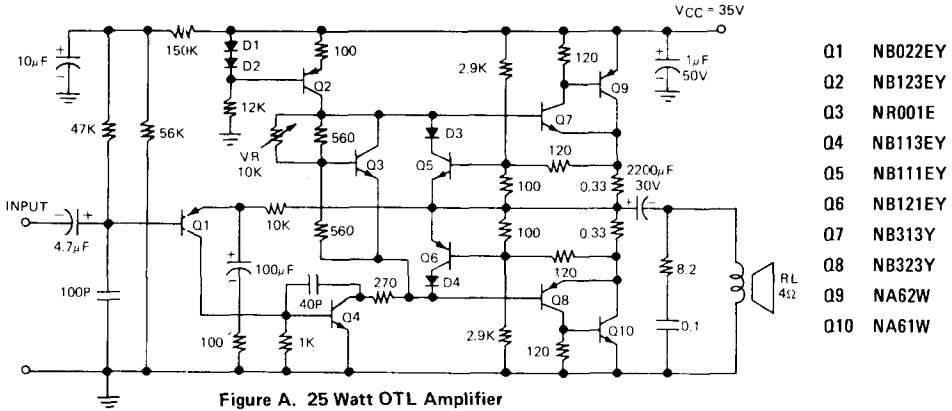


VBE(sat)

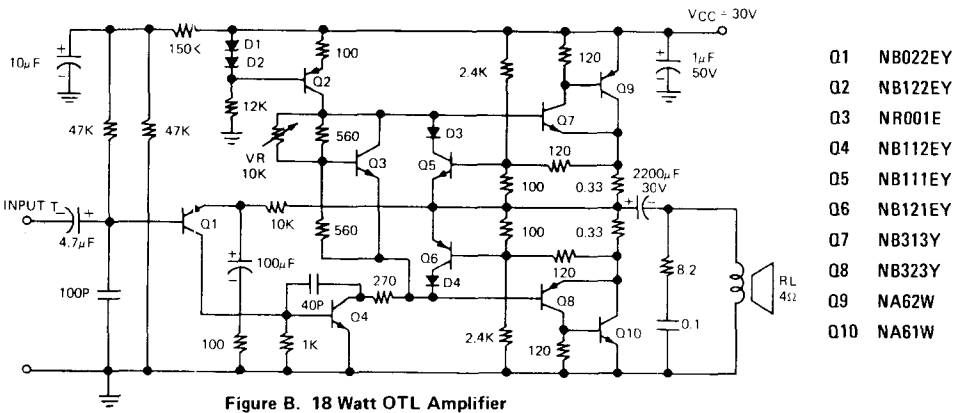
base to emitter saturation voltage (F)



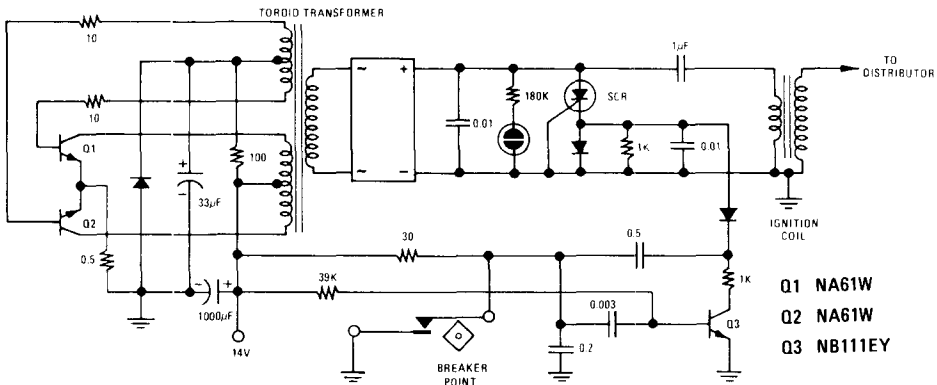
8 typical applications



- Q1 NB022EY
- Q2 NB123EY
- Q3 NR001E
- Q4 NB113EY
- Q5 NB111EY
- Q6 NB121EY
- Q7 NB313Y
- Q8 NB323Y
- Q9 NA62W
- Q10 NA61W



- Q1 NB022EY
- Q2 NB122EY
- Q3 NR001E
- Q4 NB112EY
- Q5 NB111EY
- Q6 NB121EY
- Q7 NB313Y
- Q8 NB323Y
- Q9 NA62W
- Q10 NA61W



- Q1 NA61W
- Q2 NA61W
- Q3 NB111EY



NA71 (NPN) NA72 (PNP) 3.5 Amp complementary power transistors

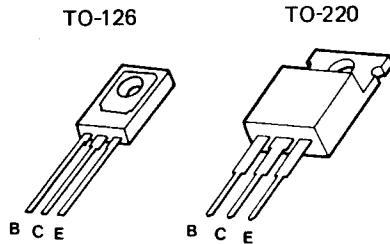
features

- 60 Volt/3.5 Amp rating
- Available in TO-126 and TO-220 packages
- Low $V_{CE(sat)}$ and $V_{BE(sat)}$ characteristics at $I_C = 2\text{ A}$, $I_B = 100\text{ mA}$
- Guaranteed $V_{CE(sat)}$ and $V_{BE(sat)}$ at $I_C = 3\text{ A}$, $I_B = 200\text{ mA}$ for improved short circuited protection design in audio amplifiers
- "Epoxy B" packaging concept for excellent reliability

applications

- 10–25 Watt 8 Ohm audio power amplifiers
- High current switching circuits
- Converter/Inverter circuits
- TV receivers

1 packages and lead coding

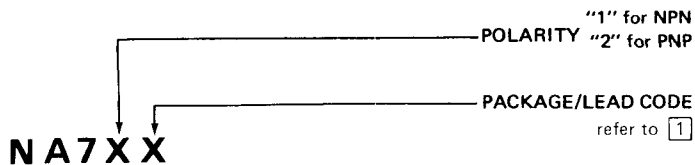


| PACKAGE CODE | |
|--------------|--------|
| TO 126 | TO 220 |
| U | W |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|---------------------------|-------------|--------------------|
| Collector-Emitter Voltage | V_{CE} | 60 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 65 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 4 | V_{DC} |
| Collector Current (continuous) | $I_C(\text{max})$ | 3.5 | A |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 1.8 | W |
| TO-220 | | 2.0 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | |
| TO-126 | | 40 | W |
| TO-220 | | 40 | W |
| Thermal Resistance | | | |
| TO-126 | θ_{JA}/θ_{JC} | 69.4/3.125 | $^\circ\text{C/W}$ |
| TO-220 | θ_{JA}/θ_{JC} | 62.5/3.125 | $^\circ\text{C/W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

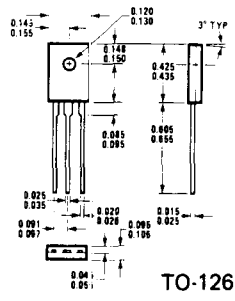
3 ordering information



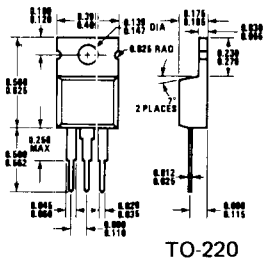
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|--|-----|----------|-----|----------|
| BV_{CEr} | Collector-Emitter Sustaining Voltage | $I_C = 10\text{ mA}, R = 1\text{ K}$ | 60 | | | V |
| BV_{CB0} | Collector-Base Breakdown Voltage | $I_C = 100\ \mu\text{A}$ | 65 | | | V |
| BV_{EB0} | Emitter-Base Breakdown Voltage | $I_E = 100\ \mu\text{A}$ | 4 | | | V |
| I_{CER} | Collector-Emitter Leakage Current | $V_{CE} = 50\text{V}, R = 1\text{ K}$ | | | 2 | mA |
| I_{CB0} | Collector-Base Leakage Current | $V_{CB} = 55\text{V}$ | | | 1 | mA |
| $V_{BE}(\text{on})$ | Base-Emitter Voltage | $I_C = 20\text{ mA}, V_{CE} = 10\text{V}$ | 520 | 600 | 680 | mV |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 2\text{A}, I_B = 100\text{ mA}$ | | | 1.5 | V |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 3\text{A}, I_B = 200\text{ mA}$ | | | 2 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 2\text{A}, I_B = 100\text{ mA}$ | | | 2 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 3\text{A}, I_B = 200\text{ mA}$ | | | 5 | V |
| HFE_1 | DC Current Gain | $I_C = 500\text{ mA}, V_{CE} = 10\text{V}$ | 30 | 100 | | ratio |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | 40 70 | | pF pF |

5 physical dimensions



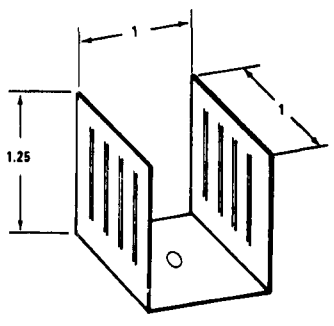
TO-126



TO-220

6 heatsink information

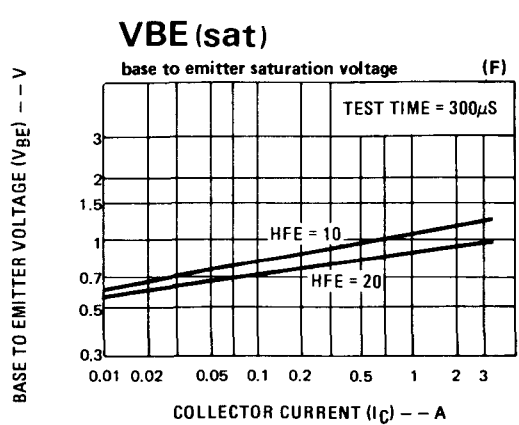
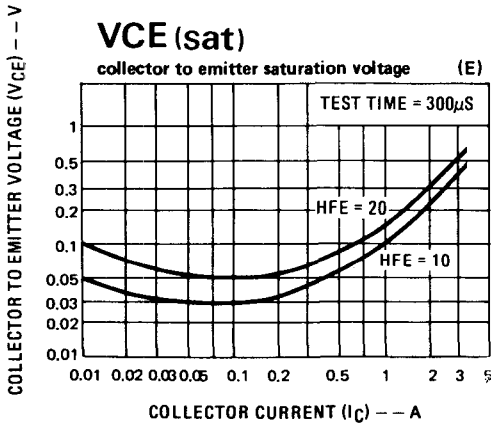
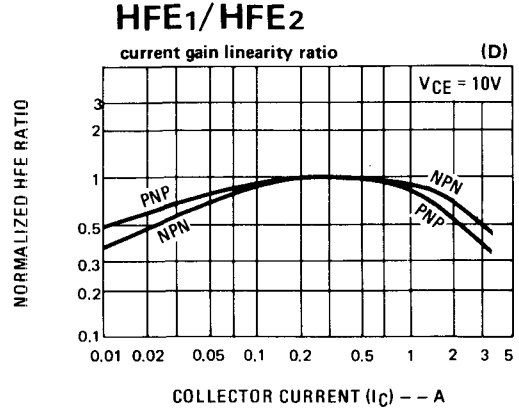
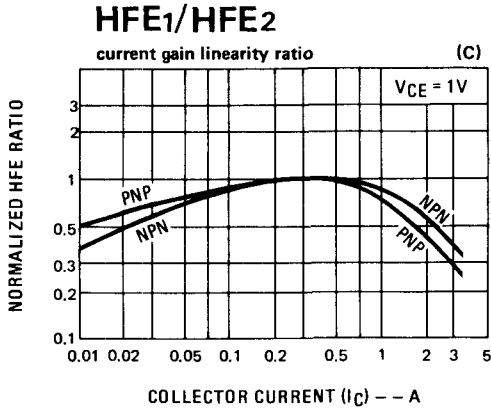
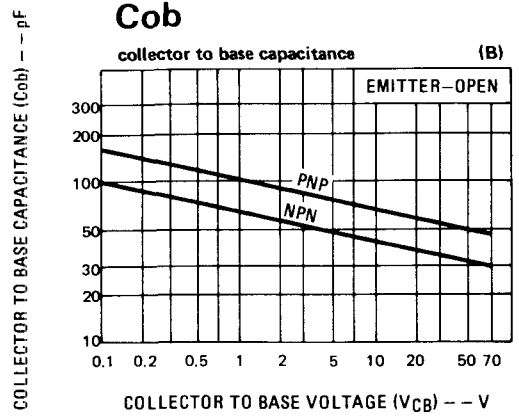
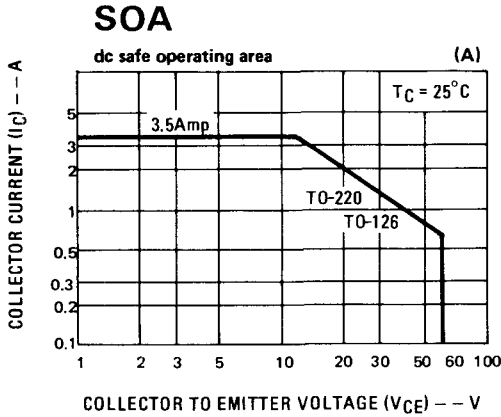
The TO-126 and TO-220 packages used with heatsink shown below permits about 10 Watts power dissipation and $\theta_{CA} = 9.4^\circ\text{C/W}$.



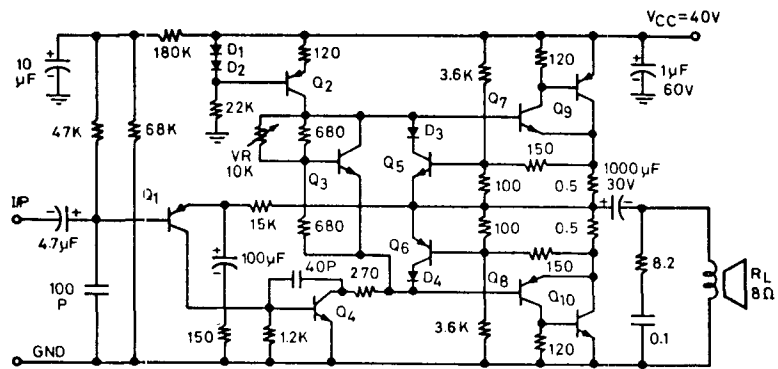
0.05 inch aluminium sheet

Mount transistor under heatsink and apply thermally conductive compound between contact surfaces.

7 typical performance characteristics

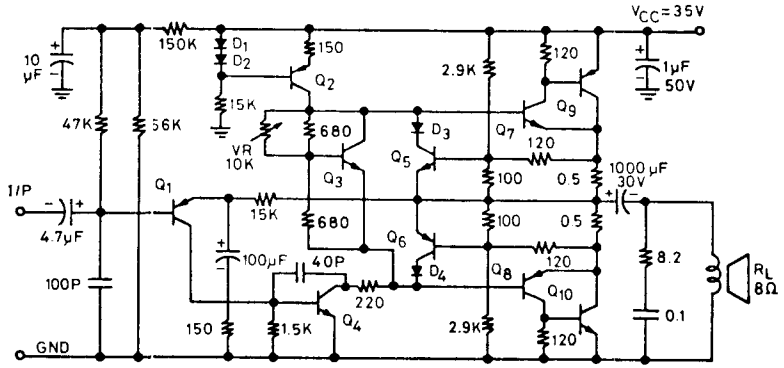


8 typical applications



- Q1 NB022EY
- Q2 NB123EY
- Q3 NR001E
- Q4 NB113EY
- Q5 NB111EY
- Q6 NB121EY
- Q7 NB313Y
- Q8 NB323Y
- Q9 NA72W
- Q10 NA71W

Figure A. 25 Watt OTL Amplifier



- Q1 NB022EY
- Q2 NB123EY
- Q3 NR001E
- Q4 NB113EY
- Q5 NB111EY
- Q6 NB121EY
- Q7 NB313Y
- Q8 NB323Y
- Q9 NA72W
- Q10 NA71W

Figure B. 18 Watt OTL Amplifier

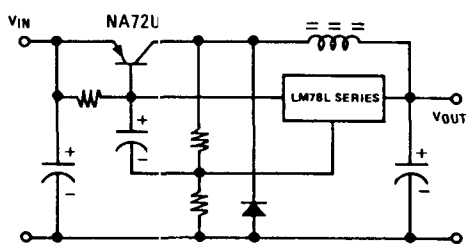


Figure C. Switching Regulator Circuit

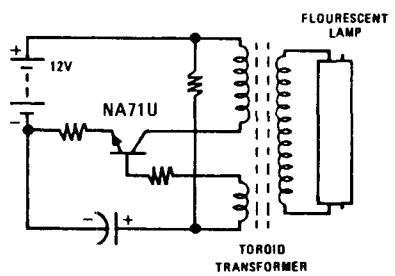


Figure D. Battery Lantern Circuit

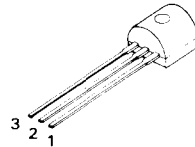


NB011,012 (NPN) 30mA general purpose transistors
NB021,022 (PNP)

features

- 35 to 50 Volt at 30 mA collector ratings
- 300 mV guaranteed V_{CE} (sat) characteristics at $I_C = 10$ mA and $I_B = 0.5$ mA
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability

1 package and lead coding



applications

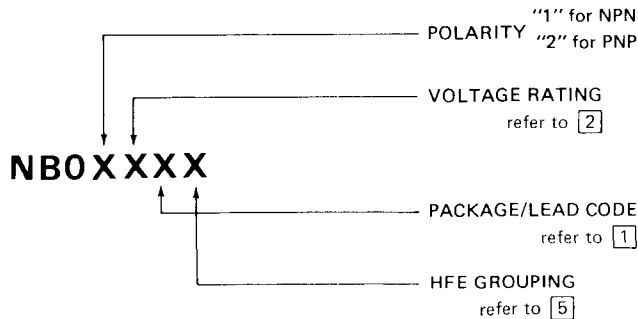
- Small signal amplifier circuits
- Equalizer preamplifiers
- Low current switching circuits
- TV receivers

| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | NB011 NB021 | NB012 NB022 | UNIT |
|--|----------------|----------------|----------------|--------------|
| Collector-Emitter Voltage | V_{CEO} | 35 | 50 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 40 | 55 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 5 | 5 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 30 | 30 | mA_{DC} |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | 0.6 | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | 1.0 | 1.0 | W |
| Thermal Resistance | θ_{JA} | 208 | 208 | $^\circ C/W$ |
| | θ_{JC} | 125 | 125 | $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | -55 to + 150 | $^\circ C$ |

3 ordering information



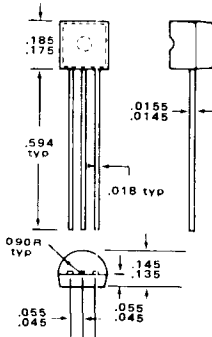
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|---|----------|--------|------------|--------------------------------|
| BV_{CEO} | Collector-Emitter Sustaining Voltage NB011/021 NB012/022 | $I_C = 1\text{ mA}$ | 35 50 | | | V V |
| BV_{CBO} | Collector-Base Breakdown Voltage NB011/021 NB012/022 | $I_C = 100\mu\text{A}$ | 40 55 | | | V V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\mu\text{A}$ | 5 | | | V |
| I_{CEO} | Collector-Emitter Leakage Current | $V_{CE} = 30\text{V NB011/021}$ 45V NB012/022 | | | 1 1 | μA μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 35\text{V NB011/021}$ 50V NB012/022 | | | 0.1 0.1 | μA μA |
| I_{EBO} | Emitter-Base Leakage Current | $V_{EB} = 4\text{V}$ | | | 0.1 | μA |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 10\text{ mA}, I_B = 0.5\text{ mA}$ | | 0.75 | 0.95 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 10\text{ mA}, I_B = 0.5\text{ mA}$ | | 0.1 | 0.3 | V |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | 2 3 | | pF pF |
| f_t | Current Gain Bandwidth Product | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 50 | 120 | | MHz |

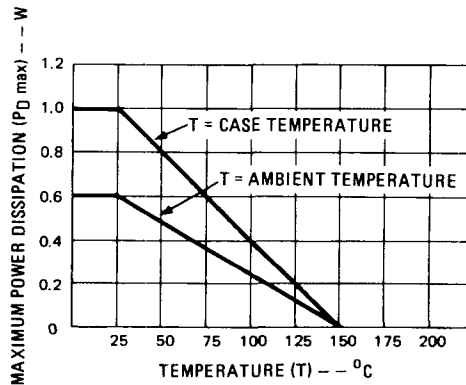
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|---|-----|-----|------|-------|
| I | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 200 | 260 | 350 | 1:1.6 |
| K | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 300 | 380 | 500 | 1:1.6 |
| L | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 450 | 580 | 750 | 1:1.6 |
| T | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 100 | 150 | 240 | 1:2.4 |
| U | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 200 | 320 | 500 | 1:2.4 |
| V | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 450 | 700 | 1100 | 1:2.4 |
| Y | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 100 | 190 | 350 | 1:3.5 |
| Z | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 300 | 580 | 1100 | 1:3.5 |

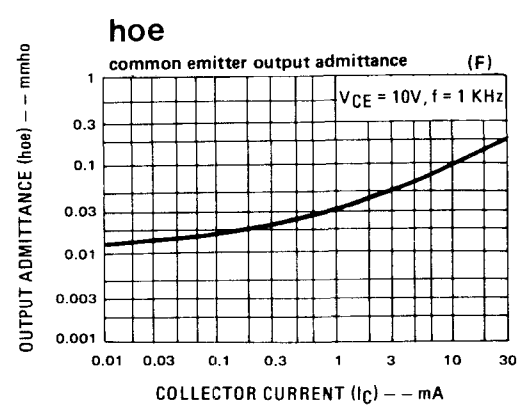
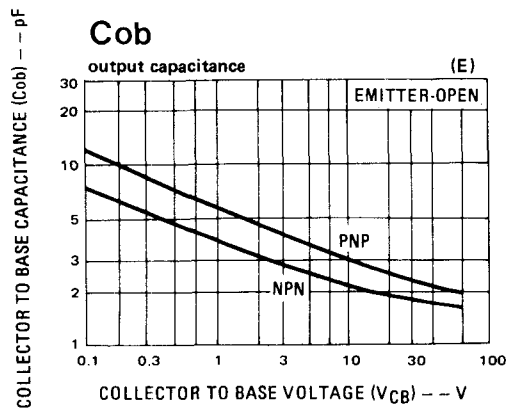
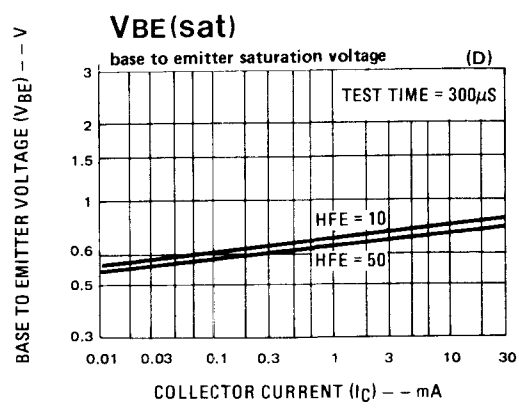
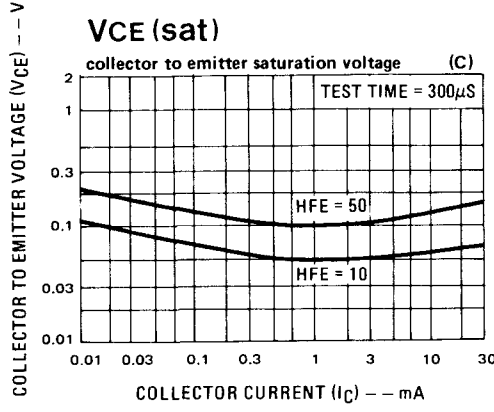
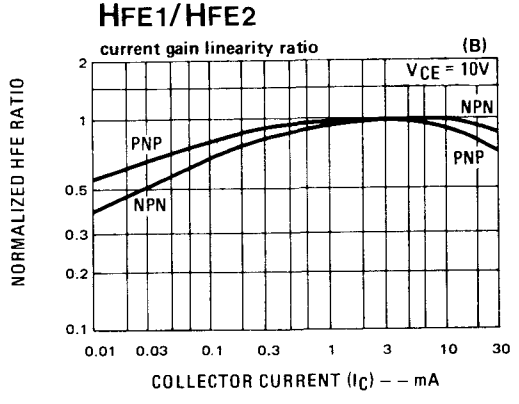
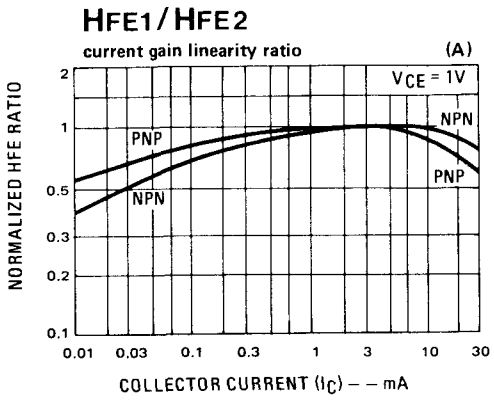
6 physical dimensions

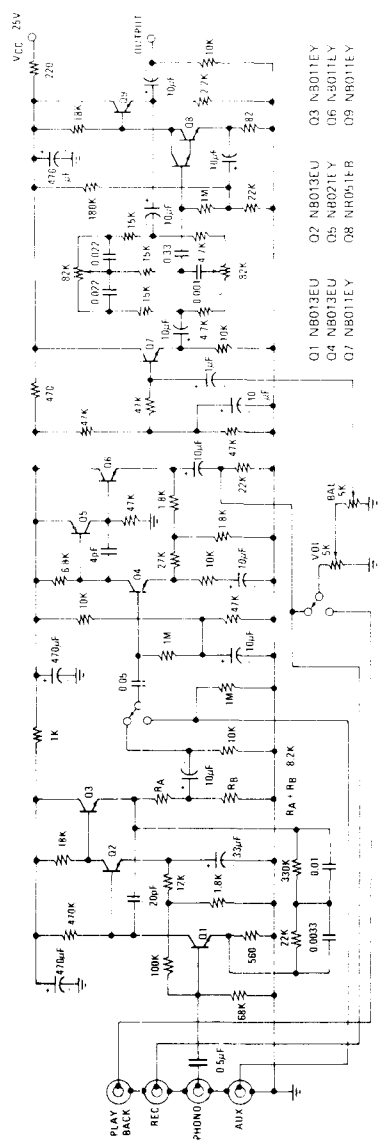


7 max power dissipation



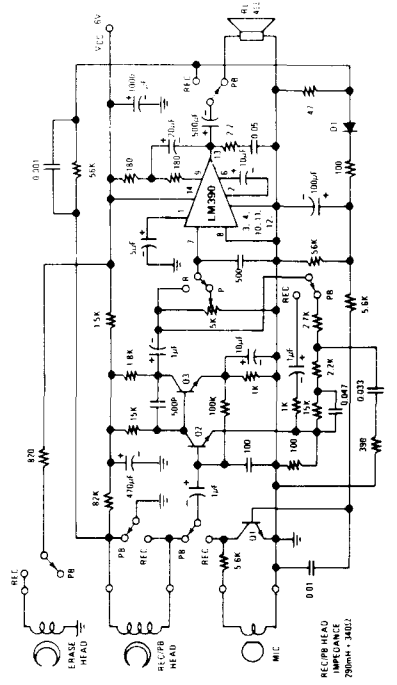
8 typical performance characteristics





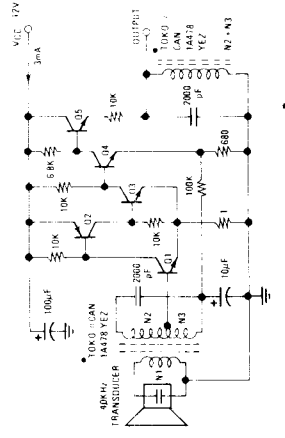
- Q1 NB013EU
- Q2 NB013EU
- Q3 NB011EY
- Q4 NB013EU
- Q5 NB021EY
- Q6 NB011EY
- Q7 NB011EY
- Q8 NR051E-B
- Q9 NB011EY

Figure A. High Quality Preamplifier with Tone Control Circuit



- Q1 NR041E
- Q2 NB013EU
- Q3 NB011EY

Figure B. Battery Operated Recording/Playback Cassette Circuit



- Q1 NB013EY
 - Q2 NB023EY
 - Q3 NB011EY
 - Q4 SB011EY
 - Q5 NB011EY
- L = 8mH
 G_m = 50
 N1 = 40T
 N2 = 360T
 N3 = 40T
 Output noise = 10mV rms

Figure C. High Gain Ultrasonic Amplifier

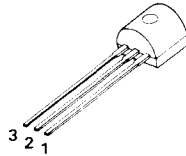


NB013, 014 (NPN) 30mA low noise transistors
NB023, 024 (PNP)

features

- 35 to 50 Volt at 30mA collector ratings
- 300mV guaranteed V_{CE} (sat) characteristics at $I_C = 10mA$ and $I_B = 0.5mA$
- 1dB typical wide-band Noise Figure
- "Epoxy B" packaging concept for excellent reliability

1 package and lead coding



applications

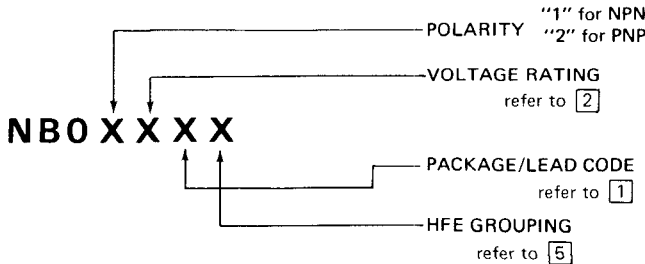
- Low noise amplifier circuits
- Equalizer preamplifiers

| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | NB013 NB023 | NB014 NB024 | UNIT |
|--|----------------|----------------|----------------|--------------|
| Collector-Emitter Voltage | V_{CEO} | 35 | 50 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 40 | 55 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 5 | 5 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 30 | 30 | mA_{DC} |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | 0.6 | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | 1.0 | 1.0 | W |
| Thermal Resistance | θ_{JA} | 208 | 208 | $^\circ C/W$ |
| | θ_{JC} | 125 | 125 | $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | -55 to + 150 | $^\circ C$ |

3 ordering information



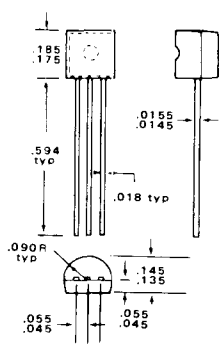
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--|--|----------|--------|----------|--------------------------------|
| BV_{CEO} | Collector-Emitter Sustaining Voltage NB013/023 NB014/024 | $I_C = 1\text{ mA}$ | 35 50 | | | V V |
| BV_{CBO} | Collector-Base Breakdown Voltage NB013/023 NB014/024 | $I_C = 100\mu\text{A}$ | 40 55 | | | V V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\mu\text{A}$ | 5 | | | V |
| I_{CEO} | Collector-Emitter Leakage Current | $V_{CE} = 30\text{V}$ NB013/023 45V NB014/024 | | | 1 1 | μA μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 35\text{V}$ NB013/023 50V NB014/024 | | | 50 50 | nA nA |
| I_{EBO} | Emitter-Base Leakage Current | $V_{EB} = 4\text{V}$ | | | 0.1 | μA |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$ | | 0.75 | 0.95 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$ | | 0.1 | 0.3 | V |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10\text{V}$, $f = 1\text{ MHz}$ | | 2 3 | | pF pF |
| f_t | Current Gain Bandwidth Product | $I_C = 1\text{ mA}$, $V_{CE} = 5\text{V}$ | 50 | 120 | | MHz |
| NF | Noise Figure | $I_C = 10\mu\text{A}$, $V_{CE} = 5\text{V}$ $R_S = 10\text{ K}$, $BW = 15.7\text{ KHz}$ | | 1 | 4 | dB |

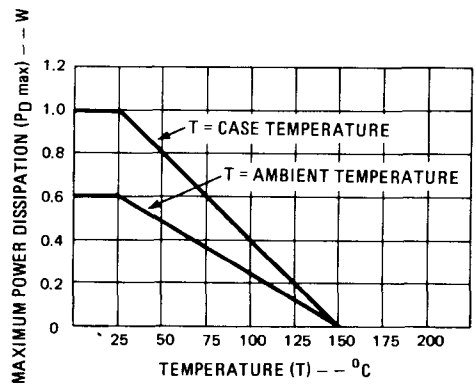
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|---|-----|-----|------|-------|
| I | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 200 | 260 | 350 | 1:1.6 |
| K | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 300 | 380 | 500 | 1:1.6 |
| L | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 450 | 580 | 750 | 1:1.6 |
| T | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 100 | 150 | 240 | 1:2.4 |
| U | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 200 | 320 | 500 | 1:2.4 |
| V | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 450 | 700 | 1100 | 1:2.4 |
| Y | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 100 | 190 | 350 | 1:3.5 |
| Z | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 300 | 580 | 1100 | 1:3.5 |

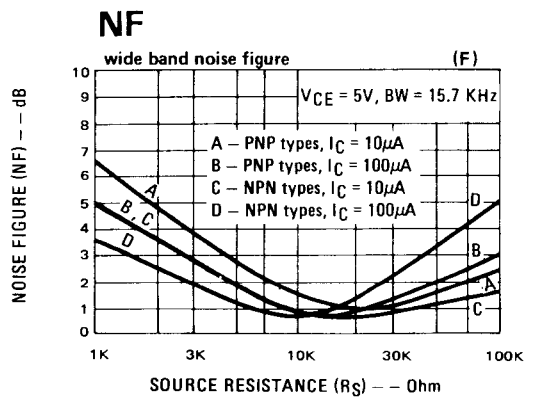
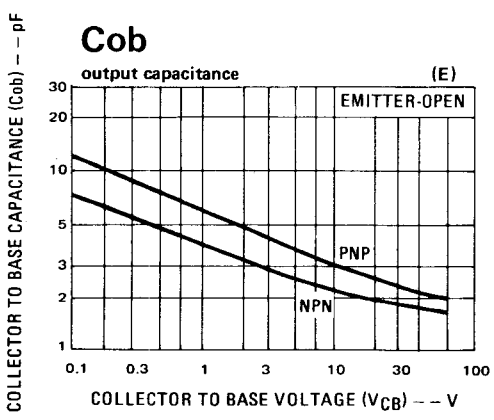
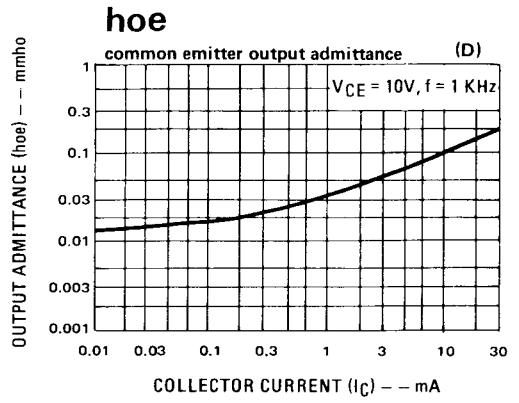
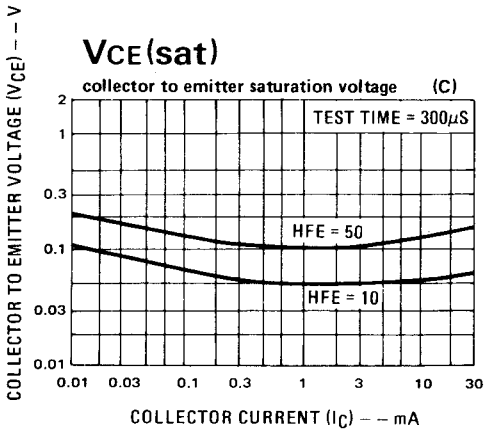
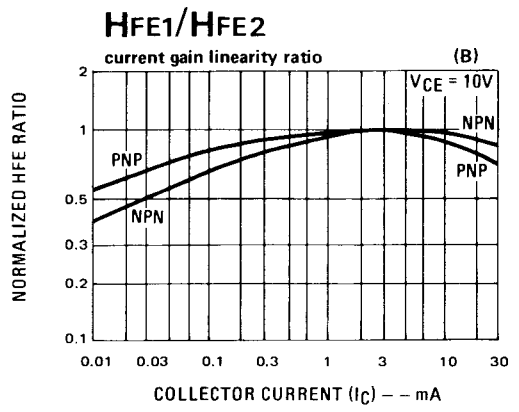
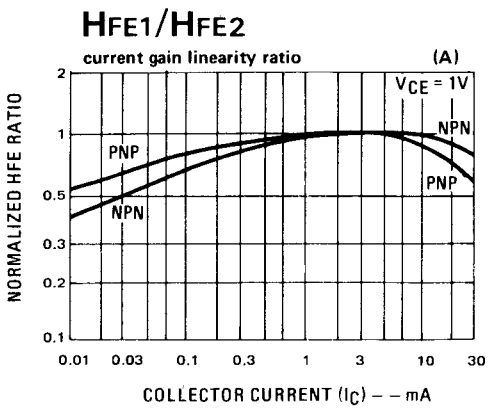
6 physical dimensions



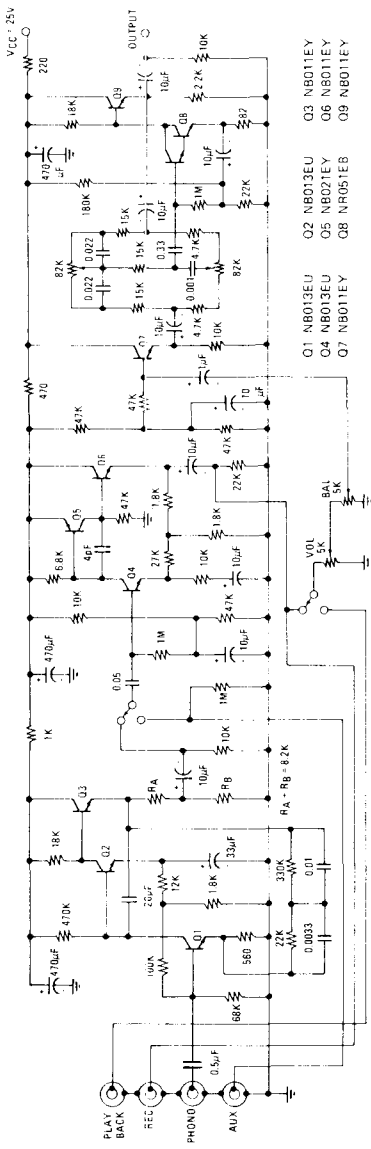
7 max power dissipation



8 typical performance characteristics

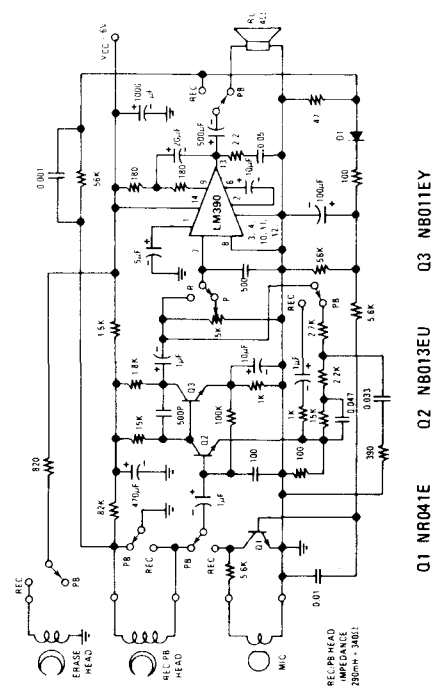


9 typical applications



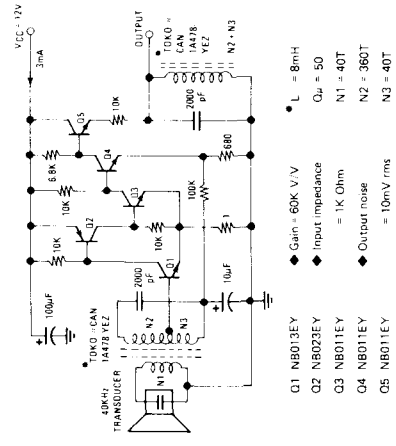
- Q1 NB013EU Q2 NB013EU Q3 NB011EY
- Q4 NB013EU Q5 NB021EY Q6 NB011EY
- Q7 NB011EY Q8 NR051ES Q9 NB011EY

Figure A. High Quality Preamplifier with Tone Control Circuit



- Q1 NR041E Q2 NB013EU Q3 NB011EY

Figure B. Battery Operated Recording/Playback Cassette Circuit



- Q1 NB013EY Q2 NB023EY Q3 NB011EY
 - Q4 NB011EY Q5 NB011EY
- L = 8mH
 Gain = 60K V/V
 Input impedance = 1K Ohm
 Output noise = 10mV rms

Figure C. High Gain Ultrasonic Amplifier

NB013, 014(NPN), NB023, 024(PNP)

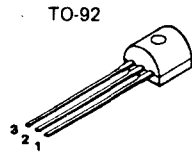


NB111, 112, 113 (NPN) 100mA general purpose transistors
NB121, 122, 123 (PNP)

features

1 package and lead coding

- 35 to 65 Volt at 100mA collector ratings
- 300mV guaranteed V_{CE} (sat) characteristics at $I_C = 40mA$ and $I_B = 0.8mA$
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability



applications

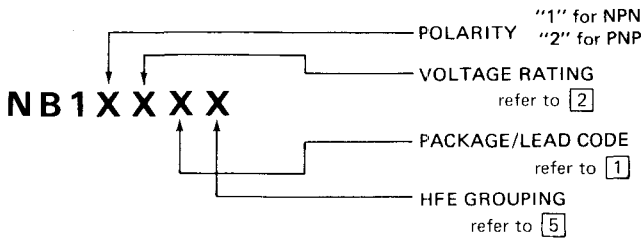
- Small signal amplifier circuits
- Medium current level switching circuits
- LED drivers
- TV receivers

| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | NB111 NB121 | NB112 NB122 | NB113 NB123 | UNIT |
|--|--------------------------------|----------------|----------------|----------------|------------------------------|
| Collector-Emitter Voltage | V_{CEO} | 35 | 50 | 65 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 40 | 55 | 70 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 6 | 6 | 6 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 100 | 100 | 100 | mA_{DC} |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | 0.6 | 0.6 | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | 1.0 | 1.0 | 1.0 | W |
| Thermal Resistance | θ_{JA} θ_{JC} | 208 125 | 208 125 | 208 125 | $^\circ C/W$ $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | -55 to + 150 | -55 to + 150 | $^\circ C$ |

3 ordering information



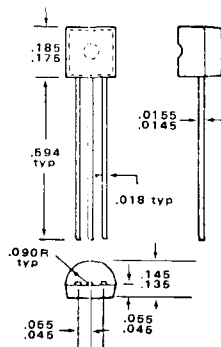
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------|---|---|----------------|--------|-------------------|---|
| BV_{CEO} | Collector-Emitter Sustaining Voltage NB111/121 NB112/122 NB113/123 | $I_C = 1\text{ mA}$ | 35 50 65 | | | V V V |
| BV_{CBO} | Collector-Base Breakdown Voltage NB111/121 NB112/122 NB113/123 | $I_C = 100\mu\text{A}$ | 40 55 70 | | | V V V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\mu\text{A}$ | 6 | | | V |
| I_{CEO} | Collector-Emitter Leakage Current | $V_{CE} = 30\text{V}$ NB111/121 45V NB112/122 60V NB113/123 | | | 1 1 1 | μA μA μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 35\text{V}$ NB111/121 50V NB112/122 65V NB113/123 | | | 0.1 0.1 0.1 | μA μA μA |
| I_{EBO} | Emitter-Base Leakage Current | $V_{EB} = 5\text{V}$ | | | 0.1 | μA |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C = 40\text{ mA}$, $I_B = 0.8\text{ mA}$ | | 0.8 | 0.95 | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 40\text{ mA}$, $I_B = 0.8\text{ mA}$ | | 0.15 | 0.3 | V |
| HFE1 | DC Current Gain | $I_C = 100\mu\text{A}$, $V_{CE} = 5\text{V}$ | 50 | | | ratio |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10\text{V}$, $f = 1\text{MHz}$ | | 2 3 | | pF pF |
| f_t | Current Gain Bandwidth Product | $I_C = 15\text{ mA}$, $V_{CE} = 5\text{V}$ | 100 | | | MHz |

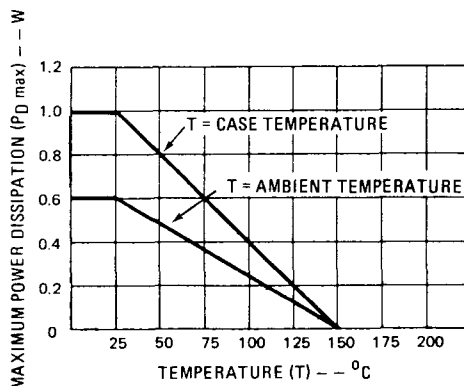
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|---|-----|-----|-----|-------|
| H | DC Current Gain | $I_C = 15\text{ mA}$, $V_{CE} = 5\text{V}$ | 100 | 127 | 160 | 1:1.6 |
| I | DC Current Gain | $I_C = 15\text{ mA}$, $V_{CE} = 5\text{V}$ | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | $I_C = 15\text{ mA}$, $V_{CE} = 5\text{V}$ | 200 | 260 | 350 | 1:1.6 |
| Y | DC Current Gain | $I_C = 15\text{ mA}$, $V_{CE} = 5\text{V}$ | 100 | 190 | 350 | 1:3.5 |

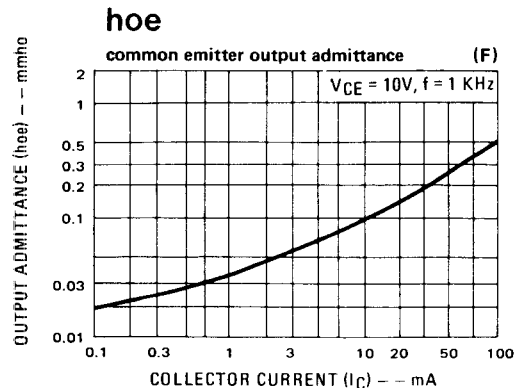
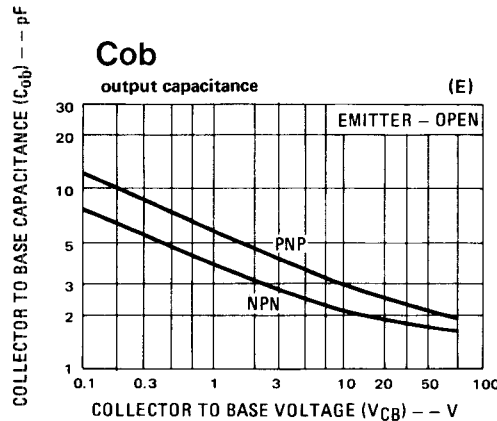
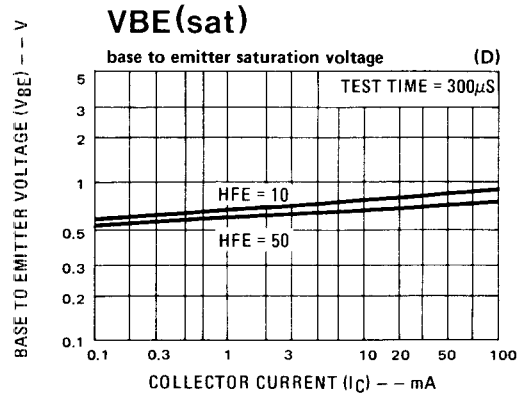
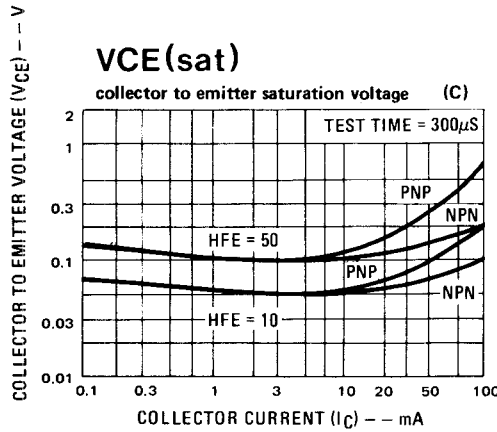
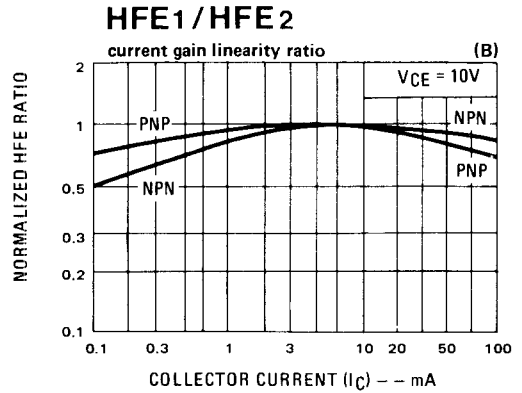
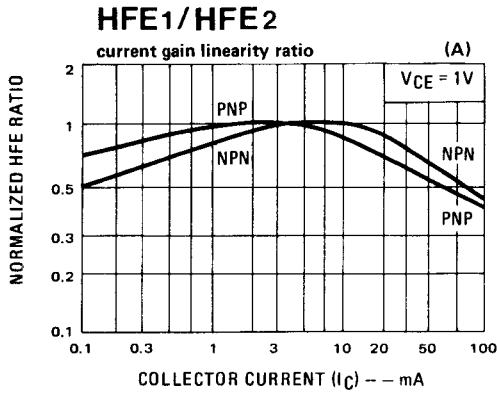
6 physical dimensions



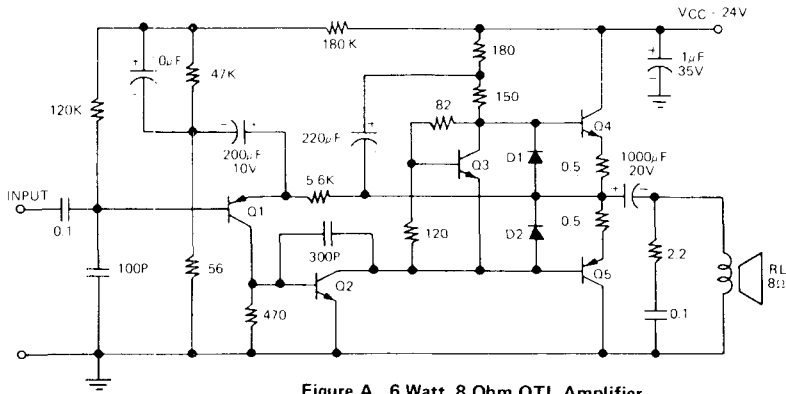
7 max power dissipation



8 typical performance characteristics

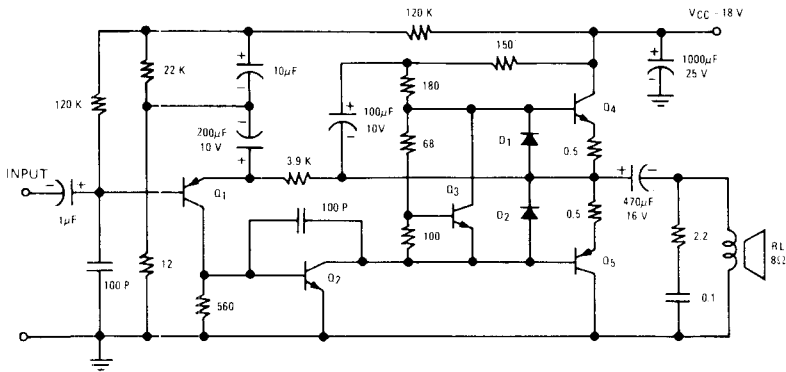


9 typical applications



- Q1 NB021EY
- Q2 NB211YY
- Q3 NR001E
- Q4 NA41U
- Q5 NA42U

Figure A. 6 Watt, 8 Ohm OTL Amplifier



- Q1 NB021EY
- Q2 NB211EY
- Q3 NR001E
- Q4 NA31YG/I
- Q5 NA32YG/I

Figure B. 4 Watt, 8 Ohm OTL Amplifier

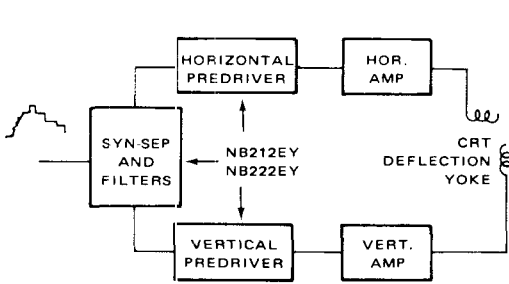


Figure C. TV processor/predriver applications

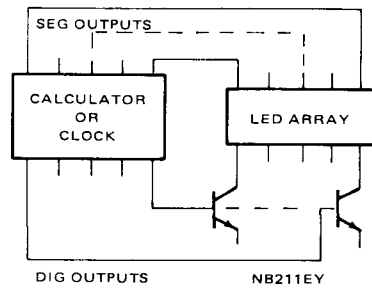


Figure D. Calculator/Clock driver application

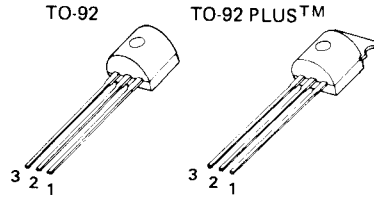


NB 211, 212, 213 (NPN) NB 221, 222, 223 (PNP) 500mA medium current driver transistors

features

- 35 to 65 Volt at 500 mA collector ratings
- 1.2 Watts practical power dissipation (TO-92 PLUSTM)
- 400 mV guaranteed V_{CE} (sat) characteristics at $I_C = 100$ mA and $I_B = 2$ mA
- Matched HFE groupings for complementary applications
- "Epoxy B" packaging concept for excellent reliability

1 package and lead coding



| PACKAGE CODE | | LEAD | | |
|--------------|------------|------|---|---|
| TO-92 | TO-92 PLUS | 1 | 2 | 3 |
| E | X | E | B | C |
| F | Y | E | C | B |
| H | Z | B | C | E |
| | | C | B | E |

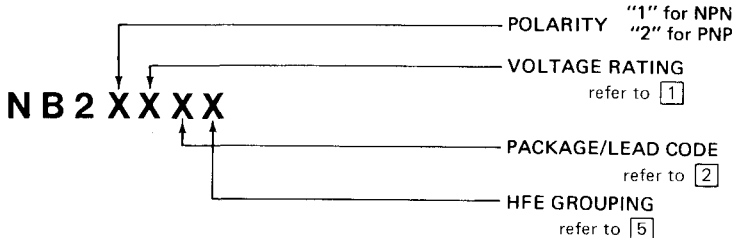
applications

- 4 to 6 Watt amplifier class A drivers
- Medium current level switching circuits
- LED drivers
- TV receivers

2 maximum ratings

| PARAMETER | SYMBOL | NB211 NB221 | NB212 NB222 | NB213 NB223 | UNIT |
|--|---------------------------|----------------|----------------|----------------|--------------|
| Collector-Emitter Voltage | V_{CEO} | 35 | 50 | 65 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 40 | 55 | 70 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 6.0 | 6.0 | 6.0 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 500 | 500 | 500 | mA |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | | | | |
| TO-92 | | 0.6 | 0.6 | 0.6 | W |
| TO-92 PLUS | | 0.75 | 0.75 | 0.75 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | | | | |
| TO-92 | | 1.0 | 1.0 | 1.0 | W |
| TO-92 PLUS | | 2.5 | 2.5 | 2.5 | W |
| Thermal Resistance | | | | | |
| TO-92 | θ_{JA}/θ_{JC} | 208/125 | 208/125 | 208/125 | $^\circ C/W$ |
| TO-92 PLUS | θ_{JA}/θ_{JC} | 167/50 | 167/50 | 167/50 | $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | -55 to +150 | -55 to +150 | $^\circ C$ |

3 ordering information



4 electrical characteristics $T_C = 25^\circ C$

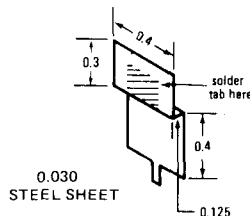
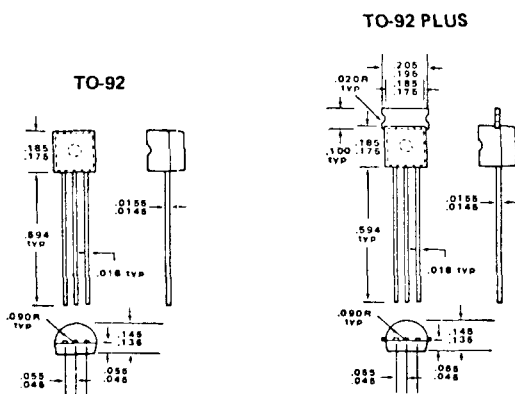
| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|---|---|-----|-----|------|-------|
| BV _{CEO} | Collector-Emitter Sustaining Voltage NB211/221 NB212/222 NB213/223 | I _C = 1 mA | 35 | | | V |
| | | | 50 | | | V |
| | | | 65 | | | V |
| BV _{CBO} | Collector-Base Breakdown Voltage NB211/221 NB212/222 NB213/223 | I _C = 100μA | 40 | | | V |
| | | | 55 | | | V |
| | | | 70 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E = 10μA | 6 | | | V |
| I _{CEO} | Collector-Emitter Leakage Current | V _{CE} = 30V NB211/221 45V NB212/222 60V NB213/223 | | | 10 | μA |
| | | | | | 10 | μA |
| | | | | | 10 | μA |
| I _{CBO} | Collector-Base Leakage Current | V _{CB} = 35V NB211/221 50V NB212/222 65V NB213/223 | | | 0.5 | μA |
| I _{EBO} | Emitter-Base Leakage Current | V _{EB} = 5V | | | 0.5 | μA |
| V _{BE} (sat) | Base-Emitter Saturation Voltage | I _C = 100 mA, I _B = 2 mA | | 0.8 | 0.95 | V |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = 100 mA, I _B = 2 mA | | 0.2 | 0.4 | V |
| HFE1 | DC Current Gain | I _C = 1 mA, V _{CE} = 5V | 30 | | | ratio |
| C _{ob} | Collector Output Capacitance NPN types PNP types | V _{CB} = 10V, f = 1 MHz | | 3.5 | | pF |
| | | | | 4.5 | | pF |
| f _t | Current Gain Bandwidth Product | I _C = 20 mA, V _{CE} = 5V | 50 | | | MHz |

5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|--|-----|-----|-----|-------|
| G | DC Current Gain | I _C = 30 mA, V _{CE} = 5V | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | I _C = 30 mA, V _{CE} = 5V | 100 | 127 | 160 | 1:1.6 |
| I | DC Current Gain | I _C = 30 mA, V _{CE} = 5V | 140 | 180 | 240 | 1:1.6 |
| J | DC Current Gain | I _C = 30 mA, V _{CE} = 5V | 200 | 260 | 350 | 1:1.6 |
| X | DC Current Gain | I _C = 30 mA, V _{CE} = 5V | 30 | 58 | 110 | 1:3.5 |
| Y | DC Current Gain | I _C = 30 mA, V _{CE} = 5V | 100 | 190 | 250 | 1:3.5 |

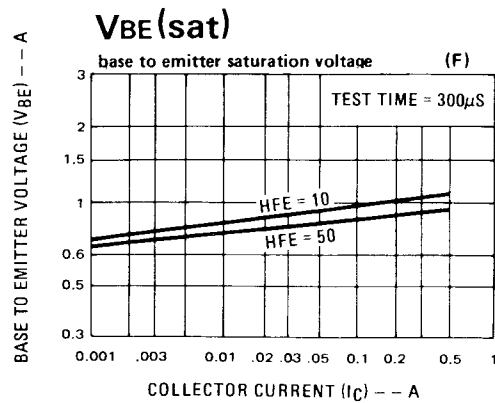
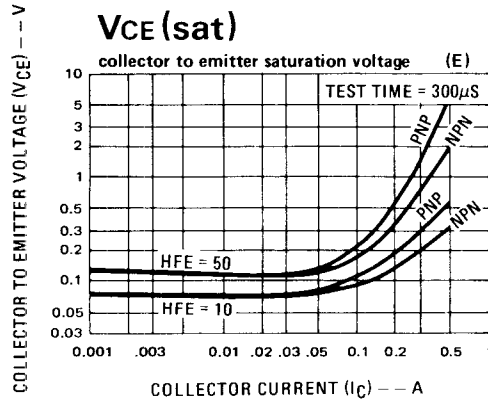
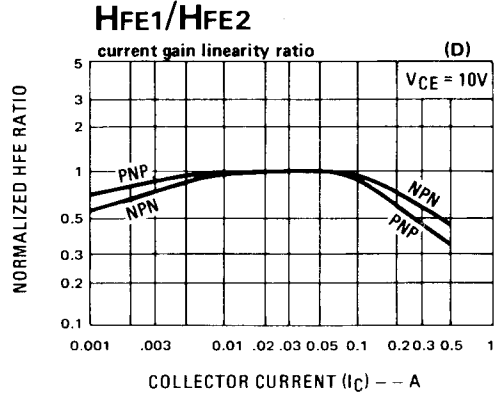
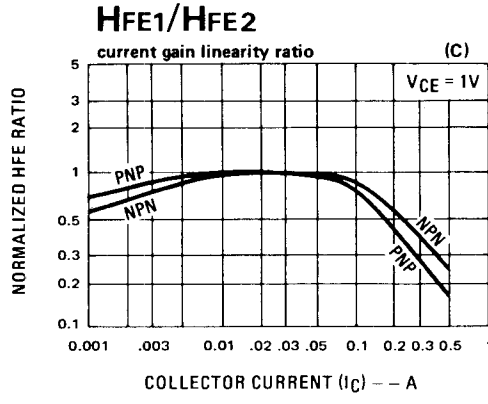
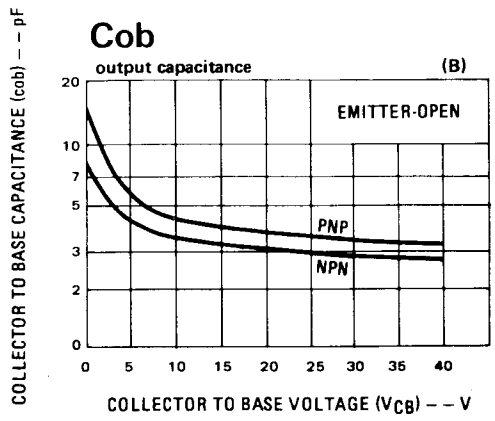
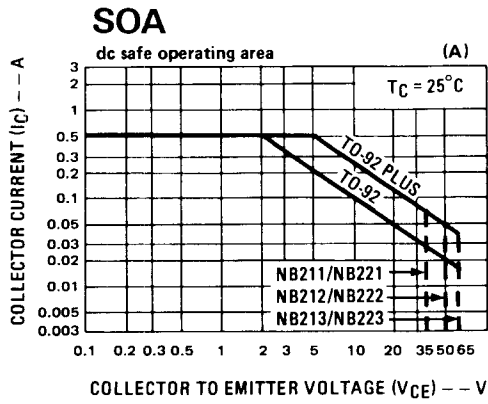
6 physical dimensions

7 heatsink information

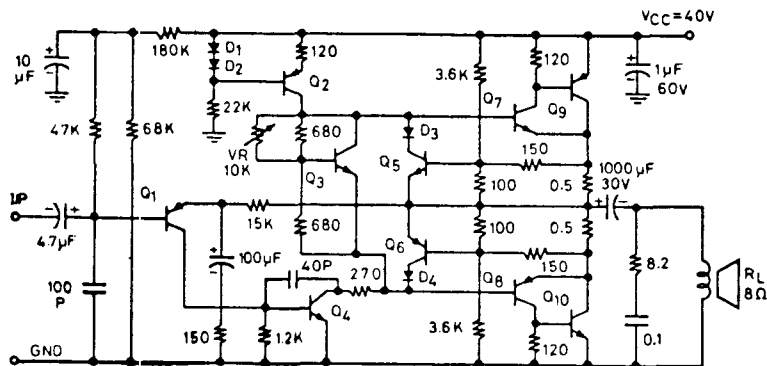


- TO-92 PLUS package with heat sink shown on right permits 1.6 Watts power dissipation and combined Thermal Resistance $\theta_{JA} = 78^\circ C/W$. If used without heat sink and PCB land area at collector lead > 1 sq. inch, $P_D = 1.2W$.

8 typical performance characteristics



9 typical applications



- Q1 NB022EY
- Q2 NB123EY
- Q3 NR001E
- Q4 NB113EY
- Q5 NB111EY
- Q6 NB121EY
- Q7 NB313Y
- Q8 NB323Y
- Q9 NA72W
- Q10 NA71W

Figure A. 25 Watt OTL Amplifier

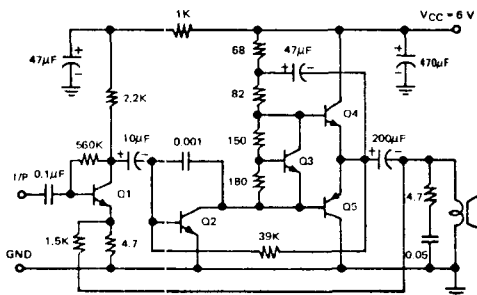


Figure B. 700mW 6V/4 Ω OTL Amplifier

- Q1 NB011EY
- Q2 NB111EH/J
- Q3 NR001
- Q4 NA21EG/J
- Q5 NA22EG/J

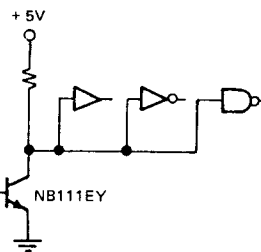


Figure C. High fan-out TTL driver

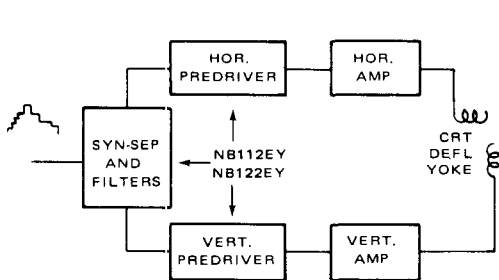


Figure D. TV processor/predriver applications

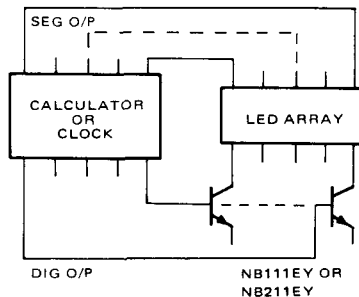


Figure E. Calculator/Clock driver application

NB211, 212, 213(NPN), NB221, 222, 223(PNP)



NB311, 312, 313 (NPN) 1.5Amp complementary power drivers
NB321, 322, 323 (PNP)

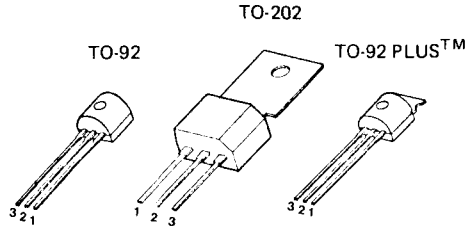
features

- 35 to 65 Volt at 1.5 Amp collector ratings
- Low $V_{CE(sat)}$ and $V_{BE(sat)}$ characteristics with $I_C = 300\text{ mA}$ and $I_B = 10\text{ mA}$ drive
- Available in TO-92, TO-92 PLUS™ and TO-202 packages
- "Epoxy B" packaging concept for excellent reliability

applications

- Driver stages in high-power audio amplifiers
- Medium-power switching circuits
- Converter/inverter circuits
- TV receivers

1 packages and lead coding

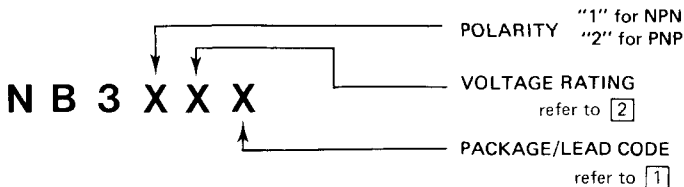


| TO-92 | PACKAGE CODE | | | LEAD | | |
|-------|--------------|--------|--|------|---|---|
| | TO-92 PLUS | TO-202 | | 1 | 2 | 3 |
| E | X | K | | E | B | C |
| F | Y | L | | E | C | B |
| | Z | M | | B | C | E |
| H | | | | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | NB311 NB321 | NB312 NB322 | NB313 NB323 | UNIT |
|--|----------------|----------------|----------------|----------------|------------------|
| Collector-Emitter Voltage | V_{CEO} | 35 | 50 | 65 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 40 | 55 | 70 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 6 | 6 | 6 | V_{DC} |
| Collector Current (continuous) | I_C | 1.5 | 1.5 | 1.5 | A_{DC} |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | | | | |
| TO-92 | | 0.6 | 0.6 | 0.6 | W |
| TO-92 PLUS | | 0.75 | 0.75 | 0.75 | W |
| TO-202 | | 1.75 | 1.75 | 1.75 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | | | | |
| TO-92 | | 1.0 | 1.0 | 1.0 | W |
| TO-92 PLUS | | 2.5 | 2.5 | 2.5 | W |
| TO-202 | | 10 | 10 | 10 | W |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | -55 to +150 | -55 to +150 | $^\circ\text{C}$ |

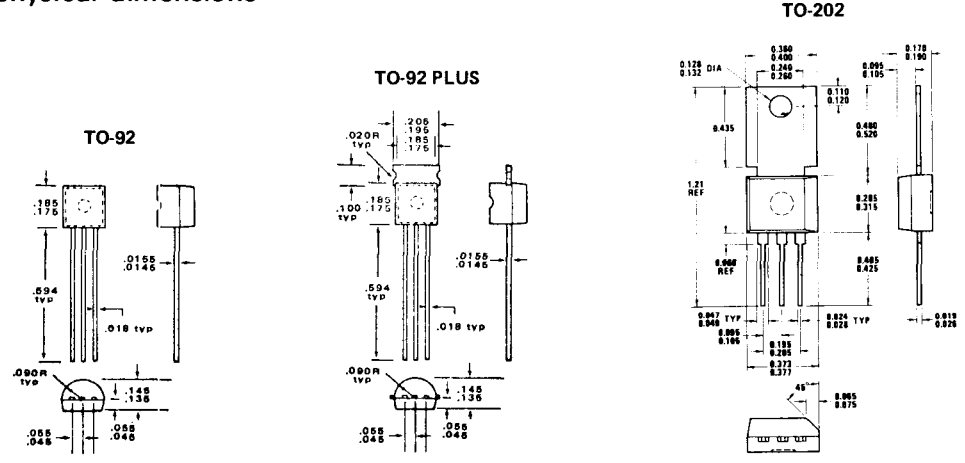
3 ordering information



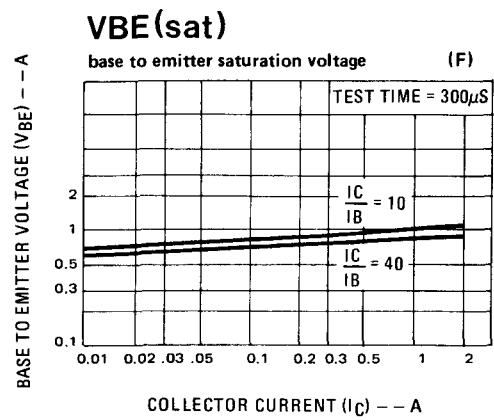
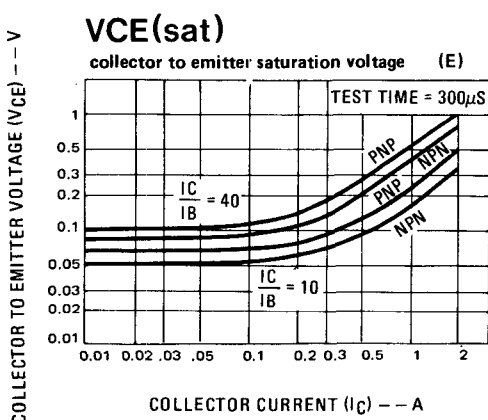
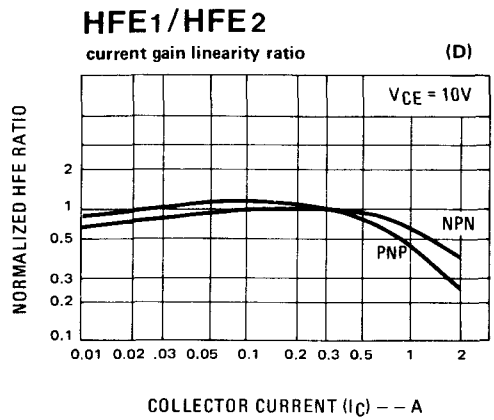
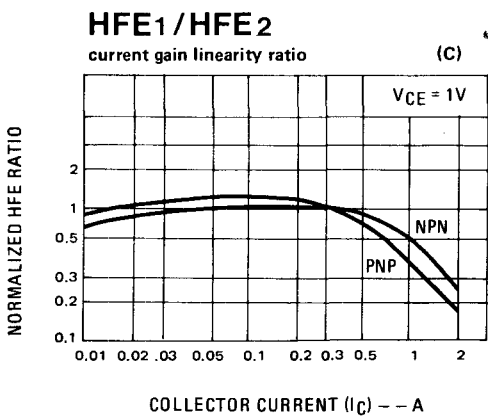
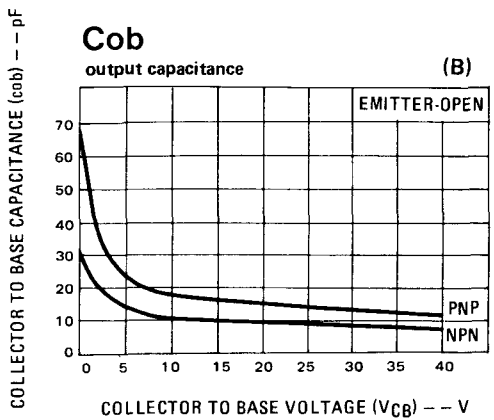
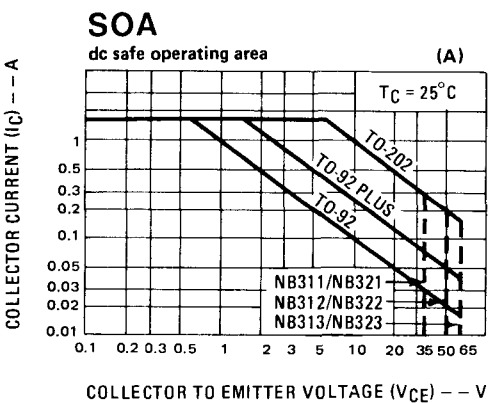
4 electrical characteristics $T_C = 25^{\circ}\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------|---|---|----------------|----------|-------------------|---|
| V_{CEO} | Collector-Emitter Sustaining Voltage NB311/321 NB312/322 NB313/323 | $I_C = 1 \text{ mA}$ | 35 50 65 | | | V V V |
| V_{CBO} | Collector-Base Breakdown Voltage NB311/321 NB312/322 NB313/323 | $I_C = 100 \mu\text{A}$ | 40 55 70 | | | V V V |
| V_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu\text{A}$ | 6 | | | V |
| I_{CEO} | Collector-Emitter Leakage Current | $V_{CE} = 30\text{V NB311/321}$ 45V NB312/322 60V NB313/323 | | | 50 50 50 | μA μA μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 35\text{V NB311/321}$ 50V NB312/322 65V NB313/323 | | | 0.5 0.5 0.5 | μA μA μA |
| I_{EBO} | Emitter-Base Leakage Current | $V_{EB} = 5\text{V}$ | | | 0.5 | μA |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C = 300 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.9 | 1 | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 300 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.15 | 0.5 | V |
| HFE_1 | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 10\text{V}$ | 30 | | | |
| HFE_2 | DC Current Gain | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | | | |
| C_{ob} | Collector Output Capacitance NPN types PNP types | $V_{CB} = 10\text{V}, f = 1 \text{ MHz}$ | | 10 17 | | pF pF |
| f_t | Current Gain Bandwidth Product | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}$ | 20 | | | MHz |

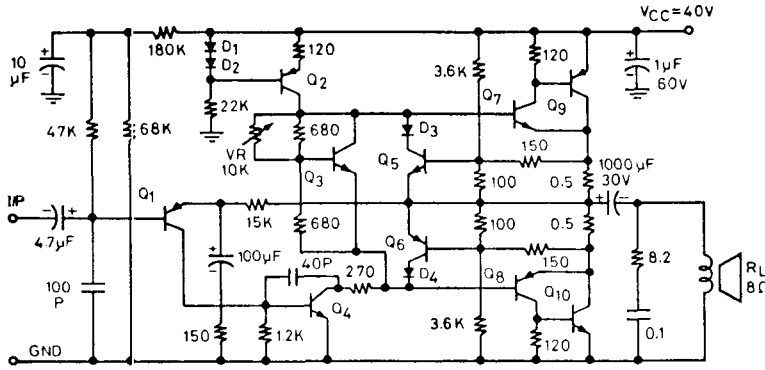
5 physical dimensions



6 typical performance characteristics

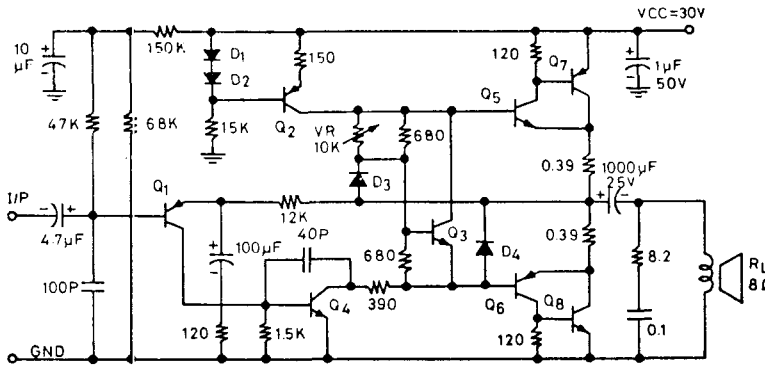


7 typical applications



- Q1 NB022EY
- Q2 NB123EY
- Q3 NR001E
- Q4 NB113EY
- Q5 NB111EY
- Q6 NB121EY
- Q7 NB313Y
- Q8 NB323Y
- Q9 NA72W
- Q10 NA71W

Figure A. 25 Watt OTL Amplifier



- Q1 NB021EY
- Q2 NB122EY
- Q3 NR001E
- Q4 NB112EY
- Q5 NB312E
- Q6 NB322E
- Q7 NA52W
- Q8 NA51W

Figure B. 12 Watt OTL Amplifier

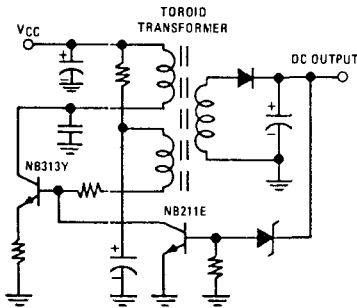


Figure C. Typical Converter Circuit

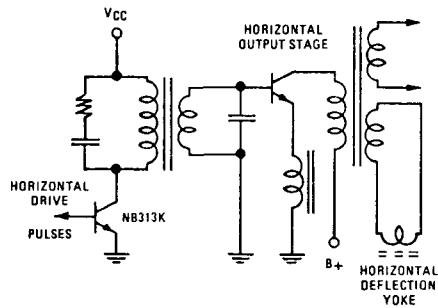


Figure D. Typical TV Horizontal Driver Application

NR421(NPN) VHF amplifier/FM converter transistor

features

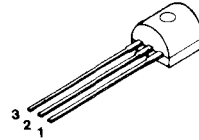
- 0.65pF typical feedback capacitance for excellent RF stability
- Guaranteed collector-base time constant and RF output resistance
- 150mV typical $V_{CE(sat)}$ characteristics at $I_C = 10$ mA, and $I_B = 0.5$ mA
- 2 dB typical noise figure at 200 MHz
- "Epoxy B" packaging concept for excellent reliability

applications

- VHF RF amplifiers/converters
- CB radios
- Low-power RF oscillators

1 package and lead coding

TO-92

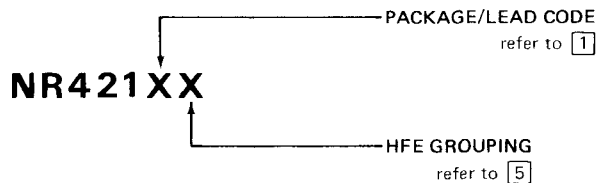


| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| D | B | E | C |
| F | E | C | B |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|----------------|--------------|--------------|
| Collector-Emitter Voltage | V_{CEO} | 30 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 35 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 3 | V_{DC} |
| Collector Current (continuous) | $I_C (max)$ | 30 | mA_{DC} |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | 1.0 | W |
| Thermal Resistance | θ_{JA} | 208 | $^\circ C/W$ |
| | θ_{JC} | 125 | $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | $^\circ C$ |

3 ordering information



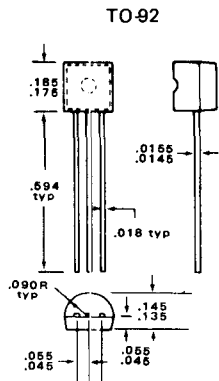
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|---|-----|------|-----|---------------|
| BV_{CE0} | Collector-Emitter Sustaining Voltage | $I_C = 1\text{ mA}$ | 30 | | | V |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 100\mu\text{A}$ | 35 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\mu\text{A}$ | 3 | 5.5 | | V |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 30\text{V}$ | | | 0.1 | μA |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 10\text{ mA}, I_B = 0.5\text{ mA}$ | | 830 | 950 | mV |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 10\text{ mA}, I_B = 0.5\text{ mA}$ | | 150 | 300 | mV |
| C_{cb} | Common Emitter Collector Feedback Capacitance | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | 0.65 | 0.9 | pF |
| C_{ob} | Collector Output Capacitance | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | 0.9 | 1.3 | pF |
| rb'/C_c | Collector Base Time Constant | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | | 8 | 20 | pS |
| R_{oep} | Common Emitter Output Resistance | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ $f = 200\text{ MHz}$ | 5 | | | KOhm |
| f_t | Current Gain Bandwidth Product | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 450 | 700 | | MHz |

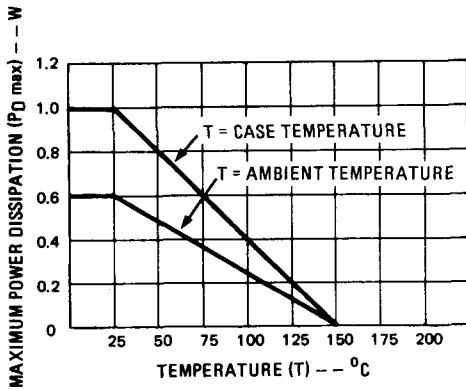
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|---|-----|-----|-----|-------|
| E | DC Current Gain | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 30 | 38 | 50 | 1:1.6 |
| F | DC Current Gain | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 45 | 58 | 75 | 1:1.6 |
| G | DC Current Gain | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 100 | 127 | 160 | 1:1.6 |
| R | DC Current Gain | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 20 | 32 | 50 | 1:2.4 |
| S | DC Current Gain | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 45 | 70 | 110 | 1:2.4 |
| T | DC Current Gain | $I_C = 2\text{ mA}, V_{CE} = 5\text{V}$ | 100 | 150 | 240 | 1:2.4 |

6 physical dimensions

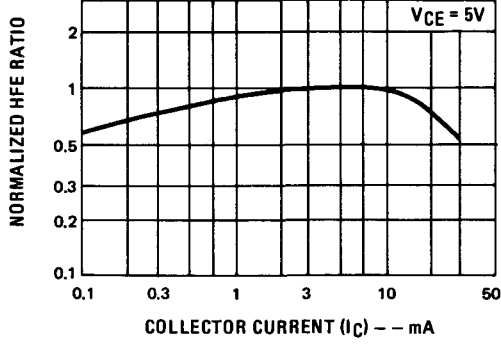


7 max power dissipation

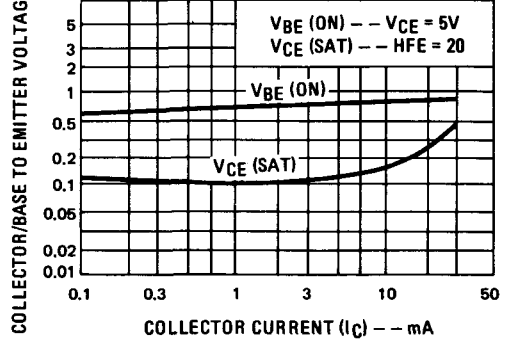


8 typical performance characteristics

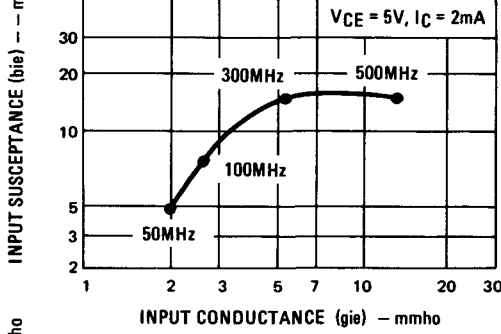
HFE1/HFE2
current linearity ratio (A)



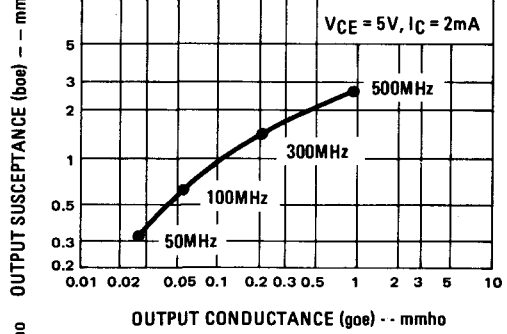
VCE(sat)/VBE(on)
collector/base to emitter voltage (B)



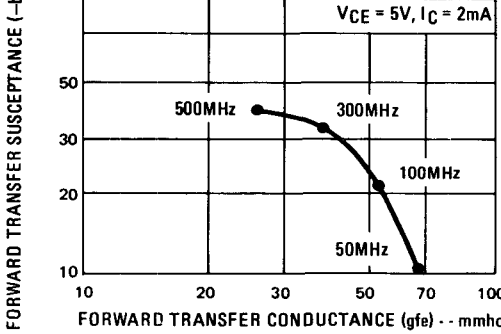
Yie
common emitter input admittance (C)



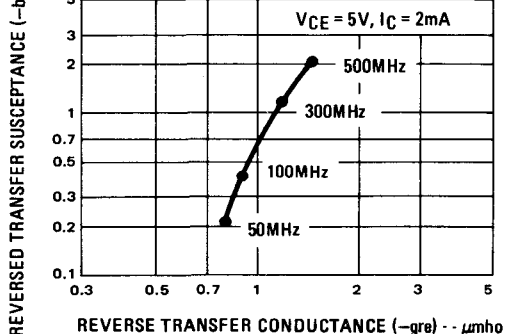
Yoe
common emitter output admittance (D)



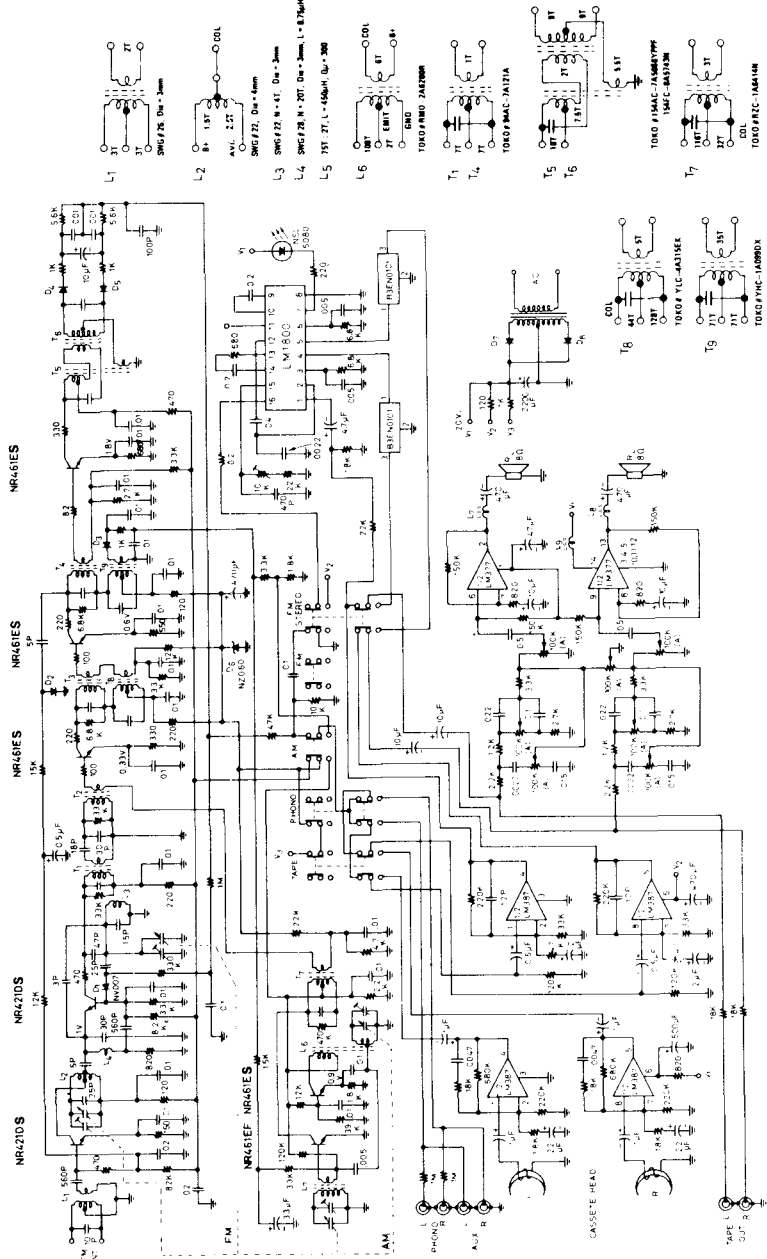
Yfe
common emitter forward transfer admittance (E)



Yre
common emitter reverse transfer admittance (F)



9 typical applications



AUDIO performance

AM performance (525-1650 KHz)

FM performance (88-108 MHz)

- 10% THD output power: 3W + 3W
- frequency response: 50Hz - 15KHz
- channel separation: 45dB
- tone control range: ±10dB
- typical system dist: 0.5%

- maximum sensitivity: 100μV/M
- 20dB quieting sensitivity: 280μV/M
- selectivity ±10KHz: -28dB
- AGC figure of merit: 52dB
- overload distortion: 3%

- 30dB quieting sensitivity: 2μV
- limiting sensitivity: 7μV
- AM rejection: 40dB
- AFC holding range: 800KHz
- stereo separation: 40dB

Figure A. AM/FM/Cassette Home Stereo Circuit

NR431(NPN)HF amplifier/FM converter transistor

features

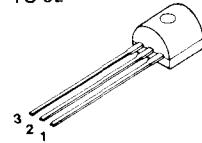
- 1.1pF typical collector feedback capacitance
- 5K Ohm minimum RF output resistance at 100 MHz
- 150mV typical V_{CE} (sat) characteristics at
 $I_C = 10$ mA, and $I_B = 0.5$ mA
- "Epoxy B" packaging concept for excellent reliability

applications

- High frequency amplifiers/converters
- CB radios
- Low power RF oscillators

1 package and lead coding

TO-92

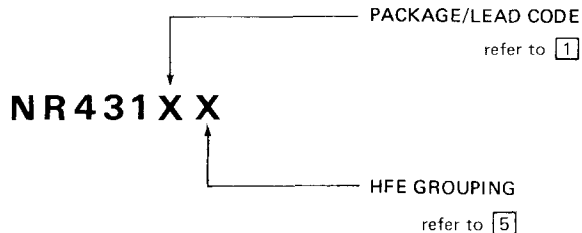


| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|----------------|-------------|--------------|
| Collector-Emitter Voltage | V_{CEO} | 15 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 18 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 3 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 30 | mA_{DC} |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | 1.0 | W |
| Thermal Resistance | θ_{JA} | 208 | $^\circ C/W$ |
| | θ_{JC} | 125 | $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to +150 | $^\circ C$ |

3 ordering information



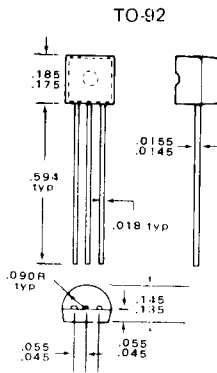
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|---|-----|-----|-----|---------------|
| BV_{CEO} | Collector-Emitter Sustaining Voltage | $I_C = 1\text{ mA}$ | 15 | | | V |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 100\mu\text{A}$ | 18 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10\mu\text{A}$ | 3 | 5.6 | | V |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 15\text{V}$ | | | 0.1 | μA |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 10\text{ mA}, I_B = 0.5\text{ mA}$ | | 830 | 950 | mV |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 10\text{ mA}, I_B = 0.5\text{ mA}$ | | 150 | 300 | mV |
| C_{cb} | Common Emitter Collector Feedback Capacitance | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | 1.1 | 1.4 | pF |
| C_{ob} | Collector Output Capacitance | $V_{CB} = 10\text{V}, f = 1\text{ MHz}$ | | 1.4 | 1.7 | pF |
| R_{oep} | Common Emitter Output Resistance | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ $f = 100\text{ MHz}$ | 5 | | | KOhm |
| f_t | Current Gain Bandwidth Product | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 350 | 600 | | MHz |

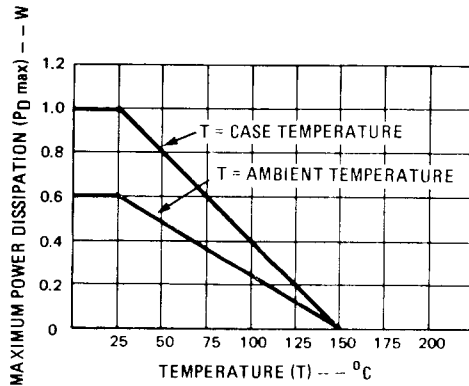
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|---|-----|-----|-----|-------|
| E | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 30 | 38 | 50 | 1:1.6 |
| F | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 45 | 58 | 75 | 1:1.6 |
| G | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 68 | 85 | 110 | 1:1.6 |
| R | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 20 | 32 | 50 | 1:2.4 |
| S | DC Current Gain | $I_C = 1\text{ mA}, V_{CE} = 5\text{V}$ | 45 | 70 | 110 | 1:2.4 |

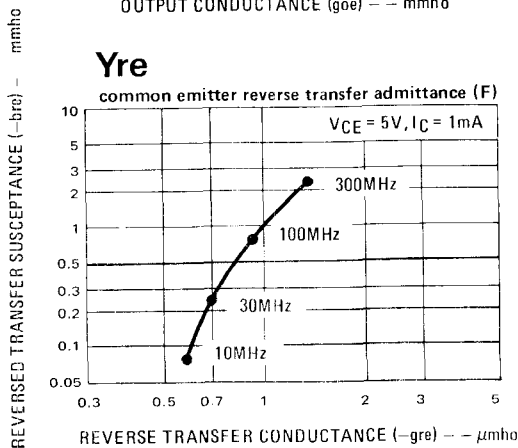
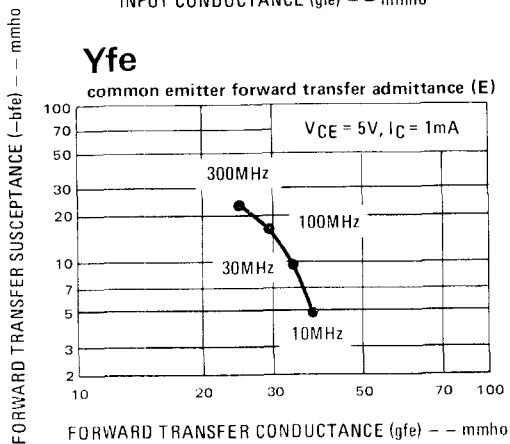
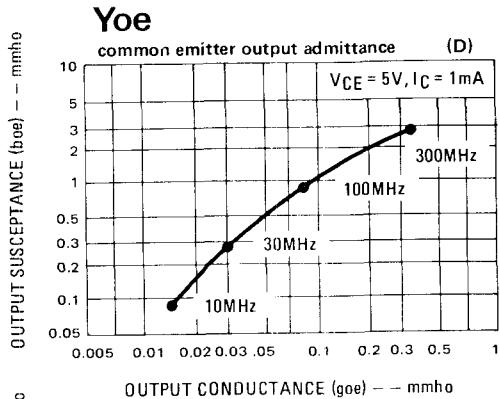
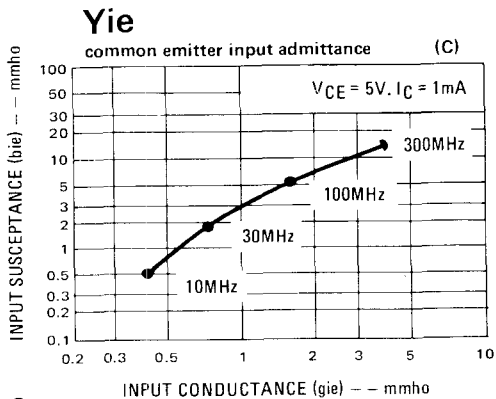
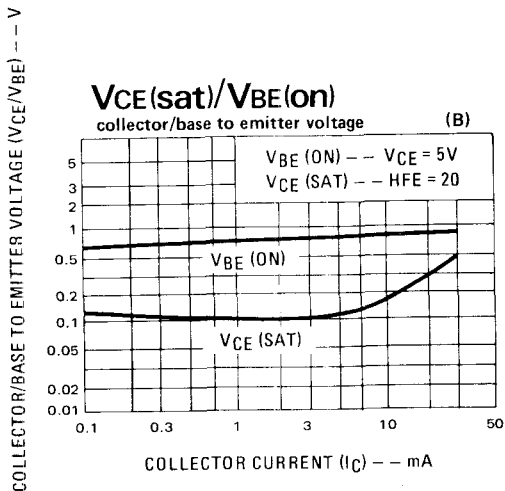
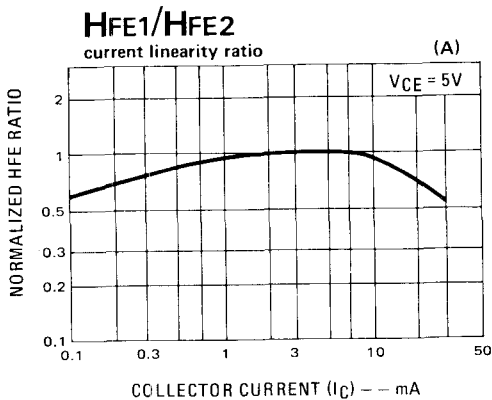
6 physical dimensions

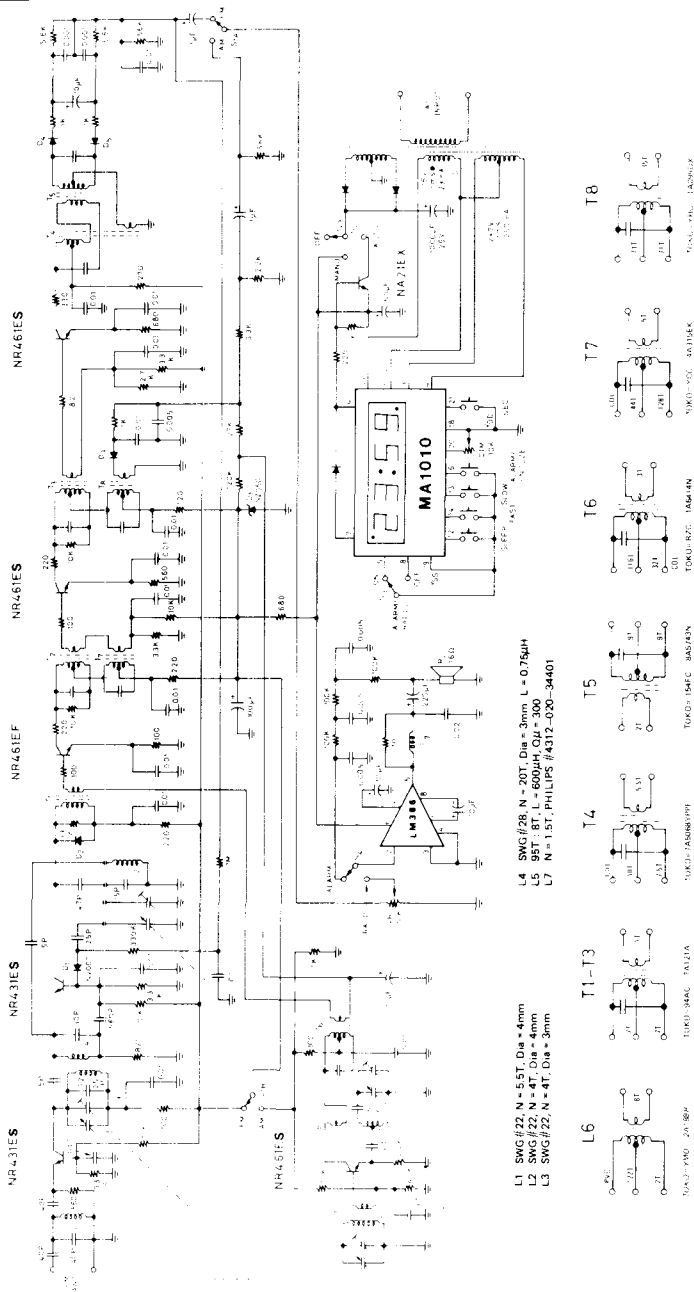


7 max power dissipation



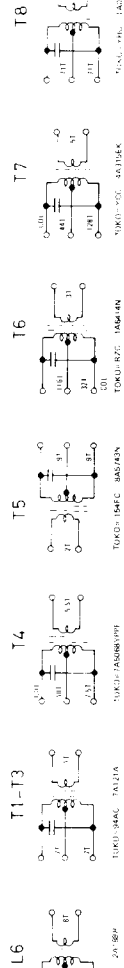
8 typical performance characteristics





L4 SWG #28, N = 20T, Dia = 3mm, L = 0.75µH
 L5 95T #8T, L = 600µH, QJ = 300
 L7 N = 15T, PHILIPS #4312-020-34401

L1 SWG #22, N = 55T, Dia = 4mm
 L2 SWG #22, N = 4T, Dia = 4mm
 L3 SWG #22, N = 4T, Dia = 3mm



- | | | |
|--|--|---|
| FM performance (88-108 MHz) | AM performance (525-1650 KHz) | AUDIO performance |
| <ul style="list-style-type: none"> ● 30dB quieting sensitivity: 5µV ● limiting sensitivity: 20µV ● AM rejection: 40dB ● AFC holding range: 800KHz ● Bandwidth: 180KHz | <ul style="list-style-type: none"> ● maximum sensitivity: 100µV/M ● 20dB quieting sensitivity: 280µV/M ● selectivity ± 10KHz: -28dB ● AGC figure of merit: 40dB ● overload distortion: 6% | <ul style="list-style-type: none"> ● gain at 1 KHz: 200 ● 10% THD output power: 900mW ● frequency response: 70Hz - 12KHz ● typical system dist: 0.8% ● alarm tone frequency: 600Hz |

Figure A. AM/FM clock radio

NR461(NPN) low-noise RF/IF transistor

features

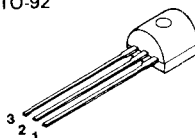
- Low C_{cb} for excellent RF stability
- High R_{oop} for simplified RF coupling designs
- 70mV typical V_{CE} (sat) characteristics at $I_C = 10$ mA, and $I_B = 0.5$ mA
- 1.1 dB typical noise figure at 1 MHz
- "Epoxy B" packaging concept for excellent reliability

applications

- MW/SW/CB radios
- 0.1 to 50 MHz frequency converters
- 455KHz to 10.7 MHz IF stages
- Low-power RF oscillators

1 package and lead coding

TO-92

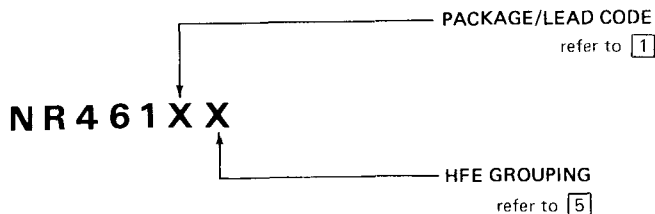


| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|----------------|--------------|--------------|
| Collector-Emitter Voltage | V_{CEO} | 30 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 35 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 4 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 30 | mA_{DC} |
| Power Dissipation ($T_A = 25^\circ C$) | P_D | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ C$) | P_D | 1.0 | W |
| Thermal Resistance | θ_{JA} | 208 | $^\circ C/W$ |
| | θ_{JC} | 125 | $^\circ C/W$ |
| Temperature, Junction and Storage | T_j, T_{stg} | -55 to + 150 | $^\circ C$ |

3 ordering information



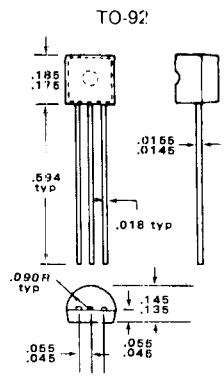
4 electrical characteristics $T_C = 25^\circ C$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|---|--|-----------|-----|-----|--------------|
| V_{CE0} | Collector-Emitter Sustaining Voltage | $I_C = 1 \text{ mA}$ | 30 | | | V |
| V_{CB0} | Collector-Base Breakdown Voltage | $I_C = 100\mu A$ | 35 | | | V |
| V_{EB0} | Emitter-Base Breakdown Voltage | $I_E = 10\mu A$ | 4 | 5.5 | | V |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 30V$ | | | 0.1 | μA |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | | 760 | 950 | mV |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | | 70 | 300 | mV |
| C_{cb} | Common Emitter Collector Feedback Capacitance | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 0.9 | 1.1 | pF |
| R_{op} | Common Emitter Output Resistance | $I_C = 1 \text{ mA}, V_{CE} = 5V$ $f = 455 \text{ KHz}$ $f = 10.7 \text{ MHz}$ | 100 20 | | | KOhm KOhm |
| f_t | Current Gain Bandwidth Product | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 180 | 300 | | MHz |

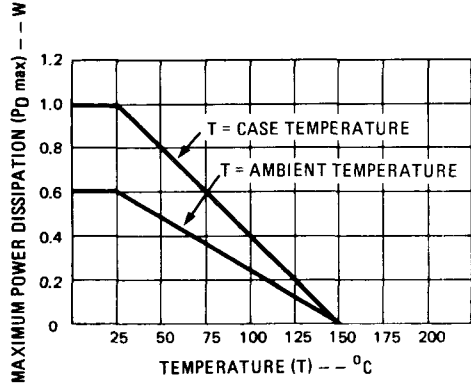
5 HFE groupings

| GROUPING | PARAMETER | CONDITIONS | MIN | TYP | MAX | RATIO |
|----------|-----------------|-----------------------------------|-----|-----|-----|-------|
| E | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 30 | 38 | 50 | 1:1.6 |
| F | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 45 | 58 | 75 | 1:1.6 |
| G | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 68 | 85 | 110 | 1:1.6 |
| H | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 100 | 127 | 160 | 1:1.6 |
| R | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 20 | 32 | 50 | 1:2.4 |
| S | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 45 | 70 | 110 | 1:2.4 |
| T | DC Current Gain | $I_C = 1 \text{ mA}, V_{CE} = 5V$ | 100 | 150 | 240 | 1:2.4 |

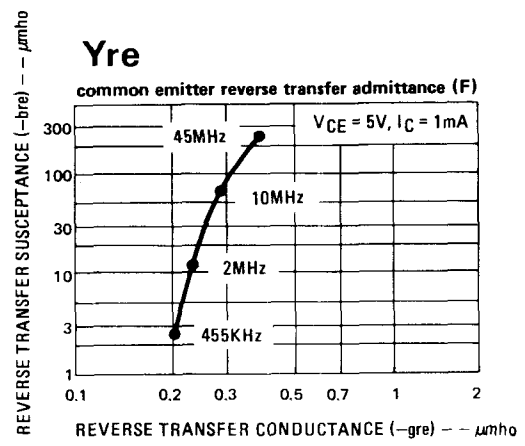
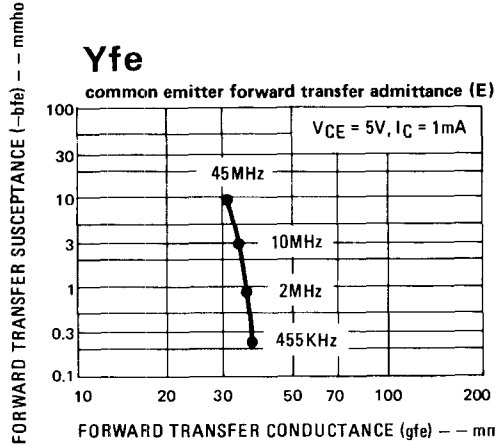
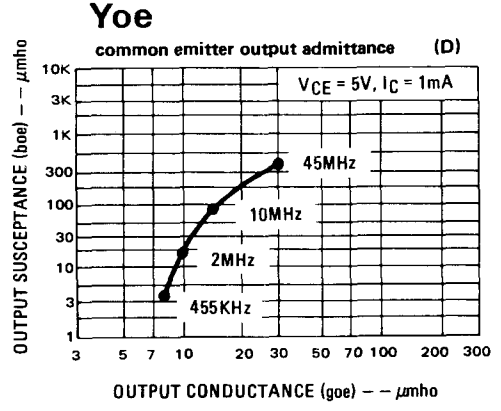
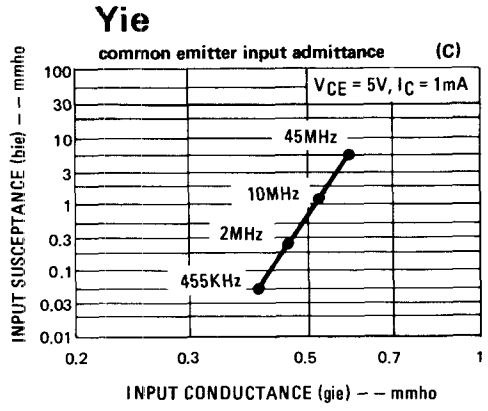
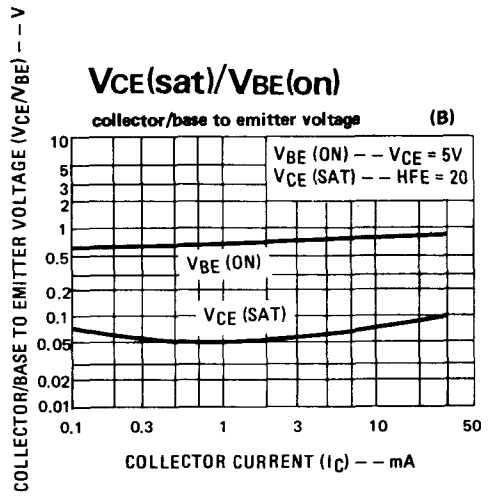
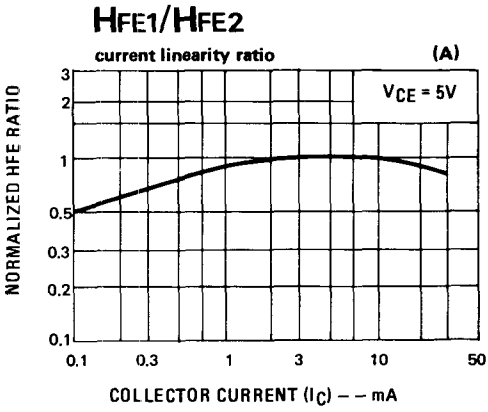
6 physical dimensions



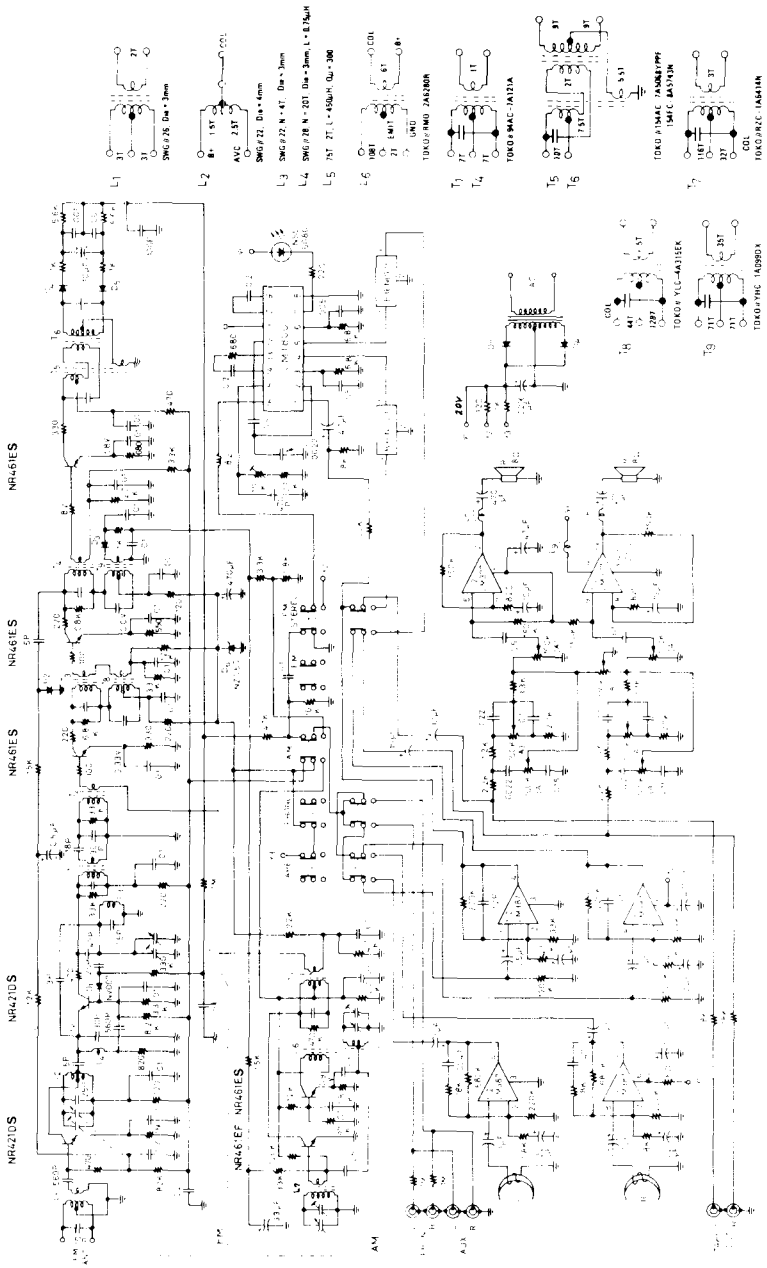
7 max power dissipation



8 typical performance characteristics



9 typical applications



- FM performance (88—108 MHz)**
- 30dB quieting sensitivity 2µV
 - limiting sensitivity: 7µV
 - AM rejection: 40dB
 - AFC holding range: 800KHz
 - stereo separation: 40dB

- AM performance (525—1650 KHz)**
- maximum sensitivity: 100µV/M
 - 20dB quieting sensitivity: 280µV/M
 - selectivity ±10KHz: -28dB
 - AGC figure of merit: 52dB
 - overload distortion: 3%

- AUDIO performance**
- 10% THD output power: 3W + 3W
 - frequency response: 50Hz — 15KHz
 - channel separation: 45dB
 - tone control range: ±10dB
 - typical system dist.: 0.5%

Figure A. AM/FM/Cassette Home Stereo Circuit

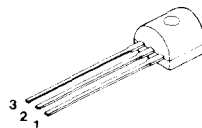
NR041 (NPN) low-level signal switching transistor

features

- 40mV guaranteed V_{CE} (sat) characteristics at $I_C = 1\text{mA}$ and $I_B = 0.1\text{mA}$
- Linear collector characteristics
- 1dB typical wide-band Noise Figure
- "Epoxy B" packaging concept for excellent reliability

1 package and lead coding

TO-92



applications

- ALC device for CB microphone circuits
- Cassette circuits
- Audio signal switches
- Envelope modulators for musical equipment

| PACKAGE CODE TO-92 | LEAD | | |
|-----------------------|------|---|---|
| | 1 | 2 | 3 |
| E | E | B | C |
| F | E | C | B |
| H | C | B | E |

2 maximum ratings

| PARAMETER | SYMBOL | RATING | UNIT |
|--|----------------|--------------|--------------------|
| Collector-Emitter Voltage | V_{CEO} | 20 | V_{DC} |
| Collector-Base Voltage | V_{CB} | 20 | V_{DC} |
| Emitter-Base Voltage | V_{EB} | 5 | V_{DC} |
| Collector Current (continuous) | I_C (max) | 30 | mA_{DC} |
| Power Dissipation ($T_A = 25^\circ\text{C}$) | P_D | 0.6 | W |
| Power Dissipation ($T_C = 25^\circ\text{C}$) | P_D | 1.0 | W |
| Thermal Resistance | θ_{JA} | 208 | $^\circ\text{C/W}$ |
| | θ_{JC} | 125 | $^\circ\text{C/W}$ |
| Temperature, Junction and Storage | T_j, T_{stg} | - 55 to +150 | $^\circ\text{C}$ |

3 ordering information

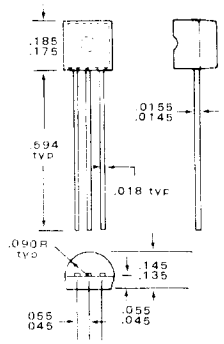
NR041X

PACKAGE/LEAD CODE
refer to 1

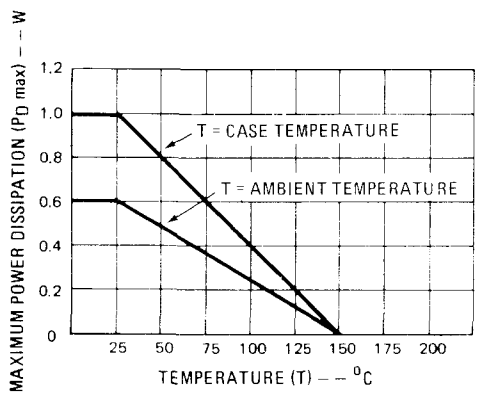
4 electrical characteristics $T_C = 25^\circ\text{C}$

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------|--------------------------------------|---|-----|------|-----|---------------|
| BV_{CEO} | Collector-Emitter Sustaining Voltage | $I_C = 1 \text{ mA}$ | 20 | | | V |
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 100 \mu\text{A}$ | 20 | | | V |
| BV_{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu\text{A}$ | 5 | | | V |
| I_{CEO} | Collector-Emitter Leakage Current | $V_{CE} = 15\text{V}$ | | | 1 | μA |
| I_{CBO} | Collector-Base Leakage Current | $V_{CB} = 15\text{V}$ | | | 50 | nA |
| I_{EBO} | Emitter-Base Leakage Current | $V_{EB} = 4\text{V}$ | | | 0.1 | μA |
| $V_{BE}(\text{sat})$ | Base-Emitter Saturation Voltage | $I_C = 1 \text{ mA}, I_B = 0.1 \text{ mA}$ | | 0.65 | 0.8 | V |
| $V_{CE}(\text{sat})$ | Collector-Emitter Saturation Voltage | $I_C = 1 \text{ mA}, I_B = 0.1 \text{ mA}$ | | 25 | 40 | mV |
| C_{ob} | Collector Output Capacitance | $V_{CB} = 10\text{V}, f = 1 \text{ MHz}$ | | 2 | | pF |
| NF | Noise Figure | $I_C = 10 \mu\text{A}, V_{CE} = 5\text{V}$ $R_S = 10\text{K}, BW = 15.7 \text{ KHz}$ | | 1 | | dB |

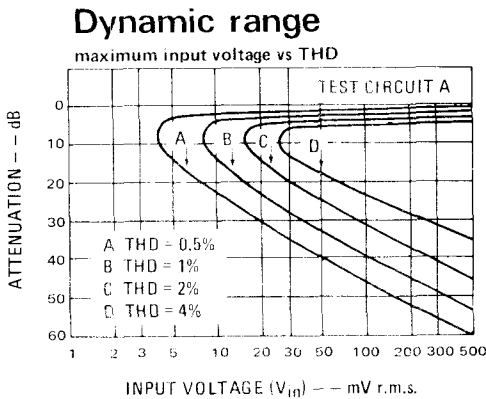
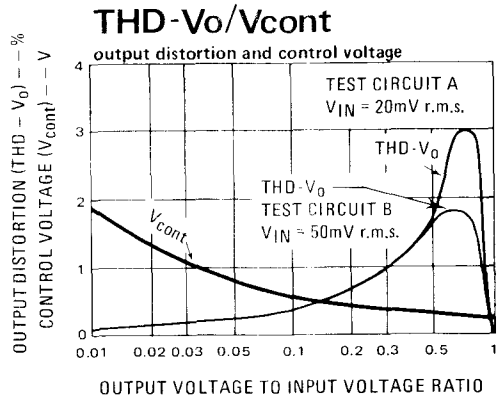
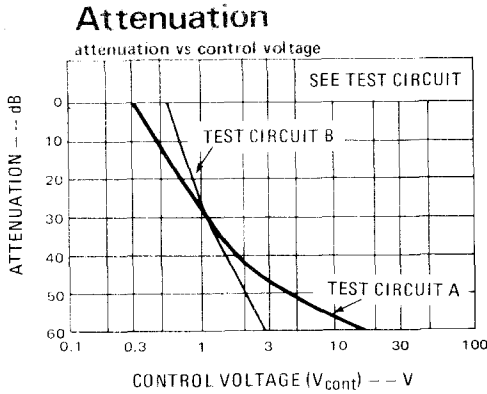
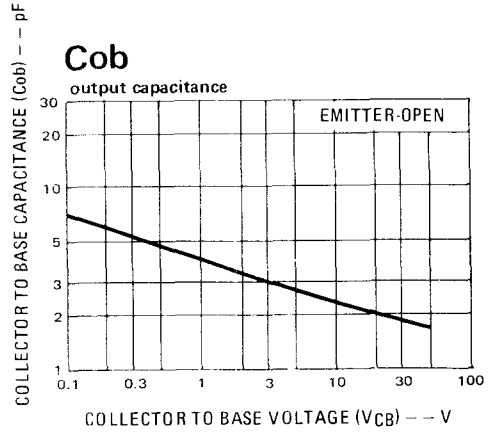
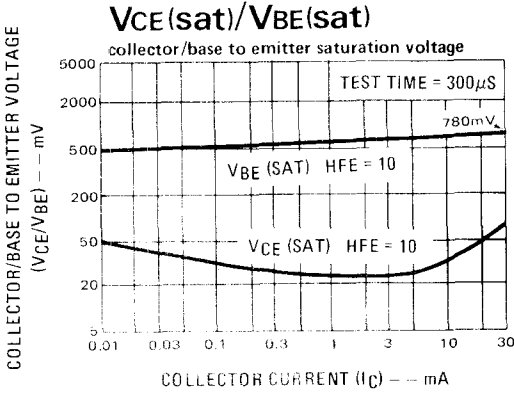
5 physical dimensions



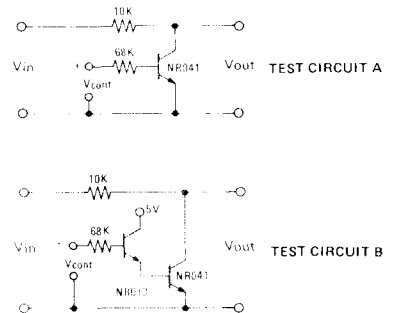
6 max power dissipation



7 typical performance characteristics



Test circuits



NOTE: ATTENUATION = $20 \log_{10} \frac{V_{out}}{V_{in}}$

8 typical applications

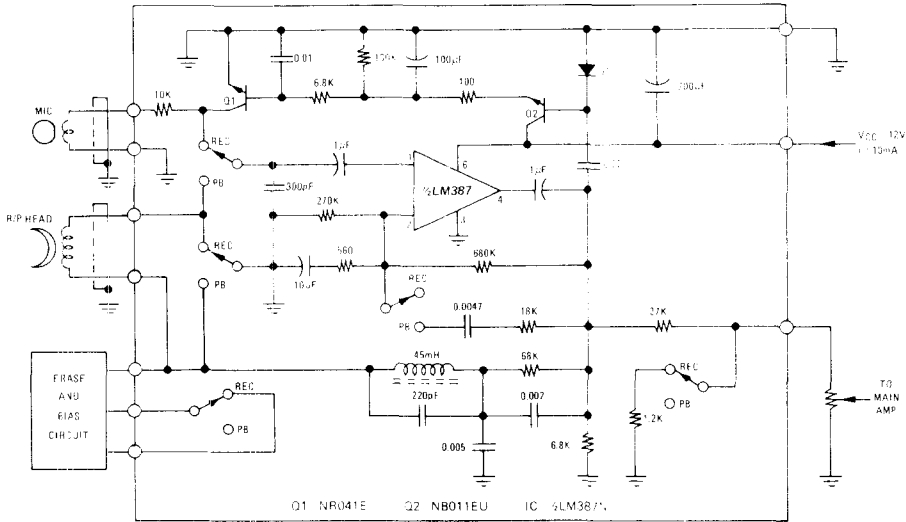


Figure A. 60dB ALC Range Record/Playback Preamplifier

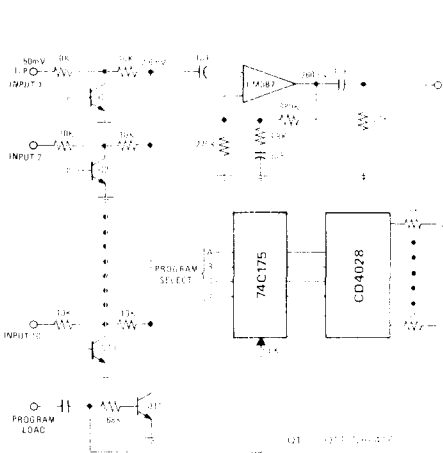


Figure B. 10 Channel Program Selector

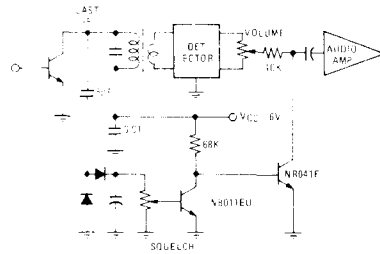


Figure C. Squelch Circuit

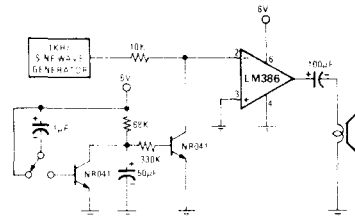


Figure D. Ringing Tone Generator





Section 6
Process
Characteristics
Double-Diffused
Epitaxial Transistors

6

DESCRIPTION

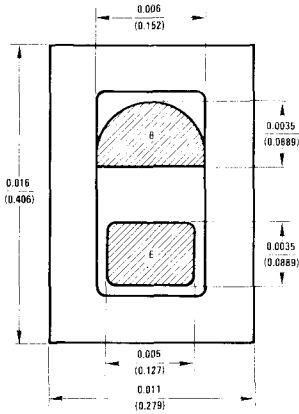
Process 02 is a non-overlay double diffused, silicon device.

APPLICATION

An economical device, good for all-around applications from DC to low radio frequencies. Ideal for use in audio, radio and television applications.

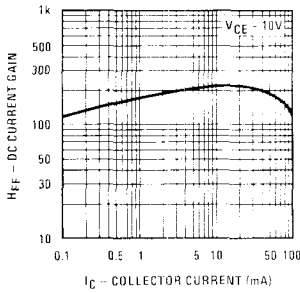
PRINCIPAL DEVICE TYPES

TO-92: MPS-A20
MPS-6573-6

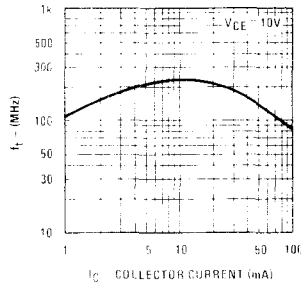


| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|--|-----|-----|------|-------|
| BV_{CEO} | $I_C = 1 \text{ mA}, I_B = 0$ | 40 | | | V |
| BV_{EBO} | $I_E = 100 \mu\text{A}, I_C = 0$ | 4.0 | | | V |
| I_{CBO} | $V_{CB} = 30\text{V}, I_E = 0$ | | 100 | | nA |
| H_{FE} | $I_C = 5 \text{ mA}, V_{CE} = 10\text{V}$ | 40 | 400 | | |
| $V_{BE(ON)}$ | $I_C = 5 \text{ mA}, V_{CE} = 10\text{V}$ | | | 0.85 | V |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | | 0.25 | V |
| f_t | $I_C = 5 \text{ mA}, V_{CE} = 10\text{V}, f = 100 \text{ MHz}$ | 125 | | | MHz |
| C_{ob} | $V_{CB} = 10\text{V}, I_E = 0, f = 100 \text{ kHz}$ | | | 4.0 | pF |

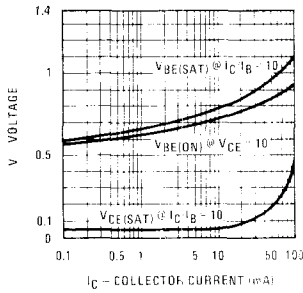
DC Current Gain vs Collector Current



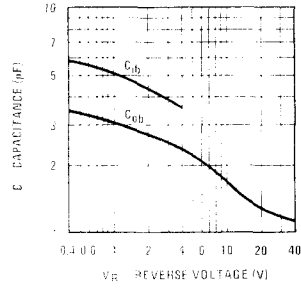
Bandwidth Product vs Collector Current



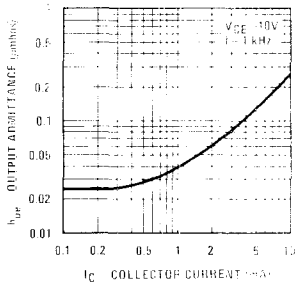
Saturation and ON Voltages



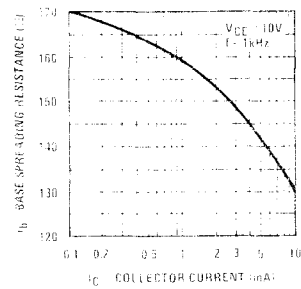
Capacitance vs Reverse Voltage

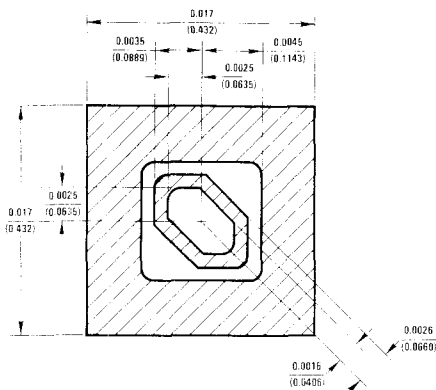


Output Admittance vs Collector Current



Base Spreading Resistance vs Collector Current





DESCRIPTION

Process 04 is a non-overlay double diffused silicon epitaxial device. Complement to Process 71.

APPLICATION

This device was designed for low noise, high gain, general purpose amplifier application. From 1 μ A to 100 mA collector current.

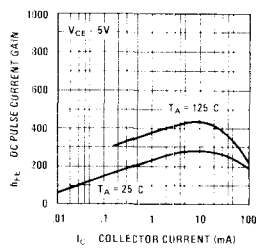
PRINCIPAL DEVICE TYPES

- TO-18 BC107 Series
- TO-92 (ECB) 2N2923 Series
- TO-92 (EBC) MPS2923 Series

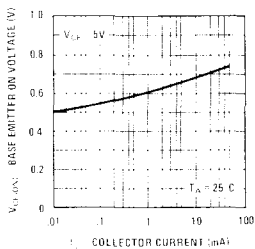
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|-------|-------|-------|-------|
| NF (spot) | $I_C = 200 \mu A, V_{CE} = 5V$ $f = 1 \text{ kHz}, R_S = 2k$ | | 2.0 | 4.0 | dB | TO-18 |
| C_{ob} | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 3.2 | 3.5 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.5V, f = 1 \text{ MHz}$ | | 7.6 | 8.5 | pF | TO-18 |
| f_T | $V_{CE} = 5V, I_C = 10 \text{ mA}$ | 150 | 350 | | MHz | |
| h_{FE} | $V_{CE} = 5V, I_C = 100 \mu A$ | 50 | 250 | 500 | | |
| h_{FE} | $V_{CE} = 5V, I_C = 2 \text{ mA}$ | 50 | 250 | 750 | | |
| h_{FE} | $V_{CE} = 5V, I_C = 100 \text{ mA}$ | 75 | 250 | 300 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 100 \text{ mA}$ | 30 | 100 | 150 | | |
| $V_{CE(sat)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.040 | 0.080 | V | |
| $V_{CE(sat)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.120 | 0.180 | V | |
| $V_{BE(sat)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.75 | 0.85 | V | |
| $V_{BE(sat)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.89 | 0.95 | V | |
| BV_{CBO} | $I_C = 10 \mu A$ | 50 | 40 | 120 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 20 | 45 | 55 | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 7.0 | | | V | |
| I_{CBO} | $V_{CB} = 40V$ | | | 10 | NA | |
| I_{EBO} | $V_{EB} = 4V$ | | | 10 | NA | |

Process 04

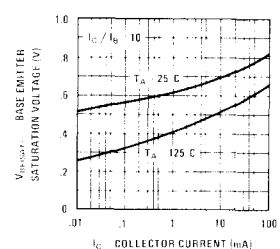
Pulsed DC Current Gain vs Collector Current



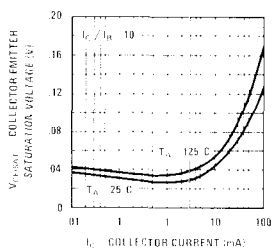
Base-Emitter On Voltage vs Collector Current



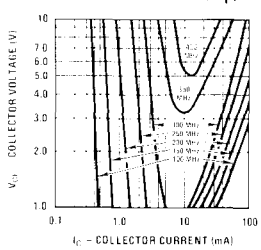
Base-Emitter Saturation Voltage vs Collector Current



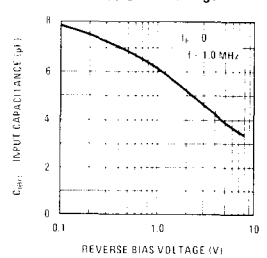
Collector-Emitter Saturation Voltage vs Collector Current



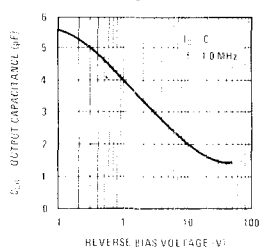
Contours of Constant Gain Bandwidth Product (FT)



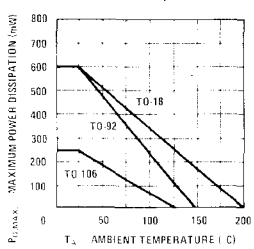
Input Capacitance vs Reverse Bias Voltage



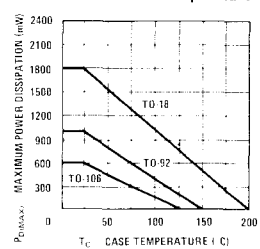
Output Capacitance vs Reverse Bias Voltage



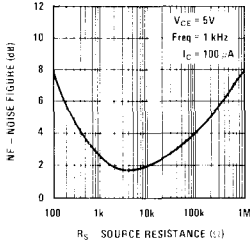
Maximum Power Dissipation vs Ambient Temperature



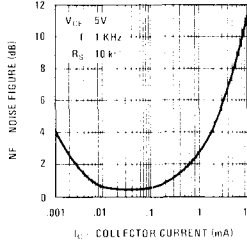
Maximum Power Dissipation vs Case Temperature



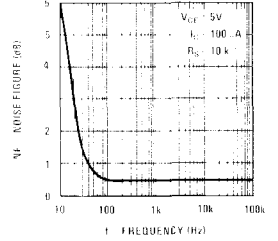
Noise Figure vs Source Resistance



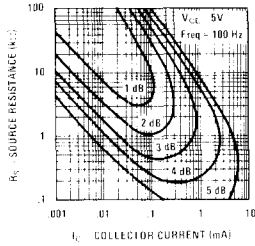
Noise Figure vs Collector Current



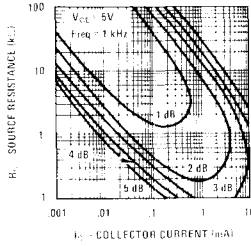
Noise Figure vs Frequency



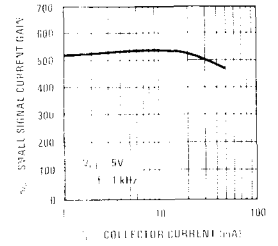
Contours of Constant Narrow Band Noise Figure



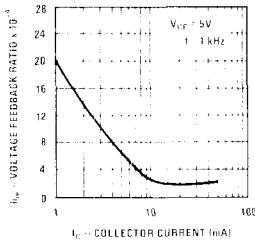
Contours of Constant Narrow Band Noise Figure



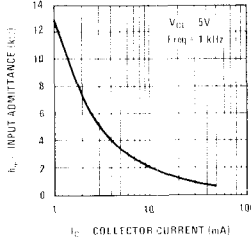
Small Signal Current Gain



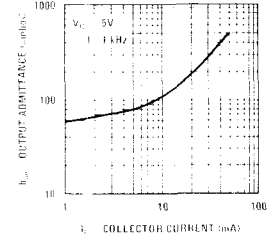
Voltage Feedback Ratio

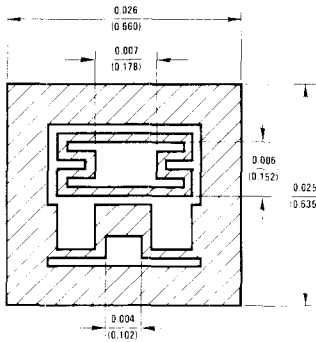


Input Admittance



Output Admittance




DESCRIPTION

Process 05 is a monolithic double diffused, silicon epitaxial Darlington.

APPLICATION

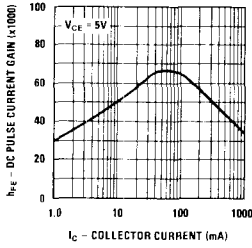
This device is designed for applications requiring extremely high current gain at collector currents to 1 Amp.

PRINCIPAL DEVICE TYPES

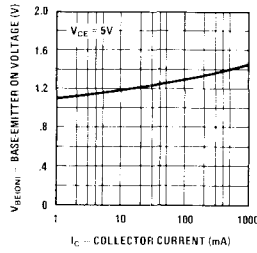
TO-92, MPS-A12 (EBC), 2N5306 (ECB)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|----------------|-------------------|--------------------|-------|-------|
| NF | $I_C = 1 \text{ mA}$, $V_{CE} = 5\text{V}$, $R_S = 100 \text{ k}$, $f = 1 \text{ kHz}$ | | 2 | | dB | |
| C_{cb} | $V_{CB} = 10\text{V}$, $I_E = 0$, $f = 1 \text{ MHz}$ | | 4 | 8 | pF | |
| h_{FE} | $I_C = 10 \text{ mA}$, $V_{CE} = 5\text{V}$ $I_C = 100 \text{ mA}$, $V_{CE} = 5\text{V}$ | 5,000 5,000 | 50,000 100,000 | 200,000 250,000 | | |
| $V_{CE(SAT)}$ | 10 mA, 0.01 mA 100 mA, 0.1 mA | | | 1.0 1.5 | V | |
| $V_{BE(ON)}$ | 10 mA, 5V 100 mA, 5V | | 1.2 1.25 | 1.4 2.0 | V | |
| h_{FE} | $I_C = 10 \text{ mA}$, $V_{CE} = 5.0\text{V}$, $f = 1 \text{ kHz}$ | | 80,000 | | | |
| BV_{CES} | $I_C = 100 \mu\text{A}$ | 30 | 40 | 50 | V | |
| I_{CES} | $V_{CE} = 15\text{V}$, $V_{BE} = 0$ | | | 100 | nA | |
| I_{CBO} | $V_{CB} = 15\text{V}$, $I_E = 0$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 10\text{V}$, $I_C = 0$ | | | 100 | nA | |

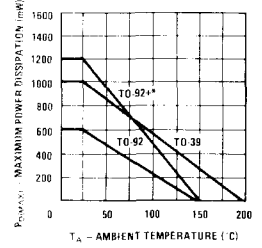
DC Pulse Current Gain vs Collector Current



Base-Emitter On Voltage vs Collector Current

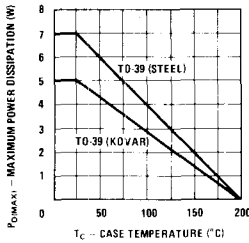


Maximum Power Dissipation vs Ambient Temperature

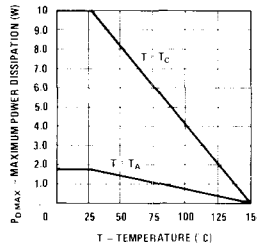


* One square inch of copper run

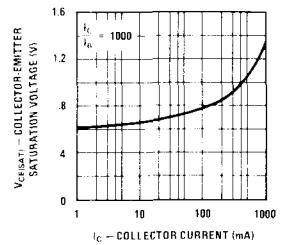
Maximum Power Dissipation vs Case Temperature



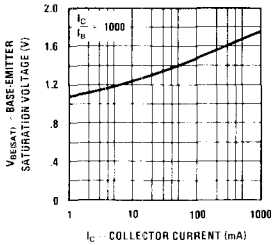
Maximum Power Dissipation TO-202 vs Case and Ambient Temperature



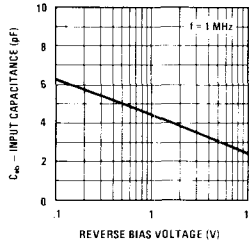
Collector-Emitter Saturation Voltage vs Collector Current



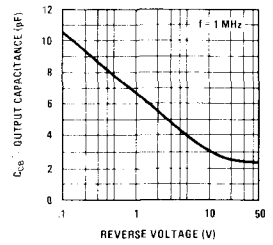
Base-Emitter Saturation Voltage vs Collector Current



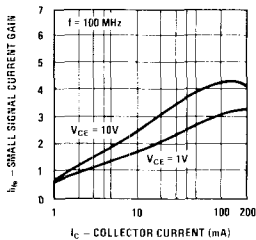
Input Capacitance vs Reverse Bias Voltage



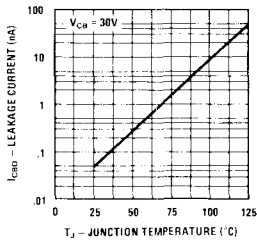
Output Capacitance vs Reverse Bias Voltage



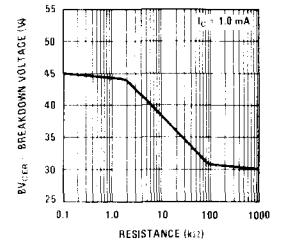
Small Signal Current Gain vs Collector Current

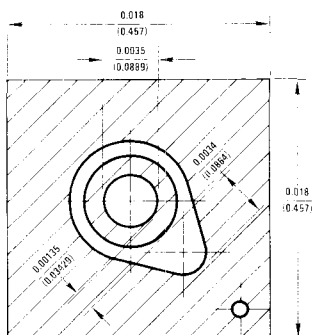


Collector-Base Diode Reverse Current vs Temperature



Collector-Emitter Breakdown Voltage vs Resistance




DESCRIPTION

Process 07 a nonoverlap, double diffused, silicon epitaxial device. Complement to Process G2.

APPLICATION

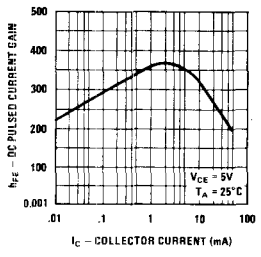
This device was designed for low noise, high gain general purpose amplifier applications. From 1 μA to 25 mA collector current.

PRINCIPAL DEVICE TYPES

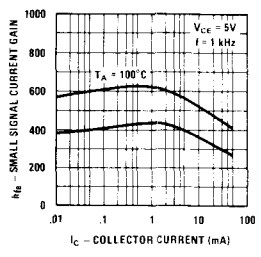
TO-18 2N930
TO-92 2N5088 (EBC), 2N3392 (ECB)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|----------------|---|-----|------|------|-------|-------|
| NF (spot) | $I_C = 10 \mu\text{A}$, $V_{CE} = 5\text{V}$, $R_S = 10\text{k}$, $f = 100 \text{ Hz}$, $P_{BW} = 20 \text{ Hz}$ | | 3 | 10 | dB | |
| NF (spot) | $I_C = 10 \mu\text{A}$, $V_{CE} = 5\text{V}$, $R_S = 10\text{k}$, $f = 1 \text{ kHz}$, $P_{BW} = 200 \text{ Hz}$ | | 1 | 3 | dB | |
| NF (spot) | $I_C = 10 \mu\text{A}$, $V_{CE} = 5\text{V}$, $R_S = 10\text{k}$, $f = 10 \text{ kHz}$, $P_{BW} = 2 \text{ kHz}$ | | 1 | 3 | dB | |
| NF (wide band) | $I_C = 10 \mu\text{A}$, $V_{CE} = 5\text{V}$, $R_S = 10\text{k}$, $P_{BW} = 15.7 \text{ kHz}$ | | 1 | 3 | dB | |
| f_{fe} | $I_C = 500 \mu\text{A}$, $V_{CE} = 5\text{V}$, $f = 20 \text{ MHz}$ | 5 | 7 | | | |
| C_{cb} | $V_{CB} = 5\text{V}$ | | 1.7 | 2.5 | pF | TO-18 |
| C_{eh} | $V_{EB} = 0.50\text{V}$ | | 4.5 | 6.0 | pF | TO-18 |
| h_{FE} | $I_C = 1 \mu\text{A}$, $V_{CE} = 5\text{V}$ | 35 | 170 | 450 | | |
| h_{FE} | $I_C = 10 \mu\text{A}$, $V_{CE} = 5\text{V}$ | 45 | 230 | 670 | | |
| h_{FE} | $I_C = 100 \mu\text{A}$, $V_{CE} = 5\text{V}$ | 60 | 300 | 830 | | |
| h_{FE} | $I_C = 500 \mu\text{A}$, $V_{CE} = 5\text{V}$ | 65 | 335 | 950 | | |
| h_{FE} | $I_C = 1 \text{ mA}$, $V_{CE} = 5\text{V}$ | 70 | 350 | 1000 | | |
| h_{FE} | $I_C = 10 \text{ mA}$, $V_{CE} = 5\text{V}$ | 65 | 320 | 900 | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}$, $I_B = 0.10 \text{ mA}$ | | 0.06 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | | 0.08 | 0.15 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}$, $I_B = 0.1 \text{ mA}$ | | 0.65 | 0.75 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | | 0.70 | 0.85 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 60 | 80 | 100 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 60 | | | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 8 | | | V | |
| I_{CBO} | $V_{CB} = 45\text{V}$ | | | 10 | nA | |
| I_{EBO} | $V_{EB} = 4\text{V}$ | | | 10 | nA | |

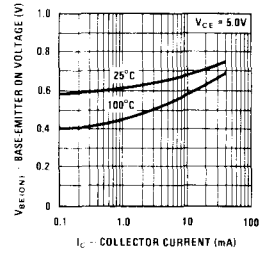
Pulsed DC Current Gain vs Collector Current



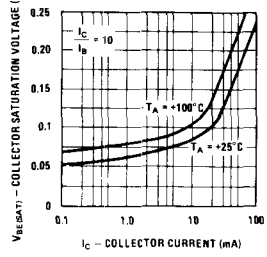
Small Signal Current Gain vs Collector Current



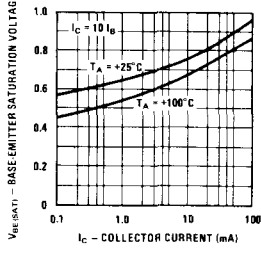
Base-Emitter On Voltage vs Collector Current



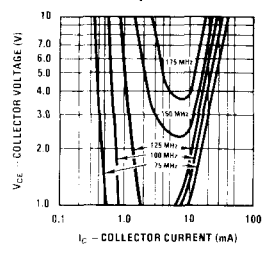
Collector Saturation Voltage vs Collector Current



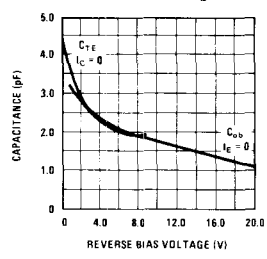
Base-Emitter Saturation Voltage vs Collector Current



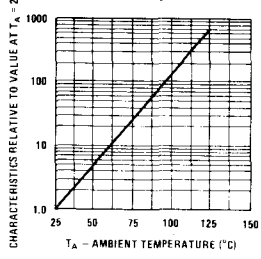
Contours of Constant Gain Bandwidth Product (fT)



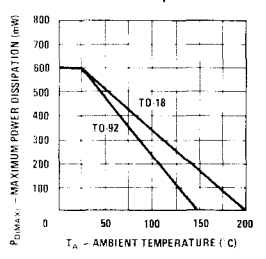
Input and Output Capacitance vs Reverse Bias Voltage



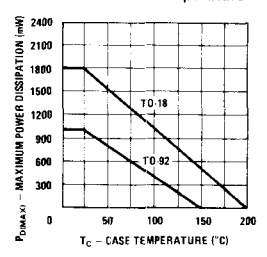
Normalized Collector Cutoff Current vs Ambient Temperature



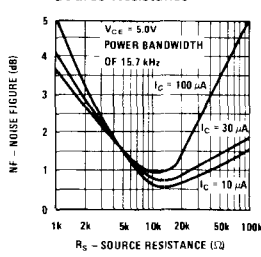
Maximum Power Dissipation vs Ambient Temperature



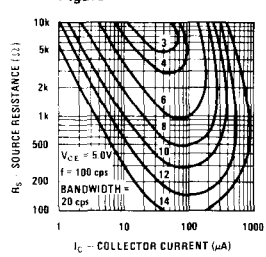
Maximum Power Dissipation vs Case Temperature



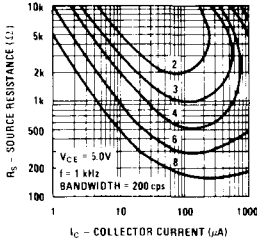
Wide Band Noise Figure vs Source Resistance



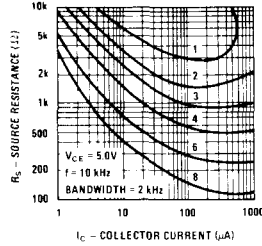
Contours of Constant Narrow Band Noise Figure



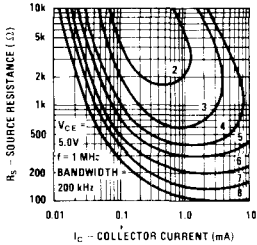
Contours of Constant Narrow Band Noise Figure



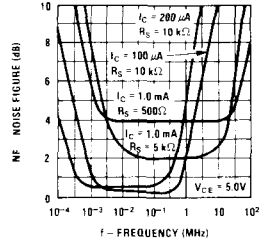
Contours of Constant Narrow Band Noise Figure



Contours of Constant Narrow Band Noise Figure



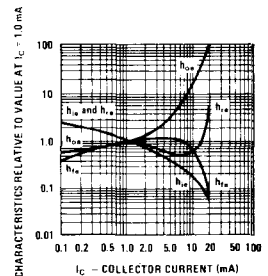
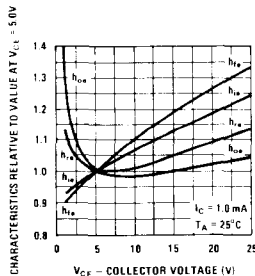
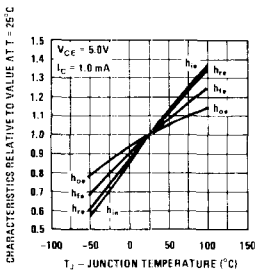
Noise Figure vs Frequency



SMALL SIGNAL CHARACTERISTICS ($f = 1.0 \text{ kHz}$)

| SYMBOL | CHARACTERISTIC | TYP. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------------------|--|
| h_{ie} | Input Resistance | 15 | $k\Omega$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0V$ |
| h_{oe} | Output Conductance | 15 | μmho | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0V$ |
| h_{re} | Voltage Feedback Ratio | 425 | $\times 10^{-6}$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0V$ |
| h_{fe} | Small Signal Current Gain | 400 | | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0V$ |
| h_{ib} | Input Resistance | 27 | ohms | $I_C = 1.0 \text{ mA}$ $V_{CB} = 5.0V$ |

TYPICAL COMMON EMITTER CHARACTERISTICS ($f = 1.0 \text{ kHz}$)



DESCRIPTION

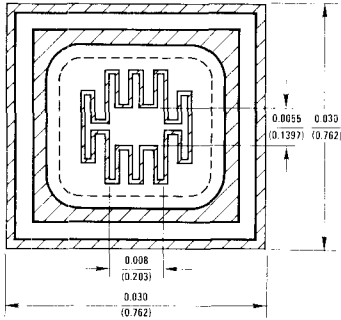
Complements Process 73.

APPLICATION

This device was designed as a general purpose amplifier and switch for applications requiring high line voltages.

PRINCIPAL DEVICE TYPES

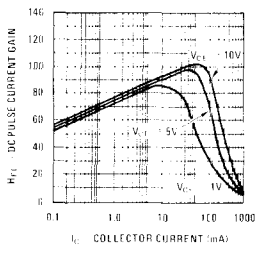
TO-39 2N3501



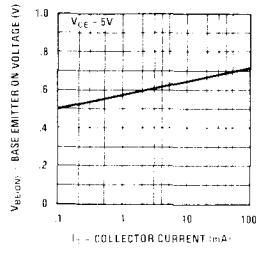
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|-----|-------|-------|
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 100 | 160 | 185 | V | |
| BV_{CBO} | $I_C = 10 \mu\text{A}$ | 100 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 6 | | | V | |
| I_{CBO} | $V_{CB} = 50\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4\text{V}$ | | | 25 | nA | |
| h_{FE} | $I_C = 0.1 \text{ mA}, V_{CE} = 10\text{V}$ | 20 | 40 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10\text{V}$ | 25 | 70 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ | 35 | 95 | | | |
| h_{FE} | $I_C = 150 \text{ mA}, V_{CE} = 10\text{V}$ | 40 | 100 | 300 | | |
| h_{FE} | $I_C = 300 \text{ mA}, V_{CE} = 10\text{V}$ | 15 | 40 | | | |
| $V_{CE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.25 | 0.4 | V | |
| $V_{BE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.9 | 1.2 | V | |
| C_{OB} | $V_{CB} = 10\text{V}$ | | 7.5 | 10 | pF | |
| C_{IB} | $V_{EB} = 0.5\text{V}$ | | 65 | 80 | pF | |
| f_T | $I_C = 20 \text{ mA}, V_{CE} = 20\text{V}, f = 100 \text{ MHz}$ | 150 | 200 | | MHz | |

Process 08

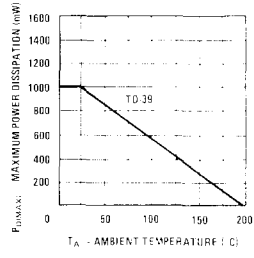
DC Pulsed Current Gain vs Collector Current



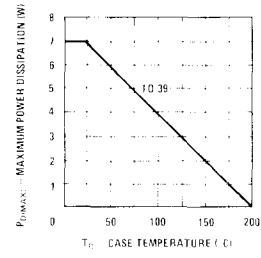
Base-Emitter On Voltage vs Collector Current



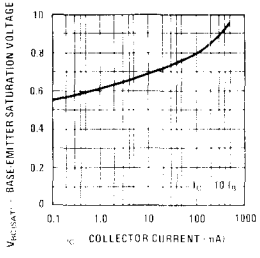
Maximum Power Dissipation vs Ambient Temperature



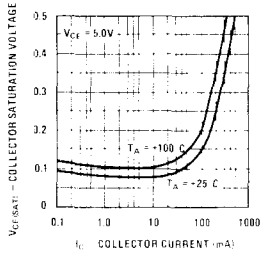
Maximum Power Dissipation vs Case Temperature



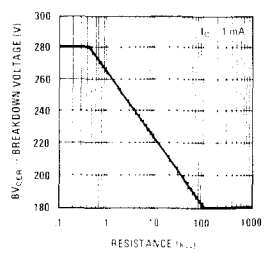
Base-Emitter Saturation Voltage vs Collector Current



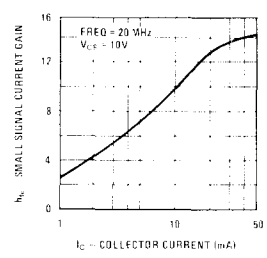
Collector-Emitter Saturation Voltage vs Collector Current



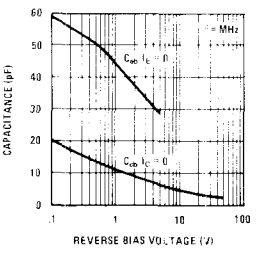
Collector-Emitter Break-down Voltage With Resistance Between Emitter and Base



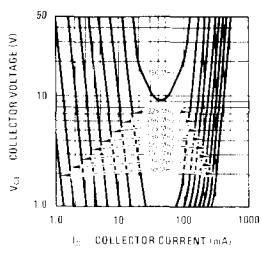
Small Signal Current Gain vs Collector Current



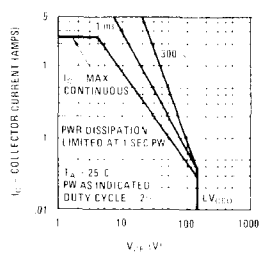
Input and Output Capacitance vs Reverse Bias Voltage



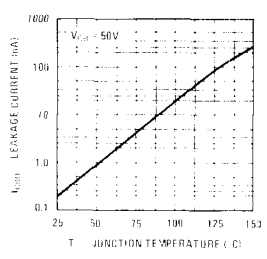
Collector-Emitter Voltage vs Collector Current



Safe Operating Area TO-39 With "Wake Field" Type 296.4 Heat Sink



Collector-Base Diode Current vs Temperature



DESCRIPTION

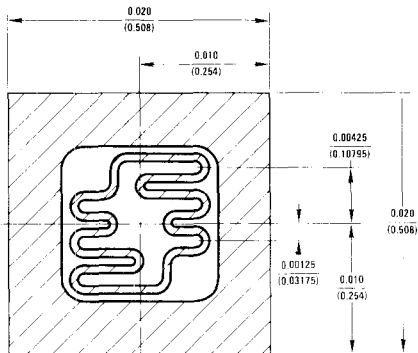
Process 09 is a nonoverlap double diffused silicon epitaxial device.

APPLICATION

This device was designed for general purpose audio amplifier applications at collector currents to one Amp.

PRINCIPAL DEVICE TYPES

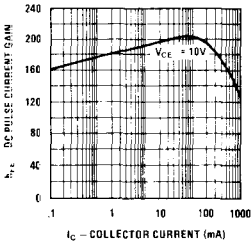
TO-92 CS9013



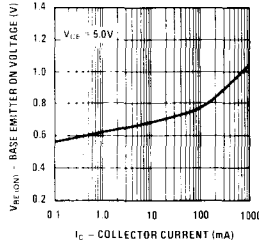
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|-----|-------|-------|
| C_{OB} | $V_{CB} = 10V$ | | 5 | 10 | pF | |
| C_{IB} | $V_{EB} = .5V$ | | 25 | 35 | pF | |
| NF | $V_{CE} = 10V, I_C = 1 mA$ | | 1.0 | | dB | |
| f_T | $R_S = 1k, f = 1 kHz$ $V_{CE} = 10V, I_C = 100 mA$ | | 400 | | MHz | |
| h_{FE} | $V_{CE} = 1.0V, I_C = 1 mA$ | 50 | 170 | 290 | | |
| h_{FE} | $V_{CE} = 1.0V, I_C = 50 mA$ | 60 | 200 | 350 | | |
| h_{FE} | $V_{CE} = 1.0V, I_C = 500 mA$ | 50 | 160 | 280 | | |
| h_{FE} | $V_{CE} = 1.0V, I_C = 1A$ | 35 | 120 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 150 mA, I_B = 15 mA$ | | 0.09 | | V | |
| $V_{CE(SAT)}$ | $I_C = 500 mA, I_B = 50 mA$ | | 0.24 | | V | |
| $V_{BE(SAT)}$ | $I_C = 150 mA, I_B = 15 mA$ | | 0.86 | | V | |
| $V_{BE(SAT)}$ | $I_C = 500 mA, I_B = 50 mA$ | | 1.0 | | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | | 100 | | | |
| BV_{CEO} | $I_C = 10 mA$ | 20 | 25 | 30 | | |
| BV_{EBO} | $I_E = 1 \mu A$ | | 7.5 | | | |
| I_{CBO} | $V_{CB} = 40V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4.0V$ | | | 50 | nA | |

Process 09

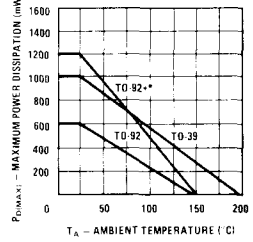
DC Pulse Current Gain vs Collector Current



Base-Emitter On Voltage vs Collector Current

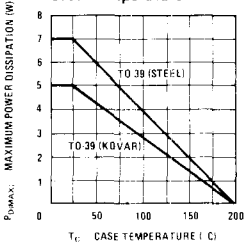


Maximum Power Dissipation vs Ambient Temperature

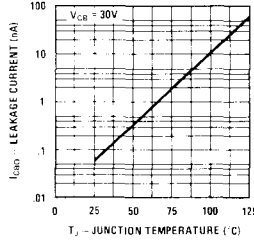


*One square inch of copper run

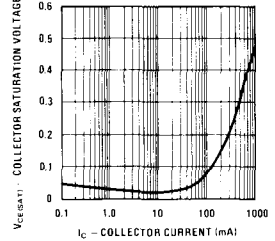
Maximum Power Dissipation vs Case Temperature



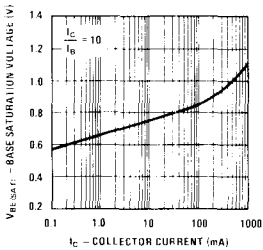
Collector-Base Diode Reverse Current vs Temperature



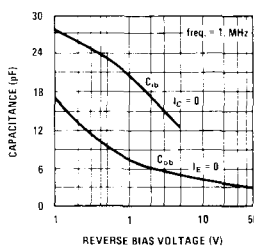
Collector-Emitter Saturation Voltage vs Collector Current



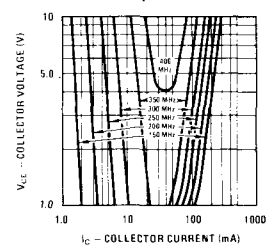
Base-Emitter Saturation Voltage vs Collector Current



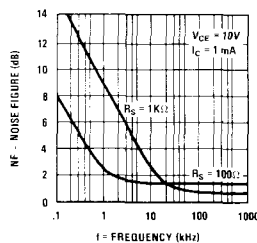
Capacitance vs Reverse Bias Voltage



Contours of Constant Gain Bandwidth Product (fT)



Noise Figure vs Frequency



DESCRIPTION

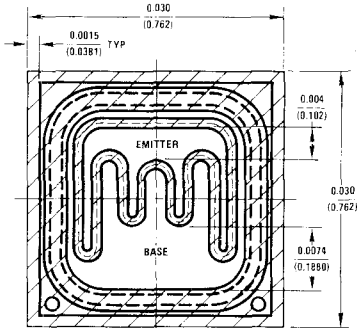
Process 12 is a nonoverlay, double diffused silicon epitaxial device. Complement to Process 67.

APPLICATION

This device was designed for general purpose medium power amplifiers and switches requiring collector currents up to 1 amp and collector voltages between 80 and 140 volts.

PRINCIPAL DEVICE TYPES

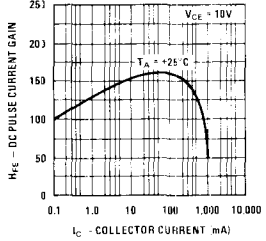
| | |
|--------|----------------|
| TO-92 | MPSA05 |
| TO-39 | 2N3019 |
| TO-202 | NSD106 |
| TO-92+ | TN3019, TN3020 |



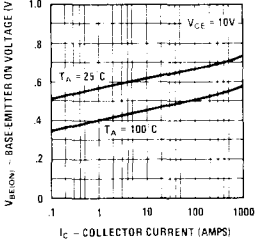
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|--------|
| t_{on} | $I_C = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$ | | 50 | 60 | ns | Fig. 1 |
| t_{off} | $I_C = 150 \text{ mA}, I_{B2} = 15 \text{ mA}$ | | 400 | 500 | ns | |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}, f = 20 \text{ MHz}$ | 4.0 | 6.5 | | | |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 6.5 | 10 | pF | TO-39 |
| C_{eb} | $V_{EB} = 0.5$ | | 50 | 60 | pF | |
| NF | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}, R_s = 1 \text{ k}$ $f = 1 \text{ kHz}, \text{PBW} = 200 \text{ Hz}$ | | 1.5 | 4 | dB | |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ | 20 | 100 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ | 30 | 130 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ | 40 | 150 | | | |
| h_{FE} | $I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$ | 40 | 170 | 300 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}$ | 30 | 130 | | | |
| h_{FE} | $I_C = 1 \text{ A}, V_{CE} = 10 \text{ V}$ | 20 | 40 | | | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.1 | 0.2 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.25 | 0.5 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.82 | 0.90 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 1.0 | 1.20 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 65 | 80 | 100 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 120 | | | V | |
| BV_{CES} | $I_C = 10 \mu\text{A}$ | 120 | | | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 7 | | | V | |
| I_{CBO} | $V_{CB} = 90 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 5 \text{ V}$ | | | 50 | nA | |

Process 12

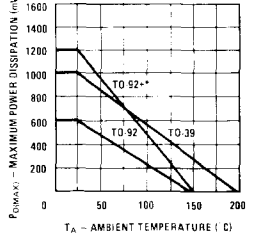
Pulsed DC Current Gain vs Collector Current



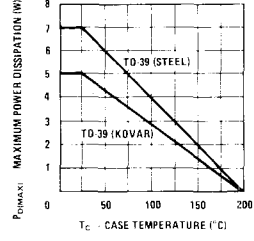
Base-Emitter On Voltage vs Collector Current



Maximum Power Dissipation vs Ambient Temperature

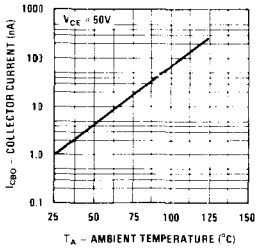


Maximum Power Dissipation vs Case Temperature

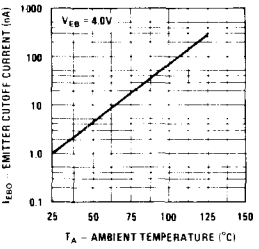


*One square inch of copper pin

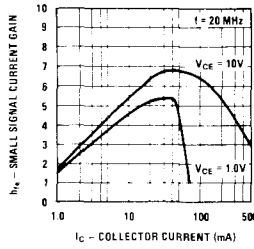
Collector Reverse Current vs Ambient Temperature



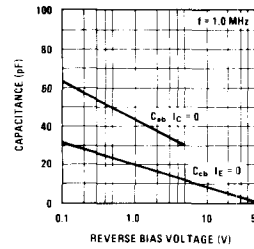
Emitter Cutoff Current vs Ambient Temperature



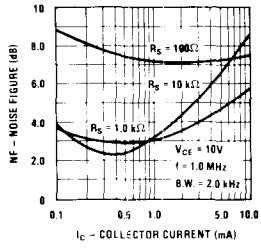
Small Signal Current Gain at 20 MHz



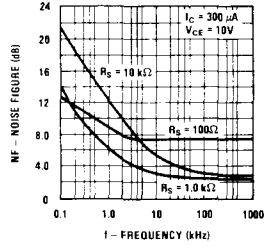
Collector-Base and Emitter Base Capacitance vs Reverse Bias Voltage



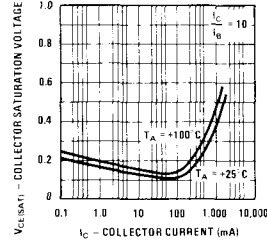
Noise Figure vs Collector Current



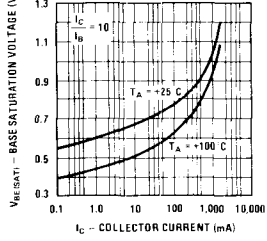
Noise Figure vs Frequency



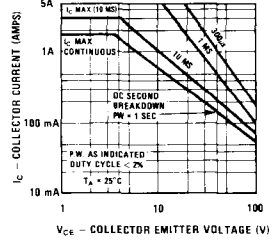
Collector Saturation Voltage vs Collector Current



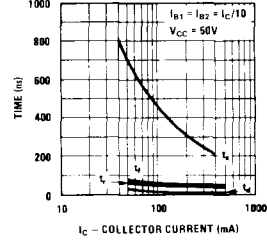
Base Saturation Voltage vs Collector Current



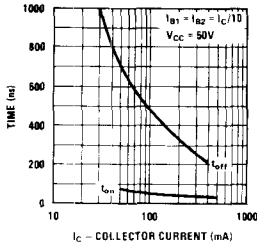
Safe Operating Area TO-39 With "Wake Field" Type 296-4 Heat Sink



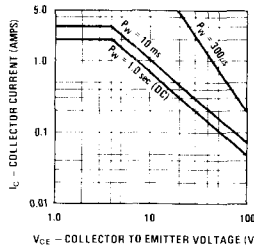
Switching Times vs Collector Current



Turn On and Turn Off Times vs Collector Current



Safe Operating Area TO-202



Maximum Power Dissipation TO-202 vs Case and Ambient Temperature

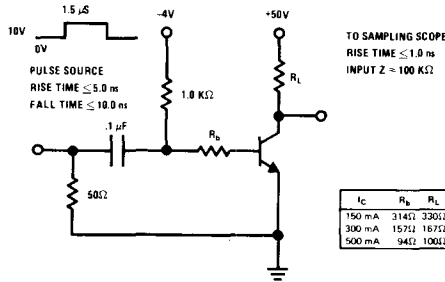
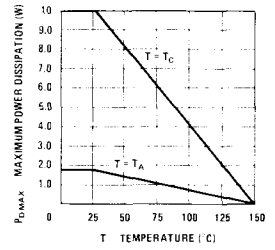
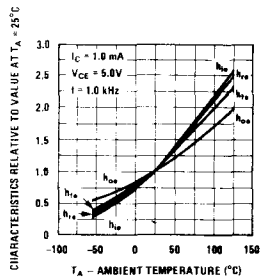
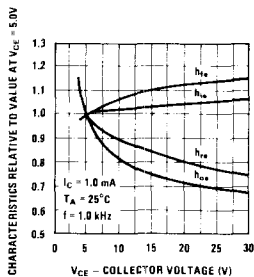
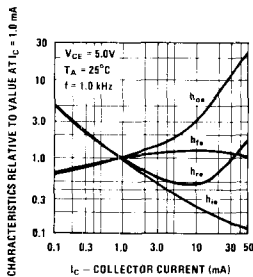


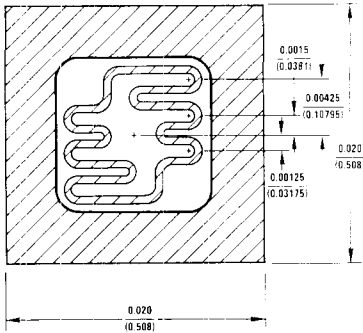
FIGURE 1. t_{on} , t_{off} Test Circuit

SMALL SIGNAL CHARACTERISTICS (f = 1.0 kHz)

| SYMBOL | CHARACTERISTIC | TYP. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------------------|---|
| h_{ie} | Input Resistance | 3000 | ohms | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |
| h_{oe} | Output Conductance | 8.0 | μmhos | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |
| h_{re} | Voltage Feedback Ratio | 2.1 | $\times 10^{-4}$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |
| h_{fe} | Small Signal Current Gain | 100 | | $I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$ |

TYPICAL COMMON EMITTER CHARACTERISTICS (f = 1.0 kHz)




DESCRIPTION

Process 13 is a nonoverlap. Complement to Process 63.

APPLICATION

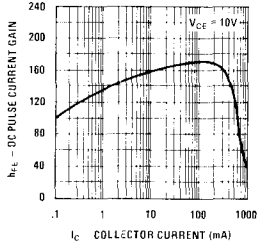
These devices were designed for use as medium power amplifiers and switches requiring collector currents of .1 mA to one Amp.

PRINCIPAL DEVICE TYPES

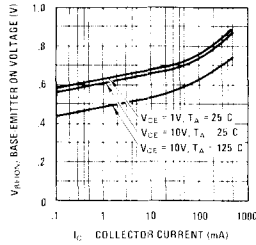
TO-92 2N4401 (EBC), 2N3704 (ECB)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| t_{on} | $I_C = 150 \text{ mA}$, $I_{B1} = 15 \text{ mA}$ | | 25 | 35 | ns | |
| t_{off} | $I_C = 150 \text{ mA}$, $I_{B2} = 15 \text{ mA}$ | | 200 | 285 | ns | |
| h_{fe} | $I_C = 20 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $f = 100 \text{ MHz}$ | 1.8 | 2.5 | | | |
| NF (spot) | $I_C = 100 \mu\text{A}$, $V_{CE} = 10 \text{ V}$ $R_S = 1 \text{ k}\Omega$, $f = 1 \text{ kHz}$, PBW = 200 Hz | | 1.2 | 4.0 | dB | |
| C_{ob} | $V_{CB} = 10 \text{ V}$ | | 4.5 | | pF | |
| C_{ib} | $V_{EB} = .5 \text{ V}$ | | 22 | | pF | |
| h_{FE} | $V_{CE} = 1.0 \text{ V}$, $I_C = 100 \mu\text{A}$ | 15 | 80 | 150 | | |
| h_{FE} | $V_{CE} = 1.0 \text{ V}$, $I_C = 1.0 \text{ mA}$ | 25 | 110 | 250 | | |
| h_{FE} | $V_{CE} = 1.0 \text{ V}$, $I_C = 10 \text{ mA}$ | 35 | 135 | 300 | | |
| h_{FE} | $V_{CE} = 1.0 \text{ V}$, $I_C = 150 \text{ mA}$ | 40 | 140 | 300 | | |
| h_{FE} | $V_{CE} = 1.0 \text{ V}$, $I_C = 500 \text{ mA}$ | 25 | 100 | 200 | | |
| h_{FE} | $V_{CE} = 5.0 \text{ V}$, $I_C = 1 \text{ A}$ | 15 | 45 | 75 | | |
| $V_{CE(SAT)}$ | $I_C = 150 \text{ mA}$, $I_B = 15 \text{ mA}$ | | 0.1 | 0.2 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | 0.26 | 0.36 | V | |
| $V_{BE(SAT)}$ | $I_C = 150 \text{ mA}$, $I_B = 15 \text{ mA}$ | | 0.87 | 0.97 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | 1.0 | 1.2 | V | |
| BV_{CBO} | $I_C = 1.0 \mu\text{A}$ | 60 | 100 | 140 | V | |
| BV_{CES} | $I_C = 10 \mu\text{A}$ | 60 | | | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 30 | 40 | 55 | V | |
| BV_{EBO} | $I_E = 1.0 \mu\text{A}$ | 6.0 | | | V | |
| I_{CBO} | $V_{CB} = 40 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4 \text{ V}$ | | | 50 | nA | |

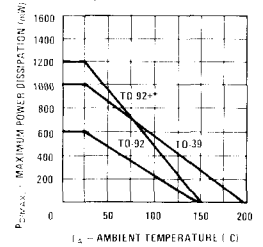
DC Pulse Current Gain vs Collector Current



Base-Emitter On Voltage vs Collector Current

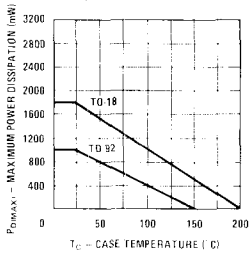


Maximum Power Dissipation vs Ambient Temperature

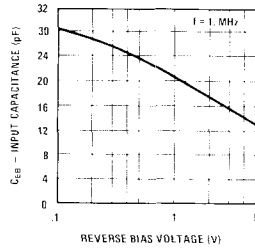


*One square inch of copper run

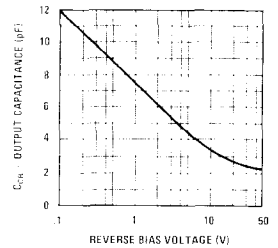
Maximum Power Dissipation vs Case Temperature



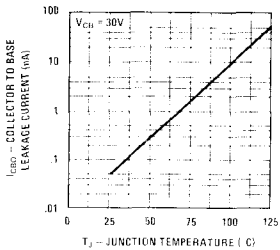
Input Capacitance vs Reverse Bias Voltage



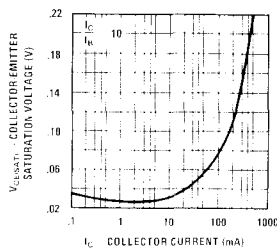
Output Capacitance vs Reverse Bias Voltage



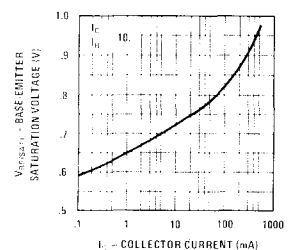
Collector to Base Diode Reverse Current vs Temperature



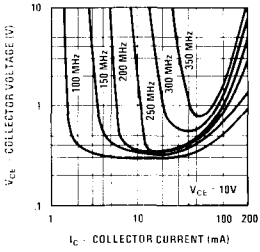
Collector-Emitter Saturation Voltage vs Collector Current



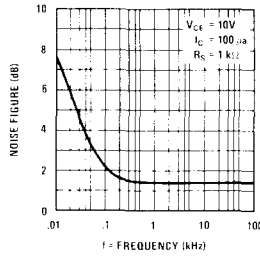
Base-Emitter Saturation Voltage vs Collector Current



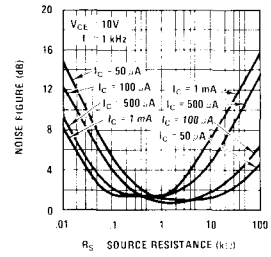
Contours of Constant Gain Bandwidth Product (f_t)



Noise Figure vs Frequency



Noise Figure vs Source Resistance

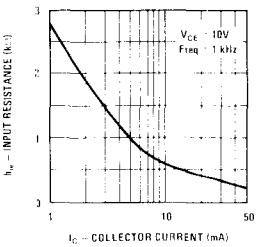


SMALL SIGNAL CHARACTERISTICS ($f = 1.0 \text{ kHz}$)

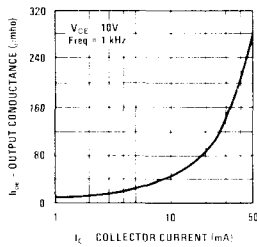
| SYMBOL | CHARACTERISTIC | TYP | UNITS | TEST CONDITIONS |
|----------|---------------------------|-----|------------------|--|
| h_{ie} | Input Resistance | 600 | ohms | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ |
| h_{oe} | Output Conductance | 50 | μmhos | $I_C > 10 \text{ mA}, V_{CE} = 10\text{V}$ |
| h_{fe} | Small Signal Current Gain | 170 | | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ |
| h_{re} | Voltage Feedback Ratio | 120 | $\times 10^{-6}$ | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ |

TYPICAL COMMON EMITTER CHARACTERISTICS ($f = 1.0 \text{ kHz}$)

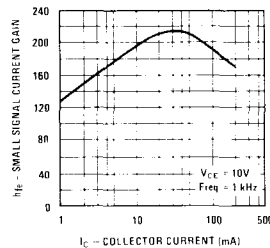
Small Signal Input Resistance vs Collector Current



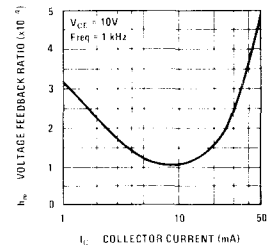
Small Signal Output Conductance vs Collector Current



Small Signal Current Gain vs Collector Current



Small Signal Voltage Feedback Ratio vs Collector Current



DESCRIPTION

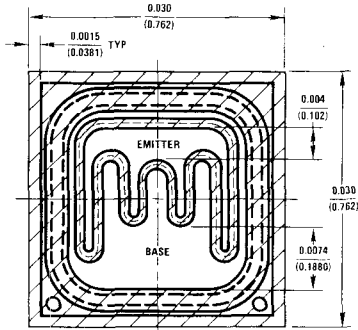
Process 14 is a nonoverlay double diffused silicon epitaxial device. Complement to Process 67.

APPLICATION

This device was designed for general purpose audio amplifier applications at collector currents to 500 mA.

PRINCIPAL DEVICE TYPES

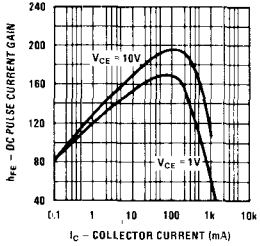
TO-39 BFY50
TO-92 MPS6560



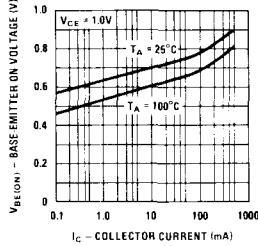
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| C_{ob} | $V_{CB} = 10V$ | | 8 | 10 | pF | |
| C_{ib} | $V_{EB} = 0.5V$ | | 55 | 65 | pF | |
| h_{fe} | $I_C = 50\text{ mA}, V_{CE} = 10V, f = 20\text{ MHz}$ | 5 | 10 | | | |
| h_{FE} | $I_C = 0.1\text{ mA}, V_{CE} = 1V$ | 20 | 60 | | | |
| h_{FE} | $I_C = 1\text{ mA}, V_{CE} = 1V$ | 20 | 80 | | | |
| h_{FE} | $I_C = 10\text{ mA}, V_{CE} = 1V$ | 20 | 100 | 400 | | |
| h_{FE} | $I_C = 150\text{ mA}, V_{CE} = 1V$ | 45 | 160 | 300 | | |
| h_{FE} | $I_C = 500\text{ mA}, V_{CE} = 1V$ | 20 | 70 | | | |
| $V_{CE(SAT)}$ | $I_C = 10\text{ mA}, I_B = 1\text{ mA}$ | | 0.04 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 150\text{ mA}, I_B = 10\text{ mA}$ | | 0.10 | 0.15 | V | |
| $V_{BE(SAT)}$ | $I_C = 10\text{ mA}, I_B = 1\text{ mA}$ | | 0.70 | 0.90 | V | |
| $V_{BE(SAT)}$ | $I_C = 150\text{ mA}, I_B = 10\text{ mA}$ | | 0.80 | 1.0 | V | |
| BV_{CEO} | $I_C = 1\text{ mA}$ | 40 | 50 | 60 | V | |
| BV_{CBO} | $I_C = 100\text{ }\mu\text{A}$ | 80 | | | V | |
| BV_{EBO} | $I_E = 10\text{ }\mu\text{A}$ | 7 | | | V | |
| I_{CBO} | $V_{CB} = 30$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3$ | | | 50 | nA | |

Process 14

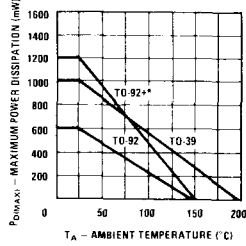
DC Pulse Current Gain vs Collector Current



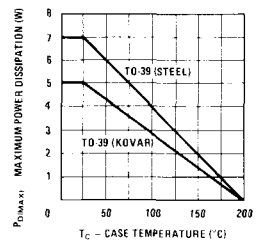
Base-Emitter On Voltage vs Collector Current



Maximum Power Dissipation vs Ambient Temperature

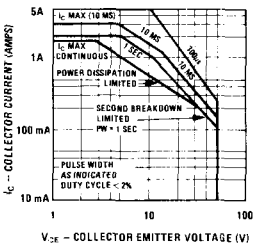


Maximum Power Dissipation vs Case Temperature

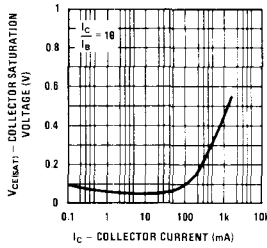


*One square inch of copper pin

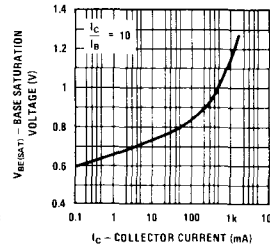
Safe Operating Area TO-39 With "Wake Field" Type 296-4 Heat Sink



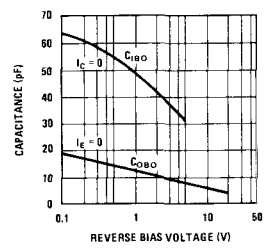
Collector-Emitter Saturation Voltage vs Collector Current



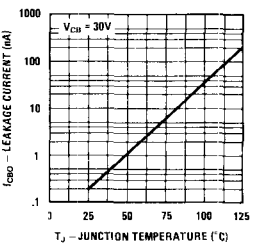
Base-Emitter Saturation Voltage vs Collector Current



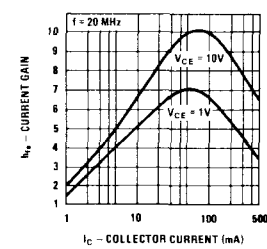
Capacitance vs Reverse Bias Voltage



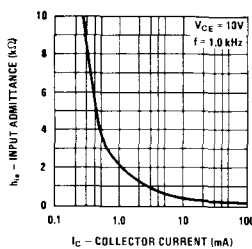
Collector-Base Diode Reverse Current vs Temperature



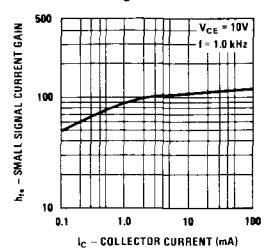
Small Signal Current Gain At 20 MHz vs Collector Current



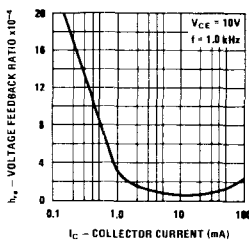
Input Admittance



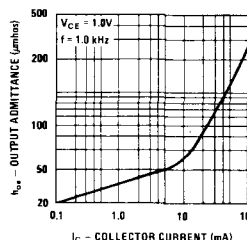
Small Signal Current Gain



Voltage Feedback Ratio



Output Admittance



DESCRIPTION

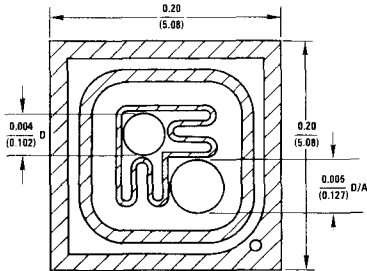
Process 16 is a nonoverlay, double diffused, epitaxial silicon device.

APPLICATION

This device was designed for general purpose high voltage amplifiers and gas discharge display driving.

PRINCIPAL DEVICE TYPES

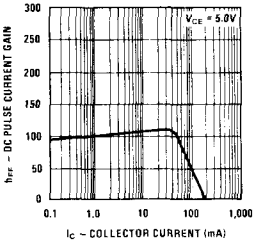
TO-92 2N5551



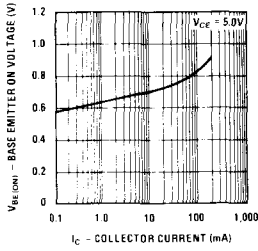
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|------|------|-------|
| BV_{CEO} | $I_C = 1.0 \text{ mA}$ | 100 | 155 | 180 | V |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 120 | | | V |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 6 | | | V |
| I_{CBO} | $V_{CB} = 120\text{V}$ | | 0.5 | 50 | nA |
| I_{EBO} | $V_{EB} = 4.0\text{V}$ | | 0.3 | 50 | nA |
| h_{FE} | $I_C = 1.0 \text{ mA}, V_{CE} = 5.0\text{V}$ | 50 | 105 | 300 | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 5.0\text{V}$ | 50 | 132 | 300 | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 5.0\text{V}$ | 20 | 60 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ | | 0.07 | 0.15 | V |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$ | | 0.12 | 0.25 | V |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ | | 0.75 | 1.0 | V |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.83 | 1.2 | V |
| f_T | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}, f = 100 \text{ MHz}$ | 100 | 220 | 300 | MHz |
| C_{ob} | $V_{CB} = 10\text{V}$ | | 2.67 | 6.0 | pF |
| C_{cb} | $V_{CB} = 10\text{V}$ | | 2.53 | 4.0 | pF |
| C_{ib} | $V_{EB} = 0.5\text{V}$ | | 17 | 30 | pF |

Process 16

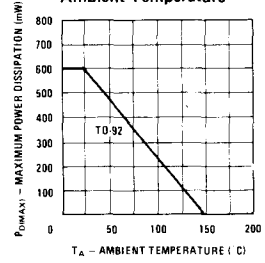
DC Pulse Current Gain vs Collector Current



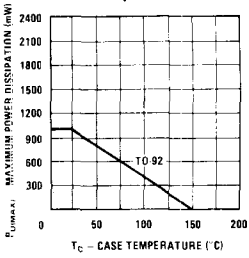
Base-Emitter on Voltage vs Collector Current



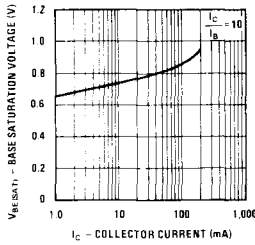
Maximum Power Dissipation vs Ambient Temperature



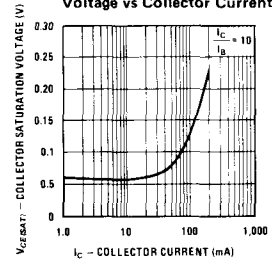
Maximum Power Dissipation vs Case Temperature



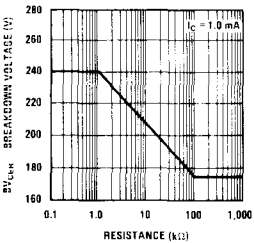
Base-Emitter Saturation Voltage vs Collector Current



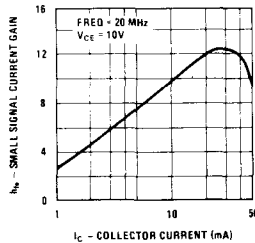
Collector-Emitter Saturation Voltage vs Collector Current



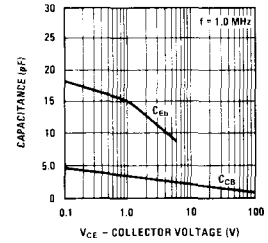
Collector-Emitter Breakdown Voltage With Resistance Between Emitter-Base



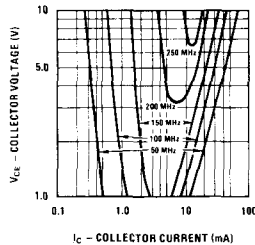
Small Signal Current Gain vs Collector Current

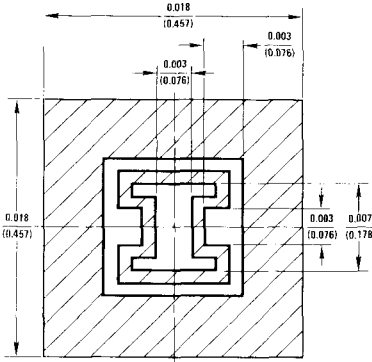


Input and Output Capacitance vs Reverse Bias Voltage



Contours of Constant Gain Bandwidth Product (fT)





DESCRIPTION

Process 19 is nonoverlap double diffused, gold doped, silicon epitaxial device. Complement to Process 63.

APPLICATION

These devices were designed for use as medium power amplifiers and switches requiring collector currents of 0.1 to 500 mA.

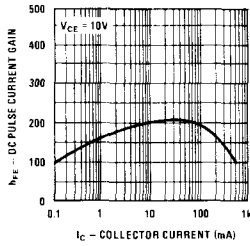
PRINCIPAL DEVICE TYPES

TO-92 PN2222

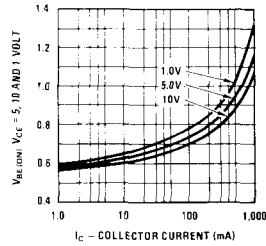
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| t_{on} | $I_C = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$ | | 25 | 35 | ns | |
| t_{off} | $I_C = 150 \text{ mA}, I_{B2} = 15 \text{ mA}$ | | 200 | 285 | ns | |
| h_{fe} | $I_C = 20 \text{ mA}, V_{CE} = 20 \text{ V}, f = 100 \text{ MHz}$ | 2.5 | 3.5 | | | |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 3.0 | 6.0 | pF | |
| C_{cb} | $V_{EB} = 0.5 \text{ V}$ | | 18 | 25 | pF | |
| NF (spot) | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ $R_S = 1 \text{ k}\Omega, f = 1 \text{ kHz}, \text{PBW} = 200 \text{ Hz}$ | | 1.2 | 4.0 | dB | |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ | 20 | 100 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ | 30 | 160 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ | 40 | 200 | 300 | | |
| h_{FE} | $I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$ | 45 | 180 | 540 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}$ | 25 | 90 | | | |
| h_{FE} | $I_C = 1 \text{ A}, V_{CE} = 10 \text{ V}$ | 15 | 30 | | | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.12 | 0.50 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.35 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.90 | 1.2 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 1.1 | 1.5 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 30 | 50 | 60 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 45 | | | V | |
| BV_{CES} | $I_C = 10 \mu\text{A}$ | 45 | | 85 | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 6 | | | V | |
| I_{CBO} | $V_{CB} = 60 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3 \text{ V}$ | | | 50 | nA | |

Process 19

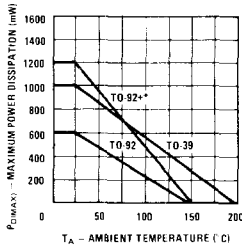
DC Pulse Current Gain vs Collector Current



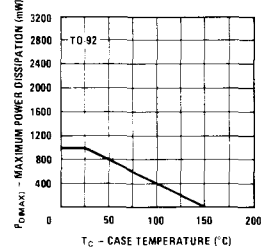
Base-Emitter On Voltage vs Collector Current



Maximum Power Dissipation vs Ambient Temperature

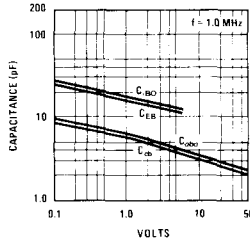


Maximum Power Dissipation vs Case Temperature

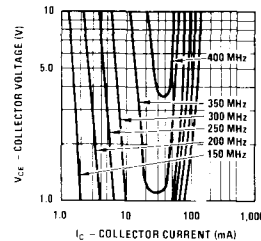


*One square inch of copper run

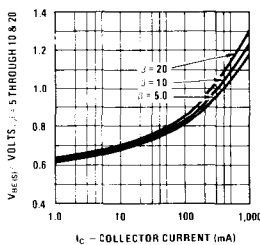
Emitter Transition and Output Capacitance vs Reverse Bias Voltage



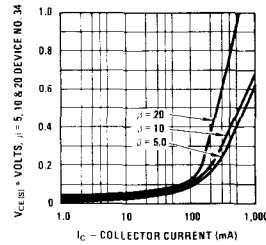
Contours of Constant Gain Bandwidth Product (fT)



Base-Emitter Saturation Voltage vs Collector Current



Collector-Emitter Saturation Voltage vs Collector Current



DESCRIPTION

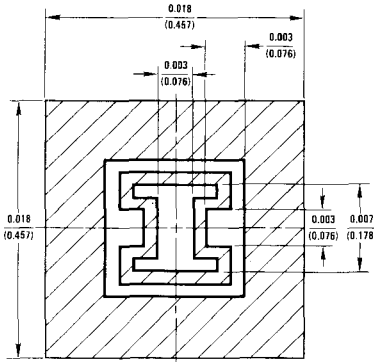
Process 20 is nonoverlap double diffused, gold doped, silicon epitaxial device. Complement to Process 63.

APPLICATION

These devices were designed for use as medium power amplifiers and switches requiring collector currents of 0.1 to 500 mA.

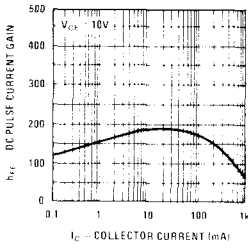
PRINCIPAL DEVICE TYPES

| | |
|--------|---------|
| TO-5 | 2N2219A |
| TO-18 | 2N2222A |
| TO-92 | MPS3642 |
| TO-105 | 2N3643 |
| TO-106 | 2N4141 |

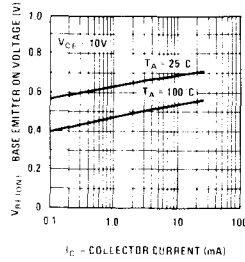


| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| t_{on} | $I_C = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$ | | 25 | 35 | ns | |
| t_{off} | $I_C = 150 \text{ mA}, I_{B2} = 15 \text{ mA}$ | | 200 | 285 | ns | |
| h_{fe} | $I_C = 20 \text{ mA}, V_{CE} = 20 \text{ V}, f = 100 \text{ MHz}$ | 2.5 | 3.5 | | | |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 3.0 | 6.0 | pF | |
| C_{ib} | $V_{EB} = 0.5 \text{ V}$ | | 19 | 25 | pF | |
| NF (spot) | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ $R_S = 1 \text{ k}\Omega, f = 1 \text{ kHz}, \text{PBW} = 200 \text{ Hz}$ | | 1.2 | 4.0 | dB | |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 10 \text{ V}$ | 30 | 100 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10 \text{ V}$ | 40 | 195 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ | 50 | 240 | 500 | | |
| h_{FE} | $I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$ | 50 | 180 | 500 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}$ | 30 | 90 | | | |
| h_{FE} | $I_C = 1 \text{ A}, V_{CE} = 10 \text{ V}$ | 15 | 30 | | | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.12 | 0.50 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.35 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.90 | 1.2 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 1.00 | 1.5 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 40 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 70 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 6 | | | V | |
| I_{CBO} | $V_{CB} = 60 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3 \text{ V}$ | | | 50 | nA | |

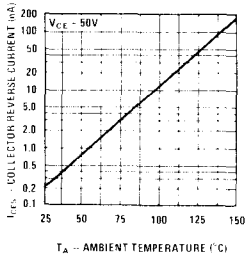
DC Pulse Current Gain vs Collector Current



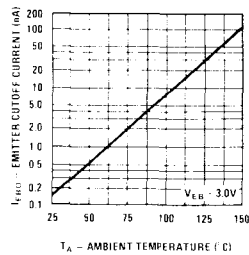
Base-Emitter On Voltage vs Collector Current



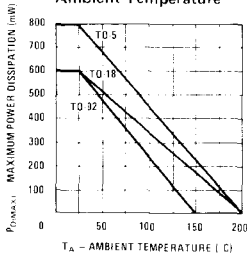
Collector Reverse Current vs Ambient Temperature



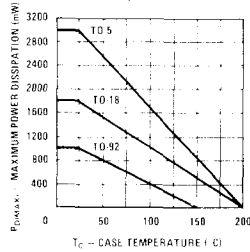
Emitter Cutoff Current vs Ambient Temperature



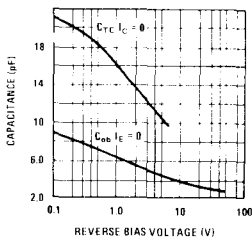
Maximum Power Dissipation vs Ambient Temperature



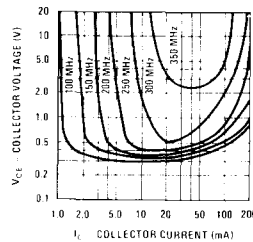
Maximum Power Dissipation vs Case Temperature



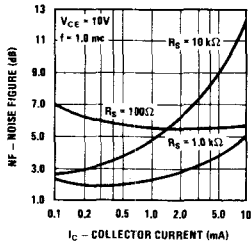
Emitter Transition and Output Capacitance vs Reverse Bias Voltage



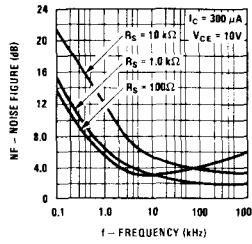
Contours of Constant Gain Bandwidth Product (f_T)



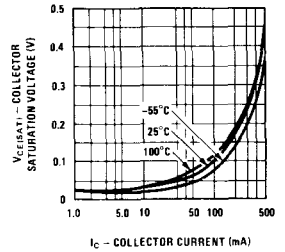
Noise Figure vs Collector Current



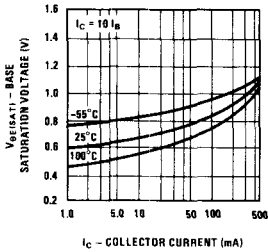
Noise Figure vs Frequency



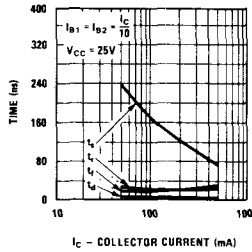
Collector Saturation Voltage vs Collector Current



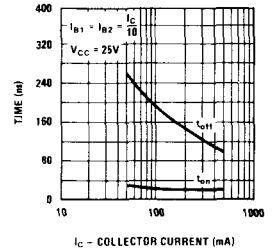
Base Saturation Voltage vs Collector Current



Switching Times vs Collector Current



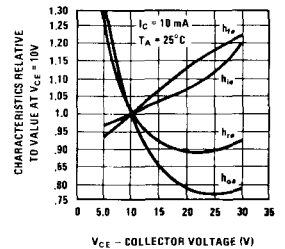
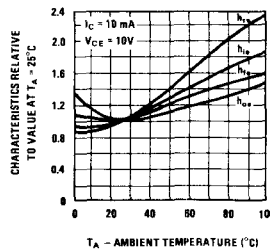
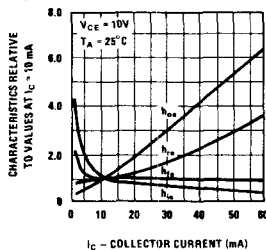
Turn On and Turn Off Times vs Collector Current



SMALL SIGNAL CHARACTERISTICS (f = 1.0 kHz)

| SYMBOL | CHARACTERISTIC | TYP | UNITS | TEST CONDITIONS |
|----------|---------------------------|-----|------------------|---|
| h_{ie} | Input Resistance | 700 | ohms | $I_C = 10 \text{ mA}$ $V_{CE} = 10 \text{ V}$ |
| h_{oe} | Output Conductance | 120 | μhos | $I_C = 10 \text{ mA}$ $V_{CE} = 10 \text{ V}$ |
| h_{fe} | Small Signal Current Gain | 240 | | $I_C = 10 \text{ mA}$ $V_{CE} = 10 \text{ V}$ |
| h_{re} | Voltage Feedback Ratio | 460 | $\times 10^{-6}$ | $I_C = 10 \text{ mA}$ $V_{CE} = 10 \text{ V}$ |

TYPICAL COMMON EMITTER CHARACTERISTICS (f = 1.0 kHz)



DESCRIPTION

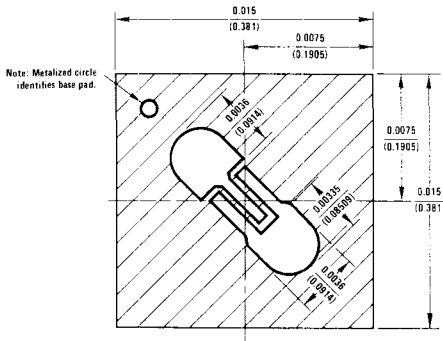
Process 21 is an overlay, double diffused, gold doped silicon epitaxial device. Complement to Process 65.

APPLICATION

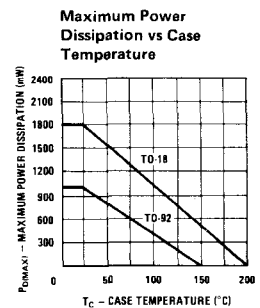
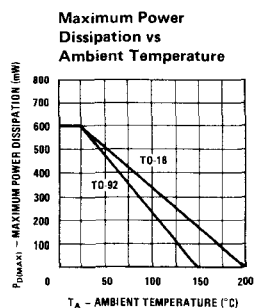
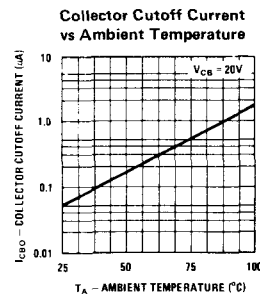
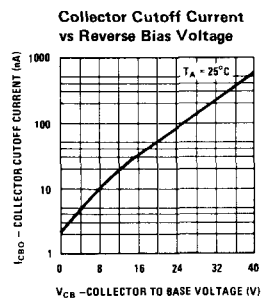
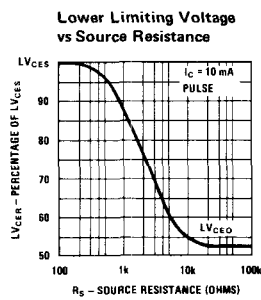
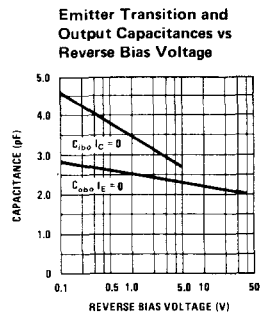
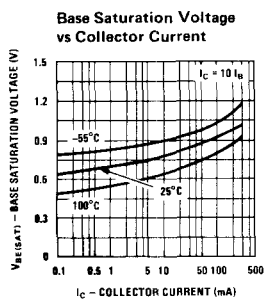
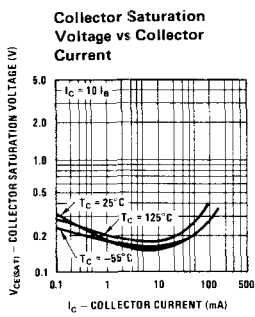
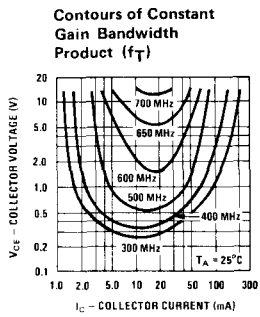
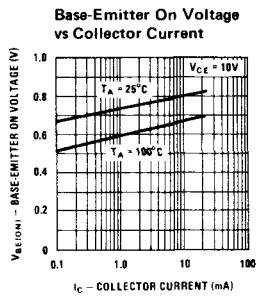
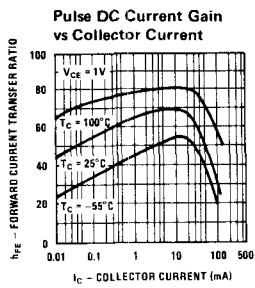
This device was designed for high speed saturated switching at collector currents of 10 to 100 mA.

PRINCIPAL DEVICE TYPES

TO-18 2N2369A
TO-92 MPS2369 (EBC)

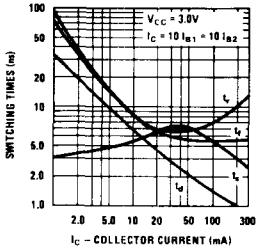


| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|--------|
| t_s | $I_{B1} = I_{B2} = I_C = 10 \text{ mA}$ | | 7 | 13 | ns | Fig. 1 |
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 3 \text{ mA}$ | | 9 | 12 | ns | Fig. 2 |
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1.50 \text{ mA}$ | | 10 | 18 | ns | Fig. 2 |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}, f = 100 \text{ MHz}$ | 5.0 | 6.5 | | | |
| C_{cb} | $V_{CB} = 5 \text{ V}$ | | 2.0 | 4.0 | pF | TO-18 |
| C_{eb} | $V_{EB} = 0.5 \text{ V}$ | | 4.0 | 5.0 | pF | TO-18 |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 1 \text{ V}$ | 30 | 65 | 150 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 1 \text{ V}$ | 30 | 70 | 150 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 1 \text{ V}$ | 25 | 55 | 150 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 30 | 150 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 0.35 \text{ V}$ | 30 | 65 | 150 | | |
| h_{FE} | $I_C = 30 \text{ mA}, V_{CE} = 0.4 \text{ V}$ | 30 | 60 | 150 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.15 | 0.2 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.35 | 0.5 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.80 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 1.0 | 1.5 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 12 | 15 | 19 | V | |
| BV_{CBO} | $I_C = 10 \mu\text{A}$ | 50 | 55 | 60 | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.5 | | | V | |
| I_{CBO} | $V_{CB} = 25 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3 \text{ V}$ | | | 50 | nA | |

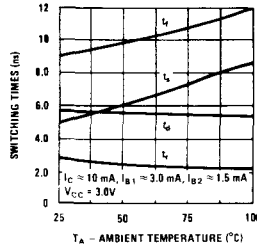


Process 21

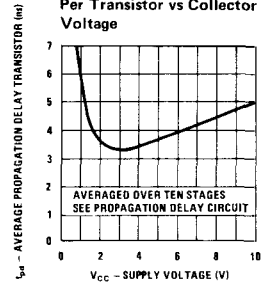
Switching Times vs Collector Current



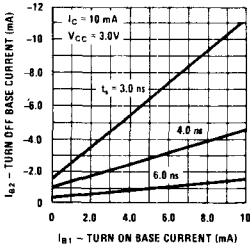
Switching Times vs Ambient Temperature



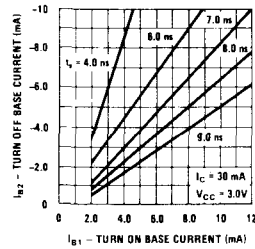
Average Propagation Delay Per Transistor vs Collector Voltage



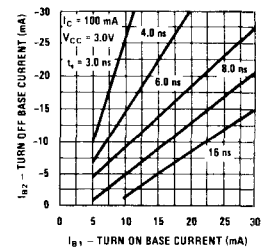
Storage Time vs Turn On and Turn Off Base Currents



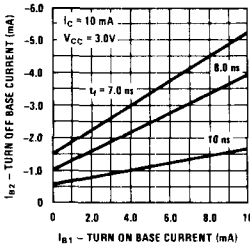
Storage Time vs Turn On and Turn Off Base Currents



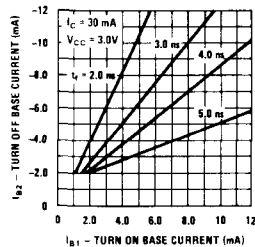
Storage Time vs Turn On and Turn Off Base Currents



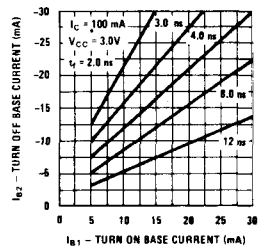
Fall Time vs Turn On and Turn Off Base Current



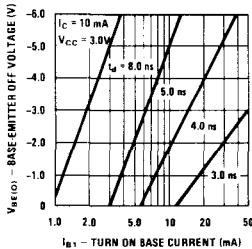
Fall Time vs Turn On and Turn Off Base Currents



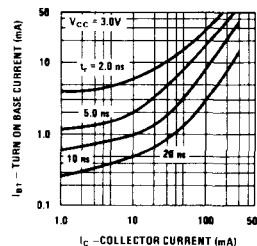
Fall Time vs Turn On and Turn Off Base Currents

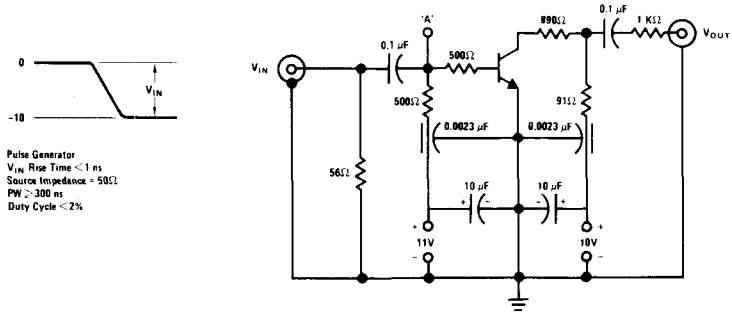


Delay Time vs Base Emitter Off Voltage and Turn On Base Current

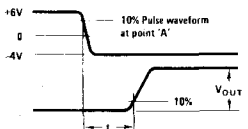


Rise Time vs Turn On Base Current and Collector Current



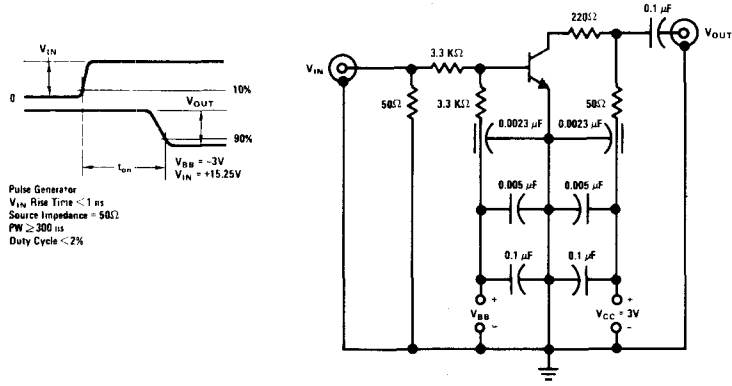


Pulse Generator
 V_{IN} Rise Time < 1 ns
 Source Impedance = 50Ω
 $PW > 300$ ns
 Duty Cycle $< 2\%$

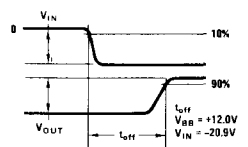


To Sampling Oscilloscope
 Input Impedance = 50Ω
 Rise Time ≤ 1 ns

FIGURE 1. Charge Storage Time Measurement Circuit

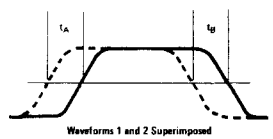
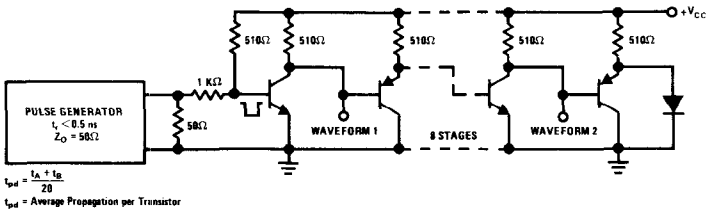


Pulse Generator
 V_{IN} Rise Time < 1 ns
 Source Impedance = 50Ω
 $PW \geq 300$ ns
 Duty Cycle $< 2\%$



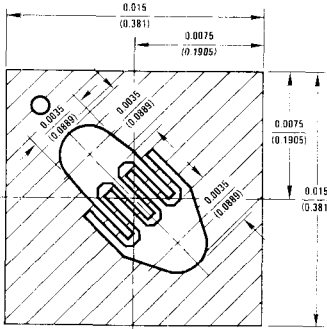
To Sampling Oscilloscope
 Input Impedance = 50Ω
 Rise Time ≤ 1 ns

FIGURE 2. t_{ON} , t_{OFF} Measurement Circuit



$t_{pd} = \frac{t_a + t_b}{20}$
 t_{pd} = Average Propagation per Transistor

FIGURE 3. Circuit For Measurement of Propagation Delay


DESCRIPTION

Process 22 is an overlay, double diffused, gold doped silicon epitaxial device. Complement to Process 64.

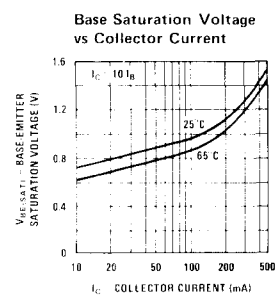
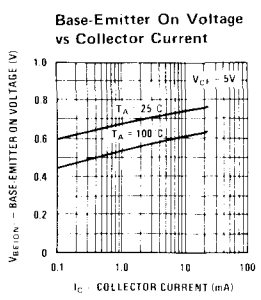
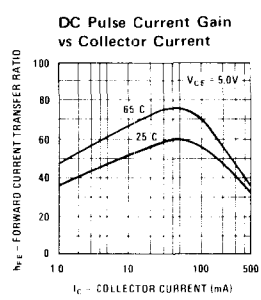
APPLICATION

This device was designed for high speed logic and core driver applications to 300 mA.

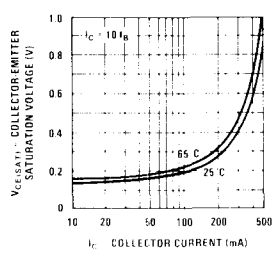
PRINCIPAL DEVICE TYPES

TO-52 2N3013
TO-92 2N5772

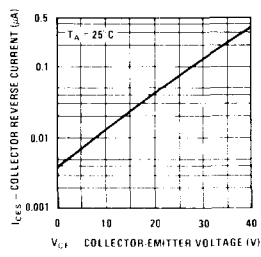
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|--------|
| t_s | $I_C = 10 \text{ mA}, I_{B1} = I_{B2} = 10 \text{ mA}$ | | 12 | 18 | ns | Fig. 1 |
| t_{on} | $I_C = 300 \text{ mA}, I_{B1} = I_{B2} = 30 \text{ mA}$ | | 10 | 18 | ns | Fig. 2 |
| t_{off} | $I_C = 300 \text{ mA}, I_{B1} = I_{B2} = 30 \text{ mA}$ | | 18 | 30 | ns | |
| C_{ob} | $V_{CB} = 5V$ | | 3.2 | 5.0 | pF | TO-18 |
| C_{ob} | $V_{EB} = 0.5V$ | | 6.2 | 8.0 | pF | TO-18 |
| h_{fe} | $I_C = 30 \text{ mA}, V_{CE} = 10V, f = 100 \text{ MHz}$ | 3.5 | 7.0 | 10 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 10 \text{ mA}$ | 20 | 50 | 150 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 30 \text{ mA}$ | 20 | 50 | 150 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 100 \text{ mA}$ | 20 | 48 | 150 | | |
| h_{FE} | $V_{CE} = 1V, I_C = 300 \text{ mA}$ | 15 | 30 | 120 | | |
| h_{FE} | $V_{CE} = 0.4V, I_C = 30 \text{ mA}$ | 20 | 50 | 150 | | |
| h_{FE} | $V_{CE} = 0.5V, I_C = 100 \text{ mA}$ | 20 | 50 | 150 | | |
| $V_{CE(SAT)}$ | $I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$ | | 0.14 | 0.20 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.20 | 0.28 | V | |
| $V_{CE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 0.40 | 0.50 | V | |
| $V_{BE(SAT)}$ | $I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$ | | 0.80 | 0.95 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.92 | 1.2 | V | |
| $V_{BE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 1.1 | 1.7 | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 40 | 50 | | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 15 | 18 | | V | |
| BV_{EBO} | $I_E = 100 \mu A$ | 5.0 | 5.7 | | V | |
| I_{CBO} | $V_{CB} = 20V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3V$ | | | 50 | nA | |



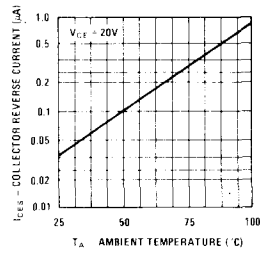
Collector Saturation Voltage vs Collector Current



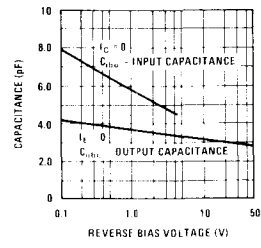
Collector Reverse Current vs Reverse Bias Voltage



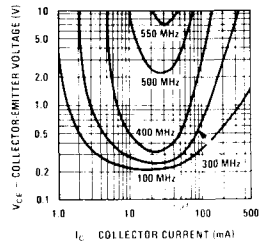
Collector Reverse Current vs Ambient Temperature



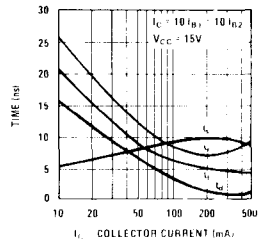
Input and Output Capacitance vs Reverse Bias Voltage



Contours of Constant Gain Bandwidth Product (f τ)

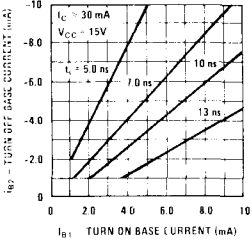


Switching Times vs Collector Current

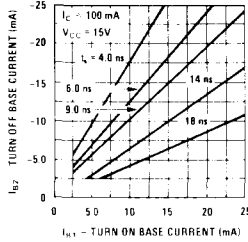


Process 22

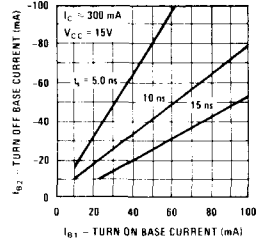
Storage Time vs Turn On and Turn Off Base Currents



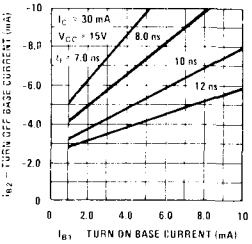
Storage Time vs Turn On and Turn Off Base Currents



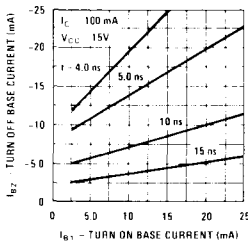
Storage Time vs Turn On and Turn Off Base Currents



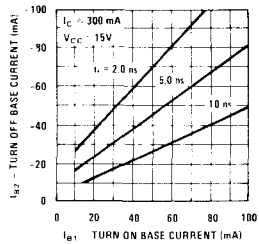
Fall Time vs Turn On and Turn Off Base Currents



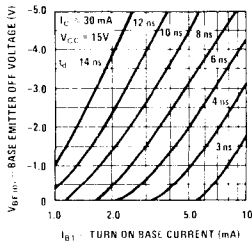
Fall Time vs Turn On and Turn Off Base Currents



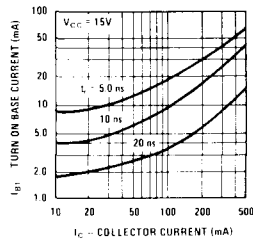
Fall Time vs Turn On and Turn Off Base Currents



Delay Time vs Base Emitter Off Voltage and Turn On Base Current



Rise Time vs Collector and Turn On Base Currents



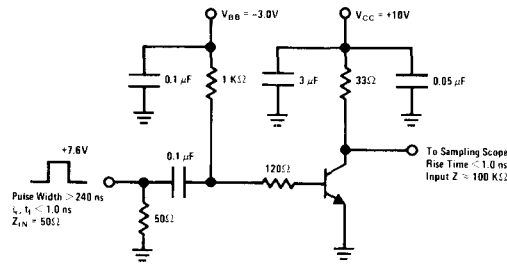
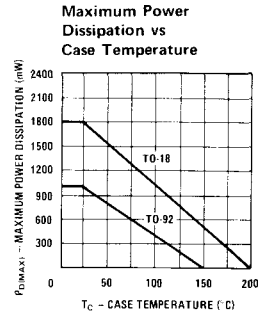
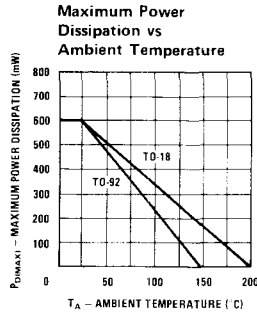
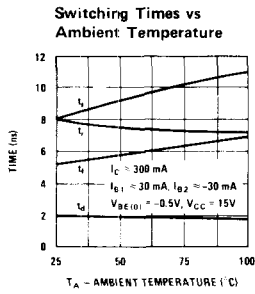


FIGURE 1. t_{on} , t_{off} Test Circuit

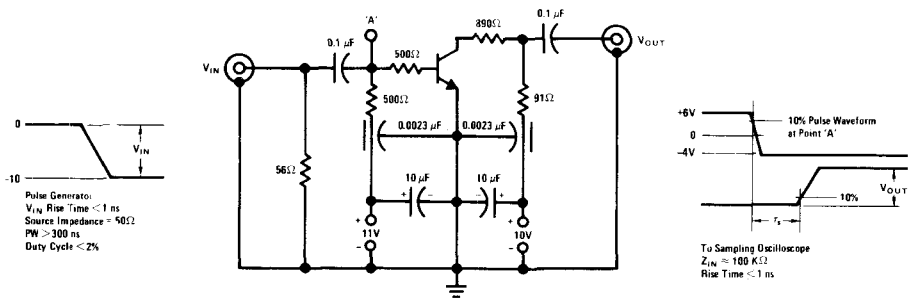
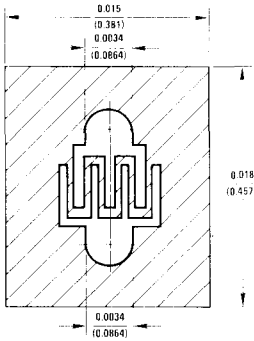


FIGURE 2. Charge Storage Time Measurement Circuit


DESCRIPTION

Process 23 is an overlay, double diffused gold doped silicon epitaxial device. Complement to Process 66.

APPLICATION

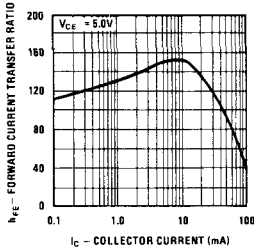
This device is designed as general purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

PRINCIPAL DEVICE TYPES

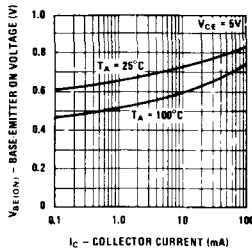
TO-18 NS3904
TO-92 2N3904

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|--------|
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | | 30 | 70 | ns | Fig. 1 |
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | | 150 | 250 | ns | Fig. 2 |
| C_{ob} | $V_{CB} = 5 \text{ V}, f = 1 \text{ MHz}$ | | 2.7 | 4.0 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.5 \text{ V}, f = 1 \text{ MHz}$ | | 5.5 | 8.0 | pF | TO-18 |
| NF | $V_{CE} = 5 \text{ V}, I_C = 100 \mu\text{A}, R_S = 1 \text{ k}\Omega,$ $P_{BW} = 15.7 \text{ kHz}$ | | 2.0 | 5.0 | dB | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V}, f = 100 \text{ MHz}$ | 2.0 | 5.0 | 7.0 | | |
| h_{FE} | $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$ | 40 | 100 | 300 | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V}$ | 70 | 150 | 300 | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}$ | 50 | 150 | 350 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 5 \text{ V}$ | 30 | 120 | 200 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 5 \text{ V}$ | 20 | 50 | 100 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.07 | 0.10 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.70 | 0.80 | V | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.10 | 0.15 | V | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.75 | 0.85 | V | |
| BV_{CBO} | $I_C = 10 \mu\text{A}$ | 60 | 90 | 120 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 30 | 40 | 50 | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 6.0 | | 8.0 | V | |
| I_{CBO} | $V_{CB} = 25 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4 \text{ V}$ | | | 50 | nA | |

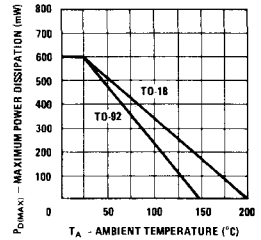
Pulsed DC Current Gain vs Collector Current



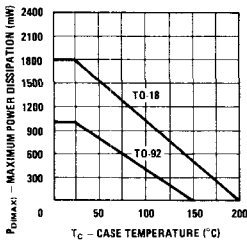
Base-Emitter On Voltage vs Collector Current



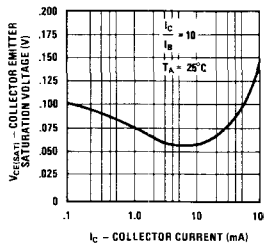
Maximum Power Dissipation vs Ambient Temperature



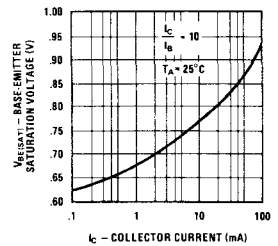
Maximum Power Dissipation vs Case Temperature



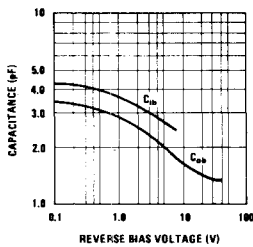
VCE(SAT) vs IC



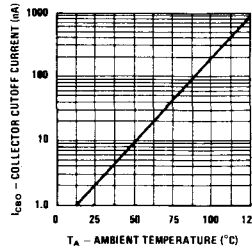
VBE(SAT) vs IC



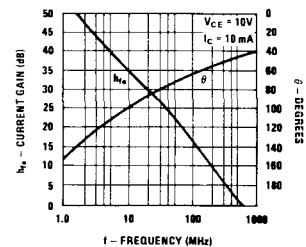
Capacitance vs Reverse Bias Voltage



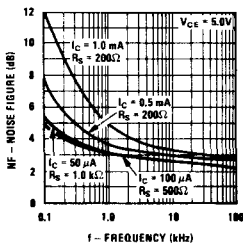
Collector Cutoff Current vs Ambient Temperature



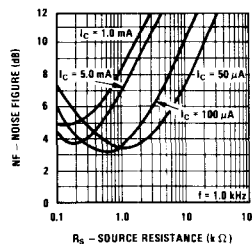
Current Gain and Phase Angle vs Frequency



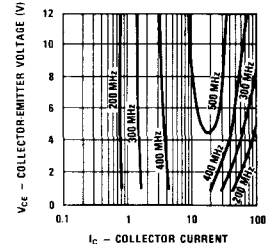
Noise Figure vs Frequency



Noise Figure vs Source Resistance

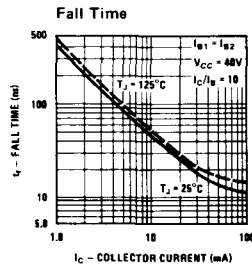
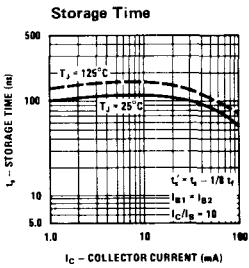
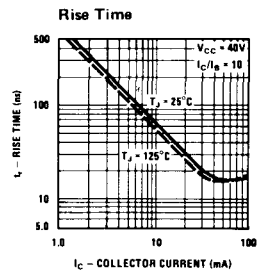
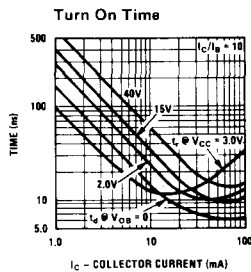
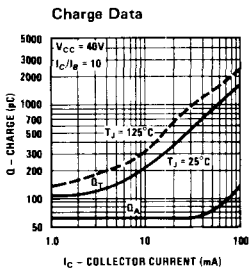
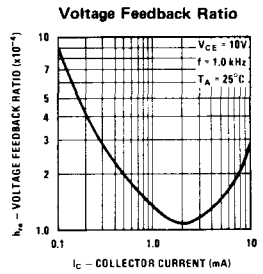
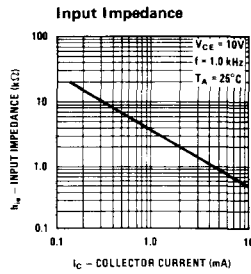
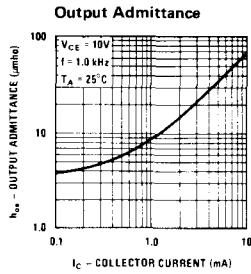
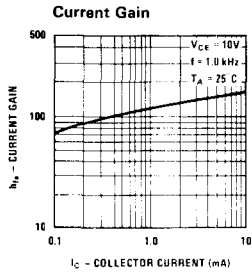


Contours of Constant Gain Bandwidth Product (fT)



Process 23

h PARAMETERS ($V_{CE} = 10 V_{DC}$, $f = 1.0 \text{ kHz}$, $T_A = 25^\circ\text{C}$)



TRANSIENT CHARACTERISTICS ($-T_J = 25^\circ\text{C} \dots T_J = 125^\circ\text{C}$)

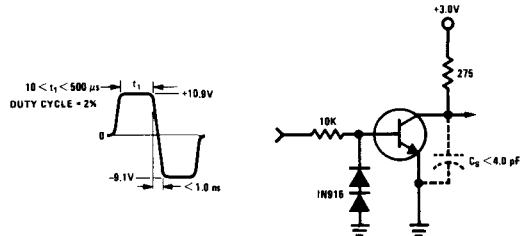
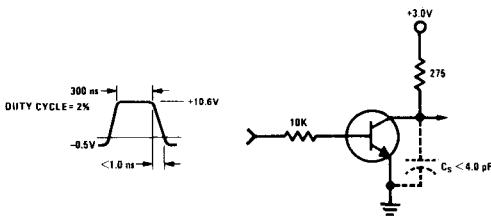
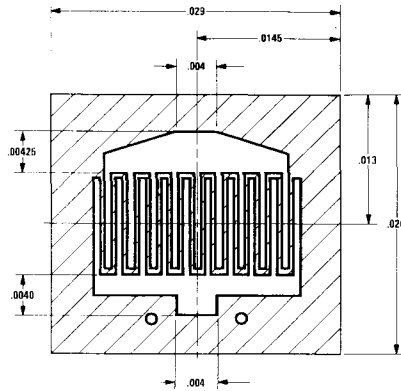


FIGURE 1. Delay and Rise Time Equivalent Test Circuit

FIGURE 2. Storage and Fall Time Equivalent Test Circuit



DESCRIPTION

Process 25 is an overlay double diffused, gold doped silicon epitaxial device. Complement to Process 70.

APPLICATION

This device was designed for high speed core driver applications.

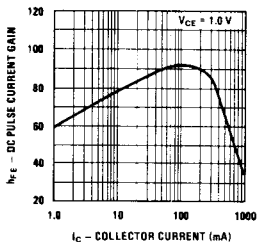
PRINCIPAL DEVICE TYPES

| | |
|--------|--------|
| TO-18 | 2N4014 |
| TO-39 | 2N3725 |
| TO-92+ | TN3725 |

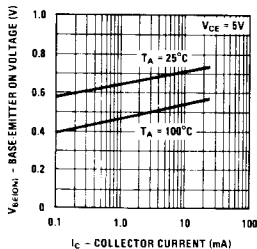
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|-------|------|---------------|--------|
| t_{on} | $I_C = 500 \text{ mA}, I_{B1} = 50 \text{ mA}$ | | 12 | 35 | ns | Fig. 1 |
| t_{off} | $I_C = 500 \text{ mA}, I_{B2} = 50 \text{ mA}$ | | 50 | 60 | ns | Fig. 1 |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}, f = 100 \text{ MHz}$ | 2.5 | 4.25 | | | |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 5.5 | 10 | pF | |
| C_{eb} | $V_{EB} = 0.5 \text{ V}$ | | 45 | 55 | pF | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 1 \text{ V}$ | 40 | 60 | 120 | | |
| h_{fe} | $I_C = 100 \text{ mA}, V_{CE} = 1 \text{ V}$ | 45 | 90 | 150 | | |
| h_{fe} | $I_C = 300 \text{ mA}, V_{CE} = 1 \text{ V}$ | 35 | 65 | 120 | | |
| h_{fe} | $I_C = 500 \text{ mA}, V_{CE} = 1 \text{ V}$ | 25 | 50 | 100 | | |
| h_{fe} | $I_C = 800 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 28 | 40 | | |
| h_{fe} | $I_C = 1 \text{ A}, V_{CE} = 1 \text{ V}$ | 15 | 25 | 35 | | |
| h_{fe} | $I_C = 800 \text{ mA}, V_{CE} = 2 \text{ V}$ | 25 | 38 | 60 | | |
| h_{fe} | $I_C = 1 \text{ A}, V_{CE} = 5 \text{ V}$ | 25 | 40 | 60 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.155 | 0.20 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.155 | 0.20 | V | |
| $V_{CE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 0.240 | 0.40 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.350 | 0.50 | V | |
| $V_{CE(SAT)}$ | $I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$ | | 0.50 | 0.80 | V | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ A}, I_B = 100 \text{ mA}$ | | 0.70 | 1.20 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.66 | 0.70 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.77 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$ | | 0.88 | 1.20 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.95 | 1.20 | V | |
| $V_{BE(SAT)}$ | $I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$ | | 1.10 | 1.50 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ A}, I_B = 100 \text{ mA}$ | | 1.18 | 1.70 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 40 | 45 | 50 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 80 | 100 | 130 | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 6.0 | | | V | |
| I_{CBO} | $V_{CB} = 40 \text{ V}$ | | | 1.0 | μA | |
| I_{EBO} | $V_{EB} = 4 \text{ V}$ | | | 1.0 | μA | |

Process 25

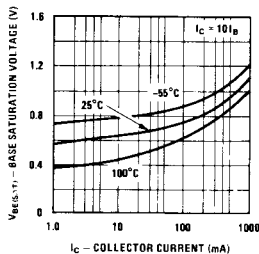
DC Pulse Current Gain vs Collector Current



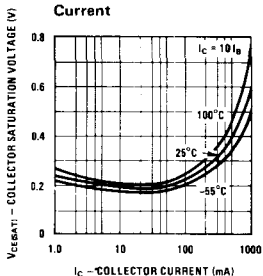
Base-Emitter On Voltage vs Collector Current



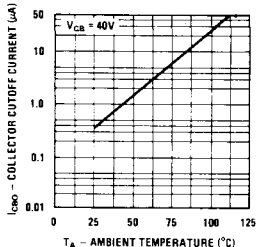
Base Saturation Voltage vs Collector Current



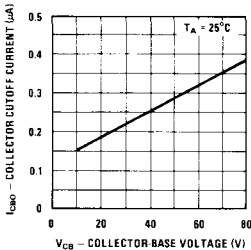
Collector Saturation Voltage vs Collector Current



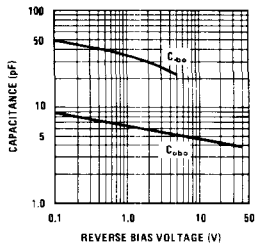
Collector Cutoff Current vs Ambient Temperature



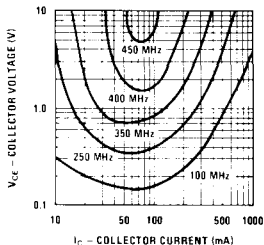
Collector Cutoff Current vs Reverse Bias Voltage



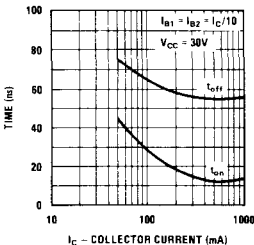
Input and Output Capacitance vs Reverse Bias



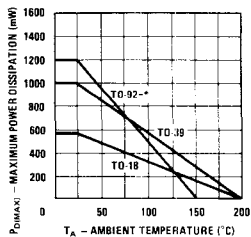
Contours of Constant Bandwidth Product (fT)



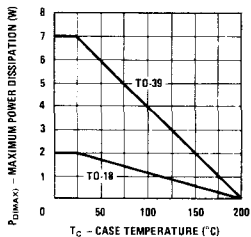
Turn On and Turn Off Times vs Collector Current



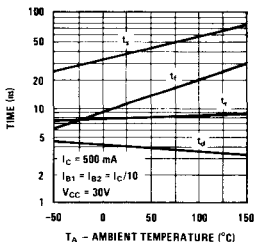
Maximum Power Dissipation vs Ambient Temperature



Maximum Power Dissipation vs Case Temperature

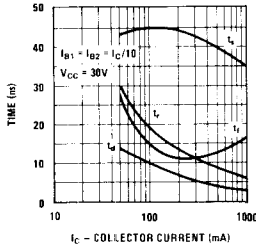


Switching Times vs Ambient Temperature

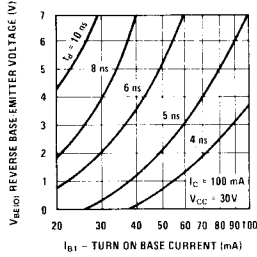


*One square inch of copper run

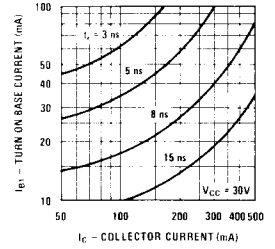
Switching Times vs Collector Current



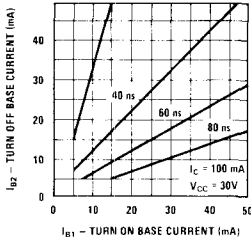
Delay Time vs Turn On Reverse Base Emitter Voltage



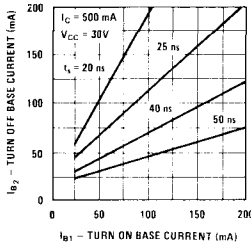
Rise Time vs Collector and Turn On Base Currents



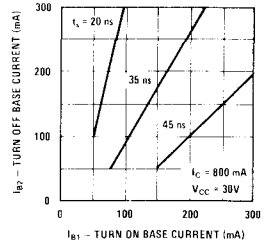
Storage Time vs Turn On and Turn Off Base Currents



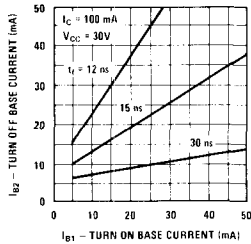
Storage Time vs Turn On and Turn Off Base Currents



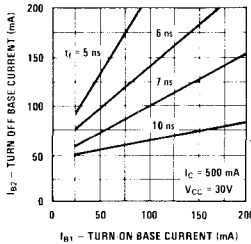
Storage Time vs Turn On and Turn Off Base Currents



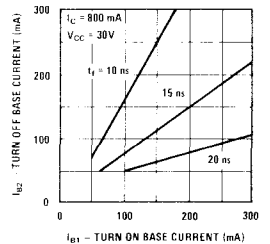
Fall Time vs Turn On and Turn Off Base Currents



Fall Time vs Turn On and Turn Off Base Currents



Fall Time vs Turn On and Turn Off Base Currents



SWITCHING TIME TEST CIRCUIT

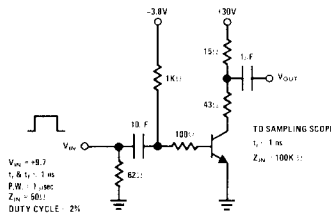
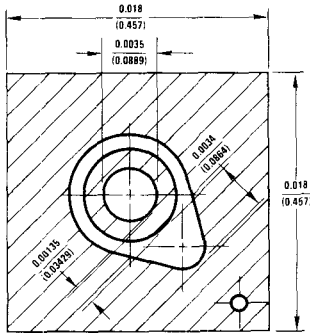


FIGURE 1. $I_C \approx 500 \text{ mA}$, $I_{B1} \approx 50 \text{ mA}$, $I_{B2} \approx -50 \text{ mA}$


DESCRIPTION

Process 27 is a nonoverlay, double diffused, silicon epitaxial device. Complement to Process 69.

APPLICATION

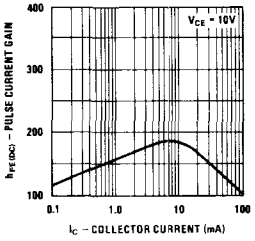
This device is designed for general purpose amplifier and switch applications, useful from audio to RF frequencies.

PRINCIPAL DEVICE TYPES

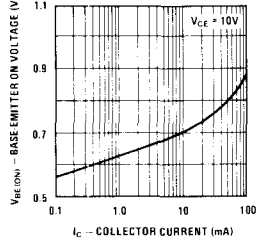
TO-18 2N915
TO-92 MPSA20 (EBC)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|----------------|---|-----|-------|------|-------|-------|
| NF (wide band) | $V_{CE} = 5V, I_C = 100 \mu A, f_{BW} = 15.7 \text{ kHz}$ | | 1.5 | | dB | |
| NF (spot) | $V_{CE} = 5V, I_C = 100 \mu A, f = 1 \text{ kHz}$ $R_S = 1k$ | | 1.5 | 3.0 | dB | |
| C_{cb} | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 2.0 | 2.5 | pF | TO-18 |
| C_{ob} | $V_{CB} = 10V, f = 1 \text{ MHz}$ | | 2.5 | 3.0 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.50V, f = 1 \text{ MHz}$ | | 5.5 | 7.0 | pF | TO-18 |
| f_T | $V_{CE} = 10V, I_C = 10 \text{ mA}$ | 100 | 500 | | MHz | |
| t_{on} | $V_{CE} = 10V, I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | 30 | 40 | 50 | ns | |
| t_{off} | $V_{CE} = 10V, I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | 400 | 600 | 700 | ns | |
| h_{FE} | $V_{CE} = 10V, I_C = 100 \mu A$ | 40 | 115 | 340 | | |
| h_{FE} | $V_{CE} = 10V, I_C = 1 \text{ mA}$ | 50 | 150 | 450 | | |
| h_{FE} | $V_{CE} = 10V, I_C = 10 \text{ mA}$ | 62 | 185 | 560 | | |
| h_{FE} | $V_{CE} = 10V, I_C = 50 \text{ mA}$ | 45 | 130 | 400 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.055 | 0.10 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.770 | 1.0 | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 50 | 70 | | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 30 | 45 | 60 | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 5.0 | 6.5 | | V | |
| I_{CBO} | $V_{CB} = 40$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4.0$ | | | 50 | nA | |

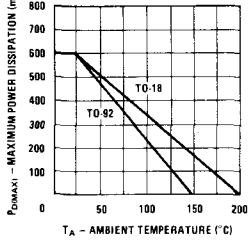
DC Pulse Current Gain vs Collector Current



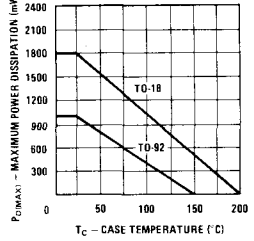
Base-Emitter On Voltage vs Collector Current



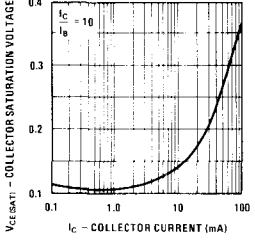
Maximum Power Dissipation vs Ambient Temperature



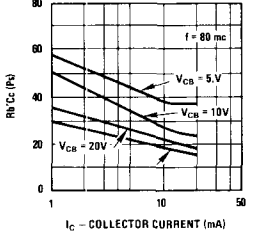
Maximum Power Dissipation vs Case Temperature



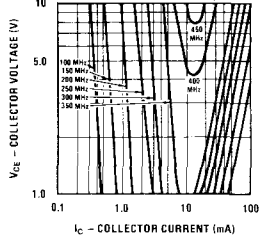
Collector-Emitter Saturation Voltage vs Collector Current



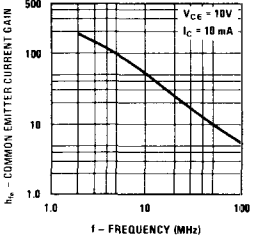
Rb'Cc vs Collector Current



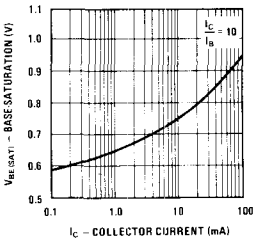
Small Signal Current Gain vs Collector Current



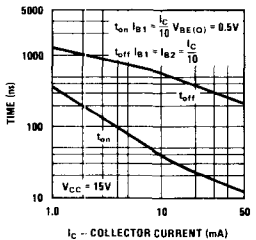
Small Signal Current Gain vs Frequency



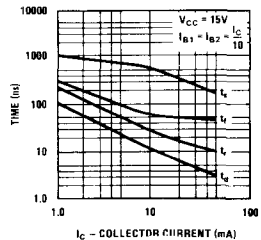
Base Saturation Voltage vs Collector Current



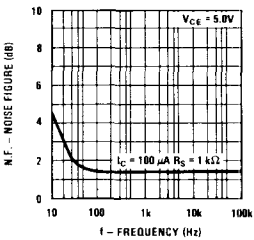
ton And toff vs Collector Current



Switching Times vs Collector Current

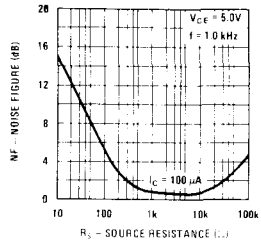


Noise Figure vs Frequency

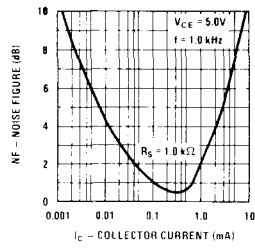


Process 27

Noise Figure vs Source Resistance

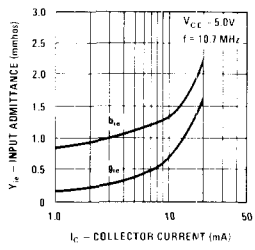


Noise Figure vs Collector Current

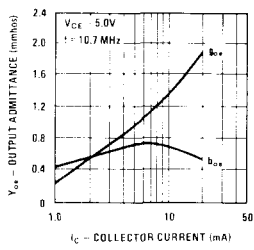


COMMON EMITTER Y PARAMETERS

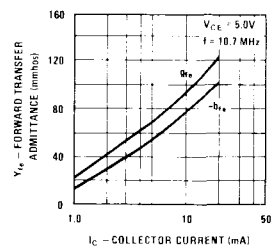
Input Admittance vs Collector Current



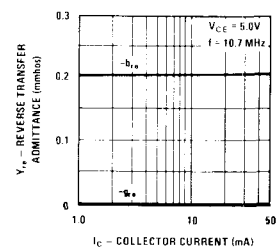
Output Admittance vs Collector Current



Forward Transfer Admittance vs Collector Current

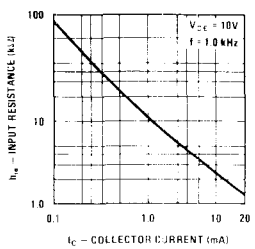


Reverse Transfer Admittance vs Collector Current

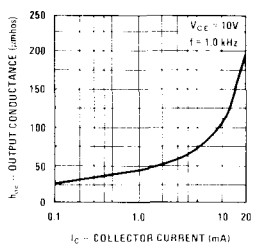


COMMON EMITTER H PARAMETERS

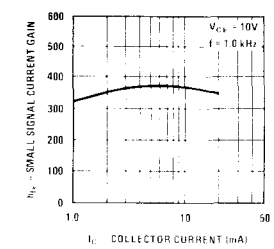
Small Signal Input Resistance vs Collector Current



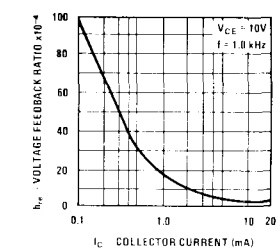
Small Signal Output Conductance vs Collector Current



Small Signal Current Gain vs Collector Current



Small Signal Voltage Feedback Ratio vs Collector Current



DESCRIPTION

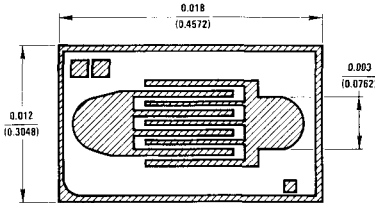
Process 29 is an overlay double diffused, silicon epitaxial device.

APPLICATION

This device was designed for use in high frequency receiver front end designs requiring good NF from low driving R_S .

PRINCIPAL DEVICE TYPES

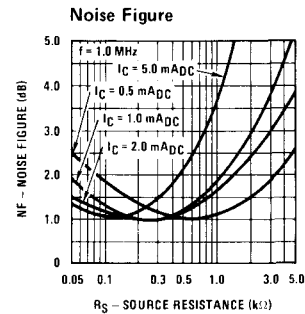
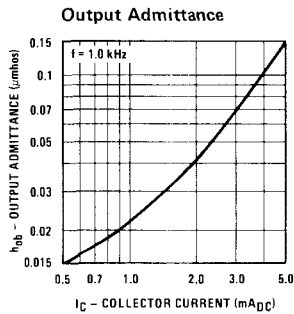
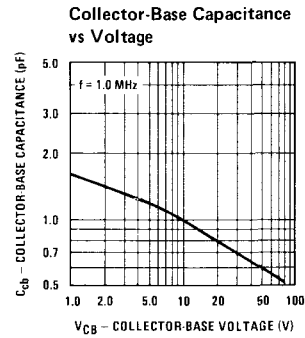
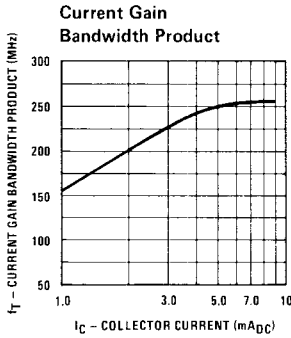
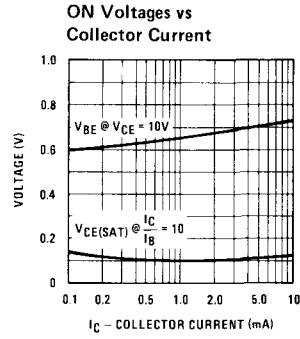
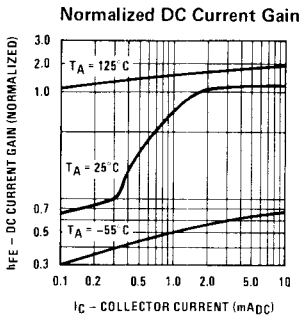
TO-92-MPS



| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|--|-----|------|------|-----------------|
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 80 | | | V |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 80 | | | V |
| BV_{EBO} | $I_E = 100 \mu\text{A}$ | 4.0 | | | V |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 50 | nA |
| I_{EBO} | $V_{EB} = 3.0\text{V}$ | | | 50 | nA |
| H_{FE} | $V_{CE} = 10\text{V}, I_C = 1.5 \text{ mA}$ | 30 | 70 | 150 | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.12 | 0.25 | V |
| f_t | $V_{CE} = 10\text{V}, I_C = 1.5 \text{ mA}, f = 100 \text{ MHz}$ | 80 | 180 | | MHz |
| C_{cb} | $V_{CB} = 10\text{V}$ | | 1.0 | 1.6 | pF |
| h_{oe} | $I_C = 1.5 \text{ mA}, V_{CE} = 10\text{V}, f = 1.0 \text{ kHz}$ | | 2.0 | 5.0 | μmho |
| NF | $I_C = 1.5 \text{ mA}, V_{CE} = 10\text{V}, R_S = 50\Omega, f = 1.0 \text{ MHz}$ | | 1.7 | 2.0 | dB |

$V_{CE} = 10V$, $T_A = 25^\circ C$ unless otherwise noted

Process 29





Process 35 NPN RF-HF Power Amplifier

DESCRIPTION

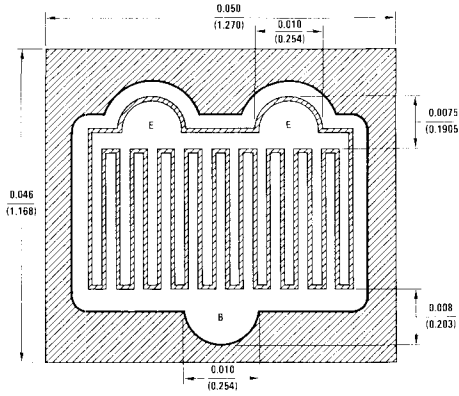
Process 35 is a double diffused silicon epitaxial device.

APPLICATION

This device is designed for use in the output stage of 4W AM Citizens Band (27 MHz) transmitters with capabilities to withstand infinite VSWR at rated output.

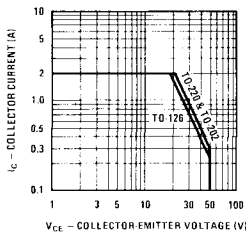
PRINCIPAL DEVICE TYPES

| | |
|--------|---------|
| TO-39 | MRF8004 |
| TO-126 | MRF472 |
| TO-220 | 2SC1678 |

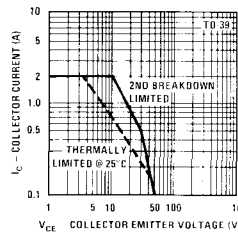


| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|------------|---|-----|-----|-----|---------|
| P_{OUT} | $f = 27 \text{ MHz}$, $I_C (\text{Avg}) = 415 \text{ mA}$, (Figure 1) | 3.0 | 3.5 | | W |
| η | $V_{CC} = 12V$, $P_{IN} = 0.4W$ | 60 | 70 | | % |
| h_{fe} | $I_C = 100 \text{ mA}$, $V_{CE} = 5V$, $f = 20 \text{ MHz}$ | 6.0 | 12 | | |
| C_{ob} | $V_{CB} = 10V$ | | 25 | 35 | pF |
| H_{FE} | $I_C = 100 \text{ mA}$, $V_{CE} = 1V$ | 30 | 70 | 150 | |
| V_{CES} | $I_C = 1.0A$, $I_B = 100 \text{ mA}$ | | 0.2 | 0.5 | V |
| BV_{CER} | $I_C = 1 \text{ mA}$, $R_{BE} = 10\Omega$ | 65 | | | V |
| BV_{EBO} | $I_E = 100 \mu A$ | 3 | | | V |
| I_{CBO} | $V_{CB} = 40V$ | | | 10 | μA |
| I_{CEO} | $V_{CE} = 40V'$ | | | 100 | μA |
| I_{EBO} | $V_{EB} = 2.0V$ | | | 10 | μA |
| SOA | $V_{CE} = 30V$, $t = 1 \text{ sec}$ | 500 | | | mA |

Safe Operating Area Curve

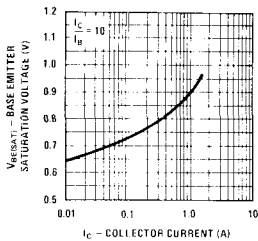


Safe Operating Area Curve

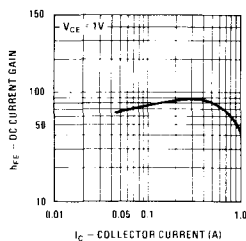


Process 35

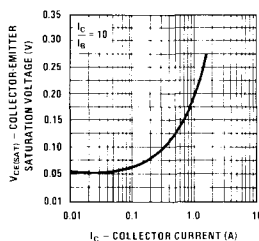
Base-Emitter Saturation Voltage vs Collector Current



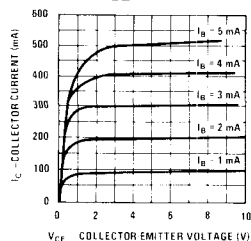
DC Current Gain vs Collector Current



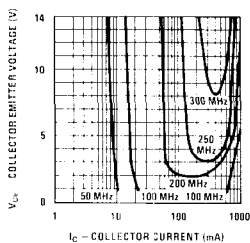
Collector-Emitter Saturation Voltage vs Collector Current



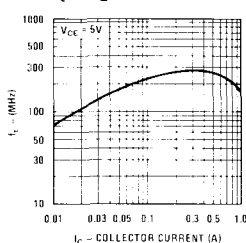
I_C vs V_{CE}



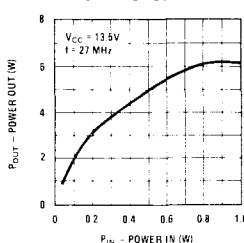
Contours of Constant Gain Bandwidth Product (f_t)



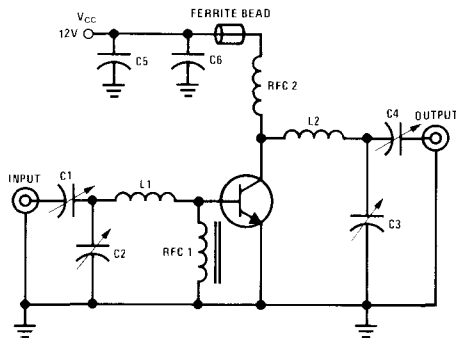
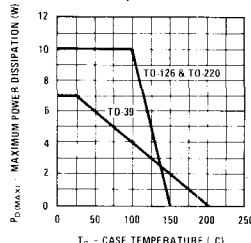
f_t vs I_C



Power In vs Power Out



Maximum Power Dissipation vs Case Temperature



- C1, C2 - 9.0-180 pF ARCO 463
- C3, C4 - 5.0-80 pF ARCO 462
- C5 - 0.01-F Disc
- C6 - 0.1-F Disc
- RFC 1 - 4 turns No. 32 enameled wire wound on Indiana General Bead No. 57-1692
- RFC 2 - 15 μH choke, J.W. Miller #4624
- L1 - 0.22 μH molded choke
- L2 - 1 μH molded choke

FIGURE 1. 27 MHz Test Circuit

DESCRIPTION

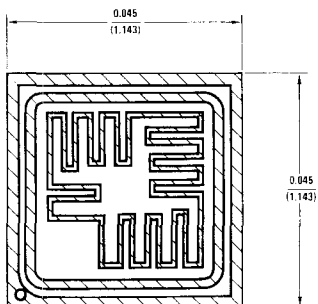
Process 36 a non-overlay double-diffused silicon epitaxial device.

APPLICATION

This device is designed for use in horizontal driver, class A off-line amplifier and off-line switching applications.

PRINCIPAL DEVICE TYPES

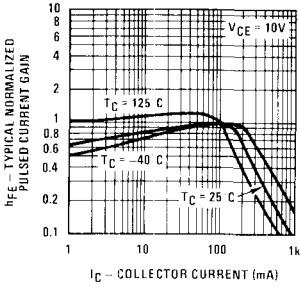
| | | |
|--------|--------|--------|
| 2N5655 | MJE340 | MJE343 |
| 2N5656 | MJE341 | MJE344 |
| 2N5657 | MJE342 | |



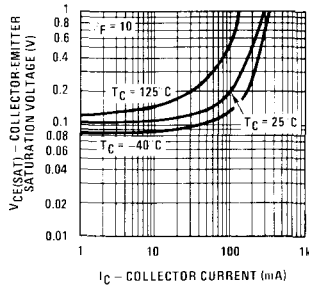
| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|--|-----|-------|------|----------------------|
| BV_{CEO} | $I_{CE} = 1 \text{ mA}^*$ | 200 | 300 | | V |
| BV_{CBO} | $I_{CB} = 100 \mu\text{A}$ | 225 | 325 | | V |
| BV_{EBO} | $I_{EB} = 10 \mu\text{A}$ | 6 | | | V |
| I_{CEO} | $V_{CE} = 200\text{V}$ | | | 50 | μA |
| I_{CBO} | $V_{CB} = 225\text{V}$ | | | 1 | μA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | | 1 | μA |
| H_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 10\text{V}^*$ | 25 | 190 | | |
| | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}^*$ | 30 | 200 | 300 | |
| | $I_C = 250 \text{ mA}, V_{CE} = 10\text{V}^*$ | 15 | 60 | | |
| | $I_C = 500 \text{ mA}, V_{CE} = 10\text{V}^*$ | 10 | 25 | | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}^*$ | | 0.08 | 0.5 | V |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 100 \text{ mA}^*$ | | 0.175 | 0.5 | V |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 100 \text{ mA}^*$ | | 0.9 | 1.2 | V |
| $V_{BE(ON)}$ | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}^*$ | | 0.7 | 1.0 | V |
| f_t | $I_C = 50 \text{ mA}, V_{CE} = 10\text{V}, f = 20 \text{ MHz}$ | 10 | 60 | | MHz |
| C_{ob} | $V_{CB} = 10\text{V}$ | | | 15 | pF |
| C_{ib} | $V_{BE} = 0.5\text{V}$ | | | 125 | pF |
| I_{SB} | $V_{CE} = 100\text{V}, T = 1 \text{ second}$ | 200 | | | mA |
| $P_D(\text{MAX})$ | TO-126 | | | 25 | W |
| | TO-202 | | | 15 | W |
| θ_{jc} | TO-126 | | | 5.0 | $^{\circ}\text{C/W}$ |
| | TO-202 | | | 8.33 | $^{\circ}\text{C/W}$ |
| θ_{jA} | TO-202 | | | 69.4 | $^{\circ}\text{C/W}$ |

*Pulse test, pulse width = 300 μs

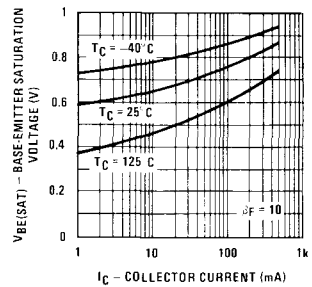
Typical Normalized Pulsed Current Gain vs Collector Current



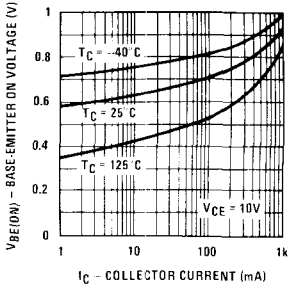
Collector-Emitter Saturation Voltage vs Collector Current



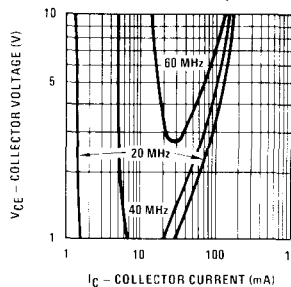
Base-Emitter Saturation Voltage vs Collector Current



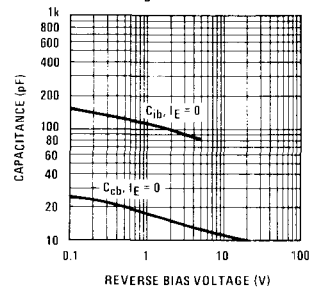
Base-Emitter ON Voltage vs Collector Current



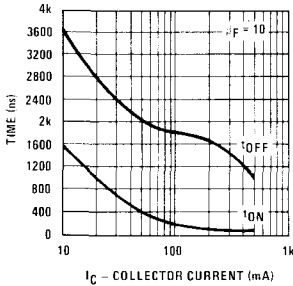
Contours of Constant Gain Bandwidth Product (f_t)



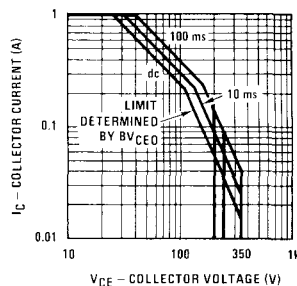
Collector-Base and Emitter-Base Capacitance vs Reverse Bias Voltage



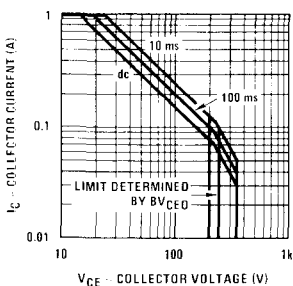
Typical Switching Time vs Collector Current



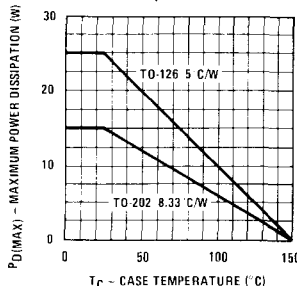
Safe Operating Area TO-126



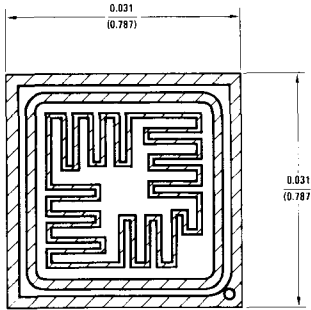
Safe Operating Area TO-202



Maximum Power Dissipation vs Case Temperature



Process 37 NPN Medium Power



DESCRIPTION

Process 37 is a double diffused silicon epitaxial planar device. Complement to Process 77.

APPLICATION

This device was designed for general purpose medium power amplifiers and switching circuits that require collector currents to 1A.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|------|-----|---------------|
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 25 | | 45 | V |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 50 | | | V |
| BV_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | 7 | | V |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | 50 | 500 | nA |
| I_{EBO} | $V_{EB} = 5 \text{ V}$ | | 0.1 | 100 | μA |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 1 \text{ V}$ | 100 | | 400 | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ A}, I_B = 0.1 \text{ A}$ | | 0.2 | 0.5 | V |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ A}, I_B = 0.1 \text{ A}$ | | 0.95 | 1.5 | V |
| f_T | $I_C = 100 \text{ mA}, V_{CE} = 10 \text{ V}$ | | 300 | | MHz |
| C_{OBO} | $V_{CB} = 10 \text{ V}$ | | | 20 | pF |

PRINCIPAL DEVICE TYPES

TO-202 (Package 35) 92 PLUS (Package 91)

NSD102 92PU01
NSD103 92PU01A

NSDU01
NSDU01A TO-126 (Package 38)

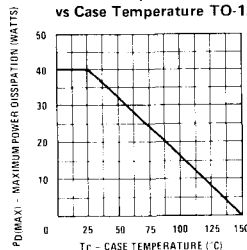
TO-202 (Package 36)
BD135

D42C1
D42C2
D42C3
D42C4
D42C5
D42C6
NSE180

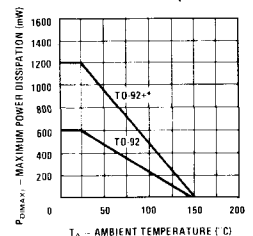
92 PLUS (Package 90)

92PE37A
BD373A

Power Dissipation vs Case Temperature TO-126

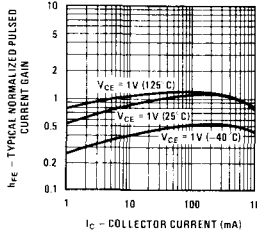


Maximum Power Dissipation vs Ambient Temperature

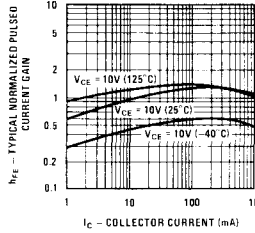


*One square inch of copper run

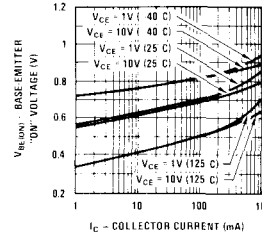
Typical Normalized Pulsed Current Gain vs Collector Current



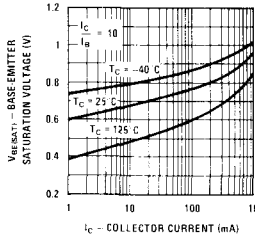
Typical Normalized Pulsed Current Gain vs Collector Current



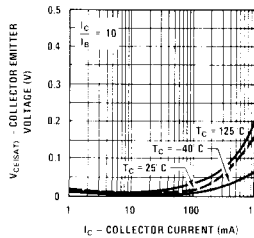
Base-Emitter "ON" Voltage vs Collector Current



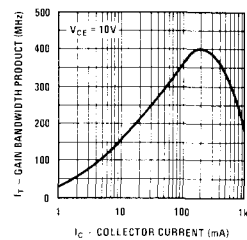
Base-Emitter Saturation Voltage vs Collector Current



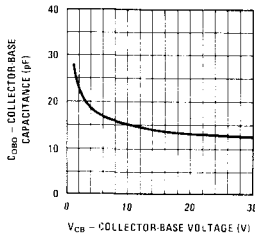
Collector-Emitter Voltage vs Collector Current



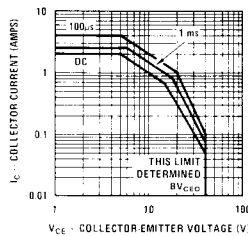
Gain Bandwidth Product vs Collector Current



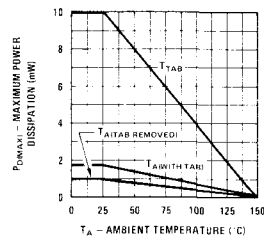
Collector-Base Capacitance vs Collector-Base Voltage



Safe Operating Area TO-202



Maximum Power Dissipation vs Ambient Temperature (TO-202)

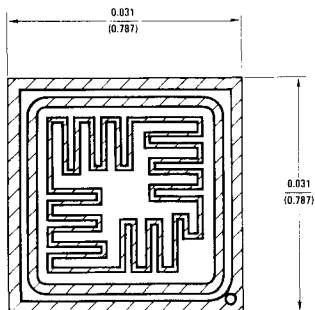


DESCRIPTION

Process 38 is a double diffused silicon epitaxial planar device. Complement to Process 78.

APPLICATION

This device was designed for general purpose medium power amplifier and switching circuits that require collector currents to 1A.



| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|-----|-----|---------------|
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 45 | | 80 | V |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 90 | | 160 | V |
| BV_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | 7 | | V |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | 50 | 500 | nA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | 0.1 | 100 | μA |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1\text{V}$ | 150 | | 500 | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.2 | 0.5 | V |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.8 | 1.4 | V |
| f_T | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}$ | | 250 | | MHz |
| C_{OBO} | $V_{CB} = 10\text{V}$ | | | 15 | pF |

PRINCIPAL DEVICE TYPES

TO-202 (Package 35) 92 PLUS (Package 91)

| | |
|---------|--------|
| NSDU05 | 92PU05 |
| NSD6178 | BD371B |
| NSD6179 | BD371C |

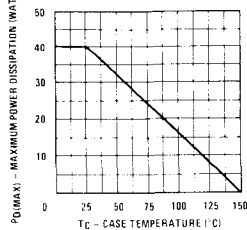
TO-202 (Package 36) TO-126 (Package 38)

| | |
|--------|-------|
| D42C7 | BD137 |
| D42C8 | |
| D42C9 | |
| NSE181 | |

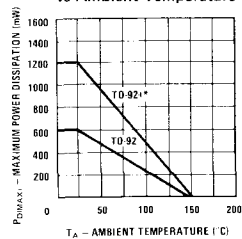
92 PLUS (Package 90)

| |
|---------|
| 92PE37B |
| BD373B |
| BD373C |

Power Dissipation vs Case Temperature TO-126

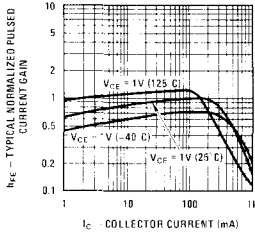


Maximum Power Dissipation vs Ambient Temperature

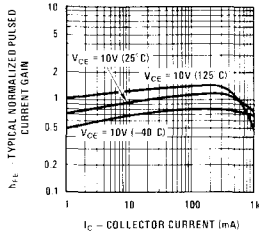


*One square inch of copper run

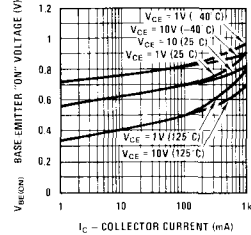
Typical Normalized Pulsed Current Gain vs Collector Current



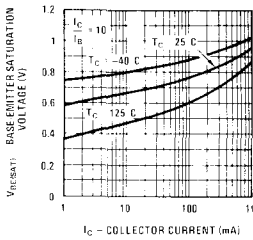
Typical Normalized Pulsed Current Gain vs Collector Current



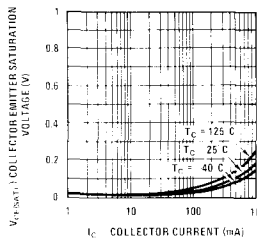
Base-Emitter "ON" Voltage vs Collector Current



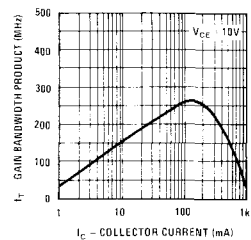
Base-Emitter Saturation Voltage vs Collector Current



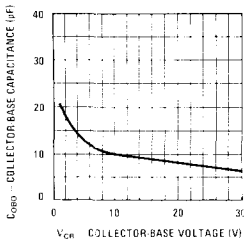
Collector-Emitter Saturation Voltage vs Collector Current



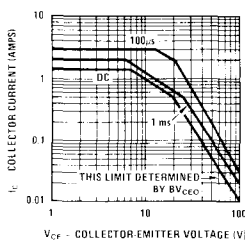
Gain Bandwidth Product vs Collector Current



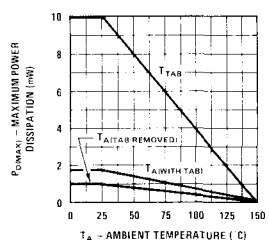
Collector-Base Capacitance vs Collector-Base Voltage



Safe Operating Area TO-202



Maximum Power Dissipation vs Ambient Temperature (TO-202)





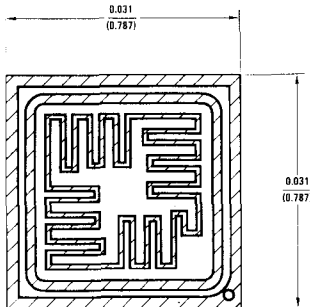
Process 39 NPN Medium Power

DESCRIPTION

Process 39 is a double diffused silicon epitaxial planar device. Complement to Process 79.

APPLICATION

This device was designed for general purpose medium power amplifier and switching circuits that require collector currents to 1A.



| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|------|-----|---------------|
| V_{CE0} | $I_C = 10 \text{ mA}$ | 80 | | 110 | V |
| V_{CBO} | $I_C = 100 \mu\text{A}$ | 160 | | 220 | V |
| V_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | 7 | | V |
| I_{CBO} | $V_{CB} = V_{CE0}$ | | 50 | 500 | nA |
| I_{EBO} | $V_{EB} = 5 \text{ V}$ | | 0.1 | 100 | μA |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1 \text{ V}$ | 100 | | 350 | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.2 | 0.5 | V |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.95 | 1.5 | V |
| f_T | $I_C = 100 \text{ mA}, V_{CE} = 10 \text{ V}$ | | 120 | | MHz |
| C_{OBO} | $V_{CB} = 10 \text{ V}$ | | | 12 | pF |

PRINCIPAL DEVICE TYPES

TO-202 (Package 35)

- NSD104
- NSD105
- NSD106
- NSDU06
- NSDU07

92 PLUS (Package 90)

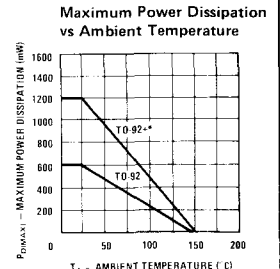
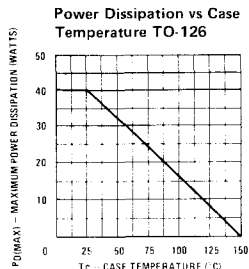
- 92PE37C
- BD373D

92 PLUS (Package 91)

- 92PU06
- 92PU07
- BD371D

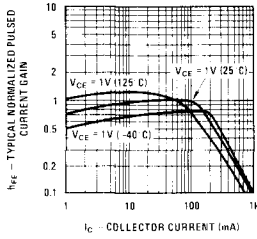
TO-126 (Package 38)

- BD139

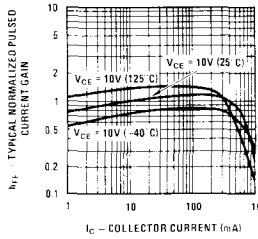


*One square inch of copper run

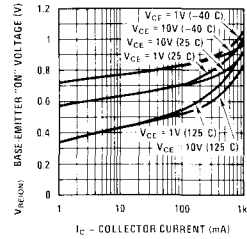
Typical Normalized Pulsed Current Gain vs Collector Current



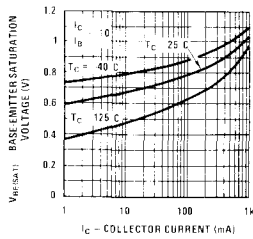
Typical Normalized Pulsed Current Gain vs Collector Current



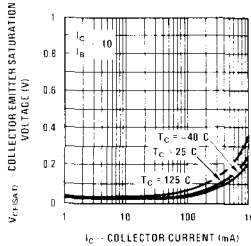
Base-Emitter "ON" Voltage vs Collector Current



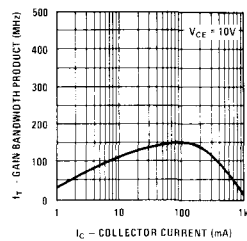
Base-Emitter Saturation Voltage vs Collector Current



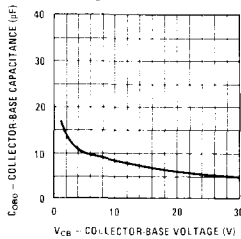
Collector-Emitter Saturation Voltage vs Collector Current



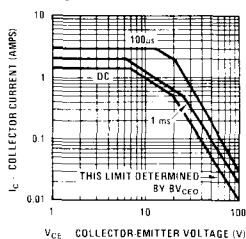
Gain Bandwidth Product vs Collector Current



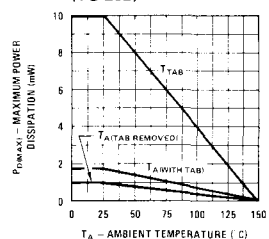
Collector-Base Capacitance vs Collector-Base Voltage

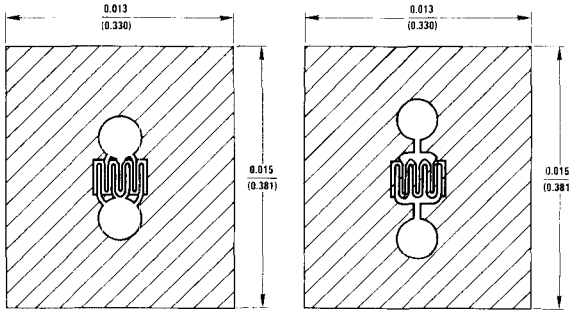


Safe Operating Area TO-202



Maximum Power Dissipation vs Ambient Temperature (TO-202)





UHF (TO-72 and Micro Disc Only)

VHF (TO-92 Only)

DESCRIPTION

Process 41 is an overlay double diffused, silicon device.

APPLICATION

This device was designed for use in extremely low noise UHF/VHF preamplifiers operated common-emitter or common base, and in UHF mixers. Exhibits forward AGC characteristics between 3–10 mA.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|-------------------|--|-----|--------------|--------------|-------|----------------|
| NF | f = 800 MHz, V _{CB} = 10V, I _C = 2 mA, Common Base, Y _S = Optimum | | 5.5 | | dB | TO-72 |
| NF | f = 800 MHz, V _{CB} = 10V, I _C = 2 mA, Common Base, Y _S = 10 ±j0 mmhos | | 7.0 | 9.5 | dB | TO-72 |
| P _G | f = 800 MHz, V _{CB} = 10V, I _C = 2 mA, Common Base, R _L = 500Ω | 7.5 | 9.0 | | dB | TO-72 |
| NF | f = 450 MHz, V _{CE} = 10V, I _C = 2 mA, Common-Emitter, R _S = 75Ω | | 2.0 | | dB | TO-72 |
| NF | f = 200 MHz, V _{CB} = 10V, I _C = 3 mA, Common Base, R _S = 100Ω | | 2.5 | 3.0 | dB | Fig. 1 |
| P _G | f = 200 MHz, V _{CB} = 10V, I _C = 3 mA, Common Base, R _L = 1 kΩ | 13 | 16 | | dB | Fig. 1 |
| rb'Cc | f = 79.8 MHz, V _{CB} = 10V, I _C = 3 mA, | | 2.5 | 5.0 | ps | TO-72 |
| h _{fe} | f = 100 MHz, V _{CE} = 10V, I _C = 2 mA | 6.0 | 7.5 | | | |
| C _{cb} | f = 1.0 MHz, V _{CB} = 10V, I _E = 0 | | 0.28 | 0.35 | pF | TO-72 |
| C _{ce} | f = 1.0 MHz, V _{CE} = 10V, I _B = 0 | | 0.12 0.19 | 0.20 0.30 | pF | TO-72 TO-92 |
| h _{FE} | V _{CE} = 10V, I _C = 2 mA | 30 | 75 | 200 | | |
| BV _{CEO} | I _C = 1 mA | 30 | | | V | |
| BV _{CBO} | I _C = 10 μA | 30 | | | V | |
| BV _{EBO} | I _E = 1 μA | 3.0 | 4.0 | | V | |
| I _{CBO} | V _{CB} = 20V | | | 100 | nA | |
| I _{EBO} | V _{EB} = 2.5V | | | 50 | nA | |

PRINCIPAL DEVICE TYPES

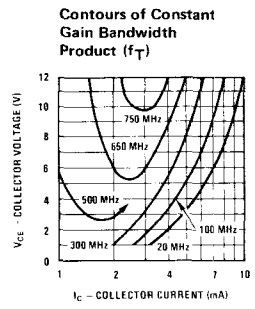
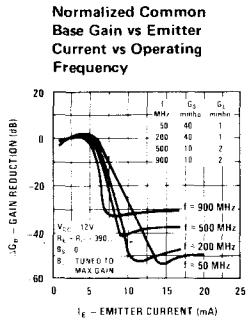
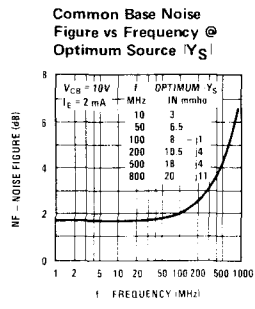
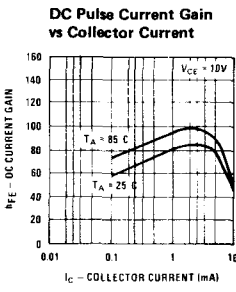
TO-72 (Package 25)

BF180
BF181
BF200

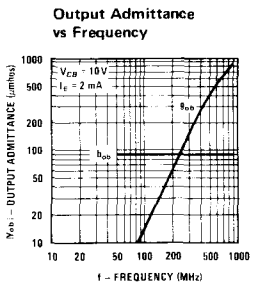
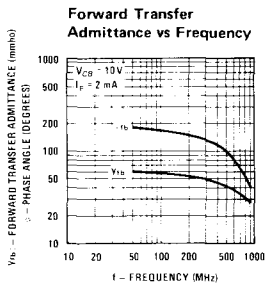
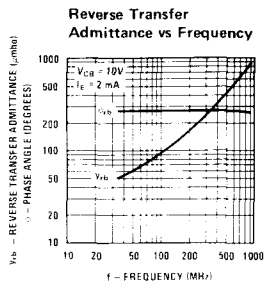
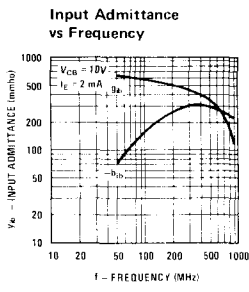
TO-92 (Package 75)

MPSH08
MPSH07

Process 41



COMMON BASE Y PARAMETERS VS FREQUENCY



CONTOURS OF CONSTANT NOISE FIGURES

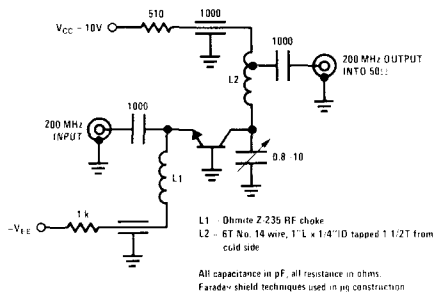
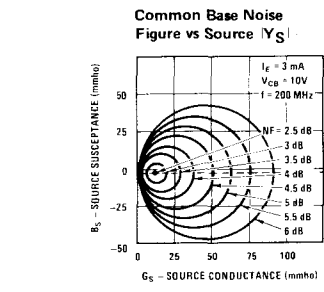
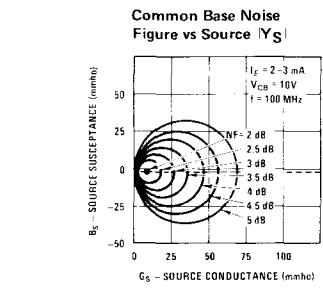
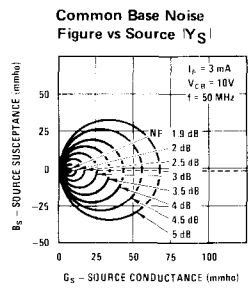
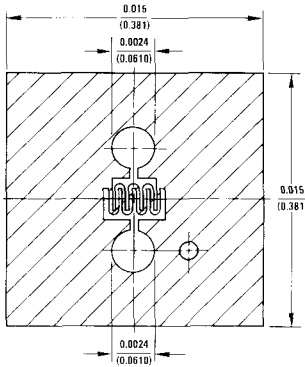


FIGURE 1. Common Base 200 MHz PG and NF Circuit



DESCRIPTION

Process 42 is an overlay double diffused silicon epitaxial device.

APPLICATION

This device was designed for use in low noise UHF/VHF amplifiers with collector current in the 100 μ A to 10 mA range in common emitter or common base mode of operation, and low frequency drift, high output UHF oscillators.

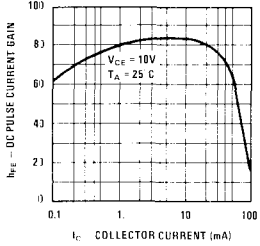
PRINCIPAL DEVICE TYPES

TO-72 2N5179
TO-92 2SC535 (ECB), MPS-H10 (BEC)

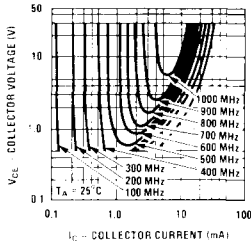
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|--------------------------------|--|-----|------|-----|-------|-----------------|
| P _G | f = 450 MHz, V _{CE} = 10V, I _C = 2 mA | 10 | 13 | | dB | Fig. 1 |
| NF | f = 450 MHz, V _{CE} = 10V, I _C = 2 mA R _g = 50 Ω | | 3.0 | 5.0 | dB | Fig. 1 |
| P _{OUT} | f = 500 MHz, V _{CB} = 15V, I _E = 8 mA | 30 | 50 | | mW | TO-92 Fig. 3 |
| P _G | f = 200 MHz, V _{CE} = 10V, I _C = 2 mA | 22 | 27 | | dB | Fig. 2 |
| NF | f = 200 MHz, V _{CE} = 10V, I _C = 2 mA R _S = 120 Ω | | 2.0 | 3.5 | dB | Fig. 2 |
| h _{fe} | f = 100 MHz, V _{CE} = 10V, I _C = 5 mA | 6.0 | 10.5 | 15 | | |
| r _{b'} C _c | f = 79.8 MHz, V _{CE} = 10V, I _C = 5 mA | | 3.5 | 10 | ps | TO-72 |
| C _{cb} | f = 1.0 MHz, V _{CB} = 10V, I _E = 0 | | 0.4 | 0.5 | pF | TO-72 |
| C _{ce} | f = 1.0 MHz, V _{CE} = 10V, I _B = 0 | | 0.2 | 0.3 | pF | TO-72 |
| C _{eb} | f = 1.0 MHz, V _{EB} = 0.5V, I _C = 0 | | 0.8 | 1.5 | pF | TO-72 |
| h _{FE} | V _{CE} = 10V, I _C = 5 mA | 30 | 90 | 200 | | |
| h _{FE} | V _{CE} = 6V, I _C = 1 mA | 25 | 75 | | | |
| V _{CE(SAT)} | I _C = 10 mA, I _B = 5 mA | | 0.07 | 0.2 | V | |
| BV _{CEO} | I _C = 1 mA | 20 | 30 | 40 | V | |
| BV _{CBO} | I _C = 100 μ A | 35 | | | V | |
| BV _{EBO} | I _E = 10 μ A | 4.0 | | | V | |
| I _{CBO} | V _{CB} = 30V | | | 100 | nA | |
| I _{EBO} | V _{EB} = 3V | | | 50 | nA | |

Process 42

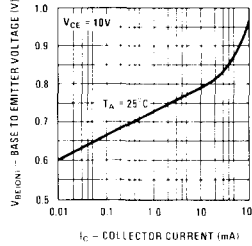
DC Pulse Current Gain vs Collector Current



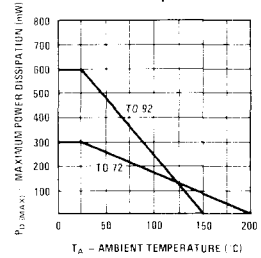
Contours Of Constant Gain Bandwidth Product (f_T)



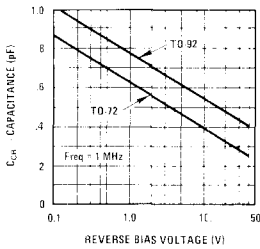
Base Emitter On Voltage vs Collector Current



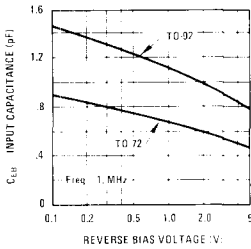
Maximum Power Dissipation vs Ambient Temperature



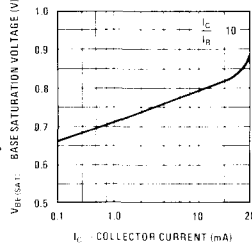
Reverse Transfer Capacitance vs Reverse Bias Voltage



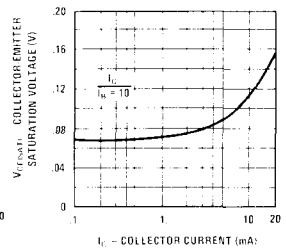
Input Capacitance vs Reverse Bias Voltage



Base-Emitter Saturation Voltage vs Collector Current

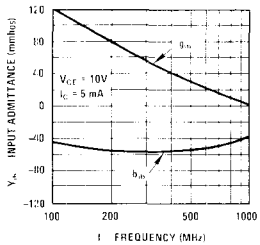


Collector-Emitter Saturation Voltage vs Collector Current

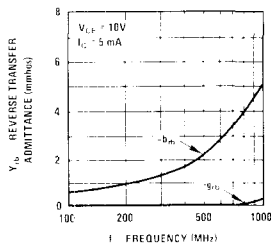


COMMON BASE Y PARAMETERS VS FREQUENCY

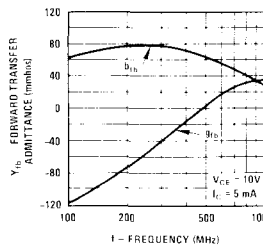
Input Admittance vs Frequency



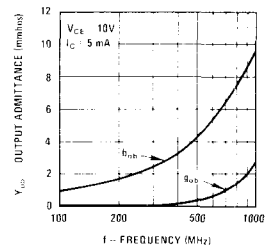
Reverse Transfer Admittance vs Frequency



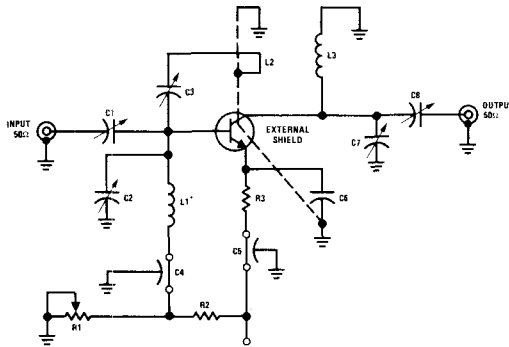
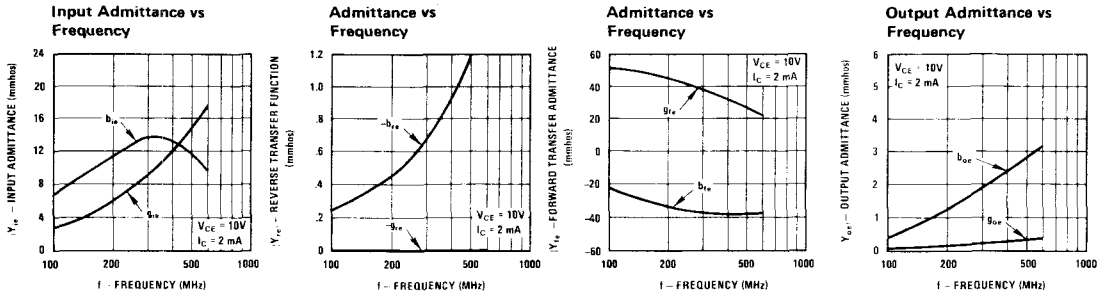
Forward Transfer Admittance vs Frequency



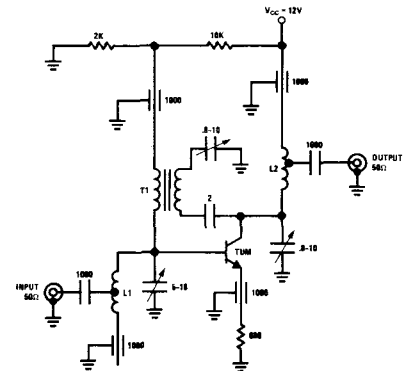
Output Admittance vs Frequency



COMMON EMITTER Y PARAMETERS VS FREQUENCY



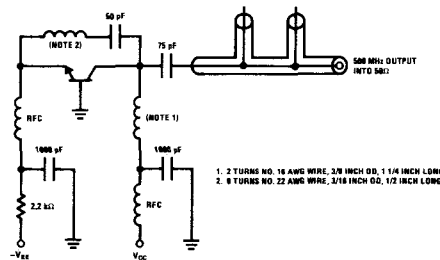
- C1, C2, C3, C7, C8 - 0.01 μ F VARIABLE CAPACITOR
- C3 - PLASTIC TUBULAR TRIMMER CAPACITOR (ADJUSTED AND FIXED FOR A TRANSISTOR HAVING A TYPICAL VALUE OF C_{ce} (0.35 pF))
- C4 - 200 μ F BUTTON TYPE FLEETHROUGH CAPACITOR
- C5 - 1000 μ F FLEETHROUGH CAPACITOR
- C6 - 470 μ F LEADLESS CERAMIC DISC CAPACITOR
- L1, L3 - 1" LENGTH OF 1/4" DIAMETER COPPER BAR STOCK
- L2 - 1/2 LOOP NO. 16 AWG ENAMELED WIRE PARALLEL TO AND APPROXIMATELY 1/8" FROM L3
- R1 - 5 k Ω POTENTIOMETER
- R2 - 2 k Ω
- R3 - 2 k Ω



- L1 - 3T #18 WIRE, 1/2" x 1/4" TAPPED 1/2T FROM COLD SIDE
- L2 - 8T #18 WIRE, 1/4" x 1/4" TAPPED 1/2T FROM COLD SIDE
- T1 - PRL 1T #18 WIRE CORE IS INDIANA GENERAL 9/8 F-804-03
- ALL CAPACITANCE IN μ F, ALL RESISTANCE IN OHMS.

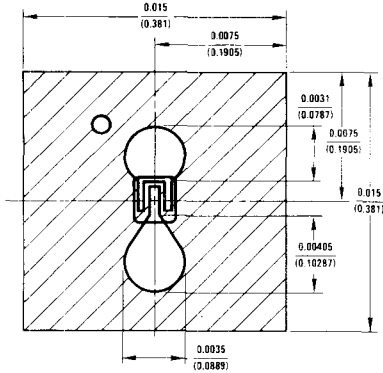
FIGURE 1. Neutralized 450-MHz Gain and Noise Figure Circuit

FIGURE 2. Neutralized 200-MHz PF & NF Circuit



- 1. 2 TURNS NO. 16 AWG WIRE, 3/16 INCH OD, 1 1/4 INCH LONG.
- 2. 8 TURNS NO. 22 AWG WIRE, 3/16 INCH OD, 1/2 INCH LONG.

FIGURE 3. 500 MHz Oscillator Circuit


DESCRIPTION

Process 43 is an overlay double diffused, silicon epitaxial device.

APPLICATION

This device was designed for use as RF amplifiers, oscillators and multipliers with collector current in the 1 mA to 2 mA range.

PRINCIPAL DEVICE TYPES

TO-72 2N918
TO-92 PN3563, PN5130 (EBC),
 2N3663 (ECB)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------------|
| G_{PE} | $f = 200 \text{ MHz}$, $I_C = 5 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 15 | 18 | | dB | Neutralized |
| NF | $f = 60 \text{ MHz}$, $I_C = 1 \text{ mA}$, $V_{CE} = 10 \text{ V}$ $R_S = 200 \Omega$ | | 3.5 | 5.0 | dB | |
| PO | $f = 500 \text{ MHz}$, $I_C = 8 \text{ mA}$, $V_{CE} = 15 \text{ V}$ | 20 | 35 | | mW | Fig. 1 |
| PO | $f = 900 \text{ MHz}$, $I_C = 8 \text{ mA}$, $V_{CE} = 15 \text{ V}$ | 3.0 | 8.0 | | mW | |
| h_{fe} | $I_C = 5 \text{ mA}$, $V_{CE} = 10 \text{ V}$, $f = 100 \text{ MHz}$ | 6.0 | 9.0 | | | |
| $rb' Cc$ | $f = 79.8 \text{ MHz}$, $V_{CE} = 10 \text{ V}$, $I_E = 8 \text{ mA}$ | | 10 | 25 | ps | |
| C_{obo} | $V_{CB} = 10 \text{ V}$, $I_E = 0$ | | 1.2 | 1.7 | pF | |
| C_{eb} | $V_{EB} = 0.5 \text{ V}$, $I_C = 0$ | | 1.4 | 2.0 | pF | TO-72 |
| h_{FE} | $I_C = 1 \text{ mA}$, $V_{CE} = 1 \text{ V}$ | 25 | 5 | | | |
| h_{FE} | $I_C = 5 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 40 | 80 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | | 0.25 | 0.40 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | | | 0.95 | V | |
| BV_{CEO} | $I_C = 3 \text{ mA}$ | 15 | 20 | 24 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 30 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.0 | | | V | |
| I_{CBO} | $V_{CB} = 15 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{CB} = 3 \text{ V}$ | | | 50 | nA | |

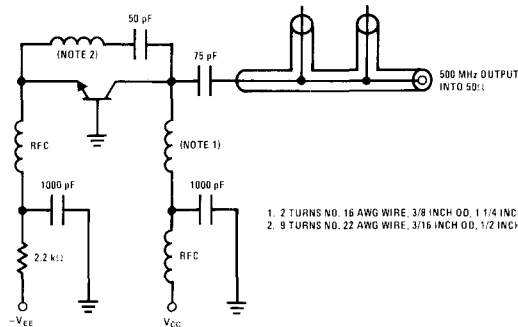
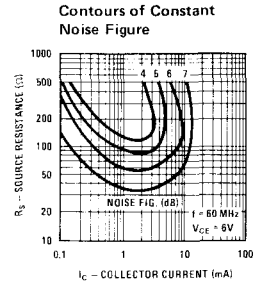
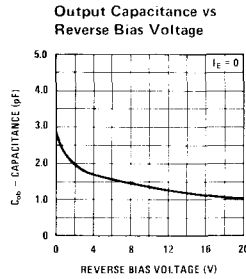
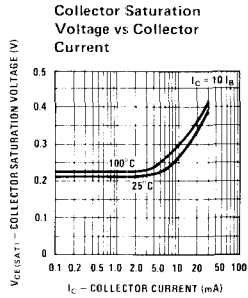
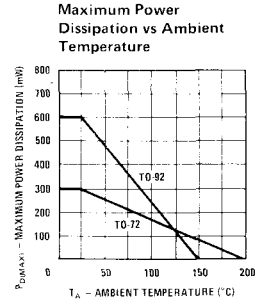
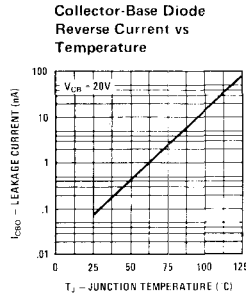
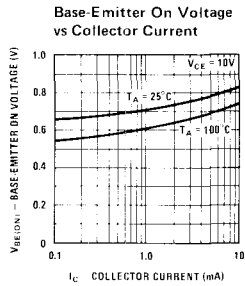
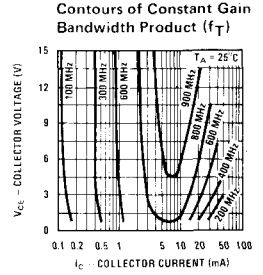
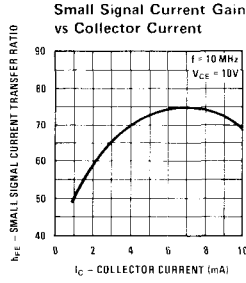
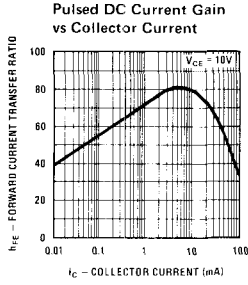
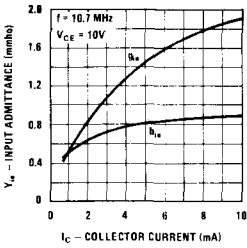
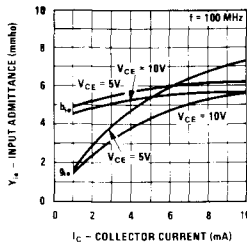


FIGURE 1. 500 MHz Oscillator Circuit

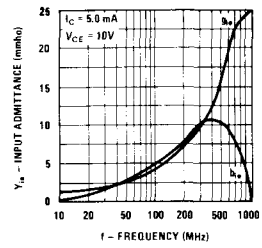
Input Admittance vs Collector Current-Output Short Circuit



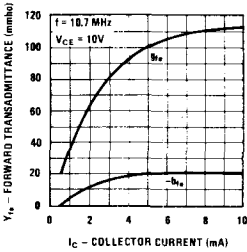
Input Admittance vs Collector Current-Output Short Circuit



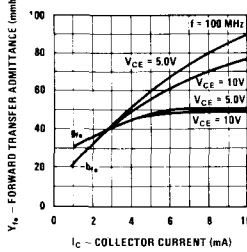
Input Admittance vs Frequency-Output Short Circuit



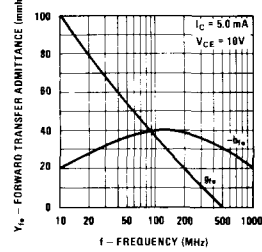
Forward Transfer Admittance vs Collector Current-Output Short Circuit



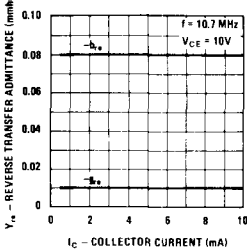
Forward Transfer Admittance vs Collector Current-Output Short Circuit



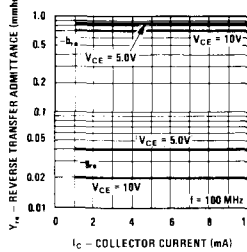
Forward Transfer Admittance vs Frequency-Output Short Circuit



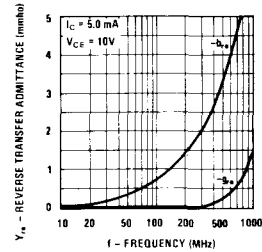
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



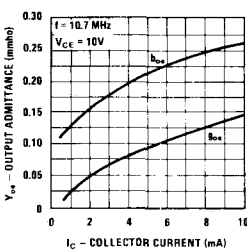
Reverse Transfer Admittance vs Collector Current-Input Short Circuit



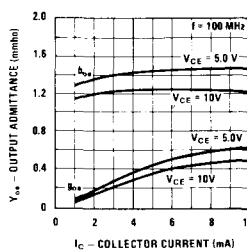
Reverse Transfer Admittance vs Frequency-Input Short Circuit



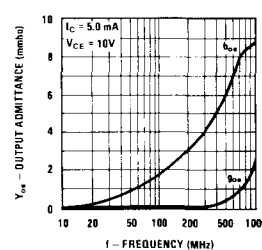
Output Admittance vs Collector Current-Input Short Circuit

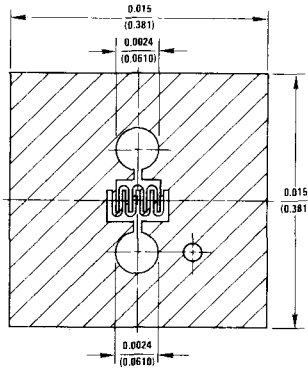


Output Admittance vs Collector Current-Input Short Circuit



Output Admittance vs Frequency-Input Short Circuit





DESCRIPTION

Process 44 is an overlay double diffused, silicon device.

APPLICATION

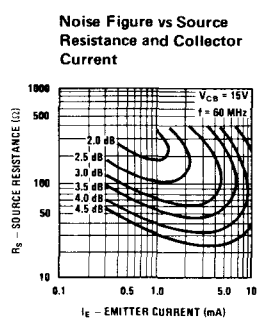
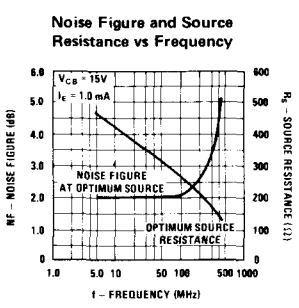
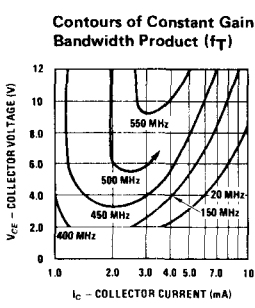
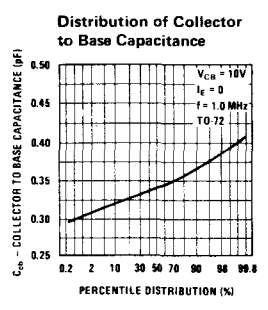
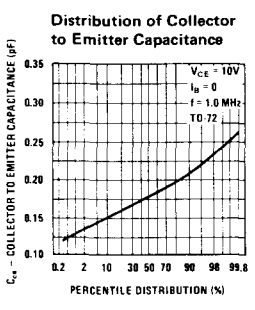
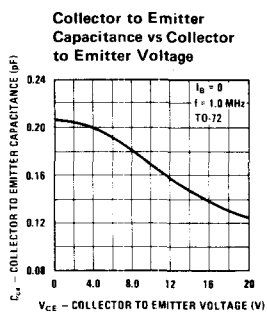
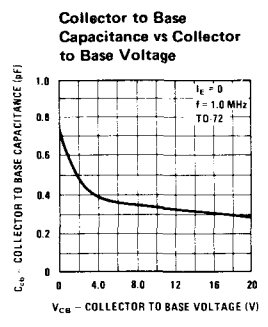
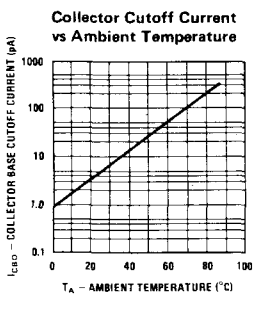
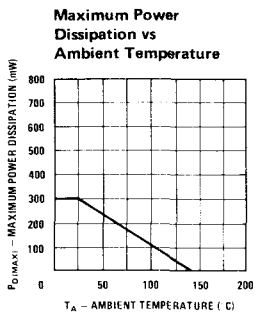
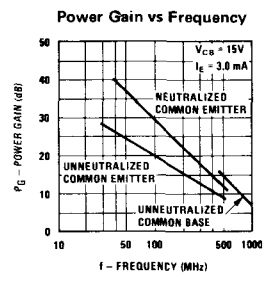
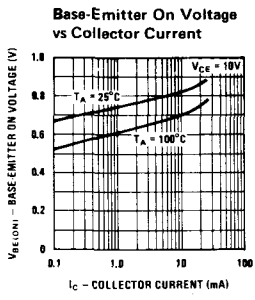
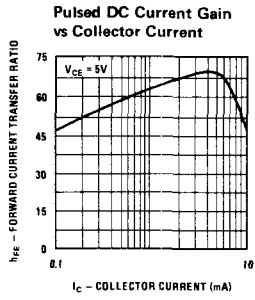
This device was designed for use as a low noise VHF amplifier with forward AGC capability.

PRINCIPAL DEVICE TYPES

TO-72 SE5020
TO-92 MPS6568, MPS-H30 (BEC)

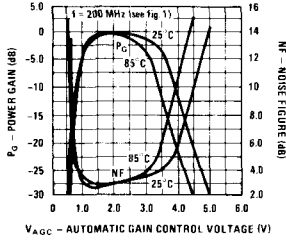
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|------|------|------|-------|--------|
| NF | $f = 200 \text{ MHz}$, $I_C = 2 \text{ mA}$, $V_{CE} = 10\text{V}$, $R_S = 50\Omega$ | | 2.0 | 3.3 | dB | Fig. 1 |
| P_G | $f = 200 \text{ MHz}$, $I_C = 2 \text{ mA}$, $V_{CE} = 10\text{V}$, $R_S = 50\Omega$ | 20 | 24 | | dB | Fig. 1 |
| NF | $f = 45 \text{ MHz}$, $I_C = 4 \text{ mA}$, $V_{CE} = 10\text{V}$, $R_S = 50\Omega$ | | 3.0 | 5.0 | dB | Fig. 2 |
| P_G | $f = 45 \text{ MHz}$, $I_C = 4 \text{ mA}$, $V_{CE} = 10\text{V}$, $R_S = 50\Omega$ | 23 | 26 | | dB | Fig. 2 |
| AGC | $f = 200 \text{ MHz}$, V_{AGC} at 30 dB Down | 4.0 | 4.5 | 5.0 | V | Fig. 1 |
| AGC | $f = 45 \text{ MHz}$, V_{AGC} at 30 dB Down | 4.3 | 5.0 | 5.6 | V | Fig. 2 |
| C_{cb} | $V_{CB} = 10\text{V}$, $I_E = 0$ | | 0.35 | 0.50 | pF | TO-72 |
| | | | 0.45 | 0.55 | pF | TO-92 |
| h_{fe} | $V_{CE} = 10\text{V}$, $I_C = 4 \text{ mA}$, $f = 100 \text{ MHz}$ | 3.75 | 5.5 | 8.0 | | |
| h_{FE} | $I_C = 4 \text{ mA}$, $V_{CE} = 5\text{V}$ | 30 | 70 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 1.0 | 2.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 0.85 | 0.95 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 30 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 30 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.0 | | | V | |
| I_{CBO} | $V_{CB} = 20\text{V}$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |

Process 44

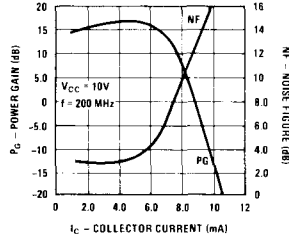


COMMON EMITTER PERFORMANCE

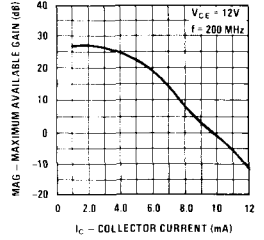
Power Gain and Noise Figure vs Automatic Gain Control Voltage



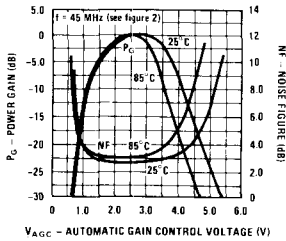
Power Gain and Noise Figure vs Collector Current



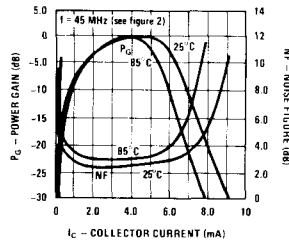
Maximum Available Gain vs Collector Current



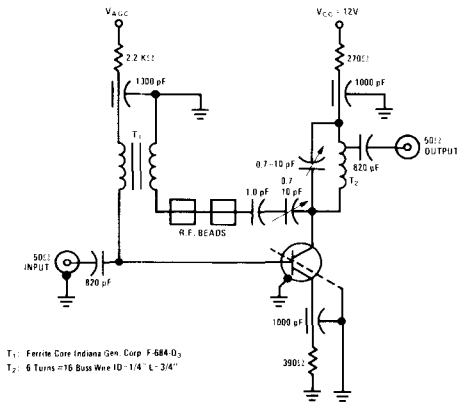
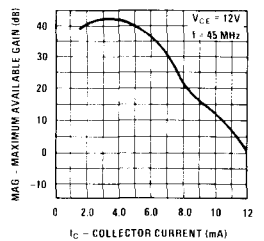
Power Gain and Noise Figure vs Automatic Gain Control Voltage



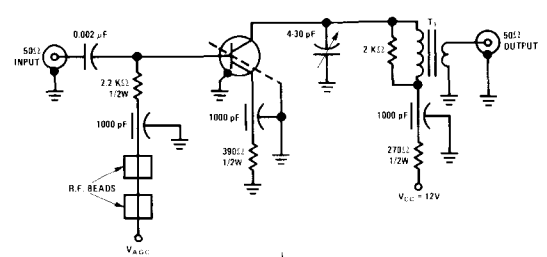
Power Gain and Noise Figure vs Collector Current



Maximum Available Gain vs Collector Current



T₁: Ferrite Core Indiana Gen. Corp. F-684-D₃
 T₂: 6 Turns = 16 Buss Wire 10-1/4" L-3/4"



T₁: D₁ Toroid 4:1 Ratio
 8T PHU - 2T SEC
 = 22 Wire

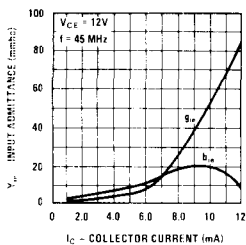
FIGURE 1. 200 MHz, AGC, Power Gain and Noise Figure Test Jig

FIGURE 2. 45 MHz, AGC, Power Gain and Noise Figure Test Jig

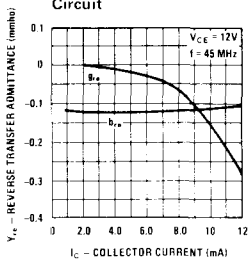
COMMON EMITTER Y PARAMETERS VS FREQUENCY

Process 44

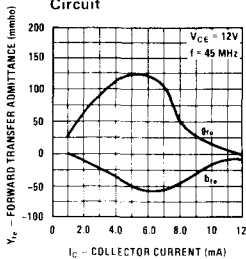
Input Admittance vs Collector Current - Output Short Circuit



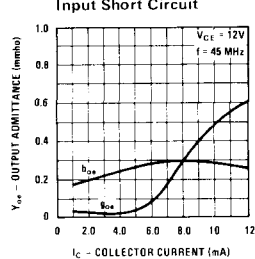
Reverse Transfer Admittance vs Collector Current - Input Short Circuit



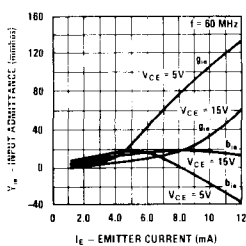
Forward Transfer Admittance vs Collector Current - Output Short Circuit



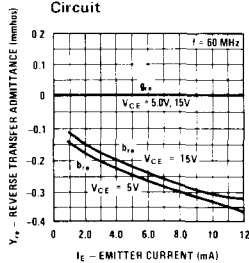
Output Admittance vs Collector Current - Input Short Circuit



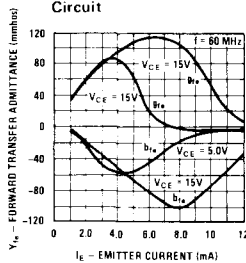
Input Admittance vs Emitter Current - Output Short Circuit



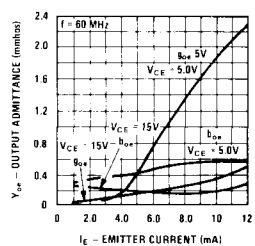
Reverse Transfer Admittance vs Emitter Current - Input Short Circuit



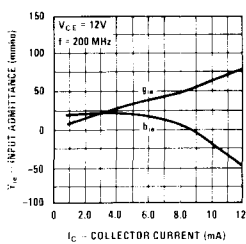
Forward Transfer Admittance vs Emitter Current - Output Short Circuit



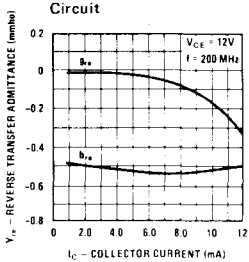
Output Admittance vs Emitter Current - Input Short Circuit



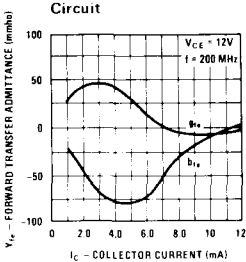
Input Admittance vs Collector Current - Output Short Circuit



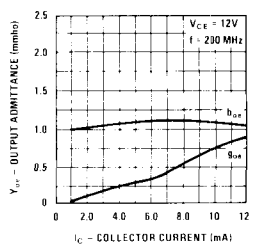
Reverse Transfer Admittance vs Collector Current - Input Short Circuit



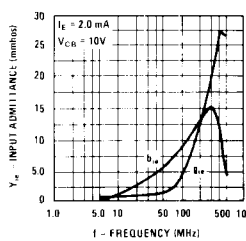
Forward Transfer Admittance vs Collector Current - Output Short Circuit



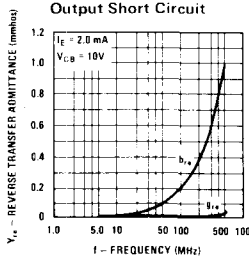
Output Admittance vs Collector Current - Input Short Circuit



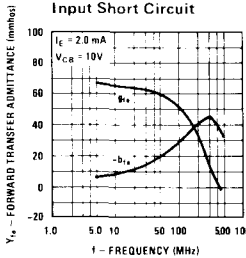
Input Admittance vs Frequency - Output Short Circuit



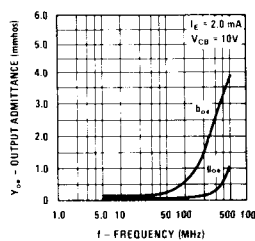
Reverse Transfer Admittance vs Frequency - Output Short Circuit



Forward Transfer Admittance vs Frequency - Input Short Circuit

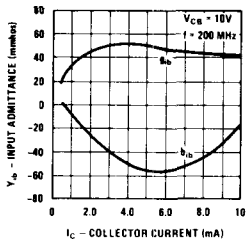


Output Admittance vs Frequency - Input Short Circuit

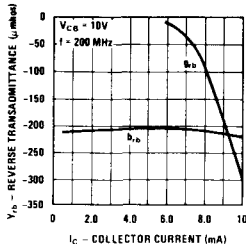


COMMON BASE Y PARAMETERS VS FREQUENCY

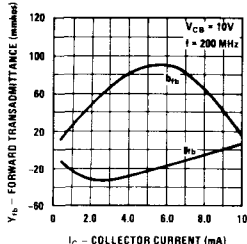
Input Admittance vs Collector Current-Output Short Circuit



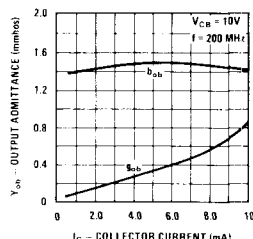
Reverse Transadmittance vs Collector Current-Input Short Circuit



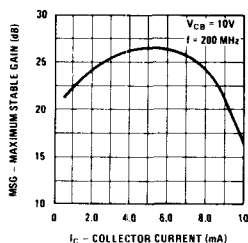
Forward Transadmittance vs Collector Current-Output Short Circuit



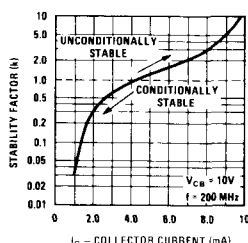
Output Admittance vs Collector Current-Input Short Circuit



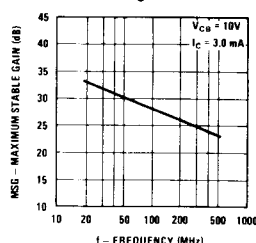
Maximum Stable Gain vs Collector Current Common Base Configuration



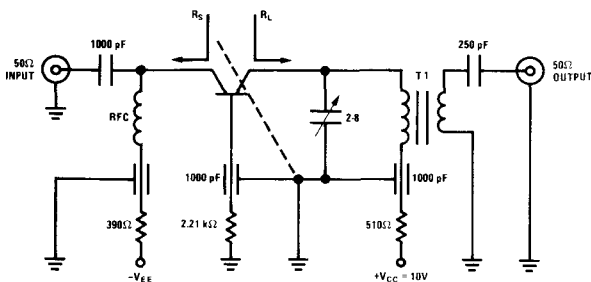
Common Base Configuration Stability Factor-k vs Collector Current



Maximum Stable Gain vs Frequency Common Base Configuration

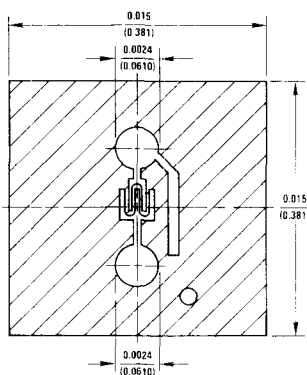


Rollett stability factor "k" is defined as: $k = \frac{2 - R_{12} - R_{21}}{Y_1 Y_2}$



T₁ - 3:1 Ratio No. 22 Bifilar on Micrometals Toroid, P/N T30-12
 R_c = 50Ω, R_L = 2.5 kΩ
 f_{bw} = 8.0 MHz

FIGURE 3. 200 MHz Common Base Power Gain, Noise Figure, Automatic Gain Control Test Circuit.


DESCRIPTION

Process 45 is an overlay double diffused silicon device, with a Faraday shield diffusion.

APPLICATION

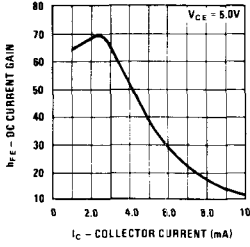
This device was designed for use as a forward AGC amplifier in IF amplifiers without neutralization.

PRINCIPAL DEVICE TYPES

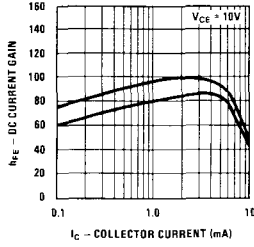
TO-72 SE5055 (pkg 28)
TO-92 MPS-H32 (BEC)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|------|------|------|-------|--------|
| P_G | $f = 45 \text{ MHz}$, $V_{CE} = 10\text{V}$, $I_C = 3 \text{ mA}$, $R_G = 50\Omega$ | 27.0 | 29.5 | | dB | Fig. 1 |
| NF | $f = 45 \text{ MHz}$, $V_{CE} = 10\text{V}$, $I_C = 3 \text{ mA}$, $R_G = 50\Omega$ | | 2.8 | 5.0 | dB | Fig. 1 |
| C_{re} | $V_{CB} = 10\text{V}$, $I_E = 0$ | | 0.13 | 0.22 | pF | TO-72 |
| C_{re} | $V_{CB} = 10\text{V}$, $I_E = 0$ | | 0.20 | 0.30 | pF | TO-92 |
| V_{AGC} | $f = 45 \text{ MHz}$, $V_{CC} = 12\text{V}$ 30 dB Gain Reduction | 3.8 | 4.4 | 5.0 | V | Fig. 1 |
| V_{AGC} | $f = 45 \text{ MHz}$, $V_{CC} = 12\text{V}$ 50 dB Gain Reduction | | 6.8 | 8.0 | V | Fig. 1 |
| h_{fe} | $V_{CE} = 10\text{V}$, $I_C = 2 \text{ mA}$, $f = 100 \text{ MHz}$ | 3.0 | 5.5 | | | |
| h_{FE} | $V_{CE} = 10\text{V}$, $I_C = 2 \text{ mA}$ | 30 | 80 | 200 | | |
| h_{FE} | $V_{CE} = 10\text{V}$, $I_C = 10 \text{ mA}$ | 18 | 35 | | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 1.0 | 2.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 5 \text{ mA}$ | | 0.92 | 1.0 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 30 | | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 30 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.0 | | | V | |
| I_{CBO} | $V_{CB} = 20\text{V}$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |

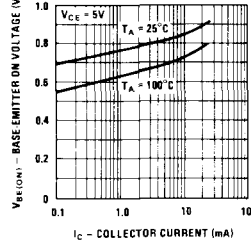
DC Current Gain vs Collector Current



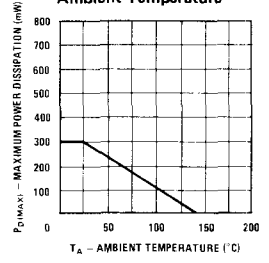
DC Pulse Current Gain vs Collector Current



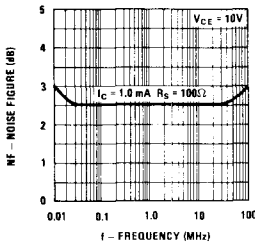
Base-Emitter On Voltage vs Collector Current



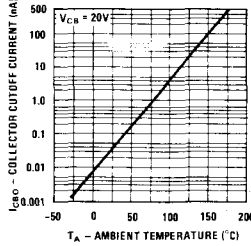
Maximum Power Dissipation vs Ambient Temperature



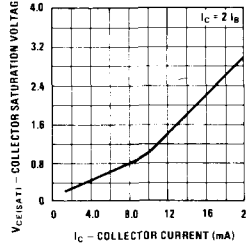
Noise Figure vs Frequency



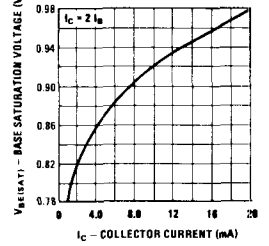
Collector Cutoff Current vs Ambient Temperature



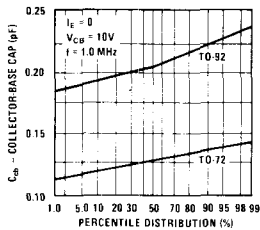
Collector Saturation Voltage vs Collector Current



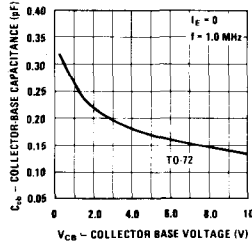
Base Saturation Voltage vs Collector Current



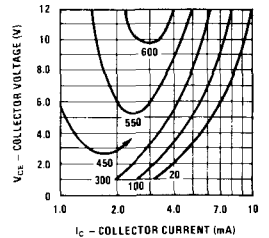
Distribution of Collector to Base Capacitance



Collector-Base Capacitance vs Collector-Base Voltage



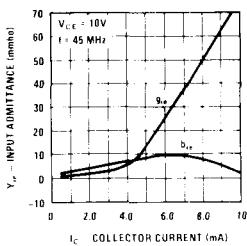
Contours of Constant Gain Bandwidth Product (fT)



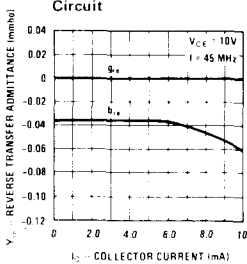
Process 45

COMMON EMITTER Y PARAMETERS VS FREQUENCY

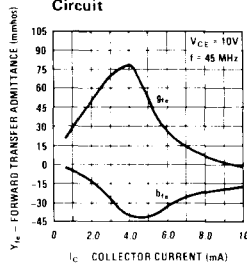
Input Admittance vs Collector Current - Output Short Circuit



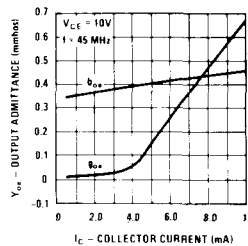
Reverse Transfer Admittance vs Collector Current - Input Short Circuit



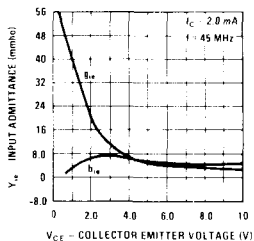
Forward Transfer Admittance vs Collector Current - Output Short Circuit



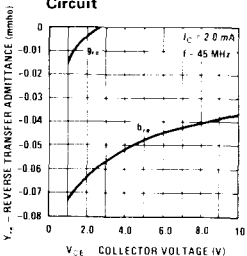
Output Admittance vs Collector Current - Input Short Circuit



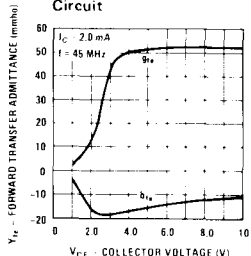
Input Admittance vs Collector Voltage - Output Short Circuit



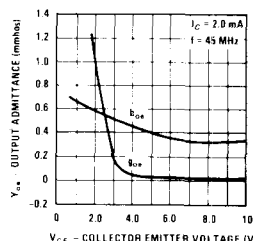
Reverse Transfer Admittance vs Collector Voltage - Input Short Circuit



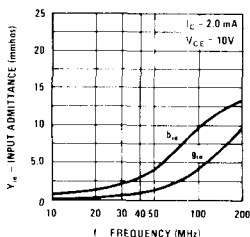
Forward Transfer Admittance vs Collector Voltage - Output Short Circuit



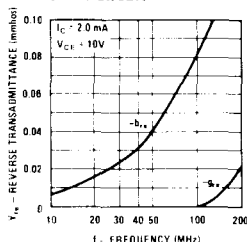
Output Admittance vs Collector Voltage - Input Short Circuit



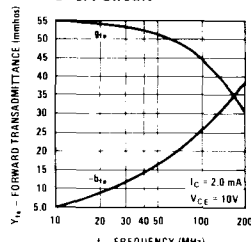
Input Admittance vs Frequency - Output Short Circuit



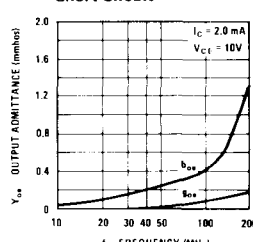
Reverse Transadmittance vs Frequency - Input Short Circuit



Forward Transadmittance vs Frequency - Output Short Circuit



Output Admittance vs Frequency - Input Short Circuit



COMMON EMITTER PERFORMANCE

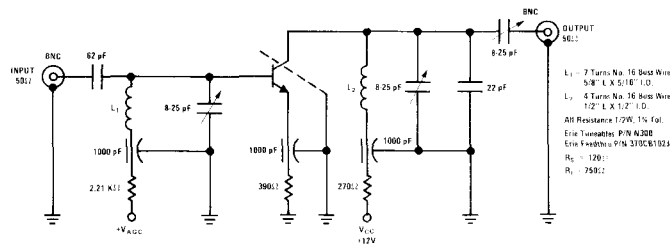
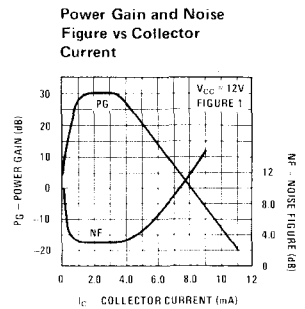
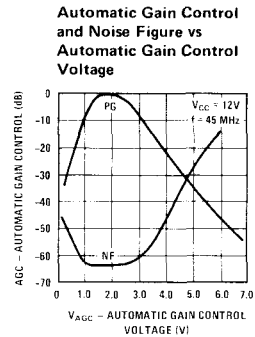
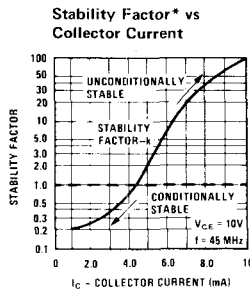
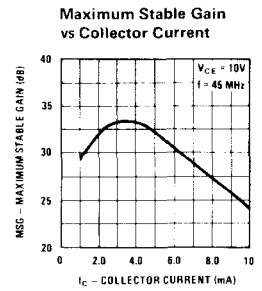
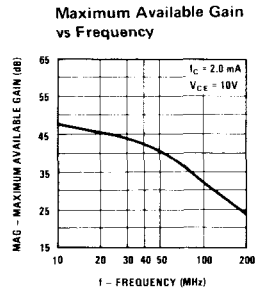
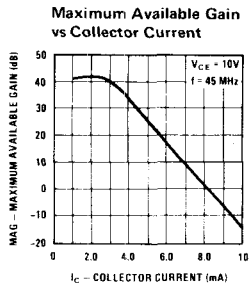
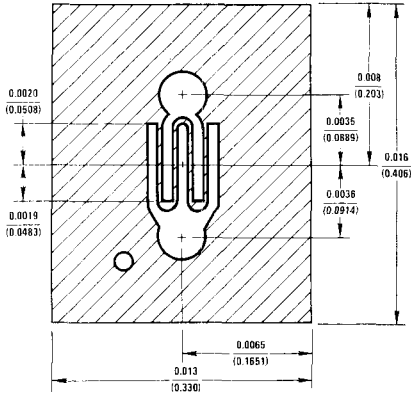


FIGURE 1. SE5055 45 MHz Gain, Noise Figure, AGC Circuit

* Rollett's stability factor "k" is defined as: $k = \frac{2 - R_{11}R_{22}}{Y_1 Y_2}$


DESCRIPTION

Process 46 is an overlay double diffused, silicon epitaxial device.

APPLICATION

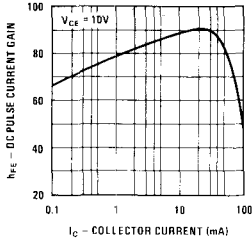
This device was designed for linear RF amplifier applications up to 100 MHz with collector current in the 1 mA to 30 mA range.

PRINCIPAL DEVICE TYPES

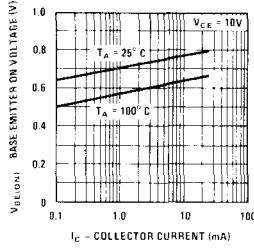
TO-92 ST5025

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|-----|-----------------|-------|
| G_{pe} | $f = 45 \text{ MHz}$, $V_{CE} = 10\text{V}$, $I_C = 10 \text{ mA}$ | 25 | 28 | | dB | |
| C_{cb} | $V_{CB} = 10\text{V}$ | | 0.8 | 1.0 | pF | TO-92 |
| g_{oe} | $f = 45 \text{ MHz}$, $V_{CE} = 10\text{V}$, $I_C = 10 \text{ mA}$ | | | 200 | μmho | |
| h_{fe} | $I_C = 10 \text{ mA}$, $V_{CE} = 10\text{V}$, $f = 100 \text{ MHz}$ | 3.0 | 4.50 | | | |
| h_{FE} | $I_C = 10 \text{ mA}$, $V_{CE} = 10\text{V}$ | 30 | 100 | 250 | | |
| $V_{CE(SAT)}$ | $I_C = 20 \text{ mA}$, $I_B = 1 \text{ mA}$ | | 0.2 | 0.6 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 30 | 55 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 35 | | | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 4.0 | | | V | |
| I_{CBO} | $V_{CB} = 30\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |

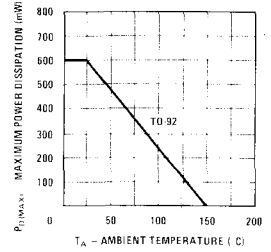
DC Pulse Current Gain vs Collector Current



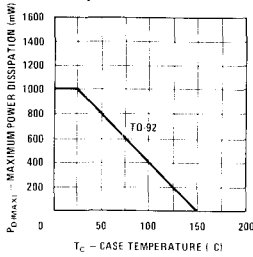
Base-Emitter On Voltage vs Collector Current



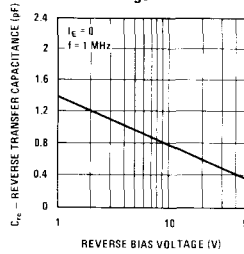
Maximum Power Dissipation vs Ambient Temperature



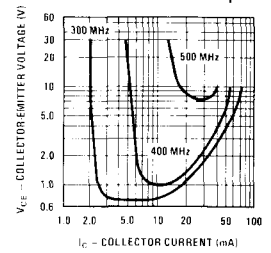
Maximum Power Dissipation vs Case Temperature



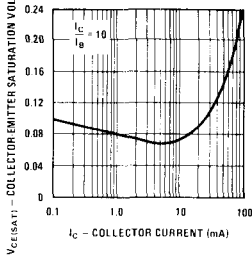
Reverse Transfer Capacitance vs Reverse Bias Voltage



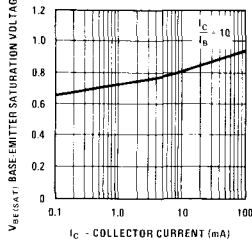
Contours of Constant Gain Bandwidth Product (fT)



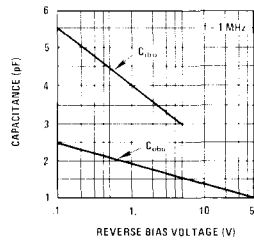
Collector-Emitter Saturation Voltage vs Collector Current



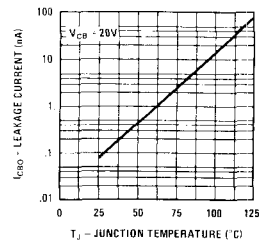
Base-Emitter Saturation Voltage vs Collector Current



Capacitance vs Reverse Bias Voltage

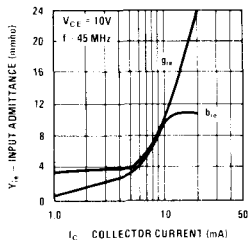


Collector-Base Diode Reverse Current vs Temperature

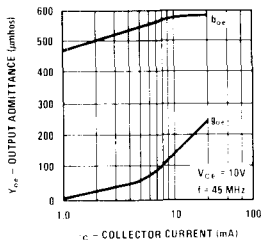


Process 46

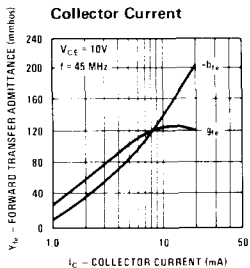
Input Admittance vs Collector Current



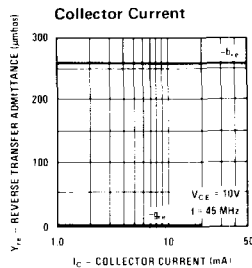
Output Admittance vs Collector Current



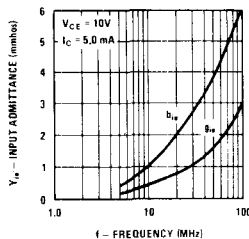
Forward Transfer Admittance vs Collector Current



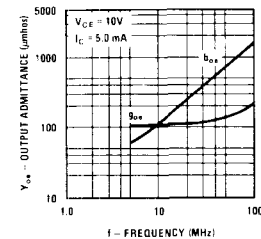
Reverse Transfer Admittance vs Collector Current



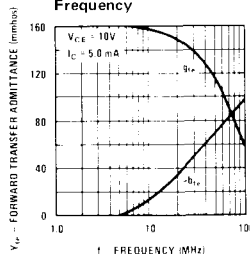
Input Admittance vs Frequency



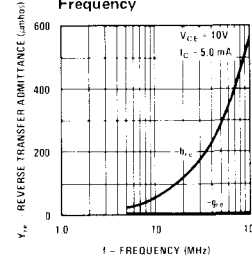
Output Admittance vs Frequency



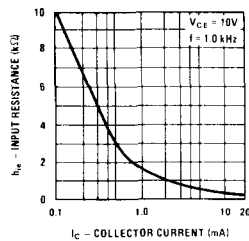
Forward Transfer Admittance vs Frequency



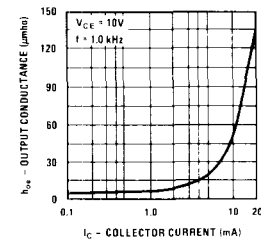
Reverse Transfer Admittance vs Frequency



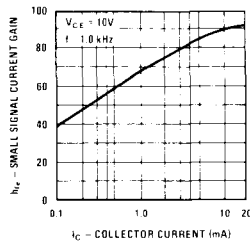
Small Signal Input Resistance vs Collector Current



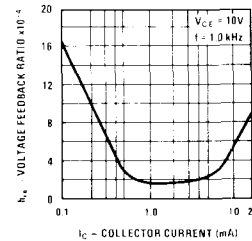
Small Signal Output Conductance vs Collector Current

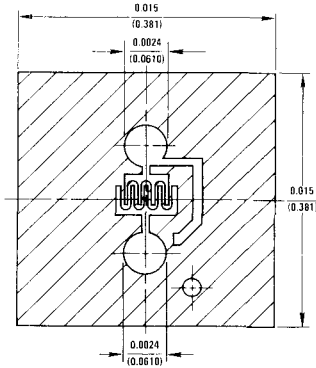


Small Signal Current Gain vs Collector Current



Small Signal Voltage Feedback Ratio vs Collector Current





DESCRIPTION

Process 47 is an overlay double diffused, silicon epitaxial device, with a Faraday shield diffusion.

APPLICATION

This device was designed for common-emitter low noise amplifier and mixer applications in the 100 μ A to 15 mA range to 300 MHz, and low frequency drift common-base VHF oscillator applications with high output levels for driving FET mixers.

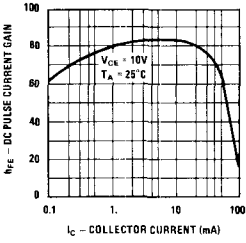
PRINCIPAL DEVICE TYPES

| | |
|-------|-------------------------|
| TO-72 | SE5035 |
| TO-92 | ST5030B, MPSH24, MPSH11 |

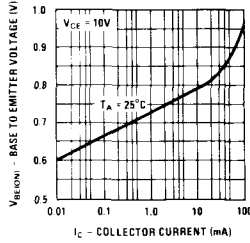
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|------|------|------|-----------|-------------------------|
| P_G | $f = 45 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 4 \text{ mA}$ | 29 | 33 | | dB | Fig. 1 |
| P_G | $f = 200 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 2 \text{ mA}$ | 17 | 19.5 | | dB | Unneutralized Fig. 3 |
| NF | $f = 200 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 2 \text{ mA}, R_S = 50\Omega$ | | 2.0 | 4.0 | dB | Fig. 3 |
| $rb'Cc$ | $f = 79.8 \text{ MHz}, V_{CB} = 10\text{V}, I_E = 5 \text{ mA}$ | | 6.5 | 15.0 | ps | |
| h_{fe} | $f = 100 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | 6 | 10 | | | |
| C_{ib} | $V_{EB} = 0.5\text{V}, I_C = 0$ | | 2.0 | 3.0 | pF | TO-92 |
| C_{cb} | $V_{CB} = 10\text{V}, I_E = 0$ | 0.25 | 0.33 | 0.40 | pF | TO-92 |
| g_{oe} | $f = 45 \text{ MHz}, V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | | | 125 | μ mho | |
| $roep$ | $f = 10.7 \text{ MHz}, V_{CE} = 10\text{V}, I_C = 2 \text{ mA}$ | 100k | | | Ω | |
| h_{FE} | $V_{CE} = 15\text{V}, I_C = 7 \text{ mA}$ | 40 | 100 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 20 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.3 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.85 | 0.92 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 20 | 30 | | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 35 | 45 | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.0 | | | V | |
| I_{CBO} | $V_{CB} = 30\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |

Process 47

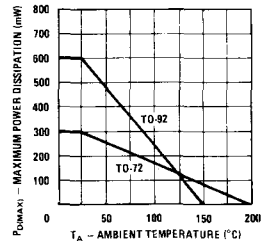
DC Pulse Current Gain vs Collector Current



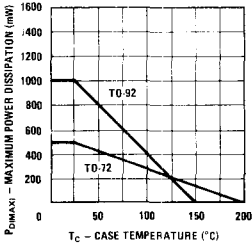
Base-Emitter On Voltage vs Collector Current



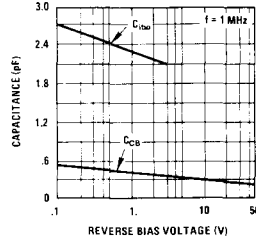
Maximum Power Dissipation vs Ambient Temperature



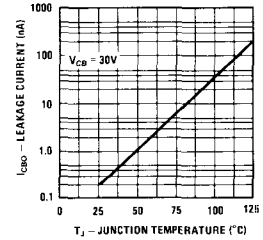
Maximum Power Dissipation vs Case Temperature



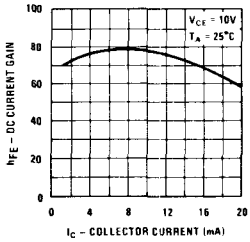
Capacitance vs Reverse Bias Voltage



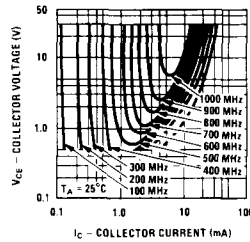
Collector-Base Diode Reverse Current vs Temperature



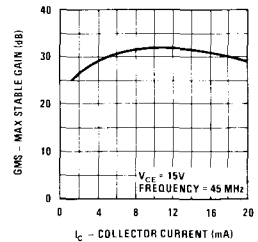
DC Current Gain vs Collector Current



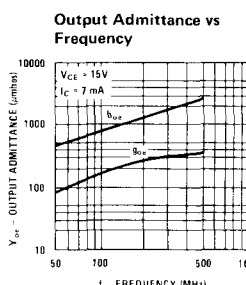
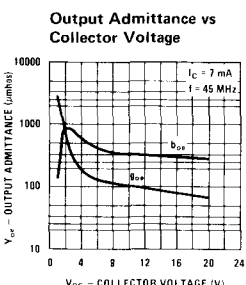
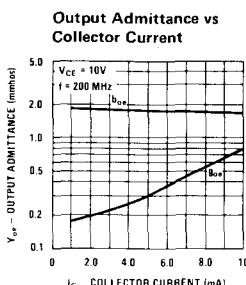
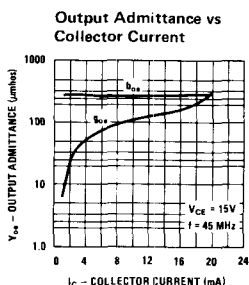
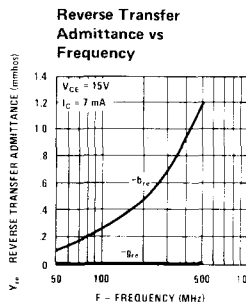
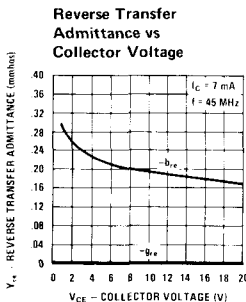
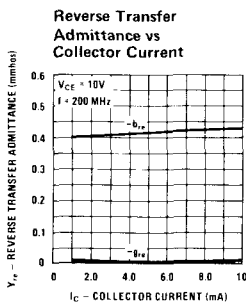
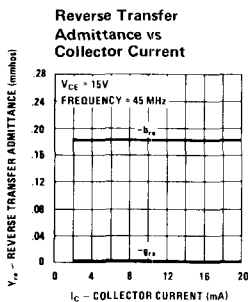
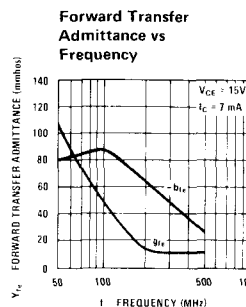
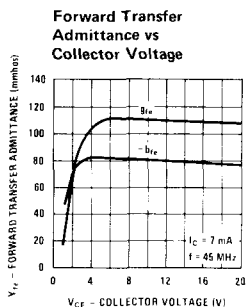
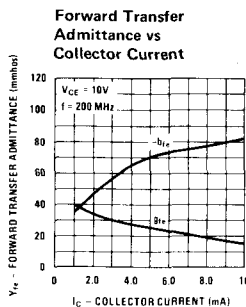
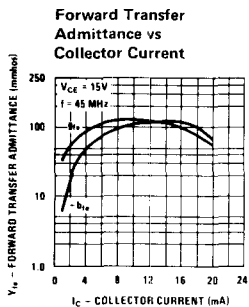
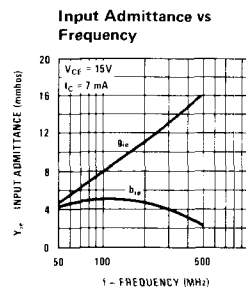
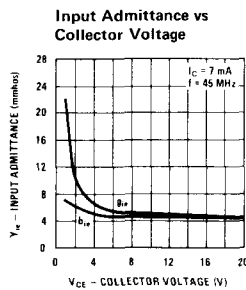
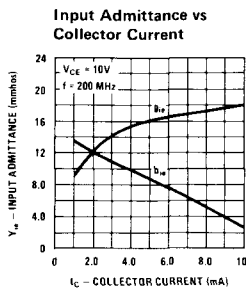
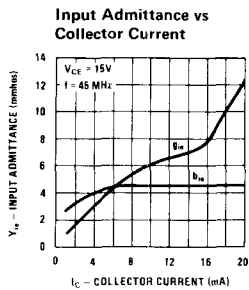
Contours of Constant Gain Bandwidth Product (fT)



Max Stable Gain vs Collector Current

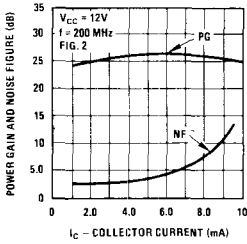


COMMON EMITTER VS FREQUENCY Y PARAMETERS



Process 47

Power Gain and Noise Figure vs Collector Current



Conversion Gain vs Collector Current

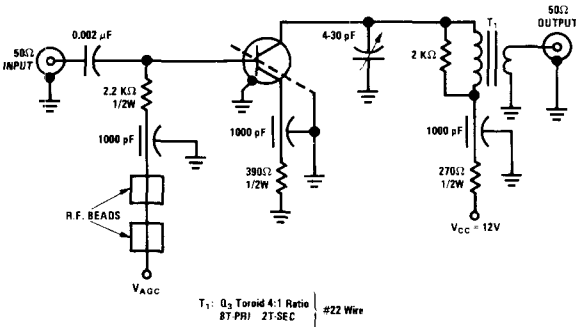
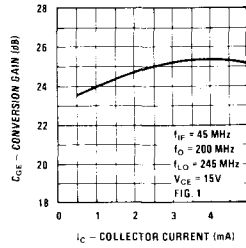


FIGURE 1. 45 MHz Power Gain Circuit

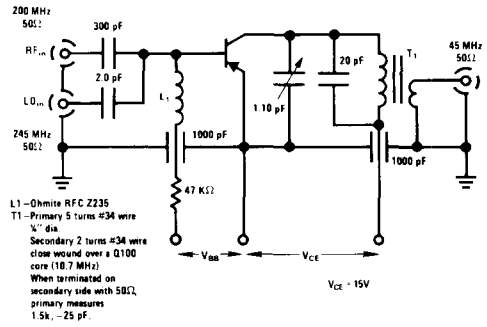


FIGURE 2. 200 MHz Conversion Gain Test Circuit

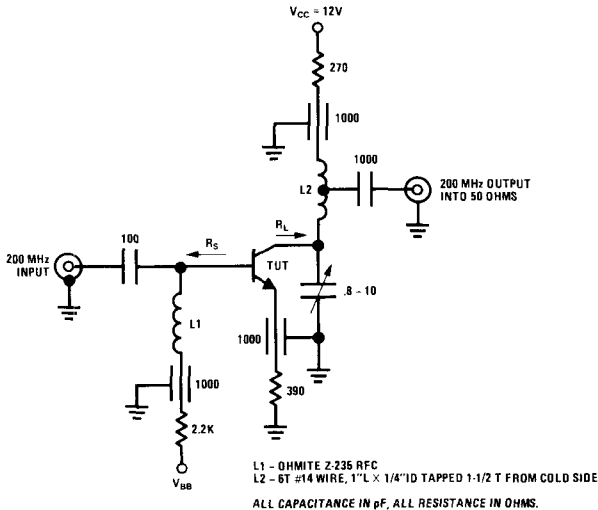
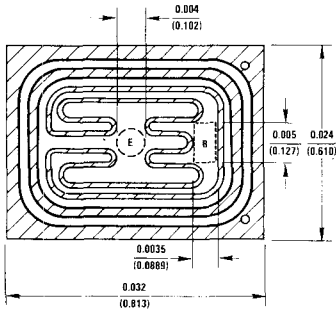


FIGURE 3. Unneutralized 200 MHz PG NF Test Circuit



DESCRIPTION

Process 48 is a nonoverlay triple diffused, silicon device with a field plate.

APPLICATION

This device was designed for application as a video output to drive color CRT.

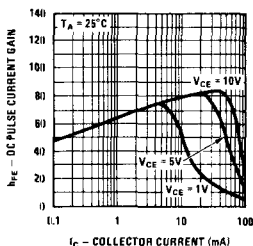
PRINCIPAL DEVICE TYPES

- TO-39 SE7056
- TO-202 SV7056, NSD134

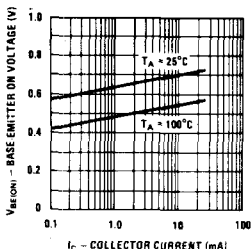
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|-------|-------|
| C_{cb} | $V_{CB} = 20\text{ V}$ | | 2.5 | 3.5 | pF | TO-39 |
| h_{fe} | $f = 20\text{ MHz}, V_{CE} = 100\text{ V}$ $I_C = 15\text{ mA}$ | 2.5 | 4.0 | | | |
| h_{fe} | $I_C = 1\text{ mA}, V_{CE} = 10\text{ V}$ | 15 | 50 | | | |
| h_{fe} | $I_C = 10\text{ mA}, V_{CE} = 10\text{ V}$ | 40 | 80 | 160 | | |
| h_{fe} | $I_C = 30\text{ mA}, V_{CE} = 10\text{ V}$ | 30 | 100 | | | |
| $V_{CE(SAT)}$ | $I_C = 20\text{ mA}, I_B = 2\text{ mA}$ | | 0.35 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 20\text{ mA}, I_B = 2\text{ mA}$ | | 0.74 | 0.85 | V | |
| C_{eb} | $V_{EB} = 0.5\text{ V}$ | | 45 | 70 | pF | |
| BV_{CEO} | $I_C = 5\text{ mA}$ | 220 | 280 | 320 | V | |
| BV_{CBO} | $I_C = 100\text{ }\mu\text{A}$ | 320 | 410 | 470 | V | |
| BV_{EBO} | $I_E = 100\text{ }\mu\text{A}$ | 7.0 | | | V | |
| I_{CBO} | $V_{CB} = 150\text{ V}$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 6\text{ V}$ | | | 100 | nA | |

Process 48

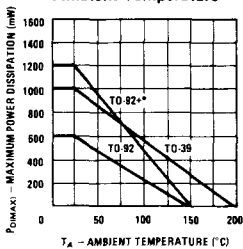
DC Pulse Current Gain vs Collector Current



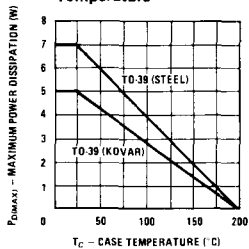
Base-Emitter On Voltage vs Collector Current



Maximum Power Dissipation vs Ambient Temperature

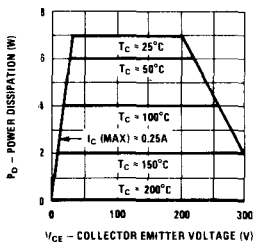


Maximum Power Dissipation vs Case Temperature

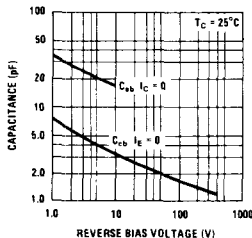


*One square inch of copper run

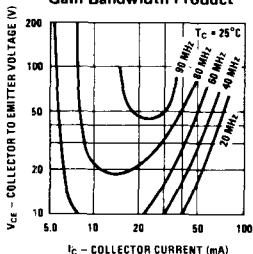
Guaranteed Maximum DC Power Dissipation vs Collector-Emitter Voltage, TO-39



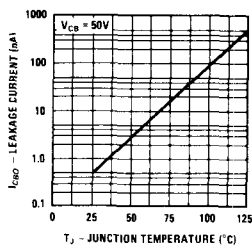
Collector to Base and Emitter to Base Capacitance vs Reverse Bias Voltage



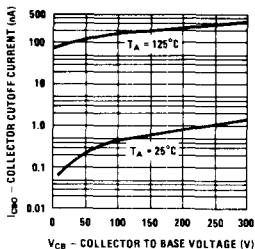
Contours of Constant Gain Bandwidth Product



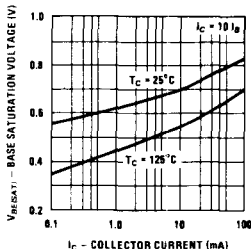
Collector-Base Diode Reverse Current vs Temperature



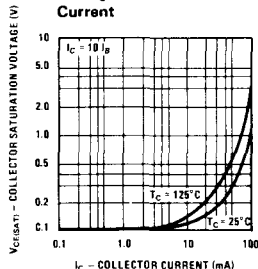
Collector Cutoff Current vs Collector Voltage



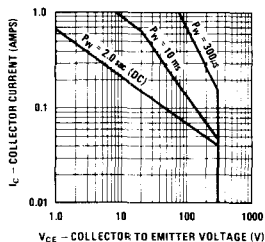
Base Saturation Voltage vs Collector Current



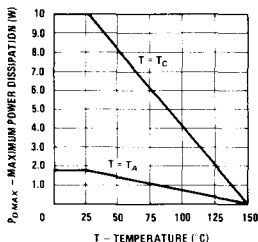
Collector Saturation Voltage vs Collector Current



Safe Operating Area, TO-202

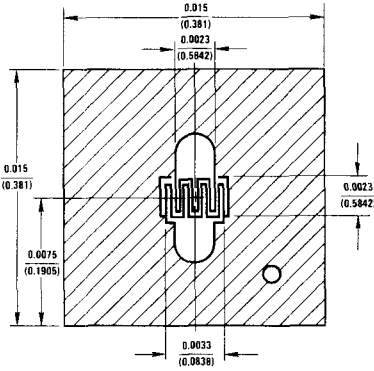


Maximum Power Dissipation TO-202 vs Case and Ambient Temperature





Process 49 NPN RF Amp



DESCRIPTION

Process 49 is an overlay double diffused silicon epitaxial device.

APPLICATION

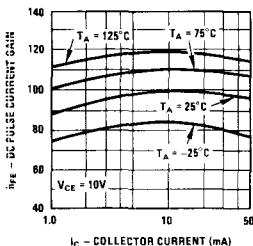
This device was designed for general RF amplifier and mixer applications to 250 MHz with collector current in the 1 mA to 20 mA range.

PRINCIPAL DEVICE TYPES

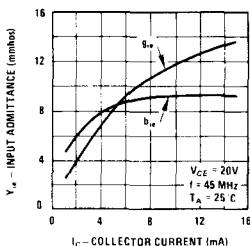
TO-92 (BEC) MPS6544, MP5H20

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|------|------------------|-------|
| P_G | $f = 45 \text{ MHz}, V_{CE} = 10V, I_C = 10 \text{ mA}$ | 25 | 30 | | dB | |
| f_t | $V_{CE} = 10V, I_C = 10 \text{ mA}$ | 400 | 700 | | MHz | |
| $r_b' C_c$ | $f = 31.9 \text{ MHz}, V_{CE} = 10V, I_C = 8 \text{ mA}$ | | 7.5 | 20.0 | ps | TO-92 |
| C_{cb} | $f = 1.0 \text{ MHz}, V_{CB} = 10V, I_E = 0$ | | 0.55 | 0.65 | pF | TO-92 |
| h_{FE} | $V_{CE} = 10V, I_C = 10 \text{ mA}$ | 30 | 100 | 250 | | |
| h_{FE} | $V_{CE} = 10V, I_C = 4 \text{ mA}$ | 30 | 90 | | | |
| $V_{BE(ON)}$ | $V_{CE} = 10V, I_C = 10 \text{ mA}$ | | 0.80 | 0.95 | V | |
| $V_{CE(SAT)}$ | $I_C = 30 \text{ mA}, I_C = 3 \text{ mA}$ | | 0.15 | 0.50 | V | |
| g_{oe} | $f = 45 \text{ MHz}, V_{CE} = 10V, I_C = 10 \text{ mA}$ | | | 100 | μmhos | |
| r_{oep} | $f = 4.5 \text{ MHz}, V_{CE} = 10V, I_C = 2 \text{ mA}$ | 80k | | | Ω | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 30 | 40 | 55 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 45 | | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.0 | | | V | |
| I_{CBO} | $V_{CB} = 30V$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 3.0V$ | | | 50 | nA | |

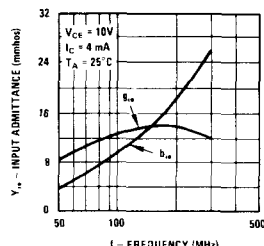
DC Pulse Current Gain vs Collector Current



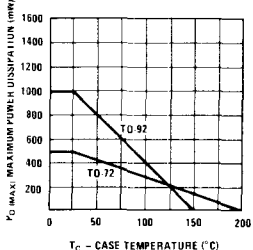
Input Admittance vs Collector Current



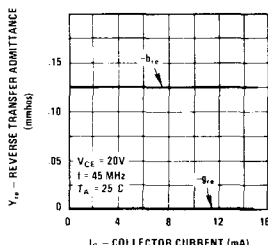
Input Admittance vs Frequency



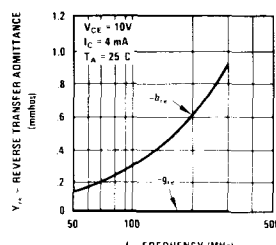
Maximum Power Dissipation vs Case Temperature



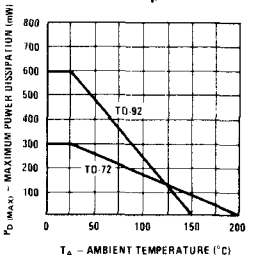
Reverse Transfer Admittance vs Collector Current



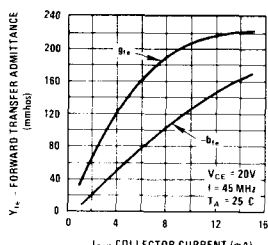
Reverse Transfer Admittance vs Frequency



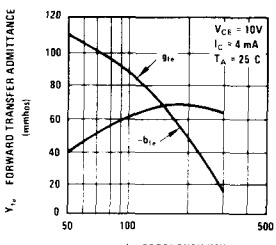
Maximum Power Dissipation vs Ambient Temperature



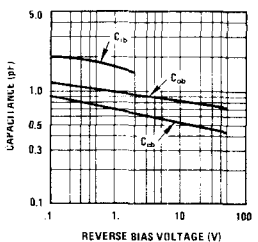
Forward Transfer Admittance vs Collector Current



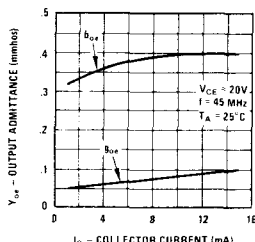
Forward Transfer Admittance vs Frequency



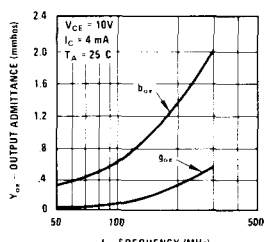
Capacitance vs Reverse Bias Voltage



Output Admittance vs Collector Current



Output Admittance vs Frequency



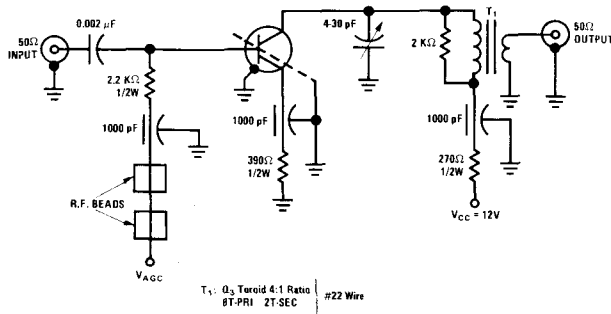
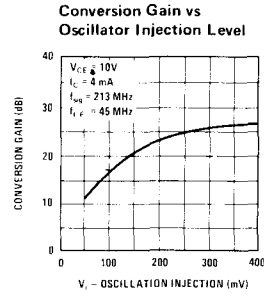
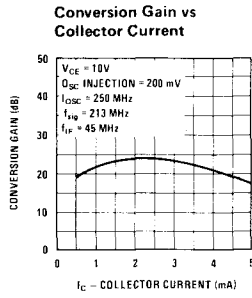
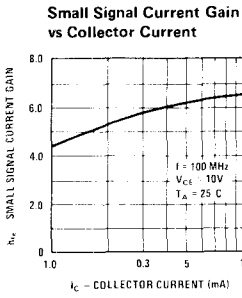


FIGURE 1. 45 MHz Power Gain Circuit

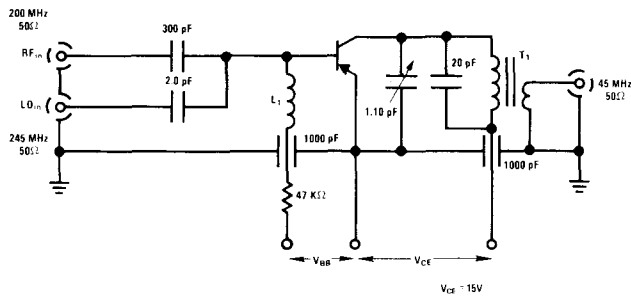
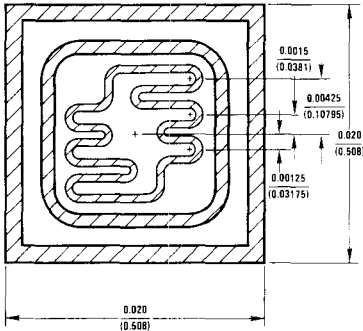


FIGURE 2. 200 MHz Conversion Gain Test Circuit


DESCRIPTION

Complements Process 09.

APPLICATION

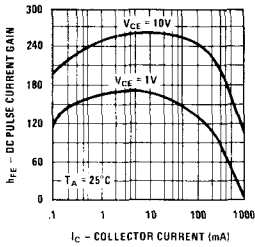
These devices are designed for general purpose amplifier applications at collector currents to 500 mA.

PRINCIPAL DEVICE TYPES

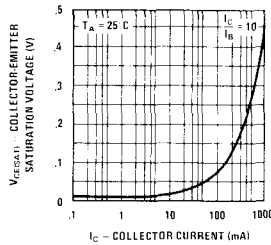
TO-92 MPS6563

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|----------------------|---|-----|------|------|-------|-------|
| COB | $V_{CB} = 10V$ | | 8 | 12 | pF | |
| C _{IB} | $V_{EB} = 1V$ | | 22 | 26 | pF | |
| NF | $V_{CE} = 10V, I_C = 1 mA$ $R_S = 1k, f = 1 kHz$ | | 0.5 | | dB | |
| f _T | $V_{CE} = 10V, I_C = 100 mA$ | | 400 | | MHz | |
| h _{FE} | $V_{CE} = 1V, I_C = 1 mA$ | 55 | 160 | 325 | | |
| h _{FE} | $V_{CE} = 1V, I_C = 50 mA$ | 50 | 150 | 300 | | |
| h _{FE} | $V_{CE} = 1V, I_C = 150 mA$ | 40 | 125 | 245 | | |
| h _{FE} | $V_{CE} = 1V, I_C = 500 mA$ | 20 | 65 | 125 | | |
| V _{CE(SAT)} | $I_C = 150 mA, I_B = 15 mA$ | | 0.1 | 0.2 | V | |
| V _{CE(SAT)} | $I_C = 500 mA, I_B = 50 mA$ | | 0.3 | 0.5 | V | |
| V _{BE(SAT)} | $I_C = 150 mA, I_B = 15 mA$ | | 0.8 | 0.96 | V | |
| V _{BE(SAT)} | $I_C = 500 mA, I_B = 50 mA$ | | 0.98 | 1.2 | V | |
| I _{CES} | $V_{CE} = 20V$ | | | 100 | nA | |
| I _{CEO} | $V_{CE} = 20V$ | | | 100 | nA | |
| BV _{CB0} | $I_C = 100 \mu A$ | 40 | | | V | |
| BV _{EBO} | $I_E = 10 \mu A$ | 7 | 8 | | V | |
| BV _{CEO} | $I_C = 10 mA$ | 20 | 30 | 40 | V | |

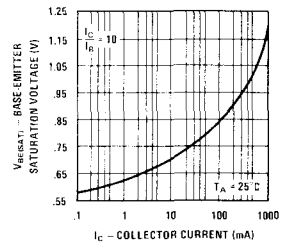
DC Pulse Current Gain vs Collector Current



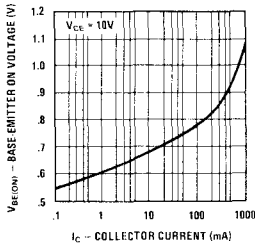
Collector-Emitter Saturation Voltage vs Collector Current



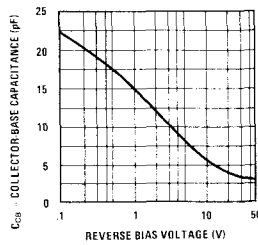
Base-Emitter Saturation Voltage vs Collector Current



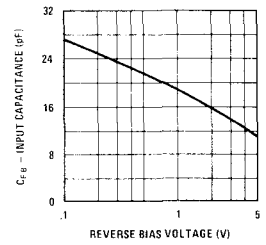
Base-Emitter On Voltage vs Collector Current



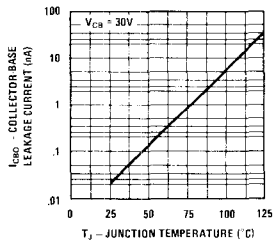
Collector-Base Capacitance vs Reverse Bias Voltage



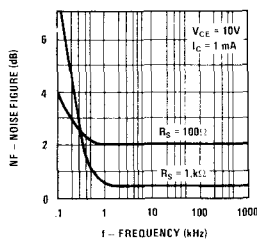
Input Capacitance vs Reverse Bias Voltage



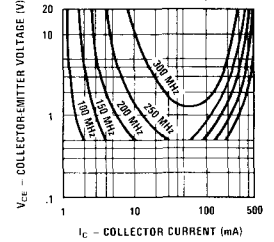
Collector-Base Diode Reverse Current vs Temperature



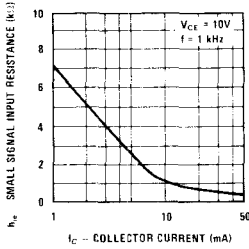
Noise Figure vs Frequency



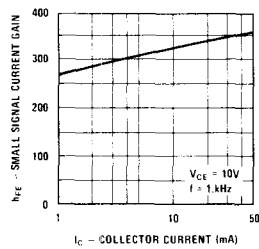
Contours of Constant Gain Bandwidth Product (f_T)



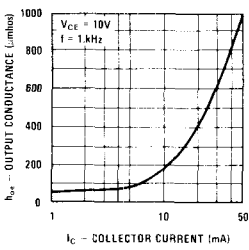
Small Signal Input Resistance vs Collector Current



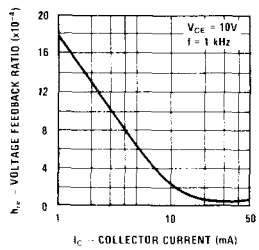
Small Signal Current Gain vs Collector Current



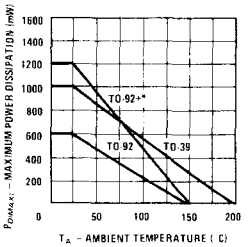
Small Signal Output Conductance vs Collector Current



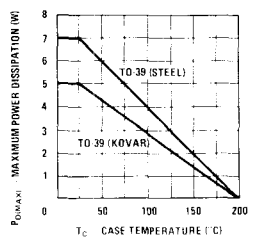
Small Signal Voltage Feedback Ratio vs Collector Current



Maximum Power Dissipation vs Ambient Temperature



Maximum Power Dissipation vs Case Temperature



*One square inch of copper run

DESCRIPTION

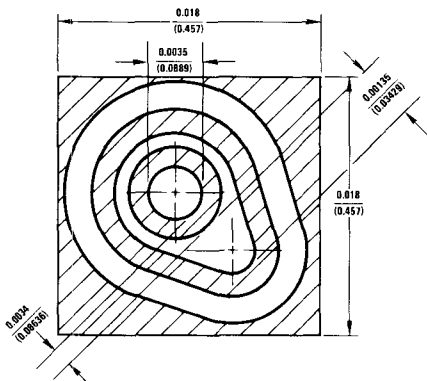
Process 62 is a nonoverlay double diffused, silicon epitaxial device. Complement to Process 07.

APPLICATION

These devices are designed for low level, high gain, low noise general purpose amplifier applications.

PRINCIPAL DEVICE TYPES

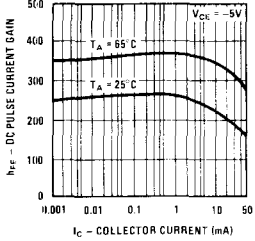
| | |
|-------|----------------------------|
| TO-18 | 2N3550 |
| TO-46 | 2N2605 |
| TO-92 | 2N5086 (EBC), 2N4058 (ECB) |



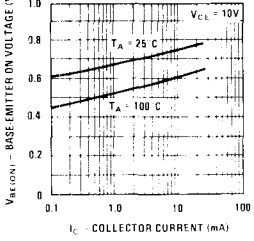
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| NF | $V_{CE} = 5V, I_C = 10 \mu A, R_S = 10 k\Omega, P_{BW} = 15.70 kHz$ | | 1.20 | 3 | dB | |
| h_{fe} | $V_{CE} = 5V, I_C = 500 \mu A, f = 20 MHz$ | 5 | 6 | | | |
| C_{eb} | $V_{EB} = 0.5V$ | | 6 | 7 | pF | |
| C_{cb} | $V_{CB} = 5V$ | | 3.5 | 5 | pF | |
| h_{FE} | $I_C = 10 \mu A, V_{CE} = 5V$ | 50 | 200 | 400 | | |
| h_{FE} | $I_C = 100 \mu A, V_{CE} = 5V$ | 50 | 250 | 500 | | |
| h_{FE} | $I_C = 500 \mu A, V_{CE} = 5V$ | 100 | 260 | 600 | | |
| h_{FE} | $I_C = 1 mA, V_{CE} = 5V$ | 50 | 270 | 500 | | |
| h_{FE} | $I_C = 10 mA, V_{CE} = 5V$ | 50 | 270 | 500 | | |
| $V_{CE(SAT)}$ | $I_C = 1 mA, I_B = 0.1 mA$ | | 0.05 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 mA, I_B = 1 mA$ | | 0.08 | 0.12 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 mA, I_B = 0.1 mA$ | | 0.68 | 0.70 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 mA, I_B = 1 mA$ | | 0.77 | 0.90 | V | |
| BV_{CEO} | $I_C = 1 mA$ | 35 | 65 | 70 | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 65 | | | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 7 | | | V | |
| I_{CBO} | $V_{CB} = 45V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 5V$ | | | 50 | nA | |

Process 62

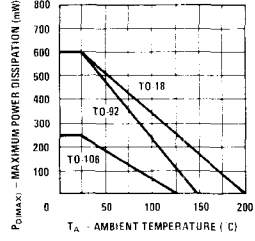
DC Pulse Current Gain vs Collector Current



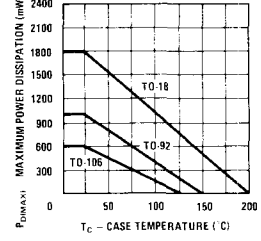
Base-Emitter On Voltage vs Collector Current



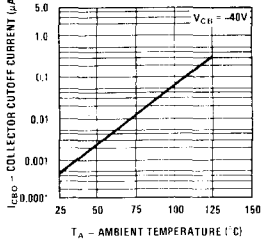
Maximum Power Dissipation vs Ambient Temperature



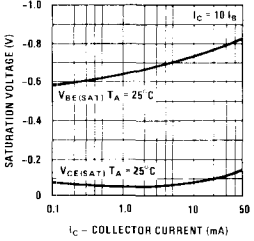
Maximum Power Dissipation vs Case Temperature



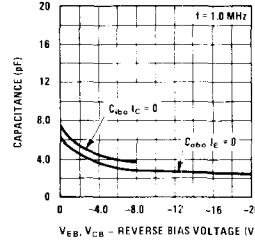
Collector Cutoff Current vs Ambient Temperature



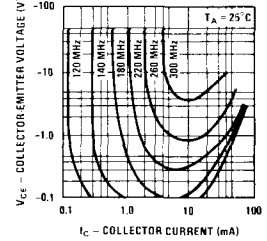
Collector and Base Saturation Voltage vs Collector Current



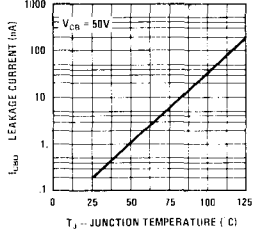
Input and Output Capacitances vs Reverse Bias Voltage



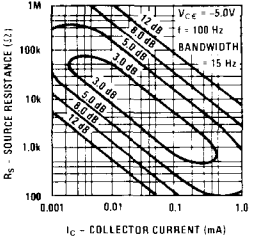
Contours of Constant Gain Bandwidth Product (fT)



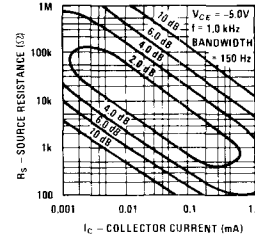
Collector-Base Diode Current vs Temperature



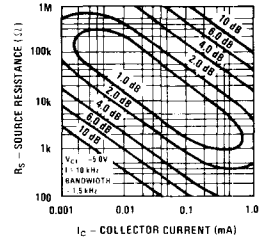
Contours of Constant Narrow Band Noise Figure



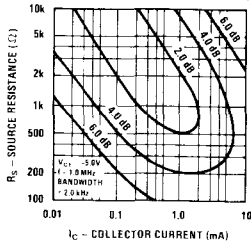
Contours of Constant Narrow Band Noise Figure



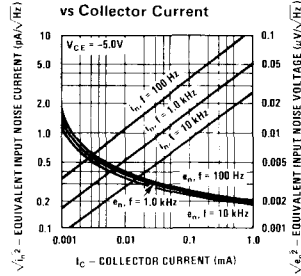
Contours of Constant Narrow Band Noise Figure



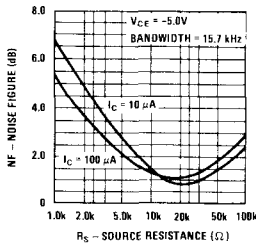
Contours of Constant Narrow Band Noise Figure



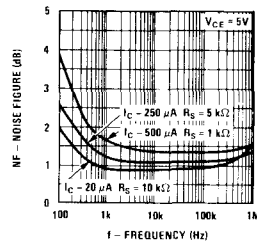
Equivalent Input Noise Voltage and Noise Current vs Collector Current



Wide Band Noise Figure vs Source Resistance



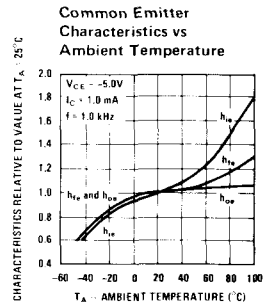
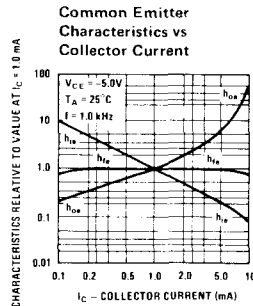
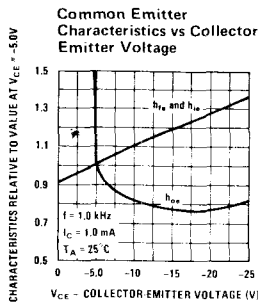
Noise Figure vs Frequency

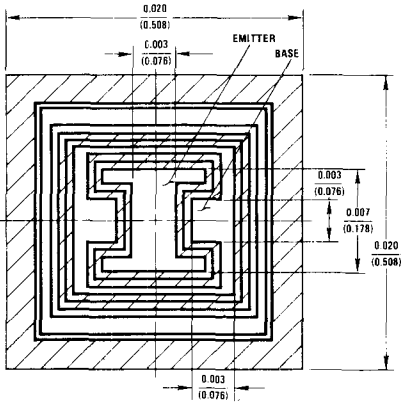


SMALL SIGNAL CHARACTERISTICS (f = 1.0 kHz)

| SYMBOL | CHARACTERISTIC | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------|------|------------------|---|
| h_{ie} | Input Resistance | 2.5 | 8.0 | 20 | $k\Omega$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |
| h_{oe} | Output Conductance | 5.0 | 19 | 50 | μmho | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |
| h_{re} | Voltage Feedback Ratio | | 10 | 10 | $\times 10^{-4}$ | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |
| h_{fe} | Small Signal Current Gain | 100 | 250 | 800 | | $I_C = 1.0 \text{ mA}$ $V_{CE} = -5.0V$ |

TYPICAL COMMON EMITTER CHARACTERISTICS (f = 1.0 kHz)




DESCRIPTION

Process 63 is a nonoverlay double diffused, silicon epitaxial device. Complement to Process 20.

APPLICATION

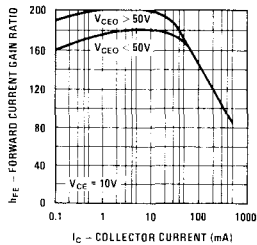
This device was designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA.

PRINCIPAL DEVICE TYPES

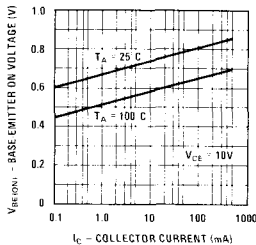
| | |
|--------|----------------------------|
| TO-5 | 2N2905A |
| TO-18 | 2N2907A |
| TO-92 | 2N4403 (EBC), 2N3702 (ECB) |
| TO-105 | 2N3645 |
| TO-106 | 2N4143 |
| TO-92+ | TN2905A |

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|------|------|------|-------|--------|
| t_{on} | $I_C = 150 \text{ mA}$, $I_{B1} = 15 \text{ mA}$ | | 30 | 45 | ns | Fig. 1 |
| t_{off} | $I_C = 150 \text{ mA}$, $I_{B2} = 15 \text{ mA}$ | | 220 | 290 | ns | Fig. 2 |
| C_{cb} | $V_{CB} = 10 \text{ V}$ | | 6 | 8 | pF | TO-18 |
| C_{eb} | $V_{EB} = 0.50 \text{ V}$ | | 15 | 18 | pF | TO-18 |
| h_{fe} | $I_C = 20 \text{ mA}$, $V_{CE} = 20 \text{ V}$, $f = 100 \text{ MHz}$ | 1.5 | 2.5 | | | |
| NF (spot) | $I_C = 100 \mu\text{A}$, $V_{CE} = 10 \text{ V}$, $R_S = 1 \text{ k}$ $f = 1 \text{ kHz}$ | | 1.5 | 3 | dB | |
| h_{FE} | $I_C = 1 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 50 | 140 | 400 | | |
| h_{FE} | $I_C = 10 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 50 | 140 | 400 | | |
| h_{FE} | $I_C = 100 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 50 | 95 | 400 | | |
| h_{FE} | $I_C = 150 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 40 | 150 | 350 | | |
| h_{FE} | $I_C = 500 \text{ mA}$, $V_{CE} = 10 \text{ V}$ | 40 | 50 | 200 | | |
| $V_{CE(SAT)}$ | $I_C = 150 \text{ mA}$, $I_B = 15 \text{ mA}$ | | 0.25 | 0.40 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | 0.60 | 1.00 | V | |
| $V_{BE(SAT)}$ | $I_C = 150 \text{ mA}$, $I_B = 15 \text{ mA}$ | | 0.90 | 1.3 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | 1.10 | 1.6 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 35 | 50 | 65 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 45 | 70 | 95 | V | |
| BV_{CES} | $I_C = 10 \mu\text{A}$ | 0.45 | | 90 | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 7 | | | V | |
| I_{CBO} | $V_{CB} = 40 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3 \text{ V}$ | | | 50 | nA | |

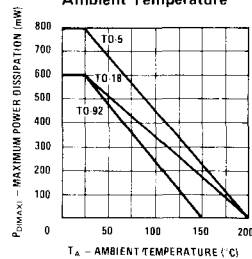
DC Pulse Current Gain vs Collector Current



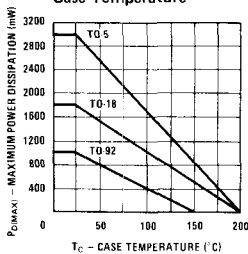
Base-Emitter On Voltage vs Collector Current



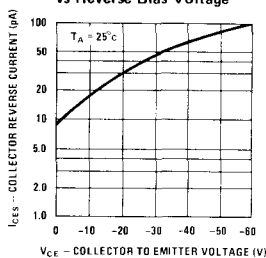
Maximum Power Dissipation vs Ambient Temperature



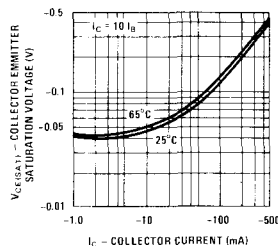
Maximum Power Dissipation vs Case Temperature



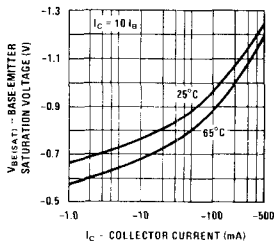
Collector Reverse Current vs Reverse Bias Voltage



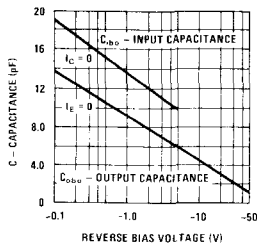
Pulsed Collector Saturation Voltage vs Collector Current



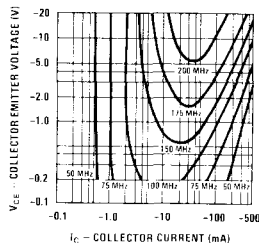
Pulsed Base Saturation Voltage vs Collector Current



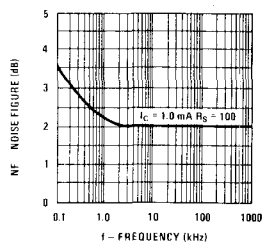
Input and Output Capacitances vs Reverse Bias Voltage



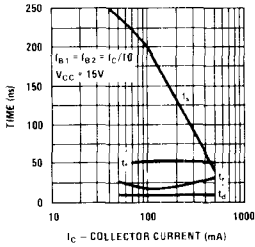
Contours of Constant Gain Bandwidth Product (f_T)



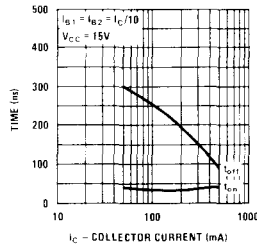
Noise Figure vs Frequency



Switching Times vs Collector Current



Turn On and Turn Off Times vs Collector Current



Rise Time vs Collector and Turn On Base Currents

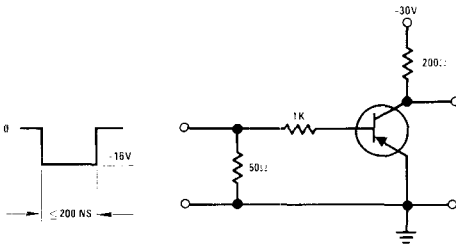
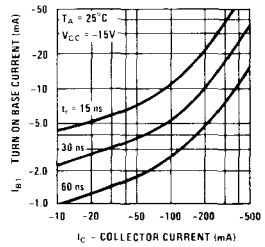


FIGURE 1. Saturated Turn-On Switching Time Test Circuit

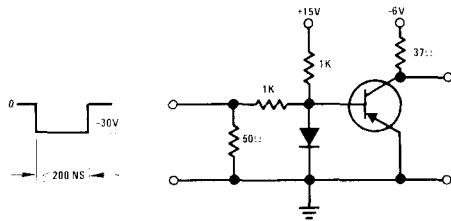
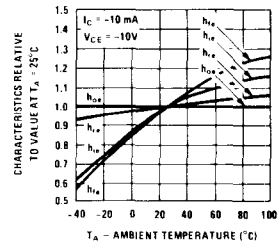
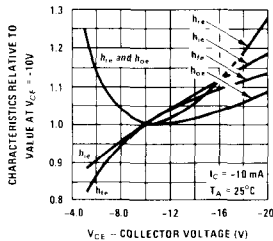
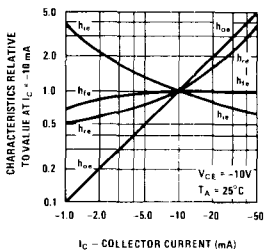


FIGURE 2. Saturated Turn-Off Switching Time Test Circuit

SMALL SIGNAL CHARACTERISTICS (f = 1.0 kHz)

| SYMBOL | CHARACTERISTIC | MIN. | TYP. | MAX. | UNITS | TEST CONDITIONS |
|----------|---------------------------|------|------|------|------------------|--|
| h_{ie} | Input Resistance | | 480 | 2000 | ohms | $I_C = 10 \text{ mA}$ $V_{CE} = -10\text{V}$ |
| h_{oe} | Output Conductance | | 80 | 1200 | μhos | $I_C = 10 \text{ mA}$ $V_{CE} = -10\text{V}$ |
| h_{re} | Voltage Feedback Ratio | | 162 | 1500 | $\times 10^{-6}$ | $I_C = 10 \text{ mA}$ $V_{CE} = -10\text{V}$ |
| h_{fe} | Small Signal Current Gain | 100 | | | | $I_C = 10 \text{ mA}$ $V_{CE} = -10\text{V}$ |

TYPICAL COMMON EMITTER CHARACTERISTICS (f = 1.0 kHz)



DESCRIPTION

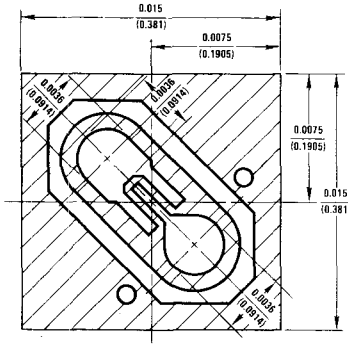
Process 64 is an overlay double diffused, gold doped silicon epitaxial device. Complement to Process 22.

APPLICATION

This device was designed for high speed saturated switching applications at collector currents to 200 mA.

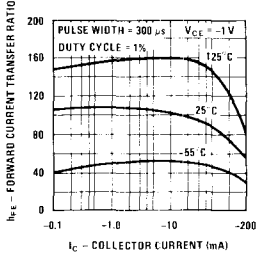
PRINCIPAL DEVICE TYPES

TO-52 2N2894A
TO-92 PN4313

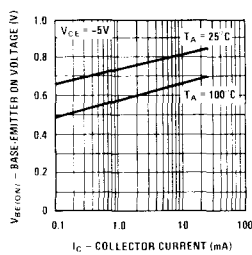


| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|--------|
| t_{on} | $I_C = 30 \text{ mA}, I_{B1} = 3 \text{ mA}$ | | 10 | 20 | ns | Fig. 1 |
| t_{off} | $I_C = 30 \text{ mA}, I_{B2} = 3 \text{ mA}$ | | 21 | 30 | ns | Fig. 1 |
| t_s | $I_C = I_{B1} = I_{B2} = 10 \text{ mA}$ | | 15 | 20 | ns | |
| C_{ob} | $V_{CE} = 5 \text{ V}$ | | 3.0 | 4.5 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.5 \text{ V}$ | | 5.0 | 6.0 | pF | TO-18 |
| h_{fe} | $f = 100 \text{ MHz}, I_C = 30 \text{ mA}, V_{CE} = 10 \text{ V}$ | 8 | 12 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 65 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 1 \text{ V}$ | 30 | 95 | | | |
| h_{FE} | $I_C = 30 \text{ mA}, V_{CE} = 1 \text{ V}$ | 40 | 95 | 130 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1 \text{ V}$ | 30 | 85 | | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.08 | 0.15 | V | |
| $V_{CE(SAT)}$ | $I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$ | | 0.11 | 0.19 | V | |
| $V_{CE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.28 | 0.45 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.80 | 0.92 | V | |
| $V_{BE(SAT)}$ | $I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$ | | 0.90 | 1.15 | V | |
| $V_{BE(SAT)}$ | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 1.10 | 1.50 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 12 | | 15 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 12 | | 15 | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 4.5 | | | V | |
| I_{CES} | $V_{CE} = 10 \text{ V}$ | | | 50 | nA | |

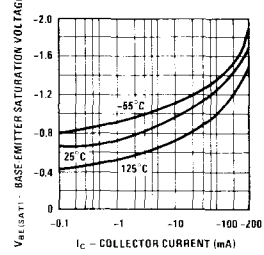
Pulsed DC Current Gain vs Collector Current



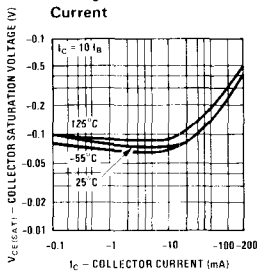
Base-Emitter On Voltage vs Collector Current



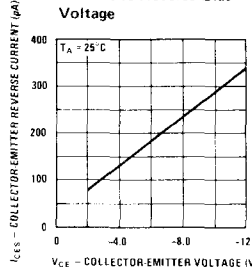
Base Saturation Voltage vs Collector Current



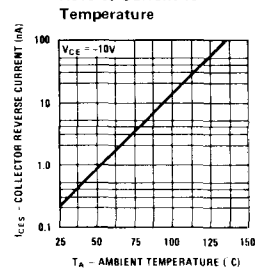
Collector Saturation Voltage vs Collector Current



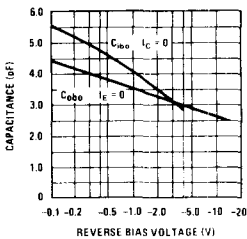
Collector-Base Reverse Current vs Reverse Bias Voltage



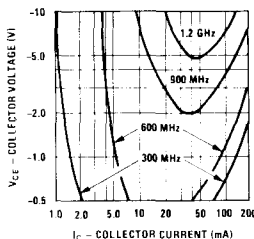
Collector-Base Diode Reverse Current vs Temperature



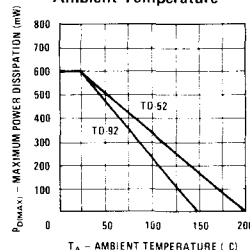
Input and Output Capacitance vs Reverse Bias Voltage



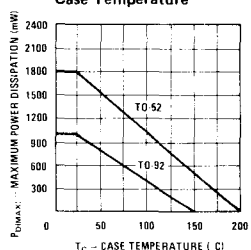
Contours of Constant Gain Bandwidth Product (fT)

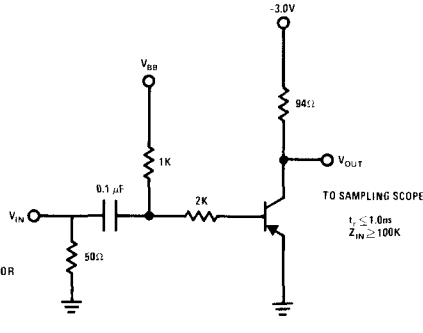
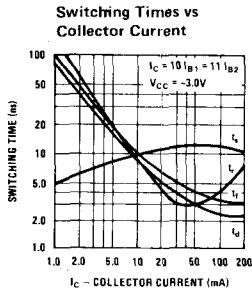


Maximum Power Dissipation vs Ambient Temperature



Maximum Power Dissipation vs Case Temperature





PULSE GENERATOR
 $t_r \leq 1.0$ ns
 PW = 400 ns
 PR = 150
 $Z_{in} = 50\Omega$

$t_{on} V_{BB} = 0, V_{IN} = -6.85V$
 $t_{off} V_{BB} = -9.85V, V_{IN} = +11.7V$

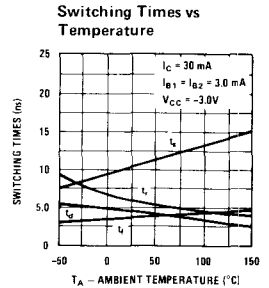
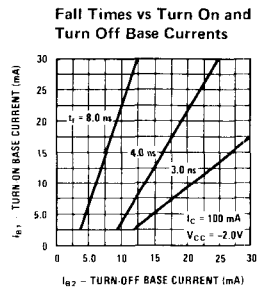
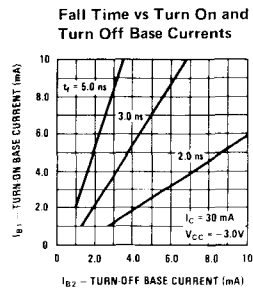
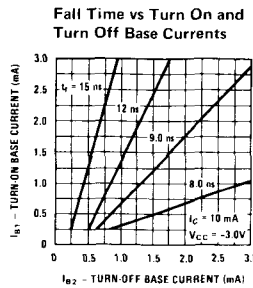
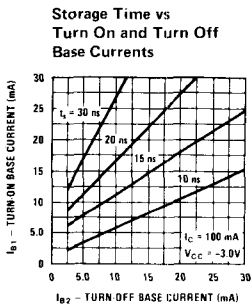
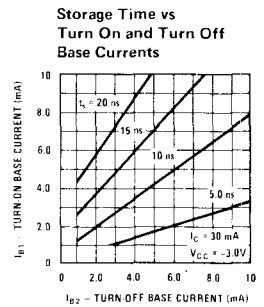
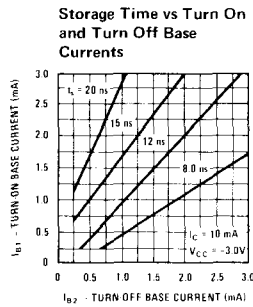
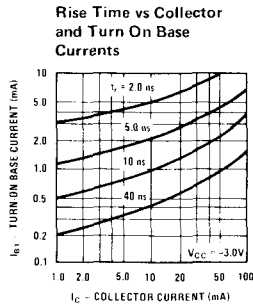
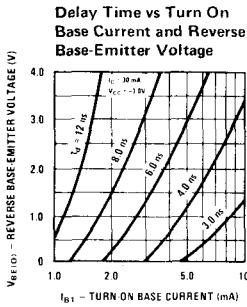


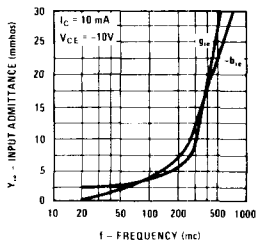
FIGURE 1. Switching Time Test Circuit



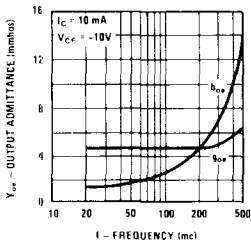
Process 64

COMMON EMITTER VS FREQUENCY Y PARAMETERS

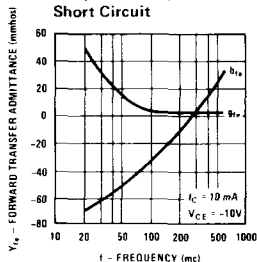
Input Admittance vs Frequency-Output Short Circuit



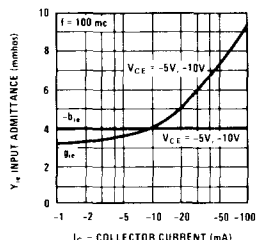
Output Admittance vs Frequency-Input Short Circuit



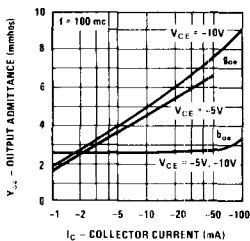
Forward Transfer Admittance vs Frequency-Output Short Circuit



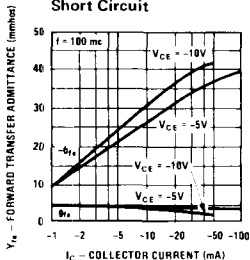
Input Admittance vs Collector Current and Voltage-Output Short Circuit



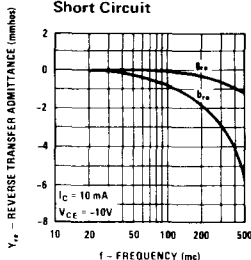
Output Admittance vs Collector Current and Voltage-Input Short Circuit



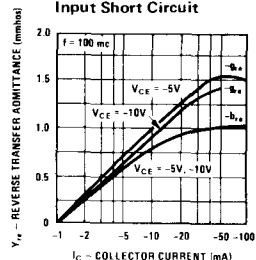
Forward Transfer Admittance vs Collector Current and Voltage-Output Short Circuit



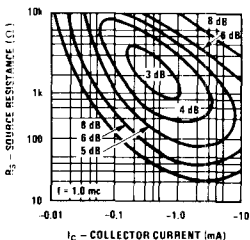
Reverse Transfer Admittance vs Frequency-Input Short Circuit



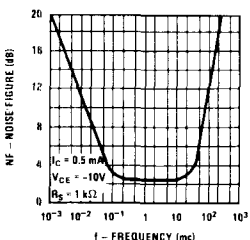
Reverse Transfer Admittance vs Collector Current and Voltage-Input Short Circuit



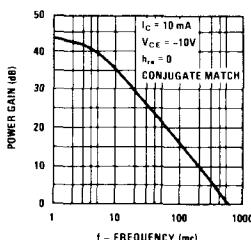
Noise Figure vs Source Resistance and Collector Current



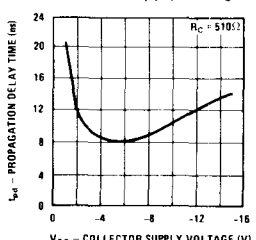
Noise Figure vs Frequency



M.A.G. vs Frequency



Propagation Delay Time vs Collector Supply Voltage



DESCRIPTION

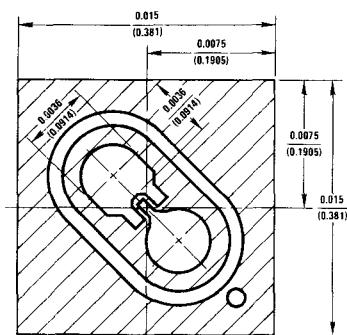
Process 65 is an overlay double diffused, gold doped, silicon epitaxial device.

APPLICATION

This device was designed for very high speed saturate switching at collector currents to 50 mA.

PRINCIPAL DEVICE TYPES

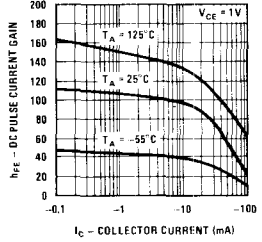
TO-18 2N4208
TO-92 MPS3640, 2N5771



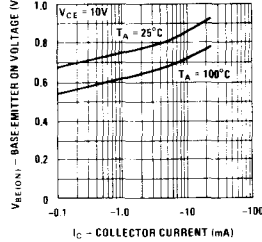
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|--------|
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | | 18 | 25 | ns | Fig. 1 |
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | | 11 | 15 | ns | Fig. 1 |
| t_s | $I_C = I_{B1} = I_{B2} = 10 \text{ mA}$ | | 15 | 20 | ns | |
| C_{ob} | $V_{CB} = 5 \text{ V}$ | | 2 | 3 | pF | TO-18 |
| C_{ib} | $V_{EB} = .5 \text{ V}$ | | 2.5 | 3.5 | pF | |
| h_{fe} | $V_{CE} = 10 \text{ V}, I_C = 10 \text{ mA}, f = 100 \text{ MHz}$ | 6.5 | 9 | | | |
| h_{fe} | $I_C = 1 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 60 | | | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 1 \text{ V}$ | 30 | 85 | 120 | | |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 75 | | | |
| h_{fe} | $I_C = 100 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 60 | | | |
| h_{fe} | $I_C = 1 \text{ mA}, V_{CE} = .5 \text{ V}$ | 20 | 60 | | | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = .3 \text{ V}$ | 20 | 67 | 150 | | |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 20 | 60 | | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1 \text{ mA}$ | | 0.10 | 0.13 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.12 | 0.15 | V | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.25 | 0.50 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}, I_B = .1 \text{ mA}$ | | 0.73 | 0.8 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.88 | 0.95 | V | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 1.00 | 1.5 | V | |
| BV_{CEO} | $I_C = 3 \text{ mA}$ | 12 | 15 | 20 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 25 | 30 | 40 | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 4.5 | | | V | |
| I_{CBO} | $V_{CB} = 3 \text{ V}$ | | | 50 | nA | |

Process 65

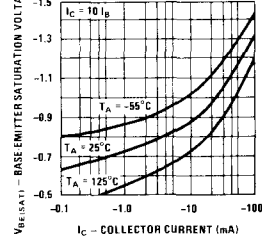
DC Pulse Current Gain vs Collector Current



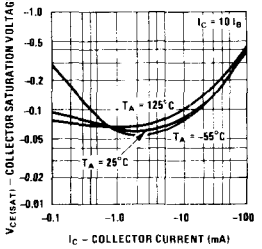
Base-Emitter On Voltage vs Collector Current



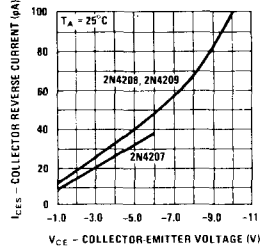
Base Saturation Voltage vs Collector Current



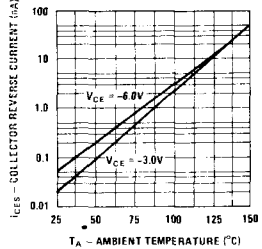
Collector Saturation Voltage vs Collector Current



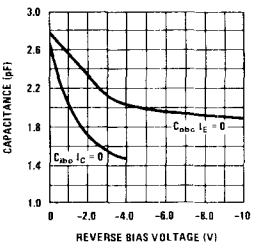
Collector Reverse Current vs Collector-Emitter Voltage



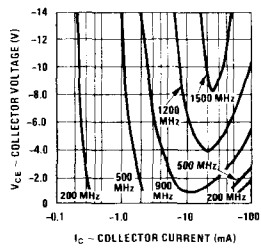
Collector Reverse Current vs Ambient Temperature



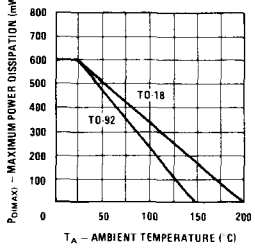
Input and Output Capacitance vs Reverse Bias Voltage



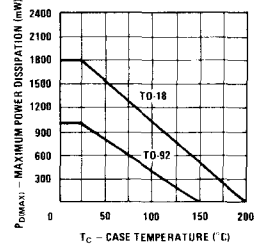
Contours of Constant Gain Bandwidth Product (fT)



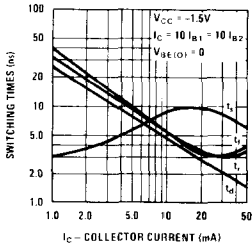
Maximum Power Dissipation vs Ambient Temperature



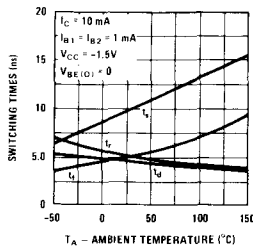
Maximum Power Dissipation vs Case Temperature



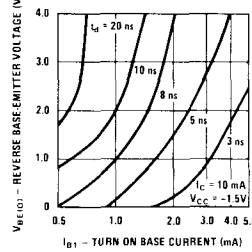
Switching Times vs Collector Current



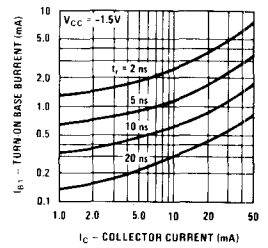
Switching Times vs Ambient Temperature



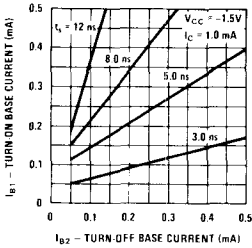
Delay Time vs Turn On Base Current and Reverse Base-Emitter Voltage



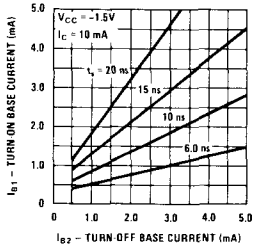
Rise Time vs Collector and Turn On Base Currents



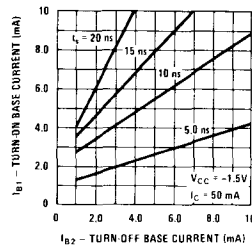
Storage Time vs Turn On and Turn Off Base Currents



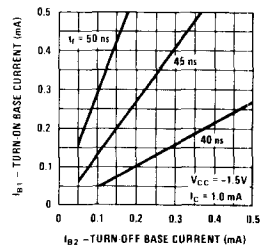
Storage Time vs Turn On and Turn Off Base Currents



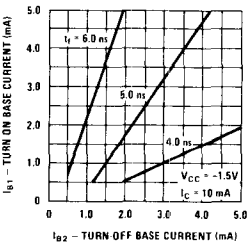
Storage Time vs Turn On and Turn Off Base Currents



Fall Time vs Turn On and Turn Off Base Currents



Fall Time vs Turn On and Turn Off Base Currents



Fall Time vs Turn On and Turn Off Base Currents

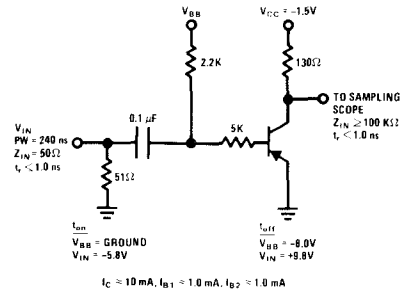
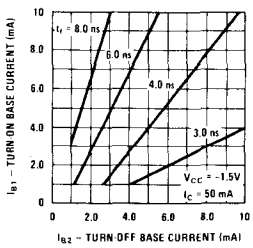


FIGURE 1. t_{on} and t_{off} Test Circuit

DESCRIPTION

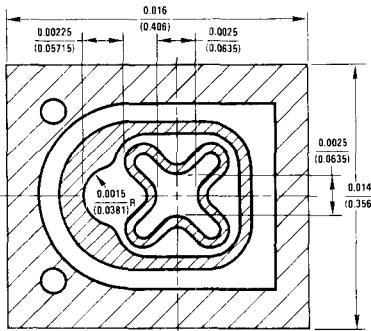
Process 66 is a nonoverlay double diffused, gold doped, silicon epitaxial device. Complement to Process 23.

APPLICATION

This device was designed for general purpose amplifier and switching applications at collector currents of 10 μ A to 100 mA.

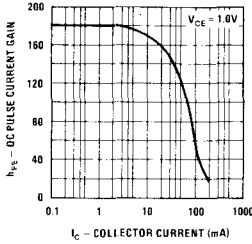
PRINCIPAL DEVICE TYPES

TO-92 2N3906

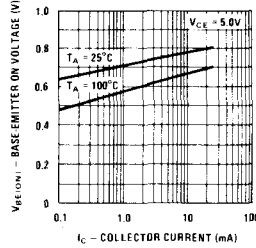


| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|-------------------|--|-----|------|------|-------|-------|
| t_{off} | $I_C = 10 \text{ mA}, I_{B2} = 1 \text{ mA}$ | | 125 | 300 | ns | |
| t_{on} | $I_C = 10 \text{ mA}, I_{B1} = 1 \text{ mA}$ | | 30 | 70 | ns | |
| C_{ob} | $V_{CE} = 5 \text{ V}$ | | 3.0 | 4.5 | pF | TO-92 |
| C_{ib} | $V_{EB} = 0.5 \text{ V}$ | | 6.0 | 10.0 | pF | TO-92 |
| h_{fe} | $f = 100 \text{ MHz}, V_{CE} = 20 \text{ V}, I_C = 10 \text{ mA}$ | 2.5 | 6.0 | | | |
| NF (wide band) | $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}, R_S = 1 \text{ k}\Omega$ | | 2.0 | 4.0 | dB | |
| h_{fe} | $I_C = 0.1 \text{ mA}, V_{CE} = 1 \text{ V}$ | 40 | 80 | | | |
| h_{fe} | $I_C = 1 \text{ mA}, V_{CE} = 1 \text{ V}$ | 50 | 120 | | | |
| h_{fe} | $I_C = 10 \text{ mA}, V_{CE} = 1 \text{ V}$ | 50 | 150 | 300 | | |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = 1 \text{ V}$ | 40 | 110 | | | |
| h_{fe} | $I_C = 100 \text{ mA}, V_{CE} = 1 \text{ V}$ | 20 | 40 | | | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.07 | 0.25 | V | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.12 | 0.40 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ | | 0.75 | 0.85 | V | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.85 | 0.95 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 30 | 45 | 60 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 45 | | 70 | V | |
| BV_{CES} | $I_C = 10 \mu\text{A}$ | 45 | | 70 | V | |
| BV_{EBO} | $I_C = 10 \mu\text{A}$ | 5.0 | | | V | |
| I_{CBO} | $V_{CB} = 25 \text{ V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4 \text{ V}$ | | | 50 | nA | |

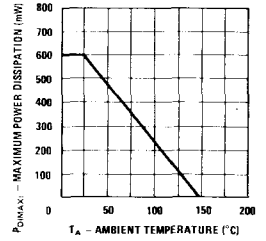
DC Pulse Current Gain vs Collector Current



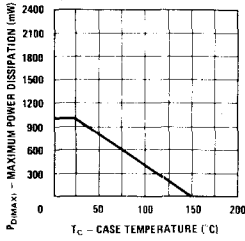
Base-Emitter On Voltage vs Collector Current



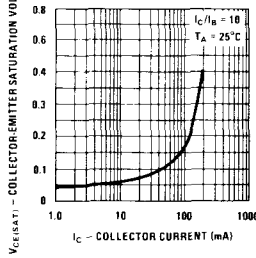
Maximum Power Dissipation vs Ambient Temperature TO-92



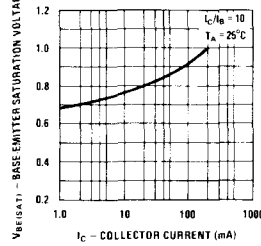
Maximum Power Dissipation vs Case Temperature TO-92



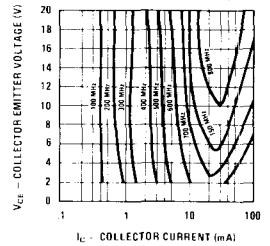
Collector-Emitter Saturation Voltage vs Collector Current



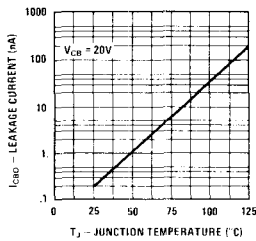
Base-Emitter Saturation Voltage vs Collector Current



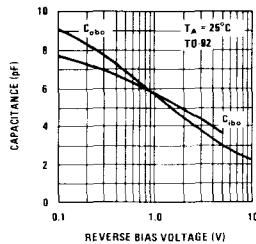
Contours of Constant Gain Bandwidth Product (fT)



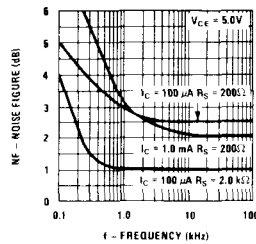
Collector-Base Diode Reverse Current vs Temperature



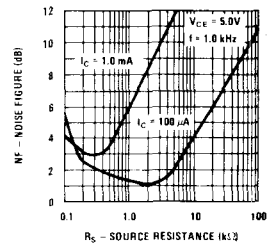
Common Base Open Circuit Input and Output Capacitance vs Reverse Bias Voltage



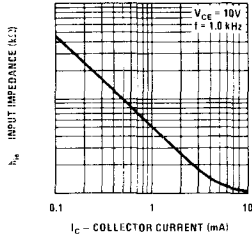
Noise Figure vs Frequency



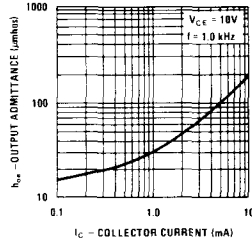
Noise Figure vs Source Resistance



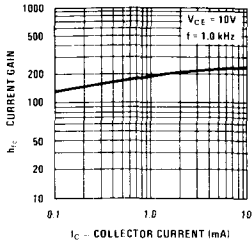
Input Impedance



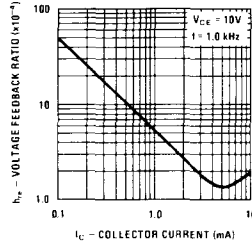
Output Admittance



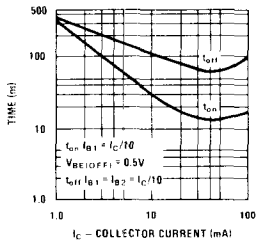
Current Gain



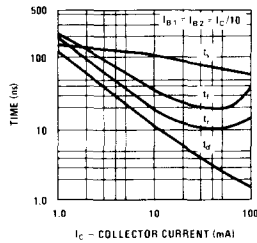
Voltage Feedback Ratio



Turn On and Turn Off Times vs Collector Current



Switching Times vs Collector Current



DESCRIPTION

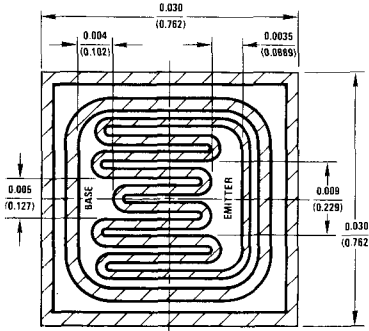
Process 67 is a nonoverlay double diffused silicon device. Complement to Process 12.

APPLICATION

This device is designed for general purpose amplifier and switching applications at currents to one amp.

PRINCIPAL DEVICE TYPES

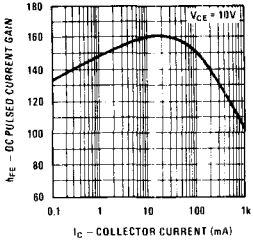
| | |
|--------|-----------------|
| TO-39 | 2N4033 |
| TO-92 | MPS4356, MPSA55 |
| TO-92+ | TN4033 |



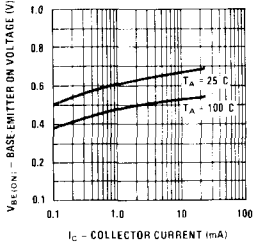
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|------|-----|-------|-------|
| t_{on} | $I_C = 500 \text{ mA}, I_{B1} = 50 \text{ mA}$ | 20 | 25 | 60 | ns | |
| t_{off} | $I_C = 500 \text{ mA}, I_{B2} = 50 \text{ mA}$ | 200 | 250 | 400 | ns | |
| C_{ob} | $V_{CB} = 10\text{V}$ | | 11 | 15 | pF | TO-39 |
| C_{ib} | $V_{EB} = 0.50\text{V}$ | | 65 | 90 | pF | TO-39 |
| h_{fe} | $V_{CE} = 10\text{V}, I_C = 50 \text{ mA}, f = 100 \text{ MHz}$ | 1.5 | 2 | | | |
| NF (spot) | $I_C = 100 \mu\text{A}, R_S = 1\text{k}, V_{CE} = 10\text{V}, f = 1 \text{ kHz}$ | | 0.5 | 4 | dB | |
| h_{FE} | $I_C = 0.10 \text{ mA}, V_{CE} = 10\text{V}$ | 36 | 135 | | | |
| h_{FE} | $I_C = 1.0 \text{ mA}, V_{CE} = 10\text{V}$ | 40 | 145 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ | 42 | 160 | 370 | | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}$ | 40 | 150 | 350 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 10\text{V}$ | 35 | 130 | | | |
| h_{FE} | $I_C = 1\text{A}, V_{CE} = 10\text{V}$ | 25 | 100 | | | |
| $V_{CE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.15 | 0.2 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.4 | 0.5 | V | |
| $V_{BE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.8 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.95 | 1.2 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 60 | 80 | 90 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 80 | 120 | | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 6 | | | V | |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 4\text{V}$ | | | 50 | nA | |

Process 67

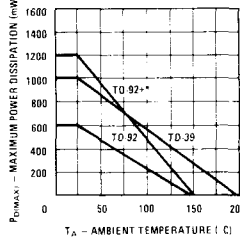
DC Pulse Current Gain vs Collector Current



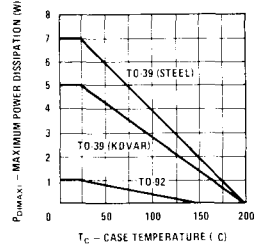
Base-Emitter On Voltage vs Collector Current



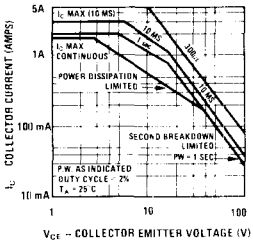
Maximum Power Dissipation vs Ambient Temperature



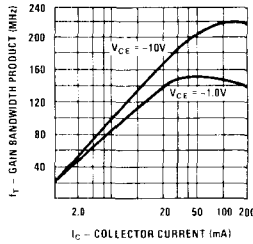
Maximum Power Dissipation vs Case Temperature



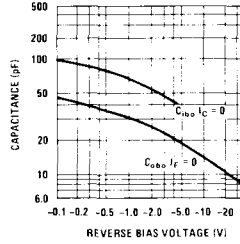
Safe Operating Area TO-39 With "Wake Field" Type 296-4 Heat Sink



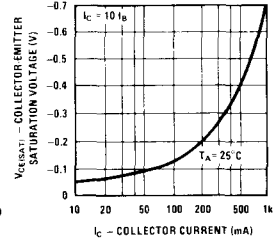
Gain Bandwidth Product vs Collector Current



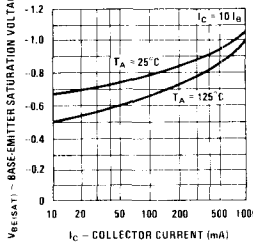
Common Base Open Circuit Input and Output Capacitance vs Reverse Bias Voltage



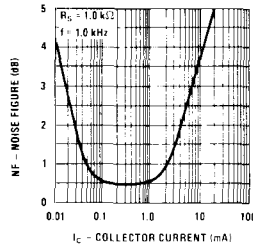
Collector-Emitter Saturation Voltage vs Collector Current



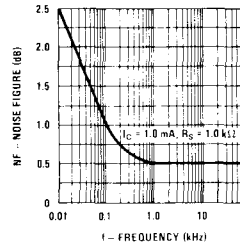
Base-Emitter Saturation Voltage vs Collector Current



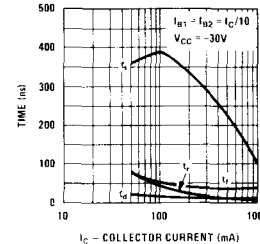
Noise Figure vs Collector Current



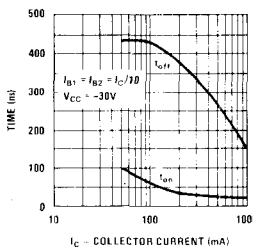
Noise Figure vs Frequency



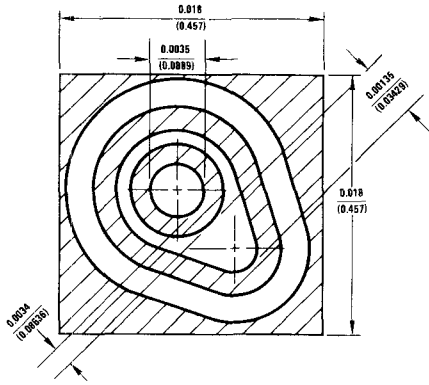
Switching Times vs Collector Current



Turn On and Turn Off Times vs Collector Current



*One square inch of copper run



DESCRIPTION

Process 69 is a nonoverlayer double diffused, silicon epitaxial device. Complements Process 27.

APPLICATION

This device was designed for general purpose amplifier and switching applications to collector currents of 100 mA.

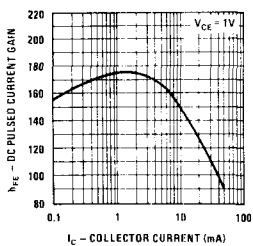
PRINCIPAL DEVICE TYPES

TO-18 2N3251A

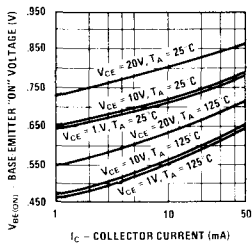
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|----------------------|---|-----|------|------|-------|-------|
| T _{ON} | I _C = 10 mA, I _B = 1 mA | | 50 | 70 | ns | |
| T _{OFF} | I _C = 10 mA, I _B = 1 mA | | 125 | 225 | ns | |
| NF | V _{CE} = 5V, I _C = 100 μA, f = 1 kHz R _S = 1 kΩ | | 1.7 | 4.5 | dB | |
| C _{OB} | V _{CE} = 5V | | 4 | 5.0 | pF | |
| C _{IB} | V _{EB} = 1V | | 6.5 | 8.0 | pF | |
| f _T | V _{CE} = 20V, I _C = 10 mA | 250 | 450 | | MHz | |
| h _{FE} | V _{CE} = 1V, I _C = 100 μA | 40 | 150 | 270 | | |
| h _{FE} | V _{CE} = 1V, I _C = 1 mA | 55 | 175 | 315 | | |
| h _{FE} | V _{CE} = 1V, I _C = 10 mA | 50 | 150 | 270 | | |
| h _{FE} | V _{CE} = 1V, I _C = 50 mA | 15 | 85 | 150 | | |
| h _{FE} | V _{CG} = 1V, I _C = 100 mA | | 18 | 35 | | |
| V _{CE(SAT)} | I _C = 10 mA, I _B = 1 mA | | 0.15 | 0.25 | V | |
| V _{CE(SAT)} | I _C = 50 mA, I _B = 5 mA | | 0.25 | 0.50 | V | |
| V _{BE(SAT)} | I _C = 10 mA, I _B = 1 mA | | 0.74 | 0.90 | V | |
| V _{BE(SAT)} | I _C = 50 mA, I _B = 5 mA | | 0.90 | 1.20 | V | |
| I _{CB0} | V _{CB} = 30V | | 1.5 | 50 | nA | |
| I _{EBO} | V _{EB} = 4V | | 0.05 | 50 | nA | |
| BV _{CB0} | I _C = 10 μA | 50 | 70 | 95 | | |
| BV _{EBO} | I _C = 10 μA | 5.0 | | | | |
| BV _{CEO} | I _C = 1 mA | 40 | 50 | 60 | | |
| BV _{CES} | I _C = 10 μA | | 70 | | | |

Process 69

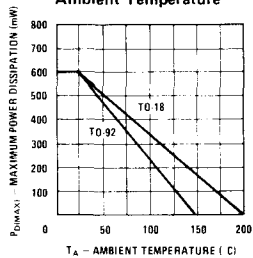
DC Pulsed Current Gain vs Collector Current



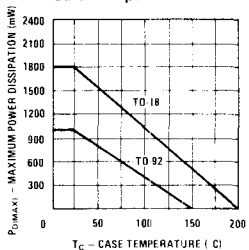
Base-Emitter On Voltage vs Collector Current



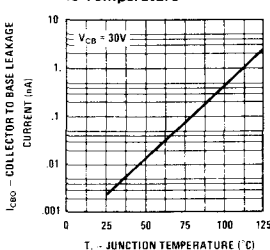
Maximum Power Dissipation vs Ambient Temperature



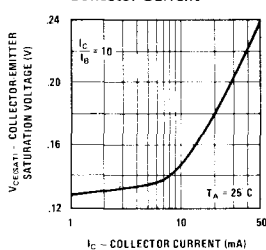
Maximum Power Dissipation vs Case Temperature



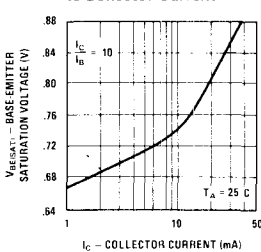
Collector-Base Diode Reverse Current vs Temperature



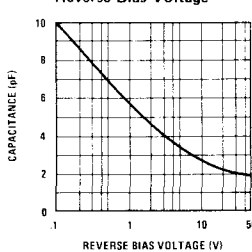
Collector-Emitter Saturation Voltage vs Collector Current



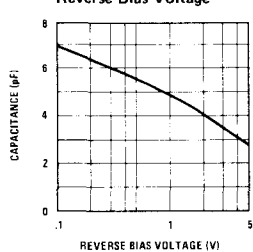
Base-Emitter On Voltage vs Collector Current



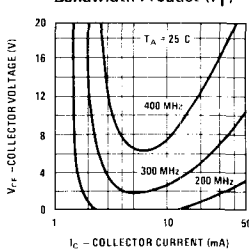
Output Capacitance vs Reverse Bias Voltage



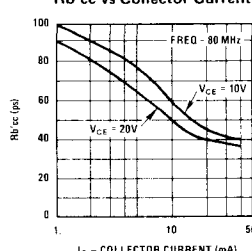
Input Capacitance vs Reverse Bias Voltage



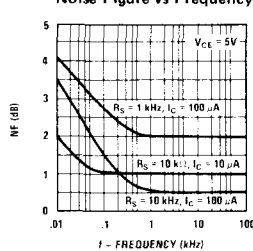
Contours of Constant Gain Bandwidth Product (fT)



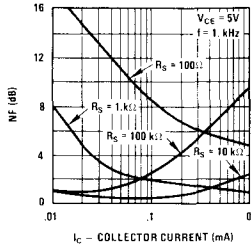
Rb'cc vs Collector Current



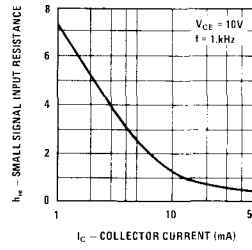
Noise Figure vs Frequency



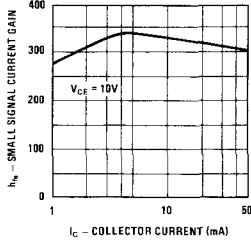
Noise Figure vs Collector Current



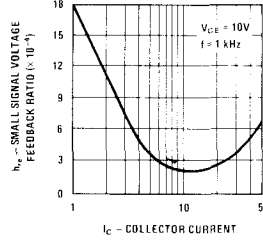
Small Signal Input Resistance vs Collector Current



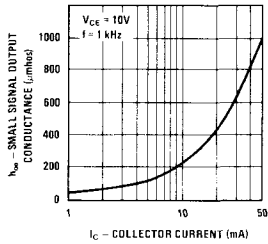
Small Signal Current Gain vs Collector Current



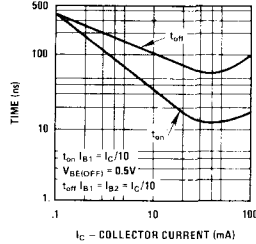
Small Signal Voltage Feedback Ratio vs Collector Current



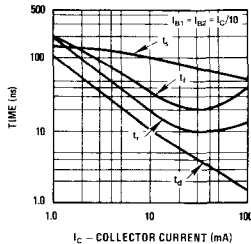
Small Signal Output Conductance vs Collector Current



Turn On and Turn Off Times vs Collector Current



Switching Times vs Collector Current



DESCRIPTION

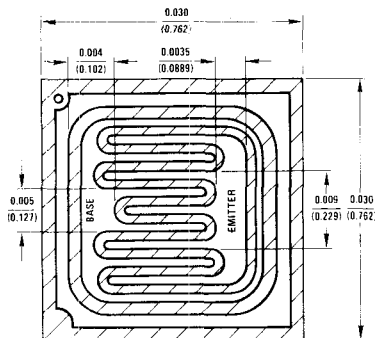
Process 70 is a nonoverlay double diffused, gold doped, silicon epitaxial device. Complement to process 25.

APPLICATION

This device was designed primarily for high speed saturated switching applications.

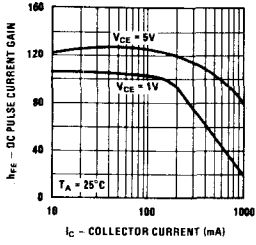
PRINCIPAL DEVICE TYPES

| | |
|--------|--------|
| TO-39 | 2N3467 |
| TO-92+ | TN3467 |

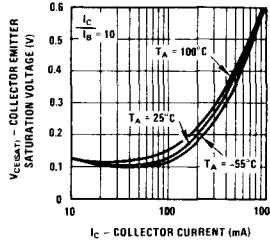


| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|------|-------|-----|-------|--------|
| t_{ON} | $I_C = 500 \text{ mA}, I_{B1} = 50 \text{ mA}$ | | 20 | 40 | ns | Fig. 1 |
| t_{OFF} | $I_C = 500 \text{ mA}, I_{B2} = 50 \text{ mA}$ | | 60 | 90 | ns | Fig. 2 |
| h_{fe} | $I_C = 50 \text{ mA}, V_{CE} = -10 \text{ V}, f = 100 \text{ MHz}$ | 1.75 | 2.9 | | | |
| C_{ob} | $V_{CB} = -10 \text{ V}$ | | 15 | 20 | pF | |
| C_{ib} | $V_{eb} = -0.5 \text{ V}$ | | 65 | 80 | pF | |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = -1 \text{ V}$ | 40 | 100 | 200 | | |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = -1 \text{ V}$ | 40 | 75 | 120 | | |
| h_{FE} | $I_C = 1 \text{ Amp}, V_{CE} = -1 \text{ V}$ | 40 | 85 | | | |
| $V_{CE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.165 | 0.3 | V | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.30 | 0.5 | V | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ Amp}, I_B = 100 \text{ mA}$ | | 0.50 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ | | 0.80 | 1.0 | V | |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.95 | 1.2 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ Amp}, I_B = 100 \text{ mA}$ | | 1.1 | 1.6 | V | |
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 30 | 40 | 50 | V | |
| BV_{CBO} | $I_C = 10 \mu\text{A}$ | 40 | 60 | 80 | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 5 | 8.0 | | V | |
| I_{CBO} | $V_{CB} = 30 \text{ V}$ | | 10 | 100 | nA | |
| I_{CEX} | $V_{CE} = -30 \text{ V}, V_{BE(OFF)} = 3 \text{ V}$ | | 10 | 100 | nA | |
| I_{DL} | $V_{CE} = -30 \text{ V}, V_{BE(OFF)} = 3 \text{ V}$ | | 10 | 120 | nA | |

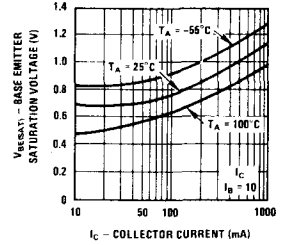
DC Pulse Current Gain vs Collector Current



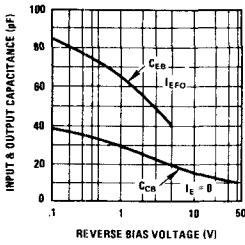
Collector-Emitter Saturation Voltage vs Collector Current



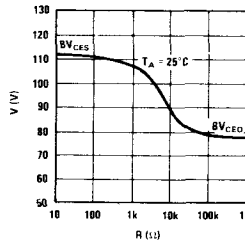
Base-Emitter Saturation Voltage vs Collector Current



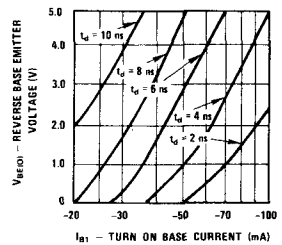
Input & Output Capacitance vs Reverse Bias Voltage



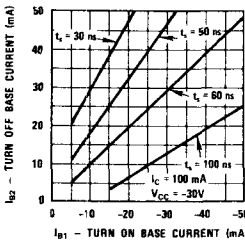
BVCER vs RBE IC = 10 mA



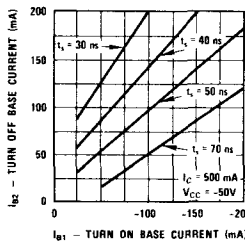
Delay Time vs Turn On Base Current and Reverse Base Emitter Voltage



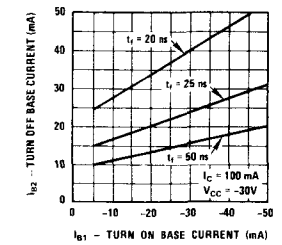
Storage Time vs Turn On and Turn Off Base Currents



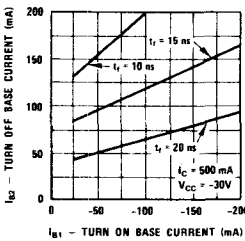
Storage Time vs Turn On and Turn Off Base Currents



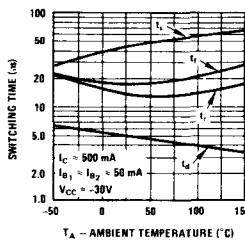
Fall Time vs Turn On and Turn Off Base Currents



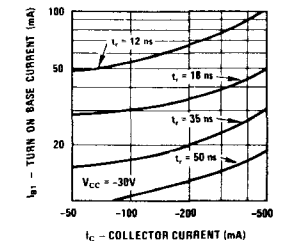
Fall Time vs Turn On and Turn Off Base Currents



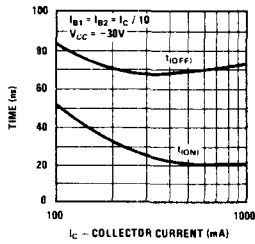
Switching Times vs Ambient Temperature



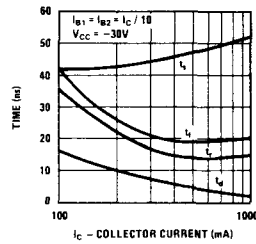
Rise Time vs Collector Current and Turn On Base Current



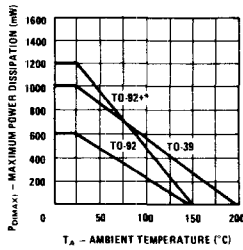
Turn On and Turn Off Times vs Collector Current



Switching Times vs Collector Current



Maximum Power Dissipation vs Ambient Temperature



*One square inch of copper run

Maximum Power Dissipation vs Case Temperature

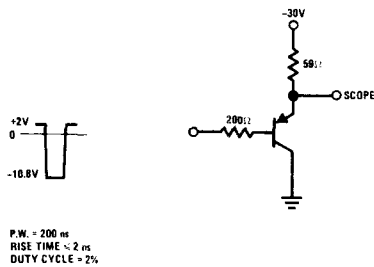
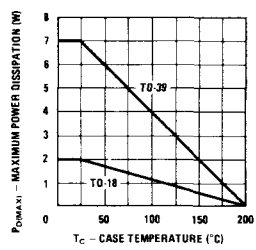


FIGURE 1. t_{ON} Equivalent Test Circuit

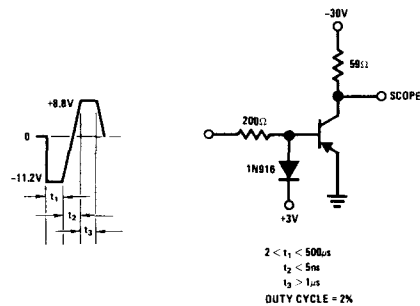
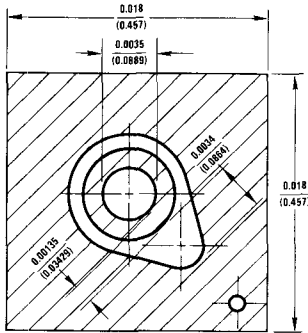


FIGURE 2. t_{OFF} Equivalent Test Circuit



DESCRIPTION

Process 71 is a nonoverlap, double diffused, silicon device. Complement to Process 04.

APPLICATION

This device was designed for general purpose amplifier applications at collector currents to 20 mA.

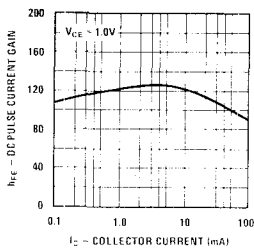
PRINCIPAL DEVICE TYPES

TO-18 BC177 Series
TO-92 BC560 Series

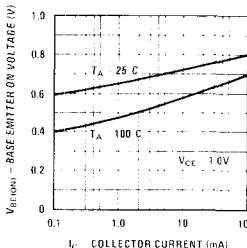
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|--|-----|-------|------|-------|-------|
| NF (spot) | $I_C = 200 \mu A$, $V_C = 5V$, $R_S = 2k$, $f = 1 \text{ kHz}$ | | 0.5 | 2.50 | dB | |
| h_{re} | $I_C = 10 \text{ mA}$, $V_{CE} = 5V$, $f = 100 \text{ MHz}$ | 3 | 5 | | | |
| C_{ob} | $V_{CB} = 10V$ | | 4 | 6 | pF | TO-18 |
| C_{ib} | $V_{EB} = 0.50V$ | | 8 | 12 | pF | TO-18 |
| h_{FE} | $I_C = 100 \mu A$, $V_{CE} = 5V$ | 40 | 140 | 400 | | |
| h_{FE} | $I_C = 1 \text{ mA}$, $V_{CE} = 5V$ | 40 | 140 | 400 | | |
| h_{FE} | $I_C = 10 \text{ mA}$, $V_{CE} = 5V$ | 40 | 130 | | | |
| h_{FE} | $I_C = 20 \text{ mA}$, $V_{CE} = 5V$ | 40 | 125 | | | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ mA}$, $I_B = 0.10 \text{ mA}$ | | 0.04 | 0.10 | V | |
| $V_{CE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | | 0.055 | 0.11 | V | |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ mA}$, $I_B = 0.10 \text{ mA}$ | | 0.8 | 0.95 | V | |
| $V_{BE(SAT)}$ | $I_C = 10 \text{ mA}$, $I_B = 1 \text{ mA}$ | | 0.9 | 1.0 | V | |
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 40 | 50 | | V | |
| BV_{CBO} | $I_C = 100 \mu A$ | 40 | | | V | |
| BV_{EBO} | $I_E = 10 \mu A$ | 5 | 6 | | V | |
| I_{CBO} | $V_{CB} = 30V$ | | | 50 | nA | |
| I_{EBO} | $V_{EB} = 3V$ | | | 50 | nA | |

Process 71

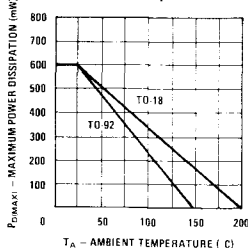
DC Pulse Current Gain vs Collector Current



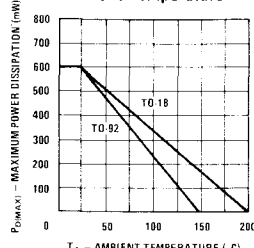
Base-Emitter On Voltage vs Collector Current



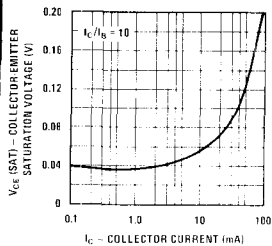
Maximum Power Dissipation vs Ambient Temperature



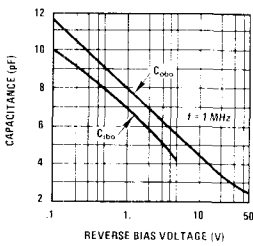
Maximum Power Dissipation vs Ambient Temperature



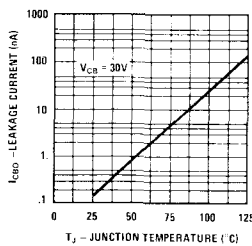
Collector-Emitter Saturation Voltage vs Collector Current



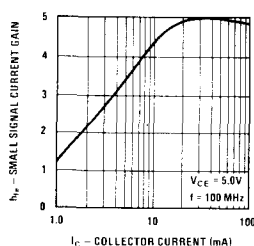
Capacitance vs Reverse Bias Voltage



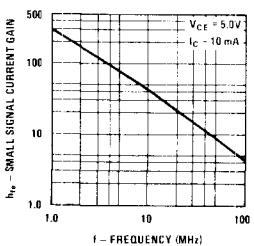
Collector-Base Diode Reverse Current vs Temperature



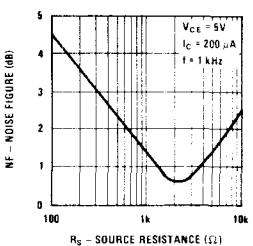
Small Signal Current Gain vs Collector Current



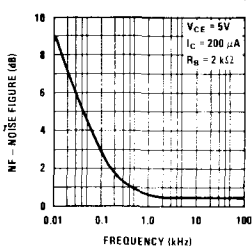
Capacitance vs Reverse Bias Voltage



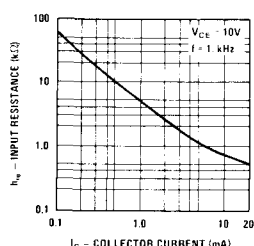
Noise Figure vs Source Resistance



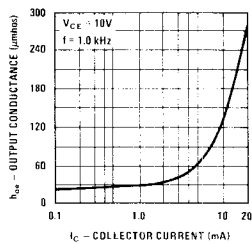
Noise Figure vs Frequency



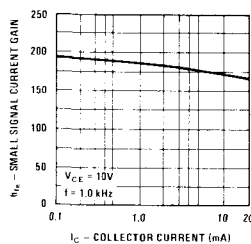
Small Signal Input Resistance vs Collector Current



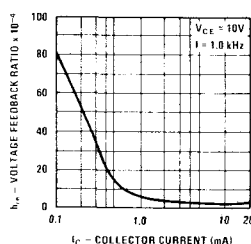
Small Signal Output Conductance vs Collector Current



Small Signal Current Gain vs Collector Current



Small Signal Voltage Feedback Ratio vs Collector Current



DESCRIPTION

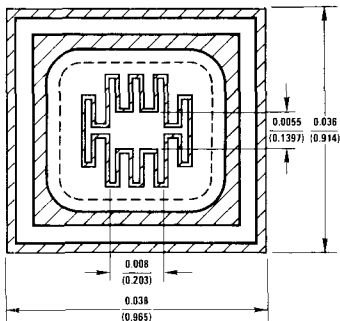
Process 73 is nonoverlay doubled diffused, silicon epitaxial device. Complement to Process 08.

APPLICATION

This device was designed as a general purpose amplifier and switch for applications requiring high line voltages.

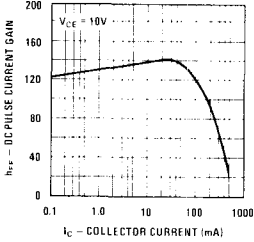
PRINCIPAL DEVICE TYPES

TO-39 2N3634
 TO-92+ TN3634

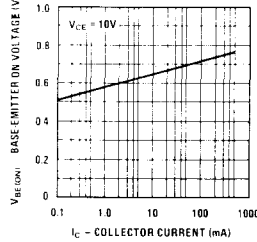


| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|-----|-------|-------|
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 105 | 160 | 180 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 145 | | 250 | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 5 | 7 | | V | |
| I_{CBO} | $V_{CB} = 100\text{V}$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |
| h_{FE} | $I_C = 0.1 \text{ mA}, V_{CE} = 10\text{V}$ | 40 | 80 | | | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 10\text{V}$ | 45 | 90 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | 100 | | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 10\text{V}$ | 55 | 135 | 270 | | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.15 | 0.3 | V | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.75 | 0.9 | | |
| C_{OB} | $V_{CB} = 20\text{V}$ | | 8 | 10 | pF | |
| C_{IB} | $V_{EB} = 1.0\text{V}$ | | 50 | 75 | pF | |
| F_T | $I_C = 30 \text{ mA}, V_{CE} = 30\text{V}, f = 100 \text{ MHz}$ | 150 | 225 | | MHz | |

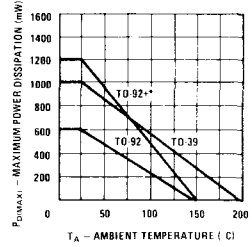
DC Pulse Current Gain vs Collector Current



Base-Emitter On Voltage vs Collector Current

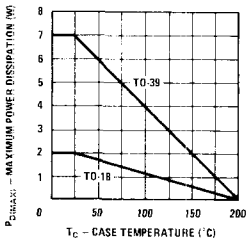


Maximum Power Dissipation vs Ambient Temperature

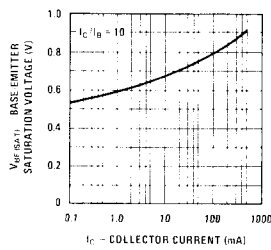


*One square inch of copper run

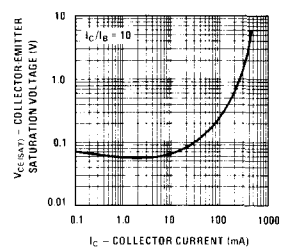
Maximum Power Dissipation vs Case Temperature



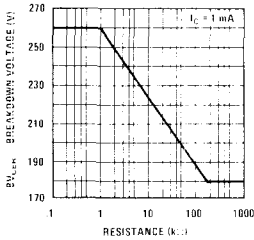
Base-Emitter Saturation Voltage vs Collector Current



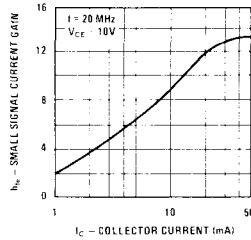
Collector-Emitter Saturation Voltage vs Collector Current



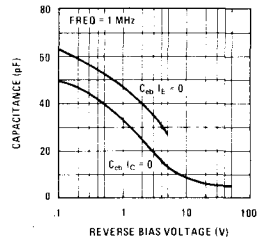
Collector-Emitter Breakdown Voltage With Resistance Between Emitter-Base



Small Signal Current Gain vs Collector Current



Input and Output Capacitance vs Reverse Bias Voltage



DESCRIPTION

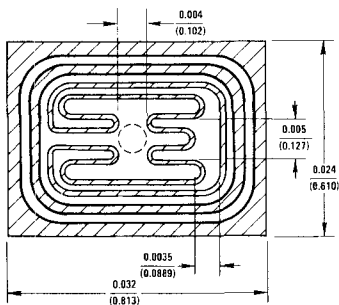
Process 74 is nonoverlay double diffused, silicon epitaxial device. Complement to Process 16.

APPLICATION

This device was designed as a general purpose amplifier and switch for applications requiring high line voltages

PRINCIPAL DEVICE TYPES

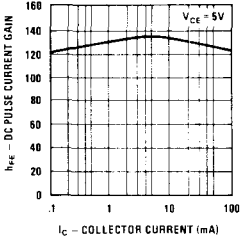
TO-92 2N5401, MPSL51



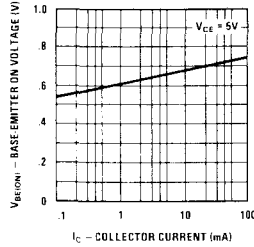
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS | NOTES |
|---------------|---|-----|------|------|-------|-------|
| BV_{CEO} | $I_C = 1 \text{ mA}$ | 105 | 170 | 210 | V | |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 150 | | 275 | V | |
| BV_{EBO} | $I_E = 10 \mu\text{A}$ | 6 | | | | |
| I_{CBO} | $V_{CB} = 100\text{V}$ | | | 100 | nA | |
| I_{EBO} | $V_{EB} = 3\text{V}$ | | | 50 | nA | |
| h_{FE} | $I_C = 1 \text{ mA}, V_{CE} = 5\text{V}$ | 30 | 60 | | | |
| h_{FE} | $I_C = 10 \text{ mA}, V_{CE} = 5\text{V}$ | 40 | 150 | 240 | | |
| h_{FE} | $I_C = 50 \text{ mA}, V_{CE} = 5\text{V}$ | 40 | 60 | | | |
| $V_{CE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.18 | 0.25 | | |
| $V_{BE(SAT)}$ | $I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$ | | 0.77 | 1.0 | | |
| C_{OB} | $V_{CB} = 10\text{V}$ | | 8 | 12 | pF | |
| f_T | $I_C = 10 \text{ mA}, V_{CE} = 10\text{V}, f = 100 \text{ MHz}$ | 100 | 160 | 300 | MHz | |

Process 74

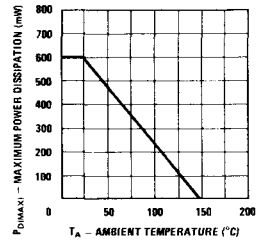
DC Pulse Current Gain vs Collector Current



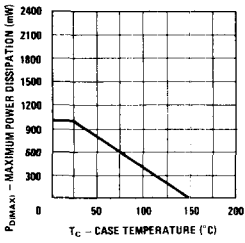
Base-Emitter On Voltage vs Collector Current



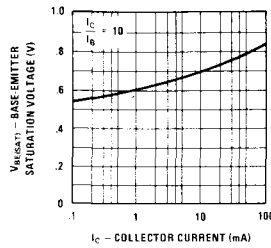
Maximum Power Dissipation vs Ambient Temperature TO-92



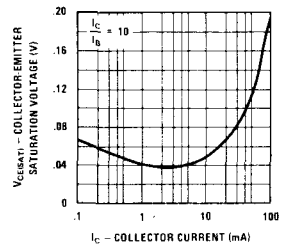
Maximum Power Dissipation vs Case Temperature TO-92



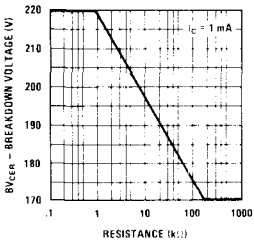
Base-Emitter Saturation Voltage vs Collector Current



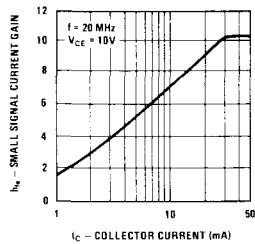
Collector-Emitter Saturation Voltage vs Collector Current



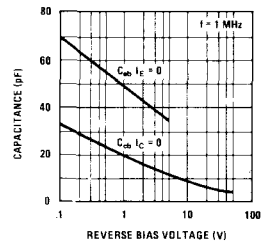
Collector-Emitter Breakdown Voltage With Resistance Between Base-Emitter



Small Signal Current Gain vs Collector Current



Input and Output Capacitance vs Reverse Bias Voltage





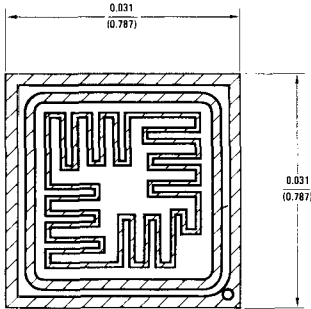
Process 77 PNP Medium Power

DESCRIPTION

Process 77 is a double diffused silicon epitaxial planar device. Complement to Process 37.

APPLICATION

This device was designed for general purpose medium power amplifier and switching circuits that require collector currents to 1A.



| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|-----|-----|---------------|
| V_{CEO} | $I_C = 10 \text{ mA}$ | 25 | | 45 | V |
| V_{CBO} | $I_C = 100 \mu\text{A}$ | 40 | | | V |
| V_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | 7 | | V |
| I_{CBO} | $V_{CB} = V_{CEO}$ | | 50 | 500 | nA |
| I_{EBO} | $V_{EB} = 5 \text{ V}$ | | 0.1 | 10C | μA |
| h_{FE} | $I_C = 500 \text{ mA}, V_{CE} = 1 \text{ V}$ | 50 | | 250 | |
| $V_{CE(SAT)}$ | $I_C = 1 \text{ A}, I_B = 0.1 \text{ A}$ | | 0.3 | 0.5 | V |
| $V_{BE(SAT)}$ | $I_C = 1 \text{ A}, I_B = 0.1 \text{ A}$ | | 1.0 | 1.5 | V |
| f_T | $I_C = 100 \text{ mA}, V_{CE} = 10 \text{ V}$ | | 200 | | MHz |
| C_{OBO} | $V_{CB} = 10 \text{ V}$ | | | 20 | pF |

PRINCIPAL DEVICE TYPES

TO-202 (Package 35) 92 PLUS (Package 91)

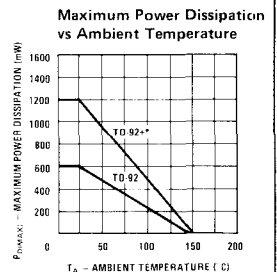
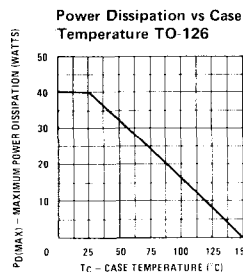
NSD202 92PU51
 NSD203 92PU51A
 NSDU51 BD370A
 NSDU51A

TO-202 (Package 36) TO-126 (Package 38)

BD136
 D43C1
 D43C2
 D43C3
 D43C4
 D43C5
 D43C6
 NSE170

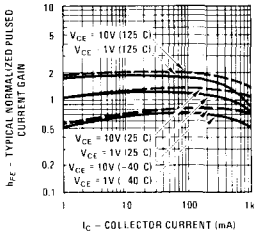
92 PLUS (Package 90)

92PE77A
 BD372A

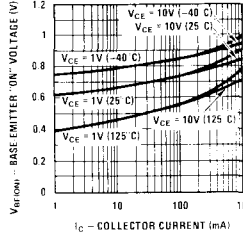


*One square inch of copper run

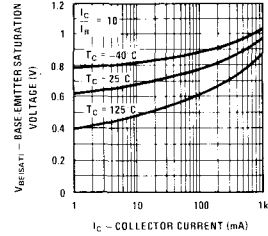
Typical Normalized Pulsed Current Gain vs Collector Current



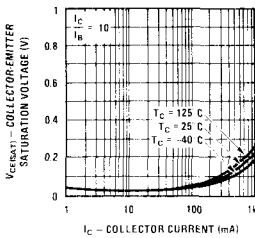
Base-Emitter "ON" Voltage vs Collector Current



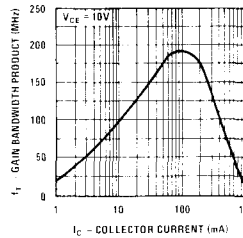
Base-Emitter Saturation Voltage vs Collector Current



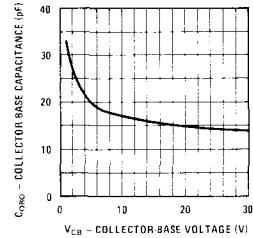
Collector-Emitter Saturation Voltage vs Collector Current



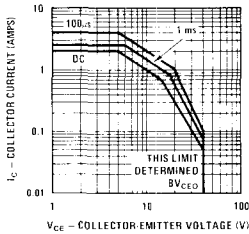
Gain Bandwidth Product vs Collector Current



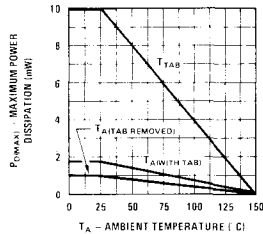
Collector-Base Capacitance vs Collector-Base Voltage



Safe Operating Area TO-202

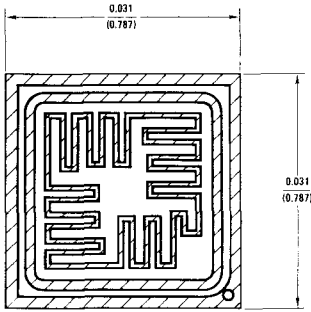


Maximum Power Dissipation vs Ambient Temperature (TO-202)





Process 78 PNP Medium Power



DESCRIPTION

Process 78 is a double diffused silicon epitaxial planar device complement to Process 38.

APPLICATION

This device was designed for general purpose medium power amplifier and switching circuits that require collector currents to 1A.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|------|-----|---------------|
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 45 | | 80 | V |
| BV_{CBO} | $I_C = 100\mu\text{A}$ | 75 | | 110 | V |
| BV_{EBO} | $I_E = 100\mu\text{A}$ | 5 | 7 | | V |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | 50 | 500 | nA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | 0.1 | 100 | μA |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1\text{V}$ | 50 | | 250 | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.2 | 0.5 | V |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.95 | 1.4 | V |
| f_T | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | | | MHz |
| C_{OBO} | $V_{CB} = 10\text{V}$ | | | 15 | pF |

PRINCIPAL DEVICE TYPES

TO-202 (Package 35) TO-126 (Package 38)

NSDU55 BD138
 NSD6180
 NSD6181

TO-202 (Package 36)

D43C7
 D43C8
 D43C9
 NSE171

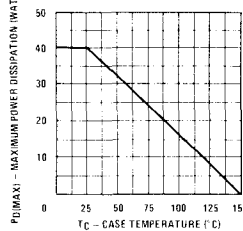
92 PLUS (Package 90)

92PE77B
 BD372B
 BD372C

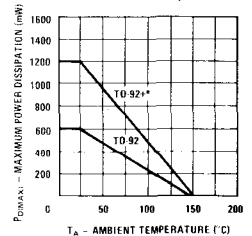
92 PLUS (Package 91)

92PU55
 BD370B
 BD370C

Power Dissipation vs Case Temperature TO-126

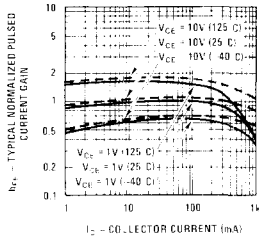


Maximum Power Dissipation vs Ambient Temperature

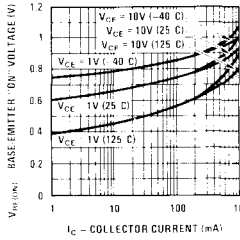


*One square inch of copper run

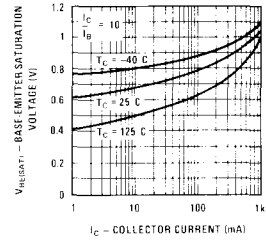
Typical Normalized Pulsed Current Gain vs Collector Current



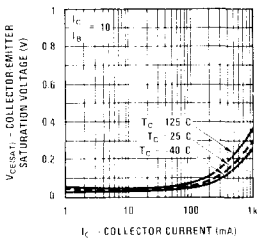
Base-Emitter 'ON' Voltage vs Collector Current



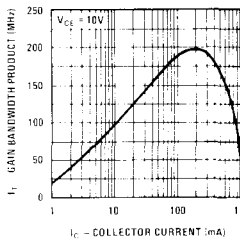
Base-Emitter Saturation Voltage vs Collector Current



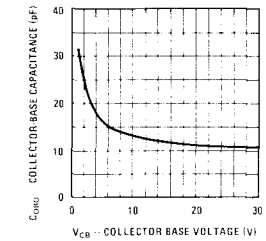
Collector-Emitter Saturation Voltage vs Collector Current



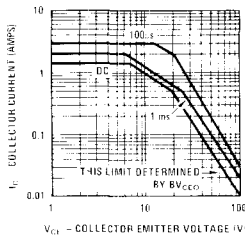
Gain Bandwidth Product vs Collector Current



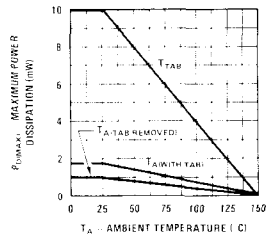
Collector-Base Capacitance vs Collector-Base Voltage



Safe Operating Area TO-202

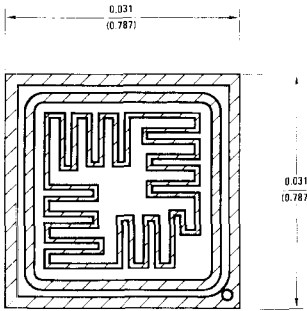


Maximum Power Dissipation vs Ambient Temperature





Process 79 PNP Medium Power



DESCRIPTION

Process 79 is a double diffused silicon epitaxial planar device complement to Process 39.

APPLICATION

This device was designed for general purpose medium power amplifier and switching circuits that require collector currents to 1A.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|-----|-----|---------------|
| BV_{CEO} | $I_C = 10 \text{ mA}$ | 80 | | 110 | V |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 110 | | 140 | V |
| BV_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | 7 | | V |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | 50 | 500 | nA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | 0.1 | 100 | μA |
| h_{FE} | $I_C = 100 \text{ mA}, V_{CE} = 1\text{V}$ | 25 | | 150 | |
| $V_{CE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.2 | 0.5 | V |
| $V_{BE(SAT)}$ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 0.9 | 1.4 | V |
| f_T | $I_C = 100 \text{ mA}, V_{CE} = 10\text{V}$ | 50 | 120 | | MHz |
| C_{OBO} | $V_{CB} = 10\text{V}$ | | | 15 | pF |

PRINCIPAL DEVICE TYPES

TO-202 (Package 35)

- NSD204
- NSD205
- NSD206
- NSDU56
- NSDU57

92 PLUS (Package 90)

- 92PE77C
- BD372D

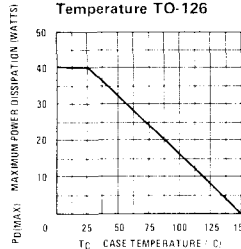
92 PLUS (Package 91)

- 92PU56
- 92PU57
- BD370D

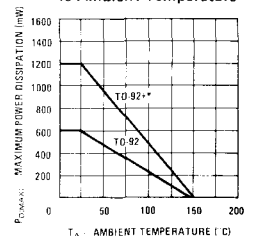
TO-126 (Package 38)

- BD140

Power Dissipation vs Case Temperature TO-126

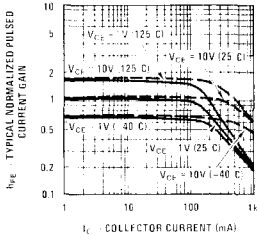


Maximum Power Dissipation vs Ambient Temperature

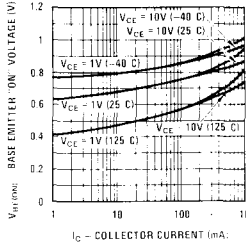


*One square inch of copper run

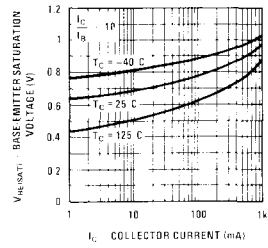
Typical Normalized Pulsed Current Gain vs Collector Current



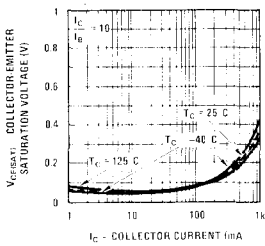
Base-Emitter "ON" Voltage vs Collector Current



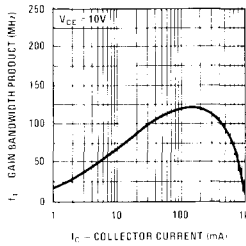
Base-Emitter Saturation Voltage vs Collector Current



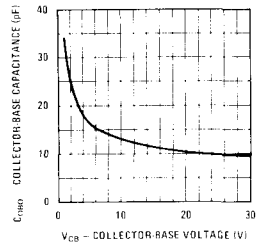
Collector-Emitter Saturation Voltage vs Collector Current



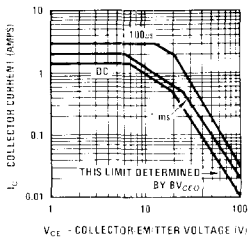
Gain Bandwidth Product vs Collector Current



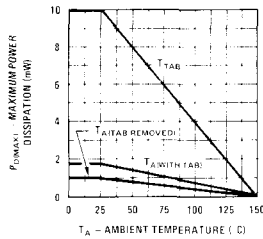
Collector-Base Capacitance vs Collector-Base Voltage



Safe Operating Area TO-202



Maximum Power Dissipation vs Ambient Temperature (TO-202)

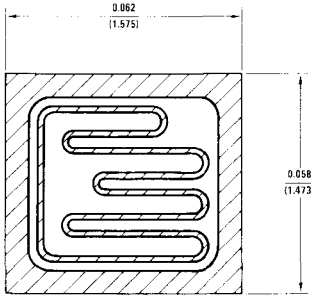






Section 7
Process
Characteristics Mesa
Transistors

7



DESCRIPTION

Process 2C/4F is a double epitaxial silicon mesa with diffused emitter.

APPLICATION

This device was designed for general purpose power amplifier and switching circuits where a large safe operating area is required.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|--|------|------|-------|----------------------|
| BV_{CEO} | $I_C = 100 \text{ mA}$, (Note 1) | 30 | | 100 | V |
| BV_{CBO} | $I_C = 1 \text{ mA}$ | 60 | | 200 | V |
| BV_{EBO} | $I_E = 1 \text{ mA}$ | 5 | 8 | | V |
| I_{CEO} | $V_{CE} = BV_{CEO}$, 10 V | | 10 | 300 | μA |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | 0.1 | 10 | μA |
| I_{EBO} | $V_{EB} = 5 \text{ V}$ | | 10 | 100 | μA |
| h_{FE} | $I_C = 1.0 \text{ A}$, $V_{CE} = 1 \text{ V}$, (Note 1) | 15 | | 200 | |
| $V_{CE(SAT)}$ | $I_C = 2.0 \text{ A}$, $I_B = 0.3 \text{ A}$, (Note 1) | | | 0.5 | V |
| $V_{BE(ON)}$ | $I_C = 2.0 \text{ A}$, $V_{CE} = 2.0 \text{ V}$, (Note 1) | | | 1.0 | V |
| SOA | TO-220, $V_{CE} = 25 \text{ V}$, $t = 1 \text{ sec}$ | 1.6 | | | A |
| SOA | TO-126, $V_{CE} = 33 \text{ V}$, $t = 1 \text{ sec}$ | 0.9 | | | A |
| SOA | TO-202, $V_{CE} = 30 \text{ V}$, $t = 1 \text{ sec}$ | 0.4 | | | A |
| f_T | $I_C = 0.5 \text{ A}$, $V_{CE} = 2 \text{ V}$ | 4 | | | MHz |
| t_{d1} | $I_C = 1 \text{ A}$, $I_{B1} = I_{B2} = 0.1 \text{ A}$, $V_{CC} = 40 \text{ V}$ | | 0.05 | | μs |
| t_r | $I_C = 1 \text{ A}$, $I_{B1} = I_{B2} = 0.1 \text{ A}$, $V_{CC} = 40 \text{ V}$ | | 0.25 | | μs |
| t_s | $I_C = 1 \text{ A}$, $I_{B1} = I_{B2} = 0.1 \text{ A}$, $V_{CC} = 40 \text{ V}$ | | 0.75 | | μs |
| t_f | $I_C = 1 \text{ A}$, $I_{B1} = I_{B2} = 0.1 \text{ A}$, $V_{CC} = 40 \text{ V}$ | | 0.25 | | μs |
| $P_{D(MAX)}$ | TO-220 | 40 | | | W |
| | TO-126 | 30 | | | W |
| | TO-202 | 12.5 | | | W |
| θ_{JC} | TO-220 | | | 3.125 | $^{\circ}\text{C/W}$ |
| | TO-126 | | | 4.167 | $^{\circ}\text{C/W}$ |
| | TO-202 | | | 10.0 | $^{\circ}\text{C/W}$ |

Note 1: Pulsed measurement = 300 μs pulse width.

PRINCIPAL DEVICE TYPES

TO-220 (Package 37)

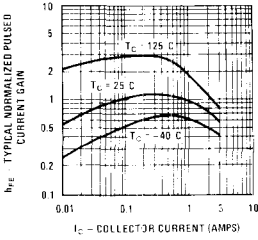
DC44C1 NSP520 TIP29B TIP61A 2N4921
 DC44C2 NSP521 TIP29C TIP61B 2N4922
 DC44C4 NSP4921 TIP31 TIP61C 2N4923
 DC44C5 NSP4922 TIP31A MJE520
 DC44C7 NSP4923 TIP31B MJE521
 DC44C8 TIP29 TIP31C
 DC44C10 TIP29A TIP61

TO-126 (Package 38)

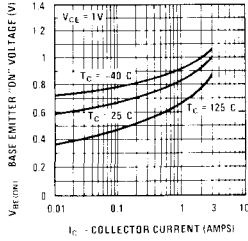
2N4921
 2N4922
 2N4923
 MJE520
 MJE521

Process 2C/4F

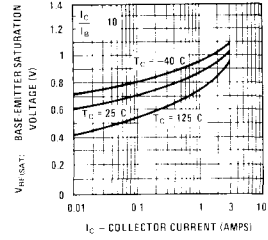
Typical Normalized Pulsed Current Gain vs Collector Current



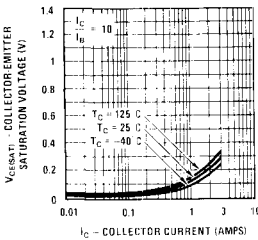
Base-Emitter "ON" Voltage vs Collector Current



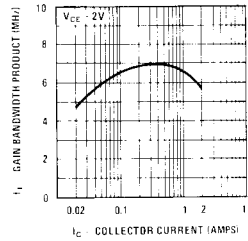
Base-Emitter Saturation Voltage vs Collector Current



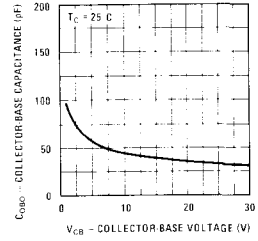
Collector-Emitter Saturation Voltage vs Collector Current



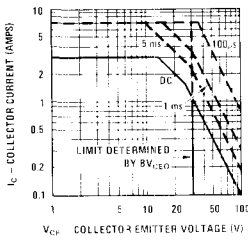
Gain Bandwidth Product vs Collector Current



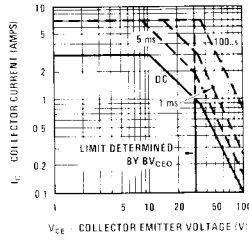
Collector-Base Capacitance vs Collector-Base Voltage



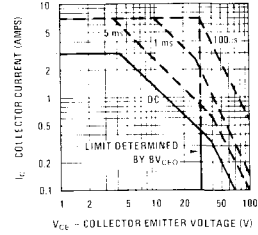
Safe Operating Area TO-220



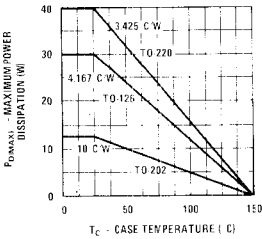
Safe Operating Area TO-126



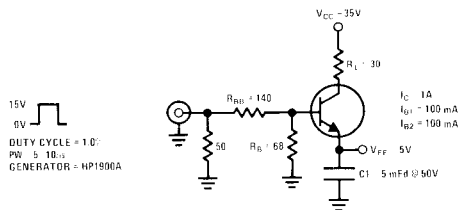
Safe Operating Area TO-202

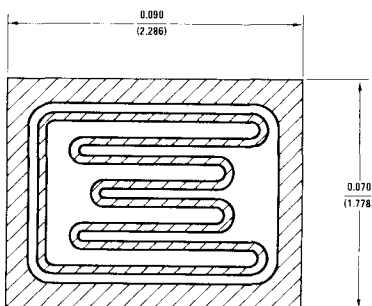


Maximum Power Dissipation vs Case Temperature



Switching Circuit





DESCRIPTION

Process 2E/4E is a double epitaxial silicon mesa with diffused emitter.

APPLICATION

This device was designed for general purpose power amplifier and switching circuits where a large safe operation area is required.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|--|-----|------|-------|----------------------|
| V_{CE0} | $I_C = 100 \text{ mA}$, (Note 1) | 30 | 60 | 100 | V |
| V_{CBO} | $I_C = 1 \text{ mA}$ | 50 | | 200 | V |
| V_{EBO} | $I_E = 1 \text{ mA}$ | 5 | 8 | | V |
| I_{CE0} | $V_{CE} = V_{CE0} \quad 10\text{V}$ | | 50 | 300 | μA |
| I_{CBO} | $V_{CB} = V_{CE0}$ | | 10 | 100 | μA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | 50 | 1000 | μA |
| h_{FE} | $I_C = 1.5\text{A}$, $V_{CE} = 20\text{V}$, (Note 1) | 20 | | 200 | |
| $V_{CE(SAT)}$ | $I_C = 4.0\text{A}$, $I_B = 0.6\text{A}$, (Note 1) | | | 0.6 | V |
| $V_{BE(ON)}$ | $I_C = 4.0\text{A}$, $V_{CE} = 2.0\text{V}$, (Note 1) | | | 1.3 | V |
| SOA | TO-220, $V_{CE} = 33.3\text{V}$, $t = 1 \text{ sec}$ | 1.5 | | | A |
| SOA | TO-126, $V_{CE} = 33.3\text{V}$, $t = 1 \text{ sec}$ | 1.2 | | | A |
| SOA | TO-202, $V_{CE} = 30\text{V}$, $t = 1 \text{ sec}$ | 0.5 | | | A |
| f_T | $I_C = 0.5\text{A}$, $V_{CE} = 2\text{V}$, $f = 1 \text{ MHz}$ | 4 | | | MHz |
| t_d | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CC} = 30\text{V}$ | | 0.10 | | μs |
| t_r | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CC} = 30\text{V}$ | | 0.25 | | μs |
| t_s | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CC} = 30\text{V}$ | | 0.35 | | μs |
| t_f | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CC} = 30\text{V}$ | | 0.23 | | μs |
| $P_{D(MAX)}$ | TO-220 | 50 | | | W |
| | TO-126 | 40 | | | W |
| | TO-202 | 15 | | | W |
| θ_{JC} | TO-220 | | | 2.5 | $^{\circ}\text{C/W}$ |
| | TO-126 | | | 3.125 | $^{\circ}\text{C/W}$ |
| | TO-202 | | | 8.33 | $^{\circ}\text{C/W}$ |

Note 1: Pulsed measurement = 300 μs pulse width

PRINCIPAL DEVICE TYPES

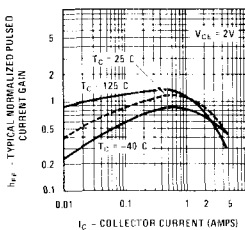
TO-220 (Package 37)

2N5293 2N5298 2N6130 2N6291 D44C9 NSP41B 2N5190
 2N5294 2N6121 2N6131 2N6292 D44C11 NSP41C 2N5191
 2N5295 2N6122 2N6288 2N6293 D44C12 NSP5190 2N5192
 2N5296 2N6123 2N6289 D44C3 NSP41 NSP5192
 2N5297 2N6129 2N6290 D44C6 NSP41A NSP5193

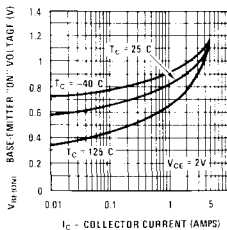
TO-126 (Package 38)

Process 2E/4E

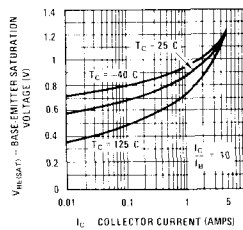
Typical Normalized Pulsed Current Gain vs Collector Current



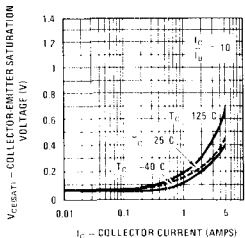
Base-Emitter "ON" Voltage vs Collector Current



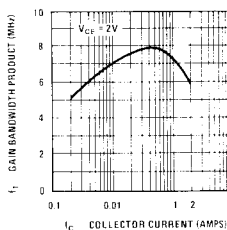
Base-Emitter Saturation Voltage vs Collector Current



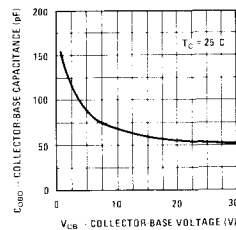
Collector-Emitter Saturation Voltage vs Collector Current



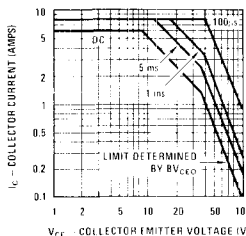
Gain Bandwidth Product vs Collector Current



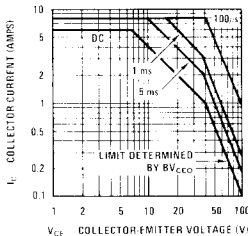
Typical Collector Capacitance vs Collector-Base Voltage



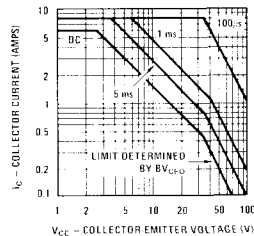
Safe Operating Area TO-220



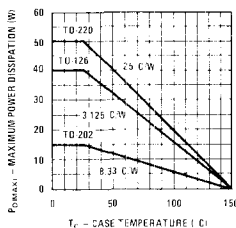
Safe Operating Area TO-126



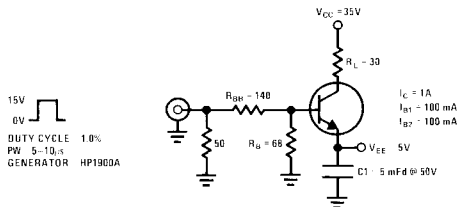
Safe Operating Area TO-202



Maximum Power Dissipation vs Case Temperature



Switching Circuit





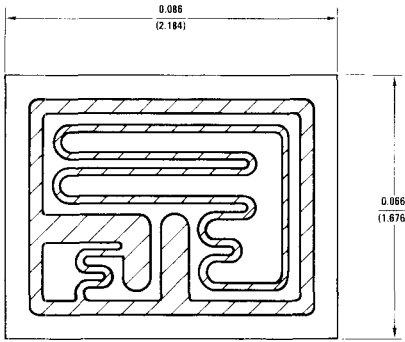
Process 2J/4J NPN Power Darlington

DESCRIPTION

Process 2J/4J is a double epitaxial silicon mesa device. Complement to Process 3J/5J.

APPLICATION

This device was designed for use in driver and output stages of complementary audio amplifier circuits. It is also well suited for solenoid driver applications.



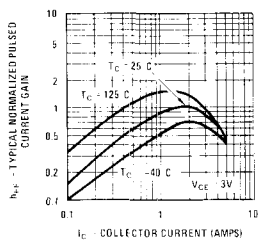
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|------|--------|----------------------|
| BV_{CEO} | $I_C = 100 \text{ mA}$ | 30 | | 100 | V |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 50 | | 120 | V |
| BV_{EBO} | $I_E = 2 \text{ mA}$ | 5 | | | V |
| I_{CEO} | $V_{CE} = 1/2 BV_{CEO}$ | | | 0.5 | mA |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | | 200 | μA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | | 2.0 | mA |
| h_{FE} | $I_C = 2\text{A}, V_{CE} = 3\text{V}$ | 500 | | 15,000 | |
| $V_{CE(SAT)}$ | $I_C = 5\text{A}, I_B = 2.0 \text{ mA}$ | | | 3.0 | V |
| $V_{BE(ON)}$ | $I_C = 5\text{A}, V_{CE} = 3\text{V}$ | | | 2.5 | V |
| C_{OBO} | $V_{CB} = 10\text{V}$ | | 30 | | pF |
| $ h_{FE} $ | $I_C = 1\text{A}, V_{CE} = 3\text{V}, f = 1 \text{ MHz}$ | | 9 | | MHz |
| t_{ON} | $I_C = 6\text{A}, V_{CE} = 30\text{V}, (\text{Figure 1})$ | | 1.25 | | μs |
| t_{OFF} | $I_C = 6\text{A}, V_{CE} = 30\text{V}, (\text{Figure 1})$ | | 2.75 | | μs |
| SOA | TO-220, $V_{CE} = 33\text{V}, t = 1 \text{ sec}$ | 1.5 | | | A |
| SOA | TO-126, $V_{CE} = 33\text{V}, t = 1 \text{ sec}$ | 1.2 | | | A |
| $P_{D(MAX)}$ | TO-220 | 50 | | | W |
| $P_{D(MAX)}$ | TO-126 | 40 | | | W |
| θ_{JC} | TO-220 | | | 2.5 | $^{\circ}\text{C/W}$ |
| θ_{JC} | TO-126 | | | 3.125 | $^{\circ}\text{C/W}$ |

PRINCIPAL DEVICE TYPES

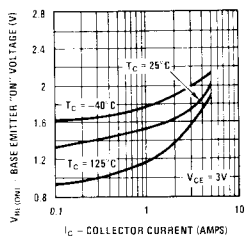
| | |
|----------------------------|----------------------------|
| TO-220 (Package 37) | TO-126 (Package 38) |
| 2N6386 NSP2101 | 2N6037 MJE802 |
| TIP110 NSP2102 | 2N6038 MJE803 |
| TIP111 NSP2103 | 2N6039 |
| TIP112 | MJE800 |
| NSP2100 | MJE801 |

Process 2J/4J

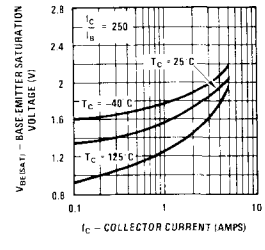
Typical Normalized Pulsed Current Gain vs Collector Current



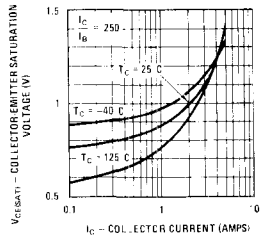
Base-Emitter "ON" Voltage vs Collector Current



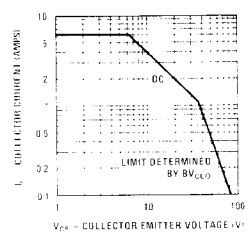
Base-Emitter Saturation Voltage vs Collector Current



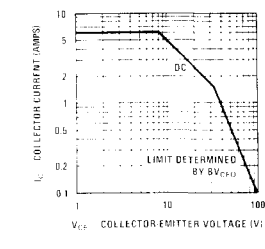
Collector-Emitter Saturation Voltage vs Collector Current



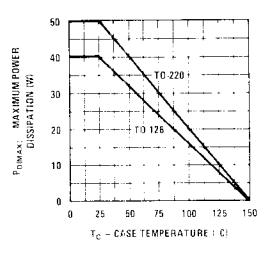
Safe Operating Area TO-126



Safe Operating Area TO-220



Maximum Power Dissipation vs Case Temperature



Switching Times vs Collector Current

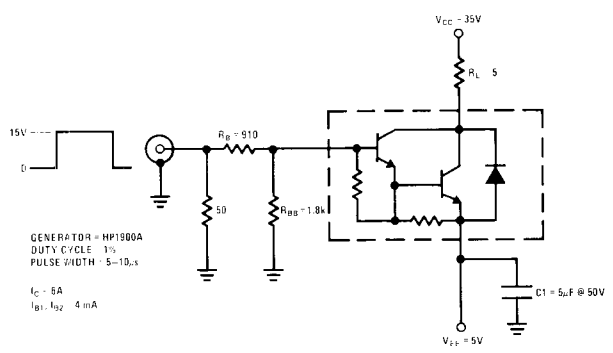
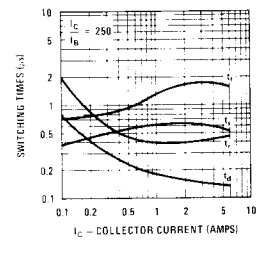


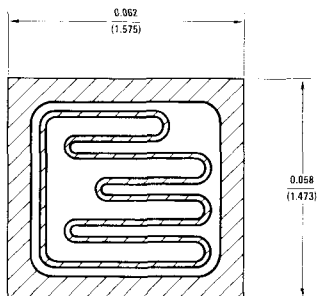
FIGURE 1

DESCRIPTION

Process 3C/5F is a double epitaxial silicon mesa with diffused emitter.

APPLICATION

This device was designed for general purpose power amplifier and switching circuits where a large safe operating area is required.



| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-------|------|-------|---------------|
| BV_{CEO} | $I_C = 100 \text{ mA}$ | 30 | | 100 | V |
| BV_{CBO} | $I_C = 1 \text{ mA}$ | 50 | | 150 | V |
| BV_{EBO} | $I_E = 1 \text{ mA}$ | 5 | 6.5 | | V |
| I_{CEO} | $V_{CE} = BV_{CEO} - 10V$ | | 10 | 300 | μA |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | 0.1 | 10 | μA |
| I_{EBO} | $V_{EB} = 5V$ | | 10 | 100 | μA |
| h_{FE} | $I_C = 1.0A, V_{CE} = 1.0V$ | 10 | | 120 | |
| $V_{CE(SAT)}$ | $I_C = 2.0A, I_B = 0.3A$ | | | 0.5 | V |
| $V_{BE(ON)}$ | $I_C = 2.0A, V_{CE} = 2.0V$ | | | 1.1 | V |
| SOA | TO-220, $V_{CE} = 25V, t = 1 \text{ sec}$ | 1.6 | | | A |
| SOA | TO-126, $V_{CE} = 33.3V, t = 1 \text{ sec}$ | 0.9 | | | A |
| SOA | TO-202, $V_{CE} = 33.3V, t = 1 \text{ sec}$ | 0.375 | | | A |
| f_T | $I_C = 0.5A, V_{CE} = 2V$ | 4 | | | MHz |
| t_d | | | 0.03 | | μs |
| t_r | $I_C = 1A, I_{B1} = I_{B2} = 0.1A$ | | 0.20 | | μs |
| t_s | $V_{CC} = 40V$ | | 0.26 | | μs |
| t_f | | | 0.20 | | μs |
| P_D | TO-220 | | | 40 | W |
| | TO-126 | | | 30 | W |
| | TO-202 | | | 12.5 | W |
| θ_{jc} | TO-220 | | | 3.125 | $^{\circ}C/W$ |
| | TO-126 | | | 4.167 | $^{\circ}C/W$ |
| | TO-202 | | | 10.0 | $^{\circ}C/W$ |

Note 1: Pulsed measurement $\approx 300\mu s$ pulse width.

PRINCIPAL DEVICE TYPES

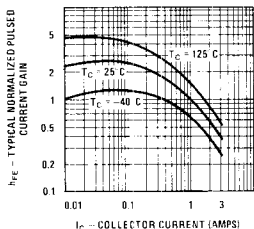
TO-220 (Package 37)

| | | | | | | |
|-------|--------|---------|--------|--------|--------|--------|
| D45C1 | D45C7 | NSP370 | TIP30 | TIP32 | TIP62 | 2N4918 |
| D45C2 | D45C8 | NSP4918 | TIP30A | TIP32A | TIP62A | 2N4919 |
| D45C4 | D45C10 | NSP4919 | TIP30B | TIP32B | TIP62B | 2N4920 |
| D45C5 | D45C11 | NSP4920 | TIP30C | TIP32C | TIP62C | MJE370 |

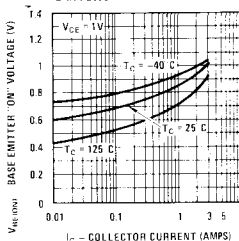
TO-126 (Package 38)

Process 3C/5F

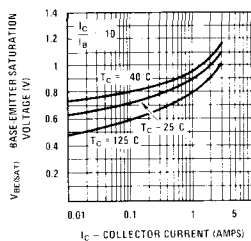
Typical Normalized Pulsed Current Gain vs Collector Current



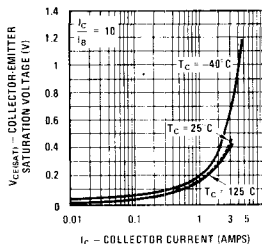
Base-Emitter "ON" Voltage vs Collector Current



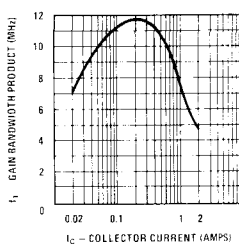
Base-Emitter Saturation Voltage vs Collector Current



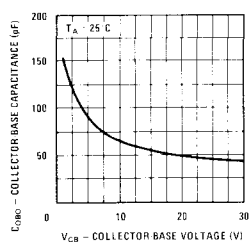
Collector-Emitter Saturation Voltage vs Collector Current



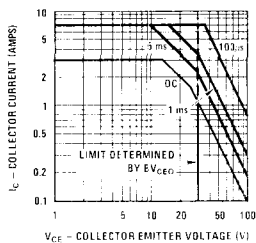
Gain Bandwidth Product vs Collector Current



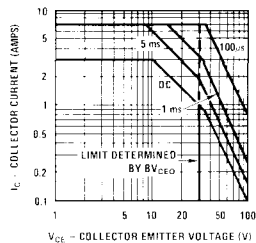
Typical Collector Capacitance vs Collector-Base Voltage



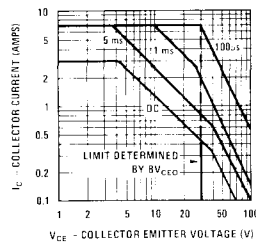
Safe Operating Area TO-220



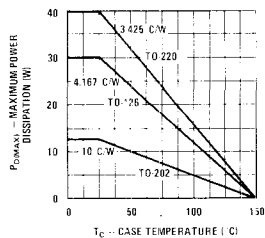
Safe Operating Area TO-126



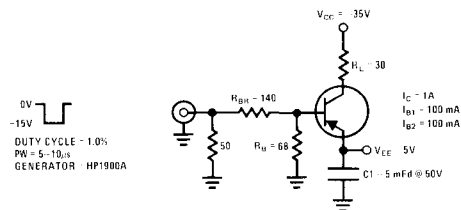
Safe Operating Area TO-202



Maximum Power Dissipation vs Case Temperature



Switching Circuit

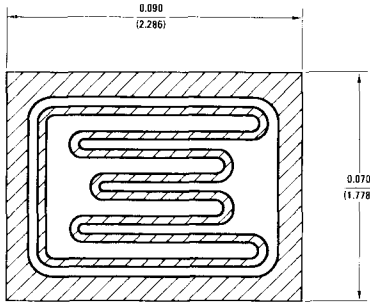


DESCRIPTION

Process 3E/5E is a double epitaxial silicon mesa with diffused emitter.

APPLICATION

This device was designed for general purpose power amplifier and switching circuits where a large safe operation area is required.



| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|--|------|------|-------|----------------------|
| BV_{CEO} | $I_C = 100 \text{ mA}$, (Note 1) | 30 | 60 | 100 | V |
| BV_{CBO} | $I_C = 1 \text{ mA}$ | 40 | | 150 | V |
| BV_{EBO} | $I_E = 1 \text{ mA}$ | 5 | 8 | | V |
| I_{CEO} | $V_{CE} = BV_{CEO}$ | | 50 | 300 | μA |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | 10 | 100 | μA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | 50 | 1000 | μA |
| h_{FE} | $I_C = 1.5\text{A}$, $V_{CE} = 2.0\text{V}$, (Note 1) | 20 | | 170 | |
| $V_{CE(SAT)}$ | $I_C = 4.0\text{A}$, $I_B = 0.6\text{A}$, (Note 1) | | | 0.65 | V |
| $V_{BE(ON)}$ | $I_C = 4.0\text{A}$, $V_{CE} = 2.0\text{V}$, (Note 1) | | | 1.3 | V |
| SOA | TO-220, $V_{CE} = 33.3\text{V}$, $t = 1 \text{ sec}$ | 1.5 | | | A |
| SOA | TO-126, $V_{CE} = 33.3\text{V}$, $t = 1 \text{ sec}$ | 1.2 | | | A |
| SOA | TO-202, $V_{CE} = 33.3\text{V}$, $t = 1 \text{ sec}$ | 0.45 | | | A |
| f_t | $I_C = 0.5\text{A}$, $V_{CE} = 2\text{V}$, $f = 1 \text{ MHz}$ | 4 | | | MHz |
| t_d | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CE} = 30\text{V}$ | | 0.10 | | μs |
| t_r | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CE} = 30\text{V}$ | | 0.25 | | μs |
| t_s | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CE} = 30\text{V}$ | | 0.40 | | μs |
| t_f | $I_C = 1.0\text{A}$, $I_{B1} = 0.1\text{A}$, $I_{B2} = 0.1\text{A}$, $V_{CE} = 30\text{V}$ | | 0.23 | | μs |
| $P_D(\text{MAX})$ | TO-220 | | | 50 | W |
| | TO-126 | | | 40 | W |
| | TO-202 | | | 15 | W |
| θ_{jc} | TO-220 | | | 2.5 | $^{\circ}\text{C/W}$ |
| | TO-126 | | | 3.125 | $^{\circ}\text{C/W}$ |
| | TO-202 | | | 8.33 | $^{\circ}\text{C/W}$ |

Note 1: Pulsed measurement = 300 μs pulse width.

PRINCIPAL DEVICE TYPES

TO-220 (Package 37)

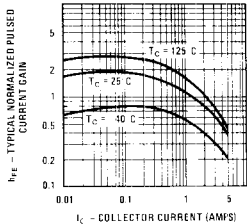
| | | | | |
|--------|--------|--------|---------|--------|
| 2N6106 | 2N6124 | D45C3 | NSP42B | 2N5193 |
| 2N6107 | 2N6125 | D45C6 | NSP42C | 2N5194 |
| 2N6108 | 2N6126 | D45C9 | NSP371 | 2N5195 |
| 2N6109 | 2N6132 | D45C12 | NSP5193 | MJE371 |
| 2N6110 | 2N6133 | NSP42 | NSP5194 | |
| 2N6111 | 2N6134 | NSP42A | NSP5195 | |

TO-126 (Package 38)

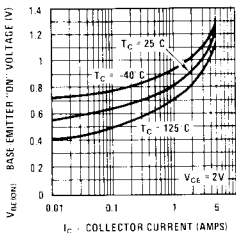
| |
|--------|
| 2N5193 |
| 2N5194 |
| 2N5195 |
| MJE371 |

Process 3E/5E

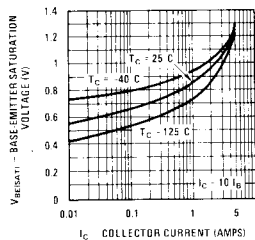
Typical Normalized Pulsed Current Gain vs Collector Current



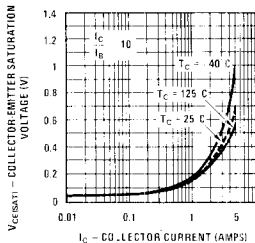
Base-Emitter "ON" Voltage vs Collector Current



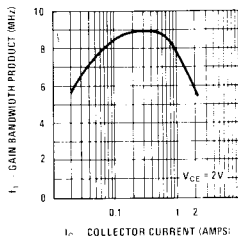
Base-Emitter Saturation Voltage vs Collector Current



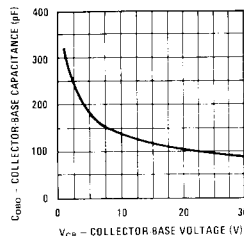
Collector-Emitter Saturation Voltage vs Collector Current



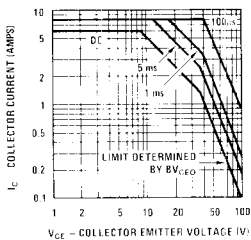
Gain Bandwidth Product vs Collector Current



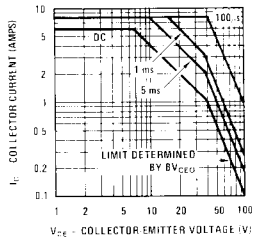
Collector-Base Capacitance vs Collector-Base Voltage



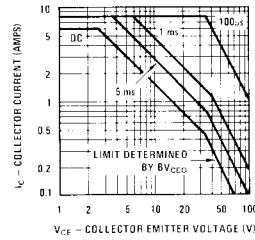
Safe Operating Area TO-220



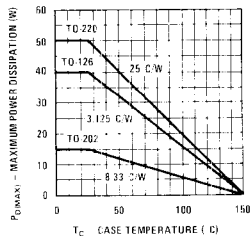
Safe Operating Area TO-126



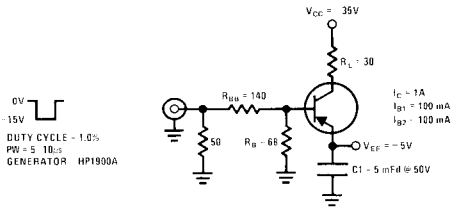
Safe Operating Area TO-202



Maximum Power Dissipation vs Case Temperature



Switching Circuit

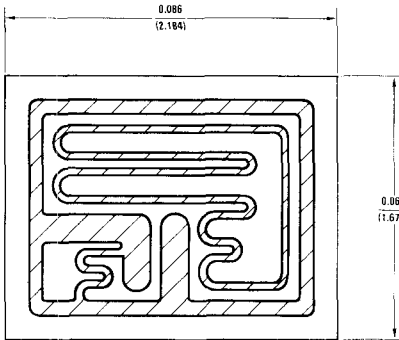


DESCRIPTION

Process 3J/5J is a double epitaxial silicon mesa device. Complement to Process 2J/4J.

APPLICATION

This device was designed for use in driver and output stages of complementary audio amplifier circuits. It is also well suited for solenoid driver applications.



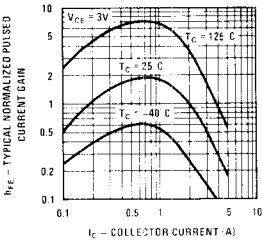
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|-----|-------|----------------------|
| BV_{CEO} | $I_C = 100 \text{ mA}$ | 30 | | 100 | V |
| BV_{CBO} | $I_C = 100 \mu\text{A}$ | 50 | | 120 | V |
| BV_{EBO} | $I_E = 2 \text{ mA}$ | 5 | | | V |
| I_{CEO} | $V_{CE} = 1/2 BV_{CEO}$ | | | 0.5 | mA |
| I_{CBO} | $V_{CB} = BV_{CEO}$ | | | 200 | μA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | | 2.0 | mA |
| h_{FE} | $I_C = 2\text{A}, V_{CE} = 3\text{V}$ | 500 | | | |
| $V_{CE(SAT)}$ | $I_C = 5\text{A}, I_B = 2.0 \text{ mA}$ | | | 3.3 | V |
| $V_{BE(ON)}$ | $I_C = 5\text{A}, V_{CE} = 3\text{V}$ | | | 2.8 | V |
| C_{OBO} | $V_{CB} = 10\text{V}$ | | 35 | | pF |
| $ h_{FE} $ | $I_C = 1\text{A}, V_{CE} = 3\text{V}, f = 1 \text{ MHz}$ | | 4 | | |
| t_{ON} | $I_C = 6\text{A}, V_{CE} = 30\text{V}, (\text{Figure 1})$ | | 2.0 | | |
| t_{OFF} | $I_C = 6\text{A}, V_{CE} = 30\text{V}, (\text{Figure 1})$ | | 2.6 | | |
| $P_{D(MAX)}$ | TO-220 | 50 | | | W |
| $P_{D(MAX)}$ | TO-126 | 40 | | | W |
| θ_{JC} | TO-220 | | | 2.5 | $^{\circ}\text{C/W}$ |
| θ_{JC} | TO-126 | | | 3.125 | $^{\circ}\text{C/W}$ |

PRINCIPAL DEVICE TYPES

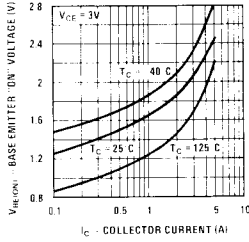
| | |
|----------------------------|----------------------------|
| TO-126 (Package 38) | TO-220 (Package 37) |
| 2N6034 | TIP115 |
| 2N6035 | TIP116 |
| 2N6036 | TIP117 |
| MJE700 | NSP2090 |
| MJE701 | NSP2091 |
| MJE702 | NSP2092 |
| MJE703 | NSP2093 |

Process 3J/5J

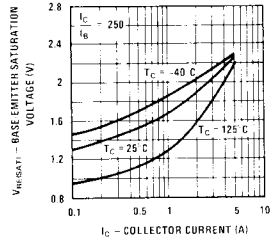
Typical Normalized Pulsed Current Gain vs Collector Current



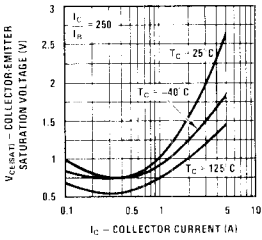
Base-Emitter "ON" Voltage vs Collector Current



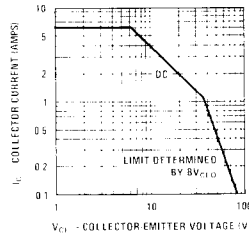
Base-Emitter Saturation Voltage vs Collector Current



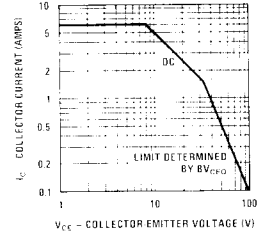
Collector-Emitter Saturation Voltage vs Collector Current



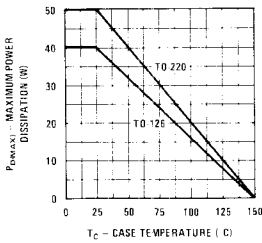
Safe Operating Area TO-126



Safe Operating Area TO-220



Maximum Power Dissipation vs Case Temperature



Switching Times vs Collector Current

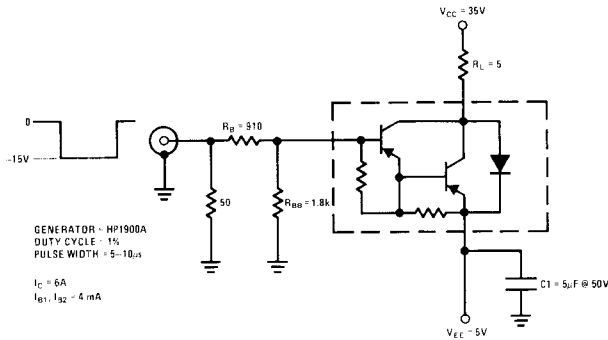
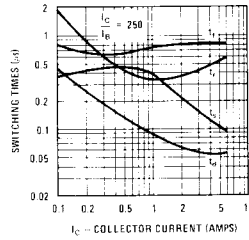
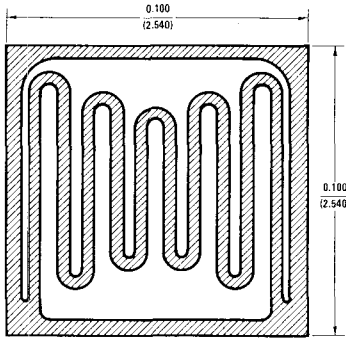


Figure 1.



DESCRIPTION

Process 4A is a double epitaxial silicon NPN mesa device with diffused emitter.

APPLICATION

This device was designed for general purpose power amplifier and switching circuits where a large safe operating area is required.

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|------|------|----------------------|
| BV_{CEO} | $I_C = 200 \text{ mA}$, (Note 1) | 40 | | 100 | V |
| BV_{CBO} | $I_C = 1 \text{ mA}$ | 60 | | | V |
| BV_{EBO} | $I_E = 0.5 \text{ mA}$ | 5 | 7 | | V |
| I_{CEO} | $V_{CE} = BV_{CEO} - 10V$ | | 10 | 200 | μA |
| I_{CBO} | $V_{CB} = BV_{CEO} + 20V$ | | 1 | 20 | μA |
| I_{EBO} | $V_{EB} = 5V$ | | 1 | 500 | μA |
| h_{FE} | $I_C = 2.5 \text{ A}$, $V_{CE} = 2V$ | 20 | | 160 | |
| $V_{CE(SAT)}$ | $I_C = 4 \text{ A}$, $I_B = 0.4 \text{ A}$ | | 0.4 | 0.6 | V |
| $V_{BE(ON)}$ | $I_C = 5 \text{ A}$, $V_{CE} = 2V$ | | 1.1 | 1.3 | V |
| SOA | TO-3, $I_C = 3 \text{ A}$, $t = 1 \text{ sec}$ | 30 | | | V |
| SOA | TO-220, $I_C = 2 \text{ A}$, $t = 1 \text{ sec}$ | 30 | | | V |
| f_t | $I_C = 0.5 \text{ A}$, $V_{CE} = 5V$, $f = 1 \text{ MHz}$ | 2 | 3 | | |
| t_d | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$ $V_{CC} = 40V$ | | 0.07 | | μs |
| t_r | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$, $V_{CC} = 40V$ | | 0.8 | | μs |
| t_s | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$, $V_{CC} = 40V$ | | 0.4 | | μs |
| t_f | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$, $V_{CC} = 40V$ | | 0.5 | | μs |
| $P_{D(MAX)}$ | TO-3 | 115 | | | W |
| $P_{D(MAX)}$ | TO-220 | 60 | | | W |
| θ_{jc} | TO-3 | | | 1.52 | $^{\circ}\text{C/W}$ |
| θ_{jc} | TO 220 | | | 2.08 | $^{\circ}\text{C/W}$ |

Note 1: Pulsed measurement = 300 μs pulse width.

PRINCIPAL DEVICE TYPES

TO-220 (Package 37)

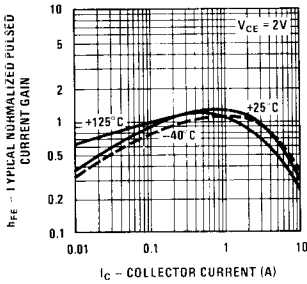
| | | |
|---------|----------------|----------------|
| NSP5977 | NSP2021 | 2N6102, 2N6103 |
| NSP5978 | NSP205 | 2N6100, 2N6101 |
| NSP5979 | NSP3055 | 2N6486 |
| NSP2020 | 2N6098, 2N6099 | 2N6487 |

TO-3 (Package 98)

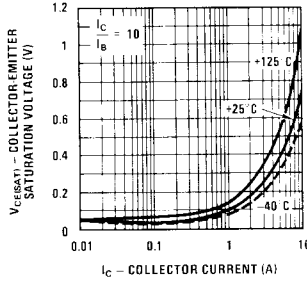
| | | | | | |
|-------|--------|---------|--------|--------|--------|
| D44H1 | D44H7 | NSP2480 | 2N3055 | 2N5067 | MJ2801 |
| D44H2 | D44H8 | NSP2481 | 2N4913 | 2N5068 | |
| D44H4 | D44H10 | NSP2482 | 2N4914 | 2N5069 | |
| D44H5 | D44H11 | NSP2483 | 2N4915 | 2N6569 | |

Process 4A

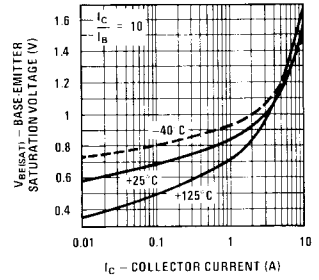
Typical Normalized Pulsed Current Gain vs Collector Current



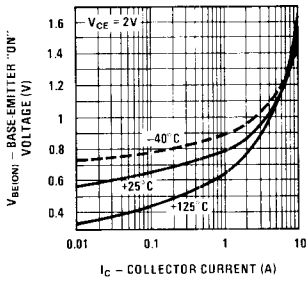
Collector-Emitter Saturation Voltage vs Collector Current



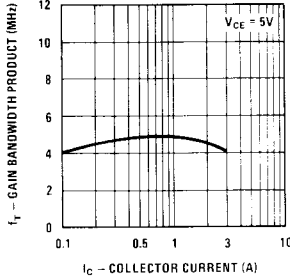
Base-Emitter Saturation Voltage vs Collector Current



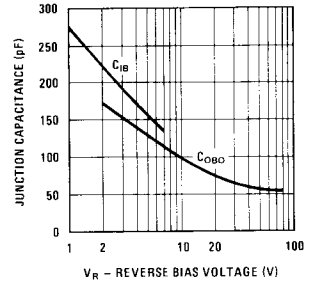
Base-Emitter "ON" Voltage vs Collector Current



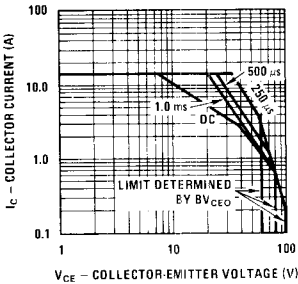
Gain Bandwidth Product vs Collector Current



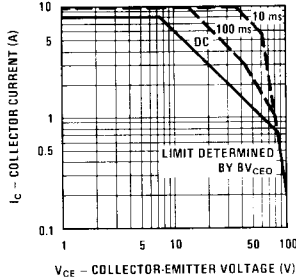
Junction Capacitance vs Reverse Bias Voltage



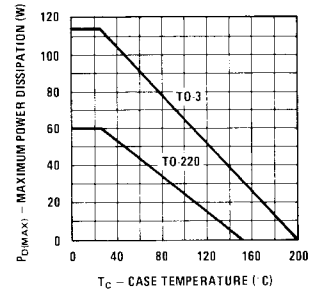
Safe Operating Area TO-3

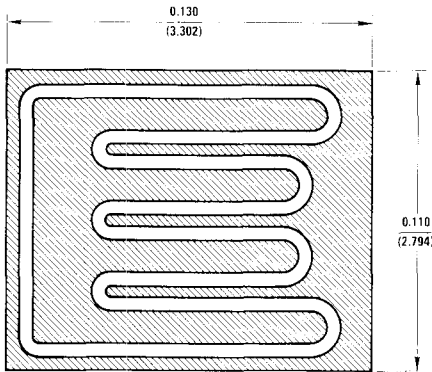


Safe Operating Area TO-220



Maximum Power Dissipation vs Case Temperature





DESCRIPTION

Process 4B is a double epitaxial silicon mesa transistor with diffused emitter.

APPLICATION

This device was designed for general purpose amplifier and switching circuits where a large safe operating area is required.

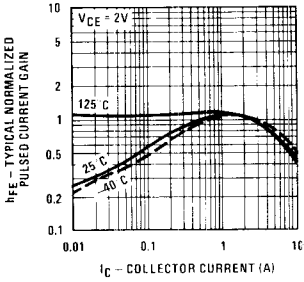
| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|------|-----|------|----------------------|
| V_{CE0} | $I_C = 200 \text{ mA}$ | 60 | 80 | 150 | V |
| V_{CB0} | $I_C = 500 \mu\text{A}$ | 60 | | | V |
| V_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | 7 | | V |
| I_{CEO} | $V_{CE} = 30\text{V}$ | | | 1 | mA |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{BE} = -1.5\text{V}$ | | | 0.5 | mA |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 0.5 | mA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | | 1 | mA |
| H_{FE} | $I_C = 1\text{A}, V_{CE} = 2\text{V}$ | 25 | | | |
| H_{FE} | $I_C = 3\text{A}, V_{CE} = 2\text{V}$ | 15 | | 100 | |
| H_{FE} | $I_C = 8\text{A}, V_{CE} = 4\text{V}$ | 5 | | | |
| $V_{CE(SAT)}$ | $I_C = 5\text{A}, I_B = 0.5\text{A}$ | | | 1 | V |
| $V_{CE(SAT)}$ | $I_C = 8\text{A}, I_B = 1.6\text{A}$ | | | 3 | V |
| $V_{BE(SAT)}$ | $I_C = 5\text{A}, I_B = 0.5\text{A}$ | | | 1.6 | V |
| $V_{BE(ON)}$ | $I_C = 3\text{A}, V_{CE} = 2\text{V}$ | | | 1.5 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 300 | pF |
| f_t | $I_C = 0.5\text{A}, V_{CE} = 10\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| SOA | TO-3, $V_{CE} = 45\text{V}, t = 1 \text{ sec}$ | 3.3 | | | A |
| SOA | TO-220, $V_{CE} = 45\text{V}, t = 1 \text{ sec}$ | 1.55 | | | A |
| $P_{D(MAX)}$ | TO-3 | 150 | | | W |
| $P_{D(MAX)}$ | TO-220 | 70 | | | W |
| θ_{jc} | TO-3 | | | 1.16 | $^{\circ}\text{C/W}$ |
| θ_{jc} | TO-220 | | | 1.78 | $^{\circ}\text{C/W}$ |

PRINCIPAL DEVICE TYPES

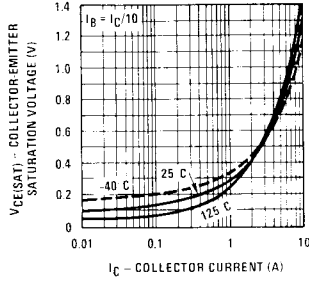
TO-3

| | | |
|--------|--------|--------|
| 2N3713 | 2N5758 | 2N5877 |
| 2N3714 | 2N5759 | 2N5878 |
| 2N3715 | 2N5760 | MJ2840 |
| 2N3716 | | MJ2841 |

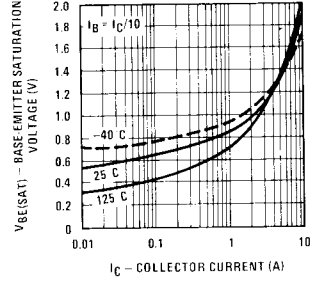
Typical Normalized Pulsed Current Gain vs Collector Current



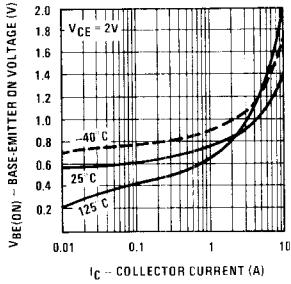
Collector-Emitter Saturation Voltage vs Collector Current



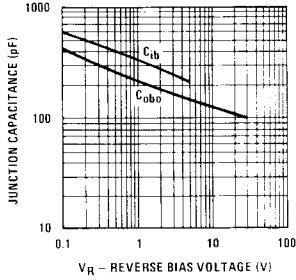
Base-Emitter Saturation Voltage vs Collector Current



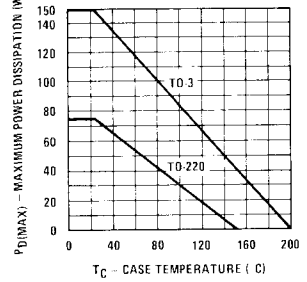
Base-Emitter ON Voltage vs Collector Current



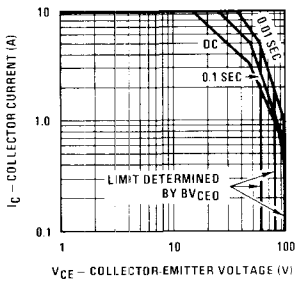
Junction Capacitance vs Reverse Bias Voltage



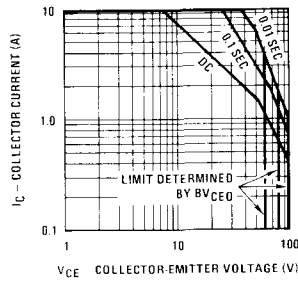
Maximum Power Dissipation vs Case Temperature

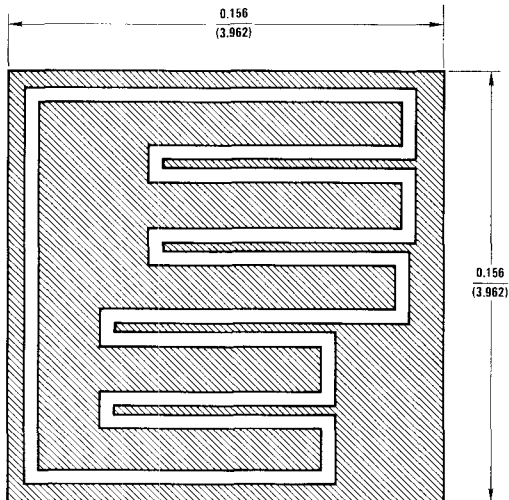


Safe Operating Area TO-3



Safe Operating Area TO-220




DESCRIPTION

Process 4C is a double epitaxial silicon mesa transistor with diffused emitter.

APPLICATION

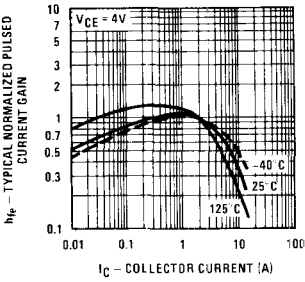
This device was designed for general purpose amplifier and switching circuits where a large safe operating area is required.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|---|-----|-----|------|----------------------|
| V_{CE0} | $I_C = 200 \text{ mA}$ | 60 | 80 | 150 | V |
| V_{CB0} | $I_C = 500 \mu\text{A}$ | 60 | | 100 | V |
| V_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | | | V |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{BE} = -1.5\text{V}$ | | | 0.5 | mA |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 0.5 | mA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | | 1.0 | mA |
| H_{FE} | $I_C = 2\text{A}, V_{CE} = 4\text{V}$ | 35 | | | |
| H_{FE} | $I_C = 6\text{A}, V_{CE} = 4\text{V}$ | 20 | | 100 | |
| H_{FE} | $I_C = 12\text{A}, V_{CE} = 4\text{V}$ | 5 | | | |
| $V_{CE(SAT)}$ | $I_C = 7\text{A}, I_B = 0.7\text{A}$ | | | 1 | V |
| $V_{CE(SAT)}$ | $I_C = 12\text{A}, I_B = 2.4\text{A}$ | | | 4 | V |
| $V_{BE(SAT)}$ | $I_C = 7\text{A}, I_B = 0.7\text{A}$ | | | 1.6 | V |
| $V_{BE(ON)}$ | $I_C = 12\text{A}, V_{CE} = 4\text{V}$ | | | 2.5 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 400 | pF |
| SOA | TO-3, $V_{CE} = 50\text{V}, t = 1 \text{ sec}$ | 3.0 | | | A |
| f_t | $I_C = 1\text{A}, V_{CE} = 10\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| $P_D(\text{MAX})$ | TO-3 | 175 | | | W |
| $P_D(\text{MAX})$ | TO-220 | 75 | | | W |
| θ_{jc} | TO-3 | | | 1.0 | $^{\circ}\text{C/W}$ |
| θ_{jc} | TO-220 | | | 1.66 | $^{\circ}\text{C/W}$ |

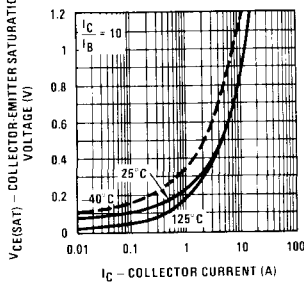
PRINCIPAL DEVICE TYPES
TO-3

| | |
|--------|--------|
| 2N5632 | 2N5881 |
| 2N5633 | 2N5882 |
| 2N5634 | BD351 |

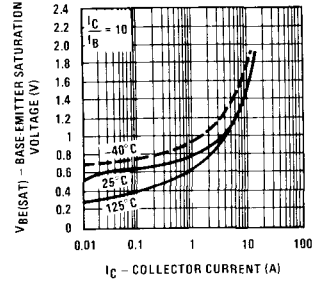
Typical Normalized Pulsed Current Gain vs Collector Current



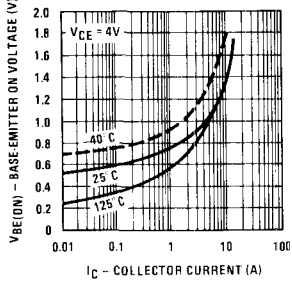
Collector-Emitter Saturation Voltage vs Collector Current



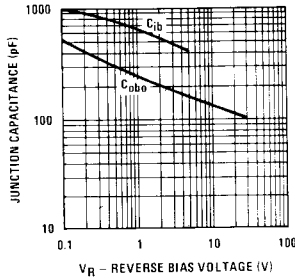
Base-Emitter Saturation Voltage vs Collector Current



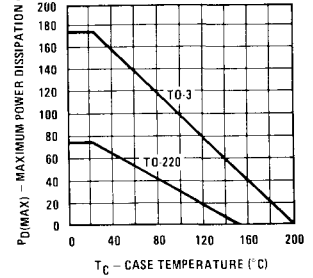
Base-Emitter ON Voltage vs Collector Current



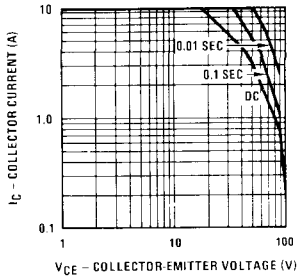
Junction Capacitance vs Reverse Bias Voltage

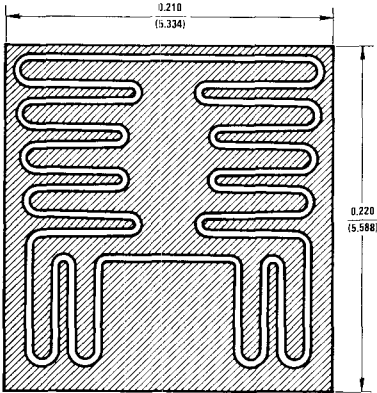


Maximum Power Dissipation vs Case Temperature



Safe Operating Area TO-3





DESCRIPTION

Process 4G is a double epitaxial silicon mesa transistor with diffused emitter.

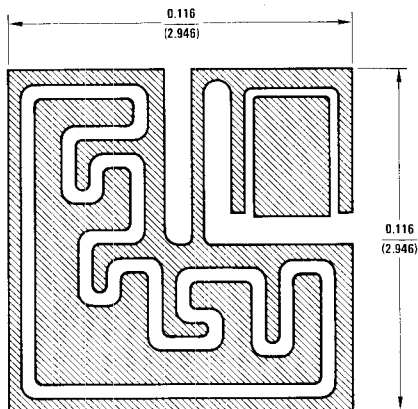
APPLICATION

This device was designed for general purpose amplifier and switching circuits where a large safe operating area is required.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|---|-----|-----|-------|----------------------|
| BV_{CEO} | $I_C = 200 \text{ mA}$ | 60 | 80 | 150 | V |
| BV_{CBO} | $I_C = 1 \text{ mA}$ | 60 | | | V |
| BV_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | | | V |
| I_{CEO} | $V_{CE} = 30\text{V}$ | | | 2 | mA |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{BE} = -1.5\text{V}$ | | | 1 | mA |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 1 | mA |
| I_{EBO} | $V_{BE} = 5\text{V}$ | | | 1 | mA |
| H_{FE} | $I_C = 3\text{A}, V_{CE} = 4\text{V}$ | 35 | | | |
| H_{FE} | $I_C = 10\text{A}, V_{CE} = 4\text{V}$ | 20 | | 100 | |
| H_{FE} | $I_C = 20\text{A}, V_{CE} = 4\text{V}$ | 5 | | | |
| $V_{CE(SAT)}$ | $I_C = 15\text{A}, I_B = 1.5\text{A}$ | | | 1 | V |
| $V_{CE(SAT)}$ | $I_C = 20\text{A}, I_B = 4\text{A}$ | | | 4 | V |
| $V_{BE(SAT)}$ | $I_C = 15\text{A}, I_B = 1.5\text{A}$ | | | 1.8 | V |
| $V_{BE(ON)}$ | $I_C = 20\text{A}, V_{CE} = 4\text{V}$ | | | 2.5 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 500 | pF |
| f_t | $I_C = 1\text{A}, V_{CE} = 10\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| $P_D(\text{MAX})$ | TO-3 | 200 | | | W |
| θ_{jc} | TO-3 | | | 0.875 | $^{\circ}\text{C/W}$ |

PRINCIPAL DEVICE TYPES

TO-3
 2N5629
 2N5630
 2N5631
 2N5885
 2N5886
 2N5301
 2N5302
 2N5303
 MJ802


DESCRIPTION

Process 4K is a double epitaxial silicon mesa Darlington transistor.

APPLICATION

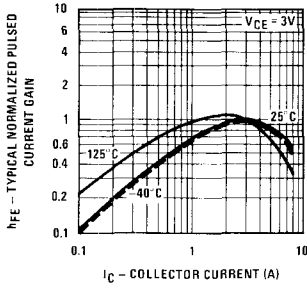
The 4K was designed for general purpose amplifier and low-speed switching applications.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|--|-----|-----|-------|----------------------|
| V_{CE0} | $I_C = 100 \text{ mA}$ | 60 | 80 | 150 | V |
| V_{CB0} | $I_C = 500 \mu\text{A}$ | 60 | | | V |
| V_{E0} | $I_E = 5 \text{ mA}$ | 5 | | | V |
| I_{CE0} | $V_{CE} = 30\text{V}$ | | | 0.5 | mA |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{EB} = 1.5\text{V}$ | | | 0.5 | mA |
| I_{E0} | $V_{BE} = 5\text{V}$ | | | 2.0 | mA |
| h_{FE} | $I_C = 4\text{A}, V_{CE} = 3\text{V}$ | 750 | | 18000 | |
| h_{FE} | $I_C = 8\text{A}, V_{CE} = 3\text{V}$ | 100 | | | |
| $V_{CE(SAT)}$ | $I_C = 4\text{A}, I_B = 16 \text{ mA}$ | | | 2 | V |
| $V_{CE(SAT)}$ | $I_C = 8\text{A}, I_B = 80 \text{ mA}$ | | | 3 | V |
| $V_{BE(SAT)}$ | $I_C = 8\text{A}, I_B = 80 \text{ mA}$ | | | 4 | V |
| $V_{BE(ON)}$ | $I_C = 4\text{A}, V_{CE} = 3\text{V}$ | | | 2.8 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 200 | pF |
| f_t | $I_C = 3\text{A}, V_{CE} = 3\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| $P_{D(MAX)}$ | TO-3 | 120 | | | W |
| $P_{D(MAX)}$ | TO-220 | 60 | | | W |
| θ_{jc} | TO-3 | | | 1.66 | $^{\circ}\text{C/W}$ |
| θ_{jc} | TO-220 | | | 2.08 | $^{\circ}\text{C/W}$ |

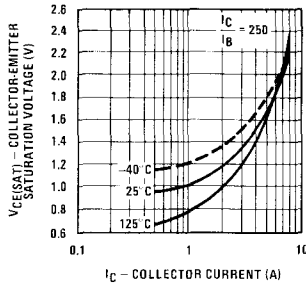
PRINCIPAL DEVICE TYPES

| | | | |
|-------------|--------|---------------|--------|
| TO-3 | | TO-220 | |
| 2N6055 | 2N6385 | TIP121 | TIP132 |
| 2N6056 | MJ1000 | TIP122 | SE9300 |
| 2N6383 | MJ1001 | TIP130 | SE9301 |
| 2N6384 | | TIP131 | SE9302 |

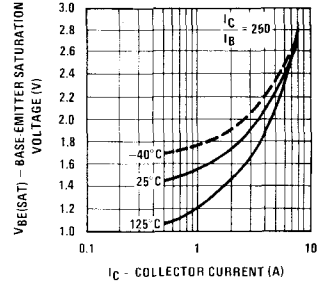
Typical Normalized Pulsed Current Gain vs Collector Current



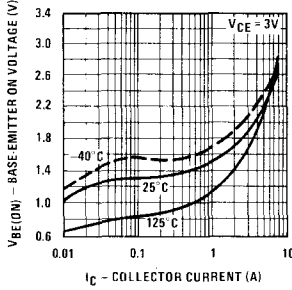
Collector-Emitter Saturation Voltage vs Collector Current



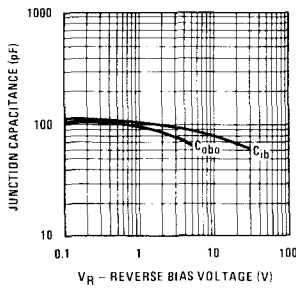
Base-Emitter Saturation Voltage vs Collector Current



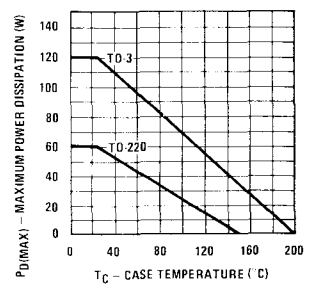
Base-Emitter ON Voltage vs Collector Current



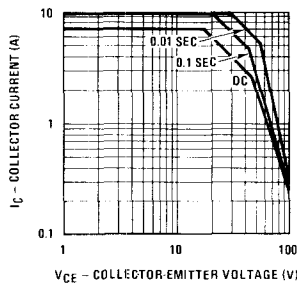
Junction Capacitance vs Reverse Bias Voltage



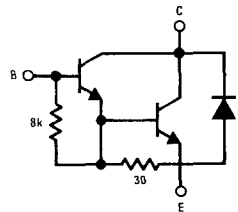
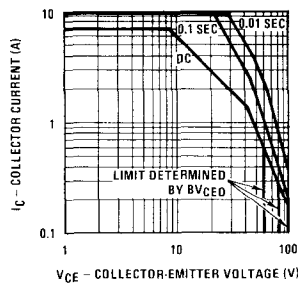
Maximum Power Dissipation vs Case Temperature

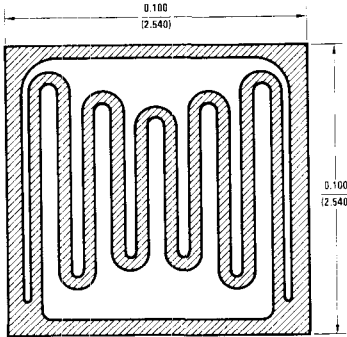


Safe Operating Area TO-3



Safe Operating Area TO-220




DESCRIPTION

Process 5A is a double epitaxial silicon PNP mesa device with a diffused emitter.

APPLICATION

This device was designed for general purpose power amplifier and switching circuits where a large safe operating area is required.

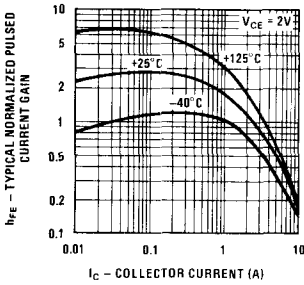
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|---|-----|------|------|----------------------|
| BV_{CEO} | $I_C = 200 \text{ mA}$, (Note 1) | 40 | | 100 | V |
| BV_{CBO} | $I_C = 1 \text{ mA}$ | 60 | | 150 | V |
| BV_{EBO} | $I_E = 0.5 \text{ mA}$ | 5 | 7 | | V |
| I_{CEO} | $V_{CE} = BV_{CEO} - 10V$ | | 10 | 200 | μA |
| I_{CBO} | $V_{CB} = BV_{CEO} + 20V$ | | 1 | 20 | μA |
| I_{EBO} | $V_{EB} = 5V$ | | 1 | 500 | μA |
| h_{FE} | $I_C = 2.5 \text{ A}$, $V_{CE} = 2V$ | 20 | | 200 | |
| $V_{CE(SAT)}$ | $I_C = 4 \text{ A}$, $I_B = 0.4 \text{ A}$ | | 0.5 | 0.6 | V |
| $V_{BE(ON)}$ | $I_C = 5 \text{ A}$, $V_{CE} = 2V$ | | 1.2 | 1.3 | V |
| S_{OA} | $I_C = 3 \text{ A}$, $t = 1 \text{ sec}$ | 30 | | | V |
| t_t | $I_C = 0.5 \text{ A}$, $V_{CE} = 5V$, $f = 1 \text{ MHz}$ | 2 | | | |
| t_d | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$ $V_{CC} = 40V$ | | 0.03 | | μs |
| t_r | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$, $V_{CC} = 40V$ | | 0.27 | | μs |
| t_s | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$, $V_{CC} = 40V$ | | 0.3 | | μs |
| t_f | $I_C = 5 \text{ A}$, $I_{B1} = I_{B2} = 0.5 \text{ A}$, $V_{CC} = 40V$ | | 0.37 | | μs |
| $P_{D(MAX)}$ | TO-220 | 60 | | | |
| θ_{JC} | TO-220 | | | 2.08 | $^{\circ}\text{C/W}$ |

Note 1: Pulsed measurement = 300 μs pulse width.

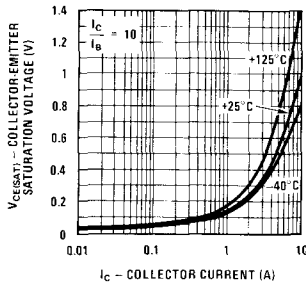
PRINCIPAL DEVICE TYPES
TO-220

| | | |
|---------|---------|--------|
| NSP5974 | NSP2955 | D45H4 |
| NSP5975 | 2N6489 | D45H5 |
| NSP5976 | 2N6490 | D45H7 |
| NSP2010 | 2N6491 | D45H8 |
| NSP2011 | D45H1 | D45H10 |
| NSP105 | D45H2 | D45H11 |

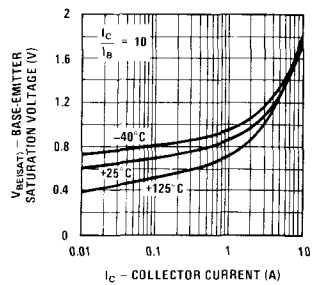
Typical Normalized Pulsed Current Gain vs Collector Current



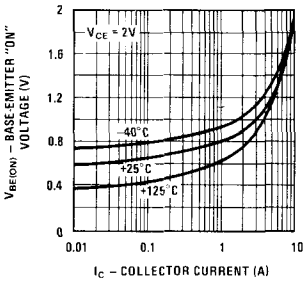
Collector-Emitter Saturation Voltage vs Collector Current



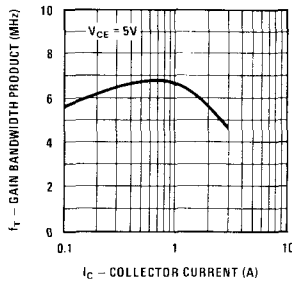
Base-Emitter Saturation Voltage vs Collector Current



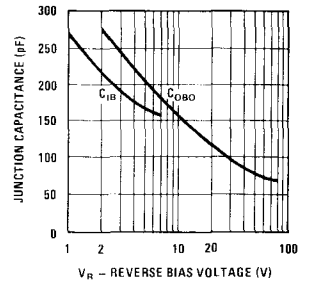
Base-Emitter "ON" Voltage vs Collector Current



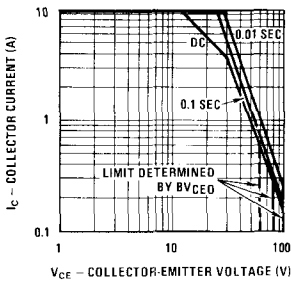
Gain Bandwidth Product vs Collector Current



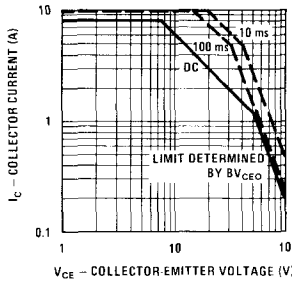
Junction Capacitance vs Reverse Bias Voltage



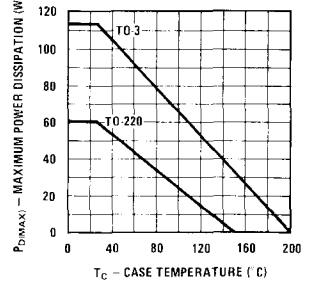
Safe Operating Area TO-3

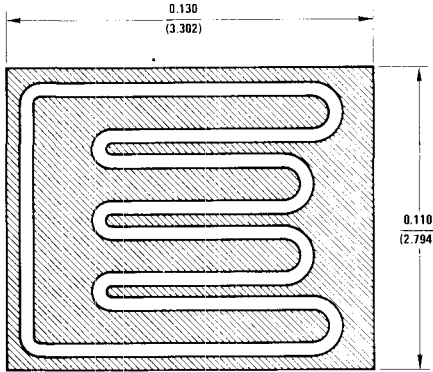


Safe Operating Area TO-220



Maximum Power Dissipation vs Case Temperature




DESCRIPTION

Process 5B is a double epitaxial silicon mesa transistor with diffused emitter.

APPLICATION

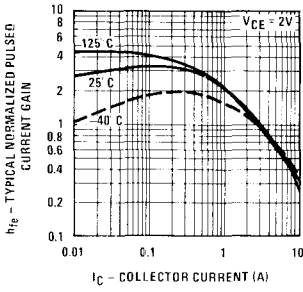
This device was designed for general purpose amplifier and switching circuits where a large safe operating area is required.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|---|-----|-----|------|----------------------|
| V_{CE0} | $I_C = 200 \text{ mA}$ | 60 | 80 | 150 | V |
| V_{CB0} | $I_C = 500 \mu\text{A}$ | 60 | | | V |
| V_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | | | V |
| I_{CE0} | $V_{CE} = 30\text{V}$ | | | 2 | mA |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{BE} = -1.5\text{V}$ | | | 1 | mA |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 1 | mA |
| I_{EBO} | $V_{BE} = 5\text{V}$ | | | 1 | mA |
| H_{FE} | $I_C = 1\text{A}, V_{CE} = 2\text{V}$ | 25 | | | |
| H_{FE} | $I_C = 3\text{A}, V_{CE} = 2\text{V}$ | 15 | | 100 | |
| H_{FE} | $I_C = 8\text{A}, V_{CE} = 4\text{V}$ | 5 | | | |
| $V_{CE(SAT)}$ | $I_C = 5\text{A}, I_B = 0.5\text{A}$ | | | 1 | V |
| $V_{CE(SAT)}$ | $I_C = 8\text{A}, I_B = 1.6\text{A}$ | | | 4 | V |
| $V_{BE(SAT)}$ | $I_C = 5\text{A}, I_B = 0.5\text{A}$ | | | 1.8 | V |
| $V_{BE(ON)}$ | $I_C = 3\text{A}, V_{CE} = 2\text{V}$ | | | 2.5 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 500 | pF |
| f_t | $I_C = 0.5\text{A}, V_{CE} = 10\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| $P_D(\text{MAX})$ | TO-3 | 150 | | | W |
| $P_D(\text{MAX})$ | TO-220 | 70 | | | W |
| θ_{jc} | TO-3 | | | 1.16 | $^{\circ}\text{C/W}$ |
| θ_{jc} | TO-220 | | | 1.78 | $^{\circ}\text{C/W}$ |

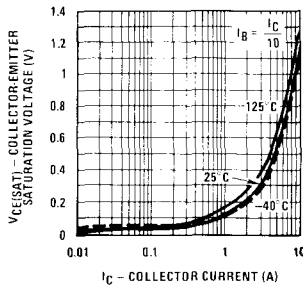
PRINCIPAL DEVICE TYPES
TO-3

| | | |
|--------|--------|--------|
| 2N3789 | 2N4908 | 2N6227 |
| 2N3790 | 2N4909 | 2N6228 |
| 2N3791 | 2N5875 | MJ2940 |
| 2N3792 | 2N5876 | MJ2941 |
| 2N4907 | 2N6226 | |

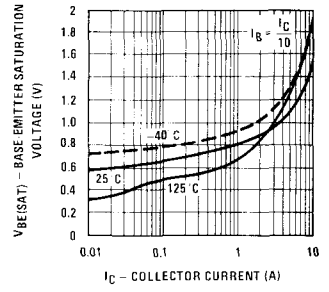
Typical Normalized Pulsed Current Gain vs Collector Current



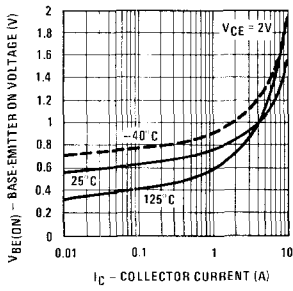
Collector-Emitter Saturation Voltage vs Collector Current



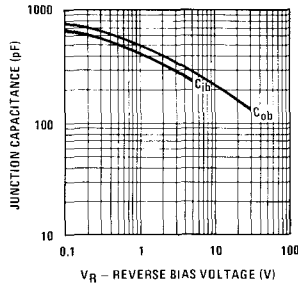
Base-Emitter Saturation Voltage vs Collector Current



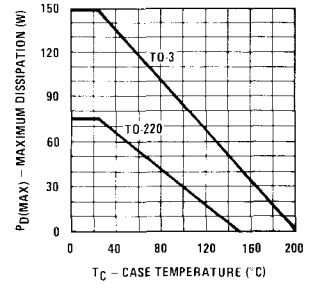
Base-Emitter ON Voltage vs Collector Current



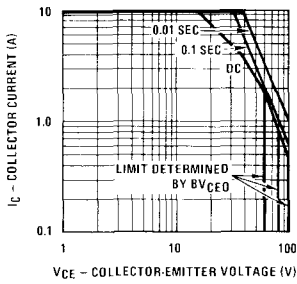
Junction Capacitance vs Reverse Bias Voltage



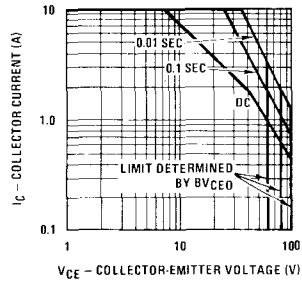
Maximum Power Dissipation vs Case Temperature

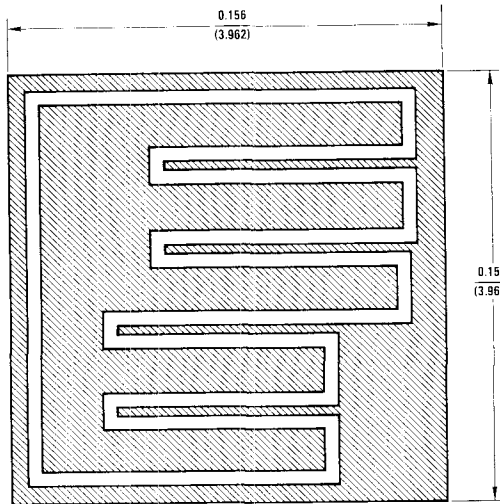


Safe Operating Area TO-3



Safe Operating Area TO-220




DESCRIPTION

Process 5C is a double epitaxial silicon mesa transistor with diffused emitter.

APPLICATION

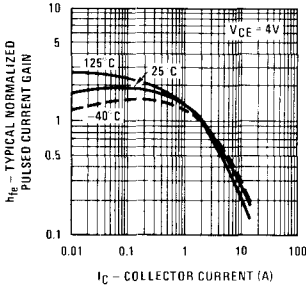
This device was designed for general purpose amplifier and switching circuits where a large safe operating area is required.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|---|-----|-----|------|----------------------|
| V_{CE0} | $I_C = 200 \text{ mA}$ | 60 | 80 | 150 | V |
| V_{CB0} | $I_C = 500 \mu\text{A}$ | 60 | | 100 | V |
| V_{E0} | $I_E = 100 \mu\text{A}$ | 5 | | | V |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{BE} = 1.5\text{V}$ | | | 0.5 | mA |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 0.5 | mA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | | 1.0 | mA |
| H_{FE} | $I_C = 2\text{A}, V_{CE} = 4\text{V}$ | 35 | | | |
| H_{FE} | $I_C = 6\text{A}, V_{CE} = 4\text{V}$ | 20 | | 100 | |
| H_{FE} | $I_C = 12\text{A}, V_{CE} = 4\text{V}$ | 5 | | | |
| $V_{CE(SAT)}$ | $I_C = 7\text{A}, I_B = 0.7\text{A}$ | | | 1 | V |
| $V_{CE(SAT)}$ | $I_C = 12\text{A}, I_B = 2.4\text{A}$ | | | 4 | V |
| $V_{BE(SAT)}$ | $I_C = 7\text{A}, I_B = 0.7\text{A}$ | | | 1.6 | V |
| $V_{BE(ON)}$ | $I_C = 12\text{A}, V_{CE} = 4\text{V}$ | | | 2.5 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 600 | pF |
| f_t | $I_C = 1\text{A}, V_{CE} = 10\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| $P_D(\text{MAX})$ | TO-3 | 175 | | | W |
| $P_D(\text{MAX})$ | TO-220 | 75 | | | W |
| θ_{jc} | TO-3 | | | 1.0 | $^{\circ}\text{C/W}$ |
| θ_{jc} | TO-220 | | | 1.66 | $^{\circ}\text{C/W}$ |

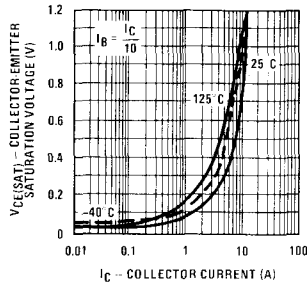
PRINCIPAL DEVICE TYPES
TO-3

| | |
|--------|--------|
| 2N6229 | 2N5879 |
| 2N6230 | 2N5880 |
| 2N6231 | BD350 |

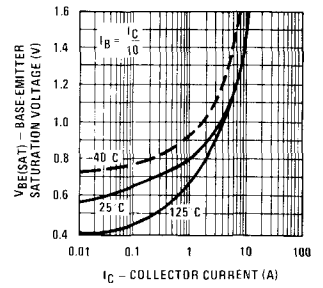
Typical Normalized Pulsed Current Gain vs Collector Current



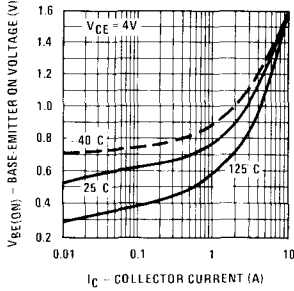
Collector-Emitter Saturation Voltage vs Collector Current



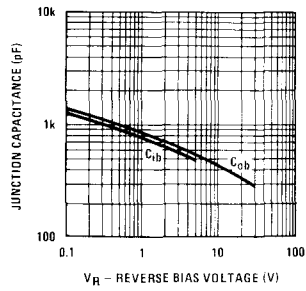
Base-Emitter Saturation Voltage vs Collector Current



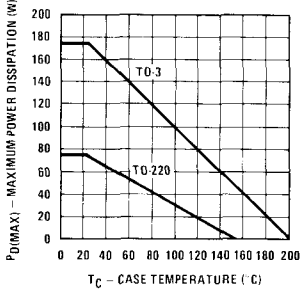
Base-Emitter ON Voltage vs Collector Current



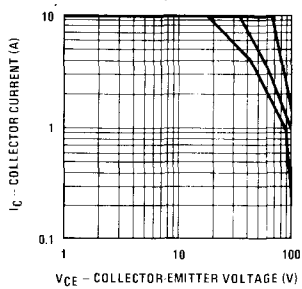
Junction Capacitance vs Reverse Bias Voltage

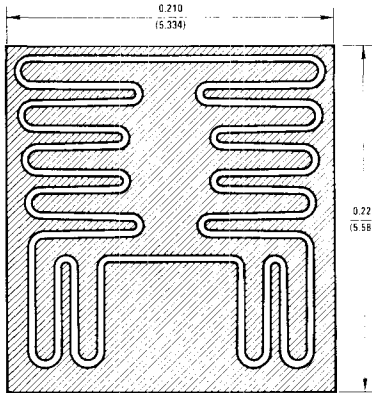


Maximum Power Dissipation vs Case Temperature



Safe Operating Area TO-3




DESCRIPTION

Process 5G is a double epitaxial silicon mesa transistor with diffused emitter.

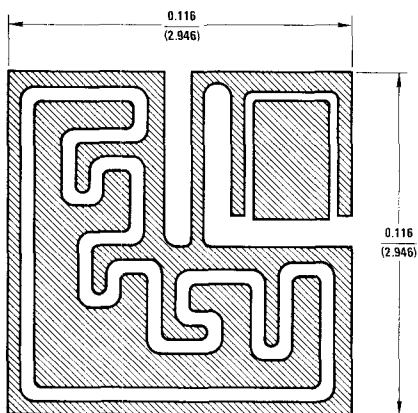
APPLICATION

This device was designed for general purpose amplifier and switching circuits where a large safe operating area is required.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|---|-----|-----|-------|----------------------|
| BV_{CEO} | $I_C = 200 \text{ mA}$ | 60 | 80 | 150 | V |
| BV_{CBO} | $I_C = 1 \text{ mA}$ | 60 | | | V |
| BV_{EBO} | $I_E = 100 \mu\text{A}$ | 5 | | | V |
| I_{CEO} | $V_{CE} = 30\text{V}$ | | | 2 | mA |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{BE} = 1.5\text{V}$ | | | 1 | mA |
| I_{CBO} | $V_{CB} = 60\text{V}$ | | | 1 | mA |
| I_{EBO} | $V_{EB} = 5\text{V}$ | | | 1 | mA |
| H_{FE} | $I_C = 3\text{A}, V_{CE} = 4\text{V}$ | 35 | | | |
| H_{FE} | $I_C = 10\text{A}, V_{CE} = 4\text{V}$ | 20 | | 100 | |
| H_{FE} | $I_C = 20\text{A}, V_{CE} = 4\text{V}$ | 5 | | | |
| $V_{CE(SAT)}$ | $I_C = 15\text{A}, I_B = 1.5\text{A}$ | | | 1 | V |
| $V_{CE(SAT)}$ | $I_C = 20\text{A}, I_B = 4\text{A}$ | | | 4 | V |
| $V_{BE(SAT)}$ | $I_C = 15\text{A}, I_B = 1.5\text{A}$ | | | 1.8 | V |
| $V_{BE(ON)}$ | $I_C = 20\text{A}, V_{CE} = 4\text{V}$ | | | 2.5 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 800 | pF |
| f_t | $I_C = 1\text{A}, V_{CE} = 10\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| $P_D(\text{MAX})$ | | 200 | | | W |
| θ_{jc} | | | | 0.875 | $^{\circ}\text{C/W}$ |

PRINCIPAL DEVICE TYPES
TO-3

2N6029
2N6030
2N6031
MJ4502


DESCRIPTION

Process 5K is a double epitaxial silicon mesa Darlington transistor.

APPLICATION

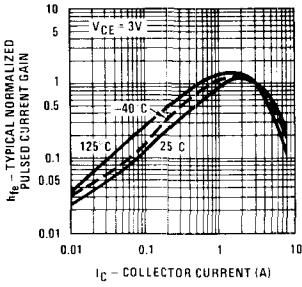
The 5K was designed for general purpose amplifier and low-speed switching applications.

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------|--|-----|-----|-------|----------------------|
| BV_{CEO} | $I_C = 100 \text{ mA}$ | 60 | 80 | 150 | V |
| BV_{CBO} | $I_C = 500 \mu\text{A}$ | 60 | | | V |
| BV_{EBO} | $I_E = 5 \text{ mA}$ | 5 | | | V |
| I_{CEO} | $V_{CE} = 30\text{V}$ | | | 0.5 | mA |
| I_{CEX} | $V_{CE} = 60\text{V}, V_{EB} = 1.5\text{V}$ | | | 0.5 | mA |
| I_{EBO} | $V_{BE} = 5\text{V}$ | | | 2.0 | mA |
| H_{FE} | $I_C = 4\text{A}, V_{CE} = 3\text{V}$ | 750 | | 18000 | |
| H_{FE} | $I_C = 8\text{A}, V_{CE} = 3\text{V}$ | 100 | | | |
| $V_{CE(SAT)}$ | $I_C = 4\text{A}, I_B = 16 \text{ mA}$ | | | 2 | V |
| $V_{CE(SAT)}$ | $I_C = 8\text{A}, I_B = 80 \text{ mA}$ | | | 3 | V |
| $V_{BE(SAT)}$ | $I_C = 8\text{A}, I_B = 80 \text{ mA}$ | | | 4 | V |
| $V_{BE(ON)}$ | $I_C = 4\text{A}, V_{CE} = 3\text{V}$ | | | 2.8 | V |
| C_{obo} | $V_{CB} = 10\text{V}$ | | | 300 | pF |
| f_t | $I_C = 3\text{A}, V_{CE} = 3\text{V}, f = 1 \text{ MHz}$ | 4 | | | MHz |
| $P_D(\text{MAX})$ | TO-3 | 120 | | | W |
| $P_D(\text{MAX})$ | TO-220 | 60 | | | W |
| θ_{jc} | TO-3 | | | 1.66 | $^{\circ}\text{C/W}$ |
| θ_{jc} | TO-220 | | | 2.08 | $^{\circ}\text{C/W}$ |

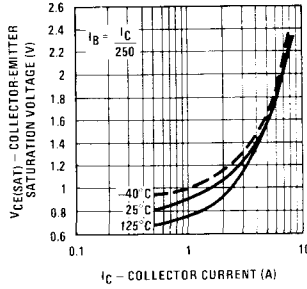
PRINCIPAL DEVICE TYPES

| | | |
|-------------|---------------|--------|
| TO-3 | TO-220 | |
| 2N6053 | TIP125 | TIP136 |
| 2N6054 | TIP126 | TIP137 |
| MJ900 | TIP127 | SE9401 |
| MJ901 | TIP135 | SE9402 |

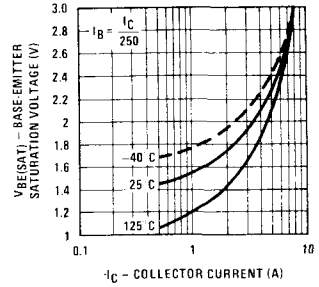
Typical Normalized Pulsed Current Gain vs Collector Current



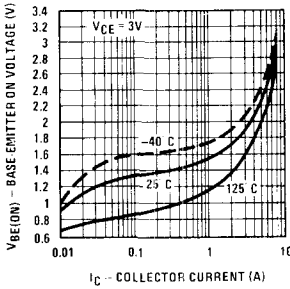
Collector-Emitter Saturation Voltage vs Collector Current



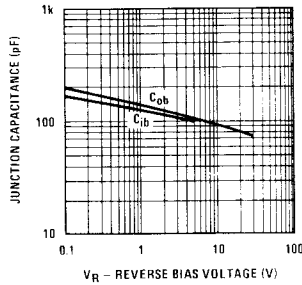
Base-Emitter Saturation Voltage vs Collector Current



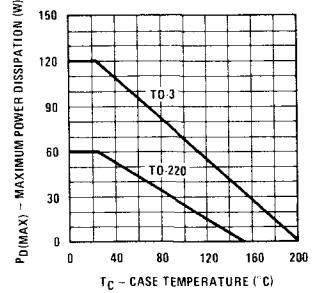
Base-Emitter ON Voltage vs Collector Current



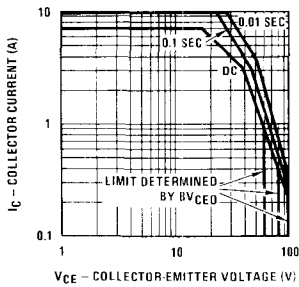
Junction Capacitance vs Reverse Bias Voltage



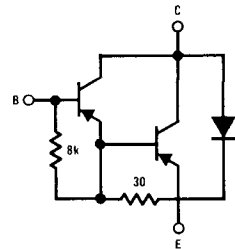
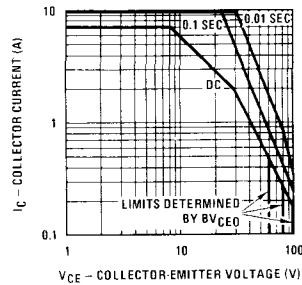
Maximum Power Dissipation vs Case Temperature



Safe Operating Area TO 3



Safe Operating Area TO-220





Section 8
**JFET Selection
Guide**



N-Channel FETs

SWITCHES/CHOPPERS

| Type No. | Case Style | BV _{GSS} BV _{GDO} (V) Min | I _{GSS} I _{DGO} (μ A) Max | I _{D(off)} @ V _{DS} (nA) Max | V _{DS} (V) Max | V _p V _{DS} (V) Max | I _D (nA) Max | I _{DSS} (mA) Max | r _{ds(on)} (Ω) Max | I _D (mA) Max | I _D (mA) Max | V _{GS} (V) Max | V _{GS} (V) Max | C _{iss} V _{DS} (pF) Max | C _{iss} V _{DS} (pF) Max | V _{GS} (V) Max | V _{GS} (V) Max | t _{on} (ns) Max | t _{off} (ns) Max | Process No. | Pkg. No. | |
|----------|------------|--|---|---|-------------------------------|---|-------------------------------|---------------------------------|--|-------------------------------|-------------------------------|-------------------------------|-------------------------------|--|--|-------------------------------|-------------------------------|--------------------------------|---------------------------------|-------------|----------|----|
| 2N3824 | TO-72 | 50 | 1 | 0.1 | 15 | -8 | 8 | 15 | 1 | 250 | 6 | 15 | 0 | 3 | 0 | 8 | 0 | 7 | | 55 | 25 | |
| 2N3966 | TO-72 | 30 | 1 | 1 | 10 | -7 | 4 | 6 | 10 | 220 | 6 | 20 | 0 | 1.5 | 0 | 7 | 0 | 8 | | 50 | 25 | |
| 2N3970 | TO-18 | 40 | 1 | 0.25 | 20 | -12 | 4 | 10 | 20 | 50 | 150 | 20 | 0 | 6 | 0 | 12 | 0 | 30 | 30 | 51 | 02 | |
| 2N3971 | TO-18 | 40 | 1 | 0.25* | 20 | 12 | 2 | 5 | 20 | 25 | 75 | 20 | 0 | 6 | 0 | -12 | 0 | 60 | 60 | 51 | 02 | |
| 2N3972 | TO-18 | 40 | 1 | 0.25* | 20 | 12 | 0.5 | 3 | 20 | 5 | 30 | 20 | 0 | 25 | 20 | 0 | 12 | 80 | 100 | 51 | 02 | |
| •2N4091 | TO-18* | 40 | 1 | 0.2* | 20 | -12 | 5 | 10 | 20 | 30 | 30 | 20 | 0 | 16 | 20 | 0 | 0 | 20 | 25 | 40 | 51 | 02 |
| •2N4092 | TO-18 | 40 | 1 | 0.2* | 20 | -8 | 2 | 7 | 20 | 50 | 15 | 20 | 0 | 16 | 20 | 0 | 0 | 35 | 60 | 51 | 02 | |
| 2N4093 | TO-18 | 40 | 1 | 0.2* | 20 | -6 | 1 | 5 | 20 | 8 | 20 | 20 | 0 | 16 | 20 | 0 | 0 | 60 | 80 | 51 | 02 | |
| 2N4391 | TO-18 | 40 | 1 | 0.1 | 20 | -12 | 4 | 10 | 20 | 50 | 150 | 20 | 0 | 3.5 | 0 | -12 | 0 | 35 | 20 | 51 | 02 | |
| 2N4392 | TO-18 | 40 | 1 | 0.1 | 20 | -7 | 2 | 5 | 20 | 25 | 75 | 20 | 0 | 14 | 20 | 0 | 0 | 20 | 55 | 51 | 02 | |
| 2N4393 | TO-18 | 40 | 1 | 0.1 | 20 | -5 | 0.5 | 3 | 20 | 5 | 30 | 20 | 0 | 14 | 20 | 0 | 0 | 20 | 60 | 51 | 02 | |
| •2N4856 | TO-18 | 40 | 1 | 0.25 | 20 | -10 | 4 | 10 | 15 | 50 | 15 | 20 | 0 | 18 | 0 | -10 | 0 | 8 | 20 | 51 | 02 | |
| 2N4856A | TO-18 | 40 | 1 | 0.25 | 20 | -10 | 4 | 10 | 15 | 5 | 50 | 15 | 0 | 10 | 0 | -10 | 0 | 8 | 20 | 51 | 02 | |
| •2N4857 | TO-18 | 40 | 1 | 0.25 | 20 | -15 | 2 | 6 | 15 | 20 | 100 | 15 | 0 | 18 | 0 | -10 | 0 | 10 | 50 | 51 | 02 | |
| 2N4857A | TO-18 | 40 | 1 | 0.25 | 20 | -15 | 2 | 6 | 15 | 5 | 20 | 100 | 15 | 0 | 0 | -10 | 0 | 10 | 40 | 51 | 02 | |
| •2N4858 | TO-18 | 40 | 1 | 0.25 | 20 | -10 | 0.8 | 4 | 15 | 5 | 8 | 80 | 15 | 18 | 0 | -10 | 0 | 20 | 100 | 51 | 02 | |
| 2N4858A | TO-18 | 40 | 1 | 0.25 | 20 | -10 | 0.8 | 4 | 15 | 5 | 8 | 80 | 15 | 18 | 0 | -10 | 0 | 16 | 80 | 51 | 02 | |
| •2N4859 | TO-18 | 30 | 1 | 0.25 | 15 | 10 | 4 | 10 | 15 | 50 | 15 | 25 | 0 | 8 | 0 | -10 | 0 | 9 | 25 | 51 | 02 | |
| 2N4859A | TO-18 | 30 | 1 | 0.25 | 15 | -10 | 4 | 10 | 15 | 50 | 15 | 25 | 0 | 8 | 0 | -10 | 0 | 8 | 20 | 51 | 02 | |
| •2N4860 | TO-18 | 30 | 1 | 0.25 | 15 | -10 | 2 | 6 | 15 | 5 | 20 | 100 | 15 | 18 | 0 | -10 | 0 | 10 | 50 | 51 | 02 | |
| 2N4860A | TO-18 | 30 | 1 | 0.25 | 15 | -10 | 2 | 6 | 15 | 5 | 20 | 100 | 15 | 18 | 0 | -10 | 0 | 10 | 40 | 51 | 02 | |
| •2N4861 | TO-18 | 30 | 1 | 0.25 | 15 | -10 | 0.8 | 4 | 15 | 5 | 8 | 80 | 15 | 18 | 0 | -10 | 0 | 10 | 100 | 51 | 02 | |
| 2N4861A | TO-18 | 30 | 1 | 0.25 | 15 | -10 | 0.8 | 4 | 15 | 5 | 8 | 80 | 15 | 18 | 0 | -10 | 0 | 10 | 100 | 51 | 02 | |
| •2N4862 | TO-18 | 30 | 1 | 0.25 | 15 | -10 | 0.8 | 4 | 15 | 5 | 8 | 80 | 15 | 18 | 0 | -10 | 0 | 16 | 80 | 51 | 02 | |
| 2N4862A | TO-18 | 30 | 1 | 0.25 | 15 | -10 | 0.8 | 4 | 15 | 5 | 8 | 80 | 15 | 18 | 0 | -10 | 0 | 16 | 80 | 51 | 02 | |
| •2N5432 | TO-52 | 25 | 1 | 0.2 | 15 | 5 | 4 | 10 | 5 | 3 | 150 | 15 | 0 | 30 | 0 | -10 | 5 | 5 | 36 | 58 | 07 | |
| 2N5433 | TO-52 | 25 | 1 | 0.2 | 15 | 5 | 3 | 9 | 5 | 3 | 100 | 15 | 0 | 30 | 0 | -10 | 5 | 5 | 36 | 58 | 07 | |
| •2N5434 | TO-52 | 25 | 1 | 0.2 | 15 | -10 | 1 | 4 | 5 | 3 | 30 | 15 | 0 | 15 | 0 | -10 | 5 | 5 | 36 | 58 | 07 | |
| 2N5555 | TO-92 | 25 | 10 | 1 | 15 | 10 | 12 | 10 | 12 | 150 | 15 | 15 | 0 | 5 | 15 | 0 | -10 | 10 | 25 | 50 | 72 | |

• Note. JAN qualified per applicable MIL-S-19500 specification.



N-Channel FETs

SWITCHES/CHOPPERS (Continued)

| Type No. | Case Style | BV _{GSS} BV _{GOO} (V) @ I _G (μ A) | I _{GSS} I _{DGO} (nA) @ V _{DG} (V) | I _{Dleff} (nA) @ V _{DG} (V) | V _G (V) | V _p @ V _{DG} (V) | I _D (nA) | I _{DSS} (mA) @ V _{DG} (V) | r _{d(ion)} (Ω) @ I _D (mA) | (pF) @ V _{DG} (V) | C _{iss} (pF) @ V _{DG} (V) | V _G (V) | (pF) @ V _{DG} (V) | C _{iss} (pF) @ V _{DG} (V) | V _G (V) | t _{on} (ns) Max | t _{off} (ns) Max | Process No. | Pkg. No. | |
|----------|------------|---|---|---|-----------------------|--|------------------------|--|--|----------------------------------|--|-----------------------|----------------------------------|--|-----------------------|-----------------------------|------------------------------|-------------|----------|----|
| 2N5638 | TO-92 | 30 | 10 | 1 | 15 | -12 | | 50 | 30 | 1 | 10 | 0 | 4 | 0 | -12 | 9 | 15 | 51 | 72 | |
| 2N5639 | TO-92 | 30 | 10 | 1 | 15 | -8 | (8) | 25 | 60 | 1 | 10 | 0 | 4 | 0 | 8 | 14 | 136 | 51 | 72 | |
| 2N5640 | TO-92 | 30 | 10 | 1 | 15 | -6 | (6) | 5 | 100 | 1 | 10 | 0 | 4 | 0 | -6 | 9 | 136 | 51 | 72 | |
| 2N5653 | TO-92 | 30 | 10 | 1 | 15 | 12 | (12) | 40 | 50 | 1 | 10 | 0 | 3.5 | 0 | 12 | 9 | 15 | 51 | 72 | |
| 2N5654 | TO-92 | 25 | 10 | 1 | 15 | 8 | (8) | 15 | 100 | 1 | 10 | 0 | 3.5 | 0 | 8 | 14 | 30 | 51 | 72 | |
| J108 | TO-92 | 25 | 1 | 3 | 15 | 5 | -10 | 80 | 8 | 10 | 130 | 0 | 15 | 0 | -10 | 15 | 136 | 58 | 72 | |
| J109 | TO-92 | 25 | 1 | 3 | 15 | 5 | -10 | 40 | 15 | 12 | 10 | 130 | 0 | 15 | 0 | -10 | 136 | 58 | 72 | |
| J110 | TO-92 | 25 | 1 | 3 | 15 | 5 | -10 | 10 | 18 | 10 | 130 | 0 | 15 | 0 | -10 | 15 | 136 | 58 | 72 | |
| J111 | TO-92 | 35 | 1 | 1 | 15 | 5 | -10 | 3 | 30 | 1 | 110 | 0 | 15 | 0 | -10 | 113 | 135 | 51 | 72 | |
| J112 | TO-92 | 35 | 1 | 1 | 15 | 5 | -10 | 5 | 50 | 1 | 110 | 0 | 15 | 0 | -10 | 113 | 135 | 51 | 72 | |
| J113 | TO-92 | 35 | 1 | 1 | 15 | 5 | -10 | 2 | 100 | 1 | 110 | 0 | 15 | 0 | -10 | 113 | 135 | 51 | 72 | |
| J114 | TO-92 | 25 | 1 | 1 | 15 | 5 | 10 | 3 | 150 | 1 | 14 | 0 | 17 | 0 | 10 | 16 | 120 | 90 | 72 | |
| PN4091 | TO-92 | 40 | 1 | 1 | 20 | -12 | 5 | 10 | 30 | 20 | 16 | 20 | 0 | 5 | 20 | 0 | 25 | 40 | 51 | 72 |
| PN4092 | TO-92 | 40 | 1 | 1 | 20 | -8 | 2 | 7 | 20 | 1 | 16 | 20 | 0 | 5 | 20 | 0 | 35 | 60 | 51 | 72 |
| PN4093 | TO-92 | 40 | 1 | 1 | 20 | -6 | 1 | 5 | 20 | 1 | 16 | 20 | 0 | 5 | 20 | 0 | 60 | 80 | 51 | 72 |
| PN4391 | TO-92 | 40 | 1 | 1 | 20 | -12 | 4 | 10 | 20 | 1 | 14 | 20 | 0 | 3.5 | 0 | -12 | 20 | 35 | 51 | 72 |
| PN4392 | TO-92 | 40 | 1 | 1 | 20 | -7 | 2 | 5 | 20 | 1 | 14 | 20 | 0 | 3.5 | 0 | -7 | 40 | 80 | 51 | 72 |
| PN4393 | TO-92 | 40 | 1 | 1 | 20 | -5 | 0.5 | 3 | 20 | 1 | 14 | 20 | 0 | 3.5 | 0 | -5 | 55 | 130 | 51 | 72 |
| PN4856 | TO-92 | 40 | 1 | 1 | 20 | 1 | 4 | 10 | 15 | 5 | 18 | 0 | 8 | 0 | -10 | 9 | 25 | 51 | 72 | |
| PN4857 | TO-92 | 40 | 1 | 1 | 20 | 1 | 6 | 15 | 5 | 20 | 100 | 15 | 40 | 0 | -10 | 10 | 50 | 51 | 72 | |
| PN4858 | TO-92 | 40 | 1 | 1 | 20 | 1 | 15 | -10 | 4 | 15 | 5 | 80 | 15 | 60 | 0 | -10 | 20 | 100 | 51 | 72 |
| PN4859 | TO-92 | 30 | 1 | 1 | 15 | 10 | 4 | 10 | 15 | 5 | 18 | 0 | 10 | 8 | 0 | 10 | 9 | 25 | 51 | 72 |
| PN4860 | TO-92 | 30 | 1 | 1 | 15 | 10 | 2 | 6 | 15 | 5 | 18 | 0 | 10 | 8 | 0 | 10 | 10 | 50 | 51 | 72 |
| PN4861 | TO-92 | 30 | 1 | 1 | 15 | 10 | 0.8 | 4 | 15 | 5 | 18 | 0 | 10 | 8 | 0 | 10 | 100 | 51 | 72 | |
| T1S73 | TO-92 | 30 | 1 | 2 | 15 | 10 | 4 | 10 | 15 | 4 | 18 | 0 | 10 | 8 | 0 | 10 | 9 | 25 | 51 | 77 |
| T1S74 | TO-92 | 30 | 1 | 2 | 15 | 10 | 2 | 6 | 15 | 4 | 18 | 0 | 10 | 8 | 0 | 10 | 10 | 50 | 51 | 77 |
| T1S75 | TO-92 | 30 | 1 | 2 | 15 | 10 | 0.8 | 4 | 15 | 4 | 18 | 0 | 10 | 8 | 0 | 10 | 100 | 51 | 77 | |
| U1897E | TO-92 | 40 | 1 | 0.2 | 20 | 15 | 5 | 10 | 20 | 1 | 16 | 20 | 0 | 5 | 0 | 20 | 25 | 40 | 51 | 72 |
| U1898E | TO-92 | 40 | 1 | 0.2 | 20 | 15 | 2 | 7 | 20 | 1 | 16 | 20 | 0 | 5 | 0 | 20 | 35 | 60 | 51 | 72 |
| U1899E | TO-92 | 40 | 1 | 0.2 | 20 | 15 | 1 | 5 | 20 | 1 | 16 | 20 | 0 | 5 | 0 | 20 | 60 | 80 | 51 | 72 |



N-Channel FETs

RF, VHF, UHF AMPLIFIERS

| Type No. | Case Style | BV _{GDO} (V) @ I _G (μA) | I _{GSS} (pA) @ V _{DG} (V) | V _p (V) @ V _{DS} (V) | I _D (nA) | I _{DSS} (mA) @ V _{DS} (V) | R _e Y _{fs} (mmho) @ Freq (MHz) | R _e (V _{os}) (μmho) @ f (MHz) | C _{iss} (pF) @ V _{DS} (V) | V _{GSS} (V) | (pF) @ V _{DS} (V) | C _{rss} (pF) @ V _{DS} (V) | V _{GSS} (V) | NF (dB) @ R _g = 1k Freq (MHz) | Process No. | Pkg. No. | | | | | |
|----------|------------|---|---|--|---------------------|---|--|--|---|----------------------|----------------------------|---|----------------------|--|-------------|----------|------|------|-----|----|----|
| 2N3819 | TO-92 | 25 | 1 | 8 | 15 | 2 | 2 | 1.6 | 100 | 8 | 15 | 0 | 4 | 15 | 0 | 50 | 74 | | | | |
| 2N3823 | TO-72 | 30 | 1 | 8 | 15 | 5 | 4 | 3.2 | 200 | 8 | 15 | 0 | 2 | 15 | 0 | 50 | 25 | | | | |
| 2N4223 | TO-72 | 30 | 10 | 0.1 | 8 | 15 | 3 | 2.7 | 200 | 8 | 15 | 0 | 2 | 15 | 0 | 50 | 25 | | | | |
| 2N4224 | TO-72 | 30 | 10 | 0.1 | 8 | 15 | 3 | 1.7 | 200 | 8 | 15 | 0 | 2 | 15 | 0 | 50 | 25 | | | | |
| 2N4416 | TO-72 | 30 | 1 | 6 | 15 | 1 | 5 | 4 | 400 | 100 | 400 | 4 | 0.8 | 15 | 0 | 50 | 25 | | | | |
| *2N4416A | TO-72 | 35 | 1 | 6 | 15 | 1 | 5 | 4 | 400 | 100 | 400 | 4 | 0.8 | 15 | 0 | 50 | 25 | | | | |
| 2N5078 | TO-72 | 30 | 1 | 6 | 15 | 1 | 4 | 200 | 200 | 6 | 15 | 0 | 2 | 15 | 0 | 50 | 25 | | | | |
| 2N5245 | TO-92 | 30 | 1 | 6 | 15 | 10 | 5 | 4 | 400 | 100 | 400 | 4.5 | 15 | 0 | 90 | 77 | | | | | |
| 2N5246 | TO-92 | 30 | 1 | 6 | 15 | 10 | 1.5 | 2.5 | 400 | 100 | 400 | 4.5 | 15 | 0 | 90 | 77 | | | | | |
| 2N5247 | TO-92 | 30 | 1 | 6 | 15 | 10 | 8 | 4 | 400 | 150 | 400 | 4.5 | 15 | 0 | 90 | 77 | | | | | |
| 2N5248 | TO-92 | 30 | 1 | 6 | 15 | 10 | 3 | 200 | 200 | 6 | 15 | 0 | 2 | 15 | 0 | 50 | 74 | | | | |
| 2N5397 | TO-72 | 25 | 1 | 6 | 10 | 1 | 10 | 30 | 10 | 5.5 | 450 | 5 | 10 | 10m | 90 | 29 | | | | | |
| 2N5398 | TO-72 | 25 | 1 | 6 | 10 | 1 | 5 | 40 | 10 | 5.0 | 450 | 5.5 | 10 | 0 | 3.2 | 450 | 90 | | | | |
| 2N5484 | TO-92 | 25 | 1 | 20 | 0.3 | 3 | 15 | 10 | 1 | 5 | 15 | 2.5 | 100 | 7 | 15 | 0 | 50 | 72 | | | |
| 2N5485 | TO-92 | 25 | 1 | 4 | 15 | 10 | 4 | 10 | 15 | 3 | 400 | 5 | 15 | 0 | 1 | 15 | 0 | 50 | 72 | | |
| 2N5486 | TO-92 | 25 | 1 | 20 | 2 | 6 | 15 | 10 | 8 | 20 | 15 | 3.5 | 400 | 5 | 15 | 0 | 4 | 400 | 50 | 72 | |
| 2N5668 | TO-92 | 25 | 10 | 2 | 15 | 10 | 1 | 5 | 15 | 1 | 100 | 7 | 15 | 0 | 3 | 15 | 0 | 50 | 72 | | |
| 2N5669 | TO-92 | 25 | 10 | 2 | 15 | 10 | 4 | 10 | 15 | 1.6 | 100 | 100 | 100 | 7 | 15 | 0 | 3 | 15 | 0 | 50 | 72 |
| 2N5670 | TO-92 | 25 | 10 | 2 | 15 | 10 | 8 | 20 | 15 | 2.5 | 100 | 150 | 100 | 7 | 15 | 0 | 3 | 15 | 0 | 50 | 72 |
| 2N5949 | TO-92 | 30 | 1 | 15 | 3 | 7 | 15 | 100 | 12 | 18 | 15 | 3.0 | 100 | 6 | 15 | 0 | 2 | 15 | 0 | 50 | 77 |
| 2N5950 | TO-92 | 30 | 1 | 15 | 2.5 | 6 | 15 | 100 | 10 | 15 | 15 | 3.0 | 100 | 6 | 15 | 0 | 2 | 15 | 0 | 50 | 77 |
| 2N5951 | TO-92 | 30 | 1 | 15 | 2 | 5 | 15 | 100 | 7 | 13 | 15 | 3.0 | 100 | 6 | 15 | 0 | 2 | 15 | 0 | 50 | 77 |
| 2N5952 | TO-92 | 30 | 1 | 15 | 1.3 | 3.5 | 15 | 100 | 4 | 8 | 15 | 1.0 | 100 | 6 | 15 | 0 | 2 | 15 | 0 | 50 | 77 |
| 2N5953 | TO-92 | 30 | 1 | 15 | 3 | 15 | 100 | 2.5 | 5 | 15 | 10 | 1.0 | 100 | 6 | 15 | 0 | 2 | 15 | 0 | 50 | 77 |
| J300 | TO-92 | 25 | 1 | 6 | 10 | 1 | 6 | 30 | 10 | 4.5 | 001 | 5.5 | 10 | 5m | 90 | 72 | 72 | | | | |
| J304 | TO-92 | 30 | 1 | 6 | 15 | 1 | 5 | 15 | 15 | 14.2 | 400 | 180 | 100 | 13 | 15 | 0 | 14 | 400 | 50 | 72 | |
| J305 | TO-92 | 30 | 1 | 6.5 | 10 | 1 | 1 | 8 | 15 | 13.0 | 400 | 180 | 100 | 13 | 15 | 0 | 14 | 400 | 50 | 72 | |
| J308 | TO-92 | 25 | 1 | 1 | 15 | 1 | 12 | 60 | 10 | 8 | 001 | 200 | 001 | 7.5 | 0 | -10 | 11.5 | 100 | 92 | 72 | |
| J309 | TO-92 | 25 | 1 | 1 | 15 | 1 | 12 | 30 | 10 | 10 | 001 | 200 | 001 | 7.5 | 0 | -10 | 11.5 | 100 | 92 | 72 | |
| J310 | TO-92 | 25 | 1 | 2 | 6.5 | 10 | 1 | 24 | 60 | 10 | 8 | 001 | 200 | 001 | 7.5 | 0 | -10 | 11.5 | 100 | 92 | 72 |

• Note. JAN qualified per applicable MIL-S-19500 specification.



N-Channel FETs

RF, VHF, UHF AMPLIFIERS (Continued)

| Type No. | Case Style | BV _{GSS} BV _{GDO} (V) @ I _G (μ A) | I _{GSS} I _{DGO} (μ A) @ V _{DG} (V) | V _p @ V _{DS} (V) | I _D (mA) | I _{DSS} (mA) | g _{fs} (mMho) @ V _{DS} (V) | R _o Y _{fs} (mMho) @ Freq (MHz) | R _e (V _{os}) (Ω /Mho) @ f (MHz) | C _{iss} (pF) @ V _{DS} (V) | V _{GS} (V) | C _{iss} (pF) @ V _{DS} (V) | V _{GS} (V) | V _{GS} (V) | NF (dB) @ R _g = 1k F _{in} Freq (MHz) | Process No. | Pkg. No. | | | | |
|----------|------------|--|---|--|------------------------|--------------------------|--|--|--|---|------------------------|---|------------------------|------------------------|---|-------------|----------|------|-----|----|----|
| MPF102 | TO-92 | 25 | 1 | 15 | 2 | 2 | 20 | 15 | 100 | 200 | 0 | 7 | 15 | 0 | 3 | 15 | 0 | 50 | 72 | | |
| MPF106 | TO-92 | 25 | 1 | 20 | 5 | 4 | 10 | 15 | 2.5 | 0.001 | 0 | 5 | 15 | 0 | 2 | 15 | 0 | 4 | 400 | 50 | 72 |
| MPF107 | TO-92 | 25 | 1 | 20 | 5 | 8 | 20 | 15 | 4 | 0.001 | 0 | 5 | 15 | 0 | 2 | 15 | 0 | 4 | 400 | 50 | 72 |
| MPF108 | TO-92 | 25 | 10 | 15 | 10 | 1.5 | 24 | 15 | 1.6 | 100 | 0 | 6.5 | 15 | 0 | 2.5 | 15 | 0 | 3 | 100 | 50 | 72 |
| PN4223 | TO-92 | 30 | 1 | 20 | 1 | 3 | 18 | 15 | 2.7 | 200 | 0 | 6 | 15 | 0 | 2 | 15 | 0 | 5 | 200 | 50 | 72 |
| PN4224 | TO-92 | 30 | 1 | 20 | 1 | 5 | 2 | 70 | 1.7 | 200 | 0 | 6 | 15 | 0 | 2 | 15 | 0 | 5 | 200 | 50 | 72 |
| PN4416 | TO-92 | 30 | 1 | 20 | 1 | 5 | 15 | 15 | 4 | 400 | 0 | 4 | 15 | 0 | 0.8 | 15 | 0 | 4 | 400 | 50 | 72 |
| U308 | TO-52 | 25 | 1 | 15 | 1 | 6 | 10 | 10 | 10 | 0.001 | 0 | 5 | 0 | 10m | 2.5 | 0 | 10mA | 13 | 450 | 92 | 07 |
| U309 | TO-52 | 25 | 1 | 15 | 1 | 4 | 10 | 10 | 10 | 0.001 | 0 | 5 | 0 | 10m | 2.5 | 0 | 10mA | 13 | 450 | 92 | 07 |
| U310 | TO-52 | 25 | 1 | 15 | 1 | 2.5 | 6 | 10 | 10 | 0.001 | 0 | 5 | 10 | 10m | 2.5 | 10 | 10mA | 13 | 450 | 92 | 07 |
| U312 | TO-52 | 25 | 1 | 15 | 1 | 6 | 10 | 10 | 6 | 0.001 | 0 | 3.8 | 10 | 10m | 1.2 | 10 | 10mA | 13.5 | 450 | 90 | 07 |
| U320 | TO-39 | 20 | 1 | 3 | 15 | 2 | 10 | 5 | 1m | 100 | 500 | 30 | 0 | 10 | 15 | 0 | 10 | 12.5 | 30 | 58 | 09 |
| U321 | TO-39 | 25 | 1 | 3 | 15 | 1 | 4 | 5 | 1m | 80 | 250 | 15 | 75 | 0 | 30 | 0 | 10 | 12.5 | 30 | 58 | 09 |
| U322 | TO-39 | 25 | 1 | 3 | 15 | 3 | 10 | 5 | 1m | 200 | 700 | 15 | 75 | 0 | 30 | 0 | 10 | 12.5 | 30 | 58 | 09 |



N-Channel FETs

LOW FREQUENCY—LOW NOISE AMPLIFIERS

| Type No. | Case Style | BV _{GSS} (V) @ I _G (μ A) | I _{GSS} (mA) @ V _{DG} (V) | V _{GS(OFF)} (V) @ V _{DS} (V) | I _D (mA) | I _{DSS} (mA) | g _{fs} (Re Y _{fs}) (mMho) @ V _{DS} (V) | f (MHz) | G _{oss} (μ mho) @ V _{DS} (V) | C _{iss} (pF) @ V _{DS} (V) | V _{GS} (V) | C _{iss} (pF) @ V _{DS} (V) | V _{GS} (V) | C _{iss} (pF) @ V _{DS} (V) | nV _{rms} @ f (Hz) | Process No. | Pkg No. | | | | | | | | | | | | | |
|----------|------------|---|---|--|------------------------|--------------------------|--|------------|---|---|------------------------|---|------------------------|---|-------------------------------|-------------|---------|-----|-----|---------|---------|-----|----|----|----|----|----|----|----|----|
| 2N4393 | TO-18 | 40 | 1.0 | 0.1 | 20 | 0.5 | 3.0 | 20 | 1.0 | 5.0 | 30 | 20 | 112 | 20 | 0.001 | 0 | 14 | 20 | 0 | 3.5 | 5.0(GS) | 0 | 10 | 51 | 02 | | | | | |
| 2N5556 | TO-72 | 30 | 10 | 0.1 | 15 | 0.2 | 4.0 | 15 | 1.0 | 0.5 | 2.5 | 15 | 1.5 | 6.5 | 15 | 0.001 | 20 | 15 | 6.0 | 15 | 0 | 3.0 | 15 | 0 | 35 | 10 | 50 | 25 | | |
| 2N5557 | TO-72 | 30 | 10 | 0.1 | 15 | 0.8 | 5.0 | 15 | 1.0 | 2.0 | 5.0 | 15 | 1.5 | 6.5 | 15 | 0.001 | 20 | 15 | 6.0 | 15 | 0 | 3.0 | 15 | 0 | 35 | 10 | 50 | 25 | | |
| 2N5558 | TO-72 | 30 | 10 | 0.1 | 15 | 1.5 | 6.0 | 15 | 1.0 | 4.0 | 10 | 15 | 1.5 | 6.5 | 15 | 0.001 | 20 | 15 | 6.0 | 15 | 0 | 3.0 | 15 | 0 | 35 | 10 | 50 | 25 | | |
| NF5101 | TO-72 | 40 | 1 | 0.2 | 15 | 0.5 | 1.1 | 15 | 1.0 | 1.0 | 12 | 15 | 3.5 | 15 | 0.001 | 25 | 15 | 112 | 15 | 0 | 14 | 15 | 0 | 14 | 15 | 1k | 51 | 25 | | |
| NF5102 | TO-72 | 40 | 1 | 0.2 | 15 | 0.7 | 1.6 | 15 | 1.0 | 4.0 | 20 | 15 | 7.5 | 15 | 0.001 | 25 | 15 | 112 | 15 | 0 | 14 | 15 | 0 | 14 | 15 | 1k | 51 | 25 | | |
| NF5103 | TO-72 | 40 | 1 | 0.2 | 15 | 1.2 | 2.7 | 15 | 1.0 | 1.0 | 10 | 40 | 15 | 7.5 | 15 | 0.001 | 25 | 15 | 112 | 15 | 0 | 14 | 15 | 0 | 14 | 15 | 1k | 51 | 25 | |
| PF5101 | TO-92 | 40 | 1 | 0.2 | 15 | 0.7 | 1.6 | 15 | 1.0 | 4.0 | 20 | 15 | 7.5 | 15 | 0.001 | 25 | 15 | 112 | 15 | 0 | 14 | 15 | 0 | 14 | 15 | 1k | 51 | 72 | 25 | |
| PF5102 | TO-92 | 40 | 1 | 0.2 | 15 | 1.2 | 2.7 | 15 | 1.0 | 10 | 40 | 15 | 7.5 | 15 | 0.001 | 25 | 15 | 112 | 15 | 0 | 14 | 15 | 0 | 14 | 15 | 1k | 51 | 72 | 25 | |
| PF5103 | TO-92 | 40 | 1 | 0.2 | 15 | 1.2 | 2.7 | 15 | 1.0 | 10 | 40 | 15 | 7.5 | 15 | 0.001 | 25 | 15 | 112 | 15 | 0 | 14 | 15 | 0 | 14 | 15 | 1k | 51 | 72 | 25 | |
| PN4393 | TO-106 | 40 | 1.0 | 0.1 | 20 | 0.5 | 3.0 | 20 | 1.0 | 5.0 | 30 | 20 | 112 | 20 | 0.001 | 14 | 20 | 0 | 3.5 | 5.0(GS) | 0 | 14 | 20 | 0 | 14 | 20 | 10 | 51 | 72 | 25 |





N-Channel FETs

ULTRA LOW INPUT CURRENT AMPS

| Transistor Type | Case Style | BV _{GSS} BV _{GDO} (V) @ I _G (μ A) Min | | I _{GSS} I _{DGO} (μ A) @ V _{DG} (V) Mhx | | V _p @ V _{DG} (V) Min Max | | I _{DSS} @ V _{DS} (μ A) Min Max | | G _{fs} (μ mho) @ V _{DS} (V) Min Max | | G _{oss} (μ mho) @ V _{DS} (V) Max | | C _{iss} (pF) @ V _{DS} (V) Max | | V _{GS} (V) | | C _{rss} (pF) @ V _{DS} (V) Max | | V _{GS} (V) | | e _h ($\frac{nV}{\sqrt{Hz}}$) @ f (Hz) Max | | Process No. | Pkg. No. |
|-----------------|------------|--|-----|---|-----|--|-----|---|-----|--|-----|---|-----|---|-----|------------------------|-----|---|-----|------------------------|-----|--|----|-------------|----------|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | |
| 2N4117 | TO-72 | 40 | 1 | 10 | 20 | 0.5 | 1.8 | 10 | 1 | 30 | 90 | 10 | 3 | 10 | 3 | 10 | 0 | 1.5 | 10 | 0 | 0 | 0 | 0 | 53 | 25 |
| 2N4117A | TO-72 | 40 | 1 | 1 | 20 | 0.6 | 1.8 | 10 | 1 | 30 | 90 | 10 | 3 | 10 | 3 | 10 | 0 | 1.5 | 10 | 0 | 0 | 0 | 53 | 25 | |
| 2N4118 | TO-72 | 40 | 1 | 10 | 20 | 1 | 3 | 10 | 1 | 80 | 240 | 10 | 5 | 10 | 3 | 10 | 0 | 1.5 | 10 | 0 | 0 | 0 | 53 | 25 | |
| 2N4118A | TO-72 | 40 | 1 | 1 | 20 | 1 | 3 | 10 | 1 | 80 | 240 | 10 | 5 | 10 | 3 | 10 | 0 | 1.5 | 10 | 0 | 0 | 0 | 53 | 25 | |
| 2N4119 | TO-72 | 40 | 1 | 10 | 20 | 2 | 6 | 10 | 1 | 200 | 600 | 10 | 10 | 10 | 3 | 10 | 0 | 1.5 | 10 | 0 | 0 | 0 | 53 | 25 | |
| 2N4119A | TO-72 | 40 | 1 | 1 | 20 | 2 | 6 | 10 | 1 | 200 | 600 | 10 | 10 | 10 | 3 | 10 | 0 | 1.5 | 10 | 0 | 0 | 0 | 53 | 25 | |



N-Channel FETs

GENERAL PURPOSE AMPS

| Transistor Type | Case Style | BV _{GSS} *BV _{GDO} (V) @ I _G (μ A) Min | | I _{GSS} I _{DGO} (μ A) @ V _{DG} (V) Max | | V _p @ V _{DG} (V) Min Max | | I _{DSS} @ V _{DS} (mA) Min Max | | G _{fs} (mmho) @ V _{DS} (V) Min Max | | G _{oss} (μ mho) @ V _{DS} (V) Max | | C _{iss} (pF) @ V _{DS} (V) Max | | V _{GS} (V) | | C _{rss} (pF) @ V _{DS} (V) Max | | V _{GS} (V) | | e _h ($\frac{nV}{\sqrt{Hz}}$) @ Freq (Hz) Max | | Process No. | Pkg. No. |
|-----------------|------------|---|-----|---|-----|--|-----|---|-----|--|-----|---|-----|---|-----|------------------------|-----|---|-----|------------------------|-----|---|-----|-------------|----------|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | |
| 2N3069 | TO-18 | *50 | 1 | 1 | 30 | 9.5 | 30 | 1000 | 2 | 10 | 30 | 80 | 30 | 15 | 0 | -12 | 1.5 | 30 | 0 | 0 | 0 | 0 | 52 | 02 | |
| 2N3070 | TO-18 | *50 | 1 | 1 | 30 | 4.5 | 30 | 1000 | 0.5 | 2.5 | 30 | 30 | 30 | 15 | 0 | -8 | 1.5 | 30 | 0 | 0 | 0 | 0 | 52 | 02 | |
| 2N3368 | TO-18 | *40 | 1 | 5 | 30 | 11.5 | 20 | 1000 | 2 | 12 | 30 | 1 | 4 | 30 | 80 | 30 | 0 | 3 | 30 | 0 | 0 | 0 | 52 | 02 | |
| 2N3369 | TO-18 | *40 | 1 | 5 | 30 | 6.5 | 20 | 1000 | 0.5 | 2.5 | 30 | 30 | 30 | 20 | 8 | 0 | 3 | 30 | 0 | 0 | 0 | 0 | 52 | 02 | |
| 2N3370 | TO-18 | *40 | 1 | 5 | 30 | 3.2 | 20 | 1000 | 0.1 | 0.6 | 30 | 0.3 | 2.5 | 30 | 15 | 30 | 20 | 8 | 0 | 0 | 0 | 0 | 52 | 02 | |
| 2N3436 | TO-18 | *50 | 1 | 0.5 | 30 | 9.8 | 20 | 1000 | 3 | 15 | 20 | 2.5 | 10 | 20 | 35 | 30 | 0 | 6 | 30 | 0 | -10 | 0 | 100 | 1000 | |
| 2N3437 | TO-18 | *50 | 1 | 0.5 | 30 | 4.8 | 20 | 1000 | 0.8 | 4 | 20 | 1.5 | 6 | 20 | 20 | 30 | 18 | 0 | 6 | 30 | 0 | 0 | 100 | 1000 | |
| 2N3438 | TO-18 | *50 | 1 | 0.5 | 30 | 2.3 | 20 | 1000 | 0.2 | 1 | 20 | 0.8 | 4.5 | 20 | 5 | 30 | 18 | 0 | 6 | 30 | 0 | -4 | 0 | 100 | 1000 |
| 2N3468 | TO-18 | *50 | 1 | 0.25 | 30 | 7.8 | 20 | 1000 | 3 | 15 | 20 | 2.5 | 10 | 20 | 35 | 30 | 18 | 0 | 5 | 30 | 0 | -10 | 0 | 225 | 20 |
| 2N3469 | TO-18 | *50 | 1 | 0.25 | 30 | 3.4 | 20 | 1000 | 0.8 | 4 | 20 | 1.5 | 6 | 20 | 20 | 30 | 18 | 0 | 5 | 30 | 0 | -6 | 0 | 155 | 20 |
| 2N3460 | TO-18 | *50 | 1 | 0.25 | 30 | 1.8 | 20 | 1000 | 0.2 | 1 | 20 | 0.8 | 4.5 | 20 | 5 | 30 | 18 | 0 | 5 | 30 | 0 | -4 | 0 | 155 | 20 |
| 2N3684 | TO-72 | 50 | 1 | 0.1 | 30 | 2 | 5 | 20 | 1 | 2.5 | 7.5 | 2 | 3 | 20 | 50 | 20 | 4 | 20 | 0 | 1.2 | 20 | 0 | 150 | 100 | |
| 2N3685 | TO-72 | 50 | 1 | 0.1 | 30 | 1 | 3.5 | 20 | 1 | 3 | 20 | 1.5 | 2.5 | 20 | 25 | 20 | 4 | 20 | 0 | 1.2 | 20 | 0 | 150 | 100 | |
| 2N3686 | TO-72 | 50 | 1 | 0.1 | 30 | 0.6 | 2 | 20 | 1 | 0.4 | 1.2 | 1 | 2 | 20 | 10 | 20 | 4 | 20 | 0 | 1.2 | 20 | 0 | 150 | 100 | |
| 2N3687 | TO-72 | 50 | 1 | 0.1 | 30 | 0.3 | 1.2 | 20 | 0.1 | 0.5 | 20 | 0.5 | 1.5 | 20 | 5 | 20 | 4 | 20 | 0 | 1.2 | 20 | 0 | 150 | 100 | |
| 2N3821 | TO-72 | 50 | 1 | 0.1 | 30 | 4 | 15 | 5 | 0.5 | 2.5 | 15 | 1.5 | 4.5 | 15 | 10 | 15 | 6 | 15 | 0 | 3 | 15 | 0 | 200 | 10 | |
| 2N3822 | TO-72 | 50 | 1 | 0.1 | 30 | 6 | 15 | 5 | 2 | 10 | 15 | 3 | 6.5 | 15 | 20 | 15 | 6 | 15 | 0 | 3 | 15 | 0 | 200 | 10 | |
| 2N3967 | TO-72 | 30 | 1 | 0.1 | 20 | 2 | 5 | 20 | 1 | 2.5 | 10 | 20 | 2.5 | 20 | 35 | 20 | 5 | 20 | 0 | 1.3 | 20 | 0 | 84 | 100 | |
| 2N3967A | TO-72 | 30 | 1 | 0.1 | 20 | 2 | 5 | 20 | 1 | 2.5 | 10 | 20 | 2.5 | 20 | 35 | 20 | 5 | 20 | 0 | 1.3 | 20 | 0 | 160 | 10 | |
| 2N3968 | TO-72 | 30 | 1 | 0.1 | 20 | 3 | 20 | 1 | 1 | 5 | 20 | 2 | 15 | 20 | 15 | 20 | 5 | 20 | 0 | 1.3 | 20 | 0 | 84 | 100 | |
| 2N3968A | TO-72 | 30 | 1 | 0.1 | 20 | 3 | 20 | 1 | 1 | 5 | 20 | 2 | 15 | 20 | 15 | 20 | 5 | 20 | 0 | 1.3 | 20 | 0 | 160 | 10 | |
| 2N3969 | TO-72 | 30 | 1 | 0.1 | 20 | 1.7 | 20 | 1 | 0.4 | 2 | 20 | 1.3 | 20 | 5 | 20 | 11 | 1.3 | 20 | 0 | 1.3 | 20 | 0 | 84 | 100 | |
| 2N3969A | TO-72 | 30 | 1 | 0.1 | 20 | 1.7 | 20 | 1 | 0.4 | 2 | 20 | 1.3 | 20 | 5 | 20 | 11 | 1.3 | 20 | 0 | 1.3 | 20 | 0 | 160 | 10 | |

• I_D = 1 mA † I_D = 500 μ A †† I_D = 100 μ A ** I_D = 100 μ A †† I_D = 40 μ A

N-Channel FETs

GENERAL PURPOSE AMPS (Continued)

| Transistor Type | Case Style | BV _{GSS} (V) @ I _G (μA) Min | I _{DGO} (mA) @ V _{DG} (V) Max | V _n @ V _{DS} (V) Min Max | I _D (mA) | I _{DSS} @ V _{DS} (mA) Min Max | G _{FS} (mmho) @ V _{DS} Min Max | G _{oss} (μmho) @ V _{DS} Max | C _{iss} (pF) @ V _{DS} (V) Max | V _{GS} (V) | (pF) @ V _{DS} Max | C _{rss} (pF) @ V _{DS} (V) Max | V _{GS} (V) | $\frac{e_n}{\sqrt{Hz}}$ @ Freq Max (NV) | Process No. | Pkg. No. | | | | | | | | | | | |
|-----------------|------------|---|---|--|---------------------|---|--|---|---|---------------------|----------------------------|---|---------------------|---|-------------|----------|------|----|----|-----|------|------|----|-----|----|----|----|
| 2N4220 | TO-72 | 30 | 0.1 | 15 | 1 | 0.5 | 3 | 15 | 1 | 4 | 15 | 10 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | | |
| 2N4220A | TO-72 | 30 | 0.1 | 15 | 1 | 0.5 | 3 | 15 | 1 | 4 | 15 | 10 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | | |
| 2N4221 | TO-72 | 30 | 0.1 | 15 | 1 | 2 | 6 | 15 | 2 | 5 | 15 | 20 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | | |
| 2N4221A | TO-72 | 30 | 0.1 | 15 | 1 | 2 | 6 | 15 | 2 | 5 | 15 | 20 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | | |
| 2N4222 | TO-72 | 30 | 0.1 | 15 | 1 | 5 | 15 | 15 | 5 | 15 | 15 | 40 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | | |
| 2N4222A | TO-72 | 30 | 0.1 | 15 | 1 | 5 | 15 | 15 | 5 | 15 | 15 | 40 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | | |
| 2N4338 | TO-18 | 50 | 1 | 0.1 | 30 | 0.2 | 0.6 | 15 | 0.6 | 1.8 | 15 | 5 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 68 | 1000 | 52 | 02 | | | | |
| 2N4339 | TO-18 | 50 | 1 | 0.1 | 30 | 0.5 | 1.5 | 15 | 0.8 | 2.4 | 15 | 15 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 68 | 1000 | 52 | 02 | | | | |
| 2N4340 | TO-18 | 50 | 1 | 0.1 | 30 | 1 | 3 | 15 | 1.3 | 3 | 15 | 30 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 68 | 1000 | 52 | 02 | | | | |
| 2N4341 | TO-18 | 50 | 1 | 0.1 | 30 | 2 | 6 | 15 | 2 | 4 | 15 | 60 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 68 | 1000 | 55 | 02 | | | | |
| 2N5103 | TO-72 | 25 | 10 | 0.1 | 15 | 0.5 | 4 | 15 | 1 | 8 | 15 | 100 | 15 | 5 | 15 | 0 | 1 | 15 | 0 | 100 | 10 | 50 | 25 | | | | |
| 2N5104 | TO-72 | 25 | 10 | 0.1 | 15 | 0.5 | 4 | 15 | 1 | 2 | 6 | 15 | 100 | 15 | 5 | 15 | 0 | 1 | 15 | 0 | 50 | 10 | 50 | 25 | | | |
| 2N5105 | TO-72 | 25 | 10 | 0.1 | 15 | 0.5 | 4 | 15 | 1 | 5 | 15 | 100 | 15 | 5 | 15 | 0 | 1 | 15 | 0 | 50 | 10 | 50 | 25 | | | | |
| 2N5358 | TO-72 | 40 | 1 | 0.1 | 20 | 0.5 | 3 | 15 | 100 | 0.5 | 1 | 15 | 10 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | |
| 2N5359 | TO-72 | 40 | 1 | 0.1 | 20 | 0.8 | 4 | 15 | 100 | 0.6 | 1.6 | 15 | 10 | 15 | 6 | 15 | 0 | 2 | 15 | 0 | 115 | 100 | 55 | 25 | | | |
| 2N5360 | TO-72 | 40 | 1 | 0.1 | 20 | 0.8 | 4 | 15 | 100 | 0.5 | 2.5 | 15 | 1.4 | 4.2 | 15 | 20 | 15 | 6 | 15 | 0 | 115 | 100 | 55 | 25 | | | |
| 2N5361 | TO-72 | 40 | 1 | 0.1 | 20 | 1 | 6 | 15 | 100 | 2.5 | 5 | 15 | 1.5 | 4.5 | 15 | 20 | 15 | 6 | 15 | 0 | 115 | 100 | 55 | 25 | | | |
| 2N5362 | TO-72 | 40 | 1 | 0.1 | 20 | 2 | 7 | 15 | 100 | 4 | 8 | 15 | 2 | 5.5 | 15 | 40 | 15 | 6 | 15 | 0 | 115 | 100 | 55 | 25 | | | |
| 2N5363 | TO-72 | 40 | 1 | 0.1 | 20 | 2.5 | 8 | 15 | 100 | 7 | 14 | 15 | 2.5 | 6 | 15 | 40 | 15 | 6 | 15 | 0 | 115 | 100 | 55 | 25 | | | |
| 2N5364 | TO-72 | 40 | 1 | 0.1 | 20 | 2.5 | 8 | 15 | 100 | 9 | 18 | 15 | 2.7 | 6.5 | 15 | 60 | 15 | 6 | 15 | 0 | 115 | 100 | 55 | 25 | | | |
| 2N5457 | TO-92 | 25 | 1 | 1 | 15 | 0.5 | 6 | 15 | 10 | 1 | 5 | 15 | 2 | 5 | 15 | 50 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 55 | 72 | | |
| 2N5458 | TO-92 | 25 | 1 | 1 | 15 | 1 | 7 | 15 | 10 | 2 | 9 | 15 | 1.5 | 5.5 | 15 | 50 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 55 | 72 | | |
| 2N5459 | TO-92 | 25 | 1 | 1 | 15 | 1 | 7 | 15 | 10 | 4 | 16 | 15 | 2 | 6 | 15 | 50 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 55 | 72 | | |
| 2N5556 | TO-72 | 30 | 1 | 0.1 | 15 | 0.2 | 4 | 15 | 1 | 0.5 | 2.5 | 15 | 1.5 | 6.5 | 15 | 20 | 15 | 6 | 15 | 0 | 3 | 15 | 0 | 35 | 10 | 50 | 25 |
| 2N5557 | TO-72 | 30 | 1 | 0.1 | 15 | 0.8 | 5 | 15 | 1 | 2.0 | 5.0 | 15 | 1.5 | 6.5 | 15 | 20 | 15 | 6 | 15 | 0 | 3 | 15 | 0 | 35 | 10 | 50 | 25 |
| 2N5558 | TO-72 | 30 | 1 | 0.1 | 15 | 1.5 | 6 | 15 | 1 | 4 | 10 | 15 | 1.5 | 6.5 | 15 | 20 | 15 | 6 | 15 | 0 | 3 | 15 | 0 | 35 | 10 | 50 | 25 |
| J201 | TO-92 | 40 | 1 | 0.1 | 20 | 0.3 | 1.5 | 20 | 10 | 0.2 | 1.0 | 20 | 0.5 | 2.0 | 20 | 11 | 20 | 5 | 20 | 0 | 12 | 20 | 0 | 110 | 1k | 52 | 72 |
| J202 | TO-92 | 40 | 1 | 0.1 | 20 | 0.8 | 4.0 | 20 | 10 | 0.9 | 4.5 | 20 | 1.0 | 2.0 | 20 | 13.5 | 20 | 15 | 20 | 0 | 12 | 20 | 0 | 110 | 1k | 52 | 72 |
| J203 | TO-92 | 40 | 1 | 0.1 | 20 | 2.0 | 10.0 | 20 | 10 | 4.0 | 20 | 110 | 20 | 15 | 20 | 0 | 12 | 20 | 0 | 110 | 1k | 52 | 72 | 90 | 72 | | |
| J210 | TO-92 | 25 | 1 | 0.1 | 15 | 1 | 3 | 15 | 1 | 2 | 15 | 150 | 15 | 15 | 15 | 0 | 11.5 | 15 | 0 | 110 | 1k | 90 | 72 | 90 | 72 | | |
| J211 | TO-92 | 25 | 1 | 0.1 | 15 | 2.5 | 4.5 | 15 | 1 | 7 | 20 | 15 | 7.0 | 12.0 | 15 | 200 | 15 | 15 | 0 | 110 | 1k | 90 | 72 | 90 | 72 | | |
| J212 | TO-92 | 25 | 1 | 0.1 | 15 | 4 | 6 | 15 | 1 | 15 | 40 | 15 | 7.0 | 12.0 | 15 | 200 | 15 | 15 | 0 | 110 | 1k | 90 | 72 | 90 | 72 | | |
| MPF 103 | TO-92 | 25 | 1 | 1 | 15 | 6 | 15 | 1 | 1 | 5 | 15 | 50 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 115 | 1000 | 55 | 72 | 55 | 72 | | |
| MPF 104 | TO-92 | 25 | 1 | 1 | 15 | 7 | 15 | 1 | 2 | 9 | 15 | 50 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 115 | 1000 | 55 | 72 | 55 | 72 | | |
| MPF 105 | TO-92 | 25 | 1 | 1 | 15 | 8 | 15 | 1 | 4 | 16 | 15 | 50 | 15 | 7 | 15 | 0 | 3 | 15 | 0 | 115 | 1000 | 55 | 72 | 55 | 72 | | |
| MPF 109 | TO-92 | 25 | 10 | 1 | 15 | 0.2 | 8 | 15 | 10 | 0.5 | 24 | 15 | 0.8 | 6 | 15 | 75 | 15 | 7 | 15 | 0 | 115 | 1000 | 55 | 72 | 55 | 72 | |

JFET Selection Guide

8-7

N-Channel FETs

GENERAL PURPOSE AMPS (Continued)

| Transistor Type | Case Style | BV _{GSS} BV _{GDD} (V) @ I _G (μ A) | I _{GSS} I _{DGO} (μ A) @ V _{DG} (V) | V _p @ V _{DS} (V) Min Max | I _D (mA) | I _{DSS} @ V _{DS} (mA) Min Max | G _{fs} (mmho) Min Max | G _{fs} @ V _{DS} (μ mho) Min Max | G _{oss} (μ mho) @ V _{DS} Max | C _{iss} (pF) @ V _{DS} Max | V _{GS} (V) | V _{GS} (μ F) @ V _{DS} Max | C _{rss} V _{DS} (V) | V _{GS} (V) | $\left(\frac{NV}{Hz}\right) @$ Freq Max (Hz) | Process No. | Pkg. No. | |
|-----------------|------------|--|---|--|------------------------|---|-----------------------------------|--|---|---|------------------------|--|--|------------------------|---|-------------|----------|------|
| MPF 111 | TO-92 | 20 | 10 | 100 | 10 | 1000 | 0.5 | 20 | 10 | 200 | 10 | | | | | 50 | 72 | |
| MPF 112 | TO-92 | 25 | 10 | 100 | 10 | 1000 | 0.5 | 10 | 10 | | | | | | | 55 | 72 | |
| PN3684 | TO-92 | 50 | 1 | 30 | 2 | 5 | 2.5 | 7.5 | 20 | 1 | 25 | 10 | 1 | 7.5 | 10 | 52 | 72 | |
| PN3685 | TO-92 | 50 | 1 | 30 | 1 | 3.5 | 1 | 3 | 20 | 1.5 | 2.5 | 20 | 4 | 20 | 0 | 150 | 20 | |
| PN3686 | TO-92 | 50 | 1 | 30 | 0.6 | 2 | 0.4 | 1.2 | 20 | 2 | 20 | 0 | 4 | 20 | 0 | 150 | 20 | |
| PN3687 | TO-92 | 50 | 1 | 30 | 0.3 | 1.2 | 0.1 | 0.5 | 20 | 0.5 | 1.5 | 20 | 4 | 20 | 0 | 150 | 20 | |
| PN4220 | TO-92 | 30 | 10 | 1 | 15 | 4 | 0.5 | 3 | 15 | 1 | 4 | 15 | 10 | 15 | 6 | 15 | 0 | |
| PN4221 | TO-92 | 30 | 10 | 1 | 15 | 1 | 2 | 6 | 15 | 2 | 5 | 15 | 6 | 15 | 6 | 15 | 0 | |
| PN4222 | TO-92 | 30 | 10 | 1 | 15 | 1 | 5 | 15 | 15 | 2.5 | 6 | 15 | 6 | 15 | 6 | 15 | 0 | |
| PN4302 | TO-92 | 30 | 1 | 10 | 4 | 20 | 10 | 0.5 | 5 | 20 | 1 | 20 | 50 | 20 | 6 | 20 | 0 | |
| PN4303 | TO-92 | 30 | 1 | 10 | 6 | 20 | 10 | 4 | 10 | 20 | 2 | 20 | 50 | 20 | 6 | 20 | 0 | |
| PN4304 | TO-92 | 30 | 1 | 10 | 10 | 20 | 10 | 0.5 | 15 | 20 | 1 | 20 | 50 | 20 | 6 | 20 | 0 | |
| PN6163 | TO-92 | 25 | 1 | 10 | 0.4 | 8 | 15 | 1000 | 1 | 40 | 15 | 2 | 9 | 15 | 200 | 15 | 0 | |
| T1S58 | TO-92 | 25 | 1 | 4 | 0.5 | 5 | 15 | 20 | 2.5 | 8 | 15 | 1.3 | 4 | 15 | 15 | 0 | 3 | |
| T1S59 | TO-92 | 25 | 1 | 4 | 1 | 9 | 15 | 20 | 6 | 25 | 15 | 1.3 | 4 | 15 | 6 | 15 | 2 mA | |
| | | | | | | | | | | | | | | | | 6 | 15 | 2 mA |

N-Channel FETs

GENERAL PURPOSE DUAL JFETs

| Type No. | Case Style | OPERATING CONDITIONS FOR THESE CHARACTERISTICS | | | | | | | | | | OP. CHAR. | | V _{GS1,2} DRIFT | | I _G (μ A) | G _{fs} (μ mho) | G _{oss} (μ mho) | CMRR | V _{GS} (V) | V _{GS} Min Max | V _p (V) | I _{DSS} (mA) | G _{fs} (mmho) | G _{oss} (μ mho) | I _{GSS} (μ A) @ V _{DG} Max (V) | C _{iss} (pF) @ V _{DS} Max | C _{iss} (pF) @ V _{DS} Max | BV (V) | V _{GS} (mV/ \sqrt{Hz}) @ f Max (Hz) | I _{DSS} Match % | G _{oss1,2} (μ mho) 125 C | I _{G1,IG2} (nA) | Process No. | Pkg. No. |
|----------|------------|--|------------------------|-------------------------|---------------------------------|------|------|-----|-----|-----|-----|-----------|-----|--------------------------|-----|------------------------------|---------------------------------|----------------------------------|------|------------------------|----------------------------|-----------------------|--------------------------|---------------------------|----------------------------------|---|---|---|-----------|---|-----------------------------|---|-----------------------------|-------------|----------|
| | | V _{DS} (V) | I _D (mA) | V _{GS} (mV) | Δ V _{GS} Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | | | | | | | | | | | | | | | | | | | |
| 2N3921 | TO-71 | 10 | 700 | 5.0 | 10 | 250 | 1500 | 20 | 20 | 20 | 3.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 72 | | | | | | |
| 2N3922 | TO-71 | 10 | 700 | 5.0 | 25 | 1500 | 1500 | 20 | 20 | 20 | 3.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 12 | | | | | | |
| 2N3934 | TO-71 | 10 | 200 | 5.0 | 10 | 100 | 300 | 5.0 | 5.0 | 5.0 | 1.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 12 | | | | | | |
| 2N3935 | TO-71 | 10 | 200 | 5.0 | 25 | 100 | 300 | 5.0 | 5.0 | 5.0 | 1.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 12 | | | | | | |
| 2N3954 | TO-71 | 20 | 200 | 5.0 | 5.0 | 50 | 50 | 0.5 | 4.0 | 1.0 | 4.5 | 0.5 | 5.0 | 1.0 | 3.0 | 35 | 100 | 30 | 4.0 | 1.2 | 50 | 150 | 100 | 5.0 | 3.0 | 10 | 10 | 83 | 12 | | | | | | |
| 2N3955A | TO-71 | 20 | 200 | 5.0 | 10 | 50 | 50 | 0.5 | 4.0 | 1.0 | 4.5 | 0.5 | 5.0 | 1.0 | 3.0 | 35 | 100 | 30 | 4.0 | 1.2 | 50 | 150 | 100 | 5.0 | 3.0 | 10 | 10 | 83 | 12 | | | | | | |
| 2N3956 | TO-71 | 20 | 200 | 10 | 25 | 50 | 50 | 0.6 | 4.0 | 1.0 | 4.5 | 0.5 | 5.0 | 1.0 | 3.0 | 35 | 100 | 30 | 4.0 | 1.2 | 50 | 150 | 100 | 5.0 | 3.0 | 10 | 10 | 83 | 12 | | | | | | |
| 2N3957 | TO-71 | 20 | 200 | 15 | 50 | 50 | 50 | 0.5 | 4.0 | 1.0 | 4.5 | 0.5 | 5.0 | 1.0 | 3.0 | 35 | 100 | 30 | 4.0 | 1.2 | 50 | 150 | 100 | 5.0 | 3.0 | 10 | 10 | 83 | 12 | | | | | | |
| 2N3958 | TO-71 | 20 | 200 | 20 | 75 | 50 | 50 | 0.5 | 4.0 | 1.0 | 4.5 | 0.5 | 5.0 | 1.0 | 3.0 | 35 | 100 | 30 | 4.0 | 1.2 | 50 | 150 | 100 | 5.0 | 3.0 | 10 | 10 | 83 | 12 | | | | | | |
| 2N3958A | TO-71 | 20 | 200 | 25 | 100 | 50 | 50 | 0.5 | 4.0 | 1.0 | 4.5 | 0.5 | 5.0 | 1.0 | 3.0 | 35 | 100 | 30 | 4.0 | 1.2 | 50 | 150 | 100 | 5.0 | 3.0 | 10 | 10 | 83 | 12 | | | | | | |
| 2N4082 | TO-71 | 10 | 200 | 15 | 10 | 100 | 300 | 10 | 10 | 10 | 3.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 12 | | | | | | |
| 2N4083 | TO-71 | 10 | 200 | 15 | 25 | 100 | 300 | 10 | 10 | 10 | 3.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 12 | | | | | | |
| 2N4084 | TO-71 | 10 | 700 | 15 | 10 | 250 | 1500 | 20 | 20 | 20 | 3.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 12 | | | | | | |
| 2N4085 | TO-71 | 10 | 700 | 15 | 25 | 250 | 1500 | 20 | 20 | 20 | 3.0 | 1.0 | 10 | 1.5 | 7.5 | 35 | 1000 | 30 | 18 | 6.0 | 50 | 100 | 1.0k | 5.0 | 5.0 | 10k | 1.0k | 83 | 12 | | | | | | |

See 2N3954.6 as an improved replacement

See 2N3954.6 as an improved replacement

See 2N3954.6 as an improved replacement

See 2N3954.6 as an improved replacement



N-Channel FETs

GENERAL PURPOSE DUAL JFETs (Continued)

| Type No. | | OPERATING CONDITIONS FOR THESE CHARACTERISTICS | | | | | | | | | | | | | Process No. | | Pkg. No. | | | | | | | | | | |
|------------|----------|--|-------------------------|------------------------|---------------------|------------------------|----------------------|------------------|---------------------|---------------------|--------------------|-----------------------|------------------------|------------------------|------------------------|--|----------|-----------------------|-----------------------|--------|---------------------|--------------------------|-------------------------|-------------------------------|----|-----|----|
| Case Style | OP. CHAR | V _{GS1} 2 ¹ DRIFT | V _{GS} (ΔV/ C) | I _G (ΔV/ C) | I _G (pA) | I _G (ΔV/ C) | V _{GS} (mV) | ΔV _{GS} | V _{GS} (V) | V _{GS} (V) | V _p (V) | I _{DSS} (mA) | G _{fs} (mmho) | G _{fs} (mmho) | G _{fs} (mmho) | I _{GSS} (pA @ V _{DS}) | | C _{iss} (pF) | C _{res} (pF) | BV (V) | f _n (Hz) | I _{DSS} Match % | G _{fs} Match % | I _{GSS1} 125 °C (nA) | | | |
| TO-71 | 2N5045 | 15 | 200 | 5.0 | 67 | | | | 0.5 | 4.5 | 0.5 | 8.0 | 1.5 | 6.0 | 75 | 250 | 30 | 4.0 | 4.0 | 50 | 10 | 5.0 | 1.0 | 83 | | | |
| TO-71 | 2N5046 | 15 | 200 | 10 | 123 | | | | 0.5 | 4.5 | 0.5 | 8.0 | 1.5 | 6.0 | 25 | 250 | 30 | 8.0 | 4.0 | 50 | 10 | 2.0 | 2.0 | 83 | | | |
| TO-71 | 2N5047 | 15 | 200 | 15 | 200 | | | | 0.5 | 4.5 | 0.5 | 8.0 | 1.5 | 6.0 | 25 | 250 | 30 | 8.0 | 4.0 | 50 | 10 | 2.0 | 3.0 | 83 | | | |
| TO-71 | 2N5196 | 20 | 200 | 5.0 | 50 | | | 0.2 | 3.8 | 0.7 | 4.5 | 0.7 | 7.0 | 1.0 | 4.0 | 50 | 25 | 6.0 | 2.0 | 50 | 10 | 5.0 | 5.0 | 83 | | | |
| TO-71 | 2N5197 | 20 | 200 | 5.0 | 10 | | | 0.2 | 3.8 | 0.7 | 4.5 | 0.7 | 7.0 | 1.0 | 4.0 | 50 | 25 | 6.0 | 2.0 | 50 | 10 | 5.0 | 5.0 | 83 | | | |
| TO-71 | 2N5198 | 20 | 200 | 10 | 20 | | | 0.2 | 3.8 | 0.7 | 4.5 | 0.7 | 7.0 | 1.0 | 4.0 | 50 | 25 | 6.0 | 2.0 | 50 | 10 | 5.0 | 5.0 | 83 | | | |
| TO-71 | 2N5199 | 20 | 200 | 15 | 40 | | | 0.2 | 3.8 | 0.7 | 4.5 | 0.7 | 7.0 | 1.0 | 4.0 | 50 | 25 | 6.0 | 2.0 | 50 | 10 | 5.0 | 5.0 | 83 | | | |
| TO-71 | 2N5452 | 20 | 200 | 5.0 | 5.0 | | | 0.2 | 4.2 | 1.0 | 4.5 | 0.5 | 6.0 | 1.0 | 3.0 | 3.0 | 100 | 30 | 4.0 | 1.2 | 50 | 20 | 1.0 | 0.25 | 83 | | |
| TO-71 | 2N5453 | 20 | 200 | 10 | 10 | | | 0.2 | 4.2 | 1.0 | 4.5 | 0.5 | 6.0 | 1.0 | 3.0 | 3.0 | 100 | 30 | 4.0 | 1.2 | 50 | 20 | 1.0 | 0.25 | 83 | | |
| TO-71 | 2N5454 | 20 | 200 | 15 | 25 | | | 0.2 | 4.2 | 1.0 | 4.5 | 0.5 | 6.0 | 1.0 | 3.0 | 3.0 | 100 | 30 | 4.0 | 1.2 | 50 | 20 | 1.0 | 0.25 | 83 | | |
| TO-71 | 2N5446 | 15 | 200 | 5.0 | 10 | | | 50 | 0.5 | 4.5 | 0.5 | 8.0 | 1.5 | 6.0 | 25 | 100 | 30 | 6.0 | 2.0 | 50 | 10 | 5.0 | 5.0 | 83 | | | |
| TO-71 | 2N5546 | 15 | 200 | 10 | 20 | | | 50 | 0.5 | 4.5 | 0.5 | 8.0 | 1.5 | 6.0 | 25 | 100 | 30 | 6.0 | 2.0 | 50 | 10 | 5.0 | 5.0 | 83 | | | |
| TO-71 | 2N5547 | 15 | 200 | 15 | 40 | | | 50 | 0.5 | 4.5 | 0.5 | 8.0 | 1.5 | 6.0 | 25 | 100 | 30 | 6.0 | 2.0 | 50 | 10 | 5.0 | 5.0 | 83 | | | |
| TO-71 | 2N5561 | TO-71 | | | | | | | | | | | | | | | | | | | | | | | 12 | | |
| TO-71 | 2N5562 | TO-71 | | | | | | | | | | | | | | | | | | | | | | | 12 | | |
| TO-71 | 2N5563 | TO-71 | | | | | | | | | | | | | | | | | | | | | | | 12 | | |
| J401 | J402 | 8-Pin | | | | | | | | | | | | | | | | | | | | | | | 98 | | |
| J403 | J404 | Mini-DIP | | | | | | | | | | | | | | | | | | | | | | | 98 | | |
| J405 | J406 | DIP | | | | | | | | | | | | | | | | | | | | | | | 98 | | |
| J410 | J411 | 8-Pin | 20 | 200 | 10 | 10 | 250 | 600 | 1200 | 5.0 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | 250 | 20 | 4.5 | 1.2 | 40 | 50 | 100 | 98 |
| J412 | J413 | DIP | 20 | 200 | 25 | 25 | 250 | 600 | 1200 | 5.0 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | 250 | 20 | 4.5 | 1.2 | 40 | 50 | 100 | 98 |
| NPD8301 | NPD8302 | 8-Pin | 20 | 200 | 5 | 10 | 100 | 700 | 1200 | 5.0 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | 100 | 20 | 4.5 | 1.2 | 40 | 50 | 100 | 98 |
| NPD8303 | NPD8304 | Mini-DIP | 20 | 200 | 10 | 15 | 100 | 700 | 1200 | 5.0 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | 100 | 20 | 4.5 | 1.2 | 40 | 50 | 100 | 98 |
| NPD8801 | NPD8802 | DIP | 20 | 200 | 15 | 25 | 100 | 700 | 1200 | 5.0 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | 100 | 20 | 4.5 | 1.2 | 40 | 50 | 100 | 98 |
| NPD8803 | NPD8804 | DIP | 20 | 200 | 10 | 10 | 50 | 600 | 1200 | 5.0 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | 250 | 20 | 4.5 | 1.2 | 40 | 50 | 100 | 98 |
| U231 | U232 | TO-71 | 20 | 200 | 5.0 | 10 | 50 | 600 | 1200 | 10 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | | | | | | | | 83 |
| U233 | U234 | TO-71 | 20 | 200 | 10 | 25 | 50 | 600 | 1200 | 10 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | | | | | | | | 83 |
| U235 | U236 | TO-71 | 20 | 200 | 15 | 50 | 50 | 600 | 1200 | 10 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | | | | | | | | 83 |
| U237 | U238 | TO-71 | 20 | 200 | 20 | 75 | 50 | 600 | 1200 | 10 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | | | | | | | | 83 |
| U239 | U240 | TO-71 | 20 | 200 | 25 | 100 | 50 | 600 | 1200 | 10 | 0.3 | 4.0 | 0.5 | 3.5 | 0.5 | 6 | 1 | 4 | 20 | | | | | | | | 83 |
| U401 | U402 | TO-71 | | | | | | | | | | | | | | | | | | | | | | | | 98 | |
| U403 | U404 | TO-71 | | | | | | | | | | | | | | | | | | | | | | | | 98 | |
| U405 | U406 | TO-71 | | | | | | | | | | | | | | | | | | | | | | | | 98 | |

PROCESS IN DEVELOPMENT

PROCESS IN DEVELOPMENT

PROCESS IN DEVELOPMENT

See 2N3954 as an improved replacement
See 2N3955 as an improved replacement
See 2N3956 as an improved replacement
See 2N3957 as an improved replacement
See 2N3958 as an improved replacement

N-Channel FETs

LOW FREQUENCY—LOW NOISE DUAL JFETs

| Type No. | Case Style | OPERATING CONDITIONS FOR THESE CHARACTERISTICS | | | | | | | | | | Pkg. No. | | | | | | | | | | | | | | | | | | | | |
|----------|------------|--|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|----------|-----|-----|-----|-----|-----|-----|-----|-----|-----|------|------|----|-----|-----|-----|-----|-----|----|----|----|
| | | OP. CHAR. V _{GS} (V) | V _{GS} (V) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | | | | | | | | | | | | | | | | | | | | | |
| 2N5516 | TO-71 | 20 | 200 | 5.0 | 100 | 500 | 1000 | 1.0 | 100 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 30 | 10 | 5.0 | 3.0 | 0.1 | 10 | 95 | 12 | |
| 2N5516 | TO-71 | 20 | 200 | 5.0 | 100 | 500 | 1000 | 1.0 | 100 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 3.0 | 0.1 | 10 | 95 | 12 | | |
| 2N5517 | TO-71 | 20 | 200 | 10 | 200 | 500 | 1000 | 1.0 | 90 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | | |
| 2N5518 | TO-71 | 20 | 200 | 15 | 40 | 100 | 500 | 1000 | 1.0 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | | |
| 2N5519 | TO-71 | 20 | 200 | 15 | 80 | 100 | 500 | 1000 | 1.0 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | | |
| 2N5520 | TO-71 | 20 | 200 | 5.0 | 5.0 | 100 | 500 | 1000 | 1.0 | 100 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 15 | 10 | 5.0 | 3.0 | 0.1 | 10 | 95 | 12 |
| 2N5521 | TO-71 | 20 | 200 | 5.0 | 10 | 100 | 500 | 1000 | 1.0 | 100 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | |
| 2N5522 | TO-71 | 20 | 200 | 10 | 20 | 100 | 500 | 1000 | 1.0 | 90 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | |
| 2N5523 | TO-71 | 20 | 200 | 15 | 40 | 100 | 500 | 1000 | 1.0 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | | |
| 2N5524 | TO-71 | 20 | 200 | 15 | 80 | 100 | 500 | 1000 | 1.0 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 250 | 30 | +25 | +5.0 | 40 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | | |
| 2N6483 | TO-71 | 20 | 200 | 5.0 | 5.0 | 100 | 500 | 1500 | 1.0 | 100 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 200 | 30 | 20 | 3.5 | 50 | 10 | 5.0 | 3.0 | 0.1 | 10 | 95 | 12 | |
| 2N6484 | TO-71 | 20 | 200 | 10 | 10 | 100 | 500 | 1500 | 1.0 | 100 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 200 | 30 | 20 | 3.5 | 50 | 10 | 5.0 | 3.0 | 0.1 | 10 | 95 | 12 | |
| 2N6485 | TO-71 | 20 | 200 | 15 | 25 | 100 | 500 | 1500 | 1.0 | 90 | 0.2 | 3.8 | 0.7 | 4.0 | 0.5 | 7.5 | 1.0 | 4.0 | 10 | 200 | 30 | 20 | 3.5 | 50 | 10 | 5.0 | 5.0 | 0.1 | 10 | 95 | 12 | |

N-Channel FETs

WIDE BAND—LOW NOISE DUAL JFETs

| Type No. | Case Style | OPERATING CONDITIONS FOR THESE CHARACTERISTICS | | | | | | | | | | Pkg. No. | | | | | | | | | | | | | | | | | | | | | |
|----------|------------|--|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|---------------------|----------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|----|-----|-----|----|----|----|----|----|
| | | OP. CHAR. V _{GS} (V) | V _{GS} (V) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | I _G (μA) | | | | | | | | | | | | | | | | | | | | | | |
| 2N5564 | TO-71 | 15 | 2000 | 5.0 | 10 | 7500 | 45 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 100 | 20 | 12 | 3.0 | 40 | 50 | 10 | 5.0 | 5.0 | 96 | 12 | | | |
| 2N5565 | TO-71 | 15 | 2000 | 10 | 25 | 7500 | 45 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 100 | 20 | 12 | 3.0 | 40 | 50 | 10 | 5.0 | 5.0 | 96 | 12 | | | |
| 2N5566 | TO-71 | 15 | 2000 | 20 | 50 | 7500 | 45 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 100 | 20 | 12 | 3.0 | 40 | 50 | 10 | 5.0 | 5.0 | 96 | 12 | | | |
| 2N5591 | TO-78 | 10 | 5000 | 10 | 20 | 5000 | 10,000 | 100 | 0.3 | 4.0 | 1.0 | 5.0 | 7.0 | 40 | 100 | 15 | 5.0 | 1.2 | 25 | 20 | 104 | 15 | 5.0 | 1.2 | 25 | 20 | 104 | 5.0 | 20 | 93 | 24 | | |
| 2N55912 | TO-78 | 10 | 5000 | 15 | 40 | 5000 | 10,000 | 100 | 0.3 | 4.0 | 1.0 | 5.0 | 7.0 | 40 | 100 | 15 | 5.0 | 1.2 | 25 | 20 | 104 | 15 | 5.0 | 1.2 | 25 | 20 | 104 | 5.0 | 20 | 93 | 24 | | |
| NFD5564 | B-Pin | 15 | 2000 | 5.0 | 10 | 7500 | 45 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 100 | 20 | 12 | 3.0 | 40 | 50 | 10 | 5.0 | 5.0 | 96 | 67 | | | |
| NFD5565 | Mini- | 15 | 2000 | 10 | 25 | 7500 | 45 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 100 | 20 | 12 | 3.0 | 40 | 50 | 10 | 5.0 | 5.0 | 96 | 67 | | | |
| NFD5566 | DIP | 15 | 2000 | 20 | 50 | 7500 | 45 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 0.5 | 3.0 | 5.0 | 30 | 100 | 20 | 12 | 3.0 | 40 | 50 | 10 | 5.0 | 5.0 | 96 | 67 | | | |
| U257 | TO-78 | 10 | 5000 | 100 | 5000 | 10,000 | 150 | 1.0 | 5.0 | 5.0 | 40 | 1.0 | 5.0 | 5.0 | 40 | 100 | 15 | 5.0 | 1.7 | 25 | 30 | 104 | 15 | 5.0 | 1.7 | 25 | 30 | 104 | 15 | 20 | 93 | 24 | |
| U430 | TO-99 | 10 | 10,000 | 10,000 | 20,000 | 150 | 150 | 1.0 | 4.0 | 1.2 | 30 | 1.0 | 4.0 | 1.2 | 30 | 150 | 15 | 1.0 | 10 | 10 | 100 | 10 | 10 | 10 | 10 | 10 | 10 | 10 | 10 | 10 | 92 | 24 | |
| U431 | TO-99 | 10 | 10,000 | 10,000 | 20,000 | 150 | 150 | 2.0 | 6.0 | 24 | 60 | 2.0 | 6.0 | 24 | 60 | 150 | 15 | 2.0 | 6.0 | 24 | 60 | 150 | 15 | 2.0 | 6.0 | 24 | 60 | 150 | 15 | 10 | 10 | 92 | 24 |



N-Channel FETS

LOW LEAKAGE—HIGH CMRR—WIDE BAND DUAL JFETS

| Type No. | Case Style | OPERATING CONDITIONS FOR THESE CHARACTERISTICS | | | | | | | | | | | | | | Pkg No. | | | | | | | | | | | | | | | |
|----------|------------|--|---------------------|-------------------------|-----|-----------------------|--------------|------|---------------------|-------------------------|---------------------|-----|-----------|---------------------|---------------------|---------|--------------------|-----------------------|------------------------|------------------------|-----------------------|---------------------|-----------------------|-----------------------|--------|------------------------|--------------------------|-------------------|---------------------------|--------------------------|-------------|
| | | OP. CHAR. V _{DG} (V) | I _D (μA) | V _{GS1-2} (mV) | | ΔV _{GS} (mV) | DRIFT (μV/C) | | I _G (μA) | ΔV _{GS} (μV/C) | V _{Gs} (V) | | CMRR (dB) | V _{GS} (V) | V _{GS} (V) | | V _p (V) | I _{DSS} (mA) | G _{fs} (μmho) | G _{ss} (μmho) | I _{GSS} (μA) | V _{DG} (V) | C _{iss} (pF) | C _{rss} (pF) | BV (V) | Δ _T (V/√Hz) | I _{DSS} Match % | G _{fs} % | G _{ss1-2} (μmho) | I _{G1-IG2} (nA) | Process No. |
| | | | | Min | Max | | Min | Max | | | Min | Max | | | | | | | | | | | | | | | | | | | |
| NDF9401 | TO-78 | 20 | 200 | 5.0 | 5.0 | 5.0 [†] | 5.0 | 5.0 | 2000 | 0.1 | 120 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 24 | | |
| NDF9402 | TO-78 | 20 | 200 | 5.0 | 10 | 5.0 [†] | 950 | 2000 | 0.1 | 120 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 24 | | | |
| NDF9403 | TO-78 | 20 | 200 | 10 | 10 | 5.0 [†] | 950 | 2000 | 0.1 | 110 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 24 | | | |
| NDF9404 | TO-78 | 20 | 200 | 15 | 10 | 5.0 [†] | 950 | 2000 | 0.1 | 110 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 24 | | | |
| NDF9405 | TO-78 | 20 | 200 | 25 | 25 | 5.0 [†] | 950 | 2000 | 0.1 | 100 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 24 | | | |
| NDF9406 | TO-71 | 20 | 200 | 5.0 | 5.0 | 5.0 [†] | 950 | 2000 | 0.1 | 120 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 12 | | | |
| NDF9407 | TO-71 | 20 | 200 | 5.0 | 10 | 5.0 [†] | 950 | 2000 | 0.1 | 110 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 12 | | | |
| NDF9408 | TO-71 | 20 | 200 | 15 | 10 | 5.0 [†] | 950 | 2000 | 0.1 | 110 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 12 | | | |
| NDF9409 | TO-71 | 20 | 200 | 15 | 10 | 5.0 [†] | 950 | 2000 | 0.1 | 110 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 12 | | | |
| NDF9410 | TO-71 | 20 | 200 | 25 | 25 | 5.0 [†] | 950 | 2000 | 0.1 | 100 | 0.1 | 4.0 | 0.5 | 4.0 | 0.5 | 10 | 30 | 5.0 | 0.02 | 50 | 30 | 10 | 5.0 | 3.0 | 0.1 | 1.0 | 94 | 12 | | | |

† V_{DG} = 35V



N-Channel FETS

ULTRA LOW LEAKAGE DUALS

| Type No. | Case Style | OPERATING CONDITIONS FOR THESE CHARACTERISTICS | | | | | | | | | | | | | | Pkg No. | | | | | | | | | | | | | | |
|----------|------------|--|---------------------|-------------------------|-----|-------------------------|-----------------|---------|---------------------|---------|------------------------|------------------------|---------|-----------------|--------------------|---------|-----------------------|------------------------|------------------------|-----------------------|---------------------|-----------------------|-----------------------|-----------------------|----------------------------------|-------------|-----|-----|-----|-----|
| | | Oper. Cond. V _{DG} (V) | I _D (μA) | V _{GS1-2} (mV) | | ΔV _{GS} (μV/C) | IG DRIFT (pA) | IG (pA) | I _G (μA) | VGS (V) | G _{fs} (μmho) | G _{ss} (μmho) | VGS (V) | VGS (V) | V _p (V) | | I _{DSS} (mA) | G _{fs} (μmho) | G _{ss} (μmho) | I _{GSS} (μA) | V _{DG} (V) | C _{iss} (pF) | C _{rss} (pF) | BV _{GSS} (V) | IG _{1-IG2} @ 125°C (nA) | Process No. | | | | |
| | | | | Min | Max | | | | | | | | | | | | | | | | | | | | | | Min | Max | Min | Max |
| 2N5902 | TO-78 | 10 | 30 | 5 | 5 | 3 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 2 | 84 | 24 | | | | |
| 2N5903 | TO-78 | 10 | 30 | 5 | 10 | 3 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 2 | 84 | 24 | | | | |
| 2N5904 | TO-78 | 10 | 30 | 10 | 20 | 3 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 2 | 84 | 24 | | | | |
| 2N5905 | TO-78 | 10 | 30 | 15 | 40 | 3 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 2 | 84 | 24 | | | | |
| 2N5906 | TO-78 | 10 | 30 | 5 | 5 | 1 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 0.2 | 84 | 24 | | | | |
| 2N5907 | TO-78 | 10 | 30 | 5 | 10 | 1 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 0.2 | 84 | 24 | | | | |
| 2N5908 | TO-78 | 10 | 30 | 10 | 20 | 1 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 0.2 | 84 | 24 | | | | |
| 2N5909 | TO-78 | 10 | 30 | 15 | 40 | 1 | 50 _u | 1 | 4 | 0.6 | 4.5 | 30 _u | 0.5 | 30 _u | 4.5 | 0.5 | 70 _u | 0.25 | 5 | 20 | 3 | 1.5 | 40 | 0.2 | 84 | 24 | | | | |
| U421 | TO-78 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| U422 | TO-78 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| U423 | TO-78 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| U424 | TO-78 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| U425 | TO-78 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| U426 | TO-78 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |

PROCESS IN DEVELOPMENT



P-Channel FETs

SWITCHES

| Transistor Type | Case Style | BV _{GSS} | | I _{GSS} IDGO (nA) @ V _{DG} (V) | I _{D(off)} | | V _p @ V _{DSS} | | I _D (μA) | I _{DSS} @ V _{DSS} | | r _{ds} (Ω) @ I _D (mA) | C _{iss} (pF) @ V _{DSS} (V) | V _{GS} (V) | C _{rss} (pF) @ V _{DSS} (V) | V _{GS} (V) | t _{on} (ns) Max | t _{off} (ns) Max | Process No. | Pkg. No. | | | | | | | | | |
|-----------------|------------|-------------------|---------|---|---------------------|----------|-----------------------------------|---------|------------------------|-------------------------------------|----------|---|--|------------------------|--|------------------------|-----------------------------|------------------------------|-------------|----------|-----|----|----|----|----|----|----|----|----|
| | | (V) Min | (V) Max | | (nA) Min | (nA) Max | (V) Min | (V) Max | | (mA) Min | (mA) Max | | | | | | | | | | | | | | | | | | |
| 2N3382 | TO-72 | 30 | 1 | 15 | 30 | 2 | 5 | 6 | 1 | 5 | -5 | 1 | 3 | 30 | 10 | 300 | | | 88 | 23 | | | | | | | | | |
| 2N3384 | TO-72 | 30 | 1 | 15 | 30 | 2 | -5 | 6 | 4 | 5 | -5 | 1 | 15 | 30 | 10 | 180 | | | 88 | 23 | | | | | | | | | |
| 2N3386 | TO-72 | 30 | 1 | 15 | 30 | 2.5 | -5 | 10 | 4 | 9.5 | -5 | 1 | 15 | 50 | 10 | 150 | | | 88 | 23 | | | | | | | | | |
| 2N3993 | TO-72 | 25 | 1 | 1.2* | 15 | 1.2 | -10 | 10 | 4 | 9.5 | -10 | 1 | 10 | 150 | 10 | 150 | | | 88 | 23 | | | | | | | | | |
| 2N3993A | TO-72 | 25 | 1 | 1.2* | 15 | 1.2 | -10 | 10 | 4 | 9.5 | -10 | 1 | 10 | 150 | 10 | 150 | | | 88 | 23 | | | | | | | | | |
| 2N3994 | TO-72 | 25 | 1 | 1.2* | 15 | 1.2 | -10 | 6 | 1 | 5.5 | -10 | 1 | 2 | 10 | 300 | 10 | 300 | | | 88 | 23 | | | | | | | | |
| 2N3994A | TO-72 | 25 | 1 | 1.2* | 15 | 1.2 | -10 | 6 | 1 | 5.5 | -10 | 1 | 2 | 10 | 300 | 10 | 300 | | | 88 | 23 | | | | | | | | |
| 2N5018 | TO-18 | 30 | 1 | 2 | 15 | 10 | -15 | 12 | 1 | 10 | -15 | 1 | 10 | 75 | 45 | -15 | 0 | 10 | 0 | 12 | 35 | 65 | 88 | 11 | | | | | |
| 2N5019 | TO-18 | 30 | 1 | 2 | 15 | 10 | -15 | 7 | 5 | 10 | -15 | 1 | 5 | 20 | 150 | 10 | 7 | 90 | 125 | 88 | 11 | | | | | | | | |
| 2N5114 | TO-18 | 30 | 1 | 0.5 | 20 | 0.5 | -15 | 12 | 5 | 10 | -15 | .001 | 30 | 90 | 18 | 75 | 1 | 25 | -15 | 0 | 12 | 16 | 21 | 88 | 11 | | | | |
| 2N5115 | TO-18 | 30 | 1 | 0.5 | 20 | 0.5 | -15 | 7 | 3 | 6 | -15 | .001 | 16 | 60 | 15 | 100 | 1 | 25 | -15 | 0 | 7 | 0 | 7 | 30 | 38 | 88 | 11 | | |
| 2N5116 | TO-18 | 30 | 1 | 0.5 | 20 | 0.5 | -15 | 5 | 1 | 4 | -15 | .001 | 5 | 25 | 15 | 150 | 1 | 25 | -15 | 0 | 7 | 0 | 5 | 42 | 60 | 88 | 11 | | |
| J174 | TO-92 | 30 | 1 | 1 | 20 | 1 | -15 | 10 | 5 | 10 | -15 | .01 | 20 | 100 | 15 | 85 | 1 | 11 | 0 | 10 | 5.5 | 0 | 10 | 2 | 5 | 88 | 74 | | |
| J176 | TO-92 | 30 | 1 | 1 | 20 | 1 | -15 | 10 | 3 | 6 | -15 | .01 | 7 | 60 | 15 | 125 | 5 | 11 | 0 | 10 | 5.5 | 0 | 10 | 5 | 10 | 88 | 74 | | |
| J177 | TO-92 | 30 | 1 | 1 | 20 | 1 | -15 | 10 | 1 | 4 | -15 | .01 | 2 | 25 | 15 | 250 | 25 | 11 | 0 | 10 | 5.5 | 0 | 10 | 15 | 15 | 88 | 74 | | |
| P1086E | TO-92 | 30 | 1 | 2 | 20 | 10 | -15 | 10 | 8 | 2.25 | -15 | .01 | 1.5 | 20 | 15 | 300 | 1 | 11 | 0 | 10 | 5.5 | 0 | 10 | 20 | 20 | 88 | 74 | | |
| P1087E | TO-92 | 30 | 1 | 2 | 20 | 10 | -15 | 5 | 5 | 10 | -15 | .01 | 10 | 75 | 1 | 75 | 1 | 45 | -15 | 0 | 10 | 15 | 0 | 35 | 50 | 88 | 71 | | |
| U304 | TO-18 | 30 | 1 | 0.5 | 20 | 0.5 | -15 | 12 | 5 | 10 | 15 | 1 | 30 | 90 | 15 | 85 | 15 | 45 | 15 | 0 | 10 | 15 | 0 | 40 | 75 | 88 | 11 | | |
| U305 | TO-18 | 30 | 1 | 0.5 | 20 | 0.5 | -15 | 7 | 3 | 4 | 15 | 1 | 15 | 60 | 15 | 110 | 110 | 27 | -15 | 0 | 7 | 0 | 7 | 0 | 12 | 35 | 35 | 88 | 11 |
| U306 | TO-18 | 30 | 1 | 0.5 | 20 | 0.5 | -15 | 5 | 1 | 4 | 15 | 1 | 5 | 25 | 15 | 175 | 175 | 27 | -15 | 0 | 7 | 0 | 7 | 0 | 5 | 60 | 80 | 88 | 11 |

* Note: JAN qualified per applicable MIL-S-19500 specification



P-Channel FETs

AMPLIFIERS

| Transistor Type | Case Style | BV _{GSS} | | I _{GSS} IDGO (nA) @ V _{DG} (V) | V _p @ V _{DSS} | | I _D (μA) | I _{DSS} @ V _{DSS} | | G _{fs} (mmho) @ V _{DSS} | G _{oss} (μmho) @ V _{DSS} | C _{iss} (pF) Max | V _{GS} (V) | C _{rss} (pF) @ V _{DSS} (V) | V _{GS} (V) | C _{iss} (pF) @ V _{DSS} (V) | V _{GS} (V) | t _{on} (ns) Max | t _{off} (ns) Max | Process No. | Pkg. No. | | | | | | |
|-----------------|------------|-------------------|---------|---|-----------------------------------|----------|------------------------|-------------------------------------|------------|--|---|------------------------------|------------------------|--|------------------------|--|------------------------|-----------------------------|------------------------------|-------------|----------|---------|---------|---------|---------|---------|---------|
| | | (V) Min | (V) Max | | (mA) Min | (mA) Max | | (mmho) Min | (mmho) Max | | | | | | | | | | | | | (V) Min | (V) Max | (V) Min | (V) Max | (V) Min | (V) Max |
| 2N2608 | TO-18 | 30 | 1 | 10 | 30 | 1 | 4 | 5 | 1 | 0.9 | 4.5 | 5 | 1 | 5 | 5 | 17 | -5 | 1 | 125 | 1000 | 89 | 11 | | | | | |
| 2N2609 | TO-18 | 30 | 1 | 30 | 30 | 1 | 4 | 5 | 1 | 2 | 10 | 5 | 2.5 | 5 | 5 | 30 | 5 | 1 | 125 | 1000 | 88 | 11 | | | | | |
| 2N3329 | TO-72 | 20 | 10 | 10 | 10 | 5 | -15 | 10 | 1 | 3 | 10 | 1 | 2 | 10/1mA | 20 | 10 | -10 | 1 | 125 | 1000 | 89 | 23 | | | | | |
| 2N3330 | TO-72 | 20 | 10 | 10 | 10 | 6 | 15 | 10 | 2 | 6 | 10 | 1.5 | 3 | 10/2mA | 40 | 10 | 10 | 1 | 125 | 1000 | 89 | 23 | | | | | |
| 2N3331 | TO-72 | 20 | 10 | 10 | 10 | 8 | -15 | 10 | 5 | 15 | 10 | 2 | 4 | 10/5mA | 100 | 10 | -10 | 1 | 155 | 1000 | 89 | 23 | | | | | |
| 2N3332 | TO-72 | 20 | 10 | 10 | 10 | 6 | -15 | 10 | 1 | 6 | 10 | 1 | 2.2 | 10/1mA | 20 | 10 | -10 | 1 | 65 | 1000 | 89 | 23 | | | | | |
| 2N4381 | TO-18 | 25 | 1 | 1 | 15 | 1 | 5 | -15 | 1 | 3 | 12 | 15 | 2 | 6 | 15 | 75 | 15 | 20 | -15 | 0 | 5 | -15 | 0 | 20 | 1000 | 89 | 11 |

* Note: JAN qualified per applicable MIL-S-19500 specification



P-Channel FETS

AMPLIFIERS (Continued)

| Transistor Type | Case Style | BV _{GSS} BV _{GDO} (V) @ I _G (μ A) | | I _{GSS} I _{DGO} (mA) @ V _{DG} (V) | | V _p @ V _{DS} (V) | | I _{DSS} @ V _{DS} (mA) | | G _{fs} (mmho) @ V _{DS} (V) | | G _{oss} (μ mho) @ V _{DS} (V) | | C _{iss} V _{DS} (pF) | | V _{GS} (V) | | C _{iss} (pF) | | V _{GS} (V) | | C _{iss} (pF) | | V _{GS} (V) | | e _h (NV) ($\sqrt{\text{Hz}}$) @ Freq (Hz) | | Process No. | | Pkg. No. | |
|-----------------|------------|--|-----|---|-----|--|-----|---|------|--|-----|---|-----|---|-----|------------------------|-----|--------------------------|-----|------------------------|-----|--------------------------|------|------------------------|-----|---|-----|-------------|-----|----------|-----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max |
| 2N5020 | TO-18 | 25 | 1 | 1 | 15 | 0.3 | 1.5 | -15 | 1 | 0.3 | 1.2 | 15 | 20 | 15 | 25 | -15 | 0 | 7 | 15 | 0 | 30 | 1000 | 89 | 11 | | | | | | | |
| 2N5021 | TO-18 | 25 | 1 | 1 | 15 | 0.5 | 2.5 | 15 | 1 | 3.5 | 15 | 15 | 20 | 15 | 25 | -15 | 0 | 7 | 15 | 0 | 30 | 1000 | 89 | 11 | | | | | | | |
| 2N5460 | TO-92 | 40 | 10 | 5 | 20 | 0.75 | 6 | -15 | 1 | 5 | 15 | 1 | 4 | 15 | 7 | -15 | 0 | 2 | -15 | 0 | 115 | 100 | 89 | 71 | | | | | | | |
| 2N5461 | TO-92 | 40 | 10 | 5 | 20 | 1 | 7.5 | -15 | 1 | 2 | 9 | 15 | 1.6 | 5 | 15 | 0 | 2 | -15 | 0 | 115 | 100 | 89 | 71 | | | | | | | | |
| 2N5462 | TO-92 | 40 | 10 | 5 | 20 | 1.8 | 9 | -15 | 1 | 4 | 16 | 15 | 2 | 6 | 15 | 0 | 2 | -15 | 0 | 115 | 100 | 89 | 71 | | | | | | | | |
| J270 | TO-92 | 30 | 1 | 0.2 | 20 | 0.5 | 2.0 | 15 | .001 | 2 | 15 | 15 | 6.0 | 15.0 | 15 | 200 | 15 | 0 | 15 | 15 | 0 | 110 | 1k | 88 | 74 | | | | | | |
| J271 | TO-92 | 30 | 1 | 0.2 | 20 | 1.5 | 4.5 | -15 | .001 | 6 | 50 | 15 | 8.0 | 18.0 | 15 | 120 | 15 | 0 | 15 | 15 | 0 | 110 | 1k | 88 | 74 | | | | | | |
| PN4342 | TO-92 | 25 | 10 | 10 | 15 | 0.5 | 5.5 | -10 | 1 | 4 | 12 | 10 | 7.5 | 10 | 20 | 10 | 0 | 5 | 10 | 0 | 80 | 100 | 89 | 71 | | | | | | | |
| PN4360 | TO-92 | 20 | 10 | 10 | 15 | 0.7 | 10 | -10 | 1 | 3 | 30 | 10 | 2 | 8 | 10 | 100 | 10 | 0 | 5 | 10 | 0 | 190 | 100 | 89 | 71 | | | | | | |
| PN5033 | TO-92 | 20 | 10 | 10 | 15 | 0.3 | 2.5 | 10 | 1 | 0.3 | 3.5 | 10 | 1 | 5 | 10 | 20 | 10 | 0 | 7 | 10 | 0 | 100 | 1000 | 89 | 71 | | | | | | |
| U301 | TO-18 | 40 | 1 | 0.1 | 20 | 2.5 | 60 | -15 | .001 | 15 | 60 | 7 | 11 | 15 | 20 | 15 | 5.5 | -15 | 5.5 | 5.5 | 5.5 | 40 | 1000 | 88 | 11 | | | | | | |



Pro-Electron FETS

AMPLIFIERS

| Type No. | Case Style | BV _{GSS} BV _{GDO} (V) @ I _G (μ A) | | IGSS IDGD (mA) @ V _{DG} (V) | | V _p @ V _{DS} (V) | | I _D @ V _{DS} (μ A) | | V _{GS} @ V _{DS} (V) | | I _{DSS} @ V _{DS} (mA) | | R _o (YFS) (mmho) @ f (MHz) | | C _{iss} V _{DS} (pF) | | V _{GS} (V) | | C _{iss} (pF) | | V _{GS} (V) | | C _{iss} (pF) | | V _{GS} (V) | | NF (dB) @ R _G = 1k e _n * (Hz) ² | | Process No. | | Pkg. No. | |
|----------|------------|--|-----|---|-----|--|------|---|-----|---|-----|---|------|---|------|---|-----|------------------------|-----|--------------------------|-----|------------------------|-----|--------------------------|-----|------------------------|-----|---|-----|-------------|-----|----------|-----|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max |
| BF244A | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 4 | 2.2 | 15 | 200 | 2 | 6.5 | 15 | 4 | 20 | 1 | 1.1 | 20 | -1 | 1.5 | 100 | 50 | 74 | | | | | | | |
| BF244B | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 1.6 | 3.8 | 15 | 200 | 6 | 15 | 15 | 4 | 20 | 1 | 1.1 | 20 | -1 | 1.5 | 100 | 50 | 74 | | | | | | | |
| BF244C | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 3.2 | 7.5 | 15 | 200 | 12 | 25 | 15 | 4 | 20 | -1 | 1.1 | 20 | -1 | 1.5 | 100 | 50 | 74 | | | | | | | |
| BF245A | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 4 | 2.2 | 15 | 200 | 2 | 6.5 | 15 | 4 | 20 | 1 | 1.1 | 20 | -1 | 1.5 | 100 | 50 | 77 | | | | | | | |
| BF245B | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 1.6 | 3.8 | 15 | 200 | 6 | 15 | 15 | 4 | 20 | -1 | 1.1 | 20 | -1 | 1.5 | 100 | 50 | 77 | | | | | | | |
| BF245C | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 3.2 | 7.5 | 15 | 200 | 12 | 25 | 15 | 4 | 20 | -1 | 1.1 | 20 | -1 | 1.5 | 100 | 50 | 77 | | | | | | | |
| BF246A | TO-92 | 25 | 1 | 5 | 15 | 6 | 14.5 | 15 | 10 | 1.5 | 4.0 | 15 | 200 | 30 | 80 | 15 | 8 | 11 | 15 | 0 | 3.5 | 15 | 0 | 51 | 74 | | | | | | | | |
| BF246B | TO-92 | 25 | 1 | 5 | 15 | 6 | 14.5 | 15 | 10 | 3.0 | 7.0 | 15 | 200 | 60 | 140 | 15 | 8 | 11 | 15 | 0 | 3.5 | 15 | 0 | 51 | 74 | | | | | | | | |
| BF246C | TO-92 | 25 | 1 | 5 | 15 | 6 | 14.5 | 15 | 10 | 5.5 | 12 | 15 | 200 | 110 | 250 | 15 | 8 | 11 | 15 | 0 | 3.5 | 15 | 0 | 51 | 74 | | | | | | | | |
| BF247A | TO-92 | 25 | 1 | 5 | 15 | 6 | 14.5 | 15 | 10 | 1.5 | 4.0 | 15 | 200 | 30 | 80 | 15 | 8 | 11 | 15 | 0 | 3.5 | 15 | 0 | 51 | 77 | | | | | | | | |
| BF247B | TO-92 | 25 | 1 | 5 | 15 | 6 | 14.5 | 15 | 10 | 3.0 | 7.0 | 15 | 200 | 60 | 140 | 15 | 8 | 11 | 15 | 0 | 3.5 | 15 | 0 | 51 | 77 | | | | | | | | |
| BF247C | TO-92 | 25 | 1 | 5 | 15 | 6 | 14.5 | 15 | 10 | 5.5 | 12 | 15 | 200 | 110 | 250 | 15 | 8 | 11 | 15 | 0 | 3.5 | 15 | 0 | 51 | 77 | | | | | | | | |
| BF256A | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 5 | 7.5 | 15 | 200 | 3 | 7 | 15 | 4.5 | 11 | 15 | 0 | 7 | 20 | 1 | 7.5 | 800 | 50 | 77 | | | | | | |
| BF256B | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 5 | 7.5 | 15 | 200 | 6 | 13 | 15 | 4.5 | 11 | 15 | 0 | 7 | 20 | -1 | 7.5 | 800 | 50 | 77 | | | | | | |
| BF256C | TO-92 | 30 | 1 | 5 | 20 | 5 | 8 | 15 | 10 | 5 | 7.5 | 15 | 200 | 11 | 18 | 15 | 4.5 | 11 | 15 | 0 | 7 | 20 | 1 | 7.5 | 800 | 50 | 77 | | | | | | |
| BC264A | TO-92 | 30 | 1 | 10 | 20 | 5 | 15 | 10 | 5 | 2 | 1.2 | 15 | 1000 | 2 | 4.5 | 15 | 2.5 | 4.0 | 15 | -1 | 1.2 | 15 | -1 | 40* | 10* | 50 | 77 | | | | | | |
| BC264B | TO-92 | 30 | 1 | 10 | 20 | 5 | 15 | 10 | 5 | 4 | 1.4 | 15 | 1500 | 3.5 | 6.5 | 15 | 3.0 | 4.0 | 15 | -1 | 1.2 | 15 | -1 | 40* | 10* | 50 | 77 | | | | | | |
| BC264C | TO-92 | 30 | 1 | 10 | 20 | 5 | 15 | 10 | 5 | 5 | 1.5 | 15 | 2500 | 5.0 | 8.0 | 15 | 3.5 | 4.0 | 15 | -1 | 1.2 | 15 | -1 | 40* | 10* | 50 | 77 | | | | | | |
| BC264D | TO-92 | 30 | 1 | 10 | 20 | 5 | 15 | 10 | 5 | 6 | 1.6 | 15 | 3500 | 7.0 | 12.0 | 15 | 4.0 | 4.0 | 15 | -1 | 1.2 | 15 | -1 | 40* | 10* | 50 | 77 | | | | | | |

JFET Selection Guide

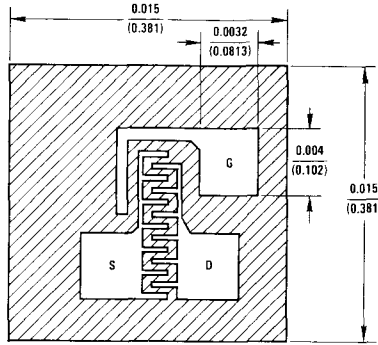


Section 9
Process
Characteristics JFETs

9



Process 50 N-Channel JFET



GATE IS ALSO BACKSIDE CONTACT

DESCRIPTION

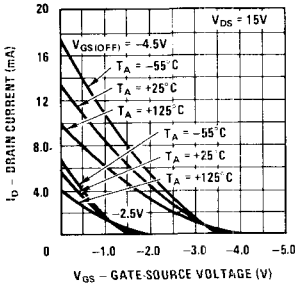
Process 50 is designed primarily for RF amplifier and mixer applications. It will operate up to 450 MHz with low noise figure and good power gain. These devices offer outstanding performance at VHF aircraft and communications frequencies. Their major advantage is low crossmodulation and intermodulation, low noise figure and good power gain. The device is also a good choice for analog switching where low capacitance is very important.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|------|------|------|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -25 | -40 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0V$ | 1.0 | 10 | 20 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 3.0 | 5.5 | 7.0 | mmhos |
| Forward Transconductance | g_{fs} | $V_{DG} = 15V, I_D = 200 \mu A$ | | 1.1 | | mmhos |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = -20V, V_{DS} = 0$ | | -5.0 | -100 | pA |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 mV, V_{GS} = 0$ | 100 | 175 | 500 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 nA$ | -0.7 | -3.5 | -6.0 | V |
| Output Conductance | g_{os} | $V_{DG} = 15V, I_D = 1 mA, f = 1 kHz$ | | 10 | | $\mu mhos$ |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, V_{GS} = 0$ | | 0.7 | 0.9 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0$ | | 3.5 | 4.0 | pF |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 1 mA, f = 100 Hz$ | | 8.0 | | nV/\sqrt{Hz} |
| Noise Figure | NF | $V_{DG} = 15V, I_D = 5 mA, R_G = 1 k\Omega, f = 400 MHz$ | | 2.2 | 4.0 | dB |
| Power Gain | G_{PS} | $V_{DG} = 15V, I_D = 5 mA, f = 400 MHz$ | | 12 | | dB |

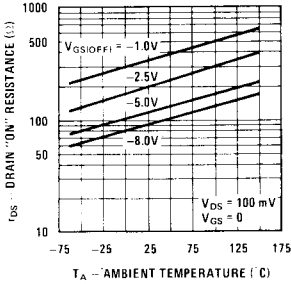
This process is available in the following device types. *Denotes preferred parts.

| TO-72 (CASE 25) | *2N5486 | TO-92 (CASE 74) | BC264C |
|-----------------|---------|-----------------|---------------------------|
| 2N3823 | 2N5555 | 2N3819 | BC264D |
| 2N3966 | 2N5668 | 2N5248 | BF245A |
| 2N4223 | 2N5669 | BF244A | BF245B |
| 2N4224 | 2N5670 | BF244B | BF245C |
| 2N4416 | *J304 | BF244C | BF256A |
| *2N4416A | *J305 | TIS58 | BF256B |
| 2N5078 | PN4223 | TIS59 | BF256C |
| 2N5103 | PN4224 | | |
| 2N5104 | *PN4416 | TO-92 (CASE 77) | QUALIFIED PER MIL-S-19500 |
| 2N5105 | PN5163 | 2N5949 | 2N3823JAN, JANTX, JANTXV |
| 2N5556 | MPF102 | 2N5950 | 2N4416AJAN, JANTX, JANTXV |
| 2N5557 | MPF106 | 2N5951 | |
| 2N5558 | MPF107 | 2N5952 | |
| | MPF110 | 2N5953 | |
| TO-92 (CASE 72) | MPF111 | BC264A | |
| *2N5484 | | BC264B | |
| *2N5485 | | | |

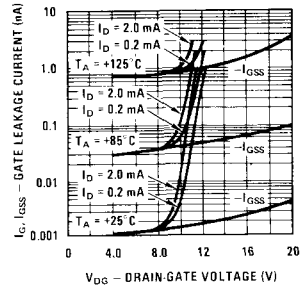
Transfer Characteristics



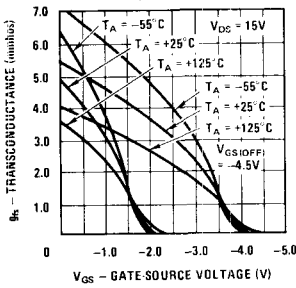
Channel Resistance vs Temperature



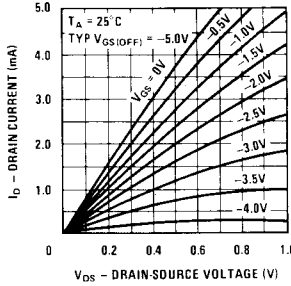
Leakage Current vs Voltage



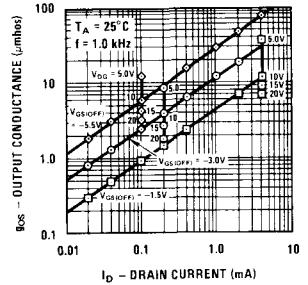
Transconductance Characteristics



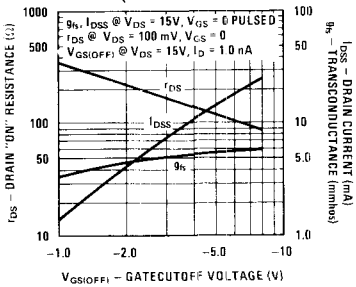
Common Drain-Source Characteristics



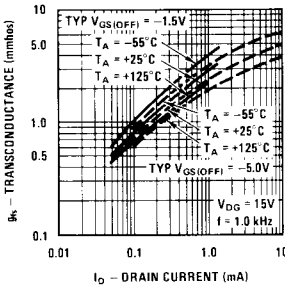
Output Conductance vs Drain Current



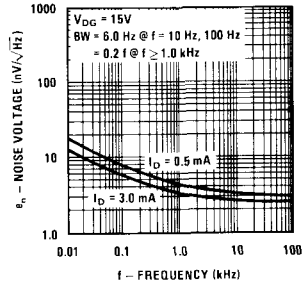
Parameter Interactions



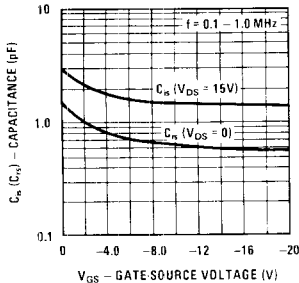
Transconductance vs Drain Current



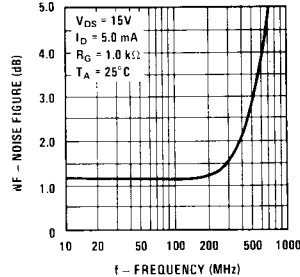
Noise Voltage vs Frequency



Capacitance vs Voltage

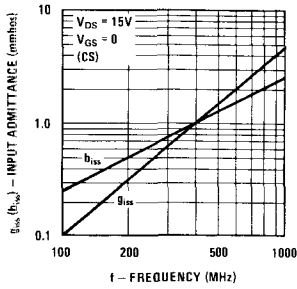


Noise Figure Frequency

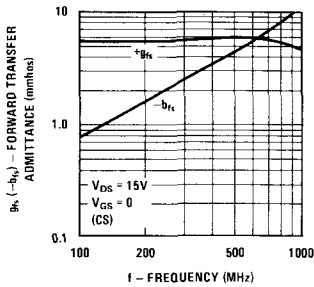


COMMON SOURCE

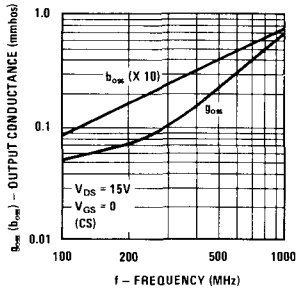
Input Admittance



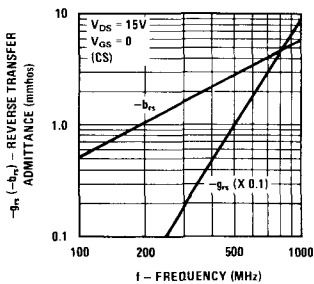
Forward Transadmittance



Output Admittance

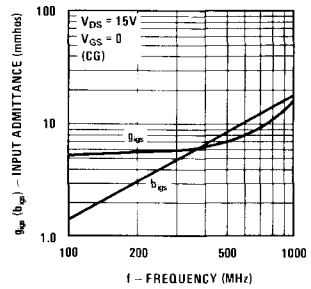


Reverse Transadmittance

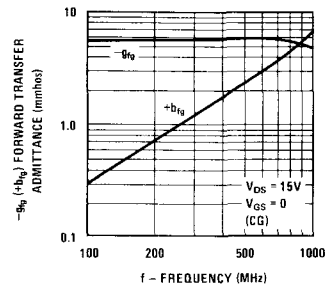


COMMON GATE

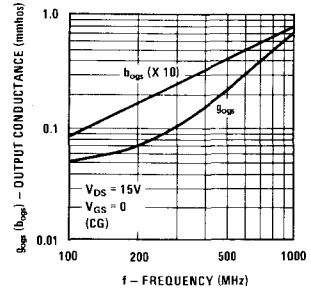
Input Admittance



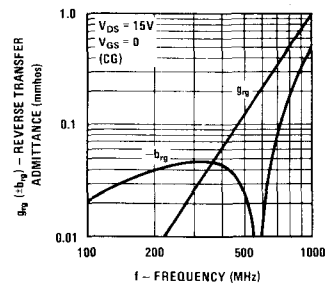
Forward Transadmittance



Output Admittance



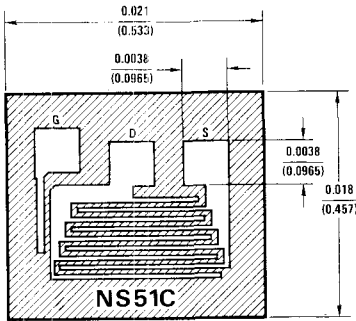
Reverse Transadmittance





Process 51 N-Channel JFET

Process 51



GATE IS ALSO BACKSIDE CONTACT

DESCRIPTION

Process 51 is designed primarily for electronic switching applications such as low ON resistance analog switching. It features excellent C_{iss} $R_{DS(ON)}$ time constant. The inherent zero offset voltage and low leakage current make these devices excellent for chopper stabilized amplifiers, sample and hold circuits, and reset switches. Low feed-through capacitance also allows them to handle video signals to 100 MHz.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|------|------|------|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -30 | -50 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 20V, V_{GS} = 0$ Pulse Test | 5.0 | 65 | 170 | mA |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = -20V, V_{DS} = 0$ | | -15 | -200 | μA |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 mV, V_{GS} = 0$ | 20 | 35 | 100 | Ω |
| Forward Transconductance | g_{fs} | $V_{DG} = 15V, I_D = 2 mA$ | | 8.5 | | mmhos |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 20V, I_D = 1 nA$ | -0.5 | -4.5 | -9.0 | V |
| Drain "OFF" Current | $I_{D(OFF)}$ | $V_{DS} = 20V, V_{GS} = -10V$ | | 15 | 200 | μA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_D = 5 mA, f = 1 MHz$ | | 3.5 | 4.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, I_D = 5 mA, f = 1 MHz$ | | 12 | 16 | pF |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 1 mA, f = 100 Hz$ | | 6.0 | | nV/\sqrt{Hz} |
| Turn-On Time | t_{on} | $V_{DD} = 10V, I_D = 6.6 mA$ | | 12 | 20 | ns |
| Turn-Off Time | t_{off} | $V_{DD} = 10V, I_D = 6.6 mA$ | | 40 | 80 | ns |

This process is available in the following device types. *Denotes preferred parts.

TO-18 (CASE 02)

2N4861
2N4861A

TO-72 (CASE 25)

2N3970
2N3971
2N3972
*2N4091
*2N4092
*2N4093
*2N4391

TO-92 (CASE 72)

*2N4392
*2N4393
*2N4856
2N4856A
*2N4857
2N4857A
*2N4858
2N4858A
2N4859
2N4859A
2N4860
2N4860A

*NF5101
*NF5102
*NF5103
*J111
*J112
*J113
*PF5101
*PF5102
*PF5103
*PN4091

*PN4092

*PN4093

*PN4391

*PN4392

*PN4393

*PN4856

*PN4857

*PN4858

*PN4859

*PN4860

*PN4861

U1897E

U1898E

U1899E

TO-92 (CASE 74)

BF246A

BF246B

BF246C

TO-92 (CASE 77)

BF247A

BF247B

BF247C

TIS73

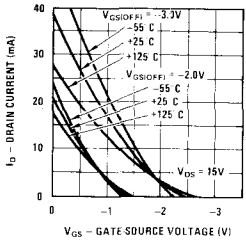
TIS74

TIS75

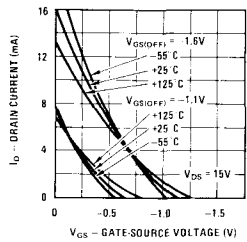
QUALIFIED PER MIL-S-19500

2N4091 JAN, JANTX
2N4092 JAN, JANTX
2N4093 JAN, JANTX, JANTXV
2N4856 JAN, JANTX, JANTXV
2N4857 JAN, JANTX, JANTXV
2N4858 JAN, JANTX, JANTXV
2N4859 JAN, JANTX, JANTXV
2N4860 JAN, JANTX, JANTXV
2N4861 JAN, JANTX, JANTXV

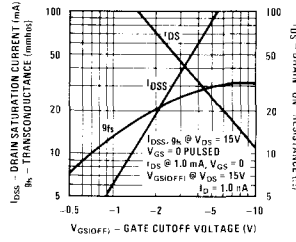
Transfer Characteristics



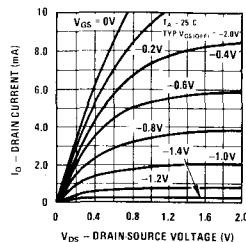
Transfer Characteristics



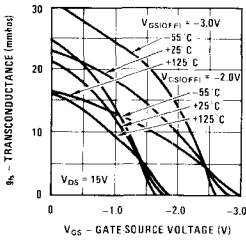
Parameter Interactions



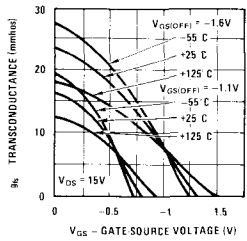
Common Drain-Source Characteristics



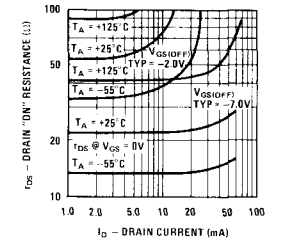
Transfer Characteristics



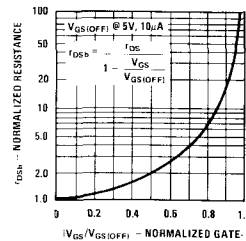
Transfer Characteristics



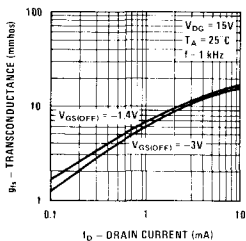
Resistance vs Drain Current



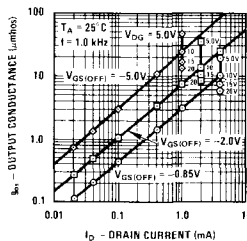
Normalized Drain Resistance vs Bias Voltage



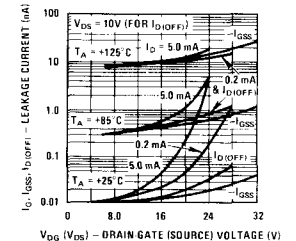
Transconductance vs Drain Current



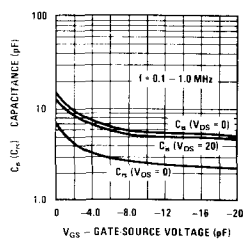
Output Conductance vs Drain Current



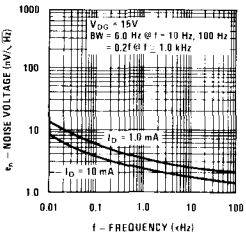
Leakage Current vs Voltage



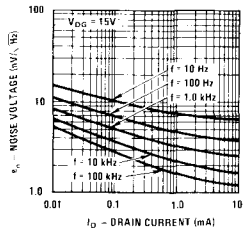
Capacitance vs Voltage



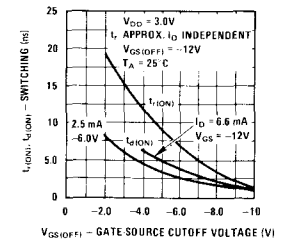
Noise Voltage vs Frequency



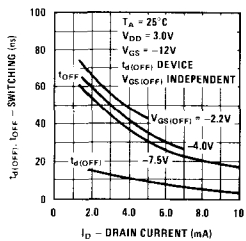
Noise Voltage vs Current



Turn-On Switching



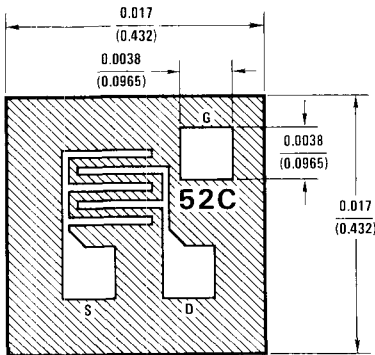
Turn-Off Switching





Process 52 N-Channel JFET

Process 52



GATE IS ALSO BACKSIDE CONTACT

DESCRIPTION

Process 52 is designed primarily for low level audio and general purpose applications. These devices provide excellent performance as input stages for piezo electric transducers or other high impedance signal sources. Their high output impedance and high voltage breakdown lend them to high gain audio and video amplifier applications. Source and drain are interchangeable.

| CHARACTERISTIC | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-------------------------------|-------------------|---|------|-----|------|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -40 | -70 | | V |
| Drain Saturation Current | I_{DSS} | $V_{DS} = 20V, V_{GS} = 0V$ | 0.2 | 1.5 | 12 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 20V, V_{GS} = 0V$ | 1.0 | 2.5 | 5.0 | mmho |
| Forward Transconductance | g_{fs} | $V_{DS} = 20V, I_D = 200 \mu A$ | | 700 | | μmho |
| Reverse Gate Leakage Current | I_{GSS} | $V_{GS} = -30V, V_{DS} = 0V$ | | -10 | | μA |
| Drain ON Resistance | r_{DS} | $V_{DS} = 100 mV, V_{GS} = 0V$ | 250 | 400 | 2000 | Ω |
| Gate Cutoff Voltage | $V_{GS(OFF), VP}$ | $V_{DS} = 15V, I_D = 1 nA$ | -0.3 | 1.0 | -8.0 | V |
| Output Conductance | g_{os} | $V_{DG} = 15V, I_D = 200 \mu A$ | | 2.0 | | μmho |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, V_{GS} = 0V, f = 1 MHz$ | | 1.3 | 1.8 | pF |
| Input Capacitance | C_{iss} | $V_{DG} = 15V, V_{GS} = 0V, f = 1 MHz$ | | 5 | 6 | pF |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 200 \mu A, f = 100 Hz$ | | 10 | | nV/\sqrt{Hz} |

This process is available in the following device types.

* Denotes preferred parts.

TO-18 (CASE 02)

2N3069
2N3070
2N3071
2N3368
2N3369
2N3370
2N3458
2N3459
2N3460
*2N4338
*2N4339
*2N4340
*2N4341

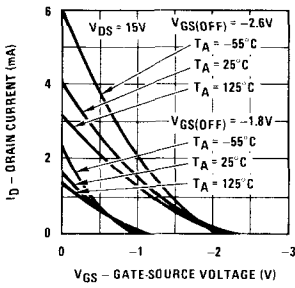
TO-72 (CASE 25)

*2N3684
*2N3685
*2N3686
*2N3687
2N3967
2N3967A
2N3968
2N3968A
2N3969
2N3969A

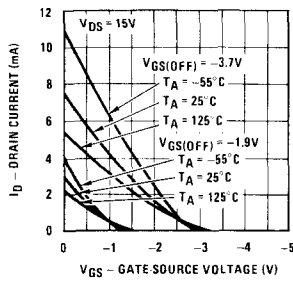
TO-92 (CASE 72)

*J201
*J202
*J203
*PN3684
*PN3685
*PN3686
*PN3687
*PN4302
*PN4303
*PN4304

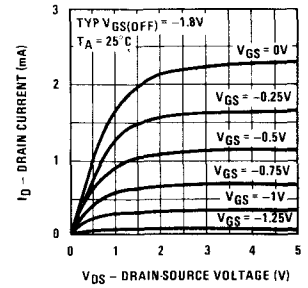
Transfer Characteristics



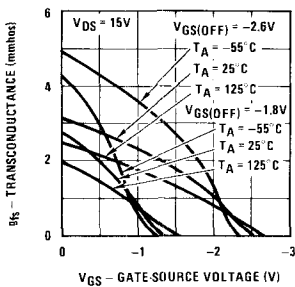
Transfer Characteristics



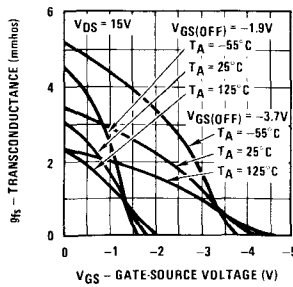
Common Drain-Source Characteristics



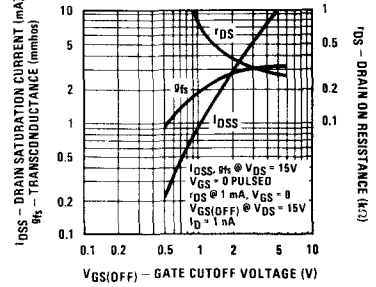
Transfer Characteristics



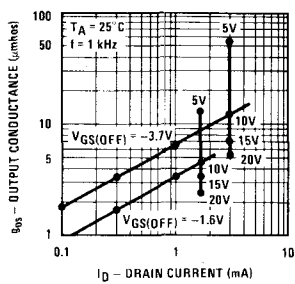
Transfer Characteristics



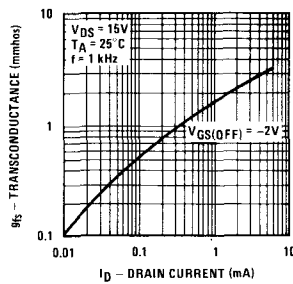
Parameter Interactions



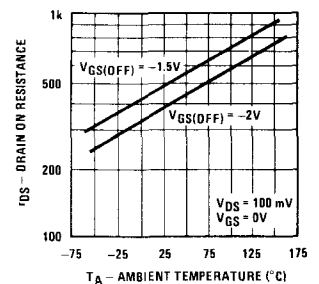
Output Conductance vs Drain Current



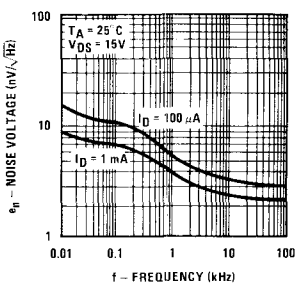
Transconductance vs Drain Current



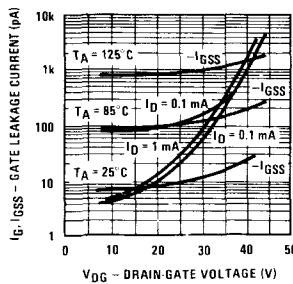
Channel Resistance vs Temperature



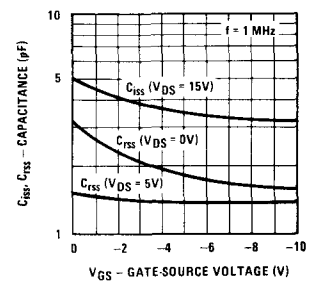
Noise Voltage vs Frequency



Leakage Current vs Voltage



Capacitance vs Voltage



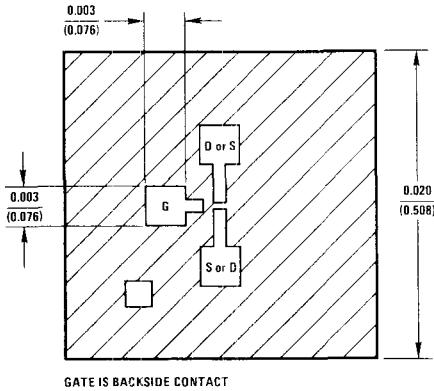


Process 53 N-Channel JFET

Process 53

DESCRIPTION

Process 53 is designed primarily for low current DC and audio applications. These devices provide excellent performance as input stages for sub pico-amp instrumentation or any high impedance signal sources.

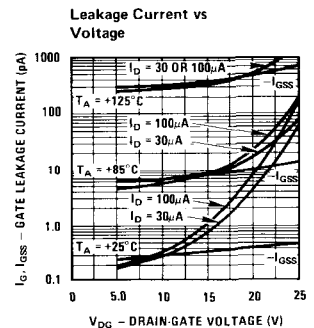
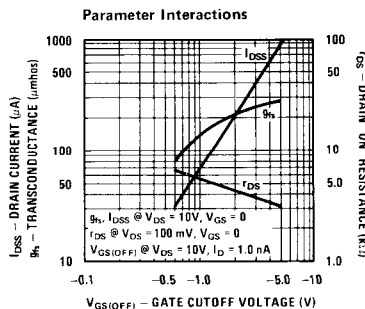


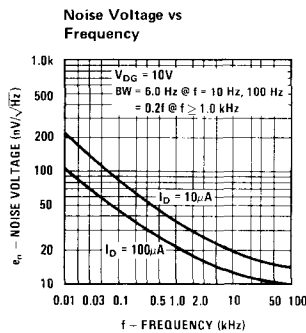
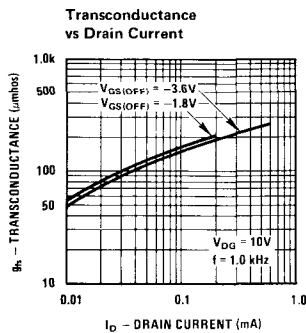
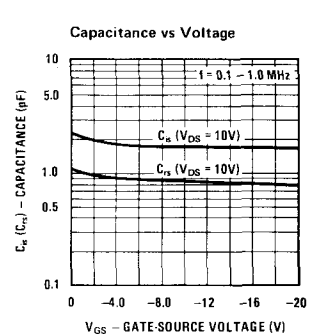
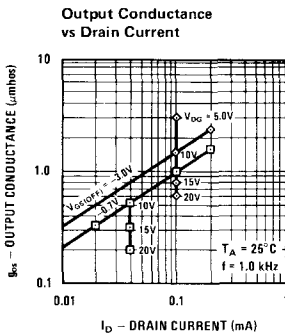
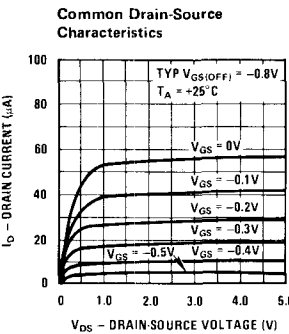
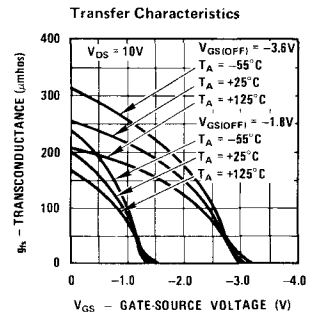
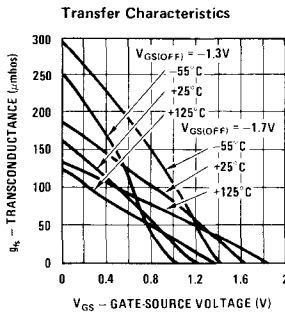
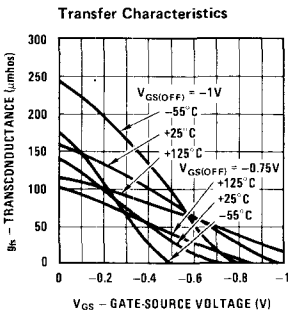
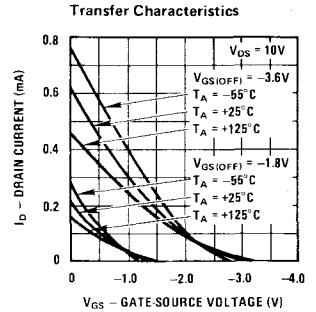
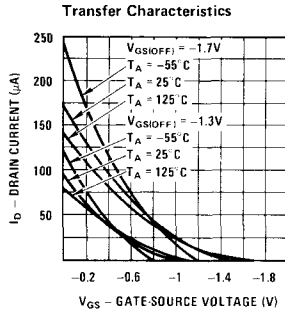
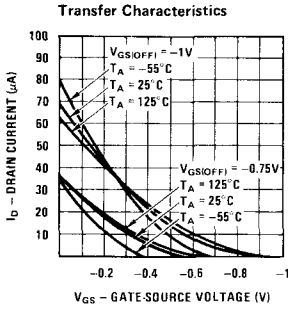
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|------|------|------|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -40 | -60 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 10V, V_{GS} = 0$ | 0.02 | 0.25 | 1.0 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 10V, V_{GS} = 0$ | 80 | 250 | 350 | μmho |
| Forward Transconductance | g_{fs} | $V_{DG} = 15V, I_D = 50 \mu A$ | | 120 | | μmho |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = -20V, V_{DS} = 0$ | | -0.3 | -10 | pA |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 10V, I_D = 1 nA$ | -0.5 | -2.2 | -6.0 | V |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, V_{GS} = 0, f = 1 MHz$ | | 0.85 | 1.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | | 2.0 | 2.5 | pF |
| Output Conductance | g_{os} | $V_{DG} = 10V, I_D = 50 \mu A$ | | 0.9 | 5.0 | $\mu mhos$ |
| Noise Voltage | e_n | $V_{DG} = 10V, I_D = 50 \mu A, f = 100 Hz$ | | 45 | 150 | nV/\sqrt{Hz} |

This process is available in the following device types.
* Denotes preferred parts.

TO-72 (CASE 25)

- 2N4117
- *2N4117A
- 2N4118
- *2N4118A
- 2N4119
- *2N4119A
- *NF5301

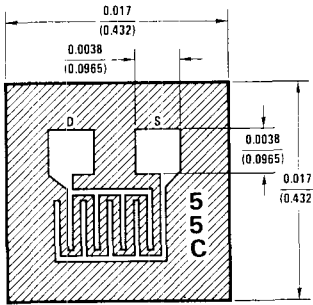






Process 55 N-Channel JFET

Process 55



DESCRIPTION

Process 55 is a general purpose low level audio amplifier and switching transistor. Wafer processing is similar to process 52 but process 55 uses a larger geometry. This results in higher Y_{fs} , I_{DSS} , and capacitance and lower $R_{DS(ON)}$. It is useful for audio and video frequency amplifiers and RF amplifiers under 50 MHz. It may also be used for analog switching applications.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---|------|------|------|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -40 | -70 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 20V, V_{GS} = 0$ | 0.5 | 5.0 | 20 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 20V, V_{GS} = 0$ | 2.0 | 4.5 | 7.0 | mmho |
| Forward Transconductance | g_{fs} | $V_{DG} = 15V, I_D = 200 \mu A$ | | 1200 | | $\mu mhos$ |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = -30V, V_{DS} = 0$ | | -10 | -100 | pA |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 mV, V_{GS} = 0$ | 140 | 250 | 600 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 20V, I_D = 1 nA$ | -0.5 | -2.0 | -8.0 | V |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, V_{GS} = 0, f = 1 MHz$ | | 1.5 | 2.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | | 6.0 | 7.0 | pF |
| Output Conductance | g_{os} | $V_{DG} = 15V, I_D = 200 \mu A$ | | 2 | | $\mu mhos$ |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 200 \mu A, f = 100 Hz$ | | 10 | | nV/\sqrt{Hz} |

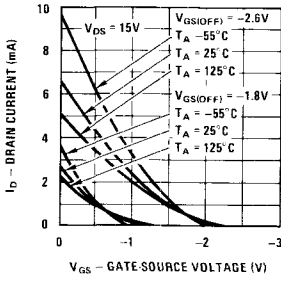
This process is available in the following device types. *Denotes preferred parts.

TO-18 (CASE 02)
 *2N5361
 2N3436 *2N5362
 2N3437 *2N5363
 2N3438 *2N5364

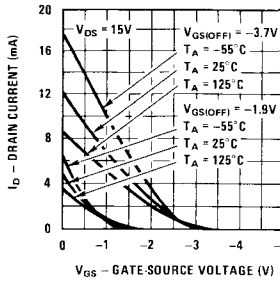
TO-72 (CASE 25) **TO-92 (CASE 72)**
 2N3821 *2N5457
 2N3822 *2N5458
 2N3824 *2N5459
 2N4220 MPF 103
 2N4220A MPF 104
 2N4221 MPF 105
 2N4221A MPF 108
 2N4222 MPF 109
 2N4222A MFF 112
 *2N5358 PN4220
 *2N5359 PN4221
 *2N5360 PN4222



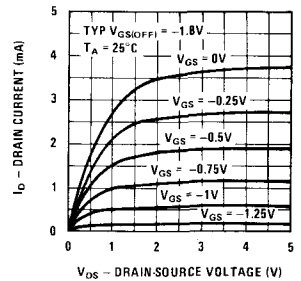
Transfer Characteristics



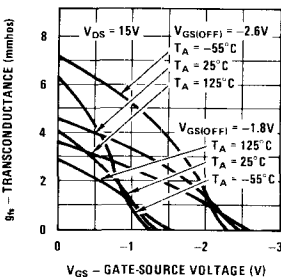
Transfer Characteristics



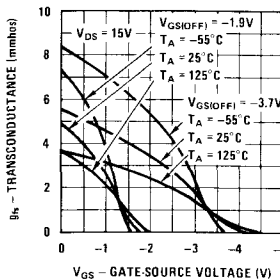
Common Drain-Source Characteristics



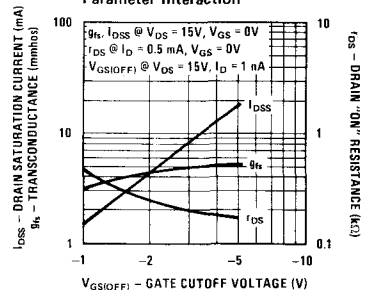
Transfer Characteristics



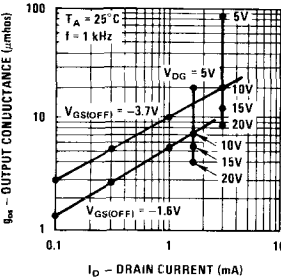
Transfer Characteristics



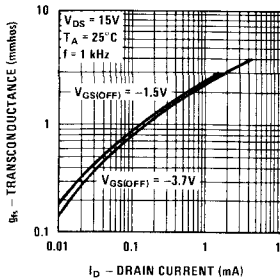
Parameter Interaction



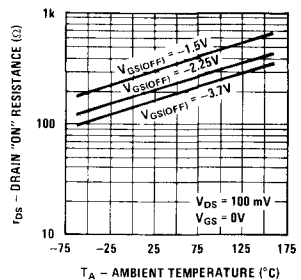
Output Conductance vs Drain Current



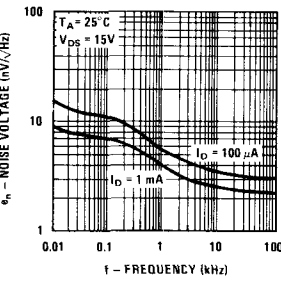
Transconductance vs Drain Current



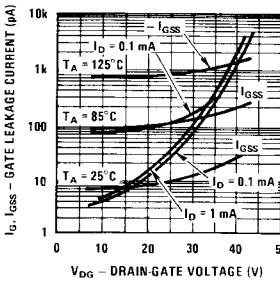
Channel Resistance vs Temperature



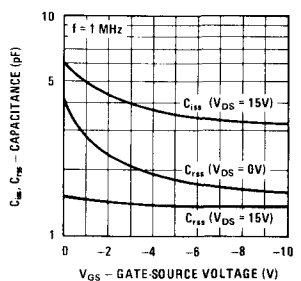
Noise Voltage vs Frequency



Leakage Current vs Voltage



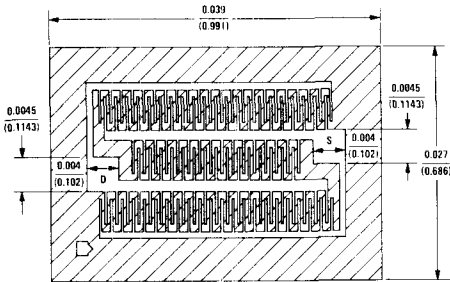
Capacitance vs Voltage





DESCRIPTION

Process 58 was developed for analog or digital switching applications where very low $r_{DS(ON)}$ is mandatory. Switching times are very fast and $R_{DS(ON)} C_{iss}$ time constant is low. The 6Ω typical on resistance is very useful in precision multiplex systems where switch resistance must be held to an absolute minimum. With r_{DS} increasing only 0.7%/°C, accuracy is retained over a wide temperature excursion.



GATE IS BACKSIDE CONTACT

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|------|------|------|-----------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1\mu A$ | -25 | -30 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 5V, V_{GS} = 0$ Pulse Test | 100 | 400 | 1000 | mA |
| Reverse Gate Leakage | I_{GSS} | $V_{GS} = -15V, V_{DS} = 0$ | | -50 | -500 | pA |
| "ON" Resistance | r_{DS} | $V_{DS} = 100\text{ mV}, V_{GS} = 0$ | 3.0 | 6.0 | 20 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 5V, I_D = 3\text{ nA}$ | -0.5 | -5.0 | -12 | V |
| Drain "OFF" Current | $I_{D(OFF)}$ | $V_{DS} = 5V, V_{GS} = -10V$ | | 0.05 | 20 | nA |
| Feedback Capacitance | C_{rss} | $V_{DG} = 15V, I_D = 2\text{ mA}, f = 1\text{ MHz}$ | | 12 | 25 | pF |
| Input Capacitance | C_{iss} | $V_{DG} = 15V, I_D = 2\text{ mA}, f = 1\text{ MHz}$ | | 25 | 50 | pF |
| Forward Trans-conductance | g_{fs} | $V_{DG} = 10V, I_D = 2\text{ mA}$ | | 10 | | mmhos |
| Output Conductance | g_{os} | $V_{DG} = 10V, I_D = 2\text{ mA}$ | | 100 | | μmhos |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 2\text{ mA}, f = 100\text{ Hz}$ | | 6.0 | | $nV/\sqrt{\text{Hz}}$ |

This process is available in the following device types. *Denotes preferred parts.

TO-39 (CASE 09)

- U320
- U321
- U322

TO-52 (CASE 07)

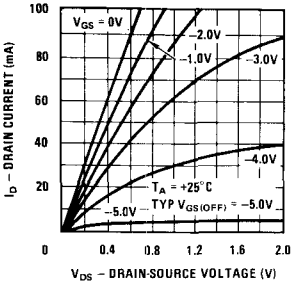
- *2N5432
- *2N5433
- *2N5434

TO-92 (CASE 72)

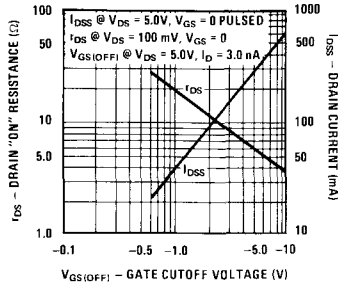
- *J108
- *J109
- *J110



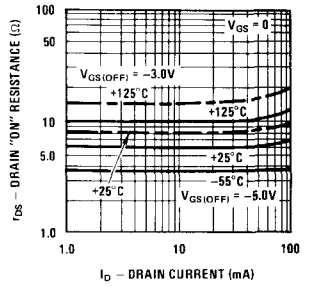
Common Drain-Source Characteristics



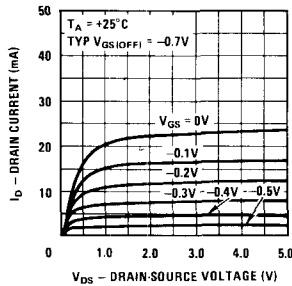
Parameter Interactions



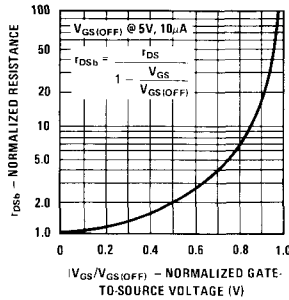
"ON" Resistance vs Drain Current



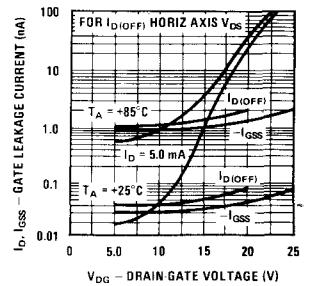
Common Drain-Source Characteristics



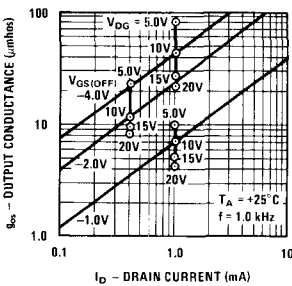
Normalized Drain Resistance vs Bias Voltage



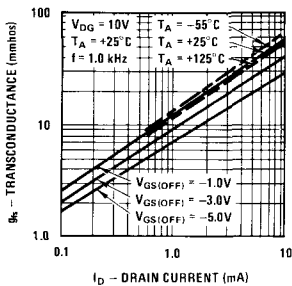
Leakage Current vs Voltage



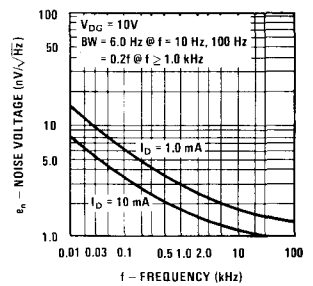
Output Conductance vs Drain Current



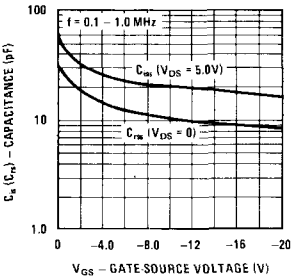
Transconductance vs Drain Current



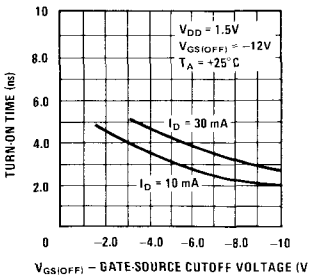
Noise Voltage vs Frequency



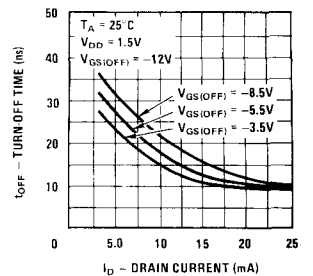
Capacitance vs Voltage



Switching Turn-On vs Gate-Source Voltage



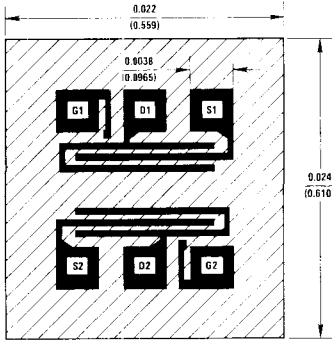
Switching Turn-Off Time vs Drain Current





Process 83 N-Channel Monolithic Dual JFET

Process 83



DESCRIPTION

Process 83 is a monolithic dual JFET with a diode isolated substrate. It is intended for operational amplifier input buffer applications. Processing results in low input bias current and virtually unmeasurable offset current. Likewise matching characteristics are virtually independent of operating current and voltage, providing design flexibility. Most GP 2N types are sorted from this family.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|-----------------------|--|------|------|------|------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -50 | -70 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 0.5 | 2.5 | 8.0 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 1.0 | 2.5 | 5.0 | mmho |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 nA$ | -0.5 | -2.0 | -4.5 | V |
| Gate Current | I_G | $V_{DG} = 20V, I_D = 0.2 mA$ | | 3.0 | 50 | pA |
| Forward Transconductance | g_{fs} | $V_{DG} = 15V, I_D = 0.2 mA$ | 600 | 850 | | $\mu mhos$ |
| Output Conductance | g_{os} | $V_{DG} = 15V, I_D = 0.2 mA$ | | 1.0 | 5.0 | $\mu mhos$ |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 mV, V_{GS} = 0$ | | 450 | | Ω |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 0.2 mA$ $f = 100 Hz$ | | 10 | 50 | nV/\sqrt{Hz} |
| Differential Match | $ V_{GS1} - V_{GS2} $ | $V_{DG} = 15V, I_D = 0.2 mA$ | | 7.0 | 25 | mV |
| Differential Match | ΔV_{GS1-2} | $V_{DG} = 15V, I_D = 0.2 mA$ | | 10 | 50 | $\mu V/^\circ C$ |
| Common Mode Rejection | CMRR | $V_{DG} = 15V, I_D = 0.2 mA$ | 80 | 95 | | dB |
| Feedback Capacitance | C_{rs} | $V_{DG} = 15V, I_D = 0.2 mA,$ $f = 1 MHz$ | | 1.0 | 1.2 | pF |
| Input Capacitance | C_{is} | $V_{DG} = 15V, I_D = 0.2 mA,$ $f = 1 MHz$ | | 3.4 | 4.0 | pF |

This process is available in the following device types. *Denotes preferred parts.

TO-71 (CASE 12)

| | | |
|----------|---------|------|
| 2N3921 | 2N5047 | U233 |
| 2N3922 | *2N5196 | U234 |
| *2N3954 | *2N5197 | U235 |
| *2N3954A | *2N5198 | |
| *2N3955 | *2N5199 | |
| *2N3955A | 2N5452 | |
| *2N3956 | 2N5453 | |
| *2N3957 | 2N5454 | |
| *2N3958 | *2N5545 | |
| 2N4084 | *2N5546 | |
| 2N4085 | *2N5547 | |
| 2N5045 | U231 | |
| 2N5046 | U232 | |

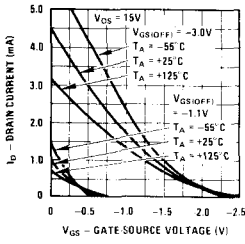
8-Pin MiniDIP (CASE 60)

| |
|------|
| J410 |
| J411 |
| J412 |

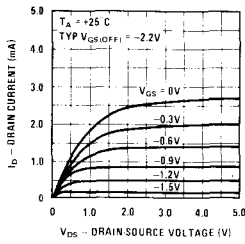
8-Pin MiniDIP (CASE 67)

| |
|----------|
| *NPD8301 |
| *NPD8302 |
| *NPD8303 |

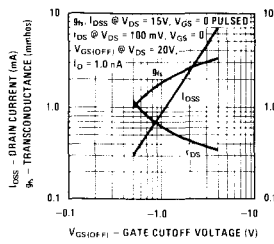
Transfer Characteristics



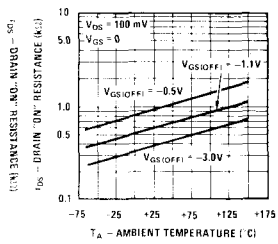
Common Drain-Source Characteristics



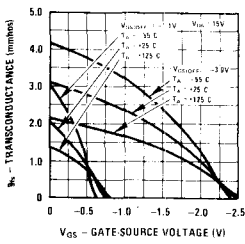
Parameter Interactions



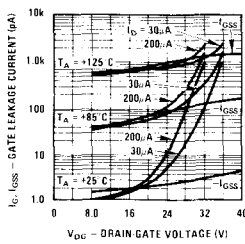
Channel Resistance vs Temperature



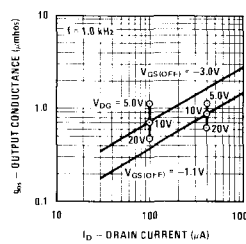
Transfer Characteristics



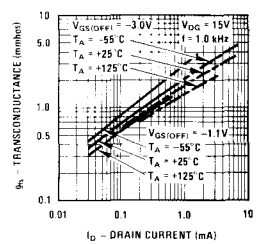
Leakage Current vs Voltage



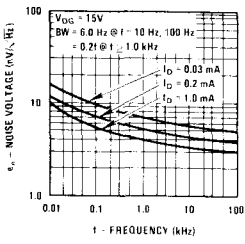
Output Conductance vs Drain Current



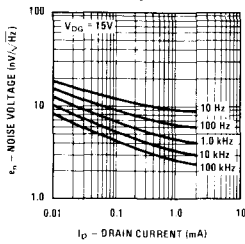
Transconductance vs Drain Current



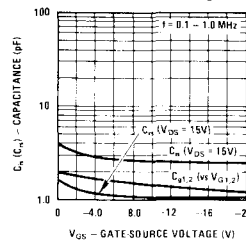
Noise Voltage vs Frequency



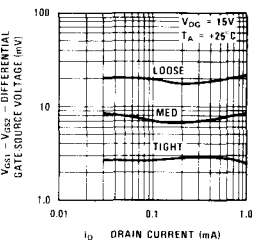
Noise Voltage vs Current



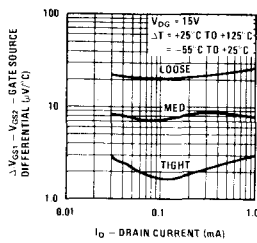
Capacitance vs Voltage



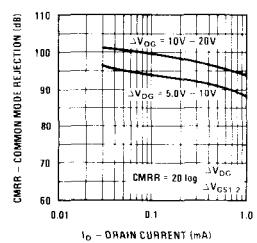
Differential Offset



Differential Drift



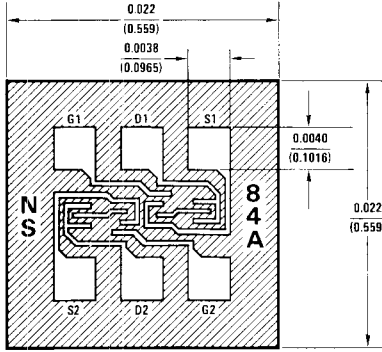
CMRR vs Drain Current





Process 84 N-Channel Monolithic Dual JFET

Process 84



DESCRIPTION

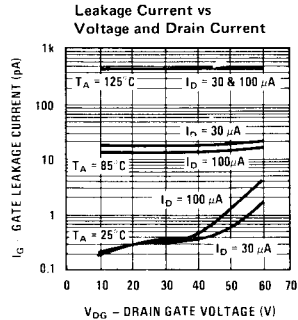
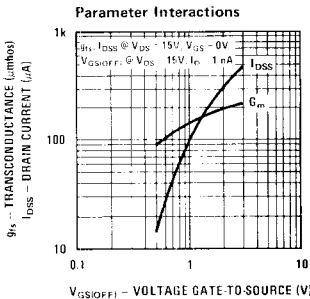
Process 84 is a monolithic dual JFET with a diode isolated substrate. It is designed for the most critical operational amplifier input stages or electrometer single ended preamp. Ideal for medical applications and instrumentation inputs where subpicoamp inputs are important. Device design considered high CMRR, subpicoamp leakage over wide input swings, low capacitance, and tight match over wide current range.

| CHARACTERISTIC | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|--|-----------------------|---|-----|------|------|------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -40 | -60 | | V |
| Drain Saturation Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0V$ | 20 | 300 | 1000 | μA |
| Forward Transconductance | g_{fs} | $V_{DS} = 15V, V_{GS} = 0V$ | 90 | 180 | 300 | $\mu mhos$ |
| Forward Transconductance | g_{fs} | $V_{DS} = 15V, I_D = 30 \mu A$ | 50 | 120 | 150 | $\mu mhos$ |
| Gate Cutoff Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 nA$ | 0.5 | 2 | 4.5 | V |
| Reverse Gate Leakage Current | I_{GSS} | $V_{DS} = 0V, V_{GS} = -20V$ | | 1 | 5 | μA |
| Gate Leakage Current | I_G | $V_{DG} = 10V, I_D = 30 \mu A$ | | 0.5 | 3 | μA |
| Feedback Capacitance | C_{rss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | | 0.3 | 0.4 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | | 2 | 3 | pF |
| Noise Voltage | e_n | $V_{DS} = 15V, I_D = 30 \mu A, f = 1 kHz$ | | 30 | 50 | nV/\sqrt{Hz} |
| Noise Voltage | e_n | $V_{DS} = 15V, I_D = 30 \mu A, f = 10 Hz$ | | 180 | | nV/\sqrt{Hz} |
| Output Conductance | g_{os} | $V_{DS} = 10V, I_D = 30 \mu A$ | | 0.01 | 0.02 | $\mu mhos$ |
| Differential Gate-Source Voltage | $ V_{GS1} - V_{GS2} $ | $V_{DS} = 10V, I_D = 30 \mu A$ | | 12 | 25 | mV |
| Differential Gate-Source Voltage Drift | ΔV_{GS1-2} | $V_{DS} = 10V, I_D = 30 \mu A$ | | 10 | 50 | $\mu V/^\circ C$ |
| Common-Mode Rejection Ratio | CMRR | $V_{DS} = 10V, I_D = 30 \mu A$ | | 112 | | dB |

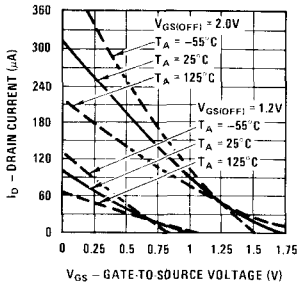
This process is available in the following device types. * Denotes preferred parts.

TO-78 (CASE 24)

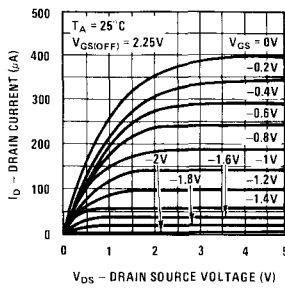
- | | |
|--------|---------|
| 2N5902 | *2N5906 |
| 2N5903 | *2N5907 |
| 2N5904 | *2N5908 |
| 2N5905 | *2N5909 |



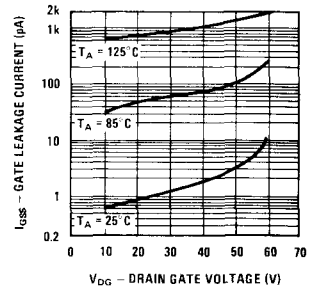
Transfer Characteristics



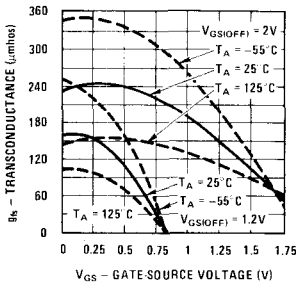
Common Drain-Source Characteristics



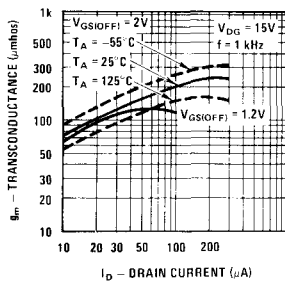
Leakage Current vs Voltage



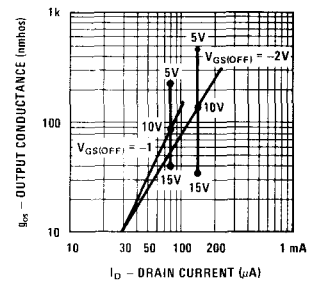
Transfer Characteristics



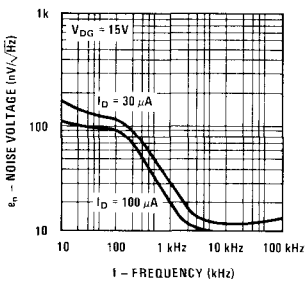
Transconductance vs Drain Current



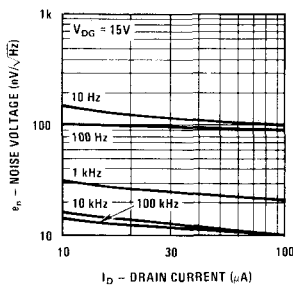
Output Conductance vs Drain Current



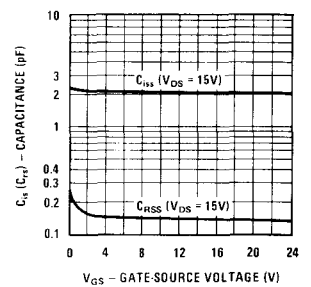
Noise Voltage vs Frequency



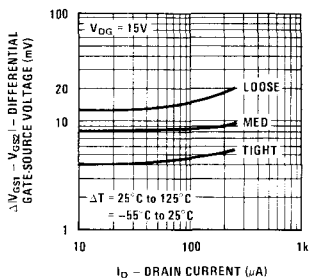
Noise Voltage vs Current



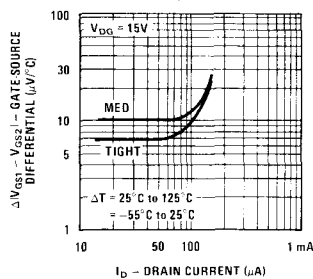
Capacitance vs Voltage



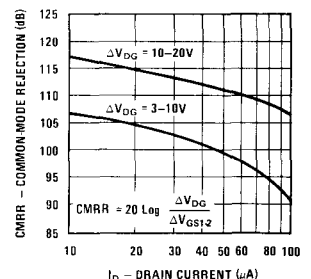
Differential Offset



Differential Drift



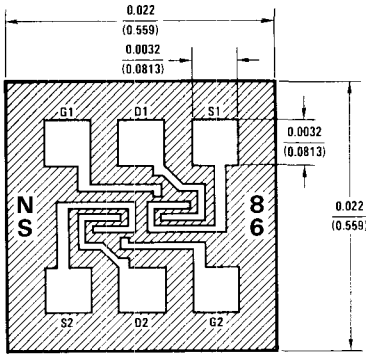
CMRR vs Drain Current





Process 86 N-Channel Monolithic Dual JFET

Process 86



DESCRIPTION

Process 86 is a monolithic dual JFET with a diode isolated substrate. It is intended for critical amplifier input stages requiring low noise, sub picoamp bias currents and high gain. Exacting process control results in consistent parameter distribution with tight match and low drift.

This process is available in the following device types.
*Denotes preferred parts.

TO-78 (CASE 24)

- U421
- U422
- U423
- U424
- U425
- U426

PROCESS IN DEVELOPMENT

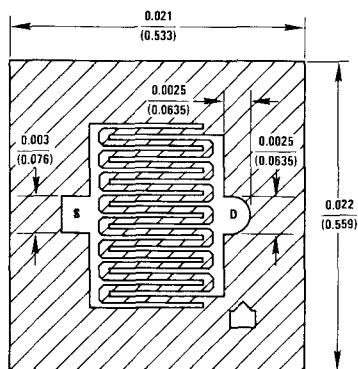
9



Process 88 P-Channel JFET

DESCRIPTION

Process 88 is designed primarily for electronic switching applications where a P channel device is desirable. Inherent zero offset voltage, low leakage and low $R_{DS(ON)}$ C_{iss} time constant make this device excellent for low level analog switching, sample and hold circuits and chopper stabilized amplifiers. This device is the complement to Process 51.



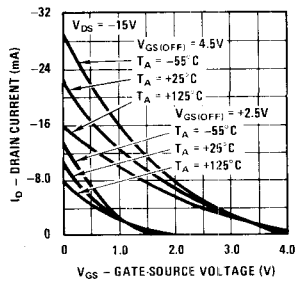
GATE IS BACKSIDE CONTACT

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|------|-------|-----|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 30 | 40 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -15V, V_{GS} = 0$ | -5.0 | -30 | -90 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = -15V, V_{GS} = 0$ | 4.0 | 13 | 17 | mmhos |
| Forward Transconductance | g_{fs} | $V_{DG} = -15V, I_D = -2 mA$ | | 3.5 | | mmhos |
| Gate Leakage | I_{GSS} | $V_{GS} = 20V, V_{DS} = 0$ | | 0.05 | 1.0 | nA |
| "ON" Resistance | r_{DS} | $V_{DS} = -100 mV, V_{GS} = 0$ | 50 | 80 | 200 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = -15V, I_D = -1 nA$ | 0.5 | 5.0 | 10 | V |
| Drain "OFF" Current | $I_{D(OFF)}$ | $V_{DS} = -15V, V_{GS} = 10V$ | | -0.05 | -10 | nA |
| Feedback Capacitance | C_{rss} | $V_{DG} = -15V, I_D = -2 mA, f = 1 MHz$ | | 4.0 | 5.0 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = -15V, I_D = -2 mA, f = 1 MHz$ | | 14 | 15 | pF |
| Output Conductance | g_{os} | $V_{DG} = -15V, I_D = -2 mA$ | | 100 | 300 | $\mu mhos$ |
| Noise Voltage | e_n | $V_{DG} = -15V, I_D = -2 mA, f = 100 Hz$ | | 20 | | nV/\sqrt{Hz} |

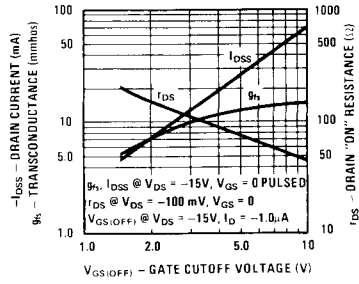
This process is available in the following device types. *Denotes preferred parts.

| | | |
|------------------------|------------------------|----------------------------------|
| TO-18 (CASE 11) | TO-72 (CASE 23) | TO-92 (CASE 74) |
| 2N2609 | 2N3382 | *J174 |
| 2N5018 | 2N3384 | *J175 |
| 2N5019 | 2N3386 | *J176 |
| *2N5114 | 2N3993 | *J177 |
| *2N5115 | 2N3993A | *J270 |
| *2N5116 | 2N3994 | *J271 |
| U301 | 2N3994A | |
| U304 | | |
| U305 | TO-92 (CASE 71) | QUALIFIED PER MIL-S-19500 |
| U306 | P1086E | *2N5114JAN, JANTX, JANTXV |
| | P1087E | *2N5115JAN, JANTX, JANTXV |
| | | *2N5116JAN, JANTX, JANTXV |

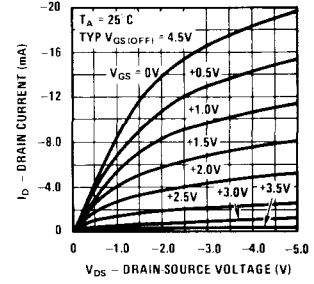
Transfer Characteristics



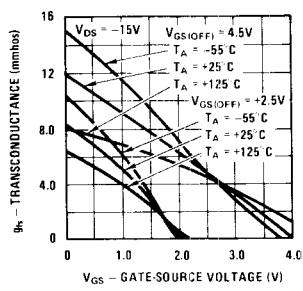
Parameter Interactions



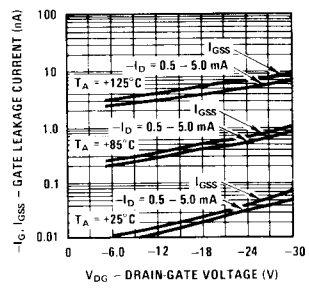
Common Drain-Source Characteristics



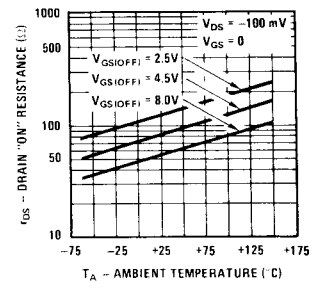
Transfer Characteristics



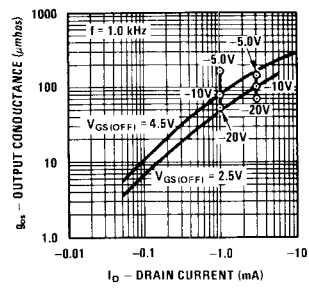
Leakage Current vs Voltage



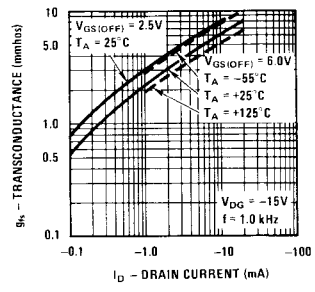
Channel Resistance vs Temperature



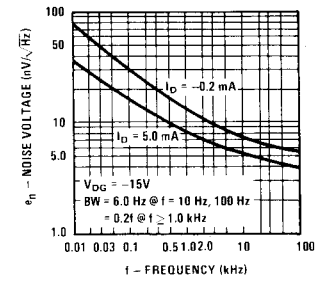
Output Conductance vs Drain Current



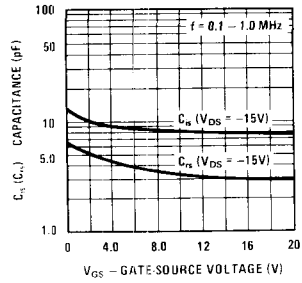
Transconductance vs Drain Current



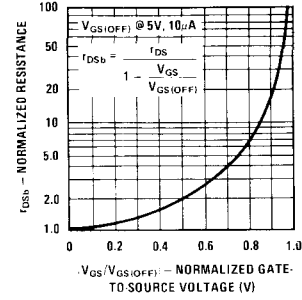
Noise Voltage vs Frequency



Capacitance vs Voltage



Normalized Drain Resistance vs Bias Voltage

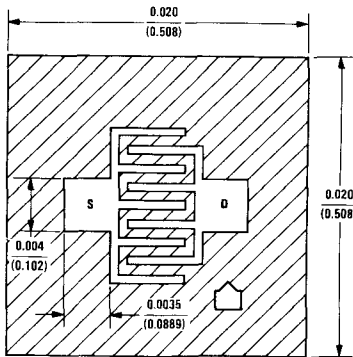




Process 89 P-Channel JFET

DESCRIPTION

Process 89 is designed primarily for low level amplifier applications. This device is the complement to Process 55. Commonly used in voltage variable resistor applications.



GATE IS BACKSIDE CONTACT

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|------|------|-----|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = 1 \mu A$ | 20 | 40 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -15V, V_{GS} = 0$ | -0.3 | -4.0 | -20 | mA |
| Forward Trans-conductance | g_{fs} | $V_{DS} = -15V, V_{GS} = 0$ | 1.0 | 2.5 | 4.0 | mmhos |
| Forward Trans-conductance | g_{fs} | $V_{DG} = -15V, I_D = -0.2 mA$ | | 700 | | $\mu mhos$ |
| Gate Leakage | I_{GSS} | $V_{GS} = 20V, V_{DS} = 0$ | | 0.02 | 1.0 | nA |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = -15V, I_D = -1 nA$ | 0.5 | 3.0 | 9.0 | V |
| Feedback Capacitance | C_{rss} | $V_{DG} = -15V, V_{GS} = 0, f = 1 MHz$ | | 2.0 | 2.5 | pF |
| Input Capacitance | C_{is} | $V_{DS} = -15V, I_D = -2 mA, f = 1 MHz$ | | 7.0 | 8.5 | pF |
| "ON" Resistance | r_{DS} | $V_{DS} = -100 mV, V_{GS} = 0$ | | 450 | | Ω |
| Output Conductance | g_{os} | $V_{DG} = -15V, I_D = -0.2 mA$ | | 5.0 | 15 | $\mu mhos$ |
| Noise Voltage | e_n | $V_{DG} = -15V, I_D = -0.2 mA, f = 100 Hz$ | | 30 | | nV/\sqrt{Hz} |

This process is available in the following device types. *Denotes preferred parts.

TO-18 (CASE 11)

2N2608
2N4381
2N5020
2N5021

TO-92 (CASE 71)

*2N5460
*2N5461
*2N5462
PN4342
PN4360
PN5033

TO-92 (CASE 74)

2N3820

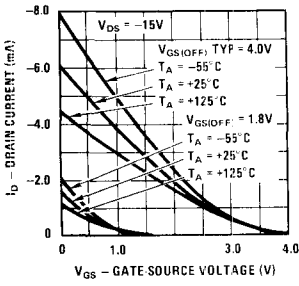
QUALIFIED PER MIL-S-19500

2N2608JAN

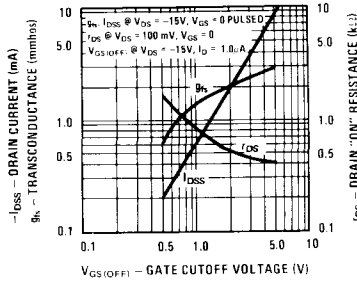
TO-72 (CASE 23)

2N3329
2N3330
2N3331
2N3332

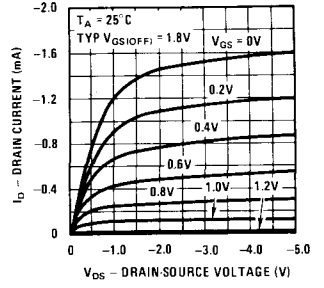
Transfer Characteristics



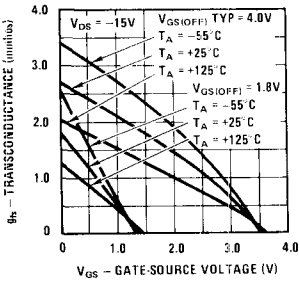
Parameter Interactions



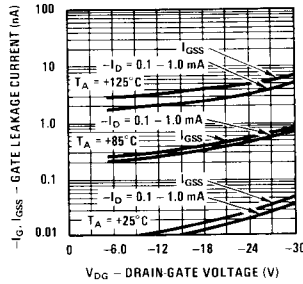
Common Drain-Source Characteristics



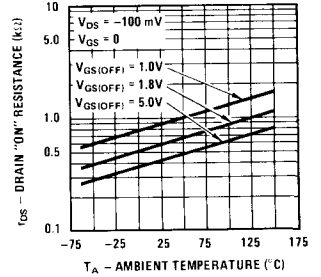
Transfer Characteristics



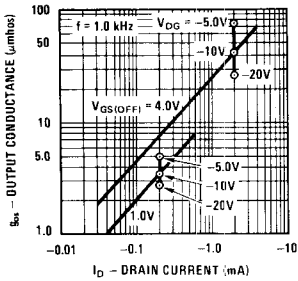
Leakage Current vs Voltage



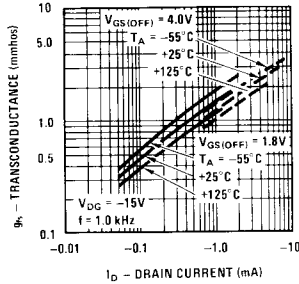
Channel Resistance vs Temperature



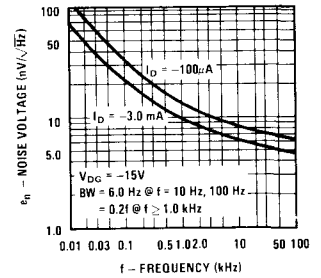
Output Conductance vs Drain Current



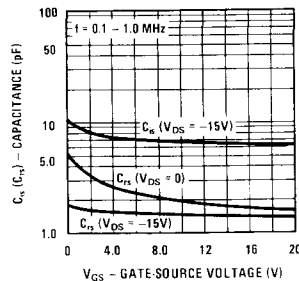
Transconductance vs Drain Current



Noise Voltage vs Frequency

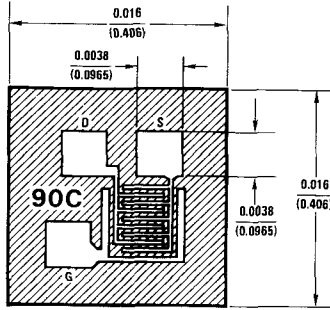


Capacitance vs Voltage





Process 90 N-Channel JFET



GATE IS ALSO BACKSIDE CONTACT

DESCRIPTION

Process 90 is designed for VHF/UHF mixer/amplifier and applications where Process 50 is not adequate. Has sufficient gain and low noise, common gate configuration at 450 MHz, for sensitive receivers. The high transconductance and square law characteristics insures low crossmodulation and intermodulation distortions. Common-gate operation simplifies circuitry. Consider Process 92 for even higher performance.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|---|------|------|------|----------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -20 | -30 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 10V, V_{GS} = 0$ | 3 | 18 | 40 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 10V, V_{GS} = 0$ | 5.5 | 8.0 | 10 | mmhos |
| Forward Transconductance | g_{fs} | $V_{DS} = 10V, I_D = 5 mA$ | 4.5 | 5.8 | | mmhos |
| Reverse Gate Current | I_{GSS} | $V_{GS} = -15V, V_{DS} = 0$ | | -5.0 | -100 | pA |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 mV, V_{GS} = 0$ | | 90 | | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 10V, I_D = 1 nA$ | -1.5 | -3.5 | -6.0 | V |
| Output Conductance | g_{os} | $V_{DG} = 10V, I_D = 5 mA$ | | 45 | 100 | $\mu mhos$ |
| Feedback Capacitance | C_{rs} | $V_{DG} = 10V, I_D = 5 mA$ | | 1.0 | 1.2 | pF |
| Input Capacitance | C_{is} | $V_{DG} = 10V, I_D = 5 mA$ | | 4.0 | 5.0 | pF |
| Noise Voltage | e_n | $V_{DG} = 10V, I_D = 5 mA, f = 100 Hz$ | | 13 | | nV/\sqrt{Hz} |
| Noise Figure | NF | $V_{DG} = 10V, I_D = 5 mA, f = 450 MHz$ | | 3.0 | | dB |
| Power Gain | $G_{pg} (CG)$ | $V_{DG} = 10V, I_D = 5 mA, f = 450 MHz$ | | 11 | | dB |

This process is available in the following device types. *Denotes preferred parts.

TO-52 (CASE 07)

U312

TO-72 (CASE 29)

*2N5397
2N5398

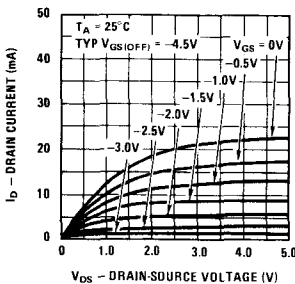
TO-92 (CASE 72)

J114
*J210
*J211
*J212
*J300

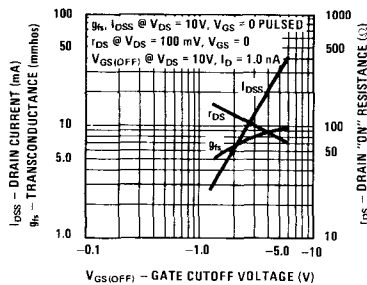
TO-92 (CASE 77)

*2N5245
*2N5246
*2N5247

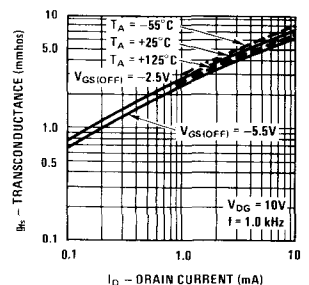
Common Drain-Source Characteristics



Parameter Interactions



Transconductance vs Drain Current

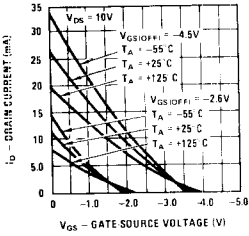


Process 90

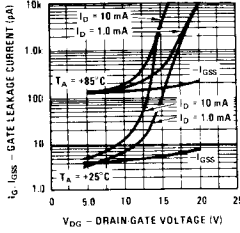
COMMON SOURCE

COMMON GATE

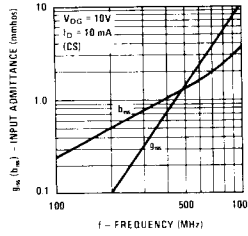
Transfer Characteristics



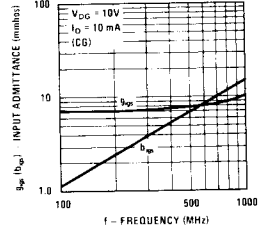
Leakage Current vs Voltage



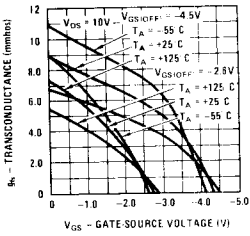
Input Admittance



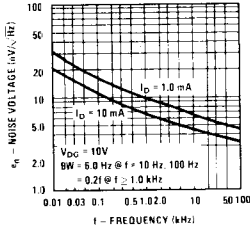
Input Admittance



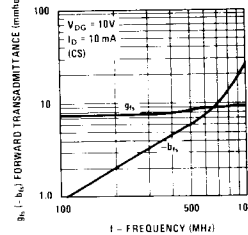
Transfer Characteristics



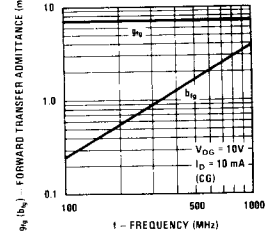
Noise Voltage vs Frequency



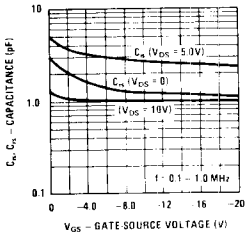
Forward Transadmittance



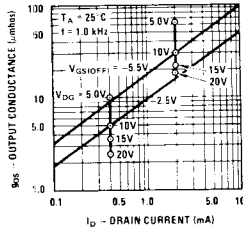
Forward Transadmittance



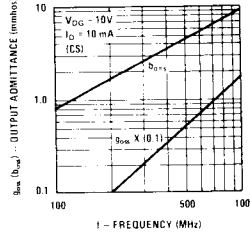
Capacitance vs Voltage



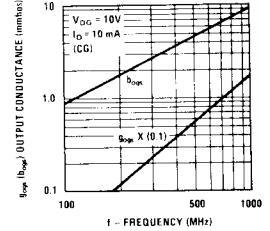
Output Conductance vs Drain Current



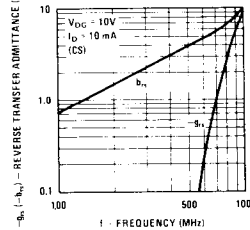
Output Admittance



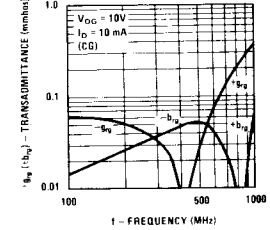
Output Admittance



Reverse Transadmittance

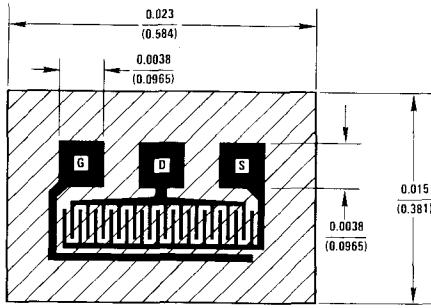


Reverse Transadmittance





Process 92 N-Channel JFET



DESCRIPTION

Process 92 is designed for VHF/UHF amplifier, oscillator, and mixer applications. As a common gate amplifier, 16 dB at 100 MHz and 12 dB at 450 MHz can be realized. Worst case 75 ohm input impedance provides ideal input match.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|---------------|--|------|------|------|-----------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -20 | -30 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 10V, V_{GS} = 0$, Pulsed | 10 | 38 | 80 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 10V, V_{GS} = 0$, Pulsed | | 19 | | mmhos |
| Forward Transconductance | g_{fs} | $V_{DG} = 10V, I_D = 10 \text{ mA}$ | 10 | 13 | 18 | mmhos |
| Reverse Gate Current | I_{GSS} | $V_{GS} = -15V, V_{DS} = 0$ | | -15 | -100 | pA |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 \text{ mV}, V_{GS} = 0$ | 35 | 45 | 80 | Ω |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 10V, I_D = 1 \text{ nA}$ | -1.5 | -4.0 | -6.5 | V |
| Output Conductance | g_{os} | $V_{DG} = 10V, I_D = 10 \text{ mA}$ | | 160 | 250 | μmhos |
| Feedback Capacitance | C_{gd} | $V_{DG} = 10V, I_D = 10 \text{ mA}, f = 1 \text{ MHz}$ | | 2.0 | 2.5 | pF |
| Input Capacitance | C_{gs} | $V_{DG} = 10V, I_D = 10 \text{ mA}, f = 1 \text{ MHz}$ | | 4.1 | 5.0 | pF |
| Noise Voltage | e_n | $V_{DG} = 10V, I_D = 10 \text{ mA}, f = 100 \text{ Hz}$ | | 6.0 | | $nV/\sqrt{\text{Hz}}$ |
| Noise Figure | NF | $V_{DG} = 10V, I_D = 10 \text{ mA}, f = 450 \text{ MHz}$ | | 3.0 | | dB |
| Power Gain | G_{pg} | $V_{DG} = 10V, I_D = 10 \text{ mA}, f = 450 \text{ MHz}$ | | 12 | | dB |

This process is available in the following device types. * Denotes preferred parts.

TO-52 (CASE 07)

- U308
- *U309
- *U310

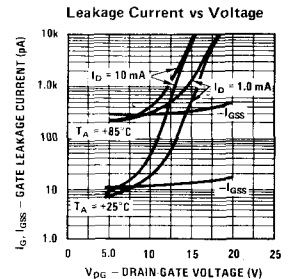
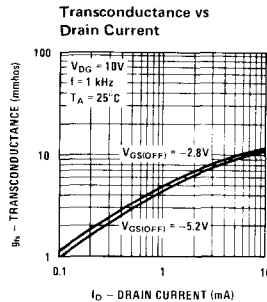
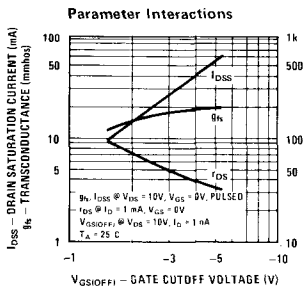
TO-99 (CASE 24)

- U430
- U431

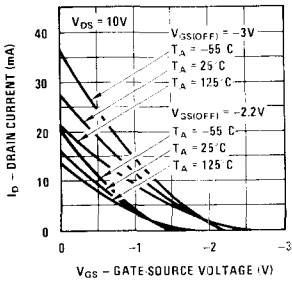
} Dual

TO-92 (CASE 72)

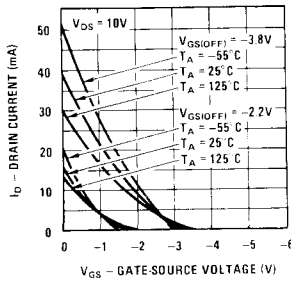
- J308
- *J309
- *J310



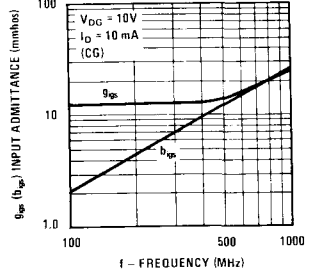
Transfer Characteristics



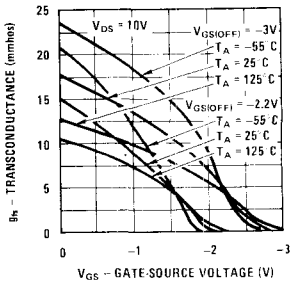
Transfer Characteristics



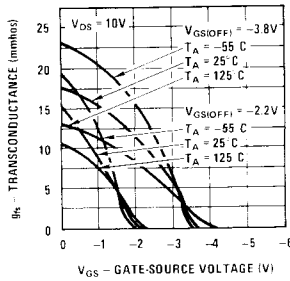
Input Admittance



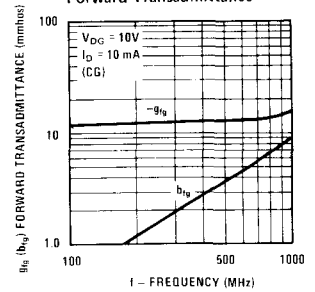
Transfer Characteristics



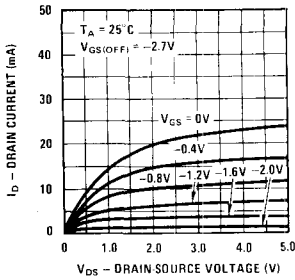
Transfer Characteristics



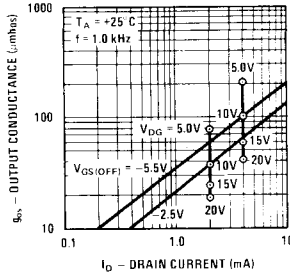
Forward Transmittance



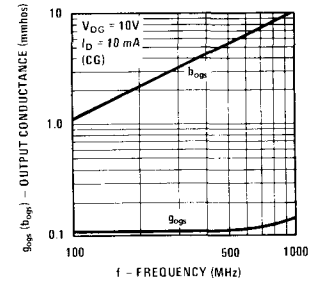
Common Drain-Source Characteristics



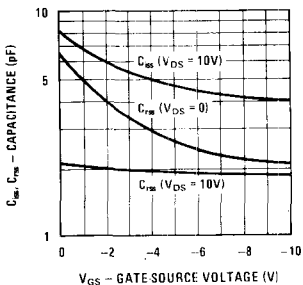
Output Conductance vs Drain Current



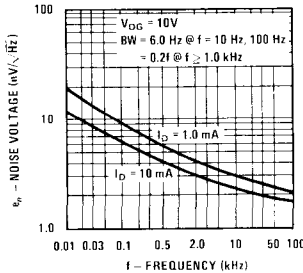
Output Admittance



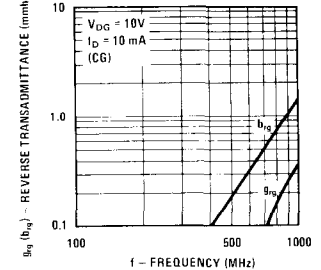
Capacitance vs Voltage



Noise Voltage vs Frequency

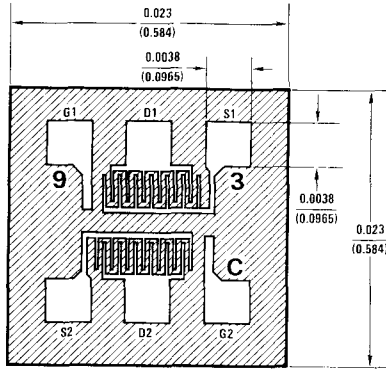


Reverse Transmittance





Process 93 N-Channel Monolithic Dual JFET



DESCRIPTION

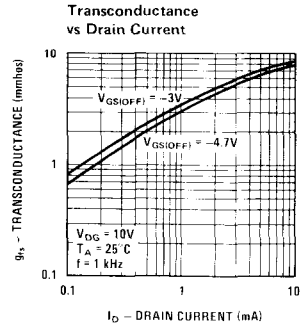
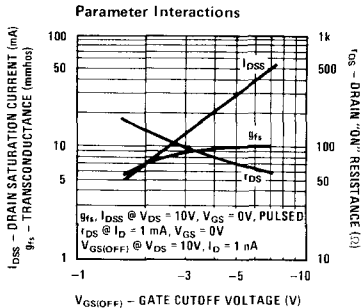
Process 93 is a monolithic dual JFET with a diode isolated substrate. It is intended for wide band, low noise, single ended video amplifier input stages, and high slew rate op amps. Monolithic structure eliminates thermal transient errors, and provides freedom to pick operating current and voltage.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|-----------------------|--|------|------|------|------------------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -25 | -30 | - | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 10V, V_{GS} = 0, \text{ Pulsed}$ | 3.0 | 18 | 40 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 10V, V_{GS} = 0, \text{ Pulsed}$ | - | 8.0 | - | mmhos |
| Forward Transconductance | g_{fs} | $V_{DG} = 10V, I_D = 5 \text{ mA}$ | 5.0 | 6.0 | 10 | mmhos |
| Output Conductance | g_{os} | $V_{DG} = 10V, I_D = 5 \text{ mA}$ | - | 50 | 100 | μmhos |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 10V, I_D = 1 \text{ nA}$ | -1.5 | -3.5 | -6.0 | V |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 \text{ mV}, V_{GS} = 0$ | - | 100 | - | Ω |
| Gate Current | I_G | $V_{DG} = 10V, I_D = 5 \text{ mA}$ | - | 10 | 100 | pA |
| Noise Voltage | e_n | $V_{DG} = 10V, I_D = 5 \text{ mA}, f = 100 \text{ Hz}$ | - | 9.0 | 30 | $nV/\sqrt{\text{Hz}}$ |
| Differential Match | $ V_{GS1} - V_{GS2} $ | $V_{DG} = 10V, I_D = 5 \text{ mA}$ | - | 9.0 | 30 | mV |
| Differential Match | ΔV_{GS1-2} | $V_{DG} = 10V, I_D = 5 \text{ mA}$ | - | 15 | 40 | $\mu\text{V}/^\circ\text{C}$ |
| Common Mode Rejection | CMRR | $V_{DG} = 10V, I_D = 5 \text{ mA}$ | - | 90 | - | dB |
| Feedback Capacitance | C_{rs} | $V_{DG} = 10V, I_D = 5 \text{ mA}, f = 1 \text{ MHz}$ | - | 1.0 | 1.2 | pF |
| Input Capacitance | C_{is} | $V_{DG} = 10V, I_D = 5 \text{ mA}, f = 1 \text{ MHz}$ | - | 4.2 | 5.0 | pF |

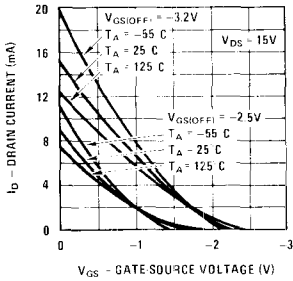
This process is available in the following device types. *Denotes preferred parts.

TO-78 (CASE 24)

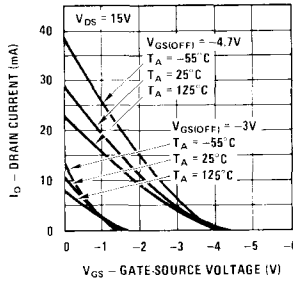
- *2N5911
- *2N5912
- U257



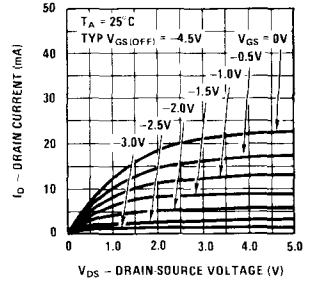
Transfer Characteristics



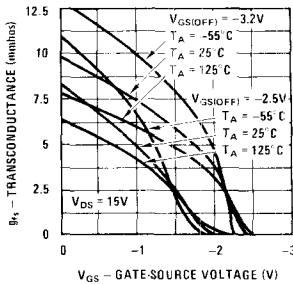
Transfer Characteristics



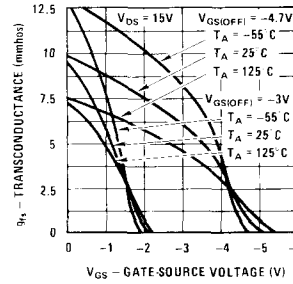
Common Drain-Source Characteristics



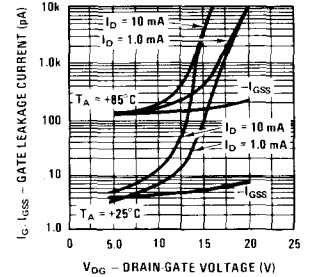
Transfer Characteristics



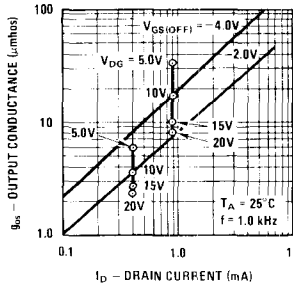
Transfer Characteristics



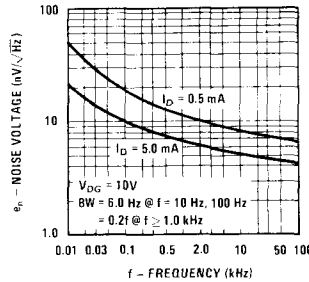
Leakage Current vs Voltage



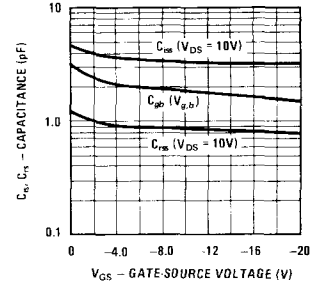
Output Conductance vs Drain Current



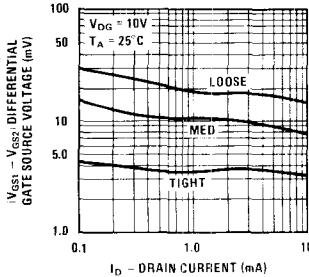
Noise Voltage vs Frequency



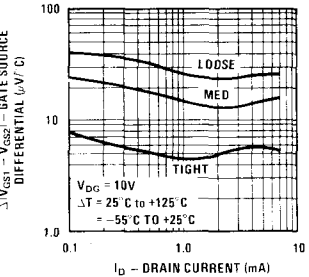
Capacitance vs Voltage



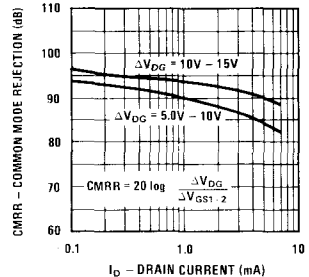
Differential Offset



Differential Drift

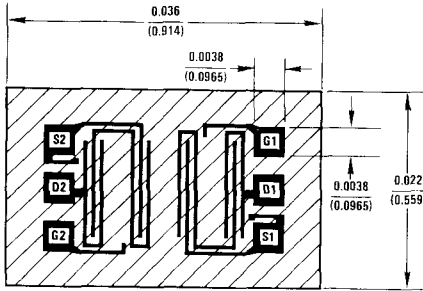


CMRR vs Drain Current





Process 94 N-Channel Monolithic Dual JFET



DESCRIPTION

Process 94 is a monolithic dual JFET. It is strictly intended for operational amplifier input buffer applications. Special processing results in extremely low input bias current and virtually unmeasurable offset current. It is important to note that the <5 pico ampere bias current is measured at 35 volts. Typical CMRR is 125 dB. Performance superior to electrometer tubes can be readily achieved with low offset voltage and almost zero long term drift.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|-----------------------|---|------|--------|------|------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -40 | -70 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 0.5 | 3.0 | 10 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 1.5 | 3.5 | 7.0 | mmho |
| Forward Transconductance | g_{fs} | $V_{DG} = 15V, I_D = 0.2 mA$ | 0.9 | 1.2 | 1.8 | mmhos |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 nA$ | -0.5 | -2.0 | -6.0 | V |
| Gate Current | I_G | $V_{DG} = 35V, I_D = 0.20 mA$ | | 1.0 | 15 | pA |
| Feedback Capacitance | C_{rss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | | 0.01 | 0.02 | pF |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 MHz$ | | 4.0 | 5.0 | pF |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 0.2 mA, f = 10 Hz$ | | 12 | 50 | nV/\sqrt{Hz} |
| Output Conductance | g_{os} | $V_{DG} = 15V, I_D = 0.2 mA$ | | <0.1 | | $\mu mhos$ |
| Differential Match | $ V_{GS1} - V_{GS2} $ | $V_{DG} = 15V, I_D = 0.2 mA$ | | 5.0 | 25 | mV |
| Differential Match | ΔV_{GS1-2} | $V_{DG} = 15V, I_D = 0.2 mA$ | | 6.0 | 50 | $\mu V/^\circ C$ |
| Common Mode Rejection | CMRR | $V_{DG} = 15V, I_D = 0.2 mA$ | | 125 | | dB |

This process is available in the following device types.

*Denotes preferred parts.

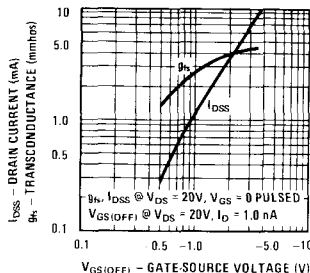
TO-71 (CASE 12)

- *NDF9406
- *NDF9407
- *NDF9408
- *NDF9409
- *NDF9410

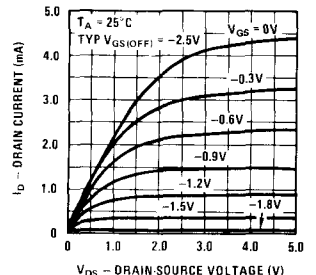
TO-78 (CASE 24)

- NDF9401
- NDF9402
- NDF9403
- NDF9404
- NDF9405

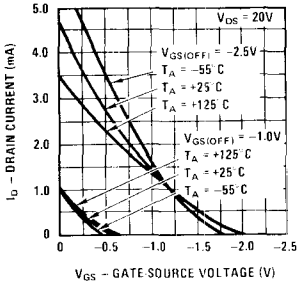
Parameter Interactions



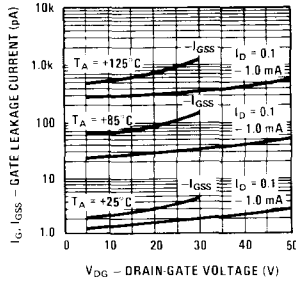
Common Drain-Source Characteristics



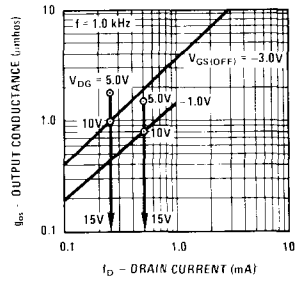
Transfer Characteristics



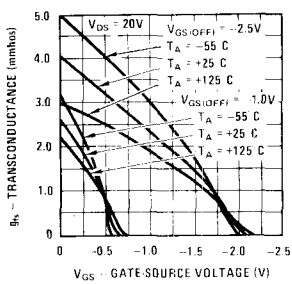
Leakage Current vs Voltage



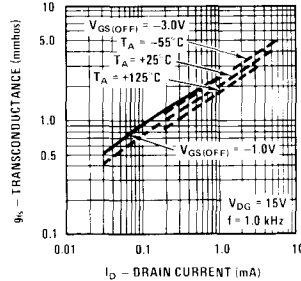
Output Conductance vs Drain Current



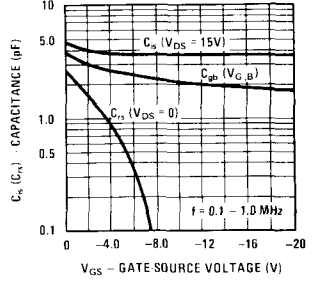
Transfer Characteristics



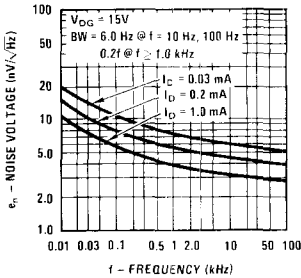
Transconductance vs Drain Current



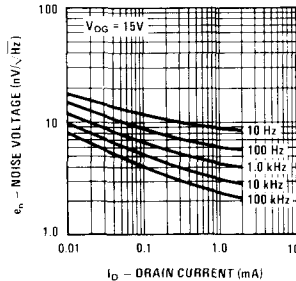
Capacitance vs Voltage



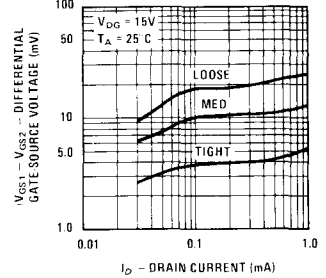
Noise Voltage vs Frequency



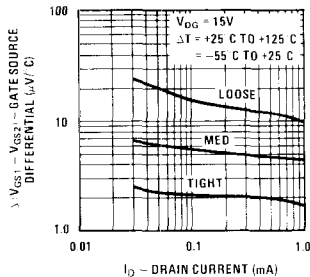
Noise Voltage vs Current



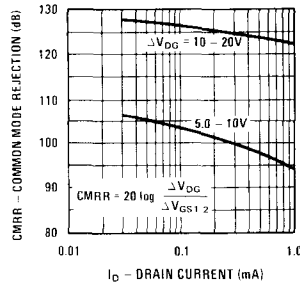
Differential Offset



Differential Drift



CMRR vs Drain Current

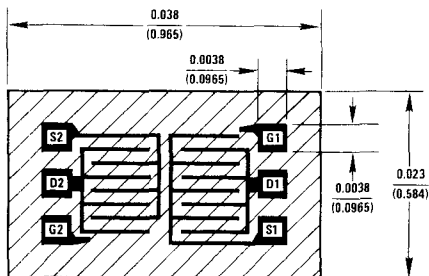




Process 95 N-Channel Monolithic Dual JFET

DESCRIPTION

Process 95 is a monolithic dual JFET with a diode isolated substrate. It is intended for operational amplifier input buffer applications. Processing results in low input bias current and virtually unmeasurable offset current. Low noise voltage and high CMRR for critical 1/f applications.



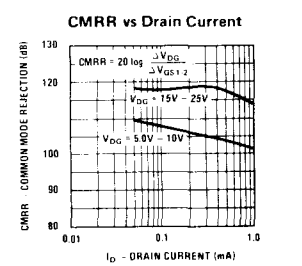
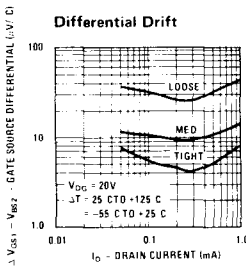
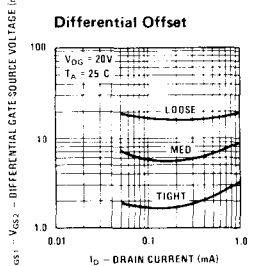
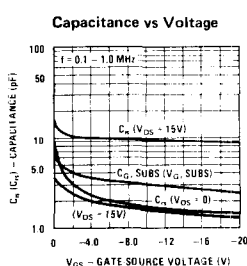
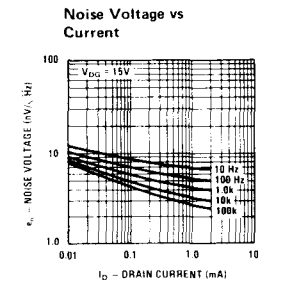
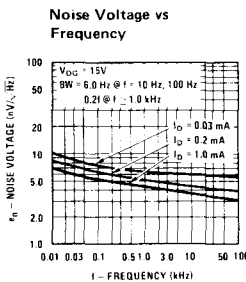
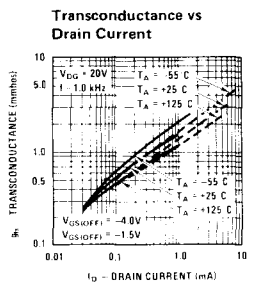
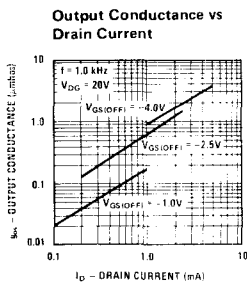
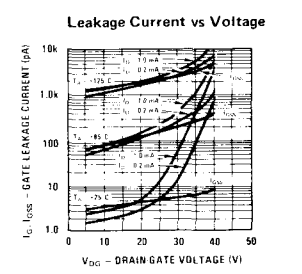
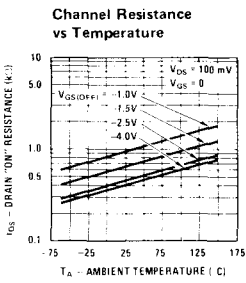
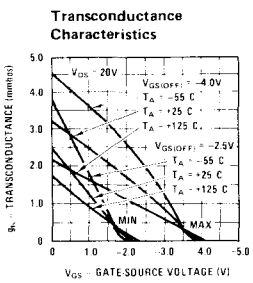
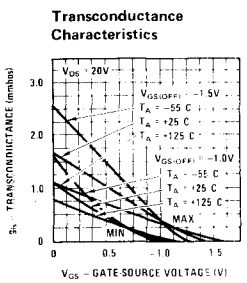
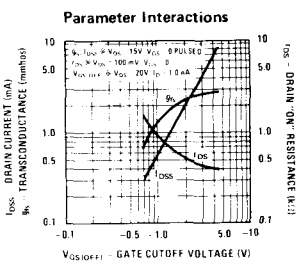
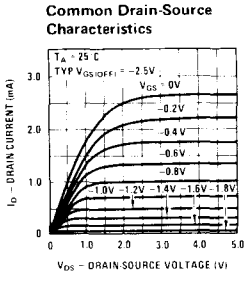
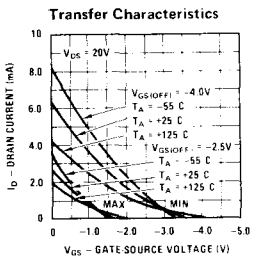
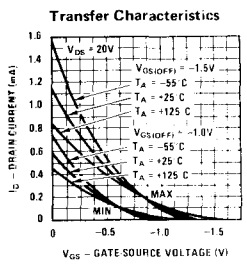
| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|-----------------------|--|------|------|------|------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -40 | -70 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 0.5 | 3.0 | 8.0 | mA |
| Forward Trans-conductance | g_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 1.0 | 2.5 | 4.0 | mmhos |
| Forward Trans-conductance | g_{fs} | $V_{DG} = 15V, I_D = 0.2 \text{ mA}$ | 0.5 | 0.7 | | mmhos |
| Gate Leakage | I_{GSS} | $V_{GS} = -20V, V_{DS} = 0$ | | -5.0 | -100 | pA |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 \text{ nA}$ | -0.5 | -2.5 | -4.0 | V |
| Input Capacitance | C_{rss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 \text{ MHz}$ | | 10 | 14 | pF |
| Noise Voltage | e_n | $V_{DS} = 15V, I_D = 0.2 \text{ mA}, f = 10 \text{ Hz}$ | | 8.0 | 30 | nV/\sqrt{Hz} |
| Noise Voltage | e_n | $V_{DS} = 15V, I_D = 0.2 \text{ mA}, f = 100 \text{ Hz}$ | | 6.0 | 10 | nV/\sqrt{Hz} |
| Output Conductance | g_{os} | $V_{DG} = 15V, I_D = 0.2 \text{ mA}$ | | 0.3 | 1.0 | μmhos |
| Feedback Capacitance | C_{rss} | $V_{DS} = 15V, V_{GS} = 0, f = 1 \text{ MHz}$ | | 3.5 | 5.0 | pF |
| Differential Match | $ V_{GS1} - V_{GS2} $ | $V_{DG} = 20V, I_D = 0.2 \text{ mA}$ | | 6.0 | 25 | mV |
| Differential Match | ΔV_{GS1-2} | $V_{DG} = 20V, I_D = 0.2 \text{ mA}$ | | 9.0 | 60 | $\mu V/^\circ C$ |
| Common Mode Rejection | CMRR | $V_{DG} = 20V, I_D = 0.2 \text{ mA}$ | 86 | 115 | | dB |

This process is available in the following device types. *Denotes preferred parts.

TO-71 (CASE 12)

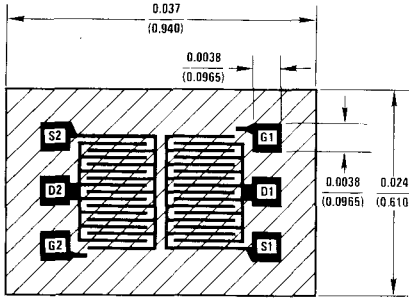
- 2N5515 *2N5522
- 2N5516 *2N5523
- 2N5517 *2N5524
- 2N5518 *2N6483
- 2N5519 *2N6484
- *2N5520 *2N6485
- *2N5521

Process 95





Process 96 N-Channel Monolithic Dual JFET



DESCRIPTION

Process 96 is a monolithic dual JFET with a diode isolated substrate. It is intended for wide band, low noise, single ended video amplifier input stages. Also ideal for matched voltage variable resistor applications over 60 dB tracking range.

| CHARACTERISTIC | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------------------------|-----------------------|--|-----|------|------|------------------|
| Gate-Source Breakdown Voltage | BV_{GSS} | $V_{DS} = 0V, I_G = -1 \mu A$ | -40 | -55 | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 15V, V_{GS} = 0$ | 5.0 | 15 | 30 | mA |
| Forward Transconductance | g_{fs} | $V_{DS} = 15V, V_{GS} = 0$ | 9.0 | 18 | 30 | mmhos |
| Forward Transconductance | g_{fs} | $V_{DG} = 15V, I_D = 2 mA$ | 7.5 | 9.0 | | mmhos |
| Output Conductance | g_{os} | $V_{DG} = 15V, I_D = 2 mA$ | | 15 | 45 | $\mu mhos$ |
| Pinch Off Voltage | $V_{GS(OFF)}$ | $V_{DS} = 15V, I_D = 1 nA$ | | -1.8 | -3.0 | V |
| "ON" Resistance | r_{DS} | $V_{DS} = 100 mV, V_{GS} = 0$ | 35 | 70 | 120 | Ω |
| Gate Current | I_{GSS} | $V_{GS} = -20V, V_{DS} = 0$ | | -8.0 | -100 | pA |
| Gate Current | I_G | $V_{DG} = 15V, I_D = 2 mA$ | | 15 | 200 | pA |
| Noise Voltage | e_n | $V_{DG} = 15V, I_D = 2 mA, f = 100 Hz$ | | 4.5 | 10 | nV/\sqrt{Hz} |
| Feedback Capacitance | C_{rs} | $V_{DG} = 15V, I_D = 2 mA, f = 1 MHz$ | | 2.5 | 3.0 | pF |
| Input Capacitance | C_{is} | $V_{DG} = 15V, I_D = 2 mA, f = 1 MHz$ | | 10 | 12 | pF |
| Differential Voltage | $ V_{GS1} - V_{GS2} $ | $V_{DG} = 15V, I_D = 2 mA$ | | 8.0 | 25 | mV |
| Differential Voltage | ΔV_{GS} | $V_{DG} = 15V, I_D = 2 mA$ | | 9.0 | 50 | $\mu V/^\circ C$ |
| Common Mode Rejection | CMRR | $V_{DG} = 15V, I_D = 2 mA$ | 76 | 95 | | dB |

This process is available in the following device types. *Denotes preferred parts.

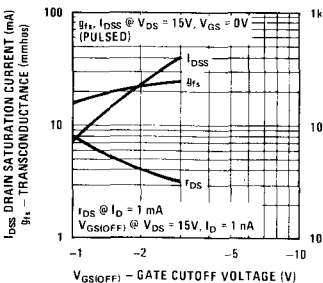
TO-71 (CASE 12)

- *2N5564
- *2N5565
- *2N5566

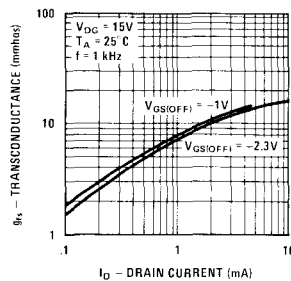
8-Pin DIP (CASE 67)

- *NPD5564
- *NPD5565
- *NPD5566

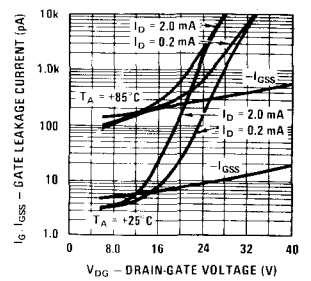
Parameter Interactions



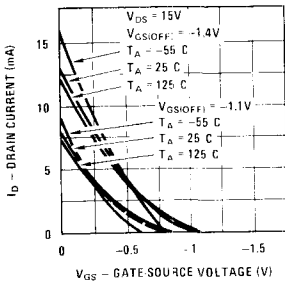
Transconductance vs Drain Current



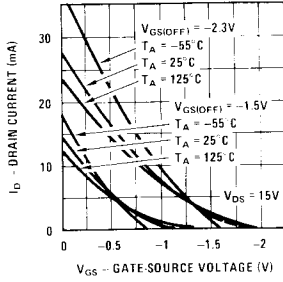
Leakage Current vs Voltage



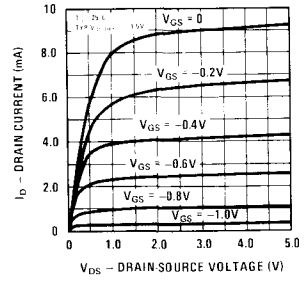
Transfer Characteristics



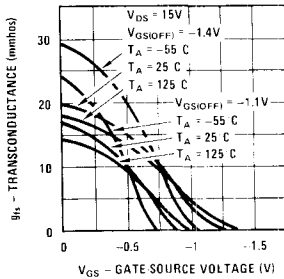
Transfer Characteristics



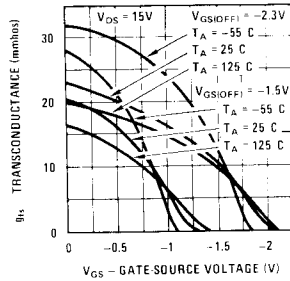
Common Drain-Source Characteristics



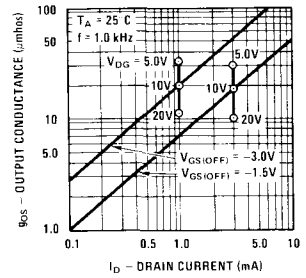
Transfer Characteristics



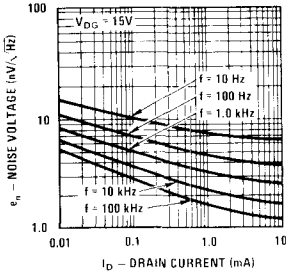
Transfer Characteristics



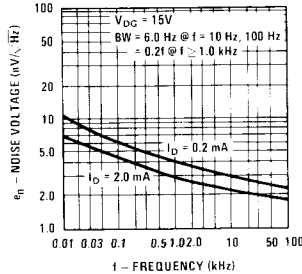
Output Conductance vs Drain Current



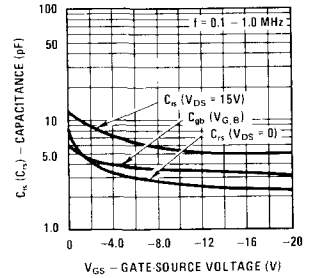
Noise Voltage vs Current



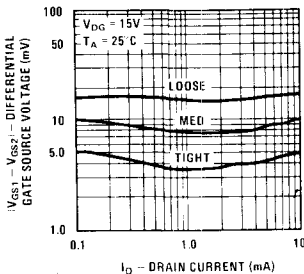
Noise Voltage vs Frequency



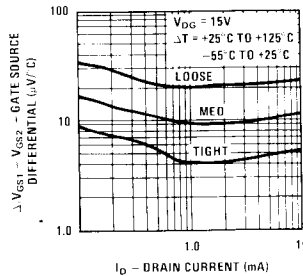
Capacitance vs Voltage



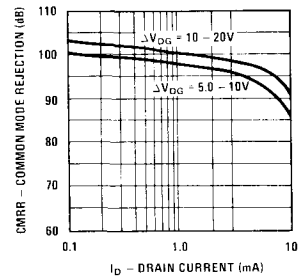
Differential Offset



Differential Drift



CMRR vs Drain Current





Process 98 N-Channel JFET

DESCRIPTION

Process 98 is a high gain, general purpose, monolithic dual JFET with a diode isolated substrate. It is intended for amplifier input stages requiring high gain, low noise and low offset drift over temperature. Strict processing controls result in low input bias currents and virtually immeasurable offset currents. Matching characteristics are essentially independent of operating current and voltage.

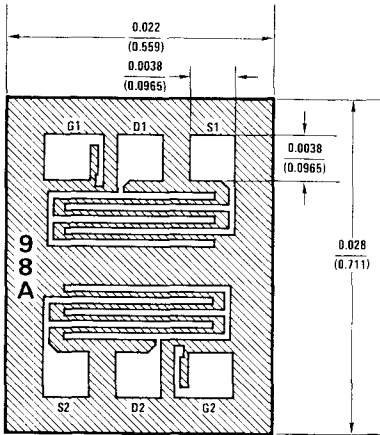
This process is available in the following device types.
 *Denotes preferred parts.

TO-71 (CASE 12)

- 2N5561
- 2N5562
- 2N5563
- U401
- U402
- U403
- U404
- U405
- U406

8-Pin DIP (CASE 60)

- J401
- J402
- J403
- J404
- J405
- J406



PROCESS IN DEVELOPMENT

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